

32-bit Arm<sup>®</sup> Cortex<sup>®</sup>-M7 480MHz MCUs, 2MB flash, 1MB RAM, 46 com. and analog interfaces, crypto

Datasheet - production data

## Features

Includes ST state-of-the-art patented technology

### Core

- 32-bit Arm<sup>®</sup> Cortex<sup>®</sup>-M7 core with double-precision FPU and L1 cache: 16 Kbytes of data and 16 Kbytes of instruction cache; frequency up to 480 MHz, MPU, 1027 DMIPS/2.14 DMIPS/MHz (Dhystone 2.1), and DSP instructions

### Memories

- 2 Mbytes of flash memory with read-while-write support
- 1 Mbyte of RAM: 192 Kbytes of TCM RAM (inc. 64 Kbytes of ITCM RAM + 128 Kbytes of DTCM RAM for time critical routines), 864 Kbytes of user SRAM, and 4 Kbytes of SRAM in Backup domain
- Dual mode Quad-SPI memory interface running up to 133 MHz
- Flexible external memory controller with up to 32-bit data bus: SRAM, PSRAM, SDRAM/LPDDR SDRAM, NOR/NAND flash memory clocked up to 100 MHz in Synchronous mode
- CRC calculation unit

### Security

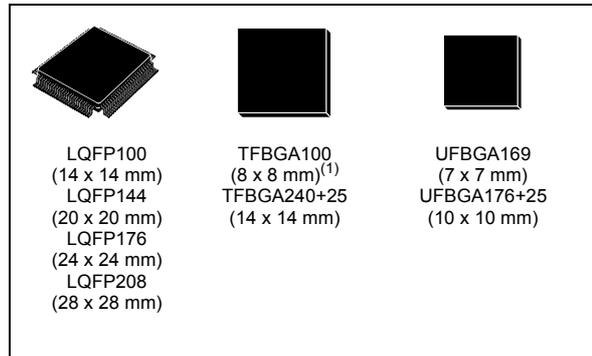
- ROP, PC-ROP, active tamper, secure firmware upgrade support, Secure access mode

### General-purpose input/outputs

- Up to 168 I/O ports with interrupt capability

### Reset and power management

- 3 separate power domains which can be independently clock-gated or switched off:
  - D1: high-performance capabilities



- D2: communication peripherals and timers
- D3: reset/clock control/power management

- 1.62 to 3.6 V application supply and I/Os
- POR, PDR, PVD and BOR
- Dedicated USB power embedding a 3.3 V internal regulator to supply the internal PHYs
- Embedded regulator (LDO) with configurable scalable output to supply the digital circuitry
- Voltage scaling in Run and Stop mode (6 configurable ranges)
- Backup regulator (~0.9 V)
- Voltage reference for analog peripheral/V<sub>REF+</sub>
- Low-power modes: Sleep, Stop, Standby and V<sub>BAT</sub> supporting battery charging

### Low-power consumption

- V<sub>BAT</sub> battery operating mode with charging capability
- CPU and domain power state monitoring pins
- 2.95 µA in Standby mode (Backup SRAM OFF, RTC/LSE ON)

### Clock management

- Internal oscillators: 64 MHz HSI, 48 MHz HSI48, 4 MHz CSI, 32 kHz LSI
- External oscillators: 4-48 MHz HSE, 32.768 kHz LSE
- 3× PLLs (1 for the system clock, 2 for kernel clocks) with Fractional mode

### Interconnect matrix

- 3 bus matrices (1 AXI and 2 AHB)
- Bridges (5× AHB2-APB, 2× AXI2-AHB)

### 4 DMA controllers to unload the CPU

- 1× high-speed master direct memory access controller (MDMA) with linked list support
- 2× dual-port DMAs with FIFO
- 1× basic DMA with request router capabilities

### Up to 35 communication peripherals

- 4× I2Cs FM+ interfaces (SMBus/PMBus)
- 4× USARTs/4x UARTs/1LPUART (ISO7816 interface, LIN, IrDA, up to 12.5 Mbit/s)
- 6 SPI (+1 with Quad-SPI + 4 with USART): 3 with muxed duplex I2S audio class accuracy via internal audio PLL or external clock, 1× I2S in LP domain (up to 150 MHz) and up to 4 additional SPI from 4 USART/UART when configured in synchronous mode.
- SPDIFRX interface
- SWPMI single-wire protocol master I/F
- MDIO Slave interface
- 2× SD/SDIO/MMC interfaces (up to 125 MHz)
- 2× CAN controllers: 2 with CAN FD, 1 with time-triggered CAN (TT-CAN)
- 2× USB OTG interfaces (1FS, 1HS/FS) crystal-less solution with LPM and BCD
- Ethernet MAC interface with DMA controller
- HDMI-CEC
- 8- to 14-bit camera interface (up to 80 MHz)

### 11 analog peripherals

- 3× ADCs with 16-bit max. resolution (up to 36 channels, up to 3.6 MSPS)
- 1× temperature sensor
- 2× 12-bit D/A converters (1 MHz)
- 2× ultra-low-power comparators
- 2× operational amplifiers (7.3 MHz bandwidth)
- 1× digital filters for sigma delta modulator (DFSDM) with 8 channels/4 filters

### Graphics

- LCD-TFT controller up to XGA resolution
- Chrom-ART graphical hardware Accelerator (DMA2D) to reduce CPU load

- Hardware JPEG Codec

### Up to 22 timers and watchdogs

- 1× high-resolution timer (2.1 ns max resolution)
- 2× 32-bit timers with up to 4 IC/OC/PWM or pulse counter and quadrature (incremental) encoder input (up to 240 MHz)
- 2× 16-bit advanced motor control timers (up to 240 MHz)
- 10× 16-bit general-purpose timers (up to 240 MHz)
- 5× 16-bit low-power timers (up to 240 MHz)
- 2× watchdogs (independent and window)
- 1× SysTick timer
- RTC with sub-second accuracy and hardware calendar

### Cryptographic acceleration

- AES 128, 192, 256, TDES
- HASH (MD5, SHA-1, SHA-2), HMAC
- True random number generators

### Debug mode

- SWD & JTAG interfaces
- 4-Kbyte embedded trace buffer

### 96-bit unique ID

### All packages are ECOPACK2 compliant

Table 1. Device summary

| Reference   | Part number  |
|-------------|--|
| STM32H753xI | STM32H753VI, STM32H753ZI, STM32H753II, STM32H753BI, STM32H753XI, STM32H753AI |

# Contents

|          |  |           |
|----------|--|-----------|
| <b>1</b> | <b>Introduction</b> .....                            | <b>17</b> |
| <b>2</b> | <b>Description</b> .....                             | <b>18</b> |
| <b>3</b> | <b>Functional overview</b> .....                     | <b>24</b> |
| 3.1      | Arm® Cortex®-M7 with FPU .....                       | 24        |
| 3.2      | Memory protection unit (MPU) .....                   | 24        |
| 3.3      | Memories .....                                       | 25        |
| 3.3.1    | Embedded flash memory .....                          | 25        |
| 3.3.2    | Secure access mode .....                             | 25        |
| 3.3.3    | Embedded SRAM .....                                  | 26        |
| 3.4      | Boot modes .....                                     | 26        |
| 3.5      | Power supply management .....                        | 27        |
| 3.5.1    | Power supply scheme .....                            | 27        |
| 3.5.2    | Power supply supervisor .....                        | 28        |
| 3.5.3    | Voltage regulator .....                              | 29        |
| 3.6      | Low-power strategy .....                             | 29        |
| 3.7      | Reset and clock controller (RCC) .....               | 30        |
| 3.7.1    | Clock management .....                               | 30        |
| 3.7.2    | System reset sources .....                           | 31        |
| 3.8      | General-purpose input/outputs (GPIOs) .....          | 31        |
| 3.9      | Bus-interconnect matrix .....                        | 31        |
| 3.10     | DMA controllers .....                                | 33        |
| 3.11     | Chrom-ART Accelerator (DMA2D) .....                  | 33        |
| 3.12     | Nested vectored interrupt controller (NVIC) .....    | 34        |
| 3.13     | Extended interrupt and event controller (EXTI) ..... | 34        |
| 3.14     | Cyclic redundancy check calculation unit (CRC) ..... | 34        |
| 3.15     | Flexible memory controller (FMC) .....               | 35        |
| 3.16     | Quad-SPI memory interface (QUADSPI) .....            | 35        |
| 3.17     | Analog-to-digital converters (ADCs) .....            | 35        |
| 3.18     | Temperature sensor .....                             | 36        |
| 3.19     | V <sub>BAT</sub> operation .....                     | 36        |

|        |   |    |
|--------|---|----|
| 3.20   | Digital-to-analog converters (DAC)  | 37 |
| 3.21   | Ultra-low-power comparators (COMP)  | 37 |
| 3.22   | Operational amplifiers (OPAMP)  | 37 |
| 3.23   | Digital filter for sigma-delta modulators (DFSDM)                                   | 38 |
| 3.24   | Digital camera interface (DCMI)   | 39 |
| 3.25   | LCD-TFT controller  | 40 |
| 3.26   | JPEG Codec (JPEG)   | 40 |
| 3.27   | True random number generator (RNG)  | 40 |
| 3.28   | Cryptographic acceleration (CRYP and HASH)  | 41 |
| 3.29   | Timers and watchdogs  | 41 |
| 3.29.1 | High-resolution timer (HRTIM1)  | 43 |
| 3.29.2 | Advanced-control timers (TIM1, TIM8)  | 44 |
| 3.29.3 | General-purpose timers (TIMx)   | 44 |
| 3.29.4 | Basic timers TIM6 and TIM7  | 45 |
| 3.29.5 | Low-power timers (LPTIM1, LPTIM2, LPTIM3, LPTIM4, LPTIM5)                           | 45 |
| 3.29.6 | Independent watchdog  | 45 |
| 3.29.7 | Window watchdog   | 45 |
| 3.29.8 | SysTick timer   | 45 |
| 3.30   | Real-time clock (RTC), backup SRAM and backup registers                             | 46 |
| 3.31   | Inter-integrated circuit interface (I <sup>2</sup> C)                               | 47 |
| 3.32   | Universal synchronous/asynchronous receiver transmitter (USART)                     | 47 |
| 3.33   | Low-power universal asynchronous receiver transmitter (LPUART)                      | 48 |
| 3.34   | Serial peripheral interfaces (SPI)/integrated interchip<br>sound interfaces (I2S)   | 49 |
| 3.35   | Serial audio interfaces (SAI)   | 49 |
| 3.36   | SPDIFRX Receiver Interface (SPDIFRX)  | 50 |
| 3.37   | Single wire protocol master interface (SWPMI)                                       | 50 |
| 3.38   | Management Data Input/Output (MDIO) slaves  | 51 |
| 3.39   | SD/SDIO/MMC card host interfaces (SDMMC)  | 51 |
| 3.40   | Controller area network (FDCAN1, FDCAN2)  | 51 |
| 3.41   | Universal serial bus on-the-go high-speed (OTG_HS)                                  | 52 |
| 3.42   | Ethernet MAC interface with dedicated DMA controller (ETH)                          | 52 |
| 3.43   | High-definition multimedia interface (HDMI)<br>- consumer electronics control (CEC) | 53 |
| 3.44   | Debug infrastructure  | 53 |

|          |  |            |
|----------|--|------------|
| <b>4</b> | <b>Memory mapping</b>                                  | <b>54</b>  |
| <b>5</b> | <b>Pinout, pin description and alternate functions</b> | <b>55</b>  |
| <b>6</b> | <b>Electrical characteristics (rev Y)</b>              | <b>101</b> |
| 6.1      | Parameter conditions                                   | 101        |
| 6.1.1    | Minimum and maximum values                             | 101        |
| 6.1.2    | Typical values   | 101        |
| 6.1.3    | Typical curves   | 101        |
| 6.1.4    | Loading capacitor                                      | 101        |
| 6.1.5    | Pin input voltage                                      | 101        |
| 6.1.6    | Power supply scheme                                    | 102        |
| 6.1.7    | Current consumption measurement                        | 103        |
| 6.2      | Absolute maximum ratings                               | 103        |
| 6.3      | Operating conditions                                   | 105        |
| 6.3.1    | General operating conditions                           | 105        |
| 6.3.2    | VCAP external capacitor                                | 106        |
| 6.3.3    | Operating conditions at power-up / power-down          | 106        |
| 6.3.4    | Embedded reset and power control block characteristics | 107        |
| 6.3.5    | Embedded reference voltage                             | 108        |
| 6.3.6    | Supply current characteristics                         | 109        |
| 6.3.7    | Wakeup time from low-power modes                       | 122        |
| 6.3.8    | External clock source characteristics                  | 123        |
| 6.3.9    | Internal clock source characteristics                  | 127        |
| 6.3.10   | PLL characteristics                                    | 129        |
| 6.3.11   | Memory characteristics                                 | 131        |
| 6.3.12   | EMC characteristics                                    | 133        |
| 6.3.13   | Absolute maximum ratings (electrical sensitivity)      | 135        |
| 6.3.14   | I/O current injection characteristics                  | 135        |
| 6.3.15   | I/O port characteristics                               | 136        |
| 6.3.16   | NRST pin characteristics                               | 144        |
| 6.3.17   | FMC characteristics                                    | 145        |
| 6.3.18   | Quad-SPI interface characteristics                     | 164        |
| 6.3.19   | Delay block (DLYB) characteristics                     | 166        |
| 6.3.20   | 16-bit ADC characteristics                             | 166        |
| 6.3.21   | DAC electrical characteristics                         | 171        |
| 6.3.22   | Voltage reference buffer characteristics               | 174        |

|          |   |            |
|----------|---|------------|
| 6.3.23   | Temperature sensor characteristics                                | 175        |
| 6.3.24   | Temperature and $V_{BAT}$ monitoring                              | 176        |
| 6.3.25   | Voltage booster for analog switch                                 | 176        |
| 6.3.26   | Comparator characteristics  | 177        |
| 6.3.27   | Operational amplifier characteristics                             | 178        |
| 6.3.28   | Digital filter for Sigma-Delta Modulators (DFSDM) characteristics | 181        |
| 6.3.29   | Camera interface (DCMI) timing specifications                     | 184        |
| 6.3.30   | LCD-TFT controller (LTDC) characteristics                         | 185        |
| 6.3.31   | Timer characteristics   | 187        |
| 6.3.32   | Communications interfaces   | 188        |
| 6.3.33   | JTAG/SWD interface characteristics                                | 202        |
| <b>7</b> | <b>Electrical characteristics (rev V)</b>                         | <b>205</b> |
| 7.1      | Parameter conditions  | 205        |
| 7.1.1    | Minimum and maximum values  | 205        |
| 7.1.2    | Typical values  | 205        |
| 7.1.3    | Typical curves  | 205        |
| 7.1.4    | Loading capacitor   | 205        |
| 7.1.5    | Pin input voltage   | 205        |
| 7.1.6    | Power supply scheme   | 206        |
| 7.1.7    | Current consumption measurement                                   | 207        |
| 7.2      | Absolute maximum ratings  | 207        |
| 7.3      | Operating conditions  | 209        |
| 7.3.1    | General operating conditions                                      | 209        |
| 7.3.2    | VCAP external capacitor   | 211        |
| 7.3.3    | Operating conditions at power-up / power-down                     | 211        |
| 7.3.4    | Embedded reset and power control block characteristics            | 212        |
| 7.3.5    | Embedded reference voltage  | 213        |
| 7.3.6    | Supply current characteristics                                    | 214        |
| 7.3.7    | Wakeup time from low-power modes                                  | 226        |
| 7.3.8    | External clock source characteristics                             | 227        |
| 7.3.9    | Internal clock source characteristics                             | 231        |
| 7.3.10   | PLL characteristics   | 234        |
| 7.3.11   | Memory characteristics  | 236        |
| 7.3.12   | EMC characteristics   | 237        |
| 7.3.13   | Absolute maximum ratings (electrical sensitivity)                 | 239        |
| 7.3.14   | I/O current injection characteristics                             | 240        |

|           |   |            |
|-----------|---|------------|
| 7.3.15    | I/O port characteristics  | 241        |
| 7.3.16    | NRST pin characteristics  | 248        |
| 7.3.17    | FMC characteristics   | 248        |
| 7.3.18    | Quad-SPI interface characteristics                                | 269        |
| 7.3.19    | Delay block (DLYB) characteristics                                | 272        |
| 7.3.20    | 16-bit ADC characteristics  | 272        |
| 7.3.21    | DAC characteristics   | 281        |
| 7.3.22    | Voltage reference buffer characteristics                          | 285        |
| 7.3.23    | Temperature sensor characteristics                                | 286        |
| 7.3.24    | Temperature and V <sub>BAT</sub> monitoring                       | 287        |
| 7.3.25    | Voltage booster for analog switch                                 | 287        |
| 7.3.26    | Comparator characteristics  | 288        |
| 7.3.27    | Operational amplifier characteristics                             | 289        |
| 7.3.28    | Digital filter for Sigma-Delta Modulators (DFSDM) characteristics | 291        |
| 7.3.29    | Camera interface (DCMI) timing specifications                     | 294        |
| 7.3.30    | LCD-TFT controller (LTDC) characteristics                         | 295        |
| 7.3.31    | Timer characteristics   | 297        |
| 7.3.32    | Communication interfaces  | 297        |
| <b>8</b>  | <b>Package information</b>  | <b>317</b> |
| 8.1       | Device marking  | 317        |
| 8.2       | LQFP100 package information (1L)                                  | 318        |
| 8.3       | TFBGA100 package information (A08Q)                               | 320        |
| 8.4       | LQFP144 package information (1A)                                  | 324        |
| 8.5       | UFBGA169 package information (A0YV)                               | 327        |
| 8.6       | LQFP176 package information (1T)                                  | 331        |
| 8.7       | LQFP208 package information (UH)                                  | 335        |
| 8.8       | UFBGA(176+25) package information (A0E7)                          | 338        |
| 8.9       | TFBGA240+25 package information (A07U)                            | 340        |
| 8.10      | Thermal characteristics   | 343        |
| 8.10.1    | Reference documents   | 345        |
| <b>9</b>  | <b>Ordering information</b>                                       | <b>346</b> |
| <b>10</b> | <b>Important security notice</b>                                  | <b>347</b> |

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|           |                               |            |
|-----------|-------------------------------|------------|
| <b>11</b> | <b>Revision history .....</b> | <b>348</b> |
|-----------|-------------------------------|------------|

## List of tables

|           |  |     |
|-----------|--|-----|
| Table 1.  | Device summary . . . . .   | 2   |
| Table 2.  | STM32H753xl features and peripheral counts . . . . .   | 20  |
| Table 3.  | System vs domain low-power mode . . . . .  | 30  |
| Table 4.  | DFSDM implementation . . . . .   | 39  |
| Table 5.  | Timer feature comparison . . . . .   | 41  |
| Table 6.  | USART features . . . . .   | 48  |
| Table 7.  | Legend/abbreviations used in the pinout table . . . . .  | 63  |
| Table 8.  | Pin/ball definition . . . . .  | 64  |
| Table 9.  | Alternate functions . . . . .  | 89  |
| Table 10. | Voltage characteristics . . . . .  | 103 |
| Table 11. | Current characteristics . . . . .  | 104 |
| Table 12. | Thermal characteristics . . . . .  | 104 |
| Table 13. | General operating conditions . . . . .   | 105 |
| Table 14. | VCAP operating conditions . . . . .  | 106 |
| Table 15. | Operating conditions at power-up / power-down (regulator ON) . . . . .   | 106 |
| Table 16. | Reset and power control block characteristics . . . . .  | 107 |
| Table 17. | Embedded reference voltage . . . . .   | 108 |
| Table 18. | Internal reference voltage calibration values . . . . .  | 109 |
| Table 19. | Typical and maximum current consumption in Run mode, code with data processing<br>running from ITCM, regulator ON . . . . .                    | 110 |
| Table 20. | Typical and maximum current consumption in Run mode, code with data processing<br>running from flash memory, cache ON, regulator ON . . . . .  | 111 |
| Table 21. | Typical and maximum current consumption in Run mode, code with data processing<br>running from flash memory, cache OFF, regulator ON . . . . . | 111 |
| Table 22. | Typical consumption in Run mode and corresponding performance<br>versus code position . . . . .  | 112 |
| Table 23. | Typical current consumption batch acquisition mode . . . . .   | 112 |
| Table 24. | Typical and maximum current consumption in Sleep mode, regulator ON . . . . .  | 112 |
| Table 25. | Typical and maximum current consumption in Stop mode, regulator ON . . . . .   | 113 |
| Table 26. | Typical and maximum current consumption in Standby mode . . . . .  | 113 |
| Table 27. | Typical and maximum current consumption in VBAT mode . . . . .   | 114 |
| Table 28. | Peripheral current consumption in Run mode . . . . .   | 116 |
| Table 29. | Peripheral current consumption in Stop, Standby and VBAT mode . . . . .  | 121 |
| Table 30. | Low-power mode wakeup timings . . . . .  | 122 |
| Table 31. | High-speed external user clock characteristics . . . . .   | 123 |
| Table 32. | Low-speed external user clock characteristics . . . . .  | 124 |
| Table 33. | 4-48 MHz HSE oscillator characteristics . . . . .  | 125 |
| Table 34. | Low-speed external user clock characteristics . . . . .  | 126 |
| Table 35. | HSI48 oscillator characteristics . . . . .   | 127 |
| Table 36. | HSI oscillator characteristics . . . . .   | 128 |
| Table 37. | CSI oscillator characteristics . . . . .   | 128 |
| Table 38. | LSI oscillator characteristics . . . . .   | 129 |
| Table 39. | PLL characteristics (wide VCO frequency range) . . . . .   | 129 |
| Table 40. | PLL characteristics (medium VCO frequency range) . . . . .   | 130 |
| Table 41. | Flash memory characteristics . . . . .   | 131 |
| Table 42. | Flash memory programming . . . . .   | 132 |
| Table 43. | Flash memory endurance and data retention . . . . .  | 132 |
| Table 44. | EMS characteristics . . . . .  | 133 |

|           |   |     |
|-----------|---|-----|
| Table 45. | EMI characteristics for fHSE = 8 MHz and fCPU = 400 MHz                     | 134 |
| Table 46. | ESD absolute maximum ratings  | 135 |
| Table 47. | Electrical sensitivities  | 135 |
| Table 48. | I/O current injection susceptibility  | 136 |
| Table 49. | I/O static characteristics  | 136 |
| Table 50. | Output voltage characteristics for all I/Os except PC13, PC14, PC15 and PI8 | 139 |
| Table 51. | Output voltage characteristics for PC13, PC14, PC15 and PI8                 | 140 |
| Table 52. | Output timing characteristics (HSLV OFF)                                    | 141 |
| Table 53. | Output timing characteristics (HSLV ON)                                     | 143 |
| Table 54. | NRST pin characteristics  | 144 |
| Table 55. | Asynchronous non-multiplexed SRAM/PSRAM/NOR read timings                    | 147 |
| Table 56. | Asynchronous non-multiplexed SRAM/PSRAM/NOR read - NWAIT timings            | 147 |
| Table 57. | Asynchronous non-multiplexed SRAM/PSRAM/NOR write timings                   | 148 |
| Table 58. | Asynchronous non-multiplexed SRAM/PSRAM/NOR write - NWAIT timings           | 149 |
| Table 59. | Asynchronous multiplexed PSRAM/NOR read timings                             | 150 |
| Table 60. | Asynchronous multiplexed PSRAM/NOR read-NWAIT timings                       | 150 |
| Table 61. | Asynchronous multiplexed PSRAM/NOR write timings                            | 151 |
| Table 62. | Asynchronous multiplexed PSRAM/NOR write-NWAIT timings                      | 152 |
| Table 63. | Synchronous multiplexed NOR/PSRAM read timings                              | 154 |
| Table 64. | Synchronous multiplexed PSRAM write timings                                 | 156 |
| Table 65. | Synchronous non-multiplexed NOR/PSRAM read timings                          | 157 |
| Table 66. | Synchronous non-multiplexed PSRAM write timings                             | 158 |
| Table 67. | Switching characteristics for NAND flash read cycles                        | 160 |
| Table 68. | Switching characteristics for NAND flash write cycles                       | 160 |
| Table 69. | SDRAM read timings  | 161 |
| Table 70. | LPSDR SDRAM read timings  | 162 |
| Table 71. | SDRAM write timings   | 163 |
| Table 72. | LPSDR SDRAM write timings   | 163 |
| Table 73. | QUADSPI characteristics in SDR mode   | 164 |
| Table 74. | QUADSPI characteristics in DDR mode   | 165 |
| Table 75. | Dynamics characteristics: Delay Block characteristics                       | 166 |
| Table 76. | ADC characteristics   | 166 |
| Table 77. | ADC accuracy  | 168 |
| Table 78. | DAC characteristics   | 171 |
| Table 79. | DAC accuracy  | 172 |
| Table 80. | VREFBUF characteristics   | 174 |
| Table 81. | Temperature sensor characteristics  | 175 |
| Table 82. | Temperature sensor calibration values                                       | 175 |
| Table 83. | V <sub>BAT</sub> monitoring characteristics                                 | 176 |
| Table 84. | V <sub>BAT</sub> charging characteristics                                   | 176 |
| Table 85. | Temperature monitoring characteristics                                      | 176 |
| Table 86. | Voltage booster for analog switch characteristics                           | 176 |
| Table 87. | COMP characteristics  | 177 |
| Table 88. | OPAMP characteristics   | 178 |
| Table 89. | DFSDM measured timing - 1.62-3.6 V  | 181 |
| Table 90. | DCMI characteristics  | 184 |
| Table 91. | LTDC characteristics  | 185 |
| Table 92. | TIMx characteristics  | 187 |
| Table 93. | Minimum i2c_ker_ck frequency in all I2C modes                               | 188 |
| Table 94. | I2C analog filter characteristics   | 188 |
| Table 95. | SPI dynamic characteristics   | 189 |
| Table 96. | I <sup>2</sup> S dynamic characteristics                                    | 192 |

|            |   |     |
|------------|---|-----|
| Table 97.  | SAI characteristics   | 194 |
| Table 98.  | MDIO Slave timing parameters  | 195 |
| Table 99.  | Dynamic characteristics: SD / MMC characteristics, VDD = 2.7 to 3.6 V   | 196 |
| Table 100. | Dynamic characteristics: eMMC characteristics, VDD = 1.71 to 1.9 V  | 197 |
| Table 101. | USB OTG_FS electrical characteristics   | 199 |
| Table 102. | Dynamic characteristics: USB ULPI   | 199 |
| Table 103. | Dynamics characteristics: Ethernet MAC signals for SMI  | 200 |
| Table 104. | Dynamics characteristics: Ethernet MAC signals for RMII   | 201 |
| Table 105. | Dynamics characteristics: Ethernet MAC signals for MII  | 202 |
| Table 106. | Dynamics JTAG characteristics   | 203 |
| Table 107. | Dynamics SWD characteristics  | 203 |
| Table 108. | Voltage characteristics   | 207 |
| Table 109. | Current characteristics   | 208 |
| Table 110. | Thermal characteristics   | 208 |
| Table 111. | General operating conditions  | 209 |
| Table 112. | Supply voltage and maximum frequency configuration  | 210 |
| Table 113. | VCAP operating conditions   | 211 |
| Table 114. | Operating conditions at power-up / power-down (regulator ON)  | 211 |
| Table 115. | Reset and power control block characteristics   | 212 |
| Table 116. | Embedded reference voltage  | 213 |
| Table 117. | Internal reference voltage calibration values   | 214 |
| Table 118. | Typical and maximum current consumption in Run mode, code with data processing running from ITCM, LDO regulator ON                    | 215 |
| Table 119. | Typical and maximum current consumption in Run mode, code with data processing running from flash memory, cache ON, LDO regulator ON  | 216 |
| Table 120. | Typical and maximum current consumption in Run mode, code with data processing running from flash memory, cache OFF, LDO regulator ON | 216 |
| Table 121. | Typical and maximum current consumption batch acquisition mode, LDO regulator ON  | 217 |
| Table 122. | Typical and maximum current consumption in Stop, LDO regulator ON   | 217 |
| Table 123. | Typical and maximum current consumption in Sleep mode, LDO regulator  | 218 |
| Table 124. | Typical and maximum current consumption in Standby  | 218 |
| Table 125. | Typical and maximum current consumption in VBAT mode  | 219 |
| Table 126. | Peripheral current consumption in Run mode  | 221 |
| Table 127. | Low-power mode wakeup timings   | 226 |
| Table 128. | High-speed external user clock characteristics  | 227 |
| Table 129. | Low-speed external user clock characteristics   | 228 |
| Table 130. | 4-48 MHz HSE oscillator characteristics   | 229 |
| Table 131. | Low-speed external user clock characteristics   | 230 |
| Table 132. | HSI48 oscillator characteristics  | 231 |
| Table 133. | HSI oscillator characteristics  | 232 |
| Table 134. | CSI oscillator characteristics  | 232 |
| Table 135. | LSI oscillator characteristics  | 233 |
| Table 136. | PLL characteristics (wide VCO frequency range)  | 234 |
| Table 137. | PLL characteristics (medium VCO frequency range)  | 235 |
| Table 138. | Flash memory characteristics  | 236 |
| Table 139. | Flash memory programming  | 236 |
| Table 140. | Flash memory endurance and data retention   | 237 |
| Table 141. | EMS characteristics   | 237 |
| Table 142. | EMI characteristics for fHSE = 8 MHz and fCPU = 400 MHz   | 238 |

|            |   |     |
|------------|---|-----|
| Table 143. | ESD absolute maximum ratings  | 239 |
| Table 144. | Electrical sensitivities  | 239 |
| Table 145. | I/O current injection susceptibility  | 240 |
| Table 146. | I/O static characteristics  | 241 |
| Table 147. | Output voltage characteristics for all I/Os except PC13, PC14, PC15 and PI8 | 243 |
| Table 148. | Output voltage characteristics for PC13, PC14, PC15 and PI8                 | 244 |
| Table 149. | Output timing characteristics (HSLV OFF)                                    | 245 |
| Table 150. | Output timing characteristics (HSLV ON)                                     | 247 |
| Table 151. | NRST pin characteristics  | 248 |
| Table 152. | Asynchronous non-multiplexed SRAM/PSRAM/NOR read timings                    | 250 |
| Table 153. | Asynchronous non-multiplexed SRAM/PSRAM/NOR read-NWAIT timings              | 250 |
| Table 154. | Asynchronous non-multiplexed SRAM/PSRAM/NOR write timings                   | 252 |
| Table 155. | Asynchronous non-multiplexed SRAM/PSRAM/NOR write-NWAIT timings             | 252 |
| Table 156. | Asynchronous multiplexed PSRAM/NOR read timings                             | 254 |
| Table 157. | Asynchronous multiplexed PSRAM/NOR read-NWAIT timings                       | 254 |
| Table 158. | Asynchronous multiplexed PSRAM/NOR write timings                            | 255 |
| Table 159. | Asynchronous multiplexed PSRAM/NOR write-NWAIT timings                      | 255 |
| Table 160. | Synchronous multiplexed NOR/PSRAM read timings                              | 257 |
| Table 161. | Synchronous multiplexed PSRAM write timings                                 | 259 |
| Table 162. | Synchronous non-multiplexed NOR/PSRAM read timings                          | 261 |
| Table 163. | Synchronous non-multiplexed PSRAM write timings                             | 263 |
| Table 164. | Switching characteristics for NAND flash read cycles                        | 265 |
| Table 165. | Switching characteristics for NAND flash write cycles                       | 265 |
| Table 166. | SDRAM read timings  | 267 |
| Table 167. | LPSDR SDRAM read timings  | 267 |
| Table 168. | SDRAM Write timings   | 268 |
| Table 169. | LPSDR SDRAM Write timings   | 269 |
| Table 170. | QUADSPI characteristics in SDR mode   | 270 |
| Table 171. | QUADSPI characteristics in DDR mode   | 271 |
| Table 172. | Delay Block characteristics   | 272 |
| Table 173. | ADC characteristics   | 272 |
| Table 174. | Minimum sampling time vs $R_{AIN}$  | 276 |
| Table 175. | ADC accuracy  | 278 |
| Table 176. | DAC characteristics   | 281 |
| Table 177. | DAC accuracy  | 283 |
| Table 178. | VREFBUF characteristics   | 285 |
| Table 179. | Temperature sensor characteristics  | 286 |
| Table 180. | Temperature sensor calibration values                                       | 286 |
| Table 181. | $V_{BAT}$ monitoring characteristics  | 287 |
| Table 182. | $V_{BAT}$ charging characteristics  | 287 |
| Table 183. | Temperature monitoring characteristics                                      | 287 |
| Table 184. | Voltage booster for analog switch characteristics                           | 287 |
| Table 185. | COMP characteristics  | 288 |
| Table 186. | Operational amplifier characteristics                                       | 289 |
| Table 187. | DFSDM measured timing - 1.62-3.6 V  | 292 |
| Table 188. | DCMI characteristics  | 294 |
| Table 189. | LTDC characteristics  | 295 |
| Table 190. | TIMx characteristics  | 297 |
| Table 191. | Minimum $i2c\_ker\_ck$ frequency in all I2C modes                           | 298 |
| Table 192. | I2C analog filter characteristics   | 298 |
| Table 193. | USART (SPI mode) characteristics  | 299 |
| Table 194. | SPI dynamic characteristics   | 301 |

|            |  |     |
|------------|--|-----|
| Table 195. | I <sup>2</sup> S dynamic characteristics                               | 304 |
| Table 196. | SAI characteristics  | 305 |
| Table 197. | MDIO Slave timing parameters   | 307 |
| Table 198. | Dynamics characteristics: SD / MMC characteristics, VDD = 2.7 to 3.6 V | 308 |
| Table 199. | Dynamics characteristics: eMMC characteristics VDD = 1.71V to 1.9V     | 309 |
| Table 200. | USB OTG_FS electrical characteristics                                  | 311 |
| Table 201. | Dynamics characteristics: USB ULPI                                     | 311 |
| Table 202. | Dynamics characteristics: Ethernet MAC signals for SMI                 | 312 |
| Table 203. | Dynamics characteristics: Ethernet MAC signals for RMI1                | 313 |
| Table 204. | Dynamics characteristics: Ethernet MAC signals for MII                 | 314 |
| Table 205. | Dynamics JTAG characteristics  | 315 |
| Table 206. | Dynamics SWD characteristics:  | 315 |
| Table 207. | LQFP100 - Mechanical data  | 319 |
| Table 208. | TFBGA100 - Mechanical data   | 321 |
| Table 209. | TFBGA100 - Example of PCB design rules (0.8 mm pitch BGA)              | 323 |
| Table 210. | LQFP144 - Mechanical data  | 325 |
| Table 211. | UFBGA169 - Mechanical data   | 328 |
| Table 212. | UFBGA169 - Example of PCB design rules (0.5 mm pitch BGA)              | 330 |
| Table 213. | LQFP176 - Mechanical data  | 332 |
| Table 214. | LQFP208 - Mechanical data  | 336 |
| Table 215. | UFBGA(176+25) - Mechanical data  | 338 |
| Table 216. | UFBGA(176+25) - Example of PCB design rules (0.65 mm pitch BGA)        | 339 |
| Table 217. | TFBGA240+25 - Mechanical data  | 341 |
| Table 218. | TFBGA240+25 - Tolerance of form and position                           | 341 |
| Table 219. | Tolerance of form and position definitions                             | 342 |
| Table 220. | TFBGA240+25 - Example of PCB design rules                              | 343 |
| Table 221. | Thermal characteristics  | 344 |
| Table 222. | Document revision history  | 348 |

## List of figures

|            |  |     |
|------------|--|-----|
| Figure 1.  | STM32H753xI block diagram  | 23  |
| Figure 2.  | Power-up/power-down sequence   | 28  |
| Figure 3.  | STM32H753xI bus matrix   | 32  |
| Figure 4.  | LQFP100 pinout   | 55  |
| Figure 5.  | TFBGA100 ballout   | 56  |
| Figure 6.  | LQFP144 pinout   | 57  |
| Figure 7.  | UFBGA169 ballout   | 58  |
| Figure 8.  | LQFP176 pinout   | 59  |
| Figure 9.  | UFBGA176+25 ballout  | 60  |
| Figure 10. | LQFP208 pinout   | 61  |
| Figure 11. | TFBGA240+25 ballout  | 62  |
| Figure 12. | Pin loading conditions   | 101 |
| Figure 13. | Pin input voltage  | 101 |
| Figure 14. | Power supply scheme  | 102 |
| Figure 15. | Current consumption measurement scheme   | 103 |
| Figure 16. | External capacitor $C_{EXT}$   | 106 |
| Figure 17. | High-speed external clock source AC timing diagram   | 123 |
| Figure 18. | Low-speed external clock source AC timing diagram  | 124 |
| Figure 19. | Typical application with an 8 MHz crystal  | 126 |
| Figure 20. | Typical application with a 32.768 kHz crystal  | 127 |
| Figure 21. | VIL/VIH for all I/Os except BOOT0  | 138 |
| Figure 22. | Recommended NRST pin protection  | 144 |
| Figure 23. | Asynchronous non-multiplexed SRAM/PSRAM/NOR read waveforms                                     | 146 |
| Figure 24. | Asynchronous non-multiplexed SRAM/PSRAM/NOR write waveforms                                    | 148 |
| Figure 25. | Asynchronous multiplexed PSRAM/NOR read waveforms  | 149 |
| Figure 26. | Asynchronous multiplexed PSRAM/NOR write waveforms   | 151 |
| Figure 27. | Synchronous multiplexed NOR/PSRAM read timings   | 153 |
| Figure 28. | Synchronous multiplexed PSRAM write timings  | 155 |
| Figure 29. | Synchronous non-multiplexed NOR/PSRAM read timings   | 157 |
| Figure 30. | Synchronous non-multiplexed PSRAM write timings  | 158 |
| Figure 31. | NAND controller waveforms for read access  | 159 |
| Figure 32. | NAND controller waveforms for write access   | 160 |
| Figure 33. | SDRAM read access waveforms (CL = 1)   | 161 |
| Figure 34. | SDRAM write access waveforms   | 162 |
| Figure 35. | Quad-SPI timing diagram - SDR mode   | 165 |
| Figure 36. | Quad-SPI timing diagram - DDR mode   | 165 |
| Figure 37. | ADC accuracy characteristics   | 169 |
| Figure 38. | Typical connection diagram when using the ADC with FT/TT pins featuring analog switch function | 169 |
| Figure 39. | Power supply and reference decoupling ( $V_{REF+}$ not connected to $V_{DDA}$ )                | 170 |
| Figure 40. | Power supply and reference decoupling ( $V_{REF+}$ connected to $V_{DDA}$ )                    | 170 |
| Figure 41. | 12-bit buffered /non-buffered DAC  | 173 |
| Figure 42. | Channel transceiver timing diagrams  | 183 |
| Figure 43. | DCMI timing diagram  | 184 |
| Figure 44. | LCD-TFT horizontal timing diagram  | 186 |
| Figure 45. | LCD-TFT vertical timing diagram  | 186 |
| Figure 46. | SPI timing diagram - slave mode and CPHA = 0   | 190 |
| Figure 47. | SPI timing diagram - slave mode and CPHA = 1 <sup>(1)</sup>                                    | 191 |

|            |   |     |
|------------|---|-----|
| Figure 48. | SPI timing diagram - master mode <sup>(1)</sup> . . . . .   | 191 |
| Figure 49. | I <sup>2</sup> S slave timing diagram (Philips protocol) <sup>(1)</sup> . . . . .                           | 193 |
| Figure 50. | I <sup>2</sup> S master timing diagram (Philips protocol) <sup>(1)</sup> . . . . .                          | 193 |
| Figure 51. | SAI master timing waveforms . . . . .   | 195 |
| Figure 52. | SAI slave timing waveforms . . . . .  | 195 |
| Figure 53. | MDIO Slave timing diagram . . . . .   | 196 |
| Figure 54. | SDIO high-speed mode . . . . .  | 198 |
| Figure 55. | SD default mode . . . . .   | 198 |
| Figure 56. | DDR mode . . . . .  | 198 |
| Figure 57. | ULPI timing diagram . . . . .   | 200 |
| Figure 58. | Ethernet SMI timing diagram . . . . .   | 201 |
| Figure 59. | Ethernet RMII timing diagram . . . . .  | 201 |
| Figure 60. | Ethernet MII timing diagram . . . . .   | 202 |
| Figure 61. | JTAG timing diagram . . . . .   | 204 |
| Figure 62. | SWD timing diagram . . . . .  | 204 |
| Figure 63. | Pin loading conditions . . . . .  | 205 |
| Figure 64. | Pin input voltage . . . . .   | 205 |
| Figure 65. | Power supply scheme . . . . .   | 206 |
| Figure 66. | Current consumption measurement scheme . . . . .  | 207 |
| Figure 67. | External capacitor C <sub>EXT</sub> . . . . .   | 211 |
| Figure 68. | High-speed external clock source AC timing diagram . . . . .  | 227 |
| Figure 69. | Low-speed external clock source AC timing diagram . . . . .   | 228 |
| Figure 70. | Typical application with an 8 MHz crystal . . . . .   | 230 |
| Figure 71. | Typical application with a 32.768 kHz crystal . . . . .   | 231 |
| Figure 72. | VIL/VIH for all I/Os except BOOT0 . . . . .   | 242 |
| Figure 73. | Recommended NRST pin protection . . . . .   | 248 |
| Figure 74. | Asynchronous non-multiplexed SRAM/PSRAM/NOR read waveforms . . . . .  | 249 |
| Figure 75. | Asynchronous non-multiplexed SRAM/PSRAM/NOR write waveforms . . . . .                                       | 251 |
| Figure 76. | Asynchronous multiplexed PSRAM/NOR read waveforms . . . . .   | 253 |
| Figure 77. | Synchronous multiplexed NOR/PSRAM read timings . . . . .  | 256 |
| Figure 78. | Synchronous multiplexed PSRAM write timings . . . . .   | 258 |
| Figure 79. | Synchronous non-multiplexed NOR/PSRAM read timings . . . . .  | 260 |
| Figure 80. | Synchronous non-multiplexed PSRAM write timings . . . . .   | 262 |
| Figure 81. | NAND controller waveforms for read access . . . . .   | 264 |
| Figure 82. | NAND controller waveforms for write access . . . . .  | 265 |
| Figure 83. | SDRAM read access waveforms (CL = 1) . . . . .  | 266 |
| Figure 84. | SDRAM write access waveforms . . . . .  | 268 |
| Figure 85. | QUADSPI timing diagram - SDR mode . . . . .   | 271 |
| Figure 86. | Quad-SPI timing diagram - DDR mode . . . . .  | 272 |
| Figure 87. | ADC accuracy characteristics . . . . .  | 279 |
| Figure 88. | Typical connection diagram when using the ADC with FT/TT pins<br>featuring analog switch function . . . . . | 279 |
| Figure 89. | Power supply and reference decoupling (V <sub>REF+</sub> not connected to V <sub>DDA</sub> ) . . . . .      | 280 |
| Figure 90. | Power supply and reference decoupling (V <sub>REF+</sub> connected to V <sub>DDA</sub> ) . . . . .          | 280 |
| Figure 91. | 12-bit buffered /non-buffered DAC . . . . .   | 284 |
| Figure 92. | Channel transceiver timing diagrams . . . . .   | 293 |
| Figure 93. | DCMI timing diagram . . . . .   | 294 |
| Figure 94. | LCD-TFT horizontal timing diagram . . . . .   | 296 |
| Figure 95. | LCD-TFT vertical timing diagram . . . . .   | 296 |
| Figure 96. | USART timing diagram in SPI master mode . . . . .   | 299 |
| Figure 97. | USART timing diagram in SPI slave mode . . . . .  | 300 |
| Figure 98. | SPI timing diagram - slave mode and CPHA = 0 . . . . .  | 302 |

|  |     |
|--|-----|
| Figure 99. SPI timing diagram - slave mode and CPHA = 1                              | 302 |
| Figure 100. SPI timing diagram - master mode   | 303 |
| Figure 101. I <sup>2</sup> S slave timing diagram (Philips protocol) <sup>(1)</sup>  | 304 |
| Figure 102. I <sup>2</sup> S master timing diagram (Philips protocol) <sup>(1)</sup> | 305 |
| Figure 103. SAI master timing waveforms  | 307 |
| Figure 104. SAI slave timing waveforms   | 307 |
| Figure 105. MDIO Slave timing diagram  | 308 |
| Figure 106. SDIO high-speed mode   | 310 |
| Figure 107. SD default mode  | 310 |
| Figure 108. DDR mode   | 310 |
| Figure 109. ULPI timing diagram  | 312 |
| Figure 110. Ethernet SMI timing diagram  | 313 |
| Figure 111. Ethernet RMII timing diagram   | 313 |
| Figure 112. Ethernet MII timing diagram  | 314 |
| Figure 113. JTAG timing diagram  | 315 |
| Figure 114. SWD timing diagram   | 316 |
| Figure 115. LQFP100 - Outline <sup>(15)</sup>  | 318 |
| Figure 116. LQFP100 - Footprint example  | 320 |
| Figure 117. TFBGA100 - Outline <sup>(13)</sup>                                       | 321 |
| Figure 118. TFBGA100 - Footprint example   | 323 |
| Figure 119. LQFP144 - Outline <sup>(15)</sup>  | 324 |
| Figure 120. LQFP144 - Footprint example  | 327 |
| Figure 121. UFBGA169 - Outline   | 328 |
| Figure 122. UFBGA169 - Footprint example   | 329 |
| Figure 123. LQFP176 - Outline <sup>(15)</sup>  | 331 |
| Figure 124. LQFP176 - Footprint example  | 334 |
| Figure 125. LQFP208 - Outline <sup>(15)</sup>  | 335 |
| Figure 126. LQFP208 - footprint example  | 337 |
| Figure 127. UFBGA(176+25) - Outline  | 338 |
| Figure 128. UFBGA(176+25) - Footprint example  | 339 |
| Figure 129. TFBGA240+25 - Outline  | 340 |
| Figure 130. TFBGA240+25 - Footprint example  | 343 |

# 1 Introduction

This document provides information on STM32H753xl microcontrollers, such as description, functional overview, pin assignment and definition, electrical characteristics, packaging, and ordering information.

This document should be read in conjunction with the STM32H753xl reference manual (RM0433), available from the STMicroelectronics website [www.st.com](http://www.st.com).

For information on the device errata with respect to the datasheet and reference manual, refer to the STM32H753xl errata sheet (ES0396), available on the STMicroelectronics website [www.st.com](http://www.st.com).

For information on the Arm® Cortex®-M7 core, please refer to the Cortex®-M7 Technical Reference Manual, available from the <http://www.arm.com> website.

The logo for Arm, consisting of the word "arm" in a bold, lowercase, sans-serif font.

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## 2 Description

STM32H753xI devices are based on the high-performance Arm® Cortex®-M7 32-bit RISC core operating at up to 480 MHz. The Cortex® -M7 core features a floating point unit (FPU) which supports Arm® double-precision (IEEE 754 compliant) and single-precision data-processing instructions and data types. STM32H753xI devices support a full set of DSP instructions and a memory protection unit (MPU) to enhance application security.

STM32H753xI devices incorporate high-speed embedded memories with a dual-bank flash memory of 2 Mbytes, up to 1 Mbyte of RAM (including 192 Kbytes of TCM RAM, up to 864 Kbytes of user SRAM and 4 Kbytes of backup SRAM), as well as an extensive range of enhanced I/Os and peripherals connected to APB buses, AHB buses, 2x32-bit multi-AHB bus matrix and a multi layer AXI interconnect supporting internal and external memory access.

All the devices offer three ADCs, two DACs, two ultra-low power comparators, a low-power RTC, a high-resolution timer, 12 general-purpose 16-bit timers, two PWM timers for motor control, five low-power timers, a true random number generator (RNG), and a cryptographic acceleration cell. The devices support four digital filters for external sigma-delta modulators (DFSDM). They also feature standard and advanced communication interfaces.

- Standard peripherals
  - Four I<sup>2</sup>Cs
  - Four USARTs, four UARTs and one LPUART
  - Six SPIs, three I2Ss in Half-duplex mode. To achieve audio class accuracy, the I2S peripherals can be clocked by a dedicated internal audio PLL or by an external clock to allow synchronization.
  - Four SAI serial audio interfaces
  - One SPDIFRX interface
  - One SWPMI (Single Wire Protocol Master Interface)
  - Management Data Input/Output (MDIO) slaves
  - Two SDMMC interfaces
  - A USB OTG full-speed and a USB OTG high-speed interface with full-speed capability (with the ULPI)
  - One FDCAN plus one TT-FDCAN interface
  - An Ethernet interface
  - Chrom-ART Accelerator
  - HDMI-CEC
- Advanced peripherals including
  - A flexible memory control (FMC) interface
  - A Quad-SPI flash memory interface
  - A camera interface for CMOS sensors
  - An LCD-TFT display controller
  - A JPEG hardware compressor/decompressor

Refer to [Table 2: STM32H753xI features and peripheral counts](#) for the list of peripherals available on each part number.

STM32H753xI devices operate in the  $-40$  to  $+85$  °C temperature range from a 1.62 to 3.6 V power supply. The supply voltage can drop down to 1.62 V by using an external power supervisor (see [Section 3.5.2: Power supply supervisor](#)) and connecting the PDR\_ON pin to  $V_{SS}$ . Otherwise the supply voltage must stay above 1.71 V with the embedded power voltage detector enabled.

Dedicated supply inputs for USB (OTG\_FS and OTG\_HS) are available on all packages except LQFP100 to allow a greater power supply choice.

A comprehensive set of power-saving modes allows the design of low-power applications.

STM32H753xI devices are offered in 8 packages ranging from 100 pins to 240 pins/balls. The set of included peripherals changes with the device chosen.

These features make STM32H753xI microcontrollers suitable for a wide range of applications:

- Motor drive and application control
- Medical equipment
- Industrial applications: PLC, inverters, circuit breakers
- Printers, and scanners
- Alarm systems, video intercom, and HVAC
- Home audio appliances
- Mobile applications, Internet of Things
- Wearable devices: smart watches.

[Figure 1](#) shows the device block diagram.

Table 2. STM32H753xl features and peripheral counts

| Peripherals               |                          | STM32H753<br>VI    | STM32H753<br>ZI | STM32H753<br>AI | STM32H753<br>II | STM32H753<br>BI | STM32H753<br>XI |
|---------------------------|--------------------------|--------------------|-----------------|-----------------|-----------------|-----------------|-----------------|
| Flash memory in Kbytes    |                          | 2 x 1 Mbyte        |                 |                 |                 |                 |                 |
| SRAM in Kbytes            | SRAM mapped onto AXI bus | 512                |                 |                 |                 |                 |                 |
|                           | SRAM1 (D2 domain)        | 128                |                 |                 |                 |                 |                 |
|                           | SRAM2 (D2 domain)        | 128                |                 |                 |                 |                 |                 |
|                           | SRAM3 (D2 domain)        | 32                 |                 |                 |                 |                 |                 |
|                           | SRAM4 (D3 domain)        | 64                 |                 |                 |                 |                 |                 |
| TCM RAM in Kbytes         | ITCM RAM (instruction)   | 64                 |                 |                 |                 |                 |                 |
|                           | DTCM RAM (data)          | 128                |                 |                 |                 |                 |                 |
| Backup SRAM (Kbytes)      |                          | 4                  |                 |                 |                 |                 |                 |
| FMC                       |                          | Yes <sup>(1)</sup> |                 |                 |                 |                 |                 |
| GPIOs                     |                          | 82                 | 114             | 131             | 140             | 168             |                 |
| Quad-SPI interface        |                          | Yes                |                 |                 |                 |                 |                 |
| Ethernet                  |                          | Yes                |                 |                 |                 |                 |                 |
| Timers                    | High-resolution          | 1                  |                 |                 |                 |                 |                 |
|                           | General-purpose          | 10                 |                 |                 |                 |                 |                 |
|                           | Advanced-control (PWM)   | 2                  |                 |                 |                 |                 |                 |
|                           | Basic                    | 2                  |                 |                 |                 |                 |                 |
|                           | Low-power                | 5                  |                 |                 |                 |                 |                 |
| Wakeup pins               |                          | 4                  |                 | 5               |                 | 6               |                 |
| Tamper pins               |                          | 2                  |                 | 2               |                 | 3               |                 |
| Random number generator   |                          | Yes                |                 |                 |                 |                 |                 |
| Cryptographic accelerator |                          | Yes                |                 |                 |                 |                 |                 |

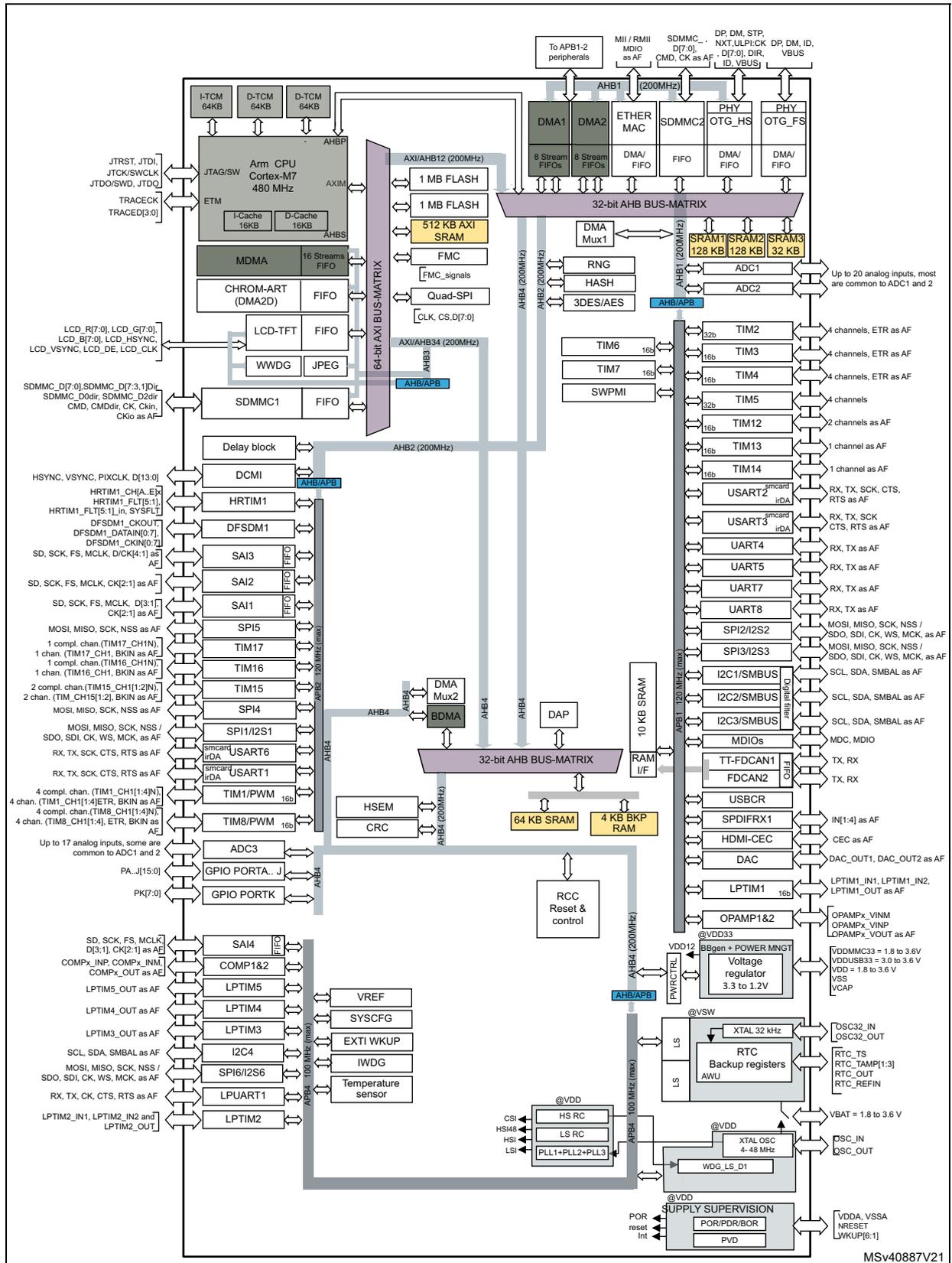
**Table 2. STM32H753xl features and peripheral counts (continued)**

| Peripherals                   |                   | STM32H753 VI  | STM32H753 ZI                 | STM32H753 AI | STM32H753 II               | STM32H753 BI | STM32H753 XI    |
|-------------------------------|-------------------|---|------------------------------|--------------|----------------------------|--------------|-----------------|
| Communication interfaces      | SPI / I2S         | 6/3 <sup>(2)</sup>                                    |                              |              |                            |              |                 |
|                               | I2C               | 4   |                              |              |                            |              |                 |
|                               | USART/UART/LPUART | 4/4<br>/1   |                              |              |                            |              |                 |
|                               | SAI               | 4   |                              |              |                            |              |                 |
|                               | SPDIFRX           | 4 inputs  |                              |              |                            |              |                 |
|                               | SWPMI             | Yes   |                              |              |                            |              |                 |
|                               | MDIO              | Yes   |                              |              |                            |              |                 |
|                               | SDMMC             | 2   |                              |              |                            |              |                 |
|                               | FDCAN/TT-FDCAN    | 1/1   |                              |              |                            |              |                 |
|                               | USB OTG_FS        | Yes   |                              |              |                            |              |                 |
|                               | USB OTG_HS        | Yes   |                              |              |                            |              |                 |
| Camera interface              |                   | Yes   |                              |              |                            |              |                 |
| LCD-TFT                       |                   | Yes   |                              |              |                            |              |                 |
| JPEG Codec                    |                   | Yes   |                              |              |                            |              |                 |
| Chrom-ART Accelerator (DMA2D) |                   | Yes   |                              |              |                            |              |                 |
| 16-bit ADCs                   |                   | 3   |                              |              |                            |              |                 |
| Number of Direct channels     |                   | 2   | 2                            | 2            |                            |              | 4               |
| Number of Fast channels       |                   | 3   | 9                            | 9            |                            |              | 9               |
| Number of Slow channels       |                   | 11  | 17                           | 21           |                            |              | 23              |
| 12-bit DAC                    |                   | Yes   |                              |              |                            |              |                 |
| Number of channels            |                   | 2   |                              |              |                            |              |                 |
| Comparators                   |                   | 2   |                              |              |                            |              |                 |
| Operational amplifiers        |                   | 2   |                              |              |                            |              |                 |
| DFSDM                         |                   | Yes   |                              |              |                            |              |                 |
| Maximum CPU frequency         |                   | 480MHz <sup>(3)(4)</sup> /400 MHz                     |                              |              |                            |              |                 |
| Operating voltage             |                   | 1.71 to 3.6 V <sup>(5)</sup>                          | 1.62 to 3.6 V <sup>(6)</sup> |              |                            |              |                 |
| Operating temperatures        |                   | Ambient temperatures: -40 up to +85 °C <sup>(7)</sup> |                              |              |                            |              |                 |
|                               |                   | Junction temperature: -40 to + 125 °C                 |                              |              |                            |              |                 |
| Package                       |                   | LQFP100<br>TFBGA100                                   | LQFP144                      | UFBGA169     | LQFP176<br>UFBGA176+<br>25 | LQFP208      | TFBGA240+<br>25 |

- SDRAM is not available on LQFP100 and TFBGA100 packages.
- The SPI1, SPI2 and SPI3 interfaces give the flexibility to work in an exclusive way in either the SPI mode or the I2S audio mode.
- The maximum CPU frequency of 480 MHz can be obtained on devices revision V.

4. The product junction temperature must be kept within the  $-40$  to  $+105$  °C temperature range.
5. Since the LQFP100 package does not feature the PDR\_ON pin (tied internally to  $V_{DD}$ ), the minimum  $V_{DD}$  value for this package is 1.71 V.
6.  $V_{DD}/V_{DDA}$  can drop down to 1.62 V by using an external power supervisor (see [Section 3.5.2: Power supply supervisor](#)) and connecting PDR\_ON pin to  $V_{SS}$ . Otherwise the supply voltage must stay above 1.71 V with the embedded power voltage detector enabled.
7. The product junction temperature must be kept within the  $-40$  to  $+125$  °C temperature range.

Figure 1. STM32H753xl block diagram



## 3 Functional overview

### 3.1 Arm<sup>®</sup> Cortex<sup>®</sup>-M7 with FPU

The Arm<sup>®</sup> Cortex<sup>®</sup>-M7 with double-precision FPU processor is the latest generation of Arm processors for embedded systems. It was developed to provide a low-cost platform that meets the needs of MCU implementation, with a reduced pin count and optimized power consumption, while delivering outstanding computational performance and low interrupt latency.

The Cortex<sup>®</sup>-M7 processor is a highly efficient high-performance featuring:

- Six-stage dual-issue pipeline
- Dynamic branch prediction
- Harvard architecture with L1 caches (16 Kbytes of I-cache and 16 Kbytes of D-cache)
- 64-bit AXI interface
- 64-bit ITCM interface
- 2x32-bit DTCM interfaces

The following memory interfaces are supported:

- Separate Instruction and Data buses (Harvard Architecture) to optimize CPU latency
- Tightly Coupled Memory (TCM) interface designed for fast and deterministic SRAM accesses
- AXI Bus interface to optimize Burst transfers
- Dedicated low-latency AHB-Lite peripheral bus (AHBP) to connect to peripherals.

The processor supports a set of DSP instructions which allow efficient signal processing and complex algorithm execution.

It also supports single and double precision FPU (floating point unit) speeds up software development by using metalanguage development tools, while avoiding saturation.

*Figure 1* shows the general block diagram of the STM32H753xI family.

*Note:* Cortex<sup>®</sup>-M7 with FPU core is binary compatible with the Cortex<sup>®</sup>-M4 core.

### 3.2 Memory protection unit (MPU)

The memory protection unit (MPU) manages the CPU access rights and the attributes of the system resources. It has to be programmed and enabled before use. Its main purposes are to prevent an untrusted user program to accidentally corrupt data used by the OS and/or by a privileged task, but also to protect data processes or read-protect memory regions.

The MPU defines access rules for privileged accesses and user program accesses. It allows defining up to 16 protected regions that can in turn be divided into up to 8 independent subregions, where region address, size, and attributes can be configured. The protection area ranges from 32 bytes to 4 Gbytes of addressable memory.

When an unauthorized access is performed, a memory management exception is generated.

## 3.3 Memories

### 3.3.1 Embedded flash memory

The STM32H753xI devices embed 2 Mbytes of flash memory that can be used for storing programs and data.

The flash memory is organized as 266-bit flash words memory that can be used for storing both code and data constants. Each word consists of:

- One flash word (8 words, 32 bytes or 256 bits)
- 10 ECC bits.

The flash memory is divided into two independent banks. Each bank is organized as follows:

- 1 Mbyte of user flash memory block containing eight user sectors of 128 Kbytes (4 K flash memory words)
- 128 Kbytes of System flash memory from which the device can boot
- 2 Kbytes (64 flash words) of user option bytes for user configuration

### 3.3.2 Secure access mode

In addition to other typical memory protection mechanism (RDP, PCROP), STM32H753xI devices introduce the Secure access mode, a new enhanced security feature. This mode allows developing user-defined secure services by ensuring, on the one hand code and data protection and on the other hand code safe execution.

Two types of secure services are available:

- STMicroelectronics Root Secure Services:  
These services are embedded in System memory. They provide a secure solution for firmware and third-party modules installation. These services rely on cryptographic algorithms based on a device unique private key.
- User-defined secure services:  
These services are embedded in user flash memory. Examples of user secure services are proprietary user firmware update solution, secure flash integrity check or any other sensitive applications that require a high level of protection.  
The secure firmware is embedded in specific user flash memory areas configured through option bytes.

Secure services are executed just after a reset and preempt all other applications to guarantee protected and safe execution. Once executed, the corresponding code and data are no more accessible.

The above secure services are available only for Cortex<sup>®</sup>-M7 core operating in Secure access mode. The other masters cannot access the option bytes involved in Secure access mode settings or the flash secured areas.

### 3.3.3 Embedded SRAM

All devices feature:

- 512 Kbytes of AXI-SRAM mapped onto AXI bus on D1 domain.
- SRAM1 mapped on D2 domain: 128 Kbytes
- SRAM2 mapped on D2 domain: 128 Kbytes
- SRAM3 mapped on D2 domain: 32 Kbytes
- SRAM4 mapped on D3 domain: 64 Kbytes
- 4 Kbytes of backup SRAM

The content of this area is protected against possible unwanted write accesses, and is retained in Standby or V<sub>BAT</sub> mode.

- RAM mapped to TCM interface (ITCM and DTCM):

Both ITCM and DTCM RAMs are 0 wait state memories. either They can be accessed either from the CPU or the MDMA (even in Sleep mode) through a specific AHB slave of the CPU(AHBP):

- 64 Kbytes of ITCM-RAM (instruction RAM)

This RAM is connected to ITCM 64-bit interface designed for execution of critical real-times routines by the CPU.

- 128 Kbytes of DTCM-RAM (2x 64-Kbyte DTCM-RAMs on 2x32-bit DTCM ports)

The DTCM-RAM could be used for critical real-time data, such as interrupt service routines or stack/heap memory. Both DTCM-RAMs can be used in parallel (for load/store operations) thanks to the Cortex<sup>®</sup>-M7 dual issue capability.

The MDMA can be used to load code or data in ITCM or DTCM RAMs.

#### Error code correction (ECC)

Over the product lifetime, and/or due to external events such as radiations, invalid bits in memories may occur. They can be detected and corrected by ECC. This is an expected behavior that has to be managed at final-application software level in order to ensure data integrity through ECC algorithms implementation.

SRAM data are protected by ECC:

- 7 ECC bits are added per 32-bit word.
- 8 ECC bits are added per 64-bit word for AXI-SRAM and ITCM-RAM.

The ECC mechanism is based on the SECDED algorithm. It supports single-error correction and double-error detection.

## 3.4 Boot modes

At startup, the boot memory space is selected by the BOOT pin and BOOT\_ADDx option bytes, allowing to program any boot memory address from 0x0000 0000 to 0x3FFF FFFF which includes:

- All flash address space
- All RAM address space: ITCM, DTCM RAMs and SRAMs
- The System memory bootloader

The boot loader is located in non-user System memory. It is used to reprogram the flash memory through a serial interface (FDCAN, USART, I2C, SPI, USB-DFU). Refer to *STM32 microcontroller System memory Boot mode* application note (AN2606) for details.

## 3.5 Power supply management

### 3.5.1 Power supply scheme

STM32H753xl power supply voltages are the following:

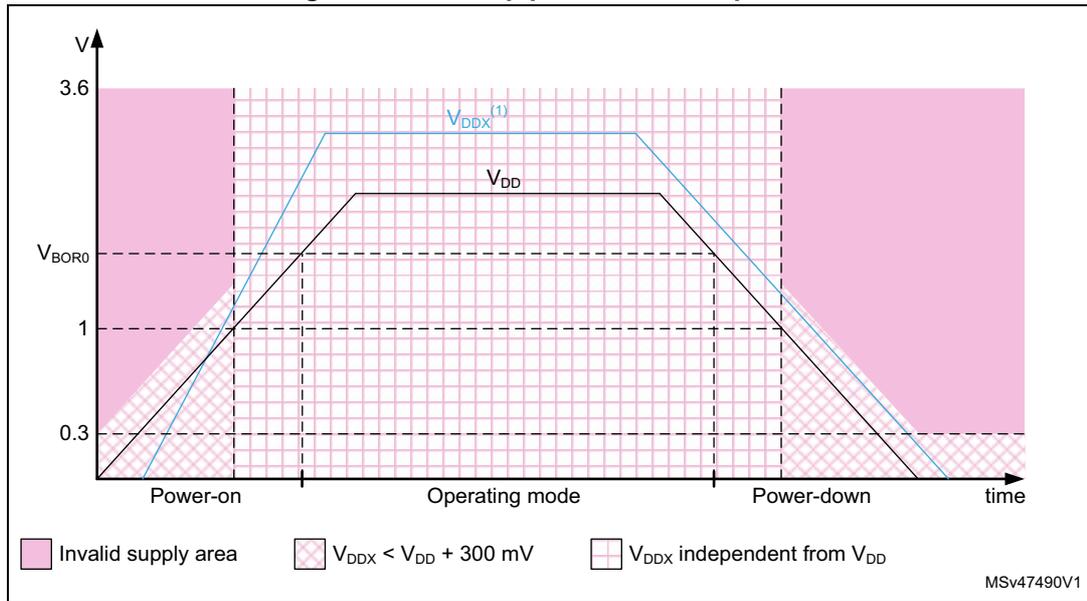
- $V_{DD} = 1.62$  to  $3.6$  V: external power supply for I/Os, provided externally through  $V_{DD}$  pins.
- $V_{DDLDO} = 1.62$  to  $3.6$  V: supply voltage for the internal regulator supplying  $V_{CORE}$
- $V_{DDA} = 1.62$  to  $3.6$  V: external analog power supplies for ADC, DAC, COMP and OPAMP.
- $V_{DD33USB}$  and  $V_{DD50USB}$ :  
 $V_{DD50USB}$  can be supplied through the USB cable to generate the  $V_{DD33USB}$  via the USB internal regulator. This allows supporting a  $V_{DD}$  supply different from  $3.3$  V.  
The USB regulator can be bypassed to supply directly  $V_{DD33USB}$  with  $V_{DD33USB} \approx 3.3$  V (see electrical characteristics).
- $V_{BAT} = 1.2$  to  $3.6$  V: power supply for the  $V_{SW}$  domain when  $V_{DD}$  is not present.
- $V_{CAP}$ :  $V_{CORE}$  supply voltage, which values depend on voltage scaling ( $1.0$  V,  $1.1$  V,  $1.2$  V or  $1.35$  V). They are configured through VOS bits in PWR\_D3CR register and ODEN bit in the SYSCFG\_PWRCR register. The  $V_{CORE}$  domain is split into the following power domains that can be independently switch off.
  - D1 domain containing some peripherals and the Cortex<sup>®</sup>-M7 core.
  - D2 domain containing a large part of the peripherals.
  - D3 domain containing some peripherals and the system control.

During power-up and power-down phases, the following power sequence requirements must be respected (see [Figure 2](#)):

- When  $V_{DD}$  is below  $1$  V, other power supplies ( $V_{DDA}$ ,  $V_{DD33USB}$ ,  $V_{DD50USB}$ ) must remain below  $V_{DD} + 300$  mV.
- When  $V_{DD}$  is above  $1$  V, all power supplies are independent.

During the power-down phase,  $V_{DD}$  can temporarily become lower than other supplies only if the energy provided to the microcontroller remains below  $1$  mJ. This allows external decoupling capacitors to be discharged with different time constants during the power-down transient phase.

Figure 2. Power-up/power-down sequence



1.  $V_{DDX}$  refers to any power supply among  $V_{DDA}$ ,  $V_{DD33USB}$ ,  $V_{DD50USB}$ .

### 3.5.2 Power supply supervisor

The devices have an integrated power-on reset (POR)/ power-down reset (PDR) circuitry coupled with a Brownout reset (BOR) circuitry:

- Power-on reset (POR)
 

The POR supervisor monitors  $V_{DD}$  power supply and compares it to a fixed threshold. The devices remain in Reset mode when  $V_{DD}$  is below this threshold,
- Power-down reset (PDR)
 

The PDR supervisor monitors  $V_{DD}$  power supply. A reset is generated when  $V_{DD}$  drops below a fixed threshold.

The PDR supervisor can be enabled/disabled through PDR\_ON pin.
- Brownout reset (BOR)
 

The BOR supervisor monitors  $V_{DD}$  power supply. Three BOR thresholds (from 2.1 to 2.7 V) can be configured through option bytes. A reset is generated when  $V_{DD}$  drops below this threshold.

### 3.5.3 Voltage regulator

The same voltage regulator supplies the 3 power domains (D1, D2 and D3). D1 and D2 can be independently switched off.

Voltage regulator output can be adjusted according to application needs through 6 power supply levels:

- Run mode (VOS0 to VOS3)
  - Scale 0: boosted performance (available only with LDO regulator)
  - Scale 1: high performance
  - Scale 2: medium performance and consumption
  - Scale 3: optimized performance and low-power consumption
- Stop mode (SVOS3 to SVOS5)
  - Scale 3: peripheral with wakeup from Stop mode capabilities (UART, SPI, I2C, LPTIM) are operational
  - Scale 4 and 5 where the peripheral with wakeup from Stop mode is disabled  
The peripheral functionality is disabled but wakeup from Stop mode is possible through GPIO or asynchronous interrupt.

## 3.6 Low-power strategy

There are several ways to reduce power consumption on STM32H753xl:

- Decrease the dynamic power consumption by slowing down the system clocks even in Run mode and by individually clock gating the peripherals that are not used.
- Save power consumption when the CPU is idle, by selecting among the available low-power mode according to the user application needs. This allows achieving the best compromise between short startup time, low-power consumption, as well as available wakeup sources.

The devices feature several low-power modes:

- CSleep (CPU clock stopped)
- CStop (CPU sub-system clock stopped)
- DStop (Domain bus matrix clock stopped)
- Stop (System clock stopped)
- DStandby (Domain powered down)
- Standby (System powered down)

CSleep and CStop low-power modes are entered by the MCU when executing the WFI (Wait for Interrupt) or WFE (Wait for Event) instructions, or when the SLEEPONEXIT bit of the Cortex<sup>®</sup>-Mx core is set after returning from an interrupt service routine.

A domain can enter low-power mode (DStop or DStandby) when the processor, its subsystem and the peripherals allocated in the domain enter low-power mode.

If part of the domain is not in low-power mode, the domain remains in the current mode.

Finally the system can enter Stop or Standby when all EXTI wakeup sources are cleared and the power domains are in DStop or DStandby mode.

Table 3. System vs domain low-power mode

| System power mode | D1 domain power mode | D2 domain power mode | D3 domain power mode |
|-------------------|----------------------|----------------------|----------------------|
| Run               | DRun/DStop/DStandby  | DRun/DStop/DStandby  | DRun                 |
| Stop              | DStop/DStandby       | DStop/DStandby       | DStop                |
| Standby           | DStandby             | DStandby             | DStandby             |

## 3.7 Reset and clock controller (RCC)

The clock and reset controller is located in D3 domain. The RCC manages the generation of all the clocks, as well as the clock gating and the control of the system and peripheral resets. It provides a high flexibility in the choice of clock sources and allows to apply clock ratios to improve the power consumption. In addition, on some communication peripherals that are capable to work with two different clock domains (either a bus interface clock or a kernel peripheral clock), the system frequency can be changed without modifying the baudrate.

### 3.7.1 Clock management

The devices embed four internal oscillators, two oscillators with external crystal or resonator, two internal oscillators with fast startup time and three PLLs.

The RCC receives the following clock source inputs:

- Internal oscillators:
  - 64 MHz HSI clock
  - 48 MHz RC oscillator
  - 4 MHz CSI clock
  - 32 kHz LSI clock
- External oscillators:
  - HSE clock: 4-50 MHz (generated from an external source) or 4-48 MHz (generated from a crystal/ceramic resonator)
  - LSE clock: 32.768 kHz

The RCC provides three PLLs: one for system clock, two for kernel clocks.

The system starts on the HSI clock. The user application can then select the clock configuration.

### 3.7.2 System reset sources

Power-on reset initializes all registers while system reset reinitializes the system except for the debug, part of the RCC and power controller status registers, as well as the backup power domain.

A system reset is generated in the following cases:

- Power-on reset (pwr\_por\_rst)
- Brownout reset
- Low level on NRST pin (external reset)
- Window watchdog
- Independent watchdog
- Software reset
- Low-power mode security reset
- Exit from Standby

### 3.8 General-purpose input/outputs (GPIOs)

Each of the GPIO pins can be configured by software as output (push-pull or open-drain, with or without pull-up or pull-down), as input (floating, with or without pull-up or pull-down) or as peripheral alternate function. Most of the GPIO pins are shared with digital or analog alternate functions. All GPIOs are high-current-capable and have speed selection to better manage internal noise, power consumption and electromagnetic emission.

After reset, all GPIOs (except debug pins) are in Analog mode to reduce power consumption (refer to GPIOs register reset values in the device reference manual).

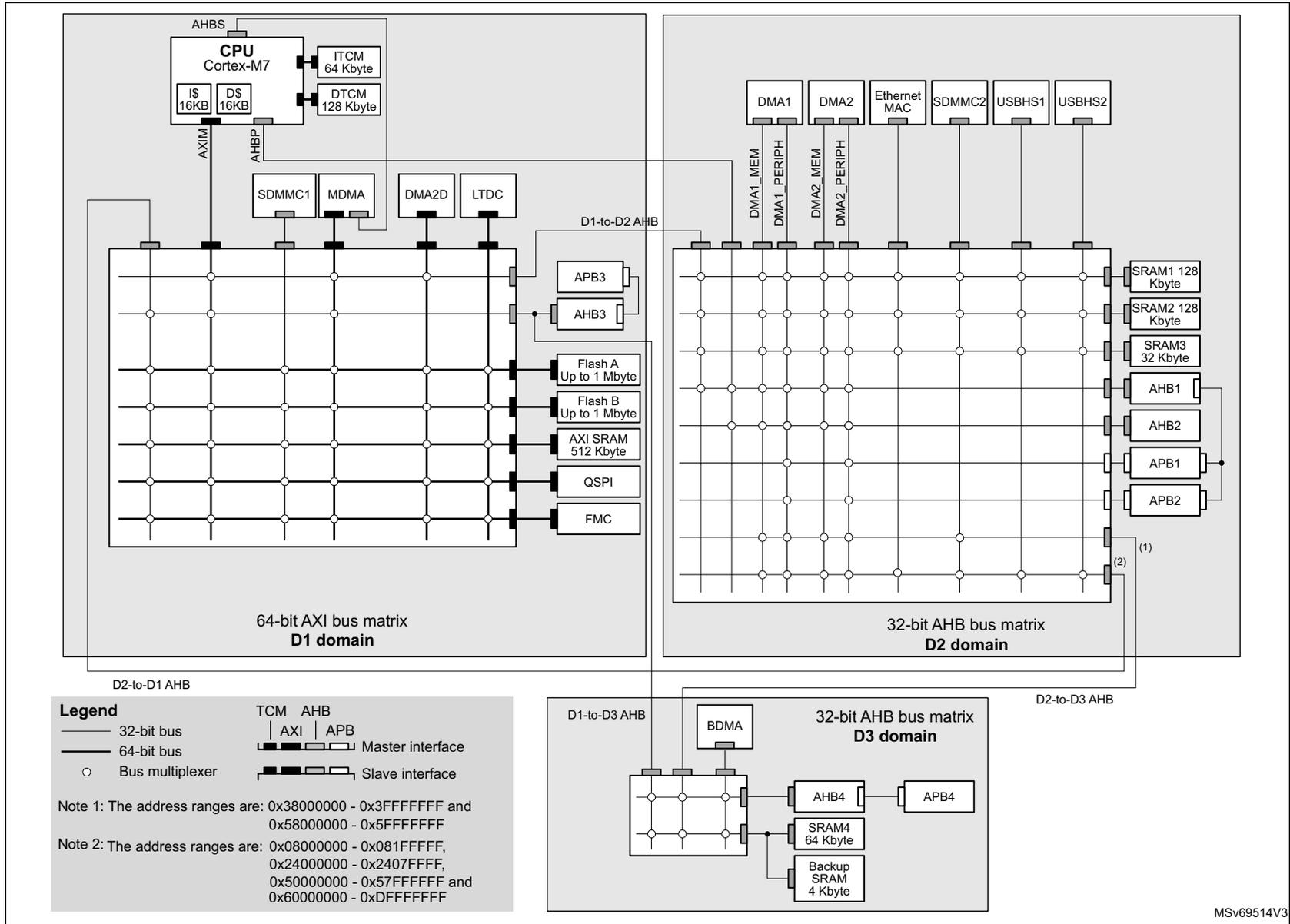
The I/O configuration can be locked if needed by following a specific sequence in order to avoid spurious writing to the I/Os registers.

### 3.9 Bus-interconnect matrix

The devices feature an AXI bus matrix, two AHB bus matrices and bus bridges that allow interconnecting bus masters with bus slaves (see [Figure 3](#)).



Figure 3. STM32H753xl bus matrix



MSv69514V3

### 3.10 DMA controllers

The devices feature four DMA instances to unload CPU activity:

- A master direct memory access (MDMA)  
The MDMA is a high-speed DMA controller, which is in charge of all types of memory transfers (peripheral to memory, memory to memory, memory to peripheral), without any CPU action. It features a master AXI interface and a dedicated AHB interface to access Cortex<sup>®</sup>-M7 TCM memories.  
The MDMA is located in D1 domain. It is able to interface with the other DMA controllers located in D2 domain to extend the standard DMA capabilities, or can manage peripheral DMA requests directly.  
Each of the 16 channels can perform single block transfers, repeated block transfers and linked list transfers.
- Two dual-port DMAs (DMA1, DMA2) located in D2 domain, with FIFO and request router capabilities.
- One basic DMA (BDMA) located in D3 domain, with request router capabilities.

The DMA request router could be considered as an extension of the DMA controller. It routes the DMA peripheral requests to the DMA controller itself. This allowing managing the DMA requests with a high flexibility, maximizing the number of DMA requests that run concurrently, as well as generating DMA requests from peripheral output trigger or DMA event.

### 3.11 Chrom-ART Accelerator (DMA2D)

The Chrom-Art Accelerator (DMA2D) is a graphical accelerator which offers advanced bit blitting, row data copy and pixel format conversion. It supports the following functions:

- Rectangle filling with a fixed color
- Rectangle copy
- Rectangle copy with pixel format conversion
- Rectangle composition with blending and pixel format conversion

Various image format coding are supported, from indirect 4bpp color mode up to 32bpp direct color. It embeds dedicated memory to store color lookup tables. The DMA2D also supports block based YCbCr to handle JPEG decoder output.

An interrupt can be generated when an operation is complete or at a programmed watermark.

All the operations are fully automatized and are running independently from the CPU or the DMAs.

### 3.12 Nested vectored interrupt controller (NVIC)

The devices embed a nested vectored interrupt controller which is able to manage 16 priority levels, and handle up to 150 maskable interrupt channels plus the 16 interrupt lines of the Cortex<sup>®</sup>-M7 with FPU core.

- Closely coupled NVIC gives low-latency interrupt processing
- Interrupt entry vector table address passed directly to the core
- Allows early processing of interrupts
- Processing of late arriving, higher-priority interrupts
- Support tail chaining
- Processor context automatically saved on interrupt entry, and restored on interrupt exit with no instruction overhead

This hardware block provides flexible interrupt management features with minimum interrupt latency.

### 3.13 Extended interrupt and event controller (EXTI)

The EXTI controller performs interrupt and event management. In addition, it can wake up the processor, power domains and/or D3 domain from Stop mode.

The EXTI handles up to 89 independent event/interrupt lines split as 28 configurable events and 61 direct events .

Configurable events have dedicated pending flags, active edge selection, and software trigger capable.

Direct events provide interrupts or events from peripherals having a status flag.

### 3.14 Cyclic redundancy check calculation unit (CRC)

The CRC (cyclic redundancy check) calculation unit is used to get a CRC code using a programmable polynomial.

Among other applications, CRC-based techniques are used to verify data transmission or storage integrity. In the scope of the EN/IEC 60335-1 standard, they offer a means of verifying the flash memory integrity. The CRC calculation unit helps compute a signature of the software during runtime, to be compared with a reference signature generated at link-time and stored at a given memory location.

### 3.15 Flexible memory controller (FMC)

The FMC controller main features are the following:

- Interface with static-memory mapped devices including:
  - Static random access memory (SRAM)
  - NOR flash memory/OneNAND flash memory
  - PSRAM (4 memory banks)
  - NAND flash memory with ECC hardware to check up to 8 Kbytes of data
- Interface with synchronous DRAM (SDRAM/Mobile LPDDR SDRAM) memories
- 8-,16-,32-bit data bus width
- Independent Chip Select control for each memory bank
- Independent configuration for each memory bank
- Write FIFO
- Read FIFO for SDRAM controller
- The maximum FMC\_CLK/FMC\_SDCLK frequency for synchronous accesses is the FMC kernel clock divided by 2.

### 3.16 Quad-SPI memory interface (QUADSPI)

All devices embed a Quad-SPI memory interface, which is a specialized communication interface targeting Single, Dual or Quad-SPI flash memories. It supports both single and double datarate operations.

It can operate in any of the following modes:

- Direct mode through registers
- External flash status register polling mode
- Memory mapped mode.

Up to 256 Mbytes of external flash memory can be mapped, and 8-, 16- and 32-bit data accesses are supported as well as code execution.

The opcode and the frame format are fully programmable.

### 3.17 Analog-to-digital converters (ADCs)

The STM32H753xl devices embed three analog-to-digital converters, which resolution can be configured to 16, 14, 12, 10 or 8 bits.

Each ADC shares up to 20 external channels, performing conversions in the Single-shot or Scan mode. In Scan mode, automatic conversion is performed on a selected group of analog inputs.

Additional logic functions embedded in the ADC interface allow:

- Simultaneous sample and hold
- Interleaved sample and hold

The ADC can be served by the DMA controller, thus allowing to automatically transfer ADC converted values to a destination location without any software action.

In addition, an analog watchdog feature can accurately monitor the converted voltage of one, some or all selected channels. An interrupt is generated when the converted voltage is outside the programmed thresholds.

To synchronize A/D conversion and timers, the ADCs could be triggered by any of TIM1, TIM2, TIM3, TIM4, TIM6, TIM8, TIM15, HRTIM1 and LPTIM1 timer.

### 3.18 Temperature sensor

STM32H753xI devices embed a temperature sensor that generates a voltage ( $V_{TS}$ ) that varies linearly with the temperature. This temperature sensor is internally connected to ADC3\_IN18. The conversion range is between 1.7 V and 3.6 V. It can measure the device junction temperature ranging from  $-40$  up to  $+125$  °C.

The temperature sensor have a good linearity, but it has to be calibrated to obtain a good overall accuracy of the temperature measurement. As the temperature sensor offset varies from chip to chip due to process variation, the uncalibrated internal temperature sensor is suitable for applications that detect temperature changes only. To improve the accuracy of the temperature sensor measurement, each device is individually factory-calibrated by ST. The temperature sensor factory calibration data are stored by ST in the System memory area, which is accessible in Read-only mode.

### 3.19 $V_{BAT}$ operation

The  $V_{BAT}$  power domain contains the RTC, the backup registers and the backup SRAM.

To optimize battery duration, this power domain is supplied by  $V_{DD}$  when available or by the voltage applied on VBAT pin (when  $V_{DD}$  supply is not present).  $V_{BAT}$  power is switched when the PDR detects that  $V_{DD}$  dropped below the PDR level.

The voltage on the VBAT pin could be provided by an external battery, a supercapacitor or directly by  $V_{DD}$ , in which case, the  $V_{BAT}$  mode is not functional.

$V_{BAT}$  operation is activated when  $V_{DD}$  is not present.

The  $V_{BAT}$  pin supplies the RTC, the backup registers and the backup SRAM.

**Note:** *When the microcontroller is supplied from  $V_{BAT}$ , external interrupts and RTC alarm/events do not exit it from  $V_{BAT}$  operation.*

*When PDR\_ON pin is connected to  $V_{SS}$  (Internal Reset OFF), the  $V_{BAT}$  functionality is no more available and  $V_{BAT}$  pin should be connected to  $V_{DD}$ .*

### 3.20 Digital-to-analog converters (DAC)

The two 12-bit buffered DAC channels can be used to convert two digital signals into two analog voltage signal outputs.

This dual digital Interface supports the following features:

- two DAC converters: one for each output channel
- 8-bit or 12-bit monotonic output
- left or right data alignment in 12-bit mode
- synchronized update capability
- noise-wave generation
- triangular-wave generation
- dual DAC channel independent or simultaneous conversions
- DMA capability for each channel including DMA underrun error detection
- external triggers for conversion
- input voltage reference  $V_{REF+}$  or internal VREFBUF reference.

The DAC channels are triggered through the timer update outputs that are also connected to different DMA streams.

### 3.21 Ultra-low-power comparators (COMP)

STM32H753xl devices embed two rail-to-rail comparators (COMP1 and COMP2). They feature programmable reference voltage (internal or external), hysteresis and speed (low speed for low-power) as well as selectable output polarity.

The reference voltage can be one of the following:

- An external I/O
- A DAC output channel
- An internal reference voltage or submultiple (1/4, 1/2, 3/4).

All comparators can wake up from Stop mode, generate interrupts and breaks for the timers, and be combined into a window comparator.

### 3.22 Operational amplifiers (OPAMP)

STM32H753xl devices embed two rail-to-rail operational amplifiers (OPAMP1 and OPAMP2) with external or internal follower routing and PGA capability.

The operational amplifier main features are:

- PGA with a non-inverting gain ranging of 2, 4, 8 or 16 or inverting gain ranging of -1, -3, -7 or -15
- One positive input connected to DAC
- Output connected to internal ADC
- Low input bias current down to 1 nA
- Low input offset voltage down to 1.5 mV
- Gain bandwidth up to 7.3 MHz

The device embeds two operational amplifiers (OPAMP1 and OPAMP2) with two inputs and one output each. These three I/Os can be connected to the external pins, thus enabling any type of external interconnections. The operational amplifiers can be configured internally as a follower, as an amplifier with a non-inverting gain ranging from 2 to 16 or with inverting gain ranging from -1 to -15.

### 3.23 Digital filter for sigma-delta modulators (DFSDM)

The device embeds one DFSDM with 4 digital filter modules and 8 external input serial channels (transceivers) or alternately 8 internal parallel inputs support.

The DFSDM peripheral is dedicated to interface the external  $\Sigma\Delta$  modulators to microcontroller and then to perform digital filtering of the received data streams (which represent analog value on  $\Sigma\Delta$  modulators inputs). DFSDM can also interface PDM (Pulse Density Modulation) microphones and perform PDM to PCM conversion and filtering in hardware. DFSDM features optional parallel data stream inputs from internal ADC peripherals or microcontroller memory (through DMA/CPU transfers into DFSDM).

DFSDM transceivers support several serial interface formats (to support various  $\Sigma\Delta$  modulators). DFSDM digital filter modules perform digital processing according to user selected filter parameters with up to 24-bit final ADC resolution.

The DFSDM peripheral supports:

- 8 multiplexed input digital serial channels:
  - configurable SPI interface to connect various SD modulator(s)
  - configurable Manchester coded 1 wire interface support
  - PDM (Pulse Density Modulation) microphone input support
  - maximum input clock frequency up to 20 MHz (10 MHz for Manchester coding)
  - clock output for SD modulator(s): 0..20 MHz
- alternative inputs from 8 internal digital parallel channels (up to 16 bit input resolution):
  - internal sources: ADC data or memory data streams (DMA)
- 4 digital filter modules with adjustable digital signal processing:
  - Sinc<sup>x</sup> filter: filter order/type (1..5), oversampling ratio (up to 1..1024)
  - integrator: oversampling ratio (1..256)
- up to 24-bit output data resolution, signed output data format
- automatic data offset correction (offset stored in register by user)
- continuous or single conversion
- start-of-conversion triggered by:
  - software trigger
  - internal timers
  - external events
  - start-of-conversion synchronously with first digital filter module (DFSDM0)
- analog watchdog feature:
  - low value and high value data threshold registers
  - dedicated configurable Sinc<sup>x</sup> digital filter (order = 1..3, oversampling ratio = 1..32)
  - input from final output data or from selected input digital serial channels
  - continuous monitoring independently from standard conversion

- short circuit detector to detect saturated analog input values (bottom and top range):
  - up to 8-bit counter to detect 1..256 consecutive 0's or 1's on serial data stream
  - monitoring continuously each input serial channel
- break signal generation on analog watchdog event or on short circuit detector event
- extremes detector:
  - storage of minimum and maximum values of final conversion data
  - refreshed by software
- DMA capability to read the final conversion data
- interrupts: end of conversion, overrun, analog watchdog, short circuit, input serial channel clock absence
- “regular” or “injected” conversions:
  - “regular” conversions can be requested at any time or even in Continuous mode without having any impact on the timing of “injected” conversions
  - “injected” conversions for precise timing and with high conversion priority

**Table 4. DFSDM implementation**

| DFSDM features   | DFSDM1 |
|--|--------|
| Number of filters                                      | 4      |
| Number of input transceivers/channels                  | 8      |
| Internal ADC parallel input                            | X      |
| Number of external triggers                            | 16     |
| Regular channel information in identification register | X      |

### 3.24 Digital camera interface (DCMI)

The devices embed a camera interface that can connect with camera modules and CMOS sensors through an 8-bit to 14-bit parallel interface, to receive video data. The camera interface can achieve a data transfer rate up to 140 Mbyte/s using a 80 MHz pixel clock. It features:

- Programmable polarity for the input pixel clock and synchronization signals
- Parallel data communication can be 8-, 10-, 12- or 14-bit
- Supports 8-, 10-, 12- and 14-bit progressive video monochrome or raw bayer format, YCbCr 4:2:2 progressive video, RGB 565 progressive video or compressed data (like JPEG)
- Supports Continuous mode or Snapshot (a single frame) mode
- Capability to automatically crop the image

### 3.25 LCD-TFT controller

The LCD-TFT display controller provides a 24-bit parallel digital RGB (Red, Green, Blue) and delivers all signals to interface directly to a broad range of LCD and TFT panels up to XGA (1024x768) resolution with the following features:

- 2 display layers with dedicated FIFO (64x64-bit)
- Color Look-Up table (CLUT) up to 256 colors (256x24-bit) per layer
- Up to 8 input color formats selectable per layer
- Flexible blending between two layers using alpha value (per pixel or constant)
- Flexible programmable parameters for each layer
- Color keying (transparency color)
- Up to 4 programmable interrupt events
- AXI master interface with burst of 16 words

### 3.26 JPEG Codec (JPEG)

The JPEG Codec can encode and decode a JPEG stream as defined in the *ISO/IEC 10918-1* specification. It provides an fast and simple hardware compressor and decompressor of JPEG images with full management of JPEG headers.

The JPEG codec main features are as follows:

- 8-bit/channel pixel depths
- Single clock per pixel encoding and decoding
- Support for JPEG header generation and parsing
- Up to four programmable quantization tables
- Fully programmable Huffman tables (two AC and two DC)
- Fully programmable minimum coded unit (MCU)
- Encode/decode support (non simultaneous)
- Single clock Huffman coding and decoding
- Two-channel interface: Pixel/Compress In, Pixel/Compressed Out
- Support for single greyscale component
- Ability to enable/disable header processing
- Fully synchronous design
- Configuration for High-speed decode mode

### 3.27 True random number generator (RNG)

The RNG is a true random number generator that provides full entropy outputs to the application as 32-bit samples. It is composed of a live entropy source (analog) and an internal conditioning component.

### 3.28 Cryptographic acceleration (CRYP and HASH)

The devices embed a cryptographic processor that supports the advanced cryptographic algorithms usually required to ensure confidentiality, authentication, data integrity and non-repudiation when exchanging messages with a peer:

- Encryption/Decryption
  - DES/TDES (data encryption standard/triple data encryption standard): ECB (electronic codebook) and CBC (cipher block chaining) chaining algorithms, 64-, 128- or 192-bit key
  - AES (advanced encryption standard): ECB, CBC, GCM, CCM, and CTR (Counter mode) chaining algorithms, 128, 192 or 256-bit key
- Universal HASH
  - SHA-1 and SHA-2 (secure HASH algorithms)
  - MD5
  - HMAC

The cryptographic accelerator supports DMA request generation.

### 3.29 Timers and watchdogs

The devices include one high-resolution timer, two advanced-control timers, ten general-purpose timers, two basic timers, five low-power timers, two watchdogs and a SysTick timer.

All timer counters can be frozen in Debug mode.

[Table 5](#) compares the features of the advanced-control, general-purpose and basic timers.

**Table 5. Timer feature comparison**

| Timer type            | Timer      | Counter resolution | Counter type      | Prescaler factor                         | DMA request generation | Capture/compare channels | Complementary output | Max interface clock (MHz) | Max timer clock (MHz) <sup>(1)</sup> |
|-----------------------|------------|--------------------|-------------------|--|------------------------|--------------------------|----------------------|---------------------------|--------------------------------------|
| High-resolution timer | HRTIM1     | 16-bit             | Up                | /1 /2 /4<br>(x2 x4 x8 x16 x32, with DLL) | Yes                    | 10                       | Yes                  | 480                       | 480                                  |
| Advanced-control      | TIM1, TIM8 | 16-bit             | Up, Down, Up/down | Any integer between 1 and 65536          | Yes                    | 4                        | Yes                  | 120                       | 240                                  |

Table 5. Timer feature comparison (continued)

| Timer type      | Timer                                  | Counter resolution | Counter type      | Prescaler factor                | DMA request generation | Capture/compare channels | Complementary output | Max interface clock (MHz) | Max timer clock (MHz) <sup>(1)</sup> |
|-----------------|--|--------------------|-------------------|---------------------------------|------------------------|--------------------------|----------------------|---------------------------|--------------------------------------|
| General purpose | TIM2, TIM5                             | 32-bit             | Up, Down, Up/down | Any integer between 1 and 65536 | Yes                    | 4                        | No                   | 120                       | 240                                  |
|                 | TIM3, TIM4                             | 16-bit             | Up, Down, Up/down | Any integer between 1 and 65536 | Yes                    | 4                        | No                   | 120                       | 240                                  |
|                 | TIM12                                  | 16-bit             | Up                | Any integer between 1 and 65536 | No                     | 2                        | No                   | 120                       | 240                                  |
|                 | TIM13, TIM14                           | 16-bit             | Up                | Any integer between 1 and 65536 | No                     | 1                        | No                   | 120                       | 240                                  |
|                 | TIM15                                  | 16-bit             | Up                | Any integer between 1 and 65536 | Yes                    | 2                        | 1                    | 120                       | 240                                  |
|                 | TIM16, TIM17                           | 16-bit             | Up                | Any integer between 1 and 65536 | Yes                    | 1                        | 1                    | 120                       | 240                                  |
| Basic           | TIM6, TIM7                             | 16-bit             | Up                | Any integer between 1 and 65536 | Yes                    | 0                        | No                   | 120                       | 240                                  |
| Low-power timer | LPTIM1, LPTIM2, LPTIM3, LPTIM4, LPTIM5 | 16-bit             | Up                | 1, 2, 4, 8, 16, 32, 64, 128     | No                     | 0                        | No                   | 120                       | 240                                  |

1. The maximum timer clock is up to 480 MHz depending on TIMPRE bit in the RCC\_CFGR register and D2PRE1/2 bits in RCC\_D2CFGR register.

### 3.29.1 High-resolution timer (HRTIM1)

The high-resolution timer (HRTIM1) allows generating digital signals with high-accuracy timings, such as PWM or phase-shifted pulses.

It consists of 6 timers, 1 master and 5 slaves, totaling 10 high-resolution outputs, which can be coupled by pairs for deadtime insertion. It also features 5 fault inputs for protection purposes and 10 inputs to handle external events such as current limitation, zero voltage or zero current switching.

The HRTIM1 timer is made of a digital kernel clocked at 480 MHz. The high-resolution is available on the 10 outputs in all operating modes: variable duty cycle, variable frequency, and constant ON time.

The slave timers can be combined to control multistage complex converters or operate independently to manage multiple independent converters.

The waveforms are defined by a combination of user-defined timings and external events such as analog or digital feedback signals.

HRTIM1 timer includes options for blanking and filtering out spurious events or faults. It also offers specific modes and features to offload the CPU: DMA requests, Burst mode controller, Push-pull and Resonant mode.

It supports many topologies including LLC, Full bridge phase shifted, buck or boost converters, either in voltage or current mode, as well as lighting application (fluorescent or LED). It can also be used as a general purpose timer, for instance to achieve high-resolution PWM-emulated DAC.

### 3.29.2 Advanced-control timers (TIM1, TIM8)

The advanced-control timers (TIM1, TIM8) can be seen as three-phase PWM generators multiplexed on 6 channels. They have complementary PWM outputs with programmable inserted dead times. They can also be considered as complete general-purpose timers. Their 4 independent channels can be used for:

- Input capture
- Output compare
- PWM generation (Edge- or Center-aligned modes)
- One-pulse mode output

If configured as standard 16-bit timers, they have the same features as the general-purpose TIMx timers. If configured as 16-bit PWM generators, they have full modulation capability (0-100%).

The advanced-control timer can work together with the TIMx timers via the Timer Link feature for synchronization or event chaining.

TIM1 and TIM8 support independent DMA request generation.

### 3.29.3 General-purpose timers (TIMx)

There are ten synchronizable general-purpose timers embedded in the STM32H753xI devices (see [Table 5](#) for differences).

- **TIM2, TIM3, TIM4, TIM5**

The devices include 4 full-featured general-purpose timers: TIM2, TIM3, TIM4 and TIM5. TIM2 and TIM5 are based on a 32-bit auto-reload up/downcounter and a 16-bit prescaler while TIM3 and TIM4 are based on a 16-bit auto-reload up/downcounter and a 16-bit prescaler. All timers feature 4 independent channels for input capture/output compare, PWM or One-pulse mode output. This gives up to 16 input capture/output compare/PWMs on the largest packages.

TIM2, TIM3, TIM4 and TIM5 general-purpose timers can work together, or with the other general-purpose timers and the advanced-control timers TIM1 and TIM8 via the Timer Link feature for synchronization or event chaining.

Any of these general-purpose timers can be used to generate PWM outputs.

TIM2, TIM3, TIM4, TIM5 all have independent DMA request generation. They are capable of handling quadrature (incremental) encoder signals and the digital outputs from 1 to 4 hall-effect sensors.

- **TIM12, TIM13, TIM14, TIM15, TIM16, TIM17**

These timers are based on a 16-bit auto-reload upcounter and a 16-bit prescaler. TIM13, TIM14, TIM16 and TIM17 feature one independent channel, whereas TIM12 and TIM15 have two independent channels for input capture/output compare, PWM or One-pulse mode output. They can be synchronized with the TIM2, TIM3, TIM4, TIM5 full-featured general-purpose timers or used as simple timebases.

### 3.29.4 Basic timers TIM6 and TIM7

These timers are mainly used for DAC trigger and waveform generation. They can also be used as a generic 16-bit time base.

TIM6 and TIM7 support independent DMA request generation.

### 3.29.5 Low-power timers (LPTIM1, LPTIM2, LPTIM3, LPTIM4, LPTIM5)

The low-power timers have an independent clock and is running also in Stop mode if it is clocked by LSE, LSI or an external clock. It is able to wakeup the devices from Stop mode.

This low-power timer supports the following features:

- 16-bit up counter with 16-bit autoreload register
- 16-bit compare register
- Configurable output: pulse, PWM
- Continuous / One-shot mode
- Selectable software / hardware input trigger
- Selectable clock source:
  - Internal clock source: LSE, LSI, HSI or APB clock
  - External clock source over LPTIM input (working even with no internal clock source running, used by the Pulse Counter Application)
- Programmable digital glitch filter
- Encoder mode

### 3.29.6 Independent watchdog

The independent watchdog is based on a 12-bit downcounter and 8-bit prescaler. It is clocked from an independent 32 kHz internal RC and as it operates independently from the main clock, it can operate in Stop and Standby modes. It can be used either as a watchdog to reset the device when a problem occurs, or as a free-running timer for application timeout management. It is hardware- or software-configurable through the option bytes.

### 3.29.7 Window watchdog

The window watchdog is based on a 7-bit downcounter that can be set as free-running. It can be used as a watchdog to reset the device when a problem occurs. It is clocked from the main clock. It has an early warning interrupt capability and the counter can be frozen in Debug mode.

### 3.29.8 SysTick timer

This timer is dedicated to real-time operating systems, but could also be used as a standard downcounter. It features:

- A 24-bit downcounter
- Autoreload capability
- Maskable system interrupt generation when the counter reaches 0
- Programmable clock source.

### 3.30 Real-time clock (RTC), backup SRAM and backup registers

The RTC is an independent BCD timer/counter. It supports the following features:

- Calendar with subsecond, seconds, minutes, hours (12 or 24 format), week day, date, month, year, in BCD (binary-coded decimal) format.
- Automatic correction for 28, 29 (leap year), 30, and 31 days of the month.
- Two programmable alarms.
- On-the-fly correction from 1 to 32767 RTC clock pulses. This can be used to synchronize it with a master clock.
- Reference clock detection: a more precise second source clock (50 or 60 Hz) can be used to enhance the calendar precision.
- Digital calibration circuit with 0.95 ppm resolution, to compensate for quartz crystal inaccuracy.
- Three anti-tamper detection pins with programmable filter.
- Timestamp feature which can be used to save the calendar content. This function can be triggered by an event on the timestamp pin, or by a tamper event, or by a switch to  $V_{BAT}$  mode.
- 17-bit auto-reload wakeup timer (WUT) for periodic events with programmable resolution and period.

The RTC and the 32 backup registers are supplied through a switch that takes power either from the  $V_{DD}$  supply when present or from the  $V_{BAT}$  pin.

The backup registers are 32-bit registers used to store 128 bytes of user application data when  $V_{DD}$  power is not present. They are not reset by a system or power reset, or when the device wakes up from Standby mode.

The RTC clock sources can be:

- A 32.768 kHz external crystal (LSE)
- An external resonator or oscillator (LSE)
- The internal low-power RC oscillator (LSI, with typical frequency of 32 kHz)
- The high-speed external clock (HSE) divided by 32.

The RTC is functional in  $V_{BAT}$  mode and in all low-power modes when it is clocked by the LSE. When clocked by the LSI, the RTC is not functional in  $V_{BAT}$  mode, but is functional in all low-power modes.

All RTC events (Alarm, Wakeup Timer, Timestamp or Tamper) can generate an interrupt and wakeup the device from the low-power modes.

### 3.31 Inter-integrated circuit interface (I2C)

STM32H753xl devices embed four I<sup>2</sup>C interfaces.

The I<sup>2</sup>C bus interface handles communications between the microcontroller and the serial I<sup>2</sup>C bus. It controls all I<sup>2</sup>C bus-specific sequencing, protocol, arbitration and timing.

The I2C peripheral supports:

- I<sup>2</sup>C-bus specification and user manual rev. 5 compatibility:
  - Target and controller modes, multicontroller capability
  - Standard-mode (Sm), with a bitrate up to 100 kbit/s
  - Fast-mode (Fm), with a bitrate up to 400 kbit/s
  - Fast-mode Plus (Fm+), with a bitrate up to 1 Mbit/s and 20 mA output drive I/Os
  - 7-bit and 10-bit addressing mode, multiple 7-bit target addresses
  - Programmable setup and hold times
  - Optional clock stretching
- System Management Bus (SMBus) specification rev 2.0 compatibility:
  - Hardware PEC (Packet Error Checking) generation and verification with ACK control
  - Address resolution protocol (ARP) support
  - SMBus alert
- Power System Management Protocol (PMBus™) specification rev 1.1 compatibility
- Independent clock: a choice of independent clock sources allowing the I2C communication speed to be independent from the PCLK reprogramming.
- Wakeup from Stop mode on address match
- Programmable analog and digital noise filters
- 1-byte buffer with DMA capability

### 3.32 Universal synchronous/asynchronous receiver transmitter (USART)

STM32H753xl devices have four embedded universal synchronous receiver transmitters (USART1, USART2, USART3 and USART6) and four universal asynchronous receiver transmitters (UART4, UART5, UART7 and UART8). Refer to [Table 6](#) for a summary of USARTx and UARTx features.

These interfaces provide asynchronous communication, IrDA SIR ENDEC support, multiprocessor communication mode, single-wire Half-duplex communication mode and have LIN Master/Slave capability. They provide hardware management of the CTS and RTS signals, and RS485 Driver Enable. They are able to communicate at speeds of up to 12.5 Mbit/s.

USART1, USART2, USART3 and USART6 also provide Smartcard mode (ISO 7816 compliant) and SPI-like communication capability.

The USARTs embed a Transmit FIFO (TXFIFO) and a Receive FIFO (RXFIFO). FIFO mode is enabled by software and is disabled by default.

All USART have a clock domain independent from the CPU clock, allowing the USARTx to wake up the MCU from Stop mode. The wakeup from Stop mode is programmable and can be done on:

- Start bit detection
- Any received data frame
- A specific programmed data frame
- Specific TXFIFO/RXFIFO status when FIFO mode is enabled.

All USART interfaces can be served by the DMA controller.

**Table 6. USART features**

| USART modes/features <sup>(1)</sup>              | USART1/2/3/6    | UART4/5/7/8 |
|--|-----------------|-------------|
| Hardware flow control for modem                  | X               | X           |
| Continuous communication using DMA               | X               | X           |
| Multiprocessor communication                     | X               | X           |
| Synchronous SPI mode (master/slave)              | X               | -           |
| Smartcard mode                                   | X               | -           |
| Single-wire Half-duplex communication            | X               | X           |
| IrDA SIR ENDEC block                             | X               | X           |
| LIN mode   | X               | X           |
| Dual clock domain and wakeup from low power mode | X               | X           |
| Receiver timeout interrupt                       | X               | X           |
| Modbus communication                             | X               | X           |
| Auto baud rate detection                         | X               | X           |
| Driver Enable                                    | X               | X           |
| USART data length                                | 7, 8 and 9 bits |             |
| Tx/Rx FIFO                                       | X               | X           |
| Tx/Rx FIFO size                                  | 16              |             |

1. X = supported.

### 3.33 Low-power universal asynchronous receiver transmitter (LPUART)

The device embeds one Low-Power UART (LPUART1). The LPUART supports asynchronous serial communication with minimum power consumption. It supports half duplex single wire communication and modem operations (CTS/RTS). It allows multiprocessor communication.

The LPUARTs embed a Transmit FIFO (TXFIFO) and a Receive FIFO (RXFIFO). FIFO mode is enabled by software and is disabled by default.

The LPUART has a clock domain independent from the CPU clock, and can wakeup the system from Stop mode. The wakeup from Stop mode are programmable and can be done on:

- Start bit detection
- Any received data frame
- A specific programmed data frame
- Specific TXFIFO/RXFIFO status when FIFO mode is enabled.

Only a 32.768 kHz clock (LSE) is needed to allow LPUART communication up to 9600 baud. Therefore, even in Stop mode, the LPUART can wait for an incoming frame while having an extremely low energy consumption. Higher speed clock can be used to reach higher baudrates.

LPUART interface can be served by the DMA controller.

### 3.34 Serial peripheral interfaces (SPI)/integrated interchip sound interfaces (I2S)

The devices feature up to six SPIs (SPI2S1, SPI2S2, SPI2S3, SPI4, SPI5 and SPI6) that allow communicating up to 150 Mbits/s in Master and Slave modes, in Half-duplex, Full-duplex and Simplex modes. The 3-bit prescaler gives 8 master mode frequencies and the frame is configurable from 4 to 16 bits. All SPI interfaces support NSS pulse mode, TI mode, Hardware CRC calculation and 8x 8-bit embedded Rx and Tx FIFOs with DMA capability.

Three standard I<sup>2</sup>S interfaces (multiplexed with SPI1, SPI2 and SPI3) are available. They can be operated in Master or Slave mode, in Simplex or Full-duplex communication mode, and can be configured to operate with a 16-/32-bit resolution as an input or output channel. Audio sampling frequencies from 8 kHz up to 192 kHz are supported. When either or both of the I<sup>2</sup>S interfaces is/are configured in Master mode, the master clock can be output to the external DAC/CODEC at 256 times the sampling frequency. All I<sup>2</sup>S interfaces support 16x 8-bit embedded Rx and Tx FIFOs with DMA capability.

### 3.35 Serial audio interfaces (SAI)

The devices embed 4 SAIs (SAI1, SAI2, SAI3 and SAI4) that allow designing many stereo or mono audio protocols such as I2S, LSB or MSB-justified, PCM/DSP, TDM or AC'97. An SPDIF output is available when the audio block is configured as a transmitter. To bring this level of flexibility and reconfigurability, the SAI contains two independent audio sub-blocks. Each block has its own clock generator and I/O line controller.

Audio sampling frequencies up to 192 kHz are supported.

In addition, up to 6 microphones can be supported thanks to an embedded PDM interface. The SAI can work in master or slave configuration. The audio sub-blocks can be either receiver or transmitter and can work synchronously or asynchronously (with respect to the other one). The SAI can be connected with other SAIs to work synchronously.

### 3.36 SPDIFRX Receiver Interface (SPDIFRX)

The SPDIFRX peripheral is designed to receive an S/PDIF flow compliant with IEC-60958 and IEC-61937. These standards support simple stereo streams up to high sample rate, and compressed multi-channel surround sound, such as those defined by Dolby or DTS (up to 5.1).

The main SPDIFRX features are the following:

- Up to 4 inputs available
- Automatic symbol rate detection
- Maximum symbol rate: 12.288 MHz
- Stereo stream from 32 to 192 kHz supported
- Supports Audio IEC-60958 and IEC-61937, consumer applications
- Parity bit management
- Communication using DMA for audio samples
- Communication using DMA for control and user channel information
- Interrupt capabilities

The SPDIFRX receiver provides all the necessary features to detect the symbol rate, and decode the incoming data stream. The user can select the wanted SPDIF input, and when a valid signal will be available, the SPDIFRX will re-sample the incoming signal, decode the Manchester stream, recognize frames, sub-frames and blocks elements. It delivers to the CPU decoded data, and associated status flags.

The SPDIFRX also offers a signal named `spdif_frame_sync`, which toggles at the S/PDIF sub-frame rate that will be used to compute the exact sample rate for clock drift algorithms.

### 3.37 Single wire protocol master interface (SWPMI)

The Single wire protocol master interface (SWPMI) is the master interface corresponding to the Contactless Frontend (CLF) defined in the ETSI TS 102 613 technical specification. The main features are:

- Full-duplex communication mode
- automatic SWP bus state management (active, suspend, resume)
- configurable bitrate up to 2 Mbit/s
- automatic SOF, EOF and CRC handling

SWPMI can be served by the DMA controller.

### 3.38 Management Data Input/Output (MDIO) slaves

The devices embed an MDIO slave interface it includes the following features:

- 32 MDIO Registers addresses, each of which is managed using separate input and output data registers:
  - 32 x 16-bit firmware read/write, MDIO read-only output data registers
  - 32 x 16-bit firmware read-only, MDIO write-only input data registers
- Configurable slave (port) address
- Independently maskable interrupts/events:
  - MDIO Register write
  - MDIO Register read
  - MDIO protocol error
- Able to operate in and wake up from Stop mode

### 3.39 SD/SDIO/MMC card host interfaces (SDMMC)

Two SDMMC host interfaces are available. They support *MultiMediaCard System Specification Version 4.51* in three different databus modes: 1 bit (default), 4 bits and 8 bits.

Both interfaces support the *SD memory card specifications version 4.1*. and the *SDIO card specification version 4.0*. in two different databus modes: 1 bit (default) and 4 bits.

Each SDMMC host interface supports only one SD/SDIO/MMC card at any one time and a stack of MMC Version 4.51 or previous.

The SDMMC host interface embeds a dedicated DMA controller allowing high-speed transfers between the interface and the SRAM.

### 3.40 Controller area network (FDCAN1, FDCAN2)

The controller area network (CAN) subsystem consists of two CAN modules, a shared message RAM memory and a clock calibration unit.

Both CAN modules (FDCAN1 and FDCAN2) are compliant with ISO 11898-1 (CAN protocol specification version 2.0 part A, B) and CAN FD protocol specification version 1.0.

FDCAN1 supports time triggered CAN (TT-FDCAN) specified in ISO 11898-4, including event synchronized time-triggered communication, global system time, and clock drift compensation. The FDCAN1 contains additional registers, specific to the time triggered feature. The CAN FD option can be used together with event-triggered and time-triggered CAN communication.

A 10-Kbyte message RAM memory implements filters, receive FIFOs, receive buffers, transmit event FIFOs, transmit buffers (and triggers for TT-FDCAN). This message RAM is shared between the two FDCAN1 and FDCAN2 modules.

The common clock calibration unit is optional. It can be used to generate a calibrated clock for both FDCAN1 and FDCAN2 from the HSI internal RC oscillator and the PLL, by evaluating CAN messages received by the FDCAN1.

### 3.41 Universal serial bus on-the-go high-speed (OTG\_HS)

The devices embed two USB OTG high-speed (up to 480 Mbit/s) device/host/OTG peripheral. OTG\_HS1 supports both full-speed and high-speed operations, while OTG\_HS2 supports only full-speed operations. They both integrate the transceivers for full-speed operation (12 Mbit/s) and are able to operate from the internal HSI48 oscillator. OTG\_HS1 features a UTMI low-pin interface (ULPI) for high-speed operation (480 Mbit/s). When using the USB OTG\_HS1 in HS mode, an external PHY device connected to the ULPI is required.

The USB OTG HS peripherals are compliant with the USB 2.0 specification and with the OTG 2.0 specification. They have software-configurable endpoint setting and supports suspend/resume. The USB OTG controllers require a dedicated 48 MHz clock that is generated by a PLL connected to the HSE oscillator.

The main features are:

- Combined Rx and Tx FIFO size of 4 Kbytes with dynamic FIFO sizing
- Supports the session request protocol (SRP) and host negotiation protocol (HNP)
- 9 bidirectional endpoints (including EP0)
- 16 host channels with periodic OUT support
- Software configurable to OTG1.3 and OTG2.0 modes of operation
- USB 2.0 LPM (Link Power Management) support
- Battery Charging Specification Revision 1.2 support
- Internal FS OTG PHY support
- External HS or HS OTG operation supporting ULPI in SDR mode (OTG\_HS1 only)

The OTG PHY is connected to the microcontroller ULPI port through 12 signals. It can be clocked using the 60 MHz output.

- Internal USB DMA
- HNP/SNP/IP inside (no need for any external resistor)
- For OTG/Host modes, a power switch is needed in case bus-powered devices are connected

### 3.42 Ethernet MAC interface with dedicated DMA controller (ETH)

The devices provide an IEEE-802.3-2002-compliant media access controller (MAC) for ethernet LAN communications through an industry-standard medium-independent interface (MII) or a reduced medium-independent interface (RMII). The microcontroller requires an external physical interface device (PHY) to connect to the physical LAN bus (twisted-pair, fiber, etc.). The PHY is connected to the device MII port using 17 signals for MII or 9 signals for RMII, and can be clocked using the 25 MHz (MII) from the microcontroller.

The devices include the following features:

- Supports 10 and 100 Mbit/s rates
- Dedicated DMA controller allowing high-speed transfers between the dedicated SRAM and the descriptors
- Tagged MAC frame support (VLAN support)
- Half-duplex (CSMA/CD) and full-duplex operation
- MAC control sublayer (control frames) support
- 32-bit CRC generation and removal
- Several address filtering modes for physical and multicast address (multicast and group addresses)
- 32-bit status code for each transmitted or received frame
- Internal FIFOs to buffer transmit and receive frames. The transmit FIFO and the receive FIFO are both 2 Kbytes.
- Supports hardware PTP (precision time protocol) in accordance with IEEE 1588 2008 (PTP V2) with the time stamp comparator connected to the TIM2 input
- Triggers interrupt when system time becomes greater than target time

### 3.43 High-definition multimedia interface (HDMI) - consumer electronics control (CEC)

The devices embed a HDMI-CEC controller that provides hardware support for the Consumer Electronics Control (CEC) protocol (Supplement 1 to the HDMI standard).

This protocol provides high-level control functions between all audiovisual products in an environment. It is specified to operate at low speeds with minimum processing and memory overhead. It has a clock domain independent from the CPU clock, allowing the HDMI-CEC controller to wakeup the MCU from Stop mode on data reception.

### 3.44 Debug infrastructure

The devices offer a comprehensive set of debug and trace features to support software development and system integration.

- Breakpoint debugging
- Code execution tracing
- Software instrumentation
- JTAG debug port
- Serial-wire debug port
- Trigger input and output
- Serial-wire trace port
- Trace port
- Arm® CoreSight™ debug and trace components

The debug can be controlled via a JTAG/Serial-wire debug access port, using industry standard debugging tools.

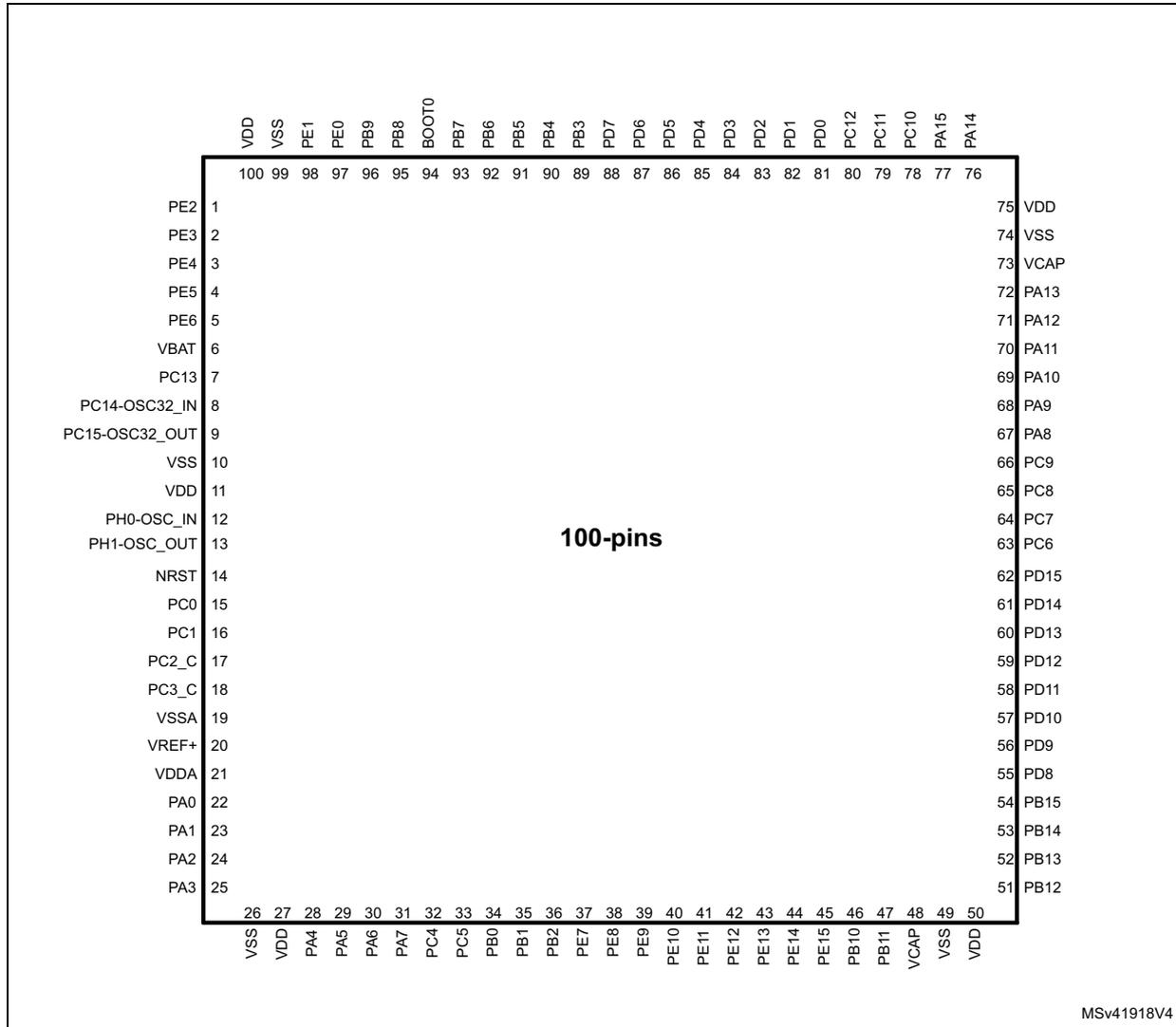
The trace port performs data capture for logging and analysis.

## 4 Memory mapping

Refer to the product line reference manual for details on the memory mapping as well as the boundary addresses for all peripherals.

# 5 Pinout, pin description and alternate functions

Figure 4. LQFP100 pinout



MSv41918V4

1. The above figure shows the package top view.

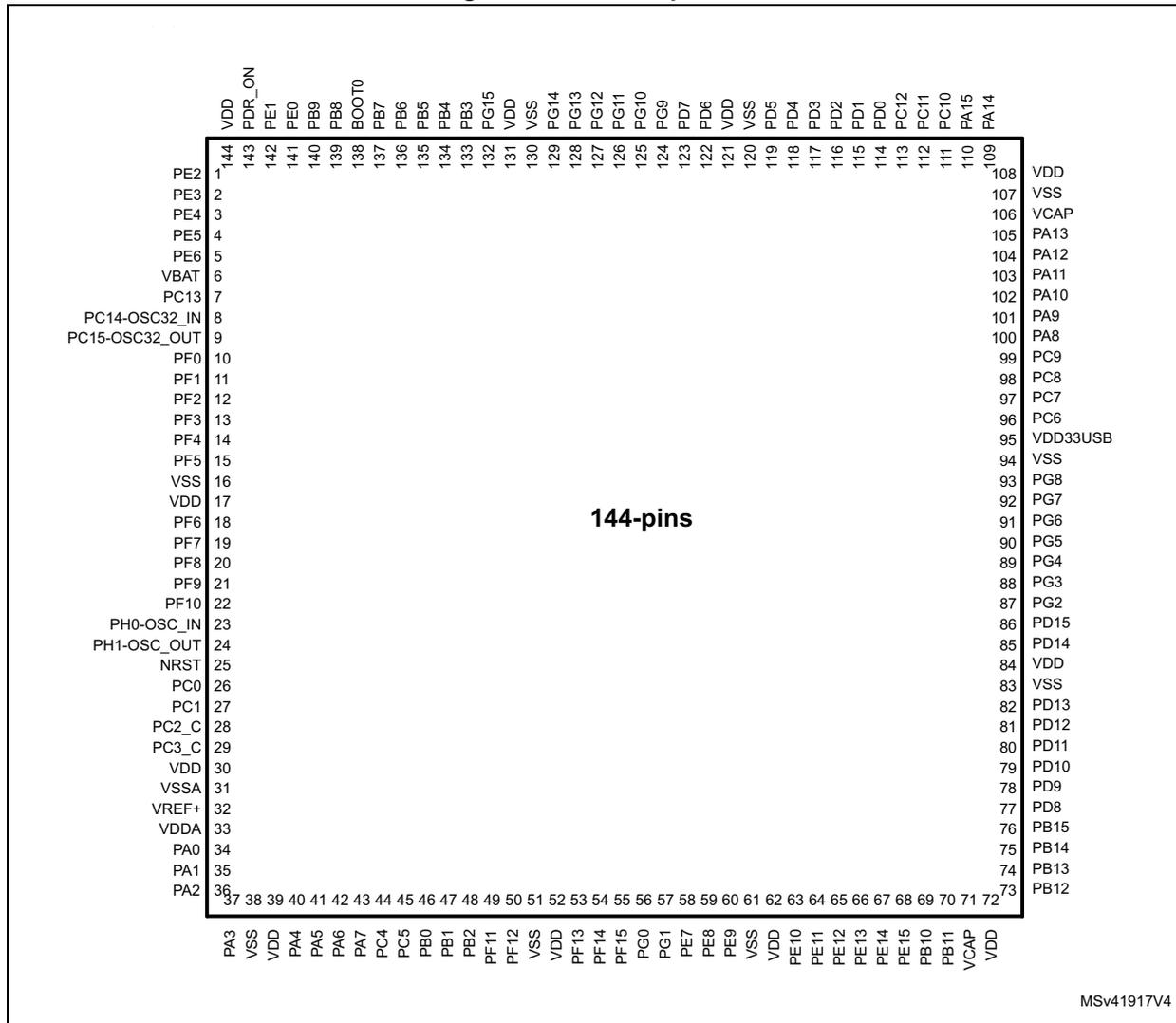
Figure 5. TFBGA100 ballout

|   | 1              | 2     | 3     | 4      | 5     | 6        | 7      | 8    | 9    | 10   |
|---|----------------|-------|-------|--------|-------|----------|--------|------|------|------|
| A | PC14-OSC32_IN  | PC13  | PE2   | PB9    | PB7   | PB4      | PB3    | PA15 | PA14 | PA13 |
| B | PC15-OSC32_OUT | VBAT  | PE3   | PB8    | PB6   | PD5      | PD2    | PC11 | PC10 | PA12 |
| C | PH0-OSC_IN     | VSS   | PE4   | PE1    | PB5   | PD6      | PD3    | PC12 | PA9  | PA11 |
| D | PH1-OSC_OUT    | VDD   | PE5   | PE0    | BOOT0 | PD7      | PD4    | PD0  | PA8  | PA10 |
| E | NRST           | PC2_C | PE6   | VSS    | VSS   | VSS      | VCAP   | PD1  | PC9  | PC7  |
| F | PC0            | PC1   | PC3_C | VDDLDO | VDD   | VDD33USB | PDR_ON | VCAP | PC8  | PC6  |
| G | VSSA           | PA0   | PA4   | PC4    | PB2   | PE10     | PE14   | PD15 | PD11 | PB15 |
| H | VDDA           | PA1   | PA5   | PC5    | PE7   | PE11     | PE15   | PD14 | PD10 | PB14 |
| J | VSS            | PA2   | PA6   | PB0    | PE8   | PE12     | PB10   | PB13 | PD9  | PD13 |
| K | VDD            | PA3   | PA7   | PB1    | PE9   | PE13     | PB11   | PB12 | PD8  | PD12 |

MSv46177V2

1. The above figure shows the package top view.

Figure 6. LQFP144 pinout



1. The above figure shows the package top view.

Figure 7. UFBGA169 ballout

|   | 1                      | 2                   | 3    | 4      | 5   | 6     | 7    | 8    | 9    | 10     | 11   | 12            | 13            |
|---|------------------------|---------------------|------|--------|-----|-------|------|------|------|--------|------|---------------|---------------|
| A | PE4                    | PE2                 | VDD  | PI6    | PB6 | PI2   | VDD  | PG10 | PD5  | VDD    | PC12 | PC10          | PI0           |
| B | PC15-<br>OSC32_<br>OUT | PE3                 | VSS  | VDDLDO | PB8 | PB4   | PI3  | PG11 | PD6  | VSS    | PC11 | PA14          | PI1           |
| C | PC14-<br>OSC32_<br>IN  | PE6                 | PE5  | PDR_ON | PB9 | PB5   | PG14 | PG9  | PD4  | PD1    | PA15 | VSS           | VDD           |
| D | VDD                    | VSS                 | PC13 | PE1    | PE0 | PB7   | PG13 | PD7  | PD3  | PD0    | PA13 | VDDLDO        | VCAP          |
| E | PI11                   | PI7                 | VBAT | PF1    | PF3 | BOOT0 | PG15 | PG12 | PD2  | PA10   | PA9  | PA8           | PA12          |
| F | PH13                   | PH12                | PF0  | PF2    | PF5 | PF7   | PB3  | PG4  | PC6  | PC7    | PC9  | PC8           | PA11          |
| G | VDD                    | VSS                 | PF4  | PF6    | PF9 | NRST  | PF13 | PE7  | PG6  | PG7    | PG8  | VDD50_<br>USB | VDD33_<br>USB |
| H | PH0-<br>OSC_<br>IN     | PH1-<br>OSC_<br>OUT | PF10 | PF8    | PJ1 | PA4   | PF14 | PE8  | PG2  | PG3    | PG5  | VSS           | VDD           |
| J | PC0                    | PC1                 | VSSA | PJ0    | PA0 | PA7   | PF15 | PE9  | PE14 | PD11   | PD13 | PD15          | PD14          |
| K | PC3_C                  | PC2_C               | PH4  | PA1    | PA6 | PC4   | PG0  | PE13 | PH10 | PH12   | PD9  | PD10          | PD12          |
| L | VDDA                   | VREF+               | PH5  | PA5    | PB1 | PB2   | PG1  | PE12 | PB10 | PH11   | PB13 | VSS           | VDD           |
| M | VDD                    | VSS                 | PH3  | VSS    | PB0 | PF11  | VSS  | PE10 | PB11 | VDDLDO | VSS  | PD8           | PB15          |
| N | PA2                    | PH2                 | PA3  | VDD    | PC5 | PF12  | VDD  | PE11 | PE15 | VCAP   | VDD  | PB12          | PB14          |

MSv45339V4

1. The above figure shows the package top view.



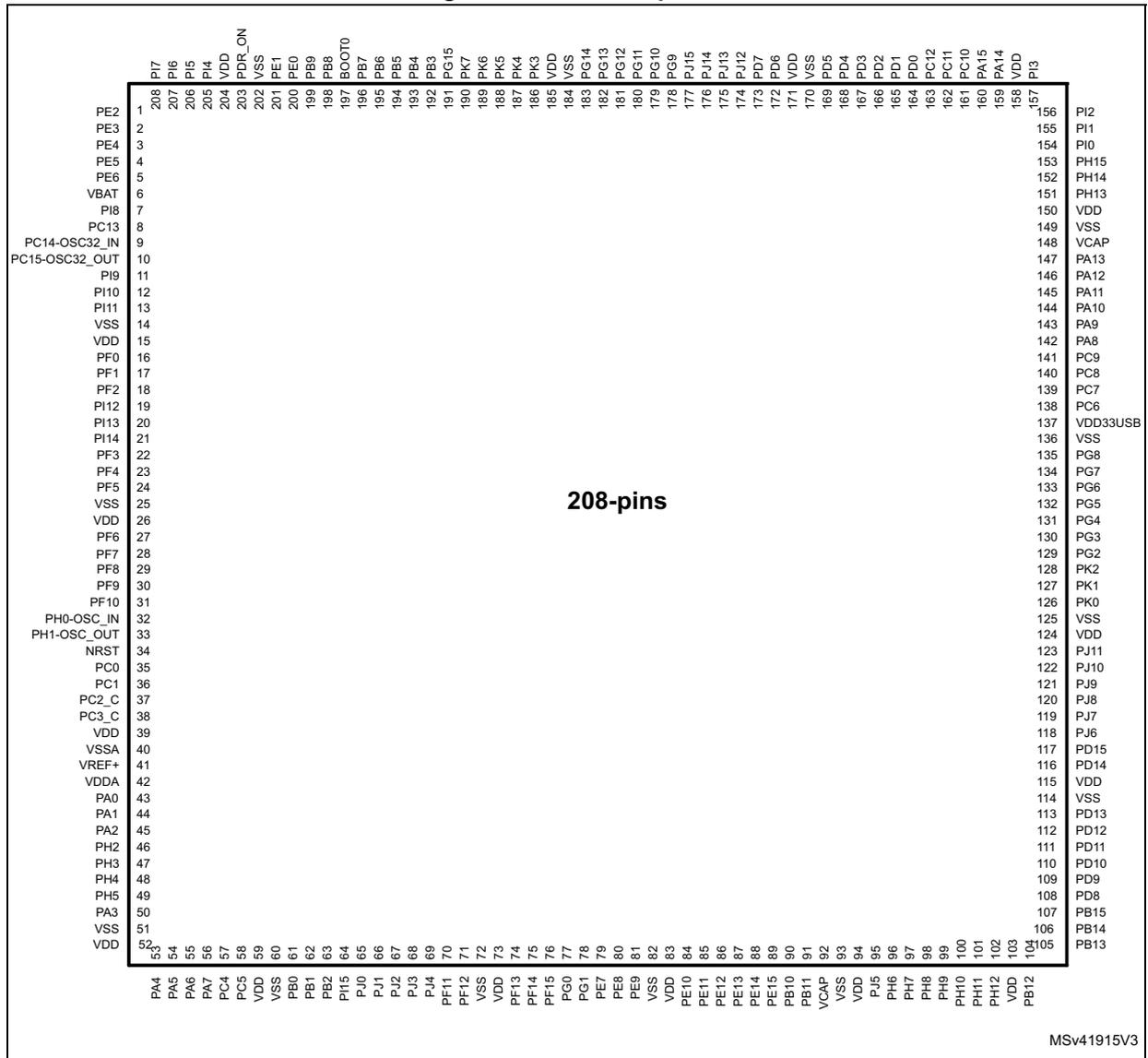
Figure 9. UFBGA176+25 ballout

|   | 1                      | 2   | 3    | 4     | 5     | 6      | 7    | 8    | 9    | 10   | 11   | 12   | 13           | 14   | 15   |
|---|------------------------|-----|------|-------|-------|--------|------|------|------|------|------|------|--------------|------|------|
| A | PE3                    | PE2 | PE1  | PE0   | PB8   | PB5    | PG14 | PG13 | PB4  | PB3  | PD7  | PC12 | PA15         | PA14 | PA13 |
| B | PE4                    | PE5 | PE6  | PB9   | PB7   | PB6    | PG15 | PG12 | PG11 | PG10 | PD6  | PD0  | PC11         | PC10 | PA12 |
| C | VBAT                   | PI7 | PI6  | PI5   | VDD   | PDR_ON | VDD  | VDD  | VDD  | PG9  | PD5  | PD1  | PI3          | PI2  | PA11 |
| D | PC13                   | PI8 | PI9  | PI4   | VSS   | BOOT0  | VSS  | VSS  | VSS  | PD4  | PD3  | PD2  | PH15         | PI1  | PA10 |
| E | PC14-<br>OSC32_<br>IN  | PF0 | PH10 | PI11  |       |        |      |      |      |      |      | PH13 | PH14         | PI0  | PA9  |
| F | PC15-<br>OSC32_<br>OUT | VSS | VDD  | PH2   |       | VSS    | VSS  | VSS  | VSS  | VSS  |      | VSS  | VCAP         | PC9  | PA8  |
| G | PH0-<br>OSC_IN         | VSS | VDD  | PH3   |       | VSS    | VSS  | VSS  | VSS  | VSS  |      | VSS  | VDD          | PC8  | PC7  |
| H | PH1-<br>OSC_<br>OUT    | PF2 | PF1  | PH4   |       | VSS    | VSS  | VSS  | VSS  | VSS  |      | VSS  | VDD<br>33USB | PG8  | PC6  |
| J | NRST                   | PF3 | PF4  | PH5   |       | VSS    | VSS  | VSS  | VSS  | VSS  |      | VDD  | VDD          | PG7  | PG6  |
| K | PF7                    | PF6 | PF5  | VDD   |       | VSS    | VSS  | VSS  | VSS  | VSS  |      | PH12 | PG5          | PG4  | PG3  |
| L | PF10                   | PF9 | PF8  | VSS   |       |        |      |      |      |      |      | PH11 | PH10         | PD15 | PG2  |
| M | VSSA                   | PC0 | PC1  | PC2_C | PC3_C | PB2    | PG1  | VSS  | VSS  | VCAP | PH6  | PH8  | PH9          | PD14 | PD13 |
| N | VREF-                  | PA1 | PA0  | PA4   | PC4   | PF13   | PG0  | VDD  | VDD  | VDD  | PE13 | PH7  | PD12         | PD11 | PD10 |
| P | VREF+                  | PA2 | PA6  | PA5   | PC5   | PF12   | PF15 | PE8  | PE9  | PE11 | PE14 | PB12 | PB13         | PD9  | PD8  |
| R | VDDA                   | PA3 | PA7  | PB1   | PB0   | PF11   | PF14 | PE7  | PE10 | PE12 | PE15 | PB10 | PB11         | PB14 | PB15 |

MSv41912V3

1. The above figure shows the package top view.

Figure 10. LQFP208 pinout



1. The above figure shows the package top view.

Figure 11. TFBGA240+25 ballout

|   | 1                 | 2             | 3    | 4    | 5    | 6       | 7      | 8     | 9    | 10   | 11   | 12      | 13   | 14   | 15   | 16   | 17        |
|---|-------------------|---------------|------|------|------|---------|--------|-------|------|------|------|---------|------|------|------|------|-----------|
| A | VSS               | PI6           | PI5  | PI4  | PB5  | VDD LDO | VCAP   | PK5   | PG10 | PG9  | PD5  | PD4     | PC10 | PA15 | PI1  | PI0  | VSS       |
| B | VBAT              | VSS           | PI7  | PE1  | PB6  | VSS     | PB4    | PK4   | PG11 | PJ15 | PD6  | PD3     | PC11 | PA14 | PI2  | PH15 | PH14      |
| C | PC15-OSC32_OUT    | PC14-OSC32_IN | PE2  | PE0  | PB7  | PB3     | PK6    | PK3   | PG12 | VSS  | PD7  | PC12    | VSS  | PI3  | PA13 | VSS  | VDD LDO   |
| D | PE5               | PE4           | PE3  | PB9  | PB8  | PG15    | PK7    | PG14  | PG13 | PJ14 | PJ12 | PD2     | PD0  | PA10 | PA9  | PH13 | VCAP      |
| E | NC <sup>(2)</sup> | PI9           | PC13 | PI8  | PE6  | VDD     | PDR_ON | BOOT0 | VDD  | PJ13 | VDD  | PD1     | PC8  | PC9  | PA8  | PA12 | PA11      |
| F | VSS               | VSS           | PI10 | PI11 | VDD  |         |        |       |      |      |      |         | PC7  | PC6  | PG8  | PG7  | VDD33 USB |
| G | PF2               | VSS           | PF1  | PF0  | VDD  |         | VSS    | VSS   | VSS  | VSS  | VSS  |         | VDD  | PG5  | PG6  | VSS  | VDD50 USB |
| H | PI12              | PI13          | PI14 | PF3  | VDD  |         | VSS    | VSS   | VSS  | VSS  | VSS  |         | VDD  | PG4  | PG3  | PG2  | PK2       |
| J | PH1-OSC_OUT       | PH0-OSC_IN    | VSS  | PF5  | PF4  |         | VSS    | VSS   | VSS  | VSS  | VSS  |         | VDD  | PK0  | PK1  | VSS  | VSS       |
| K | NRST              | PF6           | PF7  | PF8  | VDD  |         | VSS    | VSS   | VSS  | VSS  | VSS  |         | VDD  | PJ11 | VSS  | NC   | NC        |
| L | VDDA              | PC0           | PF10 | PF9  | VDD  |         | VSS    | VSS   | VSS  | VSS  | VSS  |         | VDD  | PJ10 | VSS  | NC   | NC        |
| M | VREF+             | PC1           | PC2  | PC3  | VDD  |         |        |       |      |      |      |         | VDD  | PJ9  | VSS  | NC   | NC        |
| N | VREF-             | PH2           | PA2  | PA1  | PA0  | PJ0     | VDD    | VDD   | PE10 | VDD  | VDD  | VDD     | PJ8  | PJ7  | PJ6  | VSS  | NC        |
| P | VSSA              | PH3           | PH4  | PH5  | PI15 | PJ1     | PF13   | PF14  | PE9  | PE11 | PB10 | PB11    | PH10 | PH11 | PD15 | PD14 | VDD       |
| R | PC2_C             | PC3_C         | PA6  | VSS  | PA7  | PB2     | PF12   | VSS   | PF15 | PE12 | PE15 | PJ5     | PH9  | PH12 | PD11 | PD12 | PD13      |
| T | PA0_C             | PA1_C         | PA5  | PC4  | PB1  | PJ2     | PF11   | PG0   | PE8  | PE13 | PH6  | VSS     | PH8  | PB12 | PB15 | PD10 | PD9       |
| U | VSS               | PA3           | PA4  | PC5  | PB0  | PJ3     | PJ4    | PG1   | PE7  | PE14 | VCAP | VDD LDO | PH7  | PB13 | PB14 | PD8  | VSS       |

MSv41911V7

1. The above figure shows the package top view.
2. This ball should remain floating.

**Table 7. Legend/abbreviations used in the pinout table**

| Name          |                      | Abbreviation  | Definition  |
|---------------|----------------------|---|---|
| Pin name      |                      | Unless otherwise specified in brackets below the pin name, the pin function during and after reset is the same as the actual pin name |   |
| Pin type      |                      | S   | Supply pin  |
|               |                      | I   | Input only pin  |
|               |                      | I/O   | Input / output pin  |
|               |                      | ANA   | Analog-only Input   |
| I/O structure |                      | FT  | 5 V tolerant I/O  |
|               |                      | TT  | 3.3 V tolerant I/O  |
|               |                      | B   | Dedicated BOOT0 pin   |
|               |                      | RST   | Bidirectional reset pin with embedded weak pull-up resistor |
|               |                      | <b>Option for TT and FT I/Os</b>  |   |
|               |                      | _f  | I2C FM+ option  |
|               |                      | _a  | analog option (supplied by V <sub>DDA</sub> )               |
|               |                      | _u  | USB option (supplied by V <sub>DD33USB</sub> )              |
|               |                      | _h  | High-speed low-voltage I/O                                  |
| Notes         |                      | Unless otherwise specified by a note, all I/Os are set as floating inputs during and after reset.                                     |   |
| Pin functions | Alternate functions  | Functions selected through GPIOx_AFR registers  |   |
|               | Additional functions | Functions directly selected/enabled through peripheral registers  |   |

Table 8. Pin/ball definition

| Pin/ball name |          |         |          |             |         |         |              | Pin name<br>(function<br>after<br>reset) | Pin type | I/O structure | Notes | Alternate functions  | Additional<br>functions               |
|---------------|----------|---------|----------|-------------|---------|---------|--------------|--|----------|---------------|-------|--|---------------------------------------|
| LQFP100       | TFBGA100 | LQFP144 | UFBGA169 | UFBGA176+25 | LQFP176 | LQFP208 | TFBGA240 +25 |  |          |               |       |  |                                       |
| 1             | A3       | 1       | A2       | A2          | 1       | 1       | C3           | PE2                                      | I/O      | FT_h          | -     | TRACECLK, SAI1_CK1,<br>SPI4_SCK,<br>SAI1_MCLK_A,<br>SAI4_MCLK_A,<br>QUADSPI_BK1_IO2,<br>SAI4_CK1,<br>ETH_MII_TXD3,<br>FMC_A23, EVENTOUT                                    | -                                     |
| 2             | B3       | 2       | B2       | A1          | 2       | 2       | D3           | PE3                                      | I/O      | FT_h          | -     | TRACED0, TIM15_BKIN,<br>SAI1_SD_B, SAI4_SD_B,<br>FMC_A19, EVENTOUT   | -                                     |
| 3             | C3       | 3       | A1       | B1          | 3       | 3       | D2           | PE4                                      | I/O      | FT_h          | -     | TRACED1, SAI1_D2,<br>DFSDM1_DATIN3,<br>TIM15_CH1N,<br>SPI4_NSS, SAI1_FS_A,<br>SAI4_FS_A, SAI4_D2,<br>FMC_A20, DCM1_D4,<br>LCD_B0, EVENTOUT                                 | -                                     |
| 4             | D3       | 4       | C3       | B2          | 4       | 4       | D1           | PE5                                      | I/O      | FT_h          | -     | TRACED2, SAI1_CK2,<br>DFSDM1_CKIN3,<br>TIM15_CH1, SPI4_MISO,<br>SAI1_SCK_A,<br>SAI4_SCK_A, SAI4_CK2,<br>FMC_A21, DCM1_D6,<br>LCD_G0, EVENTOUT                              | -                                     |
| 5             | E3       | 5       | C2       | B3          | 5       | 5       | E5           | PE6                                      | I/O      | FT_h          | -     | TRACED3, TIM1_BKIN2,<br>SAI1_D1, TIM15_CH2,<br>SPI4_MOSI, SAI1_SD_A,<br>SAI4_SD_A, SAI4_D1,<br>SAI2_MCLK_B,<br>TIM1_BKIN2_COMP12,<br>FMC_A22, DCM1_D7,<br>LCD_G1, EVENTOUT | -                                     |
| -             | -        | -       | M4       | H10         | -       | -       | A1           | VSS                                      | S        | -             | -     | -  | -                                     |
| -             | -        | -       | A3       | -           | -       | -       | -            | VDD                                      | S        | -             | -     | -  | -                                     |
| 6             | B2       | 6       | E3       | C1          | 6       | 6       | B1           | VBAT                                     | S        | -             | -     | -  | -                                     |
| -             | -        | -       | -        | J6          | -       | -       | B2           | VSS                                      | S        | -             | -     | -  | -                                     |
| -             | -        | -       | -        | D2          | 7       | 7       | E4           | PI8                                      | I/O      | FT            | -     | EVENTOUT   | RTC_TAMP2/W<br>KUP3                   |
| 7             | A2       | 7       | D3       | D1          | 8       | 8       | E3           | PC13                                     | I/O      | FT            | -     | EVENTOUT   | RTC_OUT/RTC<br>_TAMP1/RTC_T<br>SWKUP4 |
| -             | -        | -       | -        | J7          | -       | -       | B6           | VSS                                      | S        | -             | -     | -  | -                                     |

Table 8. Pin/ball definition (continued)

| Pin/ball name |          |         |          |             |         |         |                   | Pin name<br>(function<br>after<br>reset)             | Pin type | I/O structure | Notes | Alternate functions  | Additional<br>functions |
|---------------|----------|---------|----------|-------------|---------|---------|-------------------|--|----------|---------------|-------|--|-------------------------|
| LQFP100       | TFBGA100 | LQFP144 | UFBGA169 | UFBGA176+25 | LQFP176 | LQFP208 | TFBGA240 +25      |  |          |               |       |  |                         |
| 8             | A1       | 8       | C1       | E1          | 9       | 9       | C2                | PC14-<br>OSC32_IN<br>(OSC32_I<br>N) <sup>(1)</sup>   | I/O      | FT            | -     | EVENTOUT   | OSC32_IN                |
| 9             | B1       | 9       | B1       | F1          | 10      | 10      | C1                | PC15-<br>OSC32_O<br>UT(OSC3<br>2_OUT) <sup>(1)</sup> | I/O      | FT            | -     | EVENTOUT   | OSC32_OUT               |
| -             | -        | -       | -        | D3          | 11      | 11      | E2                | PI9  | I/O      | FT_h          | -     | UART4_RX,<br>FDCAN1_RX, FMC_D30,<br>LCD_VSYNC,<br>EVENTOUT | -                       |
| -             | -        | -       | -        | E3          | 12      | 12      | F3                | PI10   | I/O      | FT_h          | -     | ETH_MII_RX_ER,<br>FMC_D31, LCD_HSYNC,<br>EVENTOUT          | -                       |
| -             | -        | -       | E1       | E4          | 13      | 13      | F4                | PI11   | I/O      | FT            | -     | LCD_G6,<br>OTG_HS_ULPI_DIR,<br>EVENTOUT                    | WKUP5                   |
| -             | C2       | -       | D2       | F2          | 14      | 14      | A17               | VSS  | S        | -             | -     | -  | -                       |
| -             | D2       | -       | D1       | F3          | 15      | 15      | E6                | VDD  | S        | -             | -     | -  | -                       |
| -             | -        | -       | -        | -           | -       | -       | F2                | VSS  | S        | -             | -     | -  | -                       |
| -             | -        | -       | -        | -           | -       | -       | E1 <sup>(2)</sup> | NC   | S        | -             | -     | -  | -                       |
| -             | -        | -       | -        | -           | -       | -       | F1                | VSS  | S        | -             | -     | -  | -                       |
| -             | -        | -       | -        | -           | -       | -       | G2                | VSS  | S        | -             | -     | -  | -                       |
| -             | -        | 10      | F3       | E2          | 16      | 16      | G4                | PF0  | I/O      | FT_f          | -     | I2C2_SDA, FMC_A0,<br>EVENTOUT                              | -                       |
| -             | -        | 11      | E4       | H3          | 17      | 17      | G3                | PF1  | I/O      | FT_f          | -     | I2C2_SCL, FMC_A1,<br>EVENTOUT                              | -                       |
| -             | -        | 12      | F4       | H2          | 18      | 18      | G1                | PF2  | I/O      | FT            | -     | I2C2_SMBA, FMC_A2,<br>EVENTOUT                             | -                       |
| -             | -        | -       | F2       | -           | -       | 19      | H1                | PI12   | I/O      | FT            | -     | ETH_TX_ER,<br>LCD_HSYNC,<br>EVENTOUT                       | -                       |
| -             | -        | -       | F1       | -           | -       | 20      | H2                | PI13   | I/O      | FT            | -     | LCD_VSYNC,<br>EVENTOUT                                     | -                       |
| -             | -        | -       | -        | -           | -       | 21      | H3                | PI14   | I/O      | FT_h          | -     | LCD_CLK, EVENTOUT  | -                       |
| -             | -        | 13      | E5       | J2          | 19      | 22      | H4                | PF3  | I/O      | FT_h<br>a     | -     | FMC_A3, EVENTOUT   | ADC3_INP5               |
| -             | -        | 14      | G3       | J3          | 20      | 23      | J5                | PF4  | I/O      | FT_h<br>a     | -     | FMC_A4, EVENTOUT   | ADC3_INN5,<br>ADC3_INP9 |

Table 8. Pin/ball definition (continued)

| Pin/ball name |          |         |          |             |         |         |              | Pin name<br>(function<br>after<br>reset) | Pin type | I/O structure | Notes | Alternate functions   | Additional<br>functions |
|---------------|----------|---------|----------|-------------|---------|---------|--------------|--|----------|---------------|-------|---|-------------------------|
| LQFP100       | TFBGA100 | LQFP144 | UFBGA169 | UFBGA176+25 | LQFP176 | LQFP208 | TFBGA240 +25 |  |          |               |       |   |                         |
| -             | -        | 15      | F5       | K3          | 21      | 24      | J4           | PF5                                      | I/O      | FT_h<br>a     | -     | FMC_A5, EVENTOUT  | ADC3_INP4               |
| 10            | -        | 16      | B10      | G2          | 22      | 25      | C10          | VSS                                      | S        | -             | -     | -   | -                       |
| 11            | -        | 17      | G1       | G3          | 23      | 26      | E9           | VDD                                      | S        | -             | -     | -   | -                       |
| -             | -        | 18      | G4       | K2          | 24      | 27      | K2           | PF6                                      | I/O      | FT_h<br>a     | -     | TIM16_CH1, SPI5_NSS,<br>SAI1_SD_B, UART7_RX,<br>SAI4_SD_B,<br>QUADSPI_BK1_IO3,<br>EVENTOUT                                    | ADC3_INN4,<br>ADC3_INP8 |
| -             | -        | 19      | F6       | K1          | 25      | 28      | K3           | PF7                                      | I/O      | FT_h<br>a     | -     | TIM17_CH1, SPI5_SCK,<br>SAI1_MCLK_B,<br>UART7_TX,<br>SAI4_MCLK_B,<br>QUADSPI_BK1_IO2,<br>EVENTOUT                             | ADC3_INP3               |
| -             | -        | 20      | H4       | L3          | 26      | 29      | K4           | PF8                                      | I/O      | FT_h<br>a     | -     | TIM16_CH1N,<br>SPI5_MISO,<br>SAI1_SCK_B,<br>UART7_RTS/UART7_DE<br>, SAI4_SCK_B,<br>TIM13_CH1,<br>QUADSPI_BK1_IO0,<br>EVENTOUT | ADC3_INN3,<br>ADC3_INP7 |
| -             | -        | 21      | G5       | L2          | 27      | 30      | L4           | PF9                                      | I/O      | FT_h<br>a     | -     | TIM17_CH1N,<br>SPI5_MOSI, SAI1_FS_B,<br>UART7_CTS,<br>SAI4_FS_B, TIM14_CH1,<br>QUADSPI_BK1_IO1,<br>EVENTOUT                   | ADC3_INP2               |
| -             | -        | 22      | H3       | L1          | 28      | 31      | L3           | PF10                                     | I/O      | FT_h<br>a     | -     | TIM16_BKIN, SAI1_D3,<br>QUADSPI_CLK,<br>SAI4_D3, DCMI_D11,<br>LCD_DE, EVENTOUT  | ADC3_INN2,<br>ADC3_INP6 |
| 12            | C1       | 23      | H1       | G1          | 29      | 32      | J2           | PH0-<br>OSC_IN(P<br>H0)                  | I/O      | FT            | -     | EVENTOUT  | OSC_IN                  |
| 13            | D1       | 24      | H2       | H1          | 30      | 33      | J1           | PH1-<br>OSC_OUT<br>(PH1)                 | I/O      | FT            | -     | EVENTOUT  | OSC_OUT                 |
| 14            | E1       | 25      | G6       | J1          | 31      | 34      | K1           | NRST                                     | I/O      | RST           | -     | -   | -                       |

Table 8. Pin/ball definition (continued)

| Pin/ball name     |                   |                   |                   |                   |                   |                   |                   | Pin name<br>(function<br>after<br>reset) | Pin type | I/O structure | Notes | Alternate functions   | Additional<br>functions                                   |
|-------------------|-------------------|-------------------|-------------------|-------------------|-------------------|-------------------|-------------------|--|----------|---------------|-------|---|---|
| LQFP100           | TFBGA100          | LQFP144           | UFBGA169          | UFBGA176+25       | LQFP176           | LQFP208           | TFBGA240 +25      |  |          |               |       |   |   |
| 15                | F1                | 26                | J1                | M2                | 32                | 35                | L2                | PC0                                      | I/O      | FT_a          | -     | DFSDM1_CKIN0,<br>DFSDM1_DATIN4,<br>SAI2_FS_B,<br>OTG_HS_ULPI_STP,<br>FMC_SDNWE, LCD_R5,<br>EVENTOUT   | ADC123_INP10  |
| 16                | F2                | 27                | J2                | M3                | 33                | 36                | M2                | PC1                                      | I/O      | FT_h<br>a     | -     | TRACED0, SAI1_D1,<br>DFSDM1_DATIN0,<br>DFSDM1_CKIN4,<br>SPI2_MOSI/I2S2_SDO,<br>SAI1_SD_A, SAI4_SD_A,<br>SDMMC2_CK, SAI4_D1,<br>ETH_MDC,<br>MDIOS_MDC,<br>EVENTOUT | ADC123_INN10<br>,<br>ADC123_INP11,<br>RTC_TAMP3/W<br>KUP6 |
| -                 | -                 | -                 | -                 | -                 | -                 | -                 | M3 <sup>(3)</sup> | PC2                                      | I/O      | FT_a          | -     | C1DSLEEP,<br>DFSDM1_CKIN1,<br>SPI2_MISO/I2S2_SDI,<br>DFSDM1_CKOUT,<br>OTG_HS_ULPI_DIR,<br>ETH_MII_TXD2,<br>FMC_SDNE0,<br>EVENTOUT                                 | ADC123_INN11<br>,<br>ADC123_INP12                         |
| 17 <sup>(4)</sup> | E2 <sup>(4)</sup> | 28 <sup>(4)</sup> | K2 <sup>(4)</sup> | M4 <sup>(4)</sup> | 34 <sup>(4)</sup> | 37 <sup>(4)</sup> | R1 <sup>(3)</sup> | PC2_C                                    | ANA      | TT_a          | -     | -   | ADC3_INN1,<br>ADC3_INP0                                   |
| -                 | -                 | -                 | -                 | -                 | -                 | -                 | M4 <sup>(3)</sup> | PC3                                      | I/O      | FT_a          | -     | C1SLEEP,<br>DFSDM1_DATIN1,<br>SPI2_MOSI/I2S2_SDO,<br>OTG_HS_ULPI_NXT,<br>ETH_MII_TX_CLK,<br>FMC_SDCKE0,<br>EVENTOUT   | ADC12_INN12,<br>ADC12_INP13                               |
| 18 <sup>(4)</sup> | F3 <sup>(4)</sup> | 29 <sup>(4)</sup> | K1 <sup>(4)</sup> | M5 <sup>(4)</sup> | 35 <sup>(4)</sup> | 38 <sup>(4)</sup> | R2 <sup>(3)</sup> | PC3_C                                    | ANA      | TT_a          | -     | -   | ADC3_INP1   |
| -                 | F5                | 30                | -                 | -                 | 36                | 39                | E11               | VDD                                      | S        | -             | -     | -   | -   |
| -                 | E6                | -                 | B3                | J10               | -                 | -                 | C13               | VSS                                      | S        | -             | -     | -   | -   |
| 19                | G1                | 31                | J3                | M1                | 37                | 40                | P1                | VSSA                                     | S        | -             | -     | -   | -   |
| -                 | -                 | -                 | -                 | N1                | -                 | -                 | N1                | VREF-                                    | S        | -             | -     | -   | -   |
| 20                | .( <sup>5)</sup>  | 32                | L2                | P1                | 38                | 41                | M1                | VREF+                                    | S        | -             | -     | -   | -   |
| 21                | H1                | 33                | L1                | R1                | 39                | 42                | L1                | VDDA                                     | S        | -             | -     | -   | -   |

Table 8. Pin/ball definition (continued)

| Pin/ball name |          |         |          |             |         |         |                   | Pin name<br>(function<br>after<br>reset) | Pin type | I/O structure | Notes | Alternate functions  | Additional<br>functions   |
|---------------|----------|---------|----------|-------------|---------|---------|-------------------|--|----------|---------------|-------|--|---------------------------|
| LQFP100       | TFBGA100 | LQFP144 | UFBGA169 | UFBGA176+25 | LQFP176 | LQFP208 | TFBGA240 +25      |  |          |               |       |  |                           |
| 22            | G2       | 34      | J5       | N3          | 40      | 43      | N5 <sup>(3)</sup> | PA0                                      | I/O      | FT_a          | -     | TIM2_CH1/TIM2_ETR,<br>TIM5_CH1, TIM8_ETR,<br>TIM15_BKIN,<br>USART2_CTS/USART2_<br>NSS, UART4_TX,<br>SDMMC2_CMD,<br>SAI2_SD_B,<br>ETH_MII_CRG,<br>EVENTOUT                                | ADC1_INP16,<br>WKUP1      |
| -             | -        | -       | -        | -           | -       | -       | T1 <sup>(3)</sup> | PA0_C                                    | ANA      | TT_a          | -     | -  | ADC12_INN1,<br>ADC12_INP0 |
| 23            | H2       | 35      | K4       | N2          | 41      | 44      | N4 <sup>(3)</sup> | PA1                                      | I/O      | FT_h<br>a     | -     | TIM2_CH2, TIM5_CH2,<br>LPTIM3_OUT,<br>TIM15_CH1N,<br>USART2_RTS/USART2_<br>DE, UART4_RX,<br>QUADSPI_BK1_IO3,<br>SAI2_MCLK_B,<br>ETH_MII_RX_CLK/ETH_<br>RMII_REF_CLK,<br>LCD_R2, EVENTOUT | ADC1_INN16,<br>ADC1_INP17 |
| -             | -        | -       | -        | -           | -       | -       | T2 <sup>(3)</sup> | PA1_C                                    | ANA      | TT_a          | -     | -  | ADC12_INP1                |
| 24            | J2       | 36      | N1       | P2          | 42      | 45      | N3                | PA2                                      | I/O      | FT_a          | -     | TIM2_CH3, TIM5_CH3,<br>LPTIM4_OUT,<br>TIM15_CH1,<br>USART2_TX,<br>SAI2_SCK_B,<br>ETH_MDIO,<br>MDIOS_MDIO, LCD_R1,<br>EVENTOUT  | ADC12_INP14,<br>WKUP2     |
| -             | -        | -       | N2       | F4          | 43      | 46      | N2                | PH2                                      | I/O      | FT_h<br>a     | -     | LPTIM1_IN2,<br>QUADSPI_BK2_IO0,<br>SAI2_SCK_B,<br>ETH_MII_CRG,<br>FMC_SDCKE0, LCD_R0,<br>EVENTOUT  | ADC3_INP13                |
| -             | K1       | -       | M1       | -           | -       | -       | F5                | VDD                                      | S        | -             | -     | -  | -                         |
| -             | J1       | -       | M7       | J8          | -       | -       | C16               | VSS                                      | S        | -             | -     | -  | -                         |
| -             | -        | -       | M3       | G4          | 44      | 47      | P2                | PH3                                      | I/O      | FT_h<br>a     | -     | QUADSPI_BK2_IO1,<br>SAI2_MCLK_B,<br>ETH_MII_COL,<br>FMC_SDNE0, LCD_R1,<br>EVENTOUT   | ADC3_INN13,<br>ADC3_INP14 |

Table 8. Pin/ball definition (continued)

| Pin/ball name |          |         |          |             |         |         |              | Pin name<br>(function<br>after<br>reset) | Pin type | I/O structure | Notes | Alternate functions  | Additional<br>functions                   |
|---------------|----------|---------|----------|-------------|---------|---------|--------------|--|----------|---------------|-------|--|---|
| LQFP100       | TFBGA100 | LQFP144 | UFBGA169 | UFBGA176+25 | LQFP176 | LQFP208 | TFBGA240 +25 |  |          |               |       |  |   |
| -             | -        | -       | K3       | H4          | 45      | 48      | P3           | PH4                                      | I/O      | FT_fa         | -     | I2C2_SCL, LCD_G5,<br>OTG_HS_ULPI_NXT,<br>LCD_G4, EVENTOUT  | ADC3_INN14,<br>ADC3_INP15                 |
| -             | -        | -       | L3       | J4          | 46      | 49      | P4           | PH5                                      | I/O      | FT_fa         | -     | I2C2_SDA, SPI5_NSS,<br>FMC_SDNWE,<br>EVENTOUT  | ADC3_INN15,<br>ADC3_INP16                 |
| 25            | K2       | 37      | N3       | R2          | 47      | 50      | U2           | PA3                                      | I/O      | FT_h<br>a     | -     | TIM2_CH4, TIM5_CH4,<br>LPTIM5_OUT,<br>TIM15_CH2,<br>USART2_RX, LCD_B2,<br>OTG_HS_ULPI_D0,<br>ETH_MII_COL, LCD_B5,<br>EVENTOUT  | ADC12_INP15                               |
| 26            | -        | 38      | G2       | K6          | -       | 51      | -            | VSS                                      | S        | -             | -     | -  | -   |
| -             | -        | -       | -        | L4          | 48      | -       | -            | VSS                                      | S        | -             | -     | -  | -   |
| 27            | -        | 39      | -        | K4          | 49      | 52      | G5           | VDD                                      | S        | -             | -     | -  | -   |
| 28            | G3       | 40      | H6       | N4          | 50      | 53      | U3           | PA4                                      | I/O      | TT_a          | -     | D1PWREN, TIM5_ETR,<br>SPI1_NSS/I2S1_WS,<br>SPI3_NSS/I2S3_WS,<br>USART2_CK, SPI6_NSS,<br>OTG_HS_SOF,<br>DCMI_HSYNC,<br>LCD_VSYNC,<br>EVENTOUT                                   | ADC12_INP18,<br>DAC1_OUT1                 |
| 29            | H3       | 41      | L4       | P4          | 51      | 54      | T3           | PA5                                      | I/O      | TT_h<br>a     | -     | D2PWREN,<br>TIM2_CH1/TIM2_ETR,<br>TIM8_CH1N,<br>SPI1_SCK/I2S1_CK,<br>SPI6_SCK,<br>OTG_HS_ULPI_CK,<br>LCD_R4, EVENTOUT  | ADC12_INN18,<br>ADC12_INP19,<br>DAC1_OUT2 |
| 30            | J3       | 42      | K5       | P3          | 52      | 55      | R3           | PA6                                      | I/O      | FT_a          | -     | TIM1_BKIN, TIM3_CH1,<br>TIM8_BKIN,<br>SPI1_MISO/I2S1_SDI,<br>SPI6_MISO, TIM13_CH1,<br>TIM8_BKIN_COMP12,<br>MDIOS_MDC,<br>TIM1_BKIN_COMP12,<br>DCMI_PIXCLK, LCD_G2,<br>EVENTOUT | ADC12_INP3                                |

Table 8. Pin/ball definition (continued)

| Pin/ball name |          |         |          |             |         |         |              | Pin name<br>(function<br>after<br>reset) | Pin type | I/O structure | Notes | Alternate functions  | Additional<br>functions                                 |
|---------------|----------|---------|----------|-------------|---------|---------|--------------|--|----------|---------------|-------|--|---|
| LQFP100       | TFBGA100 | LQFP144 | UFBGA169 | UFBGA176+25 | LQFP176 | LQFP208 | TFBGA240 +25 |  |          |               |       |  |   |
| 31            | K3       | 43      | J6       | R3          | 53      | 56      | R5           | PA7                                      | I/O      | TT_a          | -     | TIM1_CH1N, TIM3_CH2,<br>TIM8_CH1N,<br>SPI1_MOSI/I2S1_SDO,<br>SPI6_MOSI, TIM14_CH1,<br>ETH_MII_RX_DV/ETH_R<br>MII_CRD_DV,<br>FMC_SDNWE,<br>EVENTOUT | ADC12_INN3,<br>ADC12_INP7,<br>OPAMP1_VINM               |
| 32            | G4       | 44      | K6       | N5          | 54      | 57      | T4           | PC4                                      | I/O      | TT_a          | -     | C2DSLEEP,<br>DFSDM1_CKIN2,<br>I2S1_MCK,<br>SPDIFRX1_IN3,<br>ETH_MII_RXD0/ETH_R<br>MII_RXD0, FMC_SDNE0,<br>EVENTOUT                                 | ADC12_INP4,<br>OPAMP1_VOU<br>T, COMP1_INM               |
| 33            | H4       | 45      | N5       | P5          | 55      | 58      | U4           | PC5                                      | I/O      | TT_a          | -     | C2SLEEP, SAI1_D3,<br>DFSDM1_DATIN2,<br>SPDIFRX1_IN4,<br>SAI4_D3,<br>ETH_MII_RXD1/ETH_R<br>MII_RXD1,<br>FMC_SDCKE0,<br>COMP1_OUT,<br>EVENTOUT       | ADC12_INN4,<br>ADC12_INP8,<br>OPAMP1_VINM               |
| -             | -        | -       | N4       | -           | -       | 59      | G13          | VDD                                      | S        | -             | -     | -  | -   |
| -             | -        | -       | H12      | J9          | -       | 60      | R4           | VSS                                      | S        | -             | -     | -  | -   |
| 34            | J4       | 46      | M5       | R5          | 56      | 61      | U5           | PB0                                      | I/O      | FT_a          | -     | TIM1_CH2N, TIM3_CH3,<br>TIM8_CH2N,<br>DFSDM1_CKOUT,<br>UART4_CTS, LCD_R3,<br>OTG_HS_ULPI_D1,<br>ETH_MII_RXD2,<br>LCD_G1, EVENTOUT                  | ADC12_INN5,<br>ADC12_INP9,<br>OPAMP1_VINP,<br>COMP1_INP |
| 35            | K4       | 47      | L5       | R4          | 57      | 62      | T5           | PB1                                      | I/O      | TT_a          | -     | TIM1_CH3N, TIM3_CH4,<br>TIM8_CH3N,<br>DFSDM1_DATIN1,<br>LCD_R6,<br>OTG_HS_ULPI_D2,<br>ETH_MII_RXD3,<br>LCD_G0, EVENTOUT                            | ADC12_INP5,<br>COMP1_INM                                |

Table 8. Pin/ball definition (continued)

| Pin/ball name |          |         |          |             |         |         |              | Pin name<br>(function<br>after<br>reset) | Pin type | I/O structure | Notes | Alternate functions  | Additional<br>functions |
|---------------|----------|---------|----------|-------------|---------|---------|--------------|--|----------|---------------|-------|--|-------------------------|
| LQFP100       | TFBGA100 | LQFP144 | UFBGA169 | UFBGA176+25 | LQFP176 | LQFP208 | TFBGA240 +25 |  |          |               |       |  |                         |
| 36            | G5       | 48      | L6       | M6          | 58      | 63      | R6           | PB2                                      | I/O      | FT_h<br>a     | -     | RTC_OUT, SAI1_D1,<br>DFSDM1_CKIN1,<br>SAI1_SD_A,<br>SPI3_MOSI/I2S3_SDO,<br>SAI4_SD_A,<br>QUADSPI_CLK,<br>SAI4_D1, ETH_TX_ER,<br>EVENTOUT | COMP1_INP               |
| -             | -        | -       | -        | -           | -       | 64      | P5           | PI15                                     | I/O      | FT            | -     | LCD_G2, LCD_R0,<br>EVENTOUT  | -                       |
| -             | -        | -       | J4       | -           | -       | 65      | N6           | PJ0                                      | I/O      | FT            | -     | LCD_R7, LCD_R1,<br>EVENTOUT  | -                       |
| -             | -        | -       | H5       | -           | -       | 66      | P6           | PJ1                                      | I/O      | FT            | -     | LCD_R2, EVENTOUT   | -                       |
| -             | -        | -       | -        | -           | -       | 67      | T6           | PJ2                                      | I/O      | FT            | -     | LCD_R3, EVENTOUT   | -                       |
| -             | -        | -       | -        | -           | -       | 68      | U6           | PJ3                                      | I/O      | FT            | -     | LCD_R4, EVENTOUT   | -                       |
| -             | -        | -       | -        | -           | -       | 69      | U7           | PJ4                                      | I/O      | FT            | -     | LCD_R5, EVENTOUT   | -                       |
| -             | -        | 49      | M6       | R6          | 59      | 70      | T7           | PF11                                     | I/O      | FT_a          | -     | SPI5_MOSI, SAI2_SD_B,<br>FMC_SDNRAS,<br>DCMI_D12, EVENTOUT   | ADC1_INP2               |
| -             | -        | 50      | N6       | P6          | 60      | 71      | R7           | PF12                                     | I/O      | FT_h<br>a     | -     | FMC_A6, EVENTOUT   | ADC1_INN2,<br>ADC1_INP6 |
| -             | -        | 51      | M11      | M8          | 61      | 72      | J3           | VSS                                      | S        | -             | -     | -  | -                       |
| -             | -        | 52      | -        | N8          | 62      | 73      | H5           | VDD                                      | S        | -             | -     | -  | -                       |
| -             | -        | 53      | G7       | N6          | 63      | 74      | P7           | PF13                                     | I/O      | FT_h<br>a     | -     | DFSDM1_DATIN6,<br>I2C4_SMBA, FMC_A7,<br>EVENTOUT   | ADC2_INP2               |
| -             | -        | 54      | H7       | R7          | 64      | 75      | P8           | PF14                                     | I/O      | FT_fh<br>a    | -     | DFSDM1_CKIN6,<br>I2C4_SCL, FMC_A8,<br>EVENTOUT   | ADC2_INN2,<br>ADC2_INP6 |
| -             | -        | 55      | J7       | P7          | 65      | 76      | R9           | PF15                                     | I/O      | FT_fh         | -     | I2C4_SDA, FMC_A9,<br>EVENTOUT  | -                       |
| -             | -        | 56      | K7       | N7          | 66      | 77      | T8           | PG0                                      | I/O      | FT_h          | -     | FMC_A10, EVENTOUT  | -                       |
| -             | -        | -       | M2       | F6          | -       | -       | J16          | VSS                                      | S        | -             | -     | -  | -                       |
| -             | -        | -       | A10      | -           | -       | -       | H13          | VDD                                      | S        | -             | -     | -  | -                       |
| -             | -        | 57      | L7       | M7          | 67      | 78      | U8           | PG1                                      | I/O      | TT_h          | -     | FMC_A11, EVENTOUT  | OPAMP2_VINM             |

Table 8. Pin/ball definition (continued)

| Pin/ball name |          |         |          |             |         |         |              | Pin name<br>(function<br>after<br>reset) | Pin type | I/O structure | Notes | Alternate functions   | Additional<br>functions    |
|---------------|----------|---------|----------|-------------|---------|---------|--------------|--|----------|---------------|-------|---|----------------------------|
| LQFP100       | TFBGA100 | LQFP144 | UFBGA169 | UFBGA176+25 | LQFP176 | LQFP208 | TFBGA240 +25 |  |          |               |       |   |                            |
| 37            | H5       | 58      | G8       | R8          | 68      | 79      | U9           | PE7                                      | I/O      | TT_h<br>a     | -     | TIM1_ETR,<br>DFSDM1_DATIN2,<br>UART7_RX,<br>QUADSPI_BK2_IO0,<br>FMC_D4/FMC_DA4,<br>EVENTOUT                   | OPAMP2_VO<br>UT, COMP2_INM |
| 38            | J5       | 59      | H8       | P8          | 69      | 80      | T9           | PE8                                      | I/O      | TT_h<br>a     | -     | TIM1_CH1N,<br>DFSDM1_CKIN2,<br>UART7_TX,<br>QUADSPI_BK2_IO1,<br>FMC_D5/FMC_DA5,<br>COMP2_OUT,<br>EVENTOUT     | OPAMP2_VINM                |
| 39            | K5       | 60      | J8       | P9          | 70      | 81      | P9           | PE9                                      | I/O      | TT_h<br>a     | -     | TIM1_CH1,<br>DFSDM1_CKOUT,<br>UART7_RTS/UART7_DE<br>, QUADSPI_BK2_IO2,<br>FMC_D6/FMC_DA6,<br>EVENTOUT         | OPAMP2_VINP,<br>COMP2_INP  |
| -             | -        | 61      | C12      | M9          | 71      | 82      | J17          | VSS                                      | S        | -             | -     | -   | -                          |
| -             | -        | 62      | C13      | N9          | 72      | 83      | J13          | VDD                                      | S        | -             | -     | -   | -                          |
| 40            | G6       | 63      | M8       | R9          | 73      | 84      | N9           | PE10                                     | I/O      | FT_h<br>a     | -     | TIM1_CH2N,<br>DFSDM1_DATIN4,<br>UART7_CTS,<br>QUADSPI_BK2_IO3,<br>FMC_D7/FMC_DA7,<br>EVENTOUT                 | COMP2_INM                  |
| 41            | H6       | 64      | N8       | P10         | 74      | 85      | P10          | PE11                                     | I/O      | FT_h<br>a     | -     | TIM1_CH2,<br>DFSDM1_CKIN4,<br>SPI4_NSS, SAI2_SD_B,<br>FMC_D8/FMC_DA8,<br>LCD_G3, EVENTOUT                     | COMP2_INP                  |
| 42            | J6       | 65      | L8       | R10         | 75      | 86      | R10          | PE12                                     | I/O      | FT_h          | -     | TIM1_CH3N,<br>DFSDM1_DATIN5,<br>SPI4_SCK,<br>SAI2_SCK_B,<br>FMC_D9/FMC_DA9,<br>COMP1_OUT, LCD_B4,<br>EVENTOUT | -                          |
| 43            | K6       | 66      | K8       | N11         | 76      | 87      | T10          | PE13                                     | I/O      | FT_h          | -     | TIM1_CH3,<br>DFSDM1_CKIN5,<br>SPI4_MISO, SAI2_FS_B,<br>FMC_D10/FMC_DA10,<br>COMP2_OUT, LCD_DE,<br>EVENTOUT    | -                          |

Table 8. Pin/ball definition (continued)

| Pin/ball name |          |         |          |             |         |         |              | Pin name<br>(function<br>after<br>reset) | Pin type | I/O structure | Notes | Alternate functions  | Additional<br>functions |
|---------------|----------|---------|----------|-------------|---------|---------|--------------|--|----------|---------------|-------|--|-------------------------|
| LQFP100       | TFBGA100 | LQFP144 | UFBGA169 | UFBGA176+25 | LQFP176 | LQFP208 | TFBGA240 +25 |  |          |               |       |  |                         |
| -             | -        | -       | L12      | F7          | -       | -       | T12          | VSS                                      | S        | -             | -     | -  | -                       |
| -             | -        | -       | H13      | -           | -       | -       | K13          | VDD                                      | S        | -             | -     | -  | -                       |
| 44            | G7       | 67      | J9       | P11         | 77      | 88      | U10          | PE14                                     | I/O      | FT_h          | -     | TIM1_CH4, SPI4_MOSI,<br>SAI2_MCLK_B,<br>FMC_D11/FMC_DA11,<br>LCD_CLK, EVENTOUT   | -                       |
| 45            | H7       | 68      | N9       | R11         | 78      | 89      | R11          | PE15                                     | I/O      | FT_h          | -     | TIM1_BKIN,<br>FMC_D12/FMC_DA12,<br>TIM1_BKIN_COMP12/C<br>OMP_TIM1_BKIN,<br>LCD_R7, EVENTOUT  | -                       |
| 46            | J7       | 69      | L9       | R12         | 79      | 90      | P11          | PB10                                     | I/O      | FT_f          | -     | TIM2_CH3,<br>HRTIM_SCOUT,<br>LPTIM2_IN1, I2C2_SCL,<br>SPI2_SCK/I2S2_CK,<br>DFSDM1_DATIN7,<br>USART3_TX,<br>QUADSPI_BK1_NCS,<br>OTG_HS_ULPI_D3,<br>ETH_MII_RX_ER,<br>LCD_G4, EVENTOUT | -                       |
| 47            | K7       | 70      | M9       | R13         | 80      | 91      | P12          | PB11                                     | I/O      | FT_f          | -     | TIM2_CH4,<br>HRTIM_SCIN,<br>LPTIM2_ETR,<br>I2C2_SDA,<br>DFSDM1_CKIN7,<br>USART3_RX,<br>OTG_HS_ULPI_D4,<br>ETH_MII_TX_EN/ETH_R<br>MII_TX_EN, LCD_G5,<br>EVENTOUT                      | -                       |
| 48            | F8       | 71      | N10      | M10         | 81      | 92      | U11          | VCAP                                     | S        | -             | -     | -  | -                       |
| 49            | E4       | -       | -        | K7          | -       | 93      | -            | VSS                                      | S        | -             | -     | -  | -                       |
| -             | -        | -       | M10      | -           | -       | -       | U12          | VDDLDO<br>(6)                            | S        | -             | -     | -  | -                       |
| 50            | -        | 72      | -        | N10         | 82      | 94      | L13          | VDD                                      | S        | -             | -     | -  | -                       |
| -             | -        | -       | -        | -           | -       | 95      | R12          | PJ5                                      | I/O      | FT            | -     | LCD_R6, EVENTOUT   | -                       |
| -             | -        | -       | -        | M11         | 83      | 96      | T11          | PH6                                      | I/O      | FT            | -     | TIM12_CH1,<br>I2C2_SMBA, SPI5_SCK,<br>ETH_MII_RXD2,<br>FMC_SDNE1, DCMI_D8,<br>EVENTOUT   | -                       |

Table 8. Pin/ball definition (continued)

| Pin/ball name |          |         |          |             |         |         |              | Pin name<br>(function<br>after<br>reset) | Pin type | I/O structure | Notes | Alternate functions  | Additional<br>functions |
|---------------|----------|---------|----------|-------------|---------|---------|--------------|--|----------|---------------|-------|--|-------------------------|
| LQFP100       | TFBGA100 | LQFP144 | UFBGA169 | UFBGA176+25 | LQFP176 | LQFP208 | TFBGA240 +25 |  |          |               |       |  |                         |
| -             | -        | -       | -        | N12         | 84      | 97      | U13          | PH7                                      | I/O      | FT_fa         | -     | I2C3_SCL, SPI5_MISO,<br>ETH_MII_RXD3,<br>FMC_SDCKE1,<br>DCMI_D9, EVENTOUT  | -                       |
| -             | -        | -       | -        | M12         | 85      | 98      | T13          | PH8                                      | I/O      | FT_fh<br>a    | -     | TIM5_ETR, I2C3_SDA,<br>FMC_D16,<br>DCMI_HSYNC, LCD_R2,<br>EVENTOUT   | -                       |
| -             | -        | -       | -        | F8          | -       | -       | -            | VSS                                      | S        | -             | -     | -  | -                       |
| -             | -        | -       | L13      | -           | -       | -       | M13          | VDD                                      | S        | -             | -     | -  | -                       |
| -             | -        | -       | -        | M13         | 86      | 99      | R13          | PH9                                      | I/O      | FT_h          | -     | TIM12_CH2,<br>I2C3_SMBA, FMC_D17,<br>DCMI_D0, LCD_R3,<br>EVENTOUT  | -                       |
| -             | -        | -       | K9       | L13         | 87      | 100     | P13          | PH10                                     | I/O      | FT_h          | -     | TIM5_CH1, I2C4_SMBA,<br>FMC_D18, DCMI_D1,<br>LCD_R4, EVENTOUT  | -                       |
| -             | -        | -       | L10      | L12         | 88      | 101     | P14          | PH11                                     | I/O      | FT_fh         | -     | TIM5_CH2, I2C4_SCL,<br>FMC_D19, DCMI_D2,<br>LCD_R5, EVENTOUT   | -                       |
| -             | -        | -       | K10      | K12         | 89      | 102     | R14          | PH12                                     | I/O      | FT_fh         | -     | TIM5_CH3, I2C4_SDA,<br>FMC_D20, DCMI_D3,<br>LCD_R6, EVENTOUT   | -                       |
| -             | -        | -       | -        | H12         | 90      | -       | N16          | VSS                                      | S        | -             | -     | -  | -                       |
| -             | -        | -       | N11      | J12         | 91      | 103     | P17          | VDD                                      | S        | -             | -     | -  | -                       |
| 51            | K8       | 73      | N12      | P12         | 92      | 104     | T14          | PB12 <sup>(7)</sup>                      | I/O      | FT_u          | -     | TIM1_BKIN, I2C2_SMBA,<br>SPI2_NSS/I2S2_WS,<br>DFSDM1_DATIN1,<br>USART3_CK,<br>FDCAN2_RX,<br>OTG_HS_ULPI_D5,<br>ETH_MII_TXD0/ETH_RM<br>II_TXD0, OTG_HS_ID,<br>TIM1_BKIN_COMP12,<br>UART5_RX, EVENTOUT | -                       |

Table 8. Pin/ball definition (continued)

| Pin/ball name |          |         |          |             |         |         |              | Pin name<br>(function<br>after<br>reset) | Pin type | I/O structure | Notes | Alternate functions   | Additional<br>functions |
|---------------|----------|---------|----------|-------------|---------|---------|--------------|--|----------|---------------|-------|---|-------------------------|
| LQFP100       | TFBGA100 | LQFP144 | UFBGA169 | UFBGA176+25 | LQFP176 | LQFP208 | TFBGA240 +25 |  |          |               |       |   |                         |
| 52            | J8       | 74      | L11      | P13         | 93      | 105     | U14          | PB13 <sup>(7)</sup>                      | I/O      | FT_u          | -     | TIM1_CH1N,<br>LPTIM2_OUT,<br>SPI2_SCK/I2S2_CK,<br>DFSDM1_CKIN1,<br>USART3_CTS/USART3_NSS,<br>FDCAN2_TX,<br>OTG_HS_ULPI_D6,<br>ETH_MII_TXD1/ETH_RMII_TXD1,<br>UART5_TX,<br>EVENTOUT    | OTG_HS_VBUS             |
| 53            | H10      | 75      | N13      | R14         | 94      | 106     | U15          | PB14                                     | I/O      | FT_u          | -     | TIM1_CH2N,<br>TIM12_CH1,<br>TIM8_CH2N,<br>USART1_TX,<br>SPI2_MISO/I2S2_SDI,<br>DFSDM1_DATIN2,<br>USART3_RTS/USART3_DE,<br>UART4_RTS/UART4_DE,<br>SDMMC2_D0,<br>OTG_HS_DM,<br>EVENTOUT | -                       |
| 54            | G10      | 76      | M13      | R15         | 95      | 107     | T15          | PB15                                     | I/O      | FT_u          | -     | RTC_REFIN,<br>TIM1_CH3N,<br>TIM12_CH2,<br>TIM8_CH3N,<br>USART1_RX,<br>SPI2_MOSI/I2S2_SDO,<br>DFSDM1_CKIN2,<br>UART4_CTS,<br>SDMMC2_D1,<br>OTG_HS_DP,<br>EVENTOUT                      | -                       |
| 55            | K9       | 77      | M12      | P15         | 96      | 108     | U16          | PD8                                      | I/O      | FT_h          | -     | DFSDM1_CKIN3,<br>SAI3_SCK_B,<br>USART3_TX,<br>SPDIFRX1_IN2,<br>FMC_D13/FMC_DA13,<br>EVENTOUT  | -                       |
| 56            | J9       | 78      | K11      | P14         | 97      | 109     | T17          | PD9                                      | I/O      | FT_h          | -     | DFSDM1_DATIN3,<br>SAI3_SD_B,<br>USART3_RX,<br>FMC_D14/FMC_DA14,<br>EVENTOUT   | -                       |

Table 8. Pin/ball definition (continued)

| Pin/ball name |          |         |          |             |         |         |              | Pin name<br>(function<br>after<br>reset) | Pin type | I/O structure | Notes | Alternate functions   | Additional<br>functions |
|---------------|----------|---------|----------|-------------|---------|---------|--------------|--|----------|---------------|-------|---|-------------------------|
| LQFP100       | TFBGA100 | LQFP144 | UFBGA169 | UFBGA176+25 | LQFP176 | LQFP208 | TFBGA240 +25 |  |          |               |       |   |                         |
| 57            | H9       | 79      | K12      | N15         | 98      | 110     | T16          | PD10                                     | I/O      | FT_h          | -     | DFSDM1_CKOUT,<br>SAI3_FS_B,<br>USART3_CK,<br>FMC_D15/FMC_DA15,<br>LCD_B3, EVENTOUT  | -                       |
| -             | -        | -       | N7       | -           | -       | -       | N12          | VDD                                      | S        | -             | -     | -   | -                       |
| -             | -        | -       | -        | F9          | -       | -       | U17          | VSS                                      | S        | -             | -     | -   | -                       |
| 58            | G9       | 80      | J10      | N14         | 99      | 111     | R15          | PD11                                     | I/O      | FT_h          | -     | LPTIM2_IN2,<br>I2C4_SMBA,<br>USART3_CTS/USART3_<br>NSS,<br>QUADSPI_BK1_IO0,<br>SAI2_SD_A, FMC_A16,<br>EVENTOUT                  | -                       |
| 59            | K10      | 81      | K13      | N13         | 100     | 112     | R16          | PD12                                     | I/O      | FT_fh         | -     | LPTIM1_IN1, TIM4_CH1,<br>LPTIM2_IN1, I2C4_SCL,<br>USART3_RTS/USART3_<br>DE, QUADSPI_BK1_IO1,<br>SAI2_FS_A, FMC_A17,<br>EVENTOUT | -                       |
| 60            | J10      | 82      | J11      | M15         | 101     | 113     | R17          | PD13                                     | I/O      | FT_fh         | -     | LPTIM1_OUT,<br>TIM4_CH2, I2C4_SDA,<br>QUADSPI_BK1_IO3,<br>SAI2_SCK_A, FMC_A18,<br>EVENTOUT                                      | -                       |
| -             | -        | 83      | -        | K8          | 102     | 114     | -            | VSS                                      | S        | -             | -     | -   | -                       |
| -             | -        | 84      | -        | J13         | 103     | 115     | N11          | VDD                                      | S        | -             | -     | -   | -                       |
| 61            | H8       | 85      | J13      | M14         | 104     | 116     | P16          | PD14                                     | I/O      | FT_h          | -     | TIM4_CH3,<br>SAI3_MCLK_B,<br>UART8_CTS,<br>FMC_D0/FMC_DA0,<br>EVENTOUT  | -                       |
| 62            | G8       | 86      | J12      | L14         | 105     | 117     | P15          | PD15                                     | I/O      | FT_h          | -     | TIM4_CH4,<br>SAI3_MCLK_A,<br>UART8_RTS/UART8_DE<br>, FMC_D1/FMC_DA1,<br>EVENTOUT  | -                       |
| -             | -        | -       | -        | -           | -       | 118     | N15          | PJ6                                      | I/O      | FT            | -     | TIM8_CH2, LCD_R7,<br>EVENTOUT   | -                       |
| -             | -        | -       | -        | -           | -       | 119     | N14          | PJ7                                      | I/O      | FT            | -     | TRGIN, TIM8_CH2N,<br>LCD_G0, EVENTOUT   | -                       |
| -             | -        | -       | -        | -           | -       | -       | N10          | VDD                                      | S        | -             | -     | -   | -                       |
| -             | -        | -       | -        | F10         | -       | -       | R8           | VSS                                      | S        | -             | -     | -   | -                       |

Table 8. Pin/ball definition (continued)

| Pin/ball name |          |         |          |             |         |         |                    | Pin name<br>(function<br>after<br>reset) | Pin type | I/O structure | Notes | Alternate functions   | Additional<br>functions |
|---------------|----------|---------|----------|-------------|---------|---------|--------------------|--|----------|---------------|-------|---|-------------------------|
| LQFP100       | TFBGA100 | LQFP144 | UFBGA169 | UFBGA176+25 | LQFP176 | LQFP208 | TFBGA240 +25       |  |          |               |       |   |                         |
| -             | -        | -       | -        | -           | -       | 120     | N13                | PJ8                                      | I/O      | FT            | -     | TIM1_CH3N, TIM8_CH1,<br>UART8_TX, LCD_G1,<br>EVENTOUT                               | -                       |
| -             | -        | -       | -        | -           | -       | 121     | M14                | PJ9                                      | I/O      | FT            | -     | TIM1_CH3, TIM8_CH1N,<br>UART8_RX, LCD_G2,<br>EVENTOUT                               | -                       |
| -             | -        | -       | -        | -           | -       | 122     | L14                | PJ10                                     | I/O      | FT            | -     | TIM1_CH2N, TIM8_CH2,<br>SPI5_MOSI, LCD_G3,<br>EVENTOUT                              | -                       |
| -             | -        | -       | -        | -           | -       | 123     | K14                | PJ11                                     | I/O      | FT            | -     | TIM1_CH2, TIM8_CH2N,<br>SPI5_MISO, LCD_G4,<br>EVENTOUT                              | -                       |
| -             | -        | -       | -        | -           | -       | 124     | N8                 | VDD                                      | S        | -             | -     | -   | -                       |
| -             | -        | -       | -        | G6          | -       | 125     | U1                 | VSS                                      | S        | -             | -     | -   | -                       |
| -             | -        | -       | -        | -           | -       | -       | N17 <sup>(2)</sup> | NC                                       | -        | -             | -     | -   | -                       |
| -             | -        | -       | -        | -           | -       | -       | M16 <sup>(2)</sup> | NC                                       | -        | -             | -     | -   | -                       |
| -             | -        | -       | -        | -           | -       | -       | M17 <sup>(2)</sup> | NC                                       | -        | -             | -     | -   | -                       |
| -             | -        | -       | -        | -           | -       | -       | K15                | VSS                                      | S        | -             | -     | -   | -                       |
| -             | -        | -       | -        | -           | -       | -       | L16 <sup>(2)</sup> | NC                                       | -        | -             | -     | -   | -                       |
| -             | -        | -       | -        | -           | -       | -       | L17 <sup>(2)</sup> | NC                                       | -        | -             | -     | -   | -                       |
| -             | -        | -       | -        | -           | -       | -       | K16 <sup>(2)</sup> | NC                                       | -        | -             | -     | -   | -                       |
| -             | -        | -       | -        | -           | -       | -       | K17 <sup>(2)</sup> | NC                                       | -        | -             | -     | -   | -                       |
| -             | -        | -       | -        | -           | -       | -       | L15                | VSS                                      | S        | -             | -     | -   | -                       |
| -             | -        | -       | -        | -           | -       | 126     | J14                | PK0                                      | I/O      | FT            | -     | TIM1_CH1N, TIM8_CH3,<br>SPI5_SCK, LCD_G5,<br>EVENTOUT                               | -                       |
| -             | -        | -       | -        | -           | -       | 127     | J15                | PK1                                      | I/O      | FT            | -     | TIM1_CH1, TIM8_CH3N,<br>SPI5_NSS, LCD_G6,<br>EVENTOUT                               | -                       |
| -             | -        | -       | -        | -           | -       | 128     | H17                | PK2                                      | I/O      | FT            | -     | TIM1_BKIN, TIM8_BKIN,<br>TIM8_BKIN_COMP12,<br>TIM1_BKIN_COMP12,<br>LCD_G7, EVENTOUT | -                       |

Table 8. Pin/ball definition (continued)

| Pin/ball name |          |         |          |             |         |         |              | Pin name<br>(function<br>after<br>reset) | Pin type | I/O structure | Notes | Alternate functions  | Additional<br>functions |
|---------------|----------|---------|----------|-------------|---------|---------|--------------|--|----------|---------------|-------|--|-------------------------|
| LQFP100       | TFBGA100 | LQFP144 | UFBGA169 | UFBGA176+25 | LQFP176 | LQFP208 | TFBGA240 +25 |  |          |               |       |  |                         |
| -             | -        | 87      | H9       | L15         | 106     | 129     | H16          | PG2                                      | I/O      | FT_h          | -     | TIM8_BKIN,<br>TIM8_BKIN_COMP12,<br>FMC_A12, EVENTOUT   | -                       |
| -             | -        | 88      | H10      | K15         | 107     | 130     | H15          | PG3                                      | I/O      | FT_h          | -     | TIM8_BKIN2,<br>TIM8_BKIN2_COMP12,<br>FMC_A13, EVENTOUT   | -                       |
| -             | -        | -       | -        | G7          | -       | -       | -            | VSS                                      | S        | -             | -     | -  | -                       |
| -             | -        | -       | -        | -           | -       | -       | N7           | VDD                                      | S        | -             | -     | -  | -                       |
| -             | -        | 89      | F8       | K14         | 108     | 131     | H14          | PG4                                      | I/O      | FT_h          | -     | TIM1_BKIN2,<br>TIM1_BKIN2_COMP12,<br>FMC_A14/FMC_BA0,<br>EVENTOUT  | -                       |
| -             | -        | 90      | H11      | K13         | 109     | 132     | G14          | PG5                                      | I/O      | FT_h          | -     | TIM1_ETR,<br>FMC_A15/FMC_BA1,<br>EVENTOUT  | -                       |
| -             | -        | 91      | G9       | J15         | 110     | 133     | G15          | PG6                                      | I/O      | FT_h          | -     | TIM17_BKIN,<br>HRTIM_CHE1,<br>QUADSPI_BK1_NCS,<br>FMC_NE3, DCMI_D12,<br>LCD_R7, EVENTOUT                         | -                       |
| -             | -        | 92      | G10      | J14         | 111     | 134     | F16          | PG7                                      | I/O      | FT_h          | -     | HRTIM_CHE2,<br>SAI1_MCLK_A,<br>USART6_CK, FMC_INT,<br>DCMI_D13, LCD_CLK,<br>EVENTOUT                             | -                       |
| -             | -        | 93      | G11      | H14         | 112     | 135     | F15          | PG8                                      | I/O      | FT_h          | -     | TIM8_ETR, SPI6_NSS,<br>USART6_RTS/USART6_<br>DE, SPDIFRX1_IN3,<br>ETH_PPS_OUT,<br>FMC_SDCLK, LCD_G7,<br>EVENTOUT | -                       |
| -             | -        | 94      | -        | G12         | 113     | 136     | G16          | VSS                                      | S        | -             | -     | -  | -                       |
| -             | -        | -       | G12      | -           | -       | -       | G17          | VDD50US<br>B <sup>(8)</sup>              | S        | -             | -     | -  | -                       |
| -             | F6       | 95      | G13      | H13         | 114     | 137     | F17          | VDD33US<br>B                             | S        | -             | -     | -  | -                       |
| -             | -        | -       | -        | -           | -       | -       | M5           | VDD                                      | S        | -             | -     | -  | -                       |

Table 8. Pin/ball definition (continued)

| Pin/ball name |          |         |          |             |         |         |              | Pin name<br>(function<br>after<br>reset) | Pin type | I/O structure | Notes | Alternate functions   | Additional<br>functions |   |
|---------------|----------|---------|----------|-------------|---------|---------|--------------|--|----------|---------------|-------|---|-------------------------|---|
| LQFP100       | TFBGA100 | LQFP144 | UFBGA169 | UFBGA176+25 | LQFP176 | LQFP208 | TFBGA240 +25 |  |          |               |       |   |                         |   |
| 63            | F10      | 96      | F9       | H15         | 115     | 138     | F14          | PC6                                      | I/O      | FT_h          | -     | HRTIM_CHA1,<br>TIM3_CH1, TIM8_CH1,<br>DFSDM1_CKIN3,<br>I2S2_MCK, USART6_TX,<br>SDMMC1_D0DIR,<br>FMC_NWAIT,<br>SDMMC2_D6,<br>SDMMC1_D6, DCM1_D0,<br>LCD_HSYNC,<br>EVENTOUT                   | SWPMI_IO                |   |
| 64            | E10      | 97      | F10      | G15         | 116     | 139     | F13          | PC7                                      | I/O      | FT_h          | -     | TRGIO, HRTIM_CHA2,<br>TIM3_CH2, TIM8_CH2,<br>DFSDM1_DATIN3,<br>I2S3_MCK,<br>USART6_RX,<br>SDMMC1_D123DIR,<br>FMC_NE1,<br>SDMMC2_D7,<br>SWPMI_TX,<br>SDMMC1_D7, DCM1_D1,<br>LCD_G6, EVENTOUT | -                       |   |
| 65            | F9       | 98      | F12      | G14         | 117     | 140     | E13          | PC8                                      | I/O      | FT_h          | -     | TRACED1,<br>HRTIM_CHB1,<br>TIM3_CH3, TIM8_CH3,<br>USART6_CK,<br>UART5_RTS/UART5_DE<br>, FMC_NE2/FMC_NCE,<br>SWPMI_RX,<br>SDMMC1_D0, DCM1_D2,<br>EVENTOUT                                    | -                       |   |
| 66            | E9       | 99      | F11      | F14         | 118     | 141     | E14          | PC9                                      | I/O      | FT_fh         | -     | MCO2, TIM3_CH4,<br>TIM8_CH4, I2C3_SDA,<br>I2S_CKIN, UART5_CTS,<br>QUADSPI_BK1_IO0,<br>LCD_G3,<br>SWPMI_SUSPEND,<br>SDMMC1_D1, DCM1_D3,<br>LCD_B2, EVENTOUT                                  | -                       |   |
| -             | -        | -       | -        | G8          | -       | -       | -            | VSS                                      | S        | -             | -     | -   | -                       | - |
| -             | -        | -       | -        | -           | -       | -       | L5           | VDD                                      | S        | -             | -     | -   | -                       | - |

Table 8. Pin/ball definition (continued)

| Pin/ball name |          |         |          |             |         |         |              | Pin name<br>(function<br>after<br>reset) | Pin type | I/O structure         | Notes | Alternate functions   | Additional<br>functions |
|---------------|----------|---------|----------|-------------|---------|---------|--------------|--|----------|-----------------------|-------|---|-------------------------|
| LQFP100       | TFBGA100 | LQFP144 | UFBGA169 | UFBGA176+25 | LQFP176 | LQFP208 | TFBGA240 +25 |  |          |                       |       |   |                         |
| 67            | D9       | 100     | E12      | F15         | 119     | 142     | E15          | PA8                                      | I/O      | FT <sub>fh</sub><br>a | -     | MCO1, TIM1_CH1,<br>HRTIM_CHB2,<br>TIM8_BKIN2, I2C3_SCL,<br>USART1_CK,<br>OTG_FS_SOF,<br>UART7_RX,<br>TIM8_BKIN2_COMP12,<br>LCD_B3, LCD_R6,<br>EVENTOUT                            | -                       |
| 68            | C9       | 101     | E11      | E15         | 120     | 143     | D15          | PA9                                      | I/O      | FT <sub>u</sub>       | -     | TIM1_CH2,<br>HRTIM_CHC1,<br>LPUART1_TX,<br>I2C3_SMBA,<br>SPI2_SCK/I2S2_CK,<br>USART1_TX,<br>ETH_TX_ER, DCMI_D0,<br>LCD_R5, EVENTOUT   | OTG_FS_VBUS             |
| 69            | D10      | 102     | E10      | D15         | 121     | 144     | D14          | PA10                                     | I/O      | FT <sub>u</sub>       | -     | TIM1_CH3,<br>HRTIM_CHC2,<br>LPUART1_RX,<br>USART1_RX,<br>OTG_FS_ID,<br>MDIOS_MDIO, LCD_B4,<br>DCMI_D1, LCD_B1,<br>EVENTOUT  | -                       |
| 70            | C10      | 103     | F13      | C15         | 122     | 145     | E17          | PA11                                     | I/O      | FT <sub>u</sub>       | -     | TIM1_CH4,<br>HRTIM_CHD1,<br>LPUART1_CTS,<br>SPI2_NSS/I2S2_WS,<br>UART4_RX,<br>USART1_CTS/USART1_<br>NSS, FDCAN1_RX,<br>OTG_FS_DM, LCD_R4,<br>EVENTOUT                             | -                       |
| 71            | B10      | 104     | E13      | B15         | 123     | 146     | E16          | PA12                                     | I/O      | FT <sub>u</sub>       | -     | TIM1_ETR,<br>HRTIM_CHD2,<br>LPUART1_RTS/LPUART<br>1_DE,<br>SPI2_SCK/I2S2_CK,<br>UART4_TX,<br>USART1_RTS/USART1_<br>DE, SAI2_FS_B,<br>FDCAN1_TX,<br>OTG_FS_DP, LCD_R5,<br>EVENTOUT | -                       |
| 72            | A10      | 105     | D11      | A15         | 124     | 147     | C15          | PA13(JTMS/SWDIO)                         | I/O      | FT                    | -     | JTMS-SWDIO,<br>EVENTOUT   | -                       |

Table 8. Pin/ball definition (continued)

| Pin/ball name |          |         |          |             |         |         |              | Pin name<br>(function<br>after<br>reset) | Pin type | I/O structure | Notes | Alternate functions   | Additional<br>functions |
|---------------|----------|---------|----------|-------------|---------|---------|--------------|--|----------|---------------|-------|---|-------------------------|
| LQFP100       | TFBGA100 | LQFP144 | UFBGA169 | UFBGA176+25 | LQFP176 | LQFP208 | TFBGA240 +25 |  |          |               |       |   |                         |
| 73            | E7       | 106     | D13      | F13         | 125     | 148     | D17          | VCAP                                     | S        | -             | -     | -   | -                       |
| 74            | E5       | 107     | -        | F12         | 126     | 149     | -            | VSS                                      | S        | -             | -     | -   | -                       |
| -             | -        | -       | D12      | -           | -       | -       | C17          | VDDLDO <sup>(6)</sup><br>)               | S        | -             | -     | -   | -                       |
| 75            | -        | 108     | -        | G13         | 127     | 150     | K5           | VDD                                      | S        | -             | -     | -   | -                       |
| -             | -        | -       | -        | E12         | 128     | 151     | D16          | PH13                                     | I/O      | FT_h          | -     | TIM8_CH1N, UART4_TX,<br>FDCAN1_TX, FMC_D21,<br>LCD_G2, EVENTOUT                                 | -                       |
| -             | -        | -       | -        | E13         | 129     | 152     | B17          | PH14                                     | I/O      | FT_h          | -     | TIM8_CH2N,<br>UART4_RX,<br>FDCAN1_RX, FMC_D22,<br>DCMI_D4, LCD_G3,<br>EVENTOUT                  | -                       |
| -             | -        | -       | -        | D13         | 130     | 153     | B16          | PH15                                     | I/O      | FT_h          | -     | TIM8_CH3N, FMC_D23,<br>DCMI_D11, LCD_G4,<br>EVENTOUT  | -                       |
| -             | -        | -       | A13      | E14         | 131     | 154     | A16          | PI0                                      | I/O      | FT_h          | -     | TIM5_CH4,<br>SPI2_NSS/I2S2_WS,<br>FMC_D24, DCMI_D13,<br>LCD_G5, EVENTOUT                        | -                       |
| -             | -        | -       | -        | G9          | -       | -       | -            | VSS                                      | S        | -             | -     | -   | -                       |
| -             | -        | -       | B13      | D14         | 132     | 155     | A15          | PI1                                      | I/O      | FT_h          | -     | TIM8_BKIN2,<br>SPI2_SCK/I2S2_CK,<br>TIM8_BKIN2_COMP12,<br>FMC_D25, DCMI_D8,<br>LCD_G6, EVENTOUT | -                       |
| -             | -        | -       | A6       | C14         | 133     | 156     | B15          | PI2                                      | I/O      | FT_h          | -     | TIM8_CH4,<br>SPI2_MISO/I2S2_SDI,<br>FMC_D26, DCMI_D9,<br>LCD_G7, EVENTOUT                       | -                       |
| -             | -        | -       | B7       | C13         | 134     | 157     | C14          | PI3                                      | I/O      | FT_h          | -     | TIM8_ETR,<br>SPI2_MOSI/I2S2_SDO,<br>FMC_D27, DCMI_D10,<br>EVENTOUT                              | -                       |
| -             | -        | -       | -        | D9          | 135     | -       | -            | VSS                                      | S        | -             | -     | -   | -                       |
| -             | -        | -       | -        | C9          | 136     | 158     | -            | VDD                                      | S        | -             | -     | -   | -                       |
| 76            | A9       | 109     | B12      | A14         | 137     | 159     | B14          | PA14(JTCK/SWCLK)                         | I/O      | FT            | -     | JTCK-SWCLK,<br>EVENTOUT   | -                       |

Table 8. Pin/ball definition (continued)

| Pin/ball name |          |         |          |             |         |         |              | Pin name<br>(function<br>after<br>reset) | Pin type | I/O structure | Notes | Alternate functions   | Additional<br>functions |   |
|---------------|----------|---------|----------|-------------|---------|---------|--------------|--|----------|---------------|-------|---|-------------------------|---|
| LQFP100       | TFBGA100 | LQFP144 | UFBGA169 | UFBGA176+25 | LQFP176 | LQFP208 | TFBGA240 +25 |  |          |               |       |   |                         |   |
| 77            | A8       | 110     | C11      | A13         | 138     | 160     | A14          | PA15(JTDI<br>)                           | I/O      | FT            | -     | JTDI,<br>TIM2_CH1/TIM2_ETR,<br>HRTIM_FLT1, CEC,<br>SPI1_NSS/I2S1_WS,<br>SPI3_NSS/I2S3_WS,<br>SPI6_NSS,<br>UART4_RTS/UART4_DE<br>, UART7_TX,<br>EVENTOUT | -                       |   |
| 78            | B9       | 111     | A12      | B14         | 139     | 161     | A13          | PC10                                     | I/O      | FT_h<br>a     | -     | HRTIM_EEV1,<br>DFSDM1_CKIN5,<br>SPI3_SCK/I2S3_CK,<br>USART3_TX,<br>UART4_TX,<br>QUADSPI_BK1_IO1,<br>SDMMC1_D2, DCMI_D8,<br>LCD_R2, EVENTOUT             | -                       |   |
| 79            | B8       | 112     | B11      | B13         | 140     | 162     | B13          | PC11                                     | I/O      | FT_h          | -     | HRTIM_FLT2,<br>DFSDM1_DATIN5,<br>SPI3_MISO/I2S3_SDI,<br>USART3_RX,<br>UART4_RX,<br>QUADSPI_BK2_NCS,<br>SDMMC1_D3, DCMI_D4,<br>EVENTOUT                  | -                       |   |
| 80            | C8       | 113     | A11      | A12         | 141     | 163     | C12          | PC12                                     | I/O      | FT_h          | -     | TRACED3,<br>HRTIM_EEV2,<br>SPI3_MOSI/I2S3_SDO,<br>USART3_CK,<br>UART5_TX,<br>SDMMC1_CK, DCMI_D9,<br>EVENTOUT  | -                       |   |
| -             | -        | -       | -        | G10         | -       | -       | -            | VSS                                      | S        | -             | -     | -   | -                       | - |
| 81            | D8       | 114     | D10      | B12         | 142     | 164     | D13          | PD0                                      | I/O      | FT_h          | -     | DFSDM1_CKIN6,<br>SAI3_SCK_A,<br>UART4_RX,<br>FDCAN1_RX,<br>FMC_D2/FMC_DA2,<br>EVENTOUT  | -                       |   |
| 82            | E8       | 115     | C10      | C12         | 143     | 165     | E12          | PD1                                      | I/O      | FT_h          | -     | DFSDM1_DATIN6,<br>SAI3_SD_A, UART4_TX,<br>FDCAN1_TX,<br>FMC_D3/FMC_DA3,<br>EVENTOUT   | -                       |   |

Table 8. Pin/ball definition (continued)

| Pin/ball name |          |         |          |             |         |         |              | Pin name<br>(function<br>after<br>reset) | Pin type | I/O structure | Notes | Alternate functions  | Additional<br>functions |
|---------------|----------|---------|----------|-------------|---------|---------|--------------|--|----------|---------------|-------|--|-------------------------|
| LQFP100       | TFBGA100 | LQFP144 | UFBGA169 | UFBGA176+25 | LQFP176 | LQFP208 | TFBGA240 +25 |  |          |               |       |  |                         |
| 83            | B7       | 116     | E9       | D12         | 144     | 166     | D12          | PD2                                      | I/O      | FT_h          | -     | TRACED2, TIM3_ETR,<br>UART5_RX,<br>SDMMC1_CMD,<br>DCMI_D11, EVENTOUT   | -                       |
| 84            | C7       | 117     | D9       | D11         | 145     | 167     | B12          | PD3                                      | I/O      | FT_h          | -     | DFSDM1_CKOUT,<br>SPI2_SCK/I2S2_CK,<br>USART2_CTS/USART2_<br>NSS, FMC_CLK,<br>DCMI_D5, LCD_G7,<br>EVENTOUT  | -                       |
| 85            | D7       | 118     | C9       | D10         | 146     | 168     | A12          | PD4                                      | I/O      | FT_h          | -     | HRTIM_FLT3,<br>SAI3_FS_A,<br>USART2_RTS/USART2_<br>DE, FMC_NOE,<br>EVENTOUT  | -                       |
| 86            | B6       | 119     | A9       | C11         | 147     | 169     | A11          | PD5                                      | I/O      | FT_h          | -     | HRTIM_EEV3,<br>USART2_TX,<br>FMC_NWE, EVENTOUT   | -                       |
| -             | -        | 120     | -        | D8          | 148     | 170     | -            | VSS                                      | S        | -             | -     | -  | -                       |
| -             | -        | 121     | -        | C8          | 149     | 171     | -            | VDD                                      | S        | -             | -     | -  | -                       |
| 87            | C6       | 122     | B9       | B11         | 150     | 172     | B11          | PD6                                      | I/O      | FT_h          | -     | SAI1_D1,<br>DFSDM1_CKIN4,<br>DFSDM1_DATIN1,<br>SPI3_MOSI/I2S3_SDO,<br>SAI1_SD_A,<br>USART2_RX,<br>SAI4_SD_A, SAI4_D1,<br>SDMMC2_CK,<br>FMC_NWAIT,<br>DCMI_D10, LCD_B2,<br>EVENTOUT | -                       |
| 88            | D6       | 123     | D8       | A11         | 151     | 173     | C11          | PD7                                      | I/O      | FT_h          | -     | DFSDM1_DATIN4,<br>SPI1_MOSI/I2S1_SDO,<br>DFSDM1_CKIN1,<br>USART2_CK,<br>SPDIFRX1_IN1,<br>SDMMC2_CMD,<br>FMC_NE1, EVENTOUT  | -                       |
| -             | -        | -       | -        | -           | -       | 174     | D11          | PJ12                                     | I/O      | FT            | -     | TRGOUT, LCD_G3,<br>LCD_B0, EVENTOUT  | -                       |
| -             | -        | -       | -        | -           | -       | 175     | E10          | PJ13                                     | I/O      | FT            | -     | LCD_B4, LCD_B1,<br>EVENTOUT  | -                       |
| -             | -        | -       | -        | -           | -       | 176     | D10          | PJ14                                     | I/O      | FT            | -     | LCD_B2, EVENTOUT   | -                       |
| -             | -        | -       | -        | -           | -       | 177     | B10          | PJ15                                     | I/O      | FT            | -     | LCD_B3, EVENTOUT   | -                       |

Table 8. Pin/ball definition (continued)

| Pin/ball name |          |         |          |             |         |         |              | Pin name<br>(function<br>after<br>reset) | Pin type | I/O structure | Notes | Alternate functions  | Additional<br>functions |
|---------------|----------|---------|----------|-------------|---------|---------|--------------|--|----------|---------------|-------|--|-------------------------|
| LQFP100       | TFBGA100 | LQFP144 | UFBGA169 | UFBGA176+25 | LQFP176 | LQFP208 | TFBGA240 +25 |  |          |               |       |  |                         |
| -             | -        | -       | -        | H6          | -       | -       | -            | VSS                                      | S        | -             | -     | -  | -                       |
| -             | -        | -       | A7       | -           | -       | -       | -            | VDD                                      | S        | -             | -     | -  | -                       |
| -             | -        | 124     | C8       | C10         | 152     | 178     | A10          | PG9                                      | I/O      | FT_h          | -     | SPI1_MISO/I2S1_SDI,<br>USART6_RX,<br>SPDIFRX1_IN4,<br>QUADSPI_BK2_IO2,<br>SAI2_FS_B,<br>FMC_NE2/FMC_NCE,<br>DCMI_VSYNC,<br>EVENTOUT                            | -                       |
| -             | -        | 125     | A8       | B10         | 153     | 179     | A9           | PG10                                     | I/O      | FT_h          | -     | HRTIM_FLT5,<br>SPI1_NSS/I2S1_WS,<br>LCD_G3, SAI2_SD_B,<br>FMC_NE3, DCMI_D2,<br>LCD_B2, EVENTOUT  | -                       |
| -             | -        | 126     | B8       | B9          | 154     | 180     | B9           | PG11                                     | I/O      | FT_h          | -     | LPTIM1_IN2,<br>HRTIM_EEV4,<br>SPI1_SCK/I2S1_CK,<br>SPDIFRX1_IN1,<br>SDMMC2_D2,<br>ETH_MII_TX_EN/ETH_R<br>MII_TX_EN, DCMI_D3,<br>LCD_B3, EVENTOUT               | -                       |
| -             | -        | 127     | E8       | B8          | 155     | 181     | C9           | PG12                                     | I/O      | FT_h          | -     | LPTIM1_IN1,<br>HRTIM_EEV5,<br>SPI6_MISO,<br>USART6_RTS/USART6_<br>DE, SPDIFRX1_IN2,<br>LCD_B4,<br>ETH_MII_TXD1/ETH_RM<br>II_TXD1, FMC_NE4,<br>LCD_B1, EVENTOUT | -                       |
| -             | -        | 128     | D7       | A8          | 156     | 182     | D9           | PG13                                     | I/O      | FT_h          | -     | TRACED0,<br>LPTIM1_OUT,<br>HRTIM_EEV10,<br>SPI6_SCK,<br>USART6_CTS/USART6_<br>NSS,<br>ETH_MII_TXD0/ETH_RM<br>II_TXD0, FMC_A24,<br>LCD_R0, EVENTOUT             | -                       |

Table 8. Pin/ball definition (continued)

| Pin/ball name |          |         |          |             |         |         |              | Pin name<br>(function<br>after<br>reset) | Pin type | I/O structure | Notes | Alternate functions  | Additional<br>functions |
|---------------|----------|---------|----------|-------------|---------|---------|--------------|--|----------|---------------|-------|--|-------------------------|
| LQFP100       | TFBGA100 | LQFP144 | UFBGA169 | UFBGA176+25 | LQFP176 | LQFP208 | TFBGA240 +25 |  |          |               |       |  |                         |
| -             | -        | 129     | C7       | A7          | 157     | 183     | D8           | PG14                                     | I/O      | FT_h          | -     | TRACED1,<br>LPTIM1_ETR,<br>SPI6_MOSI,<br>USART6_TX,<br>QUADSPI_BK2_IO3,<br>ETH_MII_TXD1/ETH_RM<br>II_TXD1, FMC_A25,<br>LCD_B0, EVENTOUT                              | -                       |
| -             | -        | 130     | -        | D7          | 158     | 184     | -            | VSS                                      | S        | -             | -     | -  | -                       |
| -             | -        | 131     | -        | C7          | 159     | 185     | -            | VDD                                      | S        | -             | -     | -  | -                       |
| -             | -        | -       | -        | -           | -       | 186     | C8           | PK3                                      | I/O      | FT            | -     | LCD_B4, EVENTOUT   | -                       |
| -             | -        | -       | -        | -           | -       | 187     | B8           | PK4                                      | I/O      | FT            | -     | LCD_B5, EVENTOUT   | -                       |
| -             | -        | -       | -        | -           | -       | 188     | A8           | PK5                                      | I/O      | FT            | -     | LCD_B6, EVENTOUT   | -                       |
| -             | -        | -       | -        | -           | -       | 189     | C7           | PK6                                      | I/O      | FT            | -     | LCD_B7, EVENTOUT   | -                       |
| -             | -        | -       | -        | -           | -       | 190     | D7           | PK7                                      | I/O      | FT            | -     | LCD_DE, EVENTOUT   | -                       |
| -             | -        | -       | -        | H7          | -       | -       | -            | VSS                                      | S        | -             | -     | -  | -                       |
| -             | -        | 132     | E7       | B7          | 160     | 191     | D6           | PG15                                     | I/O      | FT_h          | -     | USART6_CTS/USART6_<br>NSS, FMC_SDNCAS,<br>DCMI_D13, EVENTOUT   | -                       |
| 89            | A7       | 133     | F7       | A10         | 161     | 192     | C6           | PB3(JTDO<br>/TRACES<br>WO)               | I/O      | FT            | -     | JTDO/TRACESWO,<br>TIM2_CH2,<br>HRTIM_FLT4,<br>SPI1_SCK/I2S1_CK,<br>SPI3_SCK/I2S3_CK,<br>SPI6_SCK,<br>SDMMC2_D2,<br>CRS_SYNC, UART7_RX,<br>EVENTOUT                   | -                       |
| 90            | A6       | 134     | B6       | A9          | 162     | 193     | B7           | PB4(NJTR<br>ST)                          | I/O      | FT            | -     | NJTRST, TIM16_BKIN,<br>TIM3_CH1,<br>HRTIM_EEV6,<br>SPI1_MISO/I2S1_SDI,<br>SPI3_MISO/I2S3_SDI,<br>SPI2_NSS/I2S2_WS,<br>SPI6_MISO,<br>SDMMC2_D3,<br>UART7_TX, EVENTOUT | -                       |

Table 8. Pin/ball definition (continued)

| Pin/ball name |          |         |          |             |         |         |              | Pin name<br>(function<br>after<br>reset) | Pin type | I/O structure | Notes | Alternate functions   | Additional<br>functions |
|---------------|----------|---------|----------|-------------|---------|---------|--------------|--|----------|---------------|-------|---|-------------------------|
| LQFP100       | TFBGA100 | LQFP144 | UFBGA169 | UFBGA176+25 | LQFP176 | LQFP208 | TFBGA240 +25 |  |          |               |       |   |                         |
| 91            | C5       | 135     | C6       | A6          | 163     | 194     | A5           | PB5                                      | I/O      | FT            | -     | TIM17_BKIN, TIM3_CH2,<br>HRTIM_EEV7,<br>I2C1_SMBA,<br>SPI1_MOSI/I2S1_SDO,<br>I2C4_SMBA,<br>SPI3_MOSI/I2S3_SDO,<br>SPI6_MOSI,<br>FDCAN2_RX,<br>OTG_HS_ULPI_D7,<br>ETH_PPS_OUT,<br>FMC_SDCKE1,<br>DCMI_D10, UART5_RX,<br>EVENTOUT | -                       |
| -             | -        | -       | -        | H8          | -       | -       | -            | VSS                                      | S        | -             | -     | -   | -                       |
| 92            | B5       | 136     | A5       | B6          | 164     | 195     | B5           | PB6                                      | I/O      | FT_f          | -     | TIM16_CH1N,<br>TIM4_CH1,<br>HRTIM_EEV8,<br>I2C1_SCL, CEC,<br>I2C4_SCL, USART1_TX,<br>LPUART1_TX,<br>FDCAN2_TX,<br>QUADSPI_BK1_NCS,<br>DFSDM1_DATIN5,<br>FMC_SDNE1, DCMI_D5,<br>UART5_TX, EVENTOUT                               | -                       |
| 93            | A5       | 137     | D6       | B5          | 165     | 196     | C5           | PB7                                      | I/O      | FT_fa         | -     | TIM17_CH1N,<br>TIM4_CH2,<br>HRTIM_EEV9,<br>I2C1_SDA, I2C4_SDA,<br>USART1_RX,<br>LPUART1_RX,<br>DFSDM1_CKIN5,<br>FMC_NL, DCMI_VSYNC,<br>EVENTOUT   | PVD_IN                  |
| 94            | D5       | 138     | E6       | D6          | 166     | 197     | E8           | BOOT0                                    | I        | B             | -     | -   | VPP                     |
| 95            | B4       | 139     | B5       | A5          | 167     | 198     | D5           | PB8                                      | I/O      | FT_fh         | -     | TIM16_CH1, TIM4_CH3,<br>DFSDM1_CKIN7,<br>I2C1_SCL, I2C4_SCL,<br>SDMMC1_CKIN,<br>UART4_RX,<br>FDCAN1_RX,<br>SDMMC2_D4,<br>ETH_MII_TXD3,<br>SDMMC1_D4, DCMI_D6,<br>LCD_B6, EVENTOUT   | -                       |

Table 8. Pin/ball definition (continued)

| Pin/ball name |          |         |          |             |         |         |              | Pin name<br>(function<br>after<br>reset) | Pin type | I/O structure | Notes | Alternate functions   | Additional<br>functions |
|---------------|----------|---------|----------|-------------|---------|---------|--------------|--|----------|---------------|-------|---|-------------------------|
| LQFP100       | TFBGA100 | LQFP144 | UFBGA169 | UFBGA176+25 | LQFP176 | LQFP208 | TFBGA240 +25 |  |          |               |       |   |                         |
| 96            | A4       | 140     | C5       | B4          | 168     | 199     | D4           | PB9                                      | I/O      | FT_fh         | -     | TIM17_CH1, TIM4_CH4,<br>DFSDM1_DATIN7,<br>I2C1_SDA,<br>SPI2_NSS/I2S2_WS,<br>I2C4_SDA,<br>SDMMC1_CD1R,<br>UART4_TX,<br>FDCAN1_TX,<br>SDMMC2_D5,<br>I2C4_SMBA,<br>SDMMC1_D5, DCMI_D7,<br>LCD_B7, EVENTOUT | -                       |
| 97            | D4       | 141     | D5       | A4          | 169     | 200     | C4           | PE0                                      | I/O      | FT_h          | -     | LPTIM1_ETR,<br>TIM4_ETR,<br>HRTIM_SCIN,<br>LPTIM2_ETR,<br>UART8_RX,<br>SAI2_MCLK_A,<br>FMC_NBL0, DCMI_D2,<br>EVENTOUT   | -                       |
| 98            | C4       | 142     | D4       | A3          | 170     | 201     | B4           | PE1                                      | I/O      | FT_h          | -     | LPTIM1_IN2,<br>HRTIM_SCOUT,<br>UART8_TX, FMC_NBL1,<br>DCMI_D3, EVENTOUT   | -                       |
| -             | -        | -       | -        | -           | -       | -       | A7           | VCAP                                     | S        | -             | -     | -   | -                       |
| 99            | -        | -       | -        | D5          | -       | 202     | -            | VSS                                      | S        | -             | -     | -   | -                       |
| -             | F7       | 143     | C4       | C6          | 171     | 203     | E7           | PDR_ON                                   | I        | FT            | -     | -   | -                       |
| -             | F4       | -       | B4       | -           | -       | -       | A6           | VDDLDO <sup>(6)</sup>                    | S        | -             | -     | -   | -                       |
| 100           | -        | 144     | -        | C5          | 172     | 204     | -            | VDD                                      | S        | -             | -     | -   | -                       |
| -             | -        | -       | -        | D4          | 173     | 205     | A4           | PI4                                      | I/O      | FT_h          | -     | TIM8_BKIN,<br>SAI2_MCLK_A,<br>TIM8_BKIN_COMP12,<br>FMC_NBL2, DCMI_D5,<br>LCD_B4, EVENTOUT   | -                       |
| -             | -        | -       | -        | C4          | 174     | 206     | A3           | PI5                                      | I/O      | FT_h          | -     | TIM8_CH1,<br>SAI2_SCK_A,<br>FMC_NBL3,<br>DCMI_VSYNC, LCD_B5,<br>EVENTOUT  | -                       |
| -             | -        | -       | A4       | C3          | 175     | 207     | A2           | PI6                                      | I/O      | FT_h          | -     | TIM8_CH2, SAI2_SD_A,<br>FMC_D28, DCMI_D6,<br>LCD_B6, EVENTOUT   | -                       |

Table 8. Pin/ball definition (continued)

| Pin/ball name |          |         |          |             |         |         |              | Pin name<br>(function<br>after<br>reset) | Pin type | I/O structure | Notes | Alternate functions   | Additional<br>functions |
|---------------|----------|---------|----------|-------------|---------|---------|--------------|--|----------|---------------|-------|---|-------------------------|
| LQFP100       | TFBGA100 | LQFP144 | UFBGA169 | UFBGA176+25 | LQFP176 | LQFP208 | TFBGA240 +25 |  |          |               |       |   |                         |
| -             | -        | -       | E2       | C2          | 176     | 208     | B3           | PI7                                      | I/O      | FT_h          | -     | TIM8_CH3, SAI2_FS_A,<br>FMC_D29, DCMI_D7,<br>LCD_B7, EVENTOUT | -                       |
| -             | -        | -       | -        | H9          | -       | -       | -            | VSS                                      | S        | -             | -     | -   | -                       |
| -             | -        | -       | -        | K9          | -       | -       | -            | VSS                                      | S        | -             | -     | -   | -                       |
| -             | -        | -       | -        | K10         | -       | -       | M15          | VSS                                      | S        | -             | -     | -   | -                       |

1. When this pin/ball was previously configured as an oscillator, the oscillator function is kept during and after a reset. This is valid for all resets except for power-on reset.
2. This ball should remain floating.
3. Pxy\_C and Pxy pins/balls are two separate pads (analog switch open). The analog switch is configured through a SYSCFG register. Refer to the product reference manual for a detailed description of the switch configuration bits.
4. There is a direct path between Pxy\_C and Pxy pins/balls, through an analog switch. Pxy alternate functions are available on Pxy\_C when the analog switch is closed. The analog switch is configured through a SYSCFG register. Refer to the product reference manual for a detailed description of the switch configuration bits.
5. VREF+ pin, and consequently the internal voltage reference, are not available on the TFBGA100 package. On this package, this pin is double-bonded to VDDA which can be connected to an external reference. The internal voltage reference buffer is not available and must be kept disabled
6. When it is not available on a package, the VDDLDO pin is internally tied to VDD.
7. When the pin is used in USB configuration (OTG\_HS\_ID/OTG\_HS\_VBUS), the I/O is supplied by V<sub>DD33USB</sub>, otherwise it is supplied by V<sub>DD</sub>.
8. When it is not available on a package, the VDD50USB pin is internally tied to VDD33USB.

**Table 9. Alternate functions**

| Port   | AF0  | AF1                                | AF2                             | AF3   | AF4  | AF5                    | AF6  | AF7  | AF8  | AF9   | AF10   | AF11  | AF12  | AF13                           | AF14            | AF15          |              |
|--------|------|------------------------------------|---------------------------------|---|--|------------------------|--|--|--|---|--|---|---|--------------------------------|-----------------|---------------|--------------|
|        | SYS  | TIM1/2/16/<br>17/LPTIM1/<br>HRTIM1 | SAI1/<br>TIM3/4/5/<br>12/HRTIM1 | LPUART/<br>TIM8/<br>LPTIM2/3/4<br>/5/HRTIM1/<br>DFSDM | I2C1/2/3/4/<br>USART1/<br>TIM15/<br>LPTIM2/<br>DFSDM/<br>CEC | SPI1/2/3/4/<br>5/6/CEC | SPI2/3/<br>SAI1/3/<br>I2C4/<br>UART4/<br>DFSDM | SPI2/3/6/<br>USART1/2/<br>3/6/<br>UART7/<br>SDMMC1 | SPI6/SAI2/<br>4/<br>UART4/5/8<br>/LPUART<br>/SDMMC1/<br>SPDIFRX1 | SAI4/<br>FDCAN1/<br>FDACN2/<br>TIM13/14/<br>QUADSPI/<br>FMC/<br>SDMMC2/<br>LCD/<br>SPDIFRX1 | SAI2/4/<br>TIM8/<br>QUADSPI/<br>SDMMC2/<br>OTG_HS1/<br>OTG_FS2/<br>LCD/CRS | I2C4/<br>UART7/<br>SWPMI1/<br>TIM1/8/<br>DFSDM/<br>SDMMC2/<br>MDIOS/<br>ETH | TIM1/8/<br>FMC/<br>SDMMC1/<br>MDIOS/<br>OTG_FS1/<br>LCD | TIM1/<br>DCMI/<br>LCD/<br>COMP | UART5/<br>LCD   | SYS           |              |
| Port A | PA0  | -                                  | TIM2_CH1/<br>TIM2_ETR           | TIM5_CH1  | TIM8_ETR   | TIM15_<br>BKIN         | -  | -  | USART2_<br>CTS/<br>USART2_<br>NSS                                | UART4_TX  | SDMMC2_<br>CMD   | SAI2_SD_<br>B   | ETH_MII_<br>CRS   | -                              | -               | -             | EVENT<br>OUT |
|        | PA1  | -                                  | TIM2_CH2                        | TIM5_CH2  | LPTIM3_<br>OUT   | TIM15_<br>CH1N         | -  | -  | USART2_<br>RTS<br>/USART2_<br>DE                                 | UART4_RX  | QUADSPI_<br>BK1_IO3  | SAI2_<br>MCLK_B   | ETH_<br>MII_RX_<br>CLK/ETH_<br>RMII_REF_<br>CLK         | -                              | -               | LCD_R2        | EVENT<br>OUT |
|        | PA2  | -                                  | TIM2_CH3                        | TIM5_CH3  | LPTIM4_<br>OUT   | TIM15_<br>CH1          | -  | -  | USART2_<br>TX  | SAI2_SCK_<br>B  | -  | -   | ETH_MDIO  | MDIOS_<br>MDIO                 | -               | LCD_R1        | EVENT<br>OUT |
|        | PA3  | -                                  | TIM2_CH4                        | TIM5_CH4  | LPTIM5_<br>OUT   | TIM15_<br>CH2          | -  | -  | USART2_<br>RX  | -   | LCD_B2   | OTG_HS_<br>ULPI_D0  | ETH_MII_<br>COL   | -                              | -               | LCD_B5        | EVENT<br>OUT |
|        | PA4  | D1PWREN                            | -                               | TIM5_ETR  | -  | -                      | SPI1_NSS/<br>I2S1_WS                           | SPI3_NSS/<br>I2S3_WS                               | USART2_<br>CK  | SPI6_NSS  | -  | -   | -   | OTG_HS_<br>SOF                 | DCMI_<br>HSYNC  | LCD_<br>VSYNC | EVENT<br>OUT |
|        | PA5  | D2PWREN                            | TIM2_CH1/<br>TIM2_ETR           | -   | TIM8_<br>CH1N  | -                      | SPI1_SCK/<br>I2S1_CK                           | -  | -  | SPI6_SCK  | -  | OTG_HS_<br>ULPI_CK  | -   | -                              | -               | LCD_R4        | EVENT<br>OUT |
|        | PA6  | -                                  | TIM1_BKIN                       | TIM3_CH1  | TIM8_BKIN  | -                      | SPI1_<br>MISO/<br>I2S1_SDI                     | -  | -  | SPI6_<br>MISO   | TIM13_<br>CH1  | TIM8_BKIN_<br>_COMP12   | MDIOS_<br>MDC   | TIM1_BKIN_<br>_COMP12          | DCMI_<br>PIXCLK | LCD_G2        | EVENT<br>OUT |
|        | PA7  | -                                  | TIM1_<br>CH1N                   | TIM3_CH2  | TIM8_<br>CH1N  | -                      | SPI1_<br>MOSI/<br>I2S1_SDO                     | -  | -  | SPI6_<br>MOSI   | TIM14_<br>CH1  | -   | ETH_MII_<br>RX_DV/<br>ETH_<br>RMII_CRS_<br>_DV          | FMC_<br>SDNWE                  | -               | -             | EVENT<br>OUT |
|        | PA8  | MCO1                               | TIM1_CH1                        | HRTIM_<br>CHB2  | TIM8_<br>BKIN2   | I2C3_SCL               | -  | -  | USART1_<br>CK  | -   | -  | OTG_FS_<br>SOF  | UART7_RX  | TIM8_<br>BKIN2_<br>COMP12      | LCD_B3          | LCD_R6        | EVENT<br>OUT |
|        | PA9  | -                                  | TIM1_CH2                        | HRTIM_<br>CHC1  | LPUART1_<br>TX   | I2C3_<br>SMBA          | SPI2_SCK/<br>I2S2_CK                           | -  | USART1_<br>TX  | -   | -  | -   | ETH_TX_<br>ER   | -                              | DCMI_D0         | LCD_R5        | EVENT<br>OUT |
|        | PA10 | -                                  | TIM1_CH3                        | HRTIM_<br>CHC2  | LPUART1_<br>RX   | -                      | -  | -  | USART1_<br>RX  | -   | -  | OTG_FS_<br>ID   | MDIOS_<br>MDIO  | LCD_B4                         | DCMI_D1         | LCD_B1        | EVENT<br>OUT |
| PA11   | -    | TIM1_CH4                           | HRTIM_<br>CHD1                  | LPUART1_<br>CTS                                       | -  | SPI2_NSS/<br>I2S2_WS   | UART4_RX                                       | USART1_<br>CTS/<br>USART1_<br>NSS                  | -  | FDCAN1_<br>RX   | OTG_FS_<br>DM  | -   | -   | -                              | LCD_R4          | EVENT<br>OUT  |              |



Table 9. Alternate functions

| Port   | AF0  | AF1                                | AF2                             | AF3   | AF4  | AF5                    | AF6  | AF7  | AF8  | AF9  | AF10   | AF11  | AF12  | AF13                           | AF14          | AF15     |              |
|--------|------|------------------------------------|---------------------------------|---|--|------------------------|--|--|--|--|--|---|---|--------------------------------|---------------|----------|--------------|
|        | SYS  | TIM1/2/16/<br>17/LPTIM1/<br>HRTIM1 | SAI1/<br>TIM3/4/5/<br>12/HRTIM1 | LPUART/<br>TIM8/<br>LPTIM2/3/4<br>/5/HRTIM1/<br>DFSDM | I2C1/2/3/4/<br>USART1/<br>TIM15/<br>LPTIM2/<br>DFSDM/<br>CEC | SPI1/2/3/4/<br>5/6/CEC | SPI2/3/<br>SAI1/3/<br>I2C4/<br>UART4/<br>DFSDM | SPI2/3/6/<br>USART1/2/<br>3/6/<br>UART7/<br>SDMMC1 | SPI6/SAI2/<br>4/<br>UART4/5/8<br>/LPUART<br>/SDMMC1/<br>SPDIFRX1 | SAI4/<br>FDCAN1/<br>FDACN2/<br>TIM8/<br>TIM13/14/<br>QUADSPI/<br>FMC/<br>SDMMC2/<br>LCD/<br>SPDIFRX1 | SAI2/4/<br>TIM8/<br>QUADSPI/<br>SDMMC2/<br>OTG_HS1/<br>OTG_FS2/<br>LCD/CRS | I2C4/<br>UART7/<br>SWPMI1/<br>TIM1/8/<br>DFSDM/<br>SDMMC2/<br>MDIOS/<br>ETH | TIM1/8/<br>FMC/<br>SDMMC1/<br>MDIOS/<br>OTG_FS1/<br>LCD | TIM1/<br>DCMI/<br>LCD/<br>COMP | UART5/<br>LCD | SYS      |              |
| Port A | PA12 | -                                  | TIM1_ETR                        | HRTIM_<br>CHD2  | LPUART1_<br>RTS/<br>LPUART1_<br>DE                           | -                      | SPI2_SCK/<br>I2S2_CK                           | UART4_TX   | USART1_<br>RTS/<br>USART1_<br>DE                                 | SAI2_FS_B  | FDCAN1_<br>TX  | OTG_FS_<br>DP   | -   | -                              | -             | LCD_R5   | EVENT<br>OUT |
|        | PA13 | JTMS-<br>SWDIO                     | -                               | -   | -  | -                      | -  | -  | -  | -  | -  | -   | -   | -                              | -             | -        | EVENT<br>OUT |
|        | PA14 | JTCK-<br>SWCLK                     | -                               | -   | -  | -                      | -  | -  | -  | -  | -  | -   | -   | -                              | -             | -        | EVENT<br>OUT |
|        | PA15 | JTDI                               | TIM2_CH1/<br>TIM2_ETR           | HRTIM_<br>FLT1  | -  | CEC                    | SPI1_NSS/<br>I2S1_WS                           | SPI3_NSS/<br>I2S3_WS                               | SPI6_NSS   | UART4_<br>RTS/<br>UART4_<br>DE   | -  | -   | UART7_TX  | -                              | -             | -        | EVENT<br>OUT |
| Port B | PB0  | -                                  | TIM1_<br>CH2N                   | TIM3_CH3  | TIM8_<br>CH2N  | -                      | -  | DFSDM1_<br>CKOUT                                   | -  | UART4_<br>CTS  | LCD_R3   | OTG_HS_<br>ULPI_D1  | ETH_MIL_<br>RXD2  | -                              | -             | LCD_G1   | EVENT<br>OUT |
|        | PB1  | -                                  | TIM1_<br>CH3N                   | TIM3_CH4  | TIM8_<br>CH3N  | -                      | -  | DFSDM1_<br>DATIN1                                  | -  | -  | LCD_R6   | OTG_HS_<br>ULPI_D2  | ETH_MIL_<br>RXD3  | -                              | -             | LCD_G0   | EVENT<br>OUT |
|        | PB2  | RTC_OUT                            | -                               | SAI1_D1   | -  | DFSDM1_<br>CKIN1       | -  | SAI1_SD_<br>A                                      | SPI3_<br>MOSI/<br>I2S3_SDO                                       | SAI4_SD_<br>A  | QUADSPI_<br>CLK  | SAI4_D1   | ETH_TX_<br>ER   | -                              | -             | -        | EVENT<br>OUT |
|        | PB3  | JTDO/<br>TRACE<br>SWO              | TIM2_CH2                        | HRTIM_<br>FLT4  | -  | -                      | SPI1_SCK/<br>I2S1_CK                           | SPI3_SCK/<br>I2S3_CK                               | -  | SPI6_SCK   | SDMMC2_<br>D2  | CRS_<br>SYNC  | UART7_RX  | -                              | -             | -        | EVENT<br>OUT |
|        | PB4  | NJTRST                             | TIM16_<br>BKIN                  | TIM3_CH1  | HRTIM_<br>EEV6   | -                      | SPI1_<br>MISO/<br>I2S1_SDI                     | SPI3_<br>MISO/<br>I2S3_SDI                         | SPI2_NSS/<br>I2S2_WS   | SPI6_<br>MISO  | SDMMC2_<br>D3  | -   | UART7_TX  | -                              | -             | -        | EVENT<br>OUT |
|        | PB5  | -                                  | TIM17_<br>BKIN                  | TIM3_CH2  | HRTIM_<br>EEV7   | I2C1_<br>SMBA          | SPI1_<br>MOSI/<br>I2S1_SDO                     | I2C4_<br>SMBA                                      | SPI3_<br>MOSI/<br>I2S3_SDO                                       | SPI6_<br>MOSI  | FDCAN2_<br>RX  | OTG_HS_<br>ULPI_D7  | ETH_PPS_<br>OUT   | FMC_<br>SDCKE1                 | DCMI_D10      | UART5_RX | EVENT<br>OUT |
|        | PB6  | -                                  | TIM16_<br>CH1N                  | TIM4_CH1  | HRTIM_<br>EEV8   | I2C1_SCL               | CEC  | I2C4_SCL   | USART1_<br>TX  | LPUART1_<br>TX   | FDCAN2_<br>TX  | QUADSPI_<br>BK1_NCS   | DFSDM1_<br>DATIN5                                       | FMC_<br>SDNE1                  | DCMI_D5       | UART5_TX | EVENT<br>OUT |
|        | PB7  | -                                  | TIM17_<br>CH1N                  | TIM4_CH2  | HRTIM_<br>EEV9   | I2C1_SDA               | -  | I2C4_SDA   | USART1_<br>RX  | LPUART1_<br>RX   | -  | -   | DFSDM1_<br>CKIN5  | FMC_NL                         | DCMI_VSYNC    | -        | EVENT<br>OUT |
|        | PB8  | -                                  | TIM16_<br>CH1                   | TIM4_CH3  | DFSDM1_<br>CKIN7   | I2C1_SCL               | -  | I2C4_SCL   | SDMMC1_<br>CKIN  | UART4_RX   | FDCAN1_<br>RX  | SDMMC2_<br>D4   | ETH_<br>MIL_TXD3  | SDMMC1_<br>D4                  | DCMI_D6       | LCD_B6   | EVENT<br>OUT |
|        | PB9  | -                                  | TIM17_<br>CH1                   | TIM4_CH4  | DFSDM1_<br>DATIN7  | I2C1_SDA               | SPI2_NSS/<br>I2S2_WS                           | I2C4_SDA   | SDMMC1_<br>CDIR  | UART4_TX   | FDCAN1_<br>TX  | SDMMC2_<br>D5   | I2C4_<br>SMBA   | SDMMC1_<br>D5                  | DCMI_D7       | LCD_B7   | EVENT<br>OUT |



Table 9. Alternate functions

| Port   | AF0  | AF1                                | AF2                             | AF3  | AF4  | AF5                    | AF6  | AF7  | AF8  | AF9  | AF10   | AF11  | AF12  | AF13                           | AF14             | AF15     |           |
|--------|------|------------------------------------|---------------------------------|--|--|------------------------|--|--|--|--|--|---|---|--------------------------------|------------------|----------|-----------|
|        | SYS  | TIM1/2/16/<br>17/LPTIM1/<br>HRTIM1 | SAI1/<br>TIM3/4/5/<br>12/HRTIM1 | LPUART/<br>TIM8/<br>LPTIM2/3/4<br>5/HRTIM1/<br>DFSDM | I2C1/2/3/4/<br>USART1/<br>TIM15/<br>LPTIM2/<br>DFSDM/<br>CEC | SPI1/2/3/4/<br>5/6/CEC | SPI2/3/<br>SAI1/3/<br>I2C4/<br>UART4/<br>DFSDM | SPI2/3/6/<br>USART1/2/<br>3/6/<br>UART7/<br>SDMMC1 | SPI6/SAI2/<br>4/<br>UART4/5/8<br>/LPUART<br>/SDMMC1/<br>SPDIFRX1 | SAI4/<br>FDCAN1/<br>FDACN2/<br>TIM8/<br>TIM13/14/<br>QUADSPI/<br>FMC/<br>SDMMC2/<br>LCD/<br>SPDIFRX1 | SAI2/4/<br>TIM8/<br>QUADSPI/<br>SDMMC2/<br>OTG_HS1/<br>OTG_FS2/<br>LCD/CRS | I2C4/<br>UART7/<br>SWPMI1/<br>TIM1/8/<br>DFSDM/<br>SDMMC2/<br>MDIOS/<br>ETH | TIM1/8/<br>FMC/<br>SDMMC1/<br>MDIOS/<br>OTG_FS1/<br>LCD | TIM1/<br>DCMI/<br>LCD/<br>COMP | UART5/<br>LCD    | SYS      |           |
| Port B | PB10 | -                                  | TIM2_CH3                        | HRTIM_SCOUT  | LPTIM2_IN1   | I2C2_SCL               | SPI2_SCK/<br>I2S2_CK                           | DFSDM1_DATIN7                                      | USART3_TX  | -  | QUADSPI_BK1_NCS  | OTG_HS_ULPI_D3  | ETH_MII_RX_ER   | -                              | -                | LCD_G4   | EVENT OUT |
|        | PB11 | -                                  | TIM2_CH4                        | HRTIM_SCIN   | LPTIM2_ETR   | I2C2_SDA               | -  | DFSDM1_CKIN7                                       | USART3_RX  | -  | -  | OTG_HS_ULPI_D4  | ETH_MII_TX_EN/<br>ETH_RMII_TX_EN                        | -                              | -                | LCD_G5   | EVENT OUT |
|        | PB12 | -                                  | TIM1_BKIN                       | -  | -  | I2C2_SMBA              | SPI2_NSS/<br>I2S2_WS                           | DFSDM1_DATIN1                                      | USART3_CK  | -  | FDCAN2_RX  | OTG_HS_ULPI_D5  | ETH_MII_TXD0/<br>ETH_RMII_TXD0                          | OTG_HS_ID                      | TIM1_BKIN_COMP12 | UART5_RX | EVENT OUT |
|        | PB13 | -                                  | TIM1_CH1N                       | -  | LPTIM2_OUT   | -                      | SPI2_SCK/<br>I2S2_CK                           | DFSDM1_CKIN1                                       | USART3_CTS/<br>USART3_NSS  | -  | FDCAN2_TX  | OTG_HS_ULPI_D6  | ETH_MII_TXD1/<br>ETH_RMII_TXD1                          | -                              | -                | UART5_TX | EVENT OUT |
|        | PB14 | -                                  | TIM1_CH2N                       | TIM12_CH1  | TIM8_CH2N  | USART1_TX              | SPI2_MOSI/<br>I2S2_SDI                         | DFSDM1_DATIN2                                      | USART3_RTS/<br>USART3_DE   | UART4_RTS/<br>UART4_DE   | SDMMC2_D0  | -   | -   | OTG_HS_DM                      | -                | -        | EVENT OUT |
|        | PB15 | RTC_REFIN                          | TIM1_CH3N                       | TIM12_CH2  | TIM8_CH3N  | USART1_RX              | SPI2_MOSI/<br>I2S2_SDO                         | DFSDM1_CKIN2                                       | -  | UART4_CTS  | SDMMC2_D1  | -   | -   | OTG_HS_DP                      | -                | -        | EVENT OUT |
| Port C | PC0  | -                                  | -                               | -  | DFSDM1_CKIN0   | -                      | -  | DFSDM1_DATIN4                                      | -  | SAI2_FS_B  | -  | OTG_HS_ULPI_STP   | -   | FMC_SDNWE                      | -                | LCD_R5   | EVENT OUT |
|        | PC1  | TRACED0                            | -                               | SAI1_D1  | DFSDM1_DATIN0  | DFSDM1_CKIN4           | SPI2_MOSI/<br>I2S2_SDO                         | SAI1_SD_A  | -  | SAI4_SD_A  | SDMMC2_CK  | SAI4_D1   | ETH_MDC   | MDIOS_MDC                      | -                | -        | EVENT OUT |
|        | PC2  | C1DSLEEP                           | -                               | -  | DFSDM1_CKIN1   | -                      | SPI2_MISO/<br>I2S2_SDI                         | DFSDM1_CKOUT                                       | -  | -  | -  | OTG_HS_ULPI_DIR   | ETH_MII_TXD2  | FMC_SDNE0                      | -                | -        | EVENT OUT |
|        | PC3  | C1SLEEP                            | -                               | -  | DFSDM1_DATIN1  | -                      | SPI2_MOSI/<br>I2S2_SDO                         | -  | -  | -  | -  | OTG_HS_ULPI_NXT   | ETH_MII_TX_CLK  | FMC_SDCKE0                     | -                | -        | EVENT OUT |
|        | PC4  | C2DSLEEP                           | -                               | -  | DFSDM1_CKIN2   | -                      | I2S1_MCK                                       | -  | -  | -  | -  | SPDIFRX1_IN3  | ETH_MII_RXD0/<br>ETH_RMII_RXD0                          | FMC_SDNE0                      | -                | -        | EVENT OUT |
|        | PC5  | C2SLEEP                            | -                               | SAI1_D3  | DFSDM1_DATIN2  | -                      | -  | -  | -  | -  | -  | SPDIFRX1_IN4  | ETH_MII_RXD1/<br>ETH_RMII_RXD1                          | FMC_SDCKE0                     | COMP1_OUT        | -        | EVENT OUT |



Table 9. Alternate functions

| Port   | AF0  | AF1                                | AF2                             | AF3   | AF4  | AF5                    | AF6  | AF7  | AF8  | AF9   | AF10   | AF11  | AF12  | AF13                           | AF14          | AF15      |           |
|--------|------|------------------------------------|---------------------------------|---|--|------------------------|--|--|--|---|--|---|---|--------------------------------|---------------|-----------|-----------|
|        | SYS  | TIM1/2/16/<br>17/LPTIM1/<br>HRTIM1 | SAI1/<br>TIM3/4/5/<br>12/HRTIM1 | LPUART/<br>TIM8/<br>LPTIM2/3/4<br>/5/HRTIM1/<br>DFSDM | I2C1/2/3/4/<br>USART1/<br>TIM15/<br>LPTIM2/<br>DFSDM/<br>CEC | SPI1/2/3/4/<br>5/6/CEC | SPI2/3/<br>SAI1/3/<br>I2C4/<br>UART4/<br>DFSDM | SPI2/3/6/<br>USART1/2/<br>3/6/<br>UART7/<br>SDMMC1 | SPI6/SAI2/<br>4/<br>UART4/5/8<br>/LPUART<br>/SDMMC1/<br>SPDIFRX1 | SAI4/<br>FDCAN1/<br>FDACN2/<br>TIM13/14/<br>QUADSPI/<br>FMC/<br>SDMMC2/<br>LCD/<br>SPDIFRX1 | SAI2/4/<br>TIM8/<br>QUADSPI/<br>SDMMC2/<br>OTG_HS1/<br>OTG_FS2/<br>LCD/CRS | I2C4/<br>UART7/<br>SWPMI1/<br>TIM1/8/<br>DFSDM/<br>SDMMC2/<br>MDIOS/<br>ETH | TIM1/8/<br>FMC/<br>SDMMC1/<br>MDIOS/<br>OTG_FS1/<br>LCD | TIM1/<br>DCMI/<br>LCD/<br>COMP | UART5/<br>LCD | SYS       |           |
| Port C | PC6  | -                                  | HRTIM_CHA1                      | TIM3_CH1  | TIM8_CH1   | DFSDM1_CKIN3           | I2S2_MCK                                       | -  | USART6_TX  | SDMMC1_D0DIR  | FMC_NWAIT  | SDMMC2_D6   | -   | SDMMC1_D6                      | DCMI_D0       | LCD_HSYNC | EVENT OUT |
|        | PC7  | TRGIO                              | HRTIM_CHA2                      | TIM3_CH2  | TIM8_CH2   | DFSDM1_DATIN3          | -  | I2S3_MCK   | USART6_RX  | SDMMC1_D123DIR  | FMC_NE1  | SDMMC2_D7   | SWPMI_TX  | SDMMC1_D7                      | DCMI_D1       | LCD_G6    | EVENT OUT |
|        | PC8  | TRACED1                            | HRTIM_CHB1                      | TIM3_CH3  | TIM8_CH3   | -                      | -  | -  | USART6_CK  | UART5_RTS/<br>UART5_DE  | FMC_NE2/<br>FMC_NCE  | -   | SWPMI_RX  | SDMMC1_D0                      | DCMI_D2       | -         | EVENT OUT |
|        | PC9  | MCO2                               | -                               | TIM3_CH4  | TIM8_CH4   | I2C3_SDA               | I2S_CKIN                                       | -  | -  | UART5_CTS   | QUADSPI_BK1_IO0  | LCD_G3  | SWPMI_SUSPEND   | SDMMC1_D1                      | DCMI_D3       | LCD_B2    | EVENT OUT |
|        | PC10 | -                                  | -                               | HRTIM_EEV1  | DFSDM1_CKIN5   | -                      | -  | SPI3_SCK/<br>I2S3_CK                               | USART3_TX  | UART4_TX  | QUADSPI_BK1_IO1  | -   | -   | SDMMC1_D2                      | DCMI_D8       | LCD_R2    | EVENT OUT |
|        | PC11 | -                                  | -                               | HRTIM_FLT2  | DFSDM1_DATIN5  | -                      | -  | SPI3_MISO/<br>I2S3_SDI                             | USART3_RX  | UART4_RX  | QUADSPI_BK2_NCS  | -   | -   | SDMMC1_D3                      | DCMI_D4       | -         | EVENT OUT |
|        | PC12 | TRACED3                            | -                               | HRTIM_EEV2  | -  | -                      | -  | SPI3_MOSI/<br>I2S3_SDO                             | USART3_CK  | UART5_TX  | -  | -   | -   | SDMMC1_CK                      | DCMI_D9       | -         | EVENT OUT |
|        | PC13 | -                                  | -                               | -   | -  | -                      | -  | -  | -  | -   | -  | -   | -   | -                              | -             | -         | EVENT OUT |
|        | PC14 | -                                  | -                               | -   | -  | -                      | -  | -  | -  | -   | -  | -   | -   | -                              | -             | -         | EVENT OUT |
|        | PC15 | -                                  | -                               | -   | -  | -                      | -  | -  | -  | -   | -  | -   | -   | -                              | -             | -         | EVENT OUT |
| Port D | PD0  | -                                  | -                               | -   | DFSDM1_CKIN6   | -                      | -  | SAI3_SCK_A   | -  | UART4_RX  | FDCAN1_RX  | -   | -   | FMC_D2/<br>FMC_DA2             | -             | -         | EVENT OUT |
|        | PD1  | -                                  | -                               | -   | DFSDM1_DATIN6  | -                      | -  | SAI3_SD_A  | -  | UART4_TX  | FDCAN1_TX  | -   | -   | FMC_D3/<br>FMC_DA3             | -             | -         | EVENT OUT |
|        | PD2  | TRACED2                            | -                               | TIM3_ETR  | -  | -                      | -  | -  | -  | UART5_RX  | -  | -   | -   | SDMMC1_CMD                     | DCMI_D11      | -         | EVENT OUT |
|        | PD3  | -                                  | -                               | -   | DFSDM1_CKOUT   | -                      | SPI2_SCK/<br>I2S2_CK                           | -  | USART2_CTS/<br>USART2_NSS  | -   | -  | -   | -   | FMC_CLK                        | DCMI_D5       | LCD_G7    | EVENT OUT |
|        | PD4  | -                                  | -                               | HRTIM_FLT3  | -  | -                      | -  | SAI3_FS_A  | USART2_RTS/<br>USART2_DE   | -   | -  | -   | -   | FMC_NOE                        | -             | -         | EVENT OUT |



Table 9. Alternate functions

| Port   | AF0  | AF1                                | AF2                             | AF3   | AF4  | AF5                    | AF6  | AF7  | AF8  | AF9  | AF10   | AF11  | AF12  | AF13                           | AF14          | AF15         |              |
|--------|------|------------------------------------|---------------------------------|---|--|------------------------|--|--|--|--|--|---|---|--------------------------------|---------------|--------------|--------------|
|        | SYS  | TIM1/2/16/<br>17/LPTIM1/<br>HRTIM1 | SAI1/<br>TIM3/4/5/<br>12/HRTIM1 | LPUART/<br>TIM8/<br>LPTIM2/3/4<br>/5/HRTIM1/<br>DFSDM | I2C1/2/3/4/<br>USART1/<br>TIM15/<br>LPTIM2/<br>DFSDM/<br>CEC | SPI1/2/3/4/<br>5/6/CEC | SPI2/3/<br>SAI1/3/<br>I2C4/<br>UART4/<br>DFSDM | SPI2/3/6/<br>USART1/2/<br>3/6/<br>UART7/<br>SDMMC1 | SPI6/SAI2/<br>4/<br>UART4/5/8<br>/LPUART<br>/SDMMC1/<br>SPDIFRX1 | SAI4/<br>FDCAN1/<br>FDACN2/<br>TIM8/<br>TIM13/14/<br>QUADSPI/<br>FMC/<br>SDMMC2/<br>LCD/<br>SPDIFRX1 | SAI2/4/<br>TIM8/<br>QUADSPI/<br>SDMMC2/<br>OTG_HS1/<br>OTG_FS2/<br>LCD/CRS | I2C4/<br>UART7/<br>SWPMI1/<br>TIM1/8/<br>DFSDM/<br>SDMMC2/<br>MDIOS/<br>ETH | TIM1/8/<br>FMC/<br>SDMMC1/<br>MDIOS/<br>OTG_FS1/<br>LCD | TIM1/<br>DCMI/<br>LCD/<br>COMP | UART5/<br>LCD | SYS          |              |
| Port D | PD5  | -                                  | -                               | HRTIM_EE<br>V3  | -  | -                      | -  | USART2_<br>TX                                      | -  | -  | -  | -   | FMC_NWE   | -                              | -             | EVENT<br>OUT |              |
|        | PD6  | -                                  | -                               | SAI1_D1   | DFSDM1_<br>CKIN4   | DFSDM1_<br>DATIN1      | SPI3_MOS<br>I/2S3_<br>SDO                      | SAI1_SD_<br>A                                      | USART2_<br>RX  | SAI4_SD_<br>A  | -  | SAI4_D1   | SDMMC2_<br>CK   | FMC_<br>NWAIT                  | DCMI_D10      | LCD_B2       | EVENT<br>OUT |
|        | PD7  | -                                  | -                               | -   | DFSDM1_<br>DATIN4  | -                      | SPI1_MOS<br>I/2S1_<br>SDO                      | DFSDM1_<br>CKIN1                                   | USART2_<br>CK  | -  | SPDIFRX1<br>_IN1   | -   | SDMMC2_<br>CMD  | FMC_NE1                        | -             | -            | EVENT<br>OUT |
|        | PD8  | -                                  | -                               | -   | DFSDM1_<br>CKIN3   | -                      | -  | SAI3_SCK<br>_B                                     | USART3_<br>TX  | -  | SPDIFRX1<br>_IN2   | -   | -   | FMC_D13/<br>FMC_DA13           | -             | -            | EVENT<br>OUT |
|        | PD9  | -                                  | -                               | -   | DFSDM1_<br>DATIN3  | -                      | -  | SAI3_SD_<br>B                                      | USART3_<br>RX  | -  | -  | -   | -   | FMC_D14/<br>FMC_DA14           | -             | -            | EVENT<br>OUT |
|        | PD10 | -                                  | -                               | -   | DFSDM1_<br>CKOUT   | -                      | -  | SAI3_FS_B  | USART3_<br>CK  | -  | -  | -   | -   | FMC_D15/<br>FMC_DA15           | -             | LCD_B3       | EVENT<br>OUT |
|        | PD11 | -                                  | -                               | -   | LPTIM2_<br>IN2   | I2C4_<br>SMBA          | -  | -  | USART3_<br>CTS/<br>USART3_<br>NSS                                | -  | QUADSPI_<br>BK1_IO0  | SAI2_SD_<br>A   | -   | FMC_A16                        | -             | -            | EVENT<br>OUT |
|        | PD12 | -                                  | LPTIM1_<br>IN1                  | TIM4_CH1  | LPTIM2_<br>IN1   | I2C4_SCL               | -  | -  | USART3_<br>RTS/<br>USART3_<br>DE                                 | -  | QUADSPI_<br>BK1_IO1  | SAI2_FS_A   | -   | FMC_A17                        | -             | -            | EVENT<br>OUT |
|        | PD13 | -                                  | LPTIM1_<br>OUT                  | TIM4_CH2  | -  | I2C4_SDA               | -  | -  | -  | -  | QUADSPI_<br>BK1_IO3  | SAI2_SCK<br>_A  | -   | FMC_A18                        | -             | -            | EVENT<br>OUT |
|        | PD14 | -                                  | -                               | TIM4_CH3  | -  | -                      | -  | SAI3_<br>MCLK_B                                    | -  | UART8_<br>CTS  | -  | -   | -   | FMC_D0/<br>FMC_DA0             | -             | -            | EVENT<br>OUT |
|        | PD15 | -                                  | -                               | TIM4_CH4  | -  | -                      | -  | SAI3_<br>MCLK_A                                    | -  | UART8_<br>RTS/<br>UART8_DE   | -  | -   | -   | FMC_D1/<br>FMC_DA1             | -             | -            | EVENT<br>OUT |

DS12117 Rev 10

93/357

STM32H753xI

Pinout, pin description and alternate functions



Table 9. Alternate functions

| Port   | AF0  | AF1                                | AF2                             | AF3   | AF4  | AF5                    | AF6  | AF7  | AF8  | AF9  | AF10   | AF11  | AF12  | AF13                                   | AF14          | AF15      |           |
|--------|------|------------------------------------|---------------------------------|---|--|------------------------|--|--|--|--|--|---|---|--|---------------|-----------|-----------|
|        | SYS  | TIM1/2/16/<br>17/LPTIM1/<br>HRTIM1 | SAI1/<br>TIM3/4/5/<br>12/HRTIM1 | LPUART/<br>TIM8/<br>LPTIM2/3/4<br>/5/HRTIM1/<br>DFSDM | I2C1/2/3/4/<br>USART1/<br>TIM15/<br>LPTIM2/<br>DFSDM/<br>CEC | SPI1/2/3/4/<br>5/6/CEC | SPI2/3/<br>SAI1/3/<br>I2C4/<br>UART4/<br>DFSDM | SPI2/3/6/<br>USART1/2/<br>3/6/<br>UART7/<br>SDMMC1 | SPI6/SAI2/<br>4/<br>UART4/5/8<br>/LPUART<br>/SDMMC1/<br>SPDIFRX1 | SAI4/<br>FDCAN1/<br>FDACN2/<br>TIM8/<br>TIM13/14/<br>QUADSPI/<br>FMC/<br>SDMMC2/<br>LCD/<br>SPDIFRX1 | SAI2/4/<br>TIM8/<br>QUADSPI/<br>SDMMC2/<br>OTG_HS1/<br>OTG_FS2/<br>LCD/CRS | I2C4/<br>UART7/<br>SWPMI1/<br>TIM1/8/<br>DFSDM/<br>SDMMC2/<br>MDIOS/<br>ETH | TIM1/8/<br>FMC/<br>SDMMC1/<br>MDIOS/<br>OTG_FS1/<br>LCD | TIM1/<br>DCMI/<br>LCD/<br>COMP         | UART5/<br>LCD | SYS       |           |
| Port E | PE0  | -                                  | LPTIM1_ETR                      | TIM4_ETR  | HRTIM_SCIN   | LPTIM2_ETR             | -  | -  | -  | UART8_RX   | -  | SAI2_MCLK_A   | -   | FMC_NBL0                               | DCMI_D2       | -         | EVENT OUT |
|        | PE1  | -                                  | LPTIM1_IN2                      | -   | HRTIM_SCOUT  | -                      | -  | -  | -  | UART8_TX   | -  | -   | -   | FMC_NBL1                               | DCMI_D3       | -         | EVENT OUT |
|        | PE2  | TRACE CLK                          | -                               | SAI1_CK1  | -  | -                      | SPI4_SCK                                       | SAI1_MCLK_A  | -  | SAI4_MCLK_A  | QUADSPI_BK1_IO2  | SAI4_CK1  | ETH_MII_TXD3  | FMC_A23                                | -             | -         | EVENT OUT |
|        | PE3  | TRACED0                            | -                               | -   | -  | TIM15_BKIN             | SAI1_SD_B                                      | -  | SAI4_SD_B  | -  | -  | -   | -   | FMC_A19                                | -             | -         | EVENT OUT |
|        | PE4  | TRACED1                            | -                               | SAI1_D2   | DFSDM1_DATIN3  | TIM15_CH1N             | SPI4_NSS                                       | SAI1_FS_A  | -  | SAI4_FS_A  | -  | SAI4_D2   | -   | FMC_A20                                | DCMI_D4       | LCD_B0    | EVENT OUT |
|        | PE5  | TRACED2                            | -                               | SAI1_CK2  | DFSDM1_CKIN3   | TIM15_CH1              | SPI4_MISO                                      | SAI1_SCK_A   | -  | SAI4_SCK_A   | -  | SAI4_CK2  | -   | FMC_A21                                | DCMI_D6       | LCD_G0    | EVENT OUT |
|        | PE6  | TRACED3                            | TIM1_BKIN2                      | SAI1_D1   | -  | TIM15_CH2              | SPI4_MOSI                                      | SAI1_SD_A  | -  | SAI4_SD_A  | SAI4_D1  | SAI2_MCLK_B   | TIM1_BKIN2_COMP12                                       | FMC_A22                                | DCMI_D7       | LCD_G1    | EVENT OUT |
|        | PE7  | -                                  | TIM1_ETR                        | -   | DFSDM1_DATIN2  | -                      | -  | -  | UART7_RX   | -  | -  | QUADSPI_BK2_IO0   | -   | FMC_D4/<br>FMC_DA4                     | -             | -         | EVENT OUT |
|        | PE8  | -                                  | TIM1_CH1N                       | -   | DFSDM1_CKIN2   | -                      | -  | -  | UART7_TX   | -  | -  | QUADSPI_BK2_IO1   | -   | FMC_D5/<br>FMC_DA5                     | COMP2_OUT     | -         | EVENT OUT |
|        | PE9  | -                                  | TIM1_CH1                        | -   | DFSDM1_CKOUT   | -                      | -  | -  | UART7_RTS/<br>UART7_DE   | -  | -  | QUADSPI_BK2_IO2   | -   | FMC_D6/<br>FMC_DA6                     | -             | -         | EVENT OUT |
|        | PE10 | -                                  | TIM1_CH2_N                      | -   | DFSDM1_DATIN4  | -                      | -  | -  | UART7_CTS  | -  | -  | QUADSPI_BK2_IO3   | -   | FMC_D7/<br>FMC_DA7                     | -             | -         | EVENT OUT |
|        | PE11 | -                                  | TIM1_CH2                        | -   | DFSDM1_CKIN4   | -                      | SPI4_NSS                                       | -  | -  | -  | -  | SAI2_SD_B   | -   | FMC_D8/<br>FMC_DA8                     | -             | LCD_G3    | EVENT OUT |
|        | PE12 | -                                  | TIM1_CH3N                       | -   | DFSDM1_DATIN5  | -                      | SPI4_SCK                                       | -  | -  | -  | -  | SAI2_SCK_B  | -   | FMC_D9/<br>FMC_DA9                     | COMP1_OUT     | LCD_B4    | EVENT OUT |
|        | PE13 | -                                  | TIM1_CH3                        | -   | DFSDM1_CKIN5   | -                      | SPI4_MISO                                      | -  | -  | -  | -  | SAI2_FS_B   | -   | FMC_D10/<br>FMC_DA10                   | COMP2_OUT     | LCD_DE    | EVENT OUT |
| PE14   | -    | TIM1_CH4                           | -                               | -   | -  | SPI4_MOSI              | -  | -  | -  | -  | SAI2_MCLK_B  | -   | FMC_D11/<br>FMC_DA11                                    | -                                      | LCD_CLK       | EVENT OUT |           |
| Port E | PE15 | -                                  | TIM1_BKIN                       | -   | -  | -                      | -  | -  | -  | -  | -  | -   | FMC_D12/<br>FMC_DA12                                    | TIM1_BKIN_COMP12/<br>COMP<br>TIM1_BKIN | LCD_R7        | EVENT OUT |           |

**Table 9. Alternate functions**

| Port   | AF0  | AF1                                | AF2                             | AF3   | AF4  | AF5                    | AF6  | AF7  | AF8  | AF9   | AF10   | AF11  | AF12  | AF13                           | AF14          | AF15         |              |
|--------|------|------------------------------------|---------------------------------|---|--|------------------------|--|--|--|---|--|---|---|--------------------------------|---------------|--------------|--------------|
|        | SYS  | TIM1/2/16/<br>17/LPTIM1/<br>HRTIM1 | SAI1/<br>TIM3/4/5/<br>12/HRTIM1 | LPUART/<br>TIM8/<br>LPTIM2/3/4<br>/5/HRTIM1/<br>DFSDM | I2C1/2/3/4/<br>USART1/<br>TIM15/<br>LPTIM2/<br>DFSDM/<br>CEC | SPI1/2/3/4/<br>5/6/CEC | SPI2/3/<br>SAI1/3/<br>I2C4/<br>UART4/<br>DFSDM | SPI2/3/6/<br>USART1/2/<br>3/6/<br>UART7/<br>SDMMC1 | SPI6/SAI2/<br>4/<br>UART4/5/8<br>/LPUART<br>/SDMMC1/<br>SPDIFRX1 | SAI4/<br>FDCAN1/<br>FDACN2/<br>TIM13/14/<br>QUADSPI/<br>FMC/<br>SDMMC2/<br>LCD/<br>SPDIFRX1 | SAI2/4/<br>TIM8/<br>QUADSPI/<br>SDMMC2/<br>OTG_HS1/<br>OTG_FS2/<br>LCD/CRS | I2C4/<br>UART7/<br>SWPMI1/<br>TIM1/8/<br>DFSDM/<br>SDMMC2/<br>MDIOS/<br>ETH | TIM1/8/<br>FMC/<br>SDMMC1/<br>MDIOS/<br>OTG_FS1/<br>LCD | TIM1/<br>DCMI/<br>LCD/<br>COMP | UART5/<br>LCD | SYS          |              |
| Port F | PF0  | -                                  | -                               | -   | -  | I2C2_SDA               | -  | -  | -  | -   | -  | -   | FMC_A0  | -                              | -             | EVENT<br>OUT |              |
|        | PF1  | -                                  | -                               | -   | -  | I2C2_SCL               | -  | -  | -  | -   | -  | -   | FMC_A1  | -                              | -             | EVENT<br>OUT |              |
|        | PF2  | -                                  | -                               | -   | -  | I2C2_SMB               | -  | -  | -  | -   | -  | -   | FMC_A2  | -                              | -             | EVENT<br>OUT |              |
|        | PF3  | -                                  | -                               | -   | -  | -                      | -  | -  | -  | -   | -  | -   | FMC_A3  | -                              | -             | EVENT<br>OUT |              |
|        | PF4  | -                                  | -                               | -   | -  | -                      | -  | -  | -  | -   | -  | -   | FMC_A4  | -                              | -             | EVENT<br>OUT |              |
|        | PF5  | -                                  | -                               | -   | -  | -                      | -  | -  | -  | -   | -  | -   | FMC_A5  | -                              | -             | EVENT<br>OUT |              |
|        | PF6  | -                                  | TIM16_<br>CH1                   | -   | -  | -                      | SPI5_NSS                                       | SAI1_SD_<br>B                                      | UART7_RX   | SAI4_SD_<br>B   | QUADSPI_<br>BK1_IO3  | -   | -   | -                              | -             | -            | EVENT<br>OUT |
|        | PF7  | -                                  | TIM17_<br>CH1                   | -   | -  | -                      | SPI5_SCK                                       | SAI1_<br>MCLK_B                                    | UART7_TX   | SAI4_<br>MCLK_B   | QUADSPI_<br>BK1_IO2  | -   | -   | -                              | -             | -            | EVENT<br>OUT |
|        | PF8  | -                                  | TIM16_<br>CH1N                  | -   | -  | -                      | SPI5_<br>MISO                                  | SAI1_SCK_<br>B                                     | UART7_<br>RTS/<br>UART7_DE                                       | SAI4_SCK_<br>B  | TIM13_<br>CH1  | QUADSPI_<br>BK1_IO0   | -   | -                              | -             | -            | EVENT<br>OUT |
|        | PF9  | -                                  | TIM17_<br>CH1N                  | -   | -  | -                      | SPI5_<br>MOSI                                  | SAI1_FS_B  | UART7_<br>CTS  | SAI4_FS_B   | TIM14_<br>CH1  | QUADSPI_<br>BK1_IO1   | -   | -                              | -             | -            | EVENT<br>OUT |
|        | PF10 | -                                  | TIM16_<br>BKIN                  | SAI1_D3   | -  | -                      | -  | -  | -  | -   | QUADSPI_<br>CLK  | SAI4_D3   | -   | -                              | DCMI_D11      | LCD_DE       | EVENT<br>OUT |
|        | PF11 | -                                  | -                               | -   | -  | -                      | SPI5_<br>MOSI                                  | -  | -  | -   | -  | SAI2_SD_<br>B   | -   | FMC_<br>SDNRAS                 | DCMI_D12      | -            | EVENT<br>OUT |
|        | PF12 | -                                  | -                               | -   | -  | -                      | -  | -  | -  | -   | -  | -   | -   | FMC_A6                         | -             | -            | EVENT<br>OUT |
|        | PF13 | -                                  | -                               | -   | DFSDM1_<br>DATIN6  | I2C4_<br>SMB           | -  | -  | -  | -   | -  | -   | -   | FMC_A7                         | -             | -            | EVENT<br>OUT |
| PF14   | -    | -                                  | -                               | DFSDM1_<br>CKIN6                                      | I2C4_SCL   | -                      | -  | -  | -  | -   | -  | -   | FMC_A8  | -                              | -             | EVENT<br>OUT |              |
| Port F | PF15 | -                                  | -                               | -   | -  | I2C4_SDA               | -  | -  | -  | -   | -  | -   | FMC_A9  | -                              | -             | EVENT<br>OUT |              |



Table 9. Alternate functions

| Port   | AF0  | AF1                                | AF2                             | AF3  | AF4  | AF5                    | AF6  | AF7  | AF8  | AF9  | AF10   | AF11  | AF12  | AF13                           | AF14          | AF15         |              |
|--------|------|------------------------------------|---------------------------------|--|--|------------------------|--|--|--|--|--|---|---|--------------------------------|---------------|--------------|--------------|
|        | SYS  | TIM1/2/16/<br>17/LPTIM1/<br>HRTIM1 | SAI1/<br>TIM3/4/5/<br>12/HRTIM1 | LPUART/<br>TIM8/<br>LPTIM2/3/4<br>5/HRTIM1/<br>DFSDM | I2C1/2/3/4/<br>USART1/<br>TIM15/<br>LPTIM2/<br>DFSDM/<br>CEC | SPI1/2/3/4/<br>5/6/CEC | SPI2/3/<br>SAI1/3/<br>I2C4/<br>UART4/<br>DFSDM | SPI2/3/6/<br>USART1/2/<br>3/6/<br>UART7/<br>SDMMC1 | SPI6/SAI2/<br>4/<br>UART4/5/8<br>/LPUART<br>/SDMMC1/<br>SPDIFRX1 | SAI4/<br>FDCAN1/<br>FDACN2/<br>TIM8/<br>TIM13/14/<br>QUADSPI/<br>FMC/<br>SDMMC2/<br>LCD/<br>SPDIFRX1 | SAI2/4/<br>TIM8/<br>QUADSPI/<br>SDMMC2/<br>OTG_HS1/<br>OTG_FS2/<br>LCD/CRS | I2C4/<br>UART7/<br>SWPMI1/<br>TIM1/8/<br>DFSDM/<br>SDMMC2/<br>MDIOS/<br>ETH | TIM1/8/<br>FMC/<br>SDMMC1/<br>MDIOS/<br>OTG_FS1/<br>LCD | TIM1/<br>DCMI/<br>LCD/<br>COMP | UART5/<br>LCD | SYS          |              |
| Port G | PG0  | -                                  | -                               | -  | -  | -                      | -  | -  | -  | -  | -  | -   | FMC_A10   | -                              | -             | EVENT<br>OUT |              |
|        | PG1  | -                                  | -                               | -  | -  | -                      | -  | -  | -  | -  | -  | -   | FMC_A11   | -                              | -             | EVENT<br>OUT |              |
|        | PG2  | -                                  | -                               | -  | TIM8_BKIN  | -                      | -  | -  | -  | -  | -  | TIM8_BKIN<br>_COMP12  | FMC_A12   | -                              | -             | EVENT<br>OUT |              |
|        | PG3  | -                                  | -                               | -  | TIM8_BKIN2   | -                      | -  | -  | -  | -  | -  | TIM8_BKIN2<br>_COMP12   | FMC_A13   | -                              | -             | EVENT<br>OUT |              |
|        | PG4  | -                                  | TIM1_BKIN2                      | -  | -  | -                      | -  | -  | -  | -  | -  | TIM1_BKIN2<br>_COMP12   | FMC_A14/<br>FMC_BA0                                     | -                              | -             | EVENT<br>OUT |              |
|        | PG5  | -                                  | TIM1_ETR                        | -  | -  | -                      | -  | -  | -  | -  | -  | -   | FMC_A15/<br>FMC_BA1                                     | -                              | -             | EVENT<br>OUT |              |
|        | PG6  | -                                  | TIM17_BKIN                      | HRTIM_CHE1   | -  | -                      | -  | -  | -  | -  | -  | QUADSPI_BK1_NCS   | FMC_NE3   | DCMI_D12                       | LCD_R7        | EVENT<br>OUT |              |
|        | PG7  | -                                  | -                               | HRTIM_CHE2   | -  | -                      | -  | SAI1_MCLK_A  | USART6_CK  | -  | -  | -   | FMC_INT   | DCMI_D13                       | LCD_CLK       | EVENT<br>OUT |              |
|        | PG8  | -                                  | -                               | -  | TIM8_ETR   | -                      | SPI6_NSS                                       | -  | USART6_RTS/<br>USART6_DE   | SPDIFRX1_IN3   | -  | -   | ETH_PPS_OUT   | FMC_SCLK                       | -             | LCD_G7       | EVENT<br>OUT |
|        | PG9  | -                                  | -                               | -  | -  | -                      | SPI1_MISO/<br>I2S1_SDI                         | -  | USART6_RX  | SPDIFRX1_IN4   | QUADSPI_BK2_IO2  | SAI2_FS_B   | -   | FMC_NE2/<br>FMC_NCE            | DCMI_VSYNC    | -            | EVENT<br>OUT |
|        | PG10 | -                                  | -                               | HRTIM_FLT5   | -  | -                      | SPI1_NSS/<br>I2S1_WS                           | -  | -  | -  | LCD_G3   | SAI2_SD_B   | -   | FMC_NE3                        | DCMI_D2       | LCD_B2       | EVENT<br>OUT |
| PG11   | -    | LPTIM1_IN2                         | HRTIM_EEV4                      | -  | -  | SPI1_SCK/<br>I2S1_CK   | -  | -  | SPDIFRX1_IN1   | -  | SDMMC2_D2  | ETH_MII_TX_EN/<br>ETH_RMII_TX_EN  | -   | DCMI_D3                        | LCD_B3        | EVENT<br>OUT |              |



**Table 9. Alternate functions**

| Port   | AF0  | AF1                                | AF2                             | AF3   | AF4  | AF5                    | AF6  | AF7  | AF8  | AF9  | AF10   | AF11  | AF12  | AF13                           | AF14          | AF15   |           |
|--------|------|------------------------------------|---------------------------------|---|--|------------------------|--|--|--|--|--|---|---|--------------------------------|---------------|--------|-----------|
|        | SYS  | TIM1/2/16/<br>17/LPTIM1/<br>HRTIM1 | SAI1/<br>TIM3/4/5/<br>12/HRTIM1 | LPUART/<br>TIM8/<br>LPTIM2/3/4<br>/5/HRTIM1/<br>DFSDM | I2C1/2/3/4/<br>USART1/<br>TIM15/<br>LPTIM2/<br>DFSDM/<br>CEC | SPI1/2/3/4/<br>5/6/CEC | SPI2/3/<br>SAI1/3/<br>I2C4/<br>UART4/<br>DFSDM | SPI2/3/6/<br>USART1/2/<br>3/6/<br>UART7/<br>SDMMC1 | SPI6/SAI2/<br>4/<br>UART4/5/8<br>/LPUART<br>/SDMMC1/<br>SPDIFRX1 | SAI4/<br>FDCAN1/<br>FDACN2/<br>TIM8/<br>TIM13/14/<br>QUADSPI/<br>FMC/<br>SDMMC2/<br>LCD/<br>SPDIFRX1 | SAI2/4/<br>TIM8/<br>QUADSPI/<br>SDMMC2/<br>OTG_HS1/<br>OTG_FS2/<br>LCD/CRS | I2C4/<br>UART7/<br>SWPMI1/<br>TIM1/8/<br>DFSDM/<br>SDMMC2/<br>MDIOS/<br>ETH | TIM1/8/<br>FMC/<br>SDMMC1/<br>MDIOS/<br>OTG_FS1/<br>LCD | TIM1/<br>DCMI/<br>LCD/<br>COMP | UART5/<br>LCD | SYS    |           |
| Port G | PG12 | -                                  | LPTIM1_ IN1                     | HRTIM_ EEV5   | -  | -                      | SPI6_ MISO                                     | -  | USART6_ RTS/<br>USART6_ DE                                       | SPDIFRX1_ IN2  | LCD_B4   | -   | ETH_MII_ TXD1/<br>ETH_RMII_ TXD1                        | FMC_NE4                        | -             | LCD_B1 | EVENT OUT |
|        | PG13 | TRACED0                            | LPTIM1_ OUT                     | HRTIM_ EEV10  | -  | -                      | SPI6_ SCK                                      | -  | USART6_ CTS/<br>USART6_ NSS                                      | -  | -  | -   | ETH_MII_ TXD0/<br>ETH_RMII_ TXD0                        | FMC_A24                        | -             | LCD_R0 | EVENT OUT |
|        | PG14 | TRACED1                            | LPTIM1_ ETR                     | -   | -  | -                      | SPI6_ MOSI                                     | -  | USART6_ TX   | -  | QUADSPI_ BK2_IO3   | -   | ETH_MII_ TXD1/<br>ETH_RMII_ TXD1                        | FMC_A25                        | -             | LCD_B0 | EVENT OUT |
|        | PG15 | -                                  | -                               | -   | -  | -                      | -  | -  | USART6_ CTS/<br>USART6_ NSS                                      | -  | -  | -   | -   | FMC_ SDNCAS                    | DCMI_D13      | -      | EVENT OUT |
| Port H | PH0  | -                                  | -                               | -   | -  | -                      | -  | -  | -  | -  | -  | -   | -   | -                              | -             | -      | EVENT OUT |
|        | PH1  | -                                  | -                               | -   | -  | -                      | -  | -  | -  | -  | -  | -   | -   | -                              | -             | -      | EVENT OUT |
|        | PH2  | -                                  | LPTIM1_ IN2                     | -   | -  | -                      | -  | -  | -  | -  | QUADSPI_ BK2_IO0   | SAI2_ SCK_ B  | ETH_MII_ CRS  | FMC_ SDCKE0                    | -             | LCD_R0 | EVENT OUT |
|        | PH3  | -                                  | -                               | -   | -  | -                      | -  | -  | -  | -  | QUADSPI_ BK2_IO1   | SAI2_ MCLK_ B   | ETH_MII_ COL  | FMC_ SDNE0                     | -             | LCD_R1 | EVENT OUT |
|        | PH4  | -                                  | -                               | -   | -  | I2C2_ SCL              | -  | -  | -  | -  | LCD_G5   | OTG_HS_ ULPI_ NXT   | -   | -                              | -             | LCD_G4 | EVENT OUT |
|        | PH5  | -                                  | -                               | -   | -  | I2C2_ SDA              | SPI5_ NSS                                      | -  | -  | -  | -  | -   | -   | FMC_ SDNWE                     | -             | -      | EVENT OUT |
|        | PH6  | -                                  | -                               | TIM12_ CH1  | -  | I2C2_ SMBA             | SPI5_ SCK                                      | -  | -  | -  | -  | -   | ETH_MII_ RXD2   | FMC_ SDNE1                     | DCMI_D8       | -      | EVENT OUT |
|        | PH7  | -                                  | -                               | -   | -  | I2C3_ SCL              | SPI5_ MISO                                     | -  | -  | -  | -  | -   | ETH_MII_ RXD3   | FMC_ SDC KE1                   | DCMI_D9       | -      | EVENT OUT |
|        | PH8  | -                                  | -                               | TIM5_ ETR   | -  | I2C3_ SDA              | -  | -  | -  | -  | -  | -   | -   | FMC_D16                        | DCMI_ HSYNC   | LCD_R2 | EVENT OUT |
|        | PH9  | -                                  | -                               | TIM12_ CH2  | -  | I2C3_ SMBA             | -  | -  | -  | -  | -  | -   | -   | FMC_D17                        | DCMI_D0       | LCD_R3 | EVENT OUT |



Table 9. Alternate functions

| Port   | AF0  | AF1                                | AF2                             | AF3   | AF4  | AF5                    | AF6  | AF7  | AF8  | AF9  | AF10   | AF11  | AF12  | AF13                           | AF14          | AF15         |
|--------|------|------------------------------------|---------------------------------|---|--|------------------------|--|--|--|--|--|---|---|--------------------------------|---------------|--------------|
|        | SYS  | TIM1/2/16/<br>17/LPTIM1/<br>HRTIM1 | SAI1/<br>TIM3/4/5/<br>12/HRTIM1 | LPUART/<br>TIM8/<br>LPTIM2/3/4<br>/5/HRTIM1/<br>DFSDM | I2C1/2/3/4/<br>USART1/<br>TIM15/<br>LPTIM2/<br>DFSDM/<br>CEC | SPI1/2/3/4/<br>5/6/CEC | SPI2/3/<br>SAI1/3/<br>I2C4/<br>UART4/<br>DFSDM | SPI2/3/6/<br>USART1/2/<br>3/6/<br>UART7/<br>SDMMC1 | SPI6/SAI2/<br>4/<br>UART4/5/8<br>/LPUART<br>/SDMMC1/<br>SPDIFRX1 | SAI4/<br>FDCAN1/<br>FDACN2/<br>TIM8/<br>TIM13/14/<br>QUADSPI/<br>FMC/<br>SDMMC2/<br>LCD/<br>SPDIFRX1 | SAI2/4/<br>TIM8/<br>QUADSPI/<br>SDMMC2/<br>OTG_HS1/<br>OTG_FS2/<br>LCD/CRS | I2C4/<br>UART7/<br>SWPMI1/<br>TIM1/8/<br>DFSDM/<br>SDMMC2/<br>MDIOS/<br>ETH | TIM1/8/<br>FMC/<br>SDMMC1/<br>MDIOS/<br>OTG_FS1/<br>LCD | TIM1/<br>DCMI/<br>LCD/<br>COMP | UART5/<br>LCD | SYS          |
| Port H | PH10 | -                                  | -                               | TIM5_CH1  | -  | I2C4_ SMBA             | -  | -  | -  | -  | -  | -   | FMC_D18   | DCMI_D1                        | LCD_R4        | EVENT<br>OUT |
|        | PH11 | -                                  | -                               | TIM5_CH2  | -  | I2C4_SCL               | -  | -  | -  | -  | -  | -   | FMC_D19   | DCMI_D2                        | LCD_R5        | EVENT<br>OUT |
|        | PH12 | -                                  | -                               | TIM5_CH3  | -  | I2C4_SDA               | -  | -  | -  | -  | -  | -   | FMC_D20   | DCMI_D3                        | LCD_R6        | EVENT<br>OUT |
|        | PH13 | -                                  | -                               | -   | TIM8_ CH1N   | -                      | -  | -  | UART4_TX   | FDCAN1_ TX   | -  | -   | FMC_D21   | -                              | LCD_G2        | EVENT<br>OUT |
|        | PH14 | -                                  | -                               | -   | TIM8_ CH2N   | -                      | -  | -  | UART4_RX   | FDCAN1_ RX   | -  | -   | FMC_D22   | DCMI_D4                        | LCD_G3        | EVENT<br>OUT |
|        | PH15 | -                                  | -                               | -   | TIM8_ CH3N   | -                      | -  | -  | -  | -  | -  | -   | FMC_D23   | DCMI_D11                       | LCD_G4        | EVENT<br>OUT |
| Port I | PI0  | -                                  | -                               | TIM5_CH4  | -  | -                      | SPI2_NSS/<br>I2S2_WS                           | -  | -  | -  | -  | -   | FMC_D24   | DCMI_D13                       | LCD_G5        | EVENT<br>OUT |
|        | PI1  | -                                  | -                               | -   | TIM8_ BKIN2  | -                      | SPI2_SCK/<br>I2S2_CK                           | -  | -  | -  | -  | TIM8_ BKIN2_ COMP12   | FMC_D25   | DCMI_D8                        | LCD_G6        | EVENT<br>OUT |
|        | PI2  | -                                  | -                               | -   | TIM8_CH4   | -                      | SPI2_ MISO/<br>I2S2_SDI                        | -  | -  | -  | -  | -   | FMC_D26   | DCMI_D9                        | LCD_G7        | EVENT<br>OUT |
|        | PI3  | -                                  | -                               | -   | TIM8_ETR   | -                      | SPI2_ MOSI/<br>I2S2_SDO                        | -  | -  | -  | -  | -   | FMC_D27   | DCMI_D10                       | -             | EVENT<br>OUT |
|        | PI4  | -                                  | -                               | -   | TIM8_BKIN  | -                      | -  | -  | -  | -  | SAI2_ MCLK_A   | TIM8_ BKIN_ COMP12  | FMC_NBL2  | DCMI_D5                        | LCD_B4        | EVENT<br>OUT |
|        | PI5  | -                                  | -                               | -   | TIM8_CH1   | -                      | -  | -  | -  | -  | SAI2_SCK_ A  | -   | FMC_NBL3  | DCMI_ VSYNC                    | LCD_B5        | EVENT<br>OUT |
|        | PI6  | -                                  | -                               | -   | TIM8_CH2   | -                      | -  | -  | -  | -  | SAI2_SD_ A   | -   | FMC_D28   | DCMI_D6                        | LCD_B6        | EVENT<br>OUT |
|        | PI7  | -                                  | -                               | -   | TIM8_CH3   | -                      | -  | -  | -  | -  | SAI2_FS_A  | -   | FMC_D29   | DCMI_D7                        | LCD_B7        | EVENT<br>OUT |
|        | PI8  | -                                  | -                               | -   | -  | -                      | -  | -  | -  | -  | -  | -   | -   | -                              | -             | EVENT<br>OUT |



**Table 9. Alternate functions**

| Port   | AF0  | AF1                                | AF2                             | AF3   | AF4  | AF5                    | AF6  | AF7  | AF8  | AF9   | AF10   | AF11  | AF12  | AF13                           | AF14          | AF15      |
|--------|------|------------------------------------|---------------------------------|---|--|------------------------|--|--|--|---|--|---|---|--------------------------------|---------------|-----------|
|        | SYS  | TIM1/2/16/<br>17/LPTIM1/<br>HRTIM1 | SAI1/<br>TIM3/4/5/<br>12/HRTIM1 | LPUART/<br>TIM8/<br>LPTIM2/3/4<br>/5/HRTIM1/<br>DFSDM | I2C1/2/3/4/<br>USART1/<br>TIM15/<br>LPTIM2/<br>DFSDM/<br>CEC | SP11/2/3/4/<br>5/6/CEC | SPI2/3/<br>SAI1/3/<br>I2C4/<br>UART4/<br>DFSDM | SPI2/3/6/<br>USART1/2/<br>3/6/<br>UART7/<br>SDMMC1 | SPI6/SAI2/<br>4/<br>UART4/5/8<br>/LPUART<br>/SDMMC1/<br>SPDIFRX1 | SAI4/<br>FDCAN1/<br>FDACN2/<br>TIM13/14/<br>QUADSPI/<br>FMC/<br>SDMMC2/<br>LCD/<br>SPDIFRX1 | SAI2/4/<br>TIM8/<br>QUADSPI/<br>SDMMC2/<br>OTG_HS1/<br>OTG_FS2/<br>LCD/CRS | I2C4/<br>UART7/<br>SWPMI1/<br>TIM1/8/<br>DFSDM/<br>SDMMC2/<br>MDIOS/<br>ETH | TIM1/8/<br>FMC/<br>SDMMC1/<br>MDIOS/<br>OTG_FS1/<br>LCD | TIM1/<br>DCMI/<br>LCD/<br>COMP | UART5/<br>LCD | SYS       |
| Port I | PI9  | -                                  | -                               | -   | -  | -                      | -  | -  | UART4_RX   | FDCAN1_RX   | -  | -   | FMC_D30   | -                              | LCD_VSYNC     | EVENT OUT |
|        | PI10 | -                                  | -                               | -   | -  | -                      | -  | -  | -  | -   | -  | ETH_MII_RX_ER   | FMC_D31   | -                              | LCD_HSYNC     | EVENT OUT |
|        | PI11 | -                                  | -                               | -   | -  | -                      | -  | -  | -  | LCD_G6  | OTG_HS_ULPI_DIR  | -   | -   | -                              | -             | EVENT OUT |
|        | PI12 | -                                  | -                               | -   | -  | -                      | -  | -  | -  | -   | -  | ETH_TX_ER   | -   | -                              | LCD_HSYNC     | EVENT OUT |
|        | PI13 | -                                  | -                               | -   | -  | -                      | -  | -  | -  | -   | -  | -   | -   | -                              | LCD_VSYNC     | EVENT OUT |
|        | PI14 | -                                  | -                               | -   | -  | -                      | -  | -  | -  | -   | -  | -   | -   | -                              | LCD_CLK       | EVENT OUT |
|        | PI15 | -                                  | -                               | -   | -  | -                      | -  | -  | -  | -   | LCD_G2   | -   | -   | -                              | LCD_R0        | EVENT OUT |
| Port J | PJ0  | -                                  | -                               | -   | -  | -                      | -  | -  | -  | LCD_R7  | -  | -   | -   | -                              | LCD_R1        | EVENT OUT |
|        | PJ1  | -                                  | -                               | -   | -  | -                      | -  | -  | -  | -   | -  | -   | -   | -                              | LCD_R2        | EVENT OUT |
|        | PJ2  | -                                  | -                               | -   | -  | -                      | -  | -  | -  | -   | -  | -   | -   | -                              | LCD_R3        | EVENT OUT |
|        | PJ3  | -                                  | -                               | -   | -  | -                      | -  | -  | -  | -   | -  | -   | -   | -                              | LCD_R4        | EVENT OUT |
|        | PJ4  | -                                  | -                               | -   | -  | -                      | -  | -  | -  | -   | -  | -   | -   | -                              | LCD_R5        | EVENT OUT |
|        | PJ5  | -                                  | -                               | -   | -  | -                      | -  | -  | -  | -   | -  | -   | -   | -                              | LCD_R6        | EVENT OUT |
|        | PJ6  | -                                  | -                               | -   | TIM8_CH2   | -                      | -  | -  | -  | -   | -  | -   | -   | -                              | LCD_R7        | EVENT OUT |
|        | PJ7  | TRGIN                              | -                               | -   | TIM8_CH2N  | -                      | -  | -  | -  | -   | -  | -   | -   | -                              | LCD_G0        | EVENT OUT |
| PJ8    | -    | TIM1_CH3N                          | -                               | TIM8_CH1  | -  | -                      | -  | -  | UART8_TX   | -   | -  | -   | -   | LCD_G1                         | EVENT OUT     |           |



Table 9. Alternate functions

| Port   | AF0  | AF1                                | AF2                             | AF3   | AF4  | AF5                    | AF6  | AF7  | AF8  | AF9  | AF10   | AF11  | AF12  | AF13                           | AF14          | AF15         |
|--------|------|------------------------------------|---------------------------------|---|--|------------------------|--|--|--|--|--|---|---|--------------------------------|---------------|--------------|
|        | SYS  | TIM1/2/16/<br>17/LPTIM1/<br>HRTIM1 | SAI1/<br>TIM3/4/5/<br>12/HRTIM1 | LPUART/<br>TIM8/<br>LPTIM2/3/4<br>/5/HRTIM1/<br>DFSDM | I2C1/2/3/4/<br>USART1/<br>TIM15/<br>LPTIM2/<br>DFSDM/<br>CEC | SPI1/2/3/4/<br>5/6/CEC | SPI2/3/<br>SAI1/3/<br>I2C4/<br>UART4/<br>DFSDM | SPI2/3/6/<br>USART1/2/<br>3/6/<br>UART7/<br>SDMMC1 | SPI6/SAI2/<br>4/<br>UART4/5/8<br>/LPUART<br>/SDMMC1/<br>SPDIFRX1 | SAI4/<br>FDCAN1/<br>FDACN2/<br>TIM8/<br>TIM13/14/<br>QUADSPI/<br>FMC/<br>SDMMC2/<br>LCD/<br>SPDIFRX1 | SAI2/4/<br>TIM8/<br>QUADSPI/<br>SDMMC2/<br>OTG_HS1/<br>OTG_FS2/<br>LCD/CRS | I2C4/<br>UART7/<br>SWPMI1/<br>TIM1/8/<br>DFSDM/<br>SDMMC2/<br>MDIOS/<br>ETH | TIM1/8/<br>FMC/<br>SDMMC1/<br>MDIOS/<br>OTG_FS1/<br>LCD | TIM1/<br>DCMI/<br>LCD/<br>COMP | UART5/<br>LCD | SYS          |
| Port J | PJ9  | -                                  | TIM1_CH3                        | -   | TIM8_CH1N  | -                      | -  | -  | UART8_RX   | -  | -  | -   | -   | -                              | LCD_G2        | EVENT<br>OUT |
|        | PJ10 | -                                  | TIM1_CH2N                       | -   | TIM8_CH2   | -                      | SPI5_MOSI                                      | -  | -  | -  | -  | -   | -   | -                              | LCD_G3        | EVENT<br>OUT |
|        | PJ11 | -                                  | TIM1_CH2                        | -   | TIM8_CH2<br>N  | -                      | SPI5_MISO                                      | -  | -  | -  | -  | -   | -   | -                              | LCD_G4        | EVENT<br>OUT |
|        | PJ12 | TRGOUT                             | -                               | -   | -  | -                      | -  | -  | -  | -  | LCD_G3   | -   | -   | -                              | LCD_B0        | EVENT<br>OUT |
|        | PJ13 | -                                  | -                               | -   | -  | -                      | -  | -  | -  | -  | LCD_B4   | -   | -   | -                              | LCD_B1        | EVENT<br>OUT |
|        | PJ14 | -                                  | -                               | -   | -  | -                      | -  | -  | -  | -  | -  | -   | -   | -                              | LCD_B2        | EVENT<br>OUT |
|        | PJ15 | -                                  | -                               | -   | -  | -                      | -  | -  | -  | -  | -  | -   | -   | -                              | LCD_B3        | EVENT<br>OUT |
| Port K | PK0  | -                                  | TIM1_CH1N                       | -   | TIM8_CH3   | -                      | SPI5_SCK                                       | -  | -  | -  | -  | -   | -   | -                              | LCD_G5        | EVENT<br>OUT |
|        | PK1  | -                                  | TIM1_CH1                        | -   | TIM8_CH3N  | -                      | SPI5_NSS                                       | -  | -  | -  | -  | -   | -   | -                              | LCD_G6        | EVENT<br>OUT |
|        | PK2  | -                                  | TIM1_BKIN                       | -   | TIM8_BKIN  | -                      | -  | -  | -  | -  | TIM8_BKIN<br>_COMP12   | TIM1_BKIN<br>_COMP12  | -   | -                              | LCD_G7        | EVENT<br>OUT |
|        | PK3  | -                                  | -                               | -   | -  | -                      | -  | -  | -  | -  | -  | -   | -   | -                              | LCD_B4        | EVENT<br>OUT |
|        | PK4  | -                                  | -                               | -   | -  | -                      | -  | -  | -  | -  | -  | -   | -   | -                              | LCD_B5        | EVENT<br>OUT |
|        | PK5  | -                                  | -                               | -   | -  | -                      | -  | -  | -  | -  | -  | -   | -   | -                              | LCD_B6        | EVENT<br>OUT |
|        | PK6  | -                                  | -                               | -   | -  | -                      | -  | -  | -  | -  | -  | -   | -   | -                              | LCD_B7        | EVENT<br>OUT |
| PK7    | -    | -                                  | -                               | -   | -  | -                      | -  | -  | -  | -  | -  | -   | -   | LCD_DE                         | EVENT<br>OUT  |              |

## 6 Electrical characteristics (rev Y)

### 6.1 Parameter conditions

Unless otherwise specified, all voltages are referenced to  $V_{SS}$ .

#### 6.1.1 Minimum and maximum values

Unless otherwise specified the minimum and maximum values are guaranteed in the worst conditions of junction temperature, supply voltage and frequencies by tests in production on 100% of the devices with an junction temperature at  $T_J = 25\text{ °C}$  and  $T_J = T_{Jmax}$  (given by the selected temperature range).

Data based on characterization results, design simulation and/or technology characteristics are indicated in the table footnotes. Based on characterization, the minimum and maximum values refer to sample tests and represent the mean value plus or minus three times the standard deviation ( $\text{mean} \pm 3\sigma$ ).

#### 6.1.2 Typical values

Unless otherwise specified, typical data are based on  $T_J = 25\text{ °C}$ ,  $V_{DD} = 3.3\text{ V}$  (for the  $1.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$  voltage range). They are given only as design guidelines and are not tested.

Typical ADC accuracy values are determined by characterization of a batch of samples from a standard diffusion lot over the full temperature range, where 95% of the devices have an error less than or equal to the value indicated ( $\text{mean} \pm 2\sigma$ ).

#### 6.1.3 Typical curves

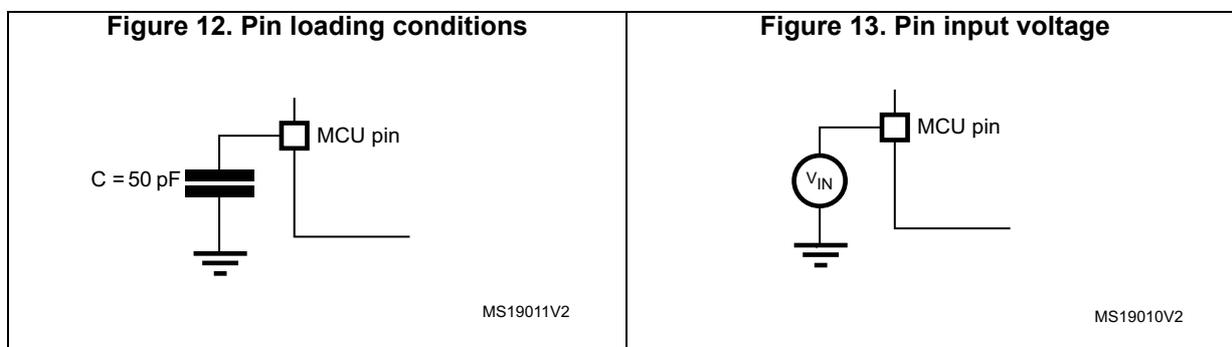
Unless otherwise specified, all typical curves are given only as design guidelines and are not tested.

#### 6.1.4 Loading capacitor

The loading conditions used for pin parameter measurement are shown in [Figure 12](#).

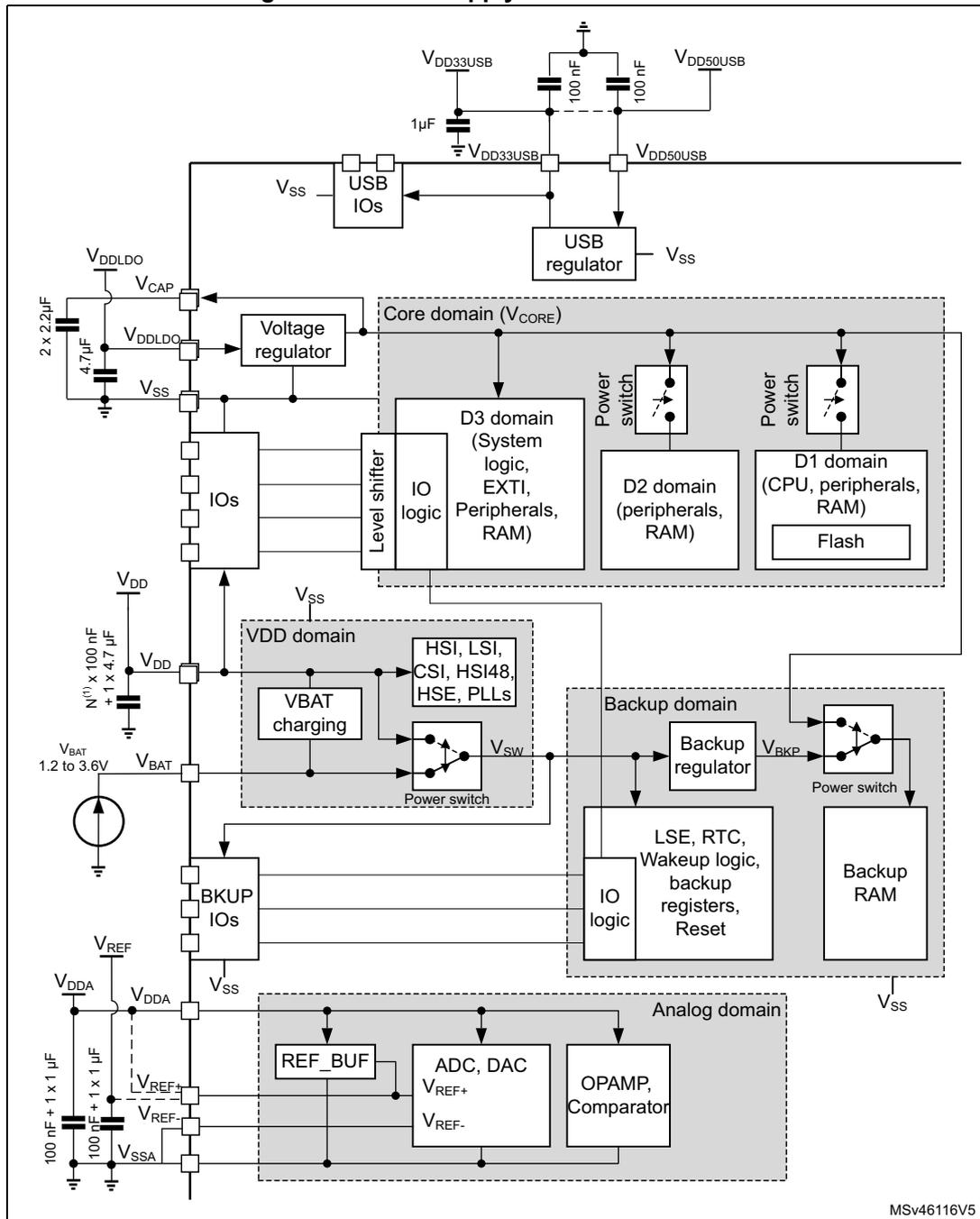
#### 6.1.5 Pin input voltage

The input voltage measurement on a pin of the device is described in [Figure 13](#).



6.1.6 Power supply scheme

Figure 14. Power supply scheme



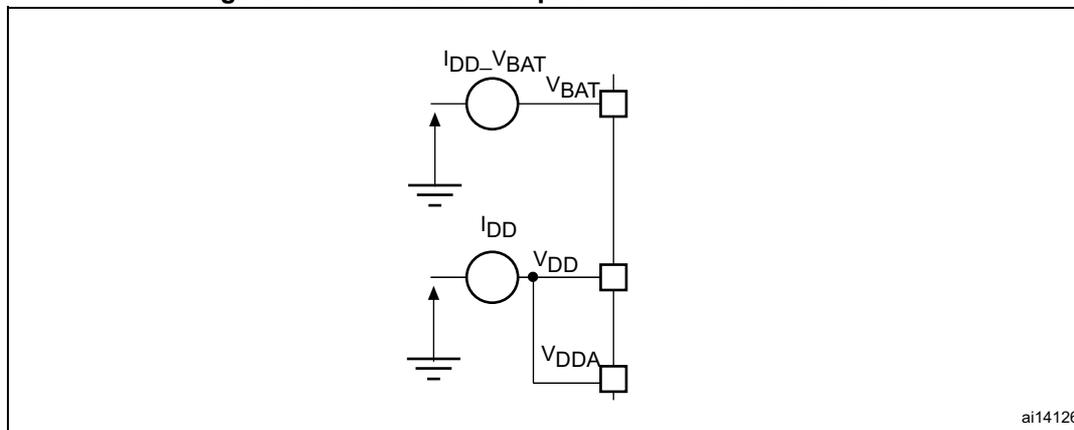
1. N corresponds to the number of VDD pins available on the package.
2. A tolerance of +/- 20% is acceptable on decoupling capacitors.

**Caution:** Each power supply pair (V<sub>DD</sub>/V<sub>SS</sub>, V<sub>DDA</sub>/V<sub>SSA</sub> ...) must be decoupled with filtering ceramic capacitors as shown above. These capacitors must be placed as close as possible to, or below, the appropriate pins on the underside of the PCB to ensure good operation of the

device. It is not recommended to remove filtering capacitors to reduce PCB size or cost. This might cause incorrect operation of the device.

### 6.1.7 Current consumption measurement

Figure 15. Current consumption measurement scheme



## 6.2 Absolute maximum ratings

Stresses above the absolute maximum ratings listed in [Table 10: Voltage characteristics](#), [Table 11: Current characteristics](#), and [Table 12: Thermal characteristics](#) may cause permanent damage to the device. These are stress ratings only and the functional operation of the device at these conditions is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability. Device mission profile (application conditions) is compliant with JEDEC JESD47 Qualification Standard, extended mission profiles are available on demand.

Table 10. Voltage characteristics <sup>(1)</sup>

| Symbols            | Ratings  | Min          | Max  | Unit |
|--------------------|--|--------------|--|------|
| $V_{DDX} - V_{SS}$ | External main supply voltage (including $V_{DD}$ , $V_{DDLDO}$ , $V_{DDA}$ , $V_{DD33USB}$ , $V_{BAT}$ ) | -0.3         | 4.0  | V    |
| $V_{IN}^{(2)}$     | Input voltage on FT_XXX pins   | $V_{SS}-0.3$ | $\text{Min}(\text{Min}(V_{DD}, V_{DDA}, V_{DD33USB}, V_{BAT}) + 4.0, 6 \text{ V})^{(3)(4)(5)}$ | V    |
|                    | Input voltage on TT_XX pins  | $V_{SS}-0.3$ | 4.0  | V    |
|                    | Input voltage on BOOT0 pin   | $V_{SS}$     | 9.0  | V    |
|                    | Input voltage on any other pins  | $V_{SS}-0.3$ | 4.0  | V    |
| $ \Delta V_{DDX} $ | Variations between different $V_{DDX}$ power pins of the same domain                                     | -            | 50   | mV   |
| $ V_{SSx}-V_{SS} $ | Variations between all the different ground pins   | -            | 50   | mV   |

- All main power ( $V_{DD}$ ,  $V_{DDA}$ ,  $V_{DD33USB}$ ,  $V_{BAT}$ ) and ground ( $V_{SS}$ ,  $V_{SSA}$ ) pins must always be connected to the external power supply, in the permitted range.
- $V_{IN}$  maximum must always be respected. Refer to [Table 48](#) for the maximum allowed injected current values.

3. This formula has to be applied on power supplies related to the IO structure described by the pin definition table.
4. To sustain a voltage higher than 4V the internal pull-up/pull-down resistors must be disabled.
5. When an FT\_a pin is used by an analog peripheral such as an ADC, the maximum  $V_{IN}$  is 4 V.

**Table 11. Current characteristics**

| Symbols                          | Ratings   | Max   | Unit |
|----------------------------------|---|-------|------|
| $\Sigma IV_{DD}$                 | Total current into sum of all $V_{DD}$ power lines (source) <sup>(1)</sup>      | 620   | mA   |
| $\Sigma IV_{SS}$                 | Total current out of sum of all $V_{SS}$ ground lines (sink) <sup>(1)</sup>     | 620   |      |
| $IV_{DD}$                        | Maximum current into each $V_{DD}$ power pin (source) <sup>(1)</sup>            | 100   |      |
| $IV_{SS}$                        | Maximum current out of each $V_{SS}$ ground pin (sink) <sup>(1)</sup>           | 100   |      |
| $I_{IO}$                         | Output current sunk by any I/O and control pin, except Px_C                     | 20    |      |
|                                  | Output current sunk by Px_C pins  | 1     |      |
| $\Sigma I_{(PIN)}$               | Total output current sunk by sum of all I/Os and control pins <sup>(2)</sup>    | 140   |      |
|                                  | Total output current sourced by sum of all I/Os and control pins <sup>(2)</sup> | 140   |      |
| $I_{INJ(PIN)}$ <sup>(3)(4)</sup> | Injected current on FT_xxx, TT_xx, RST and B pins except PA4, PA5               | -5/+0 |      |
|                                  | Injected current on PA4, PA5  | -0/0  |      |
| $\Sigma I_{INJ(PIN)}$            | Total injected current (sum of all I/Os and control pins) <sup>(5)</sup>        | ±25   |      |

1. All main power ( $V_{DD}$ ,  $V_{DDA}$ ,  $V_{DD33USB}$ ) and ground ( $V_{SS}$ ,  $V_{SSA}$ ) pins must always be connected to the external power supplies, in the permitted range.
2. This current consumption must be correctly distributed over all I/Os and control pins. The total output current must not be sunk/sourced between two consecutive power supply pins referring to high pin count QFP packages.
3. Positive injection is not possible on these I/Os and does not occur for input voltages lower than the specified maximum value.
4. A positive injection is induced by  $V_{IN} > V_{DD}$  while a negative injection is induced by  $V_{IN} < V_{SS}$ .  $I_{INJ(PIN)}$  must never be exceeded. Refer also to [Table 10: Voltage characteristics](#) for the maximum allowed input voltage values.
5. When several inputs are submitted to a current injection, the maximum  $\Sigma I_{INJ(PIN)}$  is the absolute sum of the positive and negative injected currents (instantaneous values).

**Table 12. Thermal characteristics**

| Symbol    | Ratings                      | Value       | Unit |
|-----------|------------------------------|-------------|------|
| $T_{STG}$ | Storage temperature range    | -65 to +150 | °C   |
| $T_J$     | Maximum junction temperature | 125         |      |

## 6.3 Operating conditions

### 6.3.1 General operating conditions

Table 13. General operating conditions

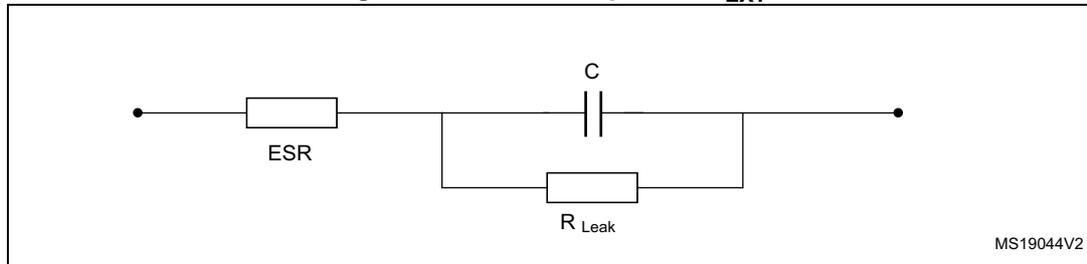
| Symbol        | Parameter                                    | Operating conditions                    | Min                 | Max   | Unit |
|---------------|--|---|---------------------|---|------|
| $V_{DD}$      | Standard operating voltage                   | -                                       | 1.62 <sup>(1)</sup> | 3.6   | V    |
| $V_{DDLDO}$   | Supply voltage for the internal regulator    | $V_{DDLDO} \leq V_{DD}$                 | 1.62 <sup>(1)</sup> | 3.6   |      |
| $V_{DD33USB}$ | Standard operating voltage, USB domain       | USB used                                | 3.0                 | 3.6   |      |
|               |  | USB not used                            | 0                   | 3.6   |      |
| $V_{DDA}$     | Analog operating voltage                     | ADC or COMP used                        | 1.62                | 3.6   |      |
|               |  | DAC used                                | 1.8                 |   |      |
|               |  | OPAMP used                              | 2.0                 |   |      |
|               |  | VREFBUF used                            | 1.8                 |   |      |
|               |  | ADC, DAC, OPAMP, COMP, VREFBUF not used | 0                   |   |      |
| $V_{IN}$      | I/O Input voltage                            | TT_xx I/O                               | -0.3                | $V_{DD}+0.3$  |      |
|               |  | BOOT0                                   | 0                   | 9   |      |
|               |  | All I/O except BOOT0 and TT_xx          | -0.3                | $\text{Min}(V_{DD}, V_{DDA}, V_{DD33USB})+3.6V < 5.5V^{(2)(3)}$ |      |
| $T_A$         | Ambient temperature for the suffix 6 version | Maximum power dissipation               | -40                 | 85  | °C   |
|               |  | Low-power dissipation <sup>(4)</sup>    | -40                 | 105   |      |
| $T_J$         | Junction temperature range                   | Suffix 6 version                        | -40                 | 125   | °C   |

1. When RESET is released functionality is guaranteed down to  $V_{BOR0}$  min
2. This formula has to be applied on power supplies related to the IO structure described by the pin definition table.
3. For operation with voltage higher than  $\text{Min}(V_{DD}, V_{DDA}, V_{DD33USB}) + 0.3V$ , the internal Pull-up and Pull-Down resistors must be disabled.
4. In low-power dissipation state,  $T_A$  can be extended to this range as long as  $T_J$  does not exceed  $T_{Jmax}$  (see [Section 8.10: Thermal characteristics](#)).

### 6.3.2 VCAP external capacitor

Stabilization for the main regulator is achieved by connecting an external capacitor  $C_{EXT}$  to the VCAP pin.  $C_{EXT}$  is specified in [Table 14](#). Two external capacitors can be connected to VCAP pins.

Figure 16. External capacitor  $C_{EXT}$



1. Legend: ESR is the equivalent series resistance.

Table 14. VCAP operating conditions<sup>(1)</sup>

| Symbol           | Parameter                         | Conditions            |
|------------------|-----------------------------------|-----------------------|
| C <sub>EXT</sub> | Capacitance of external capacitor | 2.2 μF <sup>(2)</sup> |
| ESR              | ESR of external capacitor         | < 100 mΩ              |

1. When bypassing the voltage regulator, the two 2.2 μF V<sub>CAP</sub> capacitors are not required and should be replaced by two 100 nF decoupling capacitors.
2. This value corresponds to C<sub>EXT</sub> typical value. A variation of +/-20% is tolerated.

### 6.3.3 Operating conditions at power-up / power-down

Subject to general operating conditions for T<sub>A</sub>.

Table 15. Operating conditions at power-up / power-down (regulator ON)

| Symbol              | Parameter                         | Min | Max | Unit |
|---------------------|-----------------------------------|-----|-----|------|
| t <sub>VDD</sub>    | V <sub>DD</sub> rise time rate    | 0   | ∞   | μs/V |
|                     | V <sub>DD</sub> fall time rate    | 10  | ∞   |      |
| t <sub>VDDA</sub>   | V <sub>DDA</sub> rise time rate   | 0   | ∞   |      |
|                     | V <sub>DDA</sub> fall time rate   | 10  | ∞   |      |
| t <sub>VDDUSB</sub> | V <sub>DDUSB</sub> rise time rate | 0   | ∞   |      |
|                     | V <sub>DDUSB</sub> fall time rate | 10  | ∞   |      |

### 6.3.4 Embedded reset and power control block characteristics

The parameters given in [Table 16](#) are derived from tests performed under ambient temperature and  $V_{DD}$  supply voltage conditions summarized in [Table 13: General operating conditions](#).

**Table 16. Reset and power control block characteristics**

| Symbol                   | Parameter  | Conditions                 | Min  | Typ  | Max   | Unit          |
|--------------------------|--|----------------------------|------|------|-------|---------------|
| $t_{RSTTEMP0}^{(1)}$     | Reset temporization after BOR0 released                            | -                          | -    | 377  | -     | $\mu\text{s}$ |
| $V_{BOR0/POR/PDR}$       | Brown-out reset threshold 0 ( $V_{POR}/V_{PDR}$ thresholds)        | Rising edge <sup>(1)</sup> | 1.62 | 1.67 | 1.71  | V             |
|                          |  | Falling edge               | 1.58 | 1.62 | 1.68  |               |
| $V_{BOR1}$               | Brown-out reset threshold 1  | Rising edge                | 2.04 | 2.10 | 2.15  |               |
|                          |  | Falling edge               | 1.95 | 2.00 | 2.06  |               |
| $V_{BOR2}$               | Brown-out reset threshold 2  | Rising edge                | 2.34 | 2.41 | 2.47  |               |
|                          |  | Falling edge               | 2.25 | 2.31 | 2.37  |               |
| $V_{BOR3}$               | Brown-out reset threshold 3  | Rising edge                | 2.63 | 2.70 | 2.78  |               |
|                          |  | Falling edge               | 2.54 | 2.61 | 2.68  |               |
| $V_{PVD0}$               | Programmable Voltage Detector threshold 0                          | Rising edge                | 1.90 | 1.96 | 2.01  |               |
|                          |  | Falling edge               | 1.81 | 1.86 | 1.91  |               |
| $V_{PVD1}$               | Programmable Voltage Detector threshold 1                          | Rising edge                | 2.05 | 2.10 | 2.16  |               |
|                          |  | Falling edge               | 1.96 | 2.01 | 2.06  |               |
| $V_{PVD2}$               | Programmable Voltage Detector threshold 2                          | Rising edge                | 2.19 | 2.26 | 2.32  |               |
|                          |  | Falling edge               | 2.10 | 2.15 | 2.21  |               |
| $V_{PVD3}$               | Programmable Voltage Detector threshold 3                          | Rising edge                | 2.35 | 2.41 | 2.47  |               |
|                          |  | Falling edge               | 2.25 | 2.31 | 2.37  |               |
| $V_{PVD4}$               | Programmable Voltage Detector threshold 4                          | Rising edge                | 2.49 | 2.56 | 2.62  |               |
|                          |  | Falling edge               | 2.39 | 2.45 | 2.51  |               |
| $V_{PVD5}$               | Programmable Voltage Detector threshold 5                          | Rising edge                | 2.64 | 2.71 | 2.78  |               |
|                          |  | Falling edge               | 2.55 | 2.61 | 2.68  |               |
| $V_{PVD6}$               | Programmable Voltage Detector threshold 6                          | Rising edge                | 2.78 | 2.86 | 2.94  |               |
|                          |  | Falling edge in Run mode   | 2.69 | 2.76 | 2.83  |               |
| $V_{hyst\_BOR\_PVD}$     | Hysteresis voltage of BOR (unless BOR0) and PVD                    | Hysteresis in Run mode     | -    | 100  | -     | mV            |
| $I_{DD\_BOR\_PVD}^{(1)}$ | BOR <sup>(2)</sup> (unless BOR0) and PVD consumption from $V_{DD}$ | -                          | -    | -    | 0.630 | $\mu\text{A}$ |

Table 16. Reset and power control block characteristics (continued)

| Symbol                 | Parameter  | Conditions      | Min  | Typ  | Max  | Unit |    |
|------------------------|--|-----------------|------|------|------|------|----|
| V <sub>AVM_0</sub>     | Analog voltage detector for V <sub>DDA</sub> threshold 0 | Rising edge     | 1.66 | 1.71 | 1.76 | V    |    |
|                        |  | Falling edge    | 1.56 | 1.61 | 1.66 |      |    |
| V <sub>AVM_1</sub>     | Analog voltage detector for V <sub>DDA</sub> threshold 1 | Rising edge     | 2.06 | 2.12 | 2.19 |      |    |
|                        |  | Falling edge    | 1.96 | 2.02 | 2.08 |      |    |
| V <sub>AVM_2</sub>     | Analog voltage detector for V <sub>DDA</sub> threshold 2 | Rising edge     | 2.42 | 2.50 | 2.58 |      |    |
|                        |  | Falling edge    | 2.35 | 2.42 | 2.49 |      |    |
| V <sub>AVM_3</sub>     | Analog voltage detector for V <sub>DDA</sub> threshold 3 | Rising edge     | 2.74 | 2.83 | 2.91 |      |    |
|                        |  | Falling edge    | 2.64 | 2.72 | 2.80 |      |    |
| V <sub>hyst_VDDA</sub> | Hysteresis of V <sub>DDA</sub> voltage detector          | -               | -    | 100  | -    |      | mV |
| I <sub>DD_PVM</sub>    | PVM consumption from V <sub>DD</sub> (1)                 | -               | -    | -    | 0.25 |      | μA |
| I <sub>DD_VDDA</sub>   | Voltage detector consumption on V <sub>DDA</sub> (1)     | Resistor bridge | -    | -    | 2.5  | μA   |    |

1. Guaranteed by design.
2. BOR0 is enabled in all modes and its consumption is therefore included in the supply current characteristics tables (refer to [Section 6.3.6: Supply current characteristics](#)).

### 6.3.5 Embedded reference voltage

The parameters given in [Table 17](#) are derived from tests performed under ambient temperature and V<sub>DD</sub> supply voltage conditions summarized in [Table 13: General operating conditions](#).

Table 17. Embedded reference voltage

| Symbol                        | Parameter   | Conditions   | Min   | Typ   | Max   | Unit   |
|-------------------------------|---|--|-------|-------|-------|--------|
| V <sub>REFINT</sub>           | Internal reference voltages   | -40°C < T <sub>J</sub> < 105°C,<br>V <sub>DD</sub> = 3.3 V | 1.180 | 1.216 | 1.255 | V      |
| t <sub>S_vrefint</sub> (1)(2) | ADC sampling time when reading the internal reference voltage       | -  | 4.3   | -     | -     | μs     |
| t <sub>S_vbat</sub> (1)(2)    | VBAT sampling time when reading the internal VBAT reference voltage | -  | 9     | -     | -     |        |
| I <sub>refbuf</sub> (2)       | Reference Buffer consumption for ADC                                | V <sub>DDA</sub> =3.3 V                                    | 9     | 13.5  | 23    | μA     |
| ΔV <sub>REFINT</sub> (2)      | Internal reference voltage spread over the temperature range        | -40°C < T <sub>J</sub> < 105°C                             | -     | 5     | 15    | mV     |
| T <sub>coeff</sub> (2)        | Average temperature coefficient                                     | Average temperature coefficient                            | -     | 20    | 70    | ppm/°C |
| V <sub>DDcoeff</sub> (2)      | Average Voltage coefficient   | 3.0V < V <sub>DD</sub> < 3.6V                              | -     | 10    | 1370  | ppm/V  |

Table 17. Embedded reference voltage (continued)

| Symbol                   | Parameter             | Conditions | Min | Typ | Max | Unit                     |
|--------------------------|-----------------------|------------|-----|-----|-----|--------------------------|
| V <sub>REFINT_DIV1</sub> | 1/4 reference voltage | -          | -   | 25  | -   | %<br>V <sub>REFINT</sub> |
| V <sub>REFINT_DIV2</sub> | 1/2 reference voltage | -          | -   | 50  | -   |                          |
| V <sub>REFINT_DIV3</sub> | 3/4 reference voltage | -          | -   | 75  | -   |                          |

1. The shortest sampling time for the application can be determined by multiple iterations.
2. Guaranteed by design.

Table 18. Internal reference voltage calibration values

| Symbol                 | Parameter   | Memory address      |
|------------------------|---|---------------------|
| V <sub>REFIN_CAL</sub> | Raw data acquired at temperature of 30 °C, V <sub>DDA</sub> = 3.3 V | 1FF1E860 - 1FF1E861 |

### 6.3.6 Supply current characteristics

The current consumption is a function of several parameters and factors such as the operating voltage, ambient temperature, I/O pin loading, device software configuration, operating frequencies, I/O pin switching rate, program location in memory and executed binary code.

The current consumption is measured as described in [Figure 15: Current consumption measurement scheme](#).

All the run-mode current consumption measurements given in this section are performed with a CoreMark code.

#### Typical and maximum current consumption

The MCU is placed under the following conditions:

- All I/O pins are in analog input mode.
- All peripherals are disabled except when explicitly mentioned.
- The flash memory access time is adjusted with the minimum wait states number, depending on the  $f_{\text{ACLK}}$  frequency (refer to the table “Number of wait states according to CPU clock ( $f_{\text{RCC\_C\_CK}}$ ) frequency and V<sub>CORE</sub> range” available in the reference manual).
- When the peripherals are enabled, the AHB clock frequency is the CPU frequency divided by 2 and the APB clock frequency is AHB clock frequency divided by 2.

The parameters given in [Table 19](#) to [Table 27](#) are derived from tests performed under ambient temperature and supply voltage conditions summarized in [Table 13: General operating conditions](#).

**Table 19. Typical and maximum current consumption in Run mode, code with data processing running from ITCM, regulator ON<sup>(1)</sup>**

| Symbol          | Parameter                  | Conditions               | f <sub>rcc_c_ck</sub><br>(MHz) | Typ | Max <sup>(2)</sup>    |                       |                        |                        | unit |    |
|-----------------|----------------------------|--------------------------|--------------------------------|-----|-----------------------|-----------------------|------------------------|------------------------|------|----|
|                 |                            |                          |                                |     | T <sub>J</sub> = 25°C | T <sub>J</sub> = 85°C | T <sub>J</sub> = 105°C | T <sub>J</sub> = 125°C |      |    |
| I <sub>DD</sub> | Supply current in Run mode | All peripherals disabled | VOS1                           | 400 | 71                    | 110                   | 210                    | 290                    | 540  | mA |
|                 |                            |                          |                                | 300 | 56                    | -                     | -                      | -                      | -    |    |
|                 |                            |                          | VOS2                           | 300 | 50                    | 72                    | 170                    | 230                    | 370  |    |
|                 |                            |                          |                                | 216 | 37                    | 58                    | 150                    | 210                    | 380  |    |
|                 |                            |                          | VOS3                           | 200 | 35.5                  | -                     | -                      | -                      | -    |    |
|                 |                            |                          |                                | 200 | 33                    | 50                    | 130                    | 190                    | 300  |    |
|                 |                            |                          |                                | 180 | 30                    | 47                    | 130                    | 180                    | 290  |    |
|                 |                            |                          |                                | 168 | 28                    | 45                    | 130                    | 180                    | 290  |    |
|                 |                            | 144                      |                                | 25  | 41                    | 120                   | 180                    | 290                    |      |    |
|                 |                            | All peripherals enabled  | VOS1                           | 60  | 13                    | 28                    | 110                    | 160                    | 280  |    |
|                 |                            |                          |                                | 25  | 10                    | 24                    | 99                     | 160                    | 270  |    |
|                 |                            |                          | VOS2                           | 400 | 165                   | 220 <sup>(3)</sup>    | 400                    | 500 <sup>(3)</sup>     | 840  |    |
|                 |                            |                          |                                | 300 | 130                   | -                     | -                      | -                      | -    |    |
|                 |                            |                          | VOS3                           | 300 | 120                   | 170                   | 300                    | 390                    | 570  |    |
|                 |                            |                          |                                | 200 | 83                    | -                     | -                      | -                      | -    |    |
|                 |                            |                          | 200                            | 78  | 110                   | 220                   | 300                    | 470                    |      |    |

1. Data are in DTCM for best computation performance, cache has no influence on consumption in this case.
2. Guaranteed by characterization results unless otherwise specified.
3. Guaranteed by test in production.

**Table 20. Typical and maximum current consumption in Run mode, code with data processing running from flash memory, cache ON, regulator ON**

| Symbol          | Parameter                  | Conditions               | f <sub>rcc_c_ck</sub><br>(MHz) | Typ | Max <sup>(1)</sup>    |                       |                        |                        | unit |    |
|-----------------|----------------------------|--------------------------|--------------------------------|-----|-----------------------|-----------------------|------------------------|------------------------|------|----|
|                 |                            |                          |                                |     | T <sub>J</sub> = 25°C | T <sub>J</sub> = 85°C | T <sub>J</sub> = 105°C | T <sub>J</sub> = 125°C |      |    |
| I <sub>DD</sub> | Supply current in Run mode | All peripherals disabled | VOS1                           | 400 | 105                   | 160                   | 310                    | 420                    | 750  | mA |
|                 |                            |                          |                                | 300 | 55                    | -                     | -                      | -                      | -    |    |
|                 |                            |                          | VOS2                           | 300 | 50                    | 72                    | 160                    | 230                    | 370  |    |
|                 |                            |                          |                                | 216 | 38                    | -                     | -                      | -                      | -    |    |
|                 |                            |                          | VOS3                           | 200 | 36                    | -                     | -                      | -                      | -    |    |
|                 |                            |                          |                                | 200 | 33                    | 50                    | 130                    | 190                    | 300  |    |
|                 |                            |                          |                                | 180 | 30                    | -                     | -                      | -                      | -    |    |
|                 |                            |                          |                                | 168 | 29                    | -                     | -                      | -                      | -    |    |
|                 |                            |                          |                                | 144 | 26                    | -                     | -                      | -                      | -    |    |
|                 |                            | 60                       | 14                             | -   | -                     | -                     | -                      |                        |      |    |
|                 |                            | 25                       | 14                             | -   | -                     | -                     | -                      |                        |      |    |
|                 |                            | All peripherals enabled  | VOS1                           | 400 | 160                   | 220                   | 400                    | 500                    | 750  |    |
|                 |                            |                          |                                | 300 | 130                   | -                     | -                      | -                      | -    |    |
|                 |                            |                          | VOS2                           | 300 | 120                   | 160                   | 300                    | 390                    | 560  |    |
|                 |                            |                          |                                | 200 | 81                    | -                     | -                      | -                      | -    |    |
|                 |                            |                          | VOS3                           | 200 | 77                    | 110                   | 220                    | 300                    | 460  |    |

1. Guaranteed by characterization results unless otherwise specified.

**Table 21. Typical and maximum current consumption in Run mode, code with data processing running from flash memory, cache OFF, regulator ON**

| Symbol          | Parameter                  | Conditions               | f <sub>rcc_c_ck</sub><br>(MHz) | Typ | Max <sup>(1)</sup>    |                       |                        |                        | unit |    |
|-----------------|----------------------------|--------------------------|--------------------------------|-----|-----------------------|-----------------------|------------------------|------------------------|------|----|
|                 |                            |                          |                                |     | T <sub>J</sub> = 25°C | T <sub>J</sub> = 85°C | T <sub>J</sub> = 105°C | T <sub>J</sub> = 125°C |      |    |
| I <sub>DD</sub> | Supply current in Run mode | All peripherals disabled | VOS1                           | 400 | 73                    | 110                   | 220                    | 290                    | 540  | mA |
|                 |                            |                          | VOS2                           | 300 | 52                    | 75                    | 170                    | 230                    | 370  |    |
|                 |                            |                          | VOS3                           | 200 | 34                    | 52                    | 130                    | 190                    | 300  |    |
|                 |                            | All peripherals enabled  | VOS1                           | 400 | 135                   | 190                   | 360                    | 470                    | 730  |    |
|                 |                            |                          | VOS2                           | 300 | 100                   | 150                   | 270                    | 370                    | 550  |    |
|                 |                            |                          | VOS3                           | 200 | 70                    | 100                   | 210                    | 300                    | 460  |    |

1. Guaranteed by characterization results.

**Table 22. Typical consumption in Run mode and corresponding performance versus code position**

| Symbol          | Parameter                  | Conditions                         |          | f <sub>rcc_c_ck</sub> (MHz) | CoreMark | Typ  | Unit | IDD/ CoreMark | Unit         |
|-----------------|----------------------------|------------------------------------|----------|-----------------------------|----------|------|------|---------------|--------------|
|                 |                            | Peripheral                         | Code     |                             |          |      |      |               |              |
| I <sub>DD</sub> | Supply current in Run mode | All peripherals disabled, cache ON | ITCM     | 400                         | 2012     | 71   | mA   | 35            | μA/ CoreMark |
|                 |                            |                                    | FLASH A  | 400                         | 2012     | 105  |      | 52            |              |
|                 |                            |                                    | AXI SRAM | 400                         | 2012     | 105  |      | 52            |              |
|                 |                            |                                    | SRAM1    | 400                         | 2012     | 105  |      | 52            |              |
|                 |                            |                                    | SRAM4    | 400                         | 2012     | 105  |      | 52            |              |
|                 |                            | All peripherals disabled cache OFF | ITCM     | 400                         | 2012     | 71   |      | 35            |              |
|                 |                            |                                    | FLASH A  | 400                         | 593      | 70.5 |      | 119           |              |
|                 |                            |                                    | AXI SRAM | 400                         | 344      | 70.5 |      | 205           |              |
|                 |                            |                                    | SRAM1    | 400                         | 472      | 74.5 |      | 158           |              |
|                 |                            |                                    | SRAM4    | 400                         | 432      | 72   |      | 167           |              |

**Table 23. Typical current consumption batch acquisition mode**

| Symbol          | Parameter                                | Conditions                  | f <sub>rcc_ahb_ck(AHB4)</sub> (MHz) | Typ | unit |    |
|-----------------|--|-----------------------------|-------------------------------------|-----|------|----|
| I <sub>DD</sub> | Supply current in batch acquisition mode | D1Standby, D2Standby, D3Run | VOS3                                | 64  | 6.5  | mA |
|                 |  | D1Stop, D2Stop, D3Run       | VOS3                                | 64  | 12   |    |

**Table 24. Typical and maximum current consumption in Sleep mode, regulator ON**

| Symbol                 | Parameter                    | Conditions               | f <sub>rcc_c_ck</sub> (MHz) | Typ | Max <sup>(1)</sup>    |                       |                        |                        | unit |    |
|------------------------|------------------------------|--------------------------|-----------------------------|-----|-----------------------|-----------------------|------------------------|------------------------|------|----|
|                        |                              |                          |                             |     | T <sub>J</sub> = 25°C | T <sub>J</sub> = 85°C | T <sub>J</sub> = 105°C | T <sub>J</sub> = 125°C |      |    |
| I <sub>DD(Sleep)</sub> | Supply current in Sleep mode | All peripherals disabled | VOS1                        | 400 | 31.0                  | 64                    | 220                    | 330                    | 660  | mA |
|                        |                              |                          |                             | 300 | 24.5                  | 57                    | 210                    | 330                    | 650  |    |
|                        |                              |                          | VOS2                        | 300 | 22.0                  | 48                    | 180                    | 270                    | 500  |    |
|                        |                              |                          |                             | 200 | 17.0                  | 42                    | 170                    | 270                    | 490  |    |
| VOS3                   | 200                          | 15.5                     | 37                          | 150 | 230                   | 400                   |                        |                        |      |    |

1. Guaranteed by characterization results.

**Table 25. Typical and maximum current consumption in Stop mode, regulator ON**

| Symbol                | Parameter                    | Conditions                              | Typ   | Max <sup>(1)</sup>    |                       |                        |                        | unit |    |
|-----------------------|------------------------------|---|-------|-----------------------|-----------------------|------------------------|------------------------|------|----|
|                       |                              |   |       | T <sub>J</sub> = 25°C | T <sub>J</sub> = 85°C | T <sub>J</sub> = 105°C | T <sub>J</sub> = 125°C |      |    |
| I <sub>DD(Stop)</sub> | D1Stop, D2Stop, D3Stop       | Flash memory in low-power mode, no IWDG | SVOS5 | 1.4                   | 7.2 <sup>(2)</sup>    | 49                     | 75 <sup>(2)</sup>      | 140  | mA |
|                       |                              |   | SVOS4 | 1.95                  | 11                    | 66                     | 110                    | 200  |    |
|                       |                              |   | SVOS3 | 2.85                  | 16 <sup>(2)</sup>     | 91                     | 150 <sup>(2)</sup>     | 240  |    |
|                       |                              | Flash memory ON, no IWDG                | SVOS5 | 1.65                  | 7.2                   | 49                     | 75                     | 140  |    |
|                       |                              |   | SVOS4 | 2.2                   | 11                    | 66                     | 110                    | 180  |    |
|                       |                              |   | SVOS3 | 3.15                  | 16                    | 91                     | 150                    | 300  |    |
|                       | D1Stop, D2Standby, D3Stop    | Flash memory OFF, no IWDG               | SVOS5 | 0.99                  | 5.1                   | 35                     | 60                     | 97   |    |
|                       |                              |   | SVOS4 | 1.4                   | 7.5                   | 47                     | 79                     | 130  |    |
|                       |                              |   | SVOS3 | 2.05                  | 12                    | 64                     | 110                    | 170  |    |
|                       |                              | Flash memory ON, no IWDG                | SVOS5 | 1.25                  | 5.5                   | 35                     | 61                     | 98   |    |
|                       |                              |   | SVOS4 | 1.65                  | 7.8                   | 47                     | 80                     | 130  |    |
|                       |                              |   | SVOS3 | 2.3                   | 12                    | 65                     | 110                    | 170  |    |
|                       | D1Standby, D2Stop, D3Stop    | Flash OFF, no IWDG                      | SVOS5 | 0.57                  | 3                     | 21                     | 36                     | 57   |    |
|                       |                              |   | SVOS4 | 0.805                 | 4.5                   | 27                     | 47                     | 74   |    |
|                       |                              |   | SVOS3 | 1.2                   | 6.7                   | 37                     | 63                     | 99   |    |
|                       | D1Standby, D2Standby, D3Stop | Flash OFF, no IWDG                      | SVOS5 | 0.17                  | 1.1 <sup>(2)</sup>    | 8                      | 13 <sup>(2)</sup>      | 20   |    |
|                       |                              |   | SVOS4 | 0.245                 | 1.5                   | 11                     | 17                     | 26   |    |
|                       |                              |   | SVOS3 | 0.405                 | 2.4 <sup>(2)</sup>    | 15                     | 23 <sup>(2)</sup>      | 35   |    |

1. Guaranteed by characterization results.
2. Guaranteed by test in production.

**Table 26. Typical and maximum current consumption in Standby mode**

| Symbol                       | Parameter                      | Conditions  |           | Typ <sup>(3)</sup> |       |      |       | Max (3 V) <sup>(1)</sup> |                       |                        |                        | Unit |
|------------------------------|--------------------------------|-------------|-----------|--------------------|-------|------|-------|--------------------------|-----------------------|------------------------|------------------------|------|
|                              |                                | Backup SRAM | RTC & LSE | 1.62 V             | 2.4 V | 3 V  | 3.3 V | T <sub>J</sub> = 25°C    | T <sub>J</sub> = 85°C | T <sub>J</sub> = 105°C | T <sub>J</sub> = 125°C |      |
| I <sub>DD</sub><br>(Standby) | Supply current in Standby mode | OFF         | OFF       | 1.8                | 1.9   | 1.95 | 2.05  | 4 <sup>(2)</sup>         | 18 <sup>(3)</sup>     | 40 <sup>(2)</sup>      | 90 <sup>(3)</sup>      | µA   |
|                              |                                | ON          | OFF       | 3.4                | 3.4   | 3.5  | 3.7   | 8.2 <sup>(3)</sup>       | 47 <sup>(3)</sup>     | 83 <sup>(3)</sup>      | 141 <sup>(3)</sup>     |      |
|                              |                                | OFF         | ON        | 2.4                | 3.5   | 3.86 | 4.12  | -                        | -                     | -                      | -                      |      |
|                              |                                | ON          | ON        | 3.95               | 5.1   | 5.46 | 5.97  | -                        | -                     | -                      | -                      |      |

1. The maximum current consumption values are given for PDR OFF (internal reset OFF). When the PDR is OFF (internal reset OFF), the current consumption is reduced by 1.2 µA compared to PDR ON.
2. Guaranteed by test in production.
3. Guaranteed by characterization results.

**Table 27. Typical and maximum current consumption in VBAT mode**

| Symbol                    | Parameter                      | Conditions  |           | Typ <sup>(1)</sup> |       |       |       | Max (3 V)             |                       |                        |                        | Unit |
|---------------------------|--------------------------------|-------------|-----------|--------------------|-------|-------|-------|-----------------------|-----------------------|------------------------|------------------------|------|
|                           |                                | Backup SRAM | RTC & LSE | 1.2 V              | 2 V   | 3 V   | 3.4 V | T <sub>J</sub> = 25°C | T <sub>J</sub> = 85°C | T <sub>J</sub> = 105°C | T <sub>J</sub> = 125°C |      |
| I <sub>DD</sub><br>(VBAT) | Supply current in standby mode | OFF         | OFF       | 0.024              | 0.035 | 0.062 | 0.096 | 0.5 <sup>(1)</sup>    | 4.1 <sup>(1)</sup>    | 10 <sup>(1)</sup>      | 24 <sup>(1)</sup>      | μA   |
|                           |                                | ON          | OFF       | 1.4                | 1.6   | 1.8   | 1.8   | 4.4 <sup>(1)</sup>    | 22 <sup>(1)</sup>     | 48 <sup>(1)</sup>      | 87 <sup>(1)</sup>      |      |
|                           |                                | OFF         | ON        | 0.24               | 0.45  | 0.62  | 0.73  | -                     | -                     | -                      | -                      |      |
|                           |                                | ON          | ON        | 1.97               | 2.37  | 2.57  | 2.77  | -                     | -                     | -                      | -                      |      |

1. Guaranteed by characterization results.

### I/O system current consumption

The current consumption of the I/O system has two components: static and dynamic.

#### I/O static current consumption

All the I/Os used as inputs with pull-up or pull-down generate a current consumption when the pin is externally held low. The value of this current consumption can be simply computed by using the pull-up/pull-down resistors values given in [Table 49: I/O static characteristics](#).

For the output pins, any internal or external pull-up or pull-down, and any external load must also be considered to estimate the current consumption.

An additional I/O current consumption is due to I/Os configured as inputs if an intermediate voltage level is externally applied. This current consumption is caused by the input Schmitt trigger circuits used to discriminate the input value. Unless this specific configuration is required by the application, this supply current consumption can be avoided by configuring these I/Os in analog mode. This is notably the case of ADC input pins which should be configured as analog inputs.

**Caution:** Any floating input pin can also settle to an intermediate voltage level or switch inadvertently, as a result of external electromagnetic noise. To avoid a current consumption related to floating pins, they must either be configured in analog mode, or forced internally to a definite digital value. This can be done either by using pull-up/down resistors or by configuring the pins in output mode.

#### I/O dynamic current consumption

In addition to the internal peripheral current consumption (see [Table 28: Peripheral current consumption in Run mode](#)), the I/Os used by an application also contribute to the current consumption. When an I/O pin switches, it uses the current from the MCU supply voltage to supply the I/O pin circuitry and to charge/discharge the internal or external capacitive load connected to the pin:

$$I_{SW} = V_{DDx} \times f_{SW} \times C_L$$

where

I<sub>SW</sub> is the current sunk by a switching I/O to charge/discharge the capacitive load

V<sub>DDx</sub> is the MCU supply voltage

f<sub>SW</sub> is the I/O switching frequency

C<sub>L</sub> is the total capacitance seen by the I/O pin: C = C<sub>INT</sub>+ C<sub>EXT</sub>

The test pin is configured in push-pull output mode and is toggled by software at a fixed frequency.

### On-chip peripheral current consumption

The MCU is placed under the following conditions:

- At startup, all I/O pins are in analog input configuration.
- All peripherals are disabled unless otherwise mentioned.
- The I/O compensation cell is enabled.
- $f_{\text{rcc\_c\_ck}}$  is the CPU clock.  $f_{\text{PCLK}} = f_{\text{rcc\_c\_ck}}/4$ , and  $f_{\text{HCLK}} = f_{\text{rcc\_c\_ck}}/2$ .  
The given value is calculated by measuring the difference of current consumption
  - with all peripherals clocked off
  - with only one peripheral clocked on
  - $f_{\text{rcc\_c\_ck}} = 400$  MHz (Scale 1),  $f_{\text{rcc\_c\_ck}} = 300$  MHz (Scale 2),  
 $f_{\text{rcc\_c\_ck}} = 200$  MHz (Scale 3)
- The ambient operating temperature is 25 °C and  $V_{\text{DD}}=3.3$  V.

Table 28. Peripheral current consumption in Run mode

| Peripheral  |                    | I <sub>DD</sub> (Typ) |      |      | Unit   |
|-------------|--------------------|-----------------------|------|------|--------|
|             |                    | VOS1                  | VOS2 | VOS3 |        |
| AHB3        | MDMA               | 8.3                   | 7.6  | 7    | μA/MHz |
|             | DMA2D              | 21                    | 20   | 18   |        |
|             | JPEG               | 24                    | 23   | 21   |        |
|             | FLASH              | 9.9                   | 9    | 8.3  |        |
|             | FMC registers      | 0.9                   | 0.9  | 0.8  |        |
|             | FMC kernel         | 6.1                   | 5.5  | 5.3  |        |
|             | QUADSPI registers  | 1.5                   | 1.4  | 1.3  |        |
|             | QUADSPI kernel     | 0.9                   | 0.8  | 0.7  |        |
|             | SDMMC1 registers   | 8                     | 7.2  | 6.8  |        |
|             | SDMMC1 kernel      | 2.4                   | 2    | 1.8  |        |
|             | DTCM1              | 5.7                   | 5    | 4.5  |        |
|             | DTCM2              | 5.5                   | 4.8  | 4.3  |        |
|             | ITCM               | 3.2                   | 2.9  | 2.6  |        |
|             | D1SRAM1            | 7.6                   | 6.8  | 6.1  |        |
| AHB3 bridge | 7.5                | 6.8                   | 6.3  |      |        |
| AHB1        | DMA1               | 1.1                   | 1    | 1    |        |
|             | DMA2               | 1.7                   | 1.4  | 1.1  |        |
|             | ADC1/2 registers   | 3.9                   | 3.2  | 3.1  |        |
|             | ADC1/2 kernel      | 0.9                   | 0.8  | 0.7  |        |
|             | ART accelerator    | 5.5                   | 4.5  | 4.2  |        |
|             | ETH1MAC            | 16                    | 14   | 13   |        |
|             | ETH1TX             |                       |      |      |        |
|             | ETH1RX             |                       |      |      |        |
|             | USB1 OTG registers | 15                    | 14   | 13   |        |
|             | USB1 OTG kernel    | -                     | 8.5  | 8.5  |        |
|             | USB1 ULPI          | 0.3                   | 0.3  | 0.1  |        |
|             | USB2 OTG registers | 15                    | 13   | 12   |        |
|             | USB2 OTG kernel    | -                     | 8.6  | 8.6  |        |
|             | USB2 ULPI          | 16                    | 16   | 16   |        |
| AHB1 Bridge | 10                 | 9.6                   | 8.6  |      |        |

Table 28. Peripheral current consumption in Run mode (continued)

| Peripheral  |                  | I <sub>DD</sub> (Typ) |      |      | Unit   |
|-------------|------------------|-----------------------|------|------|--------|
|             |                  | VOS1                  | VOS2 | VOS3 |        |
| AHB2        | DCMI             | 1.7                   | 1.7  | 1.7  | μA/MHz |
|             | CRYP             | 0.1                   | 0.1  | 0.1  |        |
|             | HASH             | 0.1                   | 0.1  | 0.1  |        |
|             | RNG registers    | 1.8                   | 1.4  | 1.2  |        |
|             | RNG kernel       | -                     | 9.6  | 9.6  |        |
|             | SDMMC2 registers | 13                    | 12   | 11   |        |
|             | SDMMC2 kernel    | 2.7                   | 2.5  | 2.4  |        |
|             | D2SRAM1          | 3.3                   | 3.1  | 2.8  |        |
|             | D2SRAM2          | 2.9                   | 2.7  | 2.5  |        |
|             | D2SRAM3          | 1.9                   | 1.8  | 1.7  |        |
| AHB2 bridge | 0.1              | 0.1                   | 0.1  |      |        |
| AHB4        | GPIOA            | 1.1                   | 1    | 0.9  |        |
|             | GPIOB            | 1                     | 0.9  | 0.9  |        |
|             | GPIOC            | 1.4                   | 1.3  | 1.3  |        |
|             | GIOD             | 1.1                   | 1    | 0.9  |        |
|             | GPIOE            | 1                     | 0.9  | 0.8  |        |
|             | GPIOF            | 0.9                   | 0.8  | 0.8  |        |
|             | GPIOG            | 0.9                   | 0.7  | 0.7  |        |
|             | GPIOH            | 1                     | 0.9  | 0.9  |        |
|             | GPIOI            | 0.9                   | 0.9  | 0.8  |        |
|             | GPIOJ            | 0.9                   | 0.8  | 0.8  |        |
|             | GPIOK            | 0.9                   | 0.8  | 0.7  |        |
|             | CRC              | 0.5                   | 0.4  | 0.4  |        |
|             | BDMA             | 6.2                   | 5.8  | 5.5  |        |
|             | ADC3 registers   | 1.8                   | 1.7  | 1.7  |        |
|             | ADC3 kernel      | 0.1                   | 0.1  | 0.1  |        |
|             | Backup SRAM      | 1.9                   | 1.8  | 1.8  |        |
| Bridge AHB4 | 0.1              | 0.1                   | 0.1  |      |        |
| APB3        | LCD-TFT          | 12                    | 11   | 10   | μA/MHz |
|             | WWDG1            | 0.5                   | 0.4  | 0.3  |        |
|             | APB3 bridge      | 0.5                   | 0.2  | 0.1  |        |

**Table 28. Peripheral current consumption in Run mode (continued)**

| Peripheral       |                    | I <sub>DD</sub> (Typ) |      |      | Unit   |
|------------------|--------------------|-----------------------|------|------|--------|
|                  |                    | VOS1                  | VOS2 | VOS3 |        |
| APB1             | TIM2               | 3.5                   | 3.2  | 2.9  | μA/MHz |
|                  | TIM3               | 3.4                   | 3.1  | 2.7  |        |
|                  | TIM4               | 2.7                   | 2.5  | 1.9  |        |
|                  | TIM5               | 3.2                   | 2.9  | 2.5  |        |
|                  | TIM6               | 1                     | 0.8  | 0.7  |        |
|                  | TIM7               | 1                     | 0.9  | 0.7  |        |
|                  | TIM12              | 1.7                   | 1.5  | 1.2  |        |
|                  | TIM13              | 1.5                   | 1.3  | 1    |        |
|                  | TIM14              | 1.4                   | 1.3  | 0.9  |        |
|                  | LPTIM1 registers   | 0.7                   | 0.6  | 0.5  |        |
|                  | LPTIM1 kernel      | 2.3                   | 2.1  | 1.9  |        |
|                  | WWDG2              | 0.6                   | 0.4  | 0.4  |        |
|                  | SPI2 registers     | 1.8                   | 1.5  | 1.2  |        |
|                  | SPI2 kernel        | 0.6                   | 0.5  | 0.5  |        |
|                  | SPI3 registers     | 1.5                   | 1.3  | 1.1  |        |
|                  | SPI3 kernel        | 0.6                   | 0.5  | 0.5  |        |
|                  | SPDIFRX1 registers | 0.6                   | 0.5  | 0.3  |        |
|                  | SPDIFRX1 kernel    | 2.9                   | 2.4  | 2.4  |        |
|                  | USART2 registers   | 1.4                   | 1.3  | 1    |        |
|                  | USART2 kernel      | 4.7                   | 4.1  | 4    |        |
| USART3 registers | 1.4                | 1.3                   | 1    |      |        |
| USART3 kernel    | 4.2                | 3.8                   | 3.5  |      |        |
| UART4 registers  | 1.5                | 1.1                   | 1    |      |        |
| UART4 kernel     | 3.7                | 3.6                   | 3.2  |      |        |

**Table 28. Peripheral current consumption in Run mode (continued)**

| Peripheral          |                    | I <sub>DD</sub> (Typ) |      |      | Unit   |
|---------------------|--------------------|-----------------------|------|------|--------|
|                     |                    | VOS1                  | VOS2 | VOS3 |        |
| APB1<br>(continued) | UART5 registers    | 1.4                   | 1.4  | 1    | μA/MHz |
|                     | UART5 kernel       | 3.6                   | 3.2  | 3.1  |        |
|                     | I2C1 registers     | 0.8                   | 0.8  | 0.6  |        |
|                     | I2C1 kernel        | 2                     | 1.8  | 1.7  |        |
|                     | I2C2 registers     | 0.7                   | 0.7  | 0.4  |        |
|                     | I2C2 kernel        | 1.9                   | 1.7  | 1.6  |        |
|                     | I2C3 registers     | 0.9                   | 0.7  | 0.6  |        |
|                     | I2C3 kernel        | 2.1                   | 1.9  | 1.9  |        |
|                     | HDMI-CEC registers | 0.5                   | 0.3  | 0.3  |        |
|                     | DAC1/2             | 1.4                   | 1.1  | 0.9  |        |
|                     | USART7 registers   | 1.9                   | 1.8  | 1.3  |        |
|                     | USART7 kernel      | 4                     | 3.5  | 3.3  |        |
|                     | USART8 registers   | 1.6                   | 1.5  | 1.2  |        |
|                     | USART8 kernel      | 4                     | 3.6  | 3.3  |        |
|                     | CRS                | 3.4                   | 3.1  | 2.9  |        |
|                     | SWPMI registers    | 2.3                   | 2    | 2    |        |
|                     | SWPMI kernel       | 0.1                   | 0.1  | 0.1  |        |
|                     | OPAMP              | 0.5                   | 0.4  | 0.4  |        |
|                     | MDIO               | 2.7                   | 2.4  | 2.3  |        |
|                     | FDCAN registers    | 16                    | 15   | 14   |        |
| FDCAN kernel        | 7.8                | 7.6                   | 7.1  |      |        |
| Bridge APB1         | 0.1                | 0.1                   | 0.1  |      |        |

**Table 28. Peripheral current consumption in Run mode (continued)**

| Peripheral  |                  | I <sub>DD</sub> (Typ) |      |      | Unit   |
|-------------|------------------|-----------------------|------|------|--------|
|             |                  | VOS1                  | VOS2 | VOS3 |        |
| APB2        | TIM1             | 5.1                   | 4.8  | 4.3  | μA/MHz |
|             | TIM8             | 5.4                   | 4.9  | 4.6  |        |
|             | USART1 registers | 2.7                   | 2.6  | 2.5  |        |
|             | USART1 kernel    | 0.1                   | 0.1  | 0.1  |        |
|             | USART6 registers | 2.6                   | 2.5  | 2.5  |        |
|             | USART6 kernel    | 0.1                   | 0.1  | 0.1  |        |
|             | SPI1 registers   | 1.8                   | 1.6  | 1.6  |        |
|             | SPI1 kernel      | 1                     | 0.8  | 0.6  |        |
|             | SPI4 registers   | 1.6                   | 1.5  | 1.5  |        |
|             | SPI4 kernel      | 0.5                   | 0.4  | 0.4  |        |
|             | TIM15            | 3.1                   | 2.8  | 2.7  |        |
|             | TIM16            | 2.4                   | 2.1  | 2.1  |        |
|             | TIM17            | 2.2                   | 2    | 1.9  |        |
|             | SPI5 registers   | 1.8                   | 1.7  | 1.7  |        |
|             | SPI5 kernel      | 0.6                   | 0.5  | 0.3  |        |
|             | SAI1 registers   | 1.5                   | 1.4  | 1.4  |        |
|             | SAI1 kernel      | 2                     | 1.7  | 1.5  |        |
|             | SAI2 registers   | 1.5                   | 1.5  | 1.3  |        |
|             | SAI2 kernel      | 2.2                   | 1.9  | 1.8  |        |
|             | SAI3 registers   | 1.8                   | 1.6  | 1.6  |        |
|             | SAI3 kernel      | 2.5                   | 2.3  | 2.1  |        |
|             | DFSDM1 registers | 6                     | 5.4  | 5.2  |        |
|             | DFSDM1 kernel    | 0.9                   | 0.8  | 0.7  |        |
|             | HRTIM            | 40                    | 37   | 35   |        |
| Bridge APB2 | 0.1              | 0.1                   | 0.1  |      |        |

Table 28. Peripheral current consumption in Run mode (continued)

| Peripheral  |                   | I <sub>DD</sub> (Typ) |      |      | Unit   |
|-------------|-------------------|-----------------------|------|------|--------|
|             |                   | VOS1                  | VOS2 | VOS3 |        |
| APB4        | SYSCFG            | 1                     | 0.7  | 0.7  | μA/MHz |
|             | LPUART1 registers | 1.1                   | 1.1  | 1.1  |        |
|             | LPUART1 kernel    | 2.6                   | 2.4  | 2.1  |        |
|             | SPI6 registers    | 1.6                   | 1.5  | 1.4  |        |
|             | SPI6 kernel       | 0.2                   | 0.2  | 0.2  |        |
|             | I2C4 registers    | 0.1                   | 0.1  | 0.1  |        |
|             | I2C4 kernel       | 2.4                   | 2.1  | 2    |        |
|             | LPTIM2 registers  | 0.5                   | 0.5  | 0.5  |        |
|             | LPTIM2 kernel     | 2.3                   | 2.1  | 1.8  |        |
|             | LPTIM3 registers  | 0.5                   | 0.5  | 0.5  |        |
|             | LPTIM3 kernel     | 2                     | 2.1  | 1.5  |        |
|             | LPTIM4 registers  | 0.5                   | 0.5  | 0.5  |        |
|             | LPTIM4 kernel     | 2                     | 2    | 1.9  |        |
|             | LPTIM5 registers  | 0.5                   | 0.5  | 0.5  |        |
|             | LPTIM5 kernel     | 2                     | 1.8  | 1.5  |        |
|             | COMP1/2           | 0.7                   | 0.5  | 0.5  |        |
|             | VREFBUF           | 0.6                   | 0.4  | 0.4  |        |
|             | RTC               | 1.2                   | 1.1  | 1.1  |        |
|             | SAI4 registers    | 1.6                   | 1.5  | 1.4  |        |
|             | SAI4 kernel       | 1.3                   | 1.3  | 1.2  |        |
| Bridge APB4 | 0.1               | 0.1                   | 0.1  |      |        |

Table 29. Peripheral current consumption in Stop, Standby and VBAT mode

| Symbol          | Parameter                 | Conditions | Typ  | Unit |
|-----------------|---------------------------|------------|------|------|
|                 |                           |            | 3 V  |      |
| I <sub>DD</sub> | RTC+LSE low drive         | -          | 2.32 | μA   |
|                 | RTC+LSE medium-low drive  | -          | 2.4  |      |
|                 | RTC+LSE medium-high drive | -          | 2.7  |      |
|                 | RTC+LSE High drive        | -          | 3    |      |

### 6.3.7 Wakeup time from low-power modes

The wakeup times given in [Table 30](#) are measured starting from the wakeup event trigger up to the first instruction executed by the CPU:

- For Stop or Sleep modes: the wakeup event is WFE.
- WKUP (PC1) pin is used to wakeup from Standby, Stop and Sleep modes.

All timings are derived from tests performed under ambient temperature and  $V_{DD}=3.3\text{ V}$ .

**Table 30. Low-power mode wakeup timings**

| Symbol              | Parameter                            | Conditions                                | Typ <sup>(1)</sup> | Max <sup>(1)</sup> | Unit             |
|---------------------|--------------------------------------|---|--------------------|--------------------|------------------|
| $t_{WUSLEEP}^{(2)}$ | Wakeup from Sleep                    | -   | 9                  | 10                 | CPU clock cycles |
| $t_{WUSTOP}^{(2)}$  | Wakeup from Stop                     | VOS3, HSI, flash memory in normal mode    | 4.4                | 5.6                | μs               |
|                     |                                      | VOS3, HSI, flash memory in low-power mode | 12                 | 15                 |                  |
|                     |                                      | VOS4, HSI, flash memory in normal mode    | 15                 | 20                 |                  |
|                     |                                      | VOS4, HSI, flash memory in low-power mode | 23                 | 28                 |                  |
|                     |                                      | VOS5, HSI, flash memory in normal mode    | 30                 | 71                 |                  |
|                     |                                      | VOS5, HSI, flash memory in low-power mode | 38                 | 47                 |                  |
|                     |                                      | VOS3, CSI, flash memory in normal mode    | 27                 | 37                 |                  |
|                     |                                      | VOS3, CSI, flash memory in low power mode | 36                 | 50                 |                  |
|                     |                                      | VOS4, CSI, flash memory in normal mode    | 38                 | 48                 |                  |
|                     |                                      | VOS4, CSI, flash memory in low-power mode | 47                 | 61                 |                  |
|                     |                                      | VOS5, CSI, flash memory in normal mode    | 52                 | 64                 |                  |
|                     |                                      | VOS5, CSI, flash memory in low-power mode | 62                 | 77                 |                  |
| $t_{WUSTOP2}^{(2)}$ | Wakeup from Stop, clock kept running | VOS3, HSI, flash memory in normal mode    | 2.6                | 3.4                | μs               |
|                     |                                      | VOS3, CSI, flash memory in normal mode    | 26                 | 36                 |                  |
| $t_{WUSTDBY}^{(2)}$ | Wakeup from Standby mode             | -   | 390                | 500                | μs               |

1. Guaranteed by characterization results.

2. The wakeup times are measured from the wakeup event to the point in which the application code reads the first instruction.

### 6.3.8 External clock source characteristics

#### High-speed external user clock generated from an external source

In bypass mode the HSE oscillator is switched off and the input pin is a standard I/O.

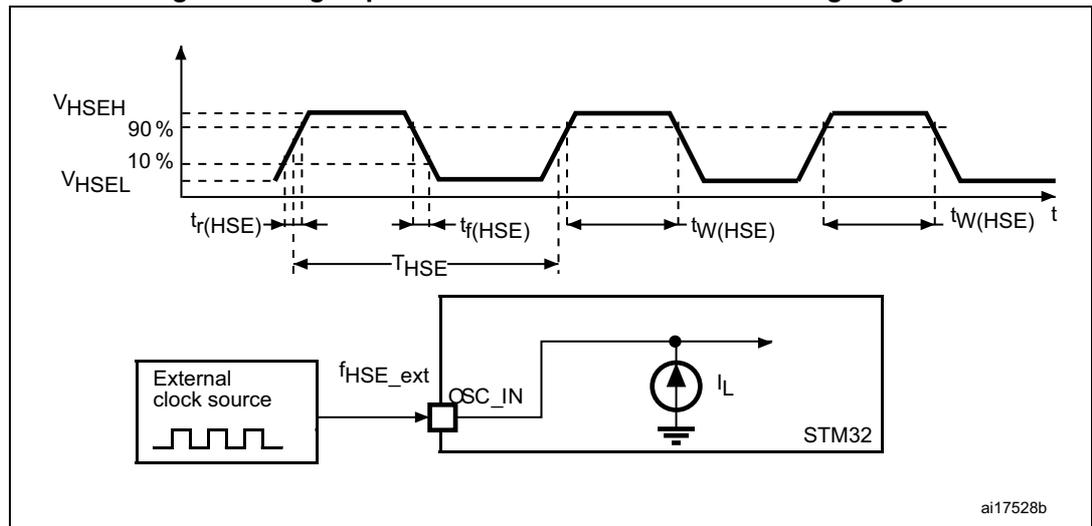
The external clock signal has to respect the [Table 49: I/O static characteristics](#). However, the recommended clock input waveform is shown in [Figure 17](#).

**Table 31. High-speed external user clock characteristics<sup>(1)</sup>**

| Symbol         | Parameter                               | Min          | Typ | Max          | Unit |
|----------------|---|--------------|-----|--------------|------|
| $f_{HSE\_ext}$ | User external clock source frequency    | 4            | 25  | 50           | MHz  |
| $V_{HSEH}$     | Digital OSC_IN input high-level voltage | $0.7 V_{DD}$ | -   | $V_{DD}$     | V    |
| $V_{HSEL}$     | Digital OSC_IN input low-level voltage  | $V_{SS}$     | -   | $0.3 V_{DD}$ |      |
| $t_{W(HSE)}$   | OSC_IN high or low time                 | 7            | -   | -            | ns   |

1. Guaranteed by design.

**Figure 17. High-speed external clock source AC timing diagram**



**Low-speed external user clock generated from an external source**

In bypass mode the LSE oscillator is switched off and the input pin is a standard I/O. The external clock signal has to respect the [Table 49: I/O static characteristics](#). However, the recommended clock input waveform is shown in [Figure 18](#).

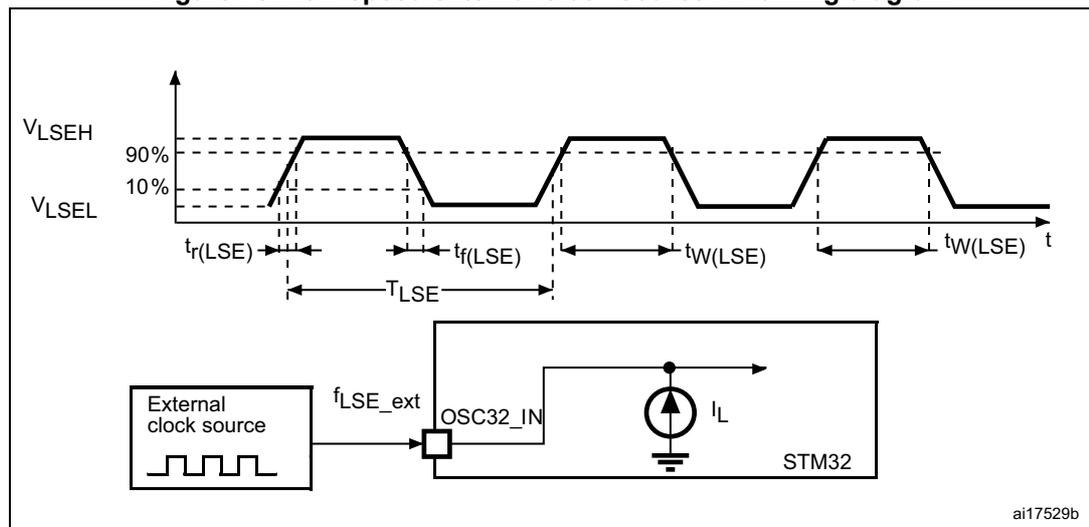
**Table 32. Low-speed external user clock characteristics<sup>(1)</sup>**

| Symbol                         | Parameter                             | Conditions | Min          | Typ    | Max          | Unit |
|--------------------------------|---------------------------------------|------------|--------------|--------|--------------|------|
| $f_{LSE\_ext}$                 | User external clock source frequency  | -          | -            | 32.768 | 1000         | kHz  |
| $V_{LSEH}$                     | OSC32_IN input pin high level voltage | -          | $0.7 V_{DD}$ | -      | $V_{DD}$     | V    |
| $V_{LSEL}$                     | OSC32_IN input pin low level voltage  | -          | $V_{SS}$     | -      | $0.3 V_{DD}$ |      |
| $t_{w(LSEH)}$<br>$t_{w(LSEL)}$ | OSC32_IN high or low time             | -          | 250          | -      | -            | ns   |

1. Guaranteed by design.

**Note:** For information on selecting the crystal, refer to the application note AN2867 “Oscillator design guide for STM8AF/AL/S, STM32 MCUs and MPUs” available from the ST website [www.st.com](http://www.st.com).

**Figure 18. Low-speed external clock source AC timing diagram**



### High-speed external clock generated from a crystal/ceramic resonator

The high-speed external (HSE) clock can be supplied with a 4 to 48 MHz crystal/ceramic resonator oscillator. All the information given in this paragraph are based on characterization results obtained with typical external components specified in [Table 33](#). In the application, the resonator and the load capacitors have to be placed as close as possible to the oscillator pins in order to minimize output distortion and startup stabilization time. Refer to the crystal resonator manufacturer for more details on the resonator characteristics (frequency, package, accuracy).

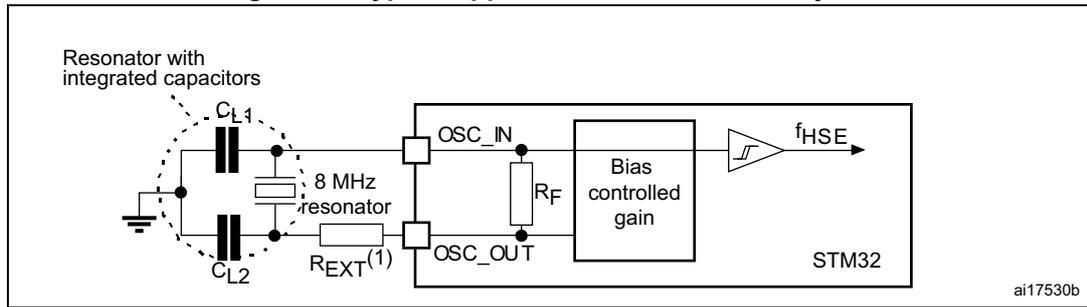
**Table 33. 4-48 MHz HSE oscillator characteristics<sup>(1)</sup>**

| Symbol                            | Parameter                   | Operating conditions <sup>(2)</sup>   | Min | Typ  | Max | Unit |
|-----------------------------------|-----------------------------|---|-----|------|-----|------|
| F                                 | Oscillator frequency        | -   | 4   | -    | 48  | MHz  |
| R <sub>F</sub>                    | Feedback resistor           | -   | -   | 200  | -   | kΩ   |
| I <sub>DD(HSE)</sub>              | HSE current consumption     | During startup <sup>(3)</sup>   | -   | -    | 4   | mA   |
|                                   |                             | V <sub>DD</sub> =3 V, R <sub>m</sub> =30 Ω<br>C <sub>L</sub> =10pF@4MHz       | -   | 0.35 | -   |      |
|                                   |                             | V <sub>DD</sub> =3 V, R <sub>m</sub> =30 Ω<br>C <sub>L</sub> =10 pF at 8 MHz  | -   | 0.40 | -   |      |
|                                   |                             | V <sub>DD</sub> =3 V, R <sub>m</sub> =30 Ω<br>C <sub>L</sub> =10 pF at 16 MHz | -   | 0.45 | -   |      |
|                                   |                             | V <sub>DD</sub> =3 V, R <sub>m</sub> =30 Ω<br>C <sub>L</sub> =10 pF at 32 MHz | -   | 0.65 | -   |      |
|                                   |                             | V <sub>DD</sub> =3 V, R <sub>m</sub> =30 Ω<br>C <sub>L</sub> =10 pF at 48 MHz | -   | 0.95 | -   |      |
| G <sub>m</sub> <sub>critmax</sub> | Maximum critical crystal gm | Startup   | -   | -    | 1.5 | mA/V |
| t <sub>SU</sub> <sup>(4)</sup>    | Start-up time               | V <sub>DD</sub> is stabilized   | -   | 2    | -   | ms   |

1. Guaranteed by design.
2. Resonator characteristics given by the crystal/ceramic resonator manufacturer.
3. This consumption level occurs during the first 2/3 of the t<sub>SU(HSE)</sub> startup time.
4. t<sub>SU(HSE)</sub> is the startup time measured from the moment it is enabled (by software) to a stabilized 8 MHz oscillation is reached. This value is measured for a standard crystal resonator and it can vary significantly with the crystal manufacturer.

**Note:** For information on selecting the crystal, refer to the application note AN2867 "Oscillator design guide for STM8AF/AL/S, STM32 MCUs and MPUs" available from the ST website [www.st.com](http://www.st.com).

Figure 19. Typical application with an 8 MHz crystal



1.  $R_{EXT}$  value depends on the crystal characteristics.

**Low-speed external clock generated from a crystal/ceramic resonator**

The low-speed external (LSE) clock can be supplied with a 32.768 kHz crystal/ceramic resonator oscillator. All the information given in this paragraph are based on characterization results obtained with typical external components specified in [Table 34](#). In the application, the resonator and the load capacitors have to be placed as close as possible to the oscillator pins in order to minimize output distortion and startup stabilization time. Refer to the crystal resonator manufacturer for more details on the resonator characteristics (frequency, package, accuracy).

Table 34. Low-speed external user clock characteristics<sup>(1)</sup>

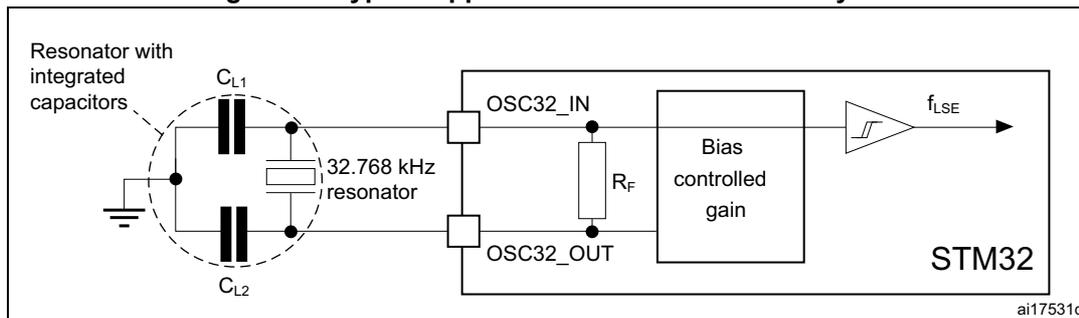
| Symbol                  | Parameter                   | Operating conditions <sup>(2)</sup>               | Min | Typ    | Max  | Unit      |
|-------------------------|-----------------------------|---|-----|--------|------|-----------|
| F                       | Oscillator frequency        | -   | -   | 32.768 | -    | kHz       |
| $I_{DD}$                | LSE current consumption     | LSEDRV[1:0] = 00,<br>Low drive capability         | -   | 290    | -    | nA        |
|                         |                             | LSEDRV[1:0] = 01,<br>Medium Low drive capability  | -   | 390    | -    |           |
|                         |                             | LSEDRV[1:0] = 10,<br>Medium high drive capability | -   | 550    | -    |           |
|                         |                             | LSEDRV[1:0] = 11,<br>High drive capability        | -   | 900    | -    |           |
| $G_{m_{critmax}}$       | Maximum critical crystal gm | LSEDRV[1:0] = 00,<br>Low drive capability         | -   | -      | 0.5  | $\mu A/V$ |
|                         |                             | LSEDRV[1:0] = 01,<br>Medium Low drive capability  | -   | -      | 0.75 |           |
|                         |                             | LSEDRV[1:0] = 10,<br>Medium high drive capability | -   | -      | 1.7  |           |
|                         |                             | LSEDRV[1:0] = 11,<br>High drive capability        | -   | -      | 2.7  |           |
| $t_{SU}$ <sup>(3)</sup> | Startup time                | VDD is stabilized                                 | -   | 2      | -    | s         |

1. Guaranteed by design.

2. Refer to the note and caution paragraphs below the table, and to the application note AN2867 “Oscillator design guide for STM8AL/AF/S, STM32 MCUs and MPUs”.
3.  $t_{SU}$  is the startup time measured from the moment it is enabled (by software) to a stabilized 32.768 kHz oscillation is reached. This value is measured for a standard crystal resonator and it can vary significantly with the crystal manufacturer.

**Note:** For information on selecting the crystal, refer to the application note AN2867 “Oscillator design guide for STM8AL/AF/S, STM32 MCUs and MPUs” available from the ST website [www.st.com](http://www.st.com).

**Figure 20. Typical application with a 32.768 kHz crystal**



1. An external resistor is not required between OSC32\_IN and OSC32\_OUT and it is forbidden to add one.

### 6.3.9 Internal clock source characteristics

The parameters given in [Table 35](#) and [Table 38](#) are derived from tests performed under ambient temperature and  $V_{DD}$  supply voltage conditions summarized in [Table 13: General operating conditions](#).

#### 48 MHz high-speed internal RC oscillator (HSI48)

**Table 35. HSI48 oscillator characteristics**

| Symbol                                       | Parameter  | Conditions  | Min                 | Typ        | Max                 | Unit          |
|--|--|---|---------------------|------------|---------------------|---------------|
| $f_{HSI48}$                                  | HSI48 frequency  | $V_{DD}=3.3\text{ V}$ , $T_J=30\text{ °C}$                                  | 47.5 <sup>(1)</sup> | 48         | 48.5 <sup>(1)</sup> | MHz           |
| TRIM <sup>(2)</sup>                          | USER trimming step   | -   | -                   | 0.17       | -                   | %             |
| USER TRIM COVERAGE <sup>(3)</sup>            | USER TRIMMING Coverage   | $\pm 32$ steps  | -                   | $\pm 5.45$ | -                   | %             |
| DuCy(HSI48) <sup>(2)</sup>                   | Duty Cycle   | -   | 45                  | -          | 55                  | %             |
| ACCHSI48_REL <sup>(3)</sup>                  | Accuracy of the HSI48 oscillator over temperature (factory calibrated)     | $V_{DD}=1.62\text{ to }3.6\text{ V}$ ,<br>$T_J=-40\text{ to }125\text{ °C}$ | -4.5                | -          | 3.5                 | %             |
| $\Delta V_{DD}(\text{HSI48})$ <sup>(3)</sup> | HSI48 oscillator frequency drift with $V_{DD}$ <sup>(4)</sup>              | $V_{DD}=3\text{ to }3.6\text{ V}$   | -                   | 0.025      | 0.05                | %             |
|  |  | $V_{DD}=1.62\text{ V to }3.6\text{ V}$                                      | -                   | 0.05       | 0.1                 |               |
| $t_{su}(\text{HSI48})$ <sup>(2)</sup>        | HSI48 oscillator start-up time   | -   | -                   | 2.1        | 3.5                 | $\mu\text{s}$ |
| $I_{DD}(\text{HSI48})$ <sup>(2)</sup>        | HSI48 oscillator power consumption   | -   | -                   | 350        | 400                 | $\mu\text{A}$ |
| $N_T$ jitter                                 | Next transition jitter<br>Accumulated jitter on 28 cycles <sup>(5)</sup>   | -   | -                   | $\pm 0.15$ | -                   | ns            |
| $P_T$ jitter                                 | Paired transition jitter<br>Accumulated jitter on 56 cycles <sup>(5)</sup> | -   | -                   | $\pm 0.25$ | -                   | ns            |

1. Guaranteed by test in production.
2. Guaranteed by design.
3. Guaranteed by characterization.
4. These values are obtained by using the formula:  
(Freq(3.6V) - Freq(3.0V)) / Freq(3.0V) or (Freq(3.6V) - Freq(1.62V)) / Freq(1.62V).
5. Jitter measurements are performed without clock source activated in parallel.

**64 MHz high-speed internal RC oscillator (HSI)**

**Table 36. HSI oscillator characteristics<sup>(1)</sup>**

| Symbol                    | Parameter  | Conditions   | Min                 | Typ   | Max                 | Unit |
|---------------------------|--|--|---------------------|-------|---------------------|------|
| f <sub>HSI</sub>          | HSI frequency  | V <sub>DD</sub> =3.3 V, T <sub>J</sub> =30 °C                              | 63.7 <sup>(2)</sup> | 64    | 64.3 <sup>(2)</sup> | MHz  |
| TRIM                      | HSI user trimming step   | Trimming is not a multiple of 32   | -                   | 0.24  | 0.32                | %    |
|                           |  | Trimming is 128, 256 and 384   | -5.2                | -1.8  | -                   |      |
|                           |  | Trimming is 64, 192, 320 and 448   | -1.4                | -0.8  | -                   |      |
|                           |  | Other trimming are a multiple of 32 (not including multiple of 64 and 128) | -0.6                | -0.25 | -                   |      |
| DuCy(HSI)                 | Duty Cycle   | -  | 45                  | -     | 55                  | %    |
| Δ V <sub>DD</sub> (HSI)   | HSI oscillator frequency drift over V <sub>DD</sub> (reference is 3.3 V) | V <sub>DD</sub> =1.62 to 3.6 V   | -0.12               | -     | 0.03                | %    |
| Δ T <sub>TEMP</sub> (HSI) | HSI oscillator frequency drift over temperature (reference is 64 MHz)    | T <sub>J</sub> =-20 to 105 °C  | -1 <sup>(3)</sup>   | -     | 1 <sup>(3)</sup>    | %    |
|                           |  | T <sub>J</sub> =-40 to T <sub>Jmax</sub> °C                                | -2 <sup>(3)</sup>   | -     | 1 <sup>(3)</sup>    |      |
| t <sub>su</sub> (HSI)     | HSI oscillator start-up time   | -  | -                   | 1.4   | 2                   | μs   |
| t <sub>stab</sub> (HSI)   | HSI oscillator stabilization time  | at 1% of target frequency  | -                   | 4     | 8                   | μs   |
| I <sub>DD</sub> (HSI)     | HSI oscillator power consumption   | -  | -                   | 300   | 400                 | μA   |

1. Guaranteed by design unless otherwise specified.
2. Guaranteed by test in production.
3. Guaranteed by characterization.

**4 MHz low-power internal RC oscillator (CSI)**

**Table 37. CSI oscillator characteristics<sup>(1)</sup>**

| Symbol           | Parameter     | Conditions                                    | Min                 | Typ  | Max                 | Unit |
|------------------|---------------|---|---------------------|------|---------------------|------|
| f <sub>CSI</sub> | CSI frequency | V <sub>DD</sub> =3.3 V, T <sub>J</sub> =30 °C | 3.96 <sup>(2)</sup> | 4    | 4.04 <sup>(2)</sup> | MHz  |
| TRIM             | Trimming step | -   | -                   | 0.35 | -                   | %    |
| DuCy(CSI)        | Duty Cycle    | -   | 45                  | -    | 55                  | %    |

Table 37. CSI oscillator characteristics<sup>(1)</sup> (continued)

| Symbol                | Parameter  | Conditions                 | Min | Typ                 | Max                | Unit    |
|-----------------------|--|----------------------------|-----|---------------------|--------------------|---------|
| $\Delta_{TEMP}$ (CSI) | CSI oscillator frequency drift over temperature                      | $T_J = 0$ to $85$ °C       | -   | -3.7 <sup>(3)</sup> | 4.5 <sup>(3)</sup> | %       |
|                       |  | $T_J = -40$ to $125$ °C    | -   | -11 <sup>(3)</sup>  | 7.5 <sup>(3)</sup> |         |
| $D_{VDD}$ (CSI)       | CSI oscillator frequency drift over $V_{DD}$                         | $V_{DD} = 1.62$ to $3.6$ V | -   | -0.06               | 0.06               | %       |
| $t_{su}$ (CSI)        | CSI oscillator startup time  | -                          | -   | 1                   | 2                  | $\mu$ s |
| $t_{stab}$ (CSI)      | CSI oscillator stabilization time (to reach $\pm 3\%$ of $f_{CSI}$ ) | -                          | -   | 4                   | 8                  | cycle   |
| $I_{DD}$ (CSI)        | CSI oscillator power consumption                                     | -                          | -   | 23                  | 30                 | $\mu$ A |

1. Guaranteed by design.
2. Guaranteed by test in production.
3. Guaranteed by characterization.

### Low-speed internal (LSI) RC oscillator

Table 38. LSI oscillator characteristics

| Symbol                          | Parameter   | Conditions  | Min   | Typ | Max   | Unit    |
|---------------------------------|---|---|-------|-----|-------|---------|
| $f_{LSI}$ <sup>(1)</sup>        | LSI frequency   | $V_{DD} = 3.3$ V, $T_J = 25$ °C                     | 31.4  | 32  | 32.6  | kHz     |
|                                 |   | $T_J = -40$ to $105$ °C, $V_{DD} = 1.62$ to $3.6$ V | 29.76 | -   | 33.60 |         |
| $t_{su}$ (LSI) <sup>(2)</sup>   | LSI oscillator startup time                           | -   | -     | 80  | 130   | $\mu$ s |
| $t_{stab}$ (LSI) <sup>(2)</sup> | LSI oscillator stabilization time (5% of final value) | -   | -     | 120 | 170   |         |
| $I_{DD}$ (LSI) <sup>(2)</sup>   | LSI oscillator power consumption                      | -   | -     | 130 | 280   | nA      |

1. Guaranteed by characterization results.
2. Guaranteed by design.

### 6.3.10 PLL characteristics

The parameters given in [Table 39](#) are derived from tests performed under temperature and  $V_{DD}$  supply voltage conditions summarized in [Table 13: General operating conditions](#).

Table 39. PLL characteristics (wide VCO frequency range)<sup>(1)</sup>

| Symbol        | Parameter                  | Conditions | Min | Typ | Max | Unit |
|---------------|----------------------------|------------|-----|-----|-----|------|
| $f_{PLL\_IN}$ | PLL input clock            | -          | 2   | -   | 16  | MHz  |
|               | PLL input clock duty cycle | -          | 10  | -   | 90  | %    |

**Table 39. PLL characteristics (wide VCO frequency range)<sup>(1)</sup> (continued)**

| Symbol                              | Parameter                                | Conditions                       | Min               | Typ               | Max                | Unit |    |
|-------------------------------------|--|----------------------------------|-------------------|-------------------|--------------------|------|----|
| f <sub>PLL_P_OUT</sub>              | PLL multiplier output clock P            | VOS1                             | 1.5               | -                 | 400 <sup>(2)</sup> | MHz  |    |
|                                     |  | VOS2                             | 1.5               | -                 | 300                |      |    |
|                                     |  | VOS3                             | 1.5               | -                 | 200                |      |    |
| f <sub>PLL_Q_OUT</sub>              | PLL multiplier output clock Q/R          | VOS1                             | 1.5               | -                 | 400 <sup>(2)</sup> |      |    |
|                                     |  | VOS2                             | 1.5               | -                 | 300                |      |    |
|                                     |  | VOS3                             | 1.5               | -                 | 200                |      |    |
| f <sub>VCO_OUT</sub>                | PLL VCO output                           | -                                | 192               | -                 | 836                |      |    |
| t <sub>LOCK</sub>                   | PLL lock time                            | Normal mode                      | -                 | 50 <sup>(3)</sup> | 150 <sup>(3)</sup> | µs   |    |
|                                     |  | Sigma-delta mode (CKIN ≥ 8 MHz)  | -                 | 58 <sup>(3)</sup> | 166 <sup>(3)</sup> |      |    |
| Jitter                              | Cycle-to-cycle jitter <sup>(4)</sup>     | VCO = 192 MHz                    | -                 | 134               | -                  | ± ps |    |
|                                     |  | VCO = 200 MHz                    | -                 | 134               | -                  |      |    |
|                                     |  | VCO = 400 MHz                    | -                 | 76                | -                  |      |    |
|                                     |  | VCO = 800 MHz                    | -                 | 39                | -                  |      |    |
|                                     | Long term jitter                         | Normal mode                      | -                 | ±0.7              | -                  | %    |    |
|                                     |  | Sigma-delta mode (CKIN = 16 MHz) | -                 | ±0.8              | -                  |      |    |
| I <sub>DD(PLL)</sub> <sup>(3)</sup> | PLL power consumption on V <sub>DD</sub> | VCO freq = 420 MHz               | V <sub>DDA</sub>  | -                 | 440                | 1150 | µA |
|                                     |  |                                  | V <sub>CORE</sub> | -                 | 530                | -    |    |
|                                     |  | VCO freq = 150 MHz               | V <sub>DDA</sub>  | -                 | 180                | 500  |    |
|                                     |  |                                  | V <sub>CORE</sub> | -                 | 200                | -    |    |

1. Guaranteed by design unless otherwise specified.
2. This value must be limited to the maximum frequency due to the product limitation (400 MHz for VOS1, 300 MHz for VOS2, 200 MHz for VOS3).
3. Guaranteed by characterization results.
4. Integer mode only.

**Table 40. PLL characteristics (medium VCO frequency range)<sup>(1)</sup>**

| Symbol               | Parameter                           | Conditions       | Min       | Typ               | Max                | Unit |
|----------------------|-------------------------------------|------------------|-----------|-------------------|--------------------|------|
| f <sub>PLL_IN</sub>  | PLL input clock                     | -                | 1         | -                 | 2                  | MHz  |
|                      | PLL input clock duty cycle          | -                | 10        | -                 | 90                 | %    |
| f <sub>PLL_OUT</sub> | PLL multiplier output clock P, Q, R | VOS1             | 1.17      | -                 | 210                | MHz  |
|                      |                                     | VOS2             | 1.17      | -                 | 210                |      |
|                      |                                     | VOS3             | 1.17      | -                 | 200                |      |
| f <sub>VCO_OUT</sub> | PLL VCO output                      | -                | 150       | -                 | 420                | MHz  |
| t <sub>LOCK</sub>    | PLL lock time                       | Normal mode      | -         | 60 <sup>(2)</sup> | 100 <sup>(2)</sup> | µs   |
|                      |                                     | Sigma-delta mode | forbidden | -                 | -                  | µs   |

**Table 40. PLL characteristics (medium VCO frequency range)<sup>(1)</sup> (continued)**

| Symbol                | Parameter                                | Conditions                    | Min           | Typ | Max    | Unit |        |
|-----------------------|--|-------------------------------|---------------|-----|--------|------|--------|
| Jitter                | Cycle-to-cycle jitter <sup>(3)</sup>     | -                             | VCO = 150 MHz | -   | 145    | -    | +/- ps |
|                       |  |                               | VCO = 300 MHz | -   | 91     | -    |        |
|                       |  |                               | VCO = 400 MHz | -   | 64     | -    |        |
|                       |  |                               | VCO = 420 MHz | -   | 63     | -    |        |
|                       | Period jitter                            | f <sub>PLL_OUT</sub> = 50 MHz | VCO = 150 MHz | -   | 55     | -    | +/- ps |
|                       |  |                               | VCO = 400 MHz | -   | 30     | -    |        |
|                       | Long term jitter                         | Normal mode                   | VCO = 150 MHz | -   | -      | -    | %      |
|                       |  |                               | VCO = 300 MHz | -   | -      | -    |        |
|                       |  |                               | VCO = 400 MHz | -   | +/-0.3 | -    |        |
| I(PLL) <sup>(2)</sup> | PLL power consumption on V <sub>DD</sub> | VCO freq = 420MHz             | VDD           | -   | 440    | 1150 | µA     |
|                       |  |                               | VCORE         | -   | 530    | -    |        |
|                       |  | VCO freq = 150MHz             | VDD           | -   | 180    | 500  |        |
|                       |  |                               | VCORE         | -   | 200    | -    |        |

1. Guaranteed by design unless otherwise specified.
2. Guaranteed by characterization results.
3. Integer mode only.

### 6.3.11 Memory characteristics

#### Flash memory

The characteristics are given at T<sub>J</sub> = -40 to 125 °C unless otherwise specified.

The devices are shipped to customers with the flash memory erased.

**Table 41. Flash memory characteristics**

| Symbol          | Parameter      | Conditions                | Min | Typ  | Max | Unit |
|-----------------|----------------|---------------------------|-----|------|-----|------|
| I <sub>DD</sub> | Supply current | Write / Erase 8-bit mode  | -   | 6.5  | -   | mA   |
|                 |                | Write / Erase 16-bit mode | -   | 11.5 | -   |      |
|                 |                | Write / Erase 32-bit mode | -   | 20   | -   |      |
|                 |                | Write / Erase 64-bit mode | -   | 35   | -   |      |

**Table 42. Flash memory programming**

| Symbol                  | Parameter                        | Conditions                     | Min <sup>(1)</sup> | Typ | Max <sup>(1)</sup> | Unit |
|-------------------------|----------------------------------|--------------------------------|--------------------|-----|--------------------|------|
| t <sub>prog</sub>       | Word (266 bits) programming time | Program/erase parallelism x 8  | -                  | 290 | 580 <sup>(2)</sup> | μs   |
|                         |                                  | Program/erase parallelism x 16 | -                  | 180 | 360                |      |
|                         |                                  | Program/erase parallelism x 32 | -                  | 130 | 260                |      |
|                         |                                  | Program/erase parallelism x 64 | -                  | 100 | 200                |      |
| t <sub>ERASE128KB</sub> | Sector (128 KB) erase time       | Program/erase parallelism x 8  | -                  | 2   | 4                  | s    |
|                         |                                  | Program/erase parallelism x 16 | -                  | 1.8 | 3.6                |      |
|                         |                                  | Program/erase parallelism x 32 | -                  | 1.1 | 2.2                |      |
|                         |                                  | Program/erase parallelism x 64 | -                  | 1   | 2                  |      |
| t <sub>ME</sub>         | Mass erase time                  | Program/erase parallelism x 8  | -                  | 13  | 26                 | s    |
|                         |                                  | Program/erase parallelism x 16 | -                  | 8   | 16                 |      |
|                         |                                  | Program/erase parallelism x 32 | -                  | 6   | 12                 |      |
|                         |                                  | Program/erase parallelism x 64 | -                  | 5   | 10                 |      |
| V <sub>prog</sub>       | Programming voltage              | Program parallelism x 8        | 1.62               | -   | 3.6                | V    |
|                         |                                  | Program parallelism x 16       |                    |     |                    |      |
|                         |                                  | Program parallelism x 32       |                    |     |                    |      |
|                         |                                  | Program parallelism x 64       | 1.8                | -   | 3.6                |      |

1. Guaranteed by characterization results.
2. The maximum programming time is measured after 10K erase operations.

**Table 43. Flash memory endurance and data retention**

| Symbol           | Parameter      | Conditions  | Value              | Unit    |
|------------------|----------------|---|--------------------|---------|
|                  |                |   | Min <sup>(1)</sup> |         |
| N <sub>END</sub> | Endurance      | T <sub>J</sub> = -40 to +125 °C (6 suffix versions) | 10                 | kcycles |
| t <sub>RET</sub> | Data retention | 1 kcycle at T <sub>A</sub> = 85 °C                  | 30                 | Years   |
|                  |                | 10 kcycles at T <sub>A</sub> = 55 °C                | 20                 |         |

1. Guaranteed by characterization results.

### 6.3.12 EMC characteristics

Susceptibility tests are performed on a sample basis during device characterization.

#### Functional EMS (electromagnetic susceptibility)

While a simple application is executed on the device (toggling 2 LEDs through I/O ports), the device is stressed by two electromagnetic events until a failure occurs. The failure is indicated by the LEDs:

- **Electrostatic discharge (ESD)** (positive and negative) is applied to all device pins until a functional disturbance occurs. This test is compliant with the IEC 61000-4-2 standard.
- **FTB**: A burst of fast transient voltage (positive and negative) is applied to  $V_{DD}$  and  $V_{SS}$  through a 100 pF capacitor, until a functional disturbance occurs. This test is compliant with the IEC 61000-4-4 standard.

A device reset allows normal operations to be resumed.

The test results are given in [Table 44](#). They are based on the EMS levels and classes defined in application note AN1709.

**Table 44. EMS characteristics**

| Symbol     | Parameter   | Conditions  | Level/Class |
|------------|---|---|-------------|
| $V_{FESD}$ | Voltage limits to be applied on any I/O pin to induce a functional disturbance  | $V_{DD} = 3.3\text{ V}$ , $T_A = +25\text{ °C}$ , UFBGA240, $f_{rcc\_c\_ck} = 400\text{ MHz}$ , conforms to IEC 61000-4-2 | 3B          |
| $V_{FTB}$  | Fast transient voltage burst limits to be applied through 100 pF on $V_{DD}$ and $V_{SS}$ pins to induce a functional disturbance |   | 4B          |

As a consequence, it is recommended to add a serial resistor (1 k $\Omega$ ) located as close as possible to the MCU to the pins exposed to noise (connected to tracks longer than 50 mm on PCB).

#### Designing hardened software to avoid noise problems

EMC characterization and optimization are performed at component level with a typical application environment and simplified MCU software. It should be noted that good EMC performance is highly dependent on the user application and the software in particular.

Therefore it is recommended that the user applies EMC software optimization and prequalification tests in relation with the EMC level requested for his application.

#### Software recommendations

The software flowchart must include the management of runaway conditions such as:

- Corrupted program counter
- Unexpected reset
- Critical Data corruption (control registers...)

**Prequalification trials**

Most of the common failures (unexpected reset and program counter corruption) can be reproduced by manually forcing a low state on the NRST pin or the Oscillator pins for 1 second.

To complete these trials, ESD stress can be applied directly on the device, over the range of specification values. When unexpected behavior is detected, the software can be hardened to prevent unrecoverable errors occurring (see application note AN1015).

**Electromagnetic Interference (EMI)**

The electromagnetic field emitted by the device are monitored while a simple application, executing EEMBC code, is running. This emission test is compliant with SAE IEC61967-2 standard which specifies the test board and the pin loading.

**Table 45. EMI characteristics for  $f_{HSE} = 8\text{ MHz}$  and  $f_{CPU} = 400\text{ MHz}$**

| Symbol    | Parameter            | Conditions   | Monitored frequency band | Value | Unit       |
|-----------|----------------------|--|--------------------------|-------|------------|
| $S_{EMI}$ | Peak <sup>(1)</sup>  | $V_{DD} = 3.6\text{ V}$ , $T_A = 25\text{ °C}$ , UFBGA240 package, compliant with IEC61967-2 | 0.1 MHz to 30 MHz        | 6     | dB $\mu$ V |
|           |                      |  | 30 MHz to 130 MHz        | 5     |            |
|           |                      |  | 130 MHz to 1 GHz         | 13    |            |
|           |                      |  | 1 GHz to 2 GHz           | 7     |            |
|           | Level <sup>(2)</sup> |  | 0.1 MHz to 2 GHz         | 2.5   | -          |

1. Refer to AN1709 "EMI radiated test" chapter.
2. Refer to AN1709 "EMI level classification" chapter.

### 6.3.13 Absolute maximum ratings (electrical sensitivity)

Based on three different tests (ESD, LU) using specific measurement methods, the device is stressed in order to determine its performance in terms of electrical sensitivity.

#### Electrostatic discharge (ESD)

Electrostatic discharges (a positive then a negative pulse) are applied to the pins of each sample according to each pin combination. This test conforms to the ANSI/ESDA/JEDEC JS-001 and ANSI/ESDA/JEDEC JS-002 standards.

**Table 46. ESD absolute maximum ratings**

| Symbol         | Ratings   | Conditions   | Packages | Class | Maximum value <sup>(1)</sup> | Unit |
|----------------|---|--|----------|-------|------------------------------|------|
| $V_{ESD(HBM)}$ | Electrostatic discharge voltage (human body model)    | $T_A = +25\text{ °C}$ conforming to ANSI/ESDA/JEDEC JS-001 | All      | 1C    | 1000                         | V    |
| $V_{ESD(CDM)}$ | Electrostatic discharge voltage (charge device model) | $T_A = +25\text{ °C}$ conforming to ANSI/ESDA/JEDEC JS-002 | All      | C1    | 250                          |      |

1. Guaranteed by characterization results.

#### Static latchup

Two complementary static tests are required on six parts to assess the latchup performance:

- A supply overvoltage is applied to each power supply pin
- A current injection is applied to each input, output and configurable I/O pin

These tests are compliant with JESD78 IC latchup standard.

**Table 47. Electrical sensitivities**

| Symbol | Parameter            | Conditions                                 | Class      |
|--------|----------------------|--|------------|
| LU     | Static latchup class | $T_A = +25\text{ °C}$ conforming to JESD78 | II level A |

### 6.3.14 I/O current injection characteristics

As a general rule, a current injection to the I/O pins, due to external voltage below  $V_{SS}$  or above  $V_{DD}$  (for standard, 3.3 V-capable I/O pins) should be avoided during the normal product operation. However, in order to give an indication of the robustness of the microcontroller in cases when an abnormal injection accidentally happens, susceptibility tests are performed on a sample basis during the device characterization.

#### Functional susceptibility to I/O current injection

While a simple application is executed on the device, the device is stressed by injecting current into the I/O pins programmed in floating input mode. While current is injected into the I/O pin, one at a time, the device is checked for functional failures.

The failure is indicated by an out of range parameter: ADC error above a certain limit (higher than 5 LSB TUE), out of conventional limits of induced leakage current on adjacent pins (out

of  $-5 \mu\text{A}/+0 \mu\text{A}$  range), or other functional failure (for example reset, oscillator frequency deviation).

The following tables are the compilation of the SIC1/SIC2 and functional ESD results.

Negative induced A negative induced leakage current is caused by negative injection and positive induced leakage current by positive injection.

**Table 48. I/O current injection susceptibility<sup>(1)</sup>**

| Symbol           | Description  | Functional susceptibility |                    | Unit |
|------------------|--|---------------------------|--------------------|------|
|                  |  | Negative injection        | Positive injection |      |
| $I_{\text{INJ}}$ | PA7, PC5, PG1, PB14, PJ7, PA11, PA12, PA13, PA14, PA15, PJ12, PB4        | 5                         | 0                  | mA   |
|                  | PA2, PH2, PH3, PE8, PA6, PA7, PC4, PE7, PE10, PE11                       | 0                         | NA                 |      |
|                  | PA0, PA_C, PA1, PA1_C, PC2, PC2_C, PC3, PC3_C, PA4, PA5, PH4, PH5, BOOT0 | 0                         | 0                  |      |
|                  | All other I/Os   | 5                         | NA                 |      |

1. Guaranteed by characterization.

### 6.3.15 I/O port characteristics

#### General input/output characteristics

Unless otherwise specified, the parameters given in [Table 49: I/O static characteristics](#) are derived from tests performed under the conditions summarized in [Table 13: General operating conditions](#). All I/Os are CMOS and TTL compliant (except for BOOT0).

For information on GPIO configuration, refer to the application note AN4899 “STM32 GPIO configuration for hardware settings and low-power consumption” available from the ST website [www.st.com](http://www.st.com).

**Table 49. I/O static characteristics**

| Symbol          | Parameter                                 | Condition  | Min                                | Typ | Max                               | Unit |
|-----------------|---|--|------------------------------------|-----|-----------------------------------|------|
| $V_{\text{IL}}$ | I/O input low level voltage except BOOT0  | $1.62 \text{ V} < V_{\text{DD}} < 3.6 \text{ V}$ | -                                  | -   | $0.3V_{\text{DD}}^{(1)}$          | V    |
|                 | I/O input low level voltage except BOOT0  |  | -                                  | -   | $0.4V_{\text{DD}}^- - 0.1^{(2)}$  |      |
|                 | BOOT0 I/O input low level voltage         |  | -                                  | -   | $0.19V_{\text{DD}}^+ - 0.1^{(2)}$ |      |
| $V_{\text{IH}}$ | I/O input high level voltage except BOOT0 | $1.62 \text{ V} < V_{\text{DD}} < 3.6 \text{ V}$ | $0.7V_{\text{DD}}^{(1)}$           | -   | -                                 | V    |
|                 | I/O input high level voltage except BOOT0 |  | $0.47V_{\text{DD}}^+ - 0.25^{(2)}$ | -   | -                                 |      |
|                 | BOOT0 I/O input high level voltage        |  | $0.17V_{\text{DD}}^+ - 0.6^{(2)}$  | -   | -                                 |      |

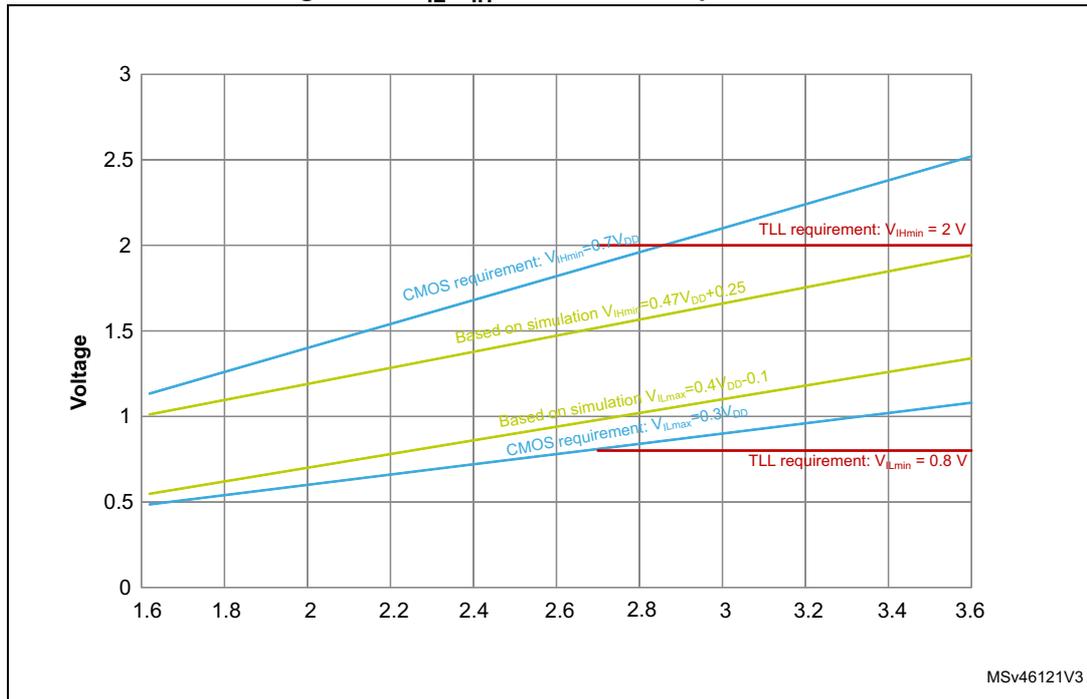
Table 49. I/O static characteristics (continued)

| Symbol                            | Parameter   | Condition   | Min | Typ | Max                 | Unit |
|-----------------------------------|---|---|-----|-----|---------------------|------|
| $V_{HYS}^{(2)}$                   | TT_xx, FT_xxx and NRST I/O input hysteresis       | $1.62\text{ V} < V_{DD} < 3.6\text{ V}$                         | -   | 250 | -                   | mV   |
|                                   | BOOT0 I/O input hysteresis                        |   | -   | 200 | -                   |      |
| $I_{lkg}^{(3)}$                   | FT_xx Input leakage current <sup>(2)</sup>        | $0 < V_{IN} \leq \text{Max}(V_{DDXXX})^{(8)}$                   | -   | -   | +/-250              | nA   |
|                                   |   | $\text{Max}(V_{DDXXX}) < V_{IN} \leq 5.5\text{ V}$<br>(4)(5)(8) | -   | -   | 1500                |      |
|                                   | FT_u IO   | $0 < V_{IN} \leq \text{Max}(V_{DDXXX})^{(8)}$                   | -   | -   | +/- 350             |      |
|                                   |   | $\text{Max}(V_{DDXXX}) < V_{IN} \leq 5.5\text{ V}$<br>(4)(5)(8) | -   | -   | 5000 <sup>(6)</sup> |      |
|                                   | TT_xx Input leakage current                       | $0 < V_{IN} \leq \text{Max}(V_{DDXXX})^{(8)}$                   | -   | -   | +/-250              |      |
|                                   | VPP (BOOT0 alternate function)                    | $0 < V_{IN} \leq V_{DD}$  | -   | -   | 15                  |      |
| $V_{DD} < V_{IN} \leq 9\text{ V}$ |   | -   | -   | 35  |                     |      |
| $R_{PU}$                          | Weak pull-up equivalent resistor <sup>(7)</sup>   | $V_{IN}=V_{SS}$   | 30  | 40  | 50                  | kΩ   |
| $R_{PD}$                          | Weak pull-down equivalent resistor <sup>(7)</sup> | $V_{IN}=V_{DD}^{(8)}$   | 30  | 40  | 50                  |      |
| $C_{IO}$                          | I/O pin capacitance                               | -   | -   | 5   | -                   | pF   |

- Compliant with CMOS requirement.
- Guaranteed by design.
- This parameter represents the pad leakage of the I/O itself. The total product pad leakage is provided by the following formula:  $I_{Total\_lkg\_max} = 10\ \mu\text{A} + [\text{number of I/Os where } V_{IN} \text{ is applied on the pad}] \times I_{lkg(Max)}$ .
- All FT\_xx IO except FT\_lu, FT\_u and PC3.
- $V_{IN}$  must be less than  $\text{Max}(V_{DDXXX}) + 3.6\text{ V}$ .
- To sustain a voltage higher than  $\text{MIN}(V_{DD}, V_{DDA}, V_{DD33USB}) + 0.3\text{ V}$ , the internal pull-up and pull-down resistors must be disabled.
- The pull-up and pull-down resistors are designed with a true resistance in series with a switchable PMOS/NMOS. This PMOS/NMOS contribution to the series resistance is minimal (~10% order).
- $\text{Max}(V_{DDXXX})$  is the maximum value of all the I/O supplies.

All I/Os are CMOS and TTL compliant (no software configuration required). Their characteristics cover more than the strict CMOS-technology or TTL parameters. The coverage of these requirements for FT I/Os is shown in [Figure 21](#).

Figure 21.  $V_{IL}/V_{IH}$  for all I/Os except BOOT0



### Output driving current

The GPIOs (general purpose input/outputs) can sink or source up to  $\pm 8\text{ mA}$ , and sink or source up to  $\pm 20\text{ mA}$  (with a relaxed  $V_{OL}/V_{OH}$ ).

In the user application, the number of I/O pins which can drive current must be limited to respect the absolute maximum rating specified in [Section 6.2](#). In particular:

- The sum of the currents sourced by all the I/Os on  $V_{DD}$ , plus the maximum Run consumption of the MCU sourced on  $V_{DD}$ , cannot exceed the absolute maximum rating  $\Sigma I_{VDD}$  (see [Table 11](#)).
- The sum of the currents sunk by all the I/Os on  $V_{SS}$  plus the maximum Run consumption of the MCU sunk on  $V_{SS}$  cannot exceed the absolute maximum rating  $\Sigma I_{VSS}$  (see [Table 11](#)).

### Output voltage levels

Unless otherwise specified, the parameters given in [Table 50](#) are derived from tests performed under ambient temperature and  $V_{DD}$  supply voltage conditions summarized in [Table 13: General operating conditions](#). All I/Os are CMOS and TTL compliant.

**Table 50. Output voltage characteristics for all I/Os except PC13, PC14, PC15 and PI8<sup>(1)</sup>**

| Symbol            | Parameter   | Conditions <sup>(3)</sup>   | Min          | Max | Unit |
|-------------------|---|---|--------------|-----|------|
| $V_{OL}$          | Output low level voltage                                | CMOS port <sup>(2)</sup><br>$I_{IO}=8\text{ mA}$<br>$2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$  | -            | 0.4 | V    |
| $V_{OH}$          | Output high level voltage                               | CMOS port <sup>(2)</sup><br>$I_{IO}=-8\text{ mA}$<br>$2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ | $V_{DD}-0.4$ | -   |      |
| $V_{OL}^{(3)}$    | Output low level voltage                                | TTL port <sup>(2)</sup><br>$I_{IO}=8\text{ mA}$<br>$2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$   | -            | 0.4 |      |
| $V_{OH}^{(3)}$    | Output high level voltage                               | TTL port <sup>(2)</sup><br>$I_{IO}=-8\text{ mA}$<br>$2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$  | 2.4          | -   |      |
| $V_{OL}^{(3)}$    | Output low level voltage                                | $I_{IO}=20\text{ mA}$<br>$2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$                             | -            | 1.3 |      |
| $V_{OH}^{(3)}$    | Output high level voltage                               | $I_{IO}=-20\text{ mA}$<br>$2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$                            | $V_{DD}-1.3$ | -   |      |
| $V_{OL}^{(3)}$    | Output low level voltage                                | $I_{IO}=4\text{ mA}$<br>$1.62\text{ V} \leq V_{DD} \leq 3.6\text{ V}$                             | -            | 0.4 |      |
| $V_{OH}^{(3)}$    | Output high level voltage                               | $I_{IO}=-4\text{ mA}$<br>$1.62\text{ V} \leq V_{DD} < 3.6\text{ V}$                               | $V_{DD}-0.4$ | -   |      |
| $V_{OLFM+}^{(3)}$ | Output low level voltage for an FTf I/O pin in FM+ mode | $I_{IO}=20\text{ mA}$<br>$2.3\text{ V} \leq V_{DD} \leq 3.6\text{ V}$                             | -            | 0.4 |      |
|                   |   | $I_{IO}=10\text{ mA}$<br>$1.62\text{ V} \leq V_{DD} \leq 3.6\text{ V}$                            | -            | 0.4 |      |

- The I/O current sourced or sunk by the device must always respect the absolute maximum rating specified in [Table 10: Voltage characteristics](#), and the sum of the currents sourced or sunk by all the I/Os (I/O ports and control pins) must always respect the absolute maximum ratings  $\Sigma I/O$ .
- TTL and CMOS outputs are compatible with JEDEC standards JESD36 and JESD52.
- Guaranteed by design.

Table 51. Output voltage characteristics for PC13, PC14, PC15 and PI8<sup>(1)</sup>

| Symbol                         | Parameter                 | Conditions <sup>(3)</sup>   | Min                  | Max | Unit |
|--------------------------------|---------------------------|---|----------------------|-----|------|
| V <sub>OL</sub>                | Output low level voltage  | CMOS port <sup>(2)</sup><br>I <sub>IO</sub> =3 mA<br>2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V  | -                    | 0.4 | V    |
| V <sub>OH</sub>                | Output high level voltage | CMOS port <sup>(2)</sup><br>I <sub>IO</sub> =-3 mA<br>2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V | V <sub>DD</sub> -0.4 | -   |      |
| V <sub>OL</sub> <sup>(3)</sup> | Output low level voltage  | TTL port <sup>(2)</sup><br>I <sub>IO</sub> =3 mA<br>2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V   | -                    | 0.4 |      |
| V <sub>OH</sub> <sup>(3)</sup> | Output high level voltage | TTL port <sup>(2)</sup><br>I <sub>IO</sub> =-3 mA<br>2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V  | 2.4                  | -   |      |
| V <sub>OL</sub> <sup>(3)</sup> | Output low level voltage  | I <sub>IO</sub> =1.5 mA<br>1.62 V ≤ V <sub>DD</sub> ≤ 3.6 V                           | -                    | 0.4 |      |
| V <sub>OH</sub> <sup>(3)</sup> | Output high level voltage | I <sub>IO</sub> =-1.5 mA<br>1.62 V ≤ V <sub>DD</sub> ≤ 3.6 V                          | V <sub>DD</sub> -0.4 | -   |      |

1. The I/O current sourced or sunk by the device must always respect the absolute maximum rating specified in [Table 10: Voltage characteristics](#), and the sum of the currents sourced or sunk by all the I/Os (I/O ports and control pins) must always respect the absolute maximum ratings  $\Sigma I/O$ .
2. TTL and CMOS outputs are compatible with JEDEC standards JESD36 and JESD52.
3. Guaranteed by design.

**Output buffer timing characteristics (HSLV option disabled)**

The HSLV bit of SYSCFG\_CCCSR register can be used to optimize the I/O speed when the product voltage is below 2.5 V.

**Table 52. Output timing characteristics (HSLV OFF)<sup>(1)(2)</sup>**

| Speed | Symbol           | Parameter   | conditions                                | Min | Max  | Unit |
|-------|------------------|---|---|-----|------|------|
| 00    | $F_{\max}^{(3)}$ | Maximum frequency   | C=50 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V  | -   | 12   | MHz  |
|       |                  |   | C=50 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V | -   | 3    |      |
|       |                  |   | C=30 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V  | -   | 12   |      |
|       |                  |   | C=30 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V | -   | 3    |      |
|       |                  |   | C=10 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V  | -   | 16   |      |
|       |                  |   | C=10 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V | -   | 4    |      |
|       | $t_r/t_f^{(4)}$  | Output high to low level fall time and output low to high level rise time | C=50 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V  | -   | 16.6 | ns   |
|       |                  |   | C=50 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V | -   | 33.3 |      |
|       |                  |   | C=30 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V  | -   | 13.3 |      |
|       |                  |   | C=30 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V | -   | 25   |      |
|       |                  |   | C=10 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V  | -   | 10   |      |
|       |                  |   | C=10 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V | -   | 20   |      |
| 01    | $F_{\max}^{(3)}$ | Maximum frequency   | C=50 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V  | -   | 60   | MHz  |
|       |                  |   | C=50 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V | -   | 15   |      |
|       |                  |   | C=30 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V  | -   | 80   |      |
|       |                  |   | C=30 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V | -   | 15   |      |
|       |                  |   | C=10 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V  | -   | 110  |      |
|       |                  |   | C=10 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V | -   | 20   |      |
|       | $t_r/t_f^{(4)}$  | Output high to low level fall time and output low to high level rise time | C=50 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V  | -   | 5.2  | ns   |
|       |                  |   | C=50 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V | -   | 10   |      |
|       |                  |   | C=30 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V  | -   | 4.2  |      |
|       |                  |   | C=30 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V | -   | 7.5  |      |
|       |                  |   | C=10 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V  | -   | 2.8  |      |
|       |                  |   | C=10 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V | -   | 5.2  |      |

Table 52. Output timing characteristics (HSLV OFF)<sup>(1)(2)</sup> (continued)

| Speed | Symbol           | Parameter   | conditions   | Min | Max | Unit |
|-------|------------------|---|--|-----|-----|------|
| 10    | $F_{\max}^{(3)}$ | Maximum frequency   | C=50 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V <sup>(5)</sup>  | -   | 85  | MHz  |
|       |                  |   | C=50 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(5)</sup> | -   | 35  |      |
|       |                  |   | C=30 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V <sup>(5)</sup>  | -   | 110 |      |
|       |                  |   | C=30 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(5)</sup> | -   | 40  |      |
|       |                  |   | C=10 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V <sup>(5)</sup>  | -   | 166 |      |
|       |                  |   | C=10 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(5)</sup> | -   | 85  |      |
|       | $t_r/t_f^{(4)}$  | Output high to low level fall time and output low to high level rise time | C=50 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V <sup>(5)</sup>  | -   | 3.8 | ns   |
|       |                  |   | C=50 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(5)</sup> | -   | 6.9 |      |
|       |                  |   | C=30 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V <sup>(5)</sup>  | -   | 2.8 |      |
|       |                  |   | C=30 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(5)</sup> | -   | 5.2 |      |
|       |                  |   | C=10 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V <sup>(5)</sup>  | -   | 1.8 |      |
|       |                  |   | C=10 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(5)</sup> | -   | 3.3 |      |
| 11    | $F_{\max}^{(3)}$ | Maximum frequency   | C=50 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V <sup>(5)</sup>  | -   | 100 | MHz  |
|       |                  |   | C=50 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(5)</sup> | -   | 50  |      |
|       |                  |   | C=30 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V <sup>(5)</sup>  | -   | 133 |      |
|       |                  |   | C=30 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(5)</sup> | -   | 66  |      |
|       |                  |   | C=10 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V <sup>(5)</sup>  | -   | 220 |      |
|       |                  |   | C=10 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(5)</sup> | -   | 100 |      |
|       | $t_r/t_f^{(4)}$  | Output high to low level fall time and output low to high level rise time | C=50 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V <sup>(5)</sup>  | -   | 3.3 | ns   |
|       |                  |   | C=50 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(5)</sup> | -   | 6.6 |      |
|       |                  |   | C=30 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V <sup>(5)</sup>  | -   | 2.4 |      |
|       |                  |   | C=30 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(5)</sup> | -   | 4.5 |      |
|       |                  |   | C=10 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V <sup>(5)</sup>  | -   | 1.5 |      |
|       |                  |   | C=10 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(5)</sup> | -   | 2.7 |      |

- Guaranteed by design.
- The frequency of the GPIOs that can be supplied in V<sub>BAT</sub> mode (PC13, PC14, PC15 and PI8) is limited to 2 MHz
- The maximum frequency is defined with the following conditions:  
 $(t_r + t_f) \leq 2/3 T$   
Skew ≤ 1/20 T  
45% < Duty cycle < 55%
- The fall and rise times are defined between 90% and 10% and between 10% and 90% of the output waveform, respectively.
- Compensation system enabled.

## Output buffer timing characteristics (HSLV option enabled)

Table 53. Output timing characteristics (HSLV ON)<sup>(1)</sup>

| Speed | Symbol  | Parameter   | conditions   | Min | Max | Unit |
|-------|---|---|--|-----|-----|------|
| 00    | F <sub>max</sub> <sup>(2)</sup>               | Maximum frequency   | C=50 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V                | -   | 10  | MHz  |
|       |   |   | C=30 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V                | -   | 10  |      |
|       |   |   | C=10 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V                | -   | 10  |      |
|       | t <sub>r</sub> /t <sub>f</sub> <sup>(3)</sup> | Output high to low level fall time and output low to high level rise time | C=50 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V                | -   | 11  | ns   |
|       |   |   | C=30 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V                | -   | 9   |      |
|       |   |   | C=10 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V                | -   | 6.6 |      |
| 01    | F <sub>max</sub> <sup>(2)</sup>               | Maximum frequency   | C=50 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V                | -   | 50  | MHz  |
|       |   |   | C=30 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V                | -   | 58  |      |
|       |   |   | C=10 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V                | -   | 66  |      |
|       | t <sub>r</sub> /t <sub>f</sub> <sup>(3)</sup> | Output high to low level fall time and output low to high level rise time | C=50 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V                | -   | 6.6 | ns   |
|       |   |   | C=30 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V                | -   | 4.8 |      |
|       |   |   | C=10 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V                | -   | 3   |      |
| 10    | F <sub>max</sub> <sup>(2)</sup>               | Maximum frequency   | C=50 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(4)</sup> | -   | 55  | MHz  |
|       |   |   | C=30 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(4)</sup> | -   | 80  |      |
|       |   |   | C=10 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(4)</sup> | -   | 133 |      |
|       | t <sub>r</sub> /t <sub>f</sub> <sup>(3)</sup> | Output high to low level fall time and output low to high level rise time | C=50 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(4)</sup> | -   | 5.8 | ns   |
|       |   |   | C=30 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(4)</sup> | -   | 4   |      |
|       |   |   | C=10 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(4)</sup> | -   | 2.4 |      |
| 11    | F <sub>max</sub> <sup>(2)</sup>               | Maximum frequency   | C=50 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(4)</sup> | -   | 60  | MHz  |
|       |   |   | C=30 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(4)</sup> | -   | 90  |      |
|       |   |   | C=10 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(4)</sup> | -   | 175 |      |
|       | t <sub>r</sub> /t <sub>f</sub> <sup>(3)</sup> | Output high to low level fall time and output low to high level rise time | C=50 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(4)</sup> | -   | 5.3 | ns   |
|       |   |   | C=30 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(4)</sup> | -   | 3.6 |      |
|       |   |   | C=10 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(4)</sup> | -   | 1.9 |      |

1. Guaranteed by design.

2. The maximum frequency is defined with the following conditions:  
 $(t_r + t_f) \leq 2/3 T$   
 Skew  $\leq 1/20 T$   
 $45\% < \text{Duty cycle} < 55\%$

3. The fall and rise times are defined between 90% and 10% and between 10% and 90% of the output waveform, respectively.

4. Compensation system enabled.

### 6.3.16 NRST pin characteristics

The NRST pin input driver uses CMOS technology. It is connected to a permanent pull-up resistor,  $R_{PU}$  (see [Table 49: I/O static characteristics](#)).

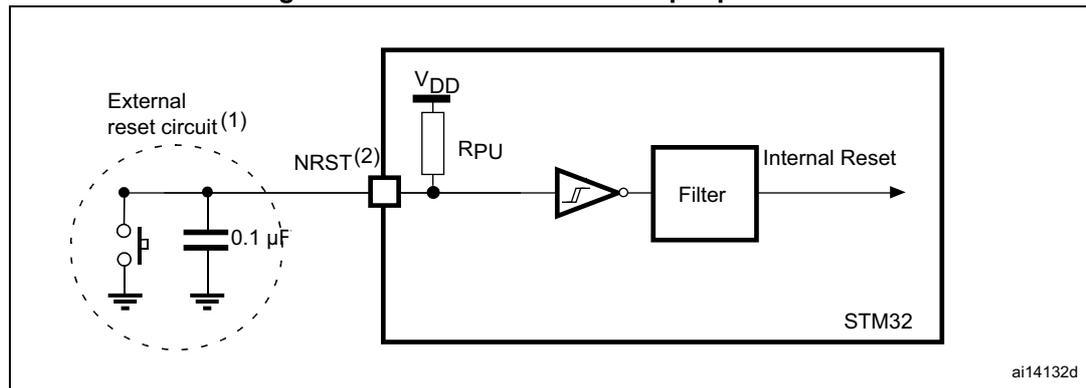
Unless otherwise specified, the parameters given in [Table 54](#) are derived from tests performed under the ambient temperature and  $V_{DD}$  supply voltage conditions summarized in [Table 13: General operating conditions](#).

**Table 54. NRST pin characteristics**

| Symbol               | Parameter                                       | Conditions                              | Min  | Typ | Max | Unit       |
|----------------------|---|---|------|-----|-----|------------|
| $R_{PU}^{(2)}$       | Weak pull-up equivalent resistor <sup>(1)</sup> | $V_{IN} = V_{SS}$                       | 30   | 40  | 50  | k $\Omega$ |
| $V_{F(NRST)}^{(2)}$  | NRST Input filtered pulse                       | $1.71\text{ V} < V_{DD} < 3.6\text{ V}$ | -    | -   | 50  | ns         |
| $V_{NF(NRST)}^{(2)}$ | NRST Input not filtered pulse                   | $1.71\text{ V} < V_{DD} < 3.6\text{ V}$ | 300  | -   | -   |            |
|                      |   | $1.62\text{ V} < V_{DD} < 3.6\text{ V}$ | 1000 | -   | -   |            |

1. The pull-up is designed with a true resistance in series with a switchable PMOS. This PMOS contribution to the series resistance must be minimum (~10% order).
2. Guaranteed by design.

**Figure 22. Recommended NRST pin protection**



1. The reset network protects the device against parasitic resets.
2. The user must ensure that the level on the NRST pin can go below the  $V_{IL(NRST)}$  max level specified in [Table 49](#). Otherwise the reset is not taken into account by the device.

### 6.3.17 FMC characteristics

Unless otherwise specified, the parameters given in [Table 55](#) to [Table 68](#) for the FMC interface are derived from tests performed under the ambient temperature,  $f_{\text{rcc\_c\_ck}}$  frequency and  $V_{\text{DD}}$  supply voltage conditions summarized in [Table 13: General operating conditions](#), with the following configuration:

- Output speed is set to  $\text{OSPEEDRy}[1:0] = 11$
- Measurement points are done at CMOS levels:  $0.5V_{\text{DD}}$

Refer to [Section 6.3.15: I/O port characteristics](#) for more details on the input/output characteristics.

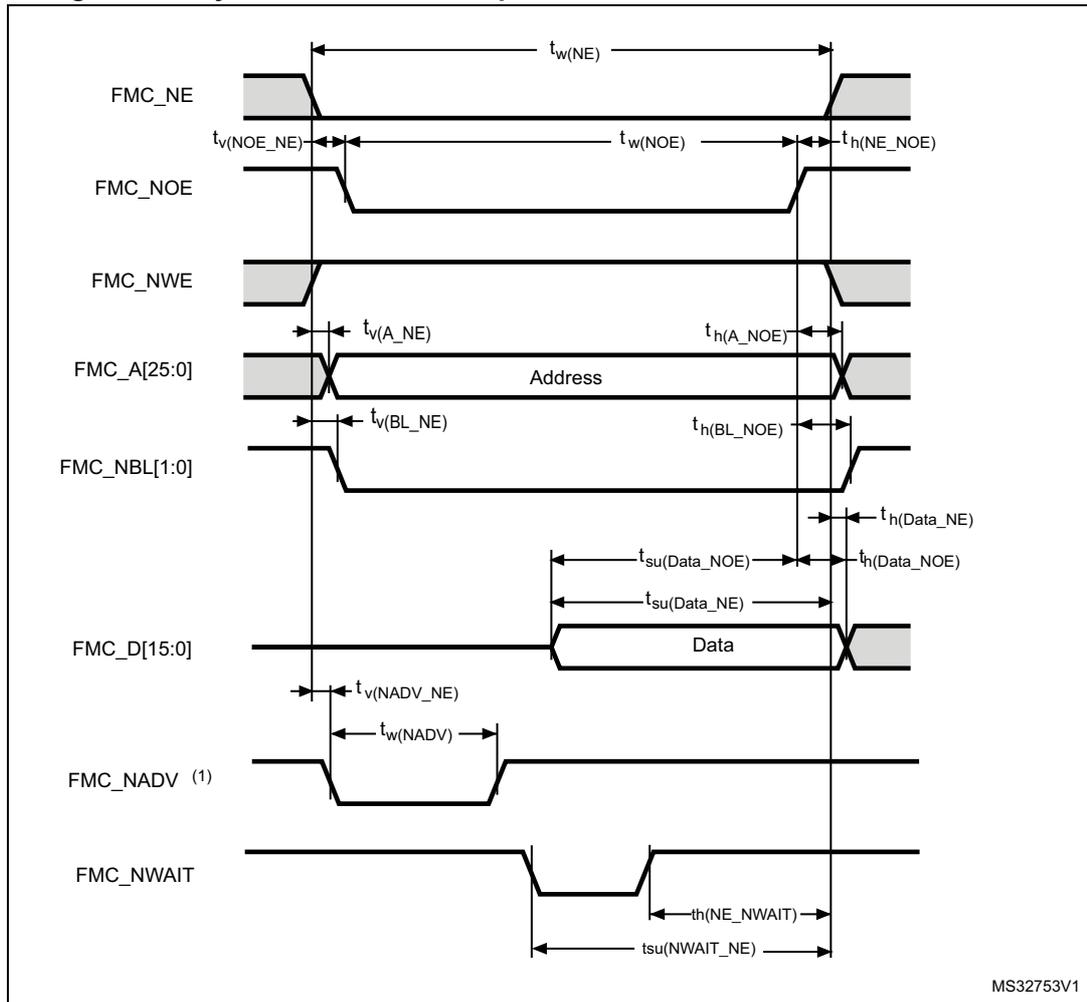
#### Asynchronous waveforms and timings

[Figure 23](#) through [Figure 26](#) represent asynchronous waveforms and [Table 55](#) through [Table 62](#) provide the corresponding timings. The results shown in these tables are obtained with the following FMC configuration:

- AddressSetupTime = 0x1
- AddressHoldTime = 0x1
- DataSetupTime = 0x1 (except for asynchronous NWAIT mode, DataSetupTime = 0x5)
- BusTurnAroundDuration = 0x0
- Capacitive load  $C_L = 30 \text{ pF}$

In all timing tables, the  $T_{\text{KERCK}}$  is the  $f_{\text{mc\_ker\_ck}}$  clock period.

Figure 23. Asynchronous non-multiplexed SRAM/PSRAM/NOR read waveforms



1. Mode 2/B, C and D only. In Mode 1, FMC\_NADV is not used.

**Table 55. Asynchronous non-multiplexed SRAM/PSRAM/NOR read timings<sup>(1)</sup>**

| Symbol              | Parameter                             | Min                     | Max                      | Unit |
|---------------------|---------------------------------------|-------------------------|--------------------------|------|
| $t_{w(NE)}$         | FMC_NE low time                       | $2T_{fmc\_ker\_ck} - 1$ | $2 T_{fmc\_ker\_ck} + 1$ | ns   |
| $t_{v(NOE\_NE)}$    | FMC_NEx low to FMC_NOE low            | 0                       | 0.5                      |      |
| $t_{w(NOE)}$        | FMC_NOE low time                      | $2T_{fmc\_ker\_ck} - 1$ | $2T_{fmc\_ker\_ck} + 1$  |      |
| $t_{h(NE\_NOE)}$    | FMC_NOE high to FMC_NE high hold time | 0                       | -                        |      |
| $t_{v(A\_NE)}$      | FMC_NEx low to FMC_A valid            | -                       | 0.5                      |      |
| $t_{h(A\_NOE)}$     | Address hold time after FMC_NOE high  | 0                       | -                        |      |
| $t_{v(BL\_NE)}$     | FMC_NEx low to FMC_BL valid           | -                       | 0.5                      |      |
| $t_{h(BL\_NOE)}$    | FMC_BL hold time after FMC_NOE high   | 0                       | -                        |      |
| $t_{su(Data\_NE)}$  | Data to FMC_NEx high setup time       | 11                      | -                        |      |
| $t_{su(Data\_NOE)}$ | Data to FMC_NOEx high setup time      | 11                      | -                        |      |
| $t_{h(Data\_NOE)}$  | Data hold time after FMC_NOE high     | 0                       | -                        |      |
| $t_{h(Data\_NE)}$   | Data hold time after FMC_NEx high     | 0                       | -                        |      |
| $t_{v(NADV\_NE)}$   | FMC_NEx low to FMC_NADV low           | -                       | 0                        |      |
| $t_{w(NADV)}$       | FMC_NADV low time                     | -                       | $T_{fmc\_ker\_ck} + 1$   |      |

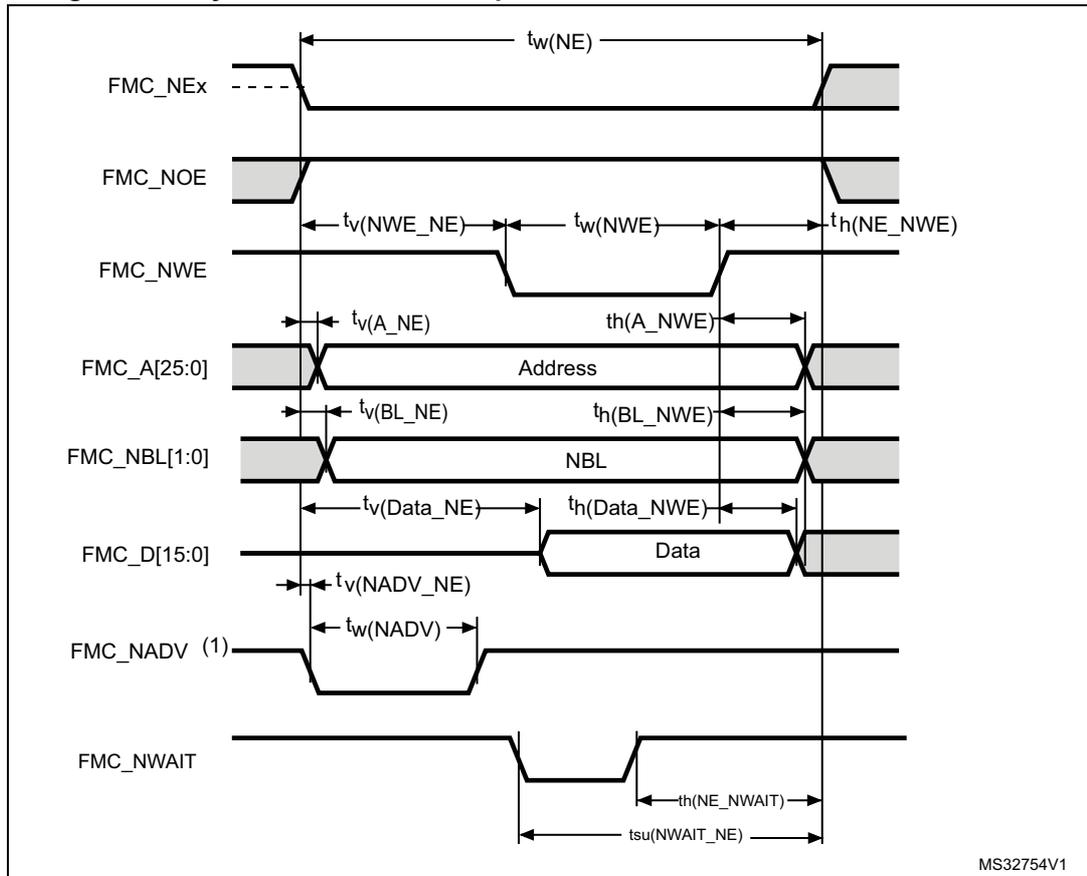
1. Guaranteed by characterization results.

**Table 56. Asynchronous non-multiplexed SRAM/PSRAM/NOR read - NWAIT timings<sup>(1)(2)</sup>**

| Symbol              | Parameter                                 | Min                        | Max                     | Unit |
|---------------------|---|----------------------------|-------------------------|------|
| $t_{w(NE)}$         | FMC_NE low time                           | $7T_{fmc\_ker\_ck} + 1$    | $7T_{fmc\_ker\_ck} + 1$ | ns   |
| $t_{w(NOE)}$        | FMC_NWE low time                          | $5T_{fmc\_ker\_ck} - 1$    | $5T_{fmc\_ker\_ck} + 1$ |      |
| $t_{w(NWAIT)}$      | FMC_NWAIT low time                        | $T_{fmc\_ker\_ck} - 0.5$   | -                       |      |
| $t_{su(NWAIT\_NE)}$ | FMC_NWAIT valid before FMC_NEx high       | $4T_{fmc\_ker\_ck} + 11$   | -                       |      |
| $t_{h(NE\_NWAIT)}$  | FMC_NEx hold time after FMC_NWAIT invalid | $3T_{fmc\_ker\_ck} + 11.5$ | -                       |      |

1. Guaranteed by characterization results.
2.  $N_{WAIT}$  pulse width is equal to 1 AHB cycle.

Figure 24. Asynchronous non-multiplexed SRAM/PSRAM/NOR write waveforms



1. Mode 2/B, C and D only. In Mode 1, FMC\_NADV is not used.

Table 57. Asynchronous non-multiplexed SRAM/PSRAM/NOR write timings<sup>(1)</sup>

| Symbol             | Parameter                             | Min                      | Max                      | Unit |
|--------------------|---------------------------------------|--------------------------|--------------------------|------|
| $t_{w(NE)}$        | FMC_NE low time                       | $3T_{fmc\_ker\_ck} - 1$  | $3T_{fmc\_ker\_ck}$      | ns   |
| $t_{v(NWE\_NE)}$   | FMC_NEx low to FMC_NWE low            | $T_{fmc\_ker\_ck}$       | $T_{fmc\_ker\_ck} + 1$   |      |
| $t_{w(NWE)}$       | FMC_NWE low time                      | $T_{fmc\_ker\_ck} - 0.5$ | $T_{fmc\_ker\_ck} + 0.5$ |      |
| $t_{h(NE\_NWE)}$   | FMC_NWE high to FMC_NE high hold time | $T_{fmc\_ker\_ck}$       | -                        |      |
| $t_{v(A\_NE)}$     | FMC_NEx low to FMC_A valid            | -                        | 2                        |      |
| $t_{h(A\_NWE)}$    | Address hold time after FMC_NWE high  | $T_{fmc\_ker\_ck} - 0.5$ | -                        |      |
| $t_{v(BL\_NE)}$    | FMC_NEx low to FMC_BL valid           | -                        | 0.5                      |      |
| $t_{h(BL\_NWE)}$   | FMC_BL hold time after FMC_NWE high   | $T_{fmc\_ker\_ck} - 0.5$ | -                        |      |
| $t_{v(Data\_NE)}$  | Data to FMC_NEx low to Data valid     | -                        | $T_{fmc\_ker\_ck} + 2.5$ |      |
| $t_{h(Data\_NWE)}$ | Data hold time after FMC_NWE high     | $T_{fmc\_ker\_ck} + 0.5$ | -                        |      |
| $t_{v(NADV\_NE)}$  | FMC_NEx low to FMC_NADV low           | -                        | 0                        |      |
| $t_{w(NADV)}$      | FMC_NADV low time                     | -                        | $T_{fmc\_ker\_ck} + 1$   |      |

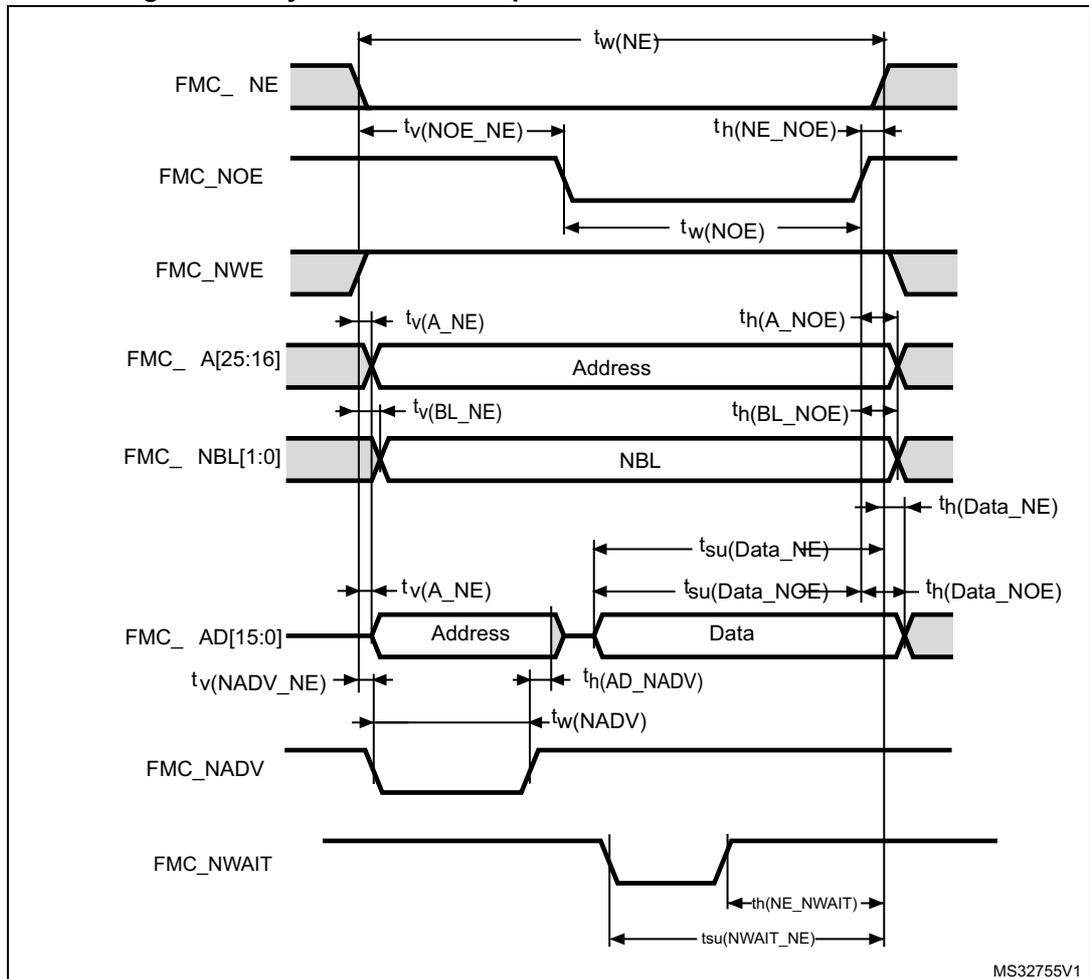
1. Guaranteed by characterization results.

**Table 58. Asynchronous non-multiplexed SRAM/PSRAM/NOR write - NWAIT timings<sup>(1)(2)</sup>**

| Symbol              | Parameter                                 | Min                       | Max                       | Unit |
|---------------------|---|---------------------------|---------------------------|------|
| $t_{w(NE)}$         | FMC_NE low time                           | $8T_{fmc\_ker\_ck} - 1$   | $8T_{fmc\_ker\_ck} + 1$   | ns   |
| $t_{w(NWE)}$        | FMC_NWE low time                          | $6T_{fmc\_ker\_ck} - 1.5$ | $6T_{fmc\_ker\_ck} + 0.5$ |      |
| $t_{su(NWAIT\_NE)}$ | FMC_NWAIT valid before FMC_NEx high       | $5T_{fmc\_ker\_ck} + 13$  | -                         |      |
| $t_{h(NE\_NWAIT)}$  | FMC_NEx hold time after FMC_NWAIT invalid | $4T_{fmc\_ker\_ck} + 13$  | -                         |      |

1. Guaranteed by characterization results.
2.  $N_{WAIT}$  pulse width is equal to 1 AHB cycle.

**Figure 25. Asynchronous multiplexed PSRAM/NOR read waveforms**



**Table 59. Asynchronous multiplexed PSRAM/NOR read timings<sup>(1)</sup>**

| Symbol              | Parameter   | Min                      | Max                       | Unit |
|---------------------|---|--------------------------|---------------------------|------|
| $t_{w(NE)}$         | FMC_NE low time                                     | $3T_{fmc\_ker\_ck} - 1$  | $3T_{fmc\_ker\_ck} + 1$   | ns   |
| $t_{v(NO\_NE)}$     | FMC_NEx low to FMC_NOE low                          | $2T_{fmc\_ker\_ck}$      | $2T_{fmc\_ker\_ck} + 0.5$ |      |
| $t_{tw(NO\_E)}$     | FMC_NOE low time                                    | $T_{fmc\_ker\_ck} - 1$   | $T_{fmc\_ker\_ck} + 1$    |      |
| $t_{h(NE\_NOE)}$    | FMC_NOE high to FMC_NE high hold time               | 0                        | -                         |      |
| $t_{v(A\_NE)}$      | FMC_NEx low to FMC_A valid                          | -                        | 0.5                       |      |
| $t_{v(NADV\_NE)}$   | FMC_NEx low to FMC_NADV low                         | 0                        | 0.5                       |      |
| $t_{w(NADV)}$       | FMC_NADV low time                                   | $T_{fmc\_ker\_ck} - 0.5$ | $T_{fmc\_ker\_ck} + 1$    |      |
| $t_{h(AD\_NADV)}$   | FMC_AD(address) valid hold time after FMC_NADV high | $T_{fmc\_ker\_ck} + 0.5$ | -                         |      |
| $t_{h(A\_NOE)}$     | Address hold time after FMC_NOE high                | $T_{fmc\_ker\_ck} - 0.5$ | -                         |      |
| $t_{h(BL\_NOE)}$    | FMC_BL time after FMC_NOE high                      | 0                        | -                         |      |
| $t_{v(BL\_NE)}$     | FMC_NEx low to FMC_BL valid                         | -                        | 0.5                       |      |
| $t_{su(Data\_NE)}$  | Data to FMC_NEx high setup time                     | $T_{fmc\_ker\_ck} - 2$   | -                         |      |
| $t_{su(Data\_NOE)}$ | Data to FMC_NOE high setup time                     | $T_{fmc\_ker\_ck} - 2$   | -                         |      |
| $t_{h(Data\_NE)}$   | Data hold time after FMC_NEx high                   | 0                        | -                         |      |
| $t_{h(Data\_NOE)}$  | Data hold time after FMC_NOE high                   | 0                        | -                         |      |

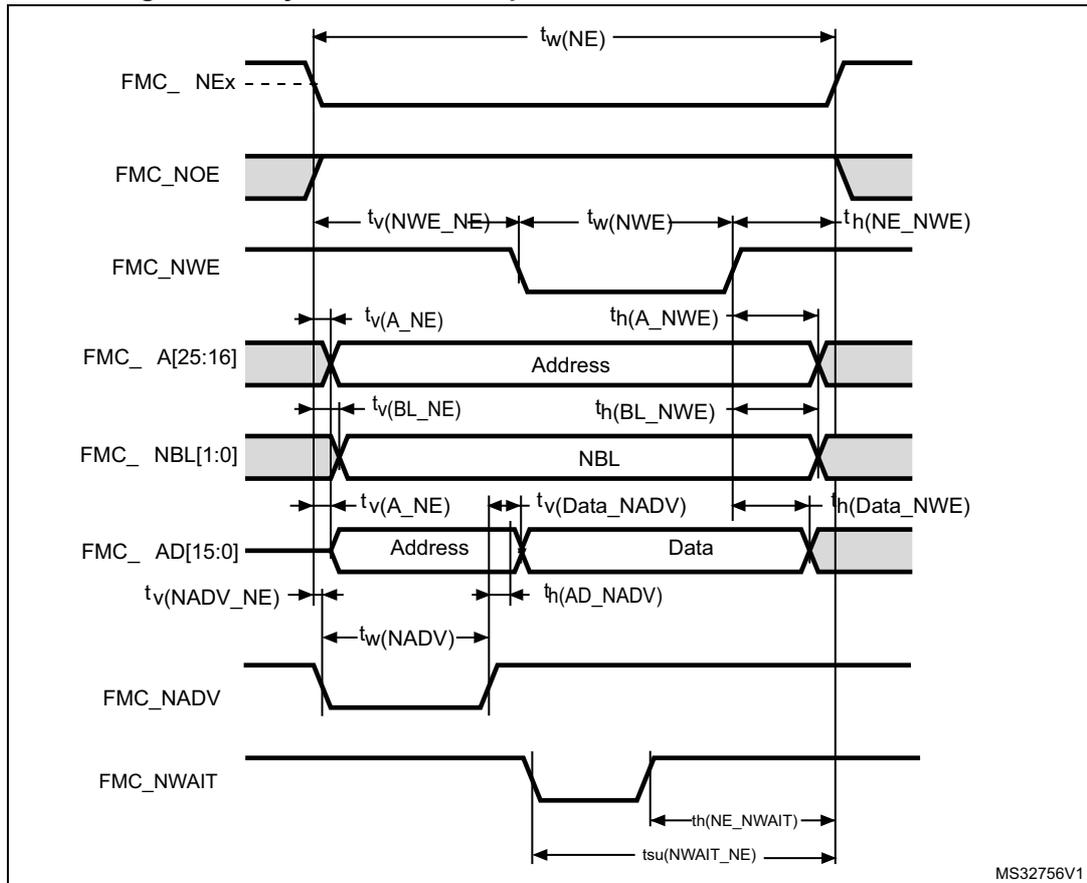
1. Guaranteed by characterization results.

**Table 60. Asynchronous multiplexed PSRAM/NOR read-NWAIT timings<sup>(1)</sup>**

| Symbol              | Parameter                                 | Min                       | Max                       | Unit |
|---------------------|---|---------------------------|---------------------------|------|
| $t_{w(NE)}$         | FMC_NE low time                           | $8T_{fmc\_ker\_ck} - 1$   | $8T_{fmc\_ker\_ck}$       | ns   |
| $t_{w(NO\_E)}$      | FMC_NWE low time                          | $5T_{fmc\_ker\_ck} - 1.5$ | $5T_{fmc\_ker\_ck} + 0.5$ |      |
| $t_{su(NWAIT\_NE)}$ | FMC_NWAIT valid before FMC_NEx high       | $5T_{fmc\_ker\_ck} + 3$   | -                         |      |
| $t_{h(NE\_NWAIT)}$  | FMC_NEx hold time after FMC_NWAIT invalid | $4T_{fmc\_ker\_ck}$       | -                         |      |

1. Guaranteed by characterization results.

Figure 26. Asynchronous multiplexed PSRAM/NOR write waveforms



MS32756V1

Table 61. Asynchronous multiplexed PSRAM/NOR write timings<sup>(1)</sup>

| Symbol              | Parameter   | Min                       | Max                       | Unit |
|---------------------|---|---------------------------|---------------------------|------|
| $t_{w(NE)}$         | FMC_NE low time                                     | $4T_{fmc\_ker\_c} - 1$    | $4T_{fmc\_ker\_ck}$       | ns   |
| $t_{v(NWE\_NE)}$    | FMC_NEx low to FMC_NWE low                          | $T_{fmc\_ker\_c} - 1$     | $T_{fmc\_ker\_ck} + 0.5$  |      |
| $t_{w(NWE)}$        | FMC_NWE low time                                    | $2T_{fmc\_ker\_ck} - 0.5$ | $2T_{fmc\_ker\_ck} + 0.5$ |      |
| $t_{h(NE\_NWE)}$    | FMC_NWE high to FMC_NE high hold time               | $T_{fmc\_ker\_ck} - 0.5$  | -                         |      |
| $t_{v(A\_NE)}$      | FMC_NEx low to FMC_A valid                          | -                         | 0                         |      |
| $t_{v(NADV\_NE)}$   | FMC_NEx low to FMC_NADV low                         | 0                         | 0.5                       |      |
| $t_{w(NADV)}$       | FMC_NADV low time                                   | $T_{fmc\_ker\_ck}$        | $T_{fmc\_ker\_ck} + 1$    |      |
| $t_{h(AD\_NADV)}$   | FMC_AD(address) valid hold time after FMC_NADV high | $T_{fmc\_ker\_ck} + 0.5$  | -                         |      |
| $t_{h(A\_NWE)}$     | Address hold time after FMC_NWE high                | $T_{fmc\_ker\_ck} + 0.5$  | -                         |      |
| $t_{h(BL\_NWE)}$    | FMC_BL hold time after FMC_NWE high                 | $T_{fmc\_ker\_ck} - 0.5$  | -                         |      |
| $t_{v(BL\_NE)}$     | FMC_NEx low to FMC_BL valid                         | -                         | 0.5                       |      |
| $t_{v(Data\_NADV)}$ | FMC_NADV high to Data valid                         | -                         | $T_{fmc\_ker\_ck} + 2$    |      |
| $t_{h(Data\_NWE)}$  | Data hold time after FMC_NWE high                   | $T_{fmc\_ker\_ck} + 0.5$  | -                         |      |

1. Guaranteed by characterization results.

**Table 62. Asynchronous multiplexed PSRAM/NOR write-NWAIT timings<sup>(1)</sup>**

| Symbol              | Parameter                                 | Min                       | Max                       | Unit |
|---------------------|---|---------------------------|---------------------------|------|
| $t_{w(NE)}$         | FMC_NE low time                           | $9T_{fmc\_ker\_ck} - 1$   | $9T_{fmc\_ker\_ck}$       | ns   |
| $t_{w(NWE)}$        | FMC_NWE low time                          | $7T_{fmc\_ker\_ck} - 0.5$ | $7T_{fmc\_ker\_ck} + 0.5$ |      |
| $t_{su(NWAIT\_NE)}$ | FMC_NWAIT valid before FMC_NEx high       | $6T_{fmc\_ker\_ck} + 3$   | -                         |      |
| $t_{h(NE\_NWAIT)}$  | FMC_NEx hold time after FMC_NWAIT invalid | $4T_{fmc\_ker\_ck}$       | -                         |      |

1. Guaranteed by characterization results.

**Synchronous waveforms and timings**

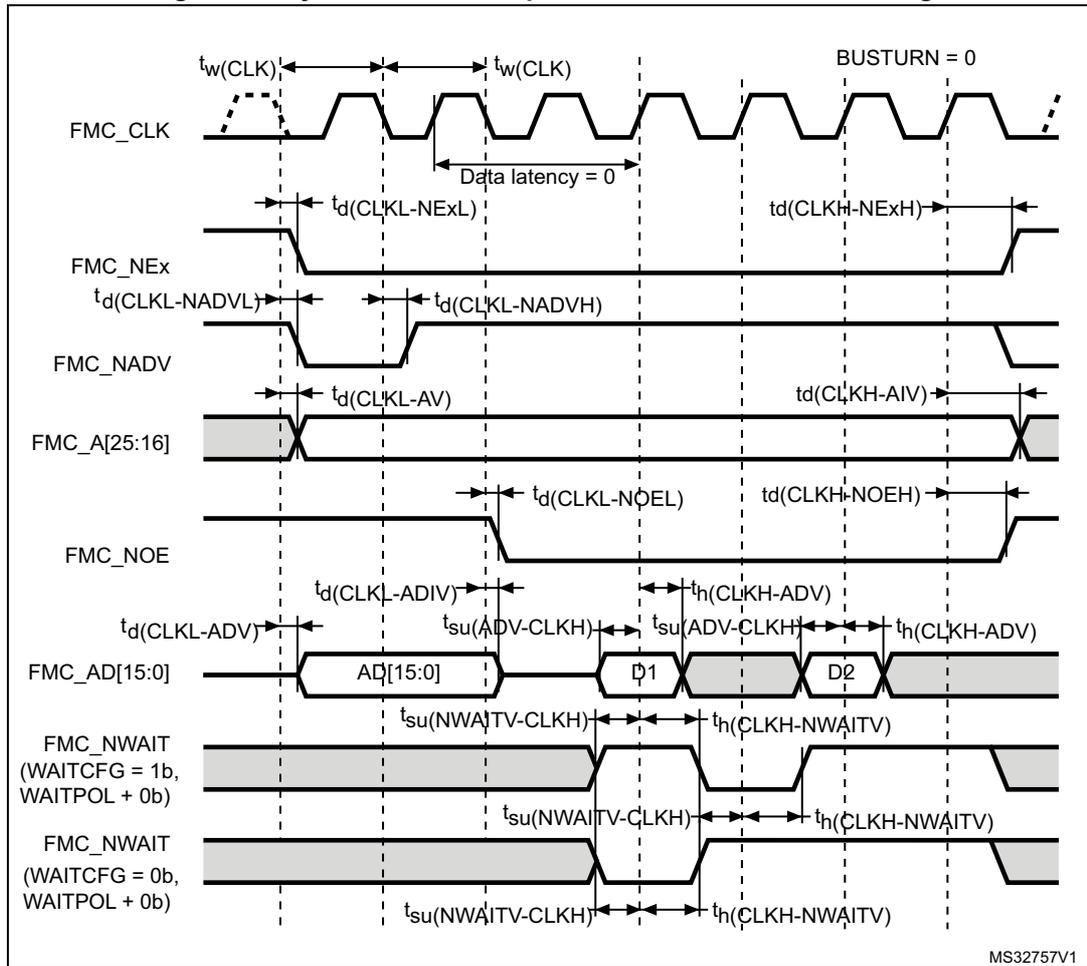
Figure 27 through Figure 30 represent synchronous waveforms and Table 63 through Table 66 provide the corresponding timings. The results shown in these tables are obtained with the following FMC configuration:

- BurstAccessMode = FMC\_BurstAccessMode\_Enable
- MemoryType = FMC\_MemoryType\_CRAM
- WriteBurst = FMC\_WriteBurst\_Enable
- CLKDivision = 1
- DataLatency = 1 for NOR flash; DataLatency = 0 for PSRAM

In all the timing tables, the  $T_{fmc\_ker\_ck}$  is the  $f_{fmc\_ker\_ck}$  clock period, with the following FMC\_CLK maximum values:

- For  $2.7\text{ V} < V_{DD} < 3.6\text{ V}$ , FMC\_CLK = 100 MHz at 20 pF
- For  $1.8\text{ V} < V_{DD} < 1.9\text{ V}$ , FMC\_CLK = 100 MHz at 20 pF
- For  $1.62\text{ V} < V_{DD} < 1.8\text{ V}$ , FMC\_CLK = 100 MHz at 15 pF

Figure 27. Synchronous multiplexed NOR/PSRAM read timings

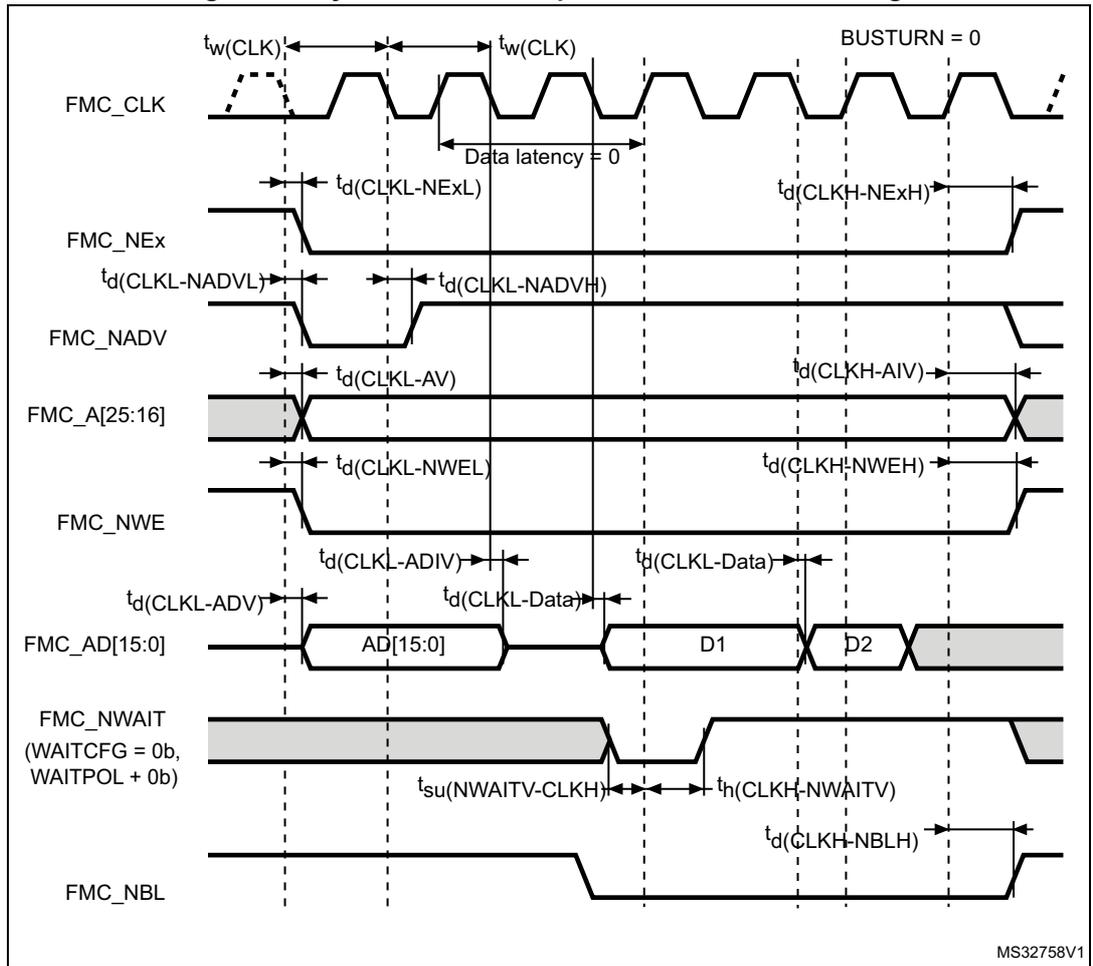


**Table 63. Synchronous multiplexed NOR/PSRAM read timings<sup>(1)</sup>**

| Symbol               | Parameter                                    | Min                      | Max | Unit |
|----------------------|--|--------------------------|-----|------|
| $t_{w(CLK)}$         | FMC_CLK period                               | $2T_{fmc\_ker\_ck} - 1$  | -   | ns   |
| $t_{d(CLKL-NEXL)}$   | FMC_CLK low to FMC_NEx low (x=0..2)          | -                        | 1   |      |
| $t_{d(CLKH-NEXH)}$   | FMC_CLK high to FMC_NEx high (x= 0...2)      | $T_{fmc\_ker\_ck} + 0.5$ | -   |      |
| $t_{d(CLKL-NADVL)}$  | FMC_CLK low to FMC_NADV low                  | -                        | 1.  |      |
| $t_{d(CLKL-NADVH)}$  | FMC_CLK low to FMC_NADV high                 | 0                        | -   |      |
| $t_{d(CLKL-AV)}$     | FMC_CLK low to FMC_Ax valid (x=16...25)      | -                        | 2.5 |      |
| $t_{d(CLKH-AIV)}$    | FMC_CLK high to FMC_Ax invalid (x=16...25)   | $T_{fmc\_ker\_ck}$       | -   |      |
| $t_{d(CLKL-NOEL)}$   | FMC_CLK low to FMC_NOE low                   | -                        | 1.5 |      |
| $t_{d(CLKH-NOEH)}$   | FMC_CLK high to FMC_NOE high                 | $T_{fmc\_ker\_ck} - 0.5$ | -   |      |
| $t_{d(CLKL-ADV)}$    | FMC_CLK low to FMC_AD[15:0] valid            | -                        | 3   |      |
| $t_{d(CLKL-ADIV)}$   | FMC_CLK low to FMC_AD[15:0] invalid          | 0                        | -   |      |
| $t_{su(ADV-CLKH)}$   | FMC_A/D[15:0] valid data before FMC_CLK high | 3                        | -   |      |
| $t_h(CLKH-ADV)$      | FMC_A/D[15:0] valid data after FMC_CLK high  | 0                        | -   |      |
| $t_{su(NWAIT-CLKH)}$ | FMC_NWAIT valid before FMC_CLK high          | 3                        | -   |      |
| $t_h(CLKH-NWAIT)$    | FMC_NWAIT valid after FMC_CLK high           | 1                        | -   |      |

1. Guaranteed by characterization results.

Figure 28. Synchronous multiplexed PSRAM write timings



**Table 64. Synchronous multiplexed PSRAM write timings<sup>(1)</sup>**

| Symbol               | Parameter                                  | Min                      | Max | Unit |
|----------------------|--|--------------------------|-----|------|
| $t_{w(CLK)}$         | FMC_CLK period                             | $2T_{fmc\_ker\_ck} - 1$  | -   | ns   |
| $t_{d(CLKL-NExL)}$   | FMC_CLK low to FMC_NEx low (x=0..2)        | -                        | 1   |      |
| $t_{d(CLKH-NExH)}$   | FMC_CLK high to FMC_NEx high (x= 0...2)    | $T_{fmc\_ker\_ck} + 0.5$ | -   |      |
| $t_{d(CLKL-NADV L)}$ | FMC_CLK low to FMC_NADV low                | -                        | 1.5 |      |
| $t_{d(CLKL-NADV H)}$ | FMC_CLK low to FMC_NADV high               | 0                        | -   |      |
| $t_{d(CLKL-AV)}$     | FMC_CLK low to FMC_Ax valid (x=16...25)    | -                        | 2   |      |
| $t_{d(CLKH-AIV)}$    | FMC_CLK high to FMC_Ax invalid (x=16...25) | $T_{fmc\_ker\_ck}$       | -   |      |
| $t_{d(CLKL-NWEL)}$   | FMC_CLK low to FMC_NWE low                 | -                        | 1.5 |      |
| $t_{d(CLKH-NWEH)}$   | FMC_CLK high to FMC_NWE high               | $T_{fmc\_ker\_ck} + 0.5$ | -   |      |
| $t_{d(CLKL-ADV)}$    | FMC_CLK low to FMC_AD[15:0] valid          | -                        | 2.5 |      |
| $t_{d(CLKL-ADIV)}$   | FMC_CLK low to FMC_AD[15:0] invalid        | 0                        | -   |      |
| $t_{d(CLKL-DATA)}$   | FMC_A/D[15:0] valid data after FMC_CLK low | -                        | 2.5 |      |
| $t_{d(CLKL-NBLL)}$   | FMC_CLK low to FMC_NBL low                 | -                        | 2   |      |
| $t_{d(CLKH-NBLH)}$   | FMC_CLK high to FMC_NBL high               | $T_{fmc\_ker\_ck} + 0.5$ | -   |      |
| $t_{su(NWAIT-CLKH)}$ | FMC_NWAIT valid before FMC_CLK high        | 2                        | -   |      |
| $t_{h(CLKH-NWAIT)}$  | FMC_NWAIT valid after FMC_CLK high         | 2                        | -   |      |

1. Guaranteed by characterization results.

Figure 29. Synchronous non-multiplexed NOR/PSRAM read timings

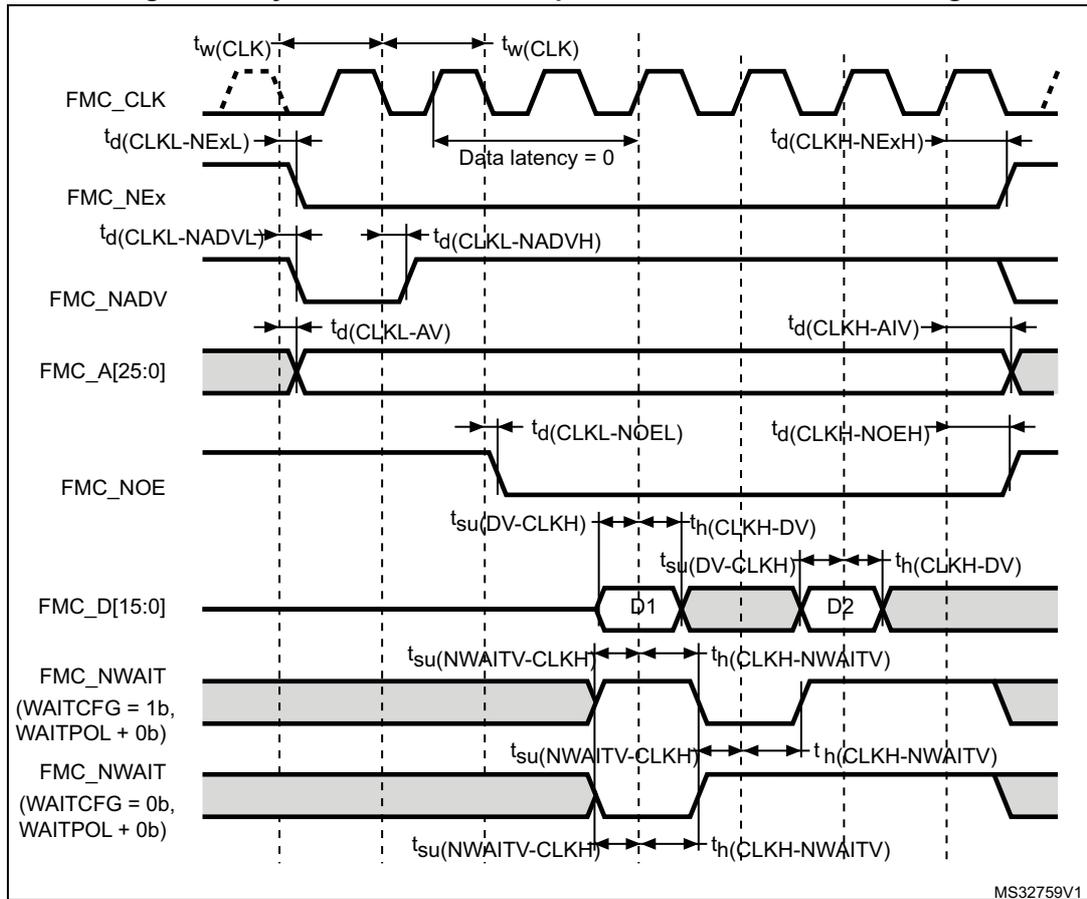


Table 65. Synchronous non-multiplexed NOR/PSRAM read timings<sup>(1)</sup>

| Symbol                              | Parameter                                  | Min                             | Max | Unit |
|-------------------------------------|--|---------------------------------|-----|------|
| $t_w(\text{CLK})$                   | FMC_CLK period                             | $2T_{\text{fmc\_ker\_ck}} - 1$  | -   | ns   |
| $t_{\text{d}}(\text{CLKL-NExL})$    | FMC_CLK low to FMC_NEx low (x=0..2)        | -                               | 2   |      |
| $t_{\text{d}}(\text{CLKH-NExH})$    | FMC_CLK high to FMC_NEx high (x= 0...2)    | $T_{\text{fmc\_ker\_ck}} + 0.5$ | -   |      |
| $t_{\text{d}}(\text{CLKL-NADV})$    | FMC_CLK low to FMC_NADV low                | -                               | 0.5 |      |
| $t_{\text{d}}(\text{CLKL-NADVH})$   | FMC_CLK low to FMC_NADV high               | 0                               | -   |      |
| $t_{\text{d}}(\text{CLKL-AV})$      | FMC_CLK low to FMC_Ax valid (x=16...25)    | -                               | 2   |      |
| $t_{\text{d}}(\text{CLKH-AIV})$     | FMC_CLK high to FMC_Ax invalid (x=16...25) | $T_{\text{fmc\_ker\_ck}}$       | -   |      |
| $t_{\text{d}}(\text{CLKL-NOEL})$    | FMC_CLK low to FMC_NOE low                 | -                               | 1.5 |      |
| $t_{\text{d}}(\text{CLKH-NOEH})$    | FMC_CLK high to FMC_NOE high               | $T_{\text{fmc\_ker\_ck}} + 0.5$ | -   |      |
| $t_{\text{su}}(\text{DV-CLKH})$     | FMC_D[15:0] valid data before FMC_CLK high | 3                               | -   |      |
| $t_{\text{h}}(\text{CLKH-DV})$      | FMC_D[15:0] valid data after FMC_CLK high  | 0                               | -   |      |
| $t_{\text{su}}(\text{NWAITV-CLKH})$ | FMC_NWAIT valid before FMC_CLK high        | 3                               | -   |      |
| $t_{\text{h}}(\text{CLKH-NWAIT})$   | FMC_NWAIT valid after FMC_CLK high         | 1                               | -   |      |

1. Guaranteed by characterization results.

Figure 30. Synchronous non-multiplexed PSRAM write timings

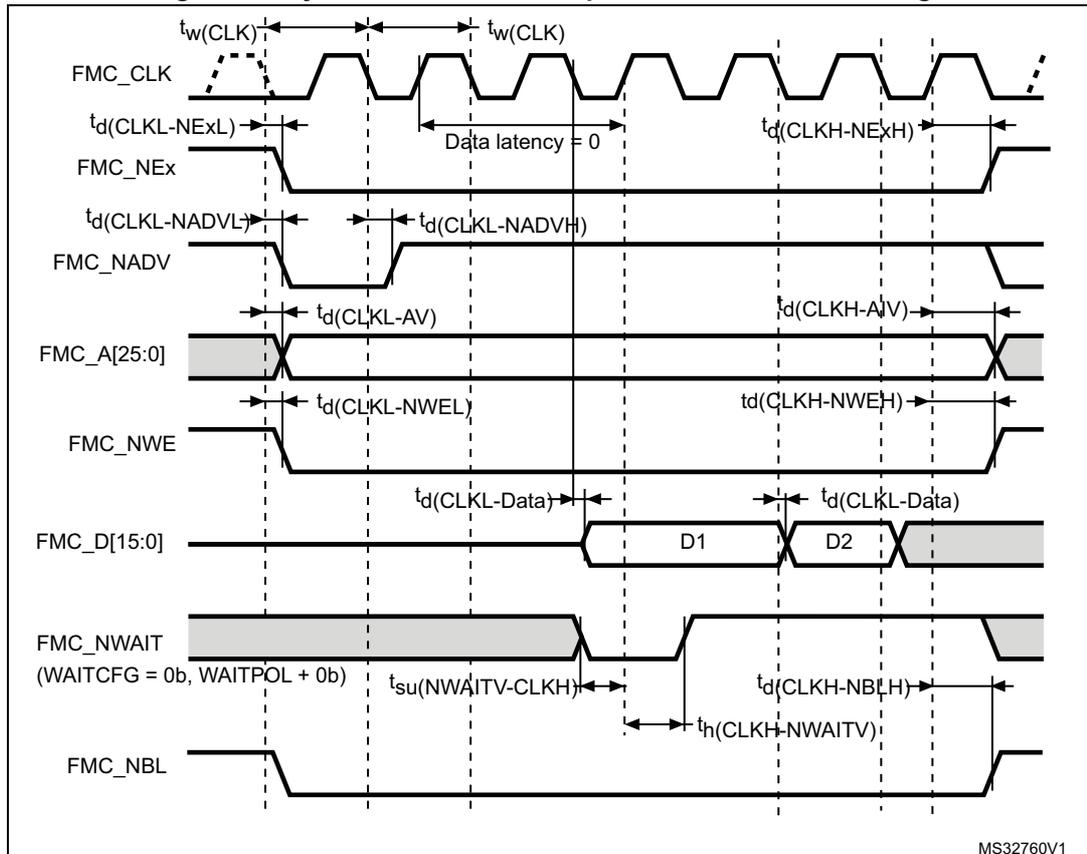


Table 66. Synchronous non-multiplexed PSRAM write timings<sup>(1)</sup>

| Symbol                | Parameter                                  | Min                      | Max | Unit |
|-----------------------|--|--------------------------|-----|------|
| $t_{(CLK)}$           | FMC_CLK period                             | $2T_{fmc\_ker\_ck} - 1$  | -   | ns   |
| $t_{d(CLKL-NExL)}$    | FMC_CLK low to FMC_NEx low (x=0..2)        | -                        | 2   |      |
| $t_{(CLKH-NExH)}$     | FMC_CLK high to FMC_NEx high (x= 0...2)    | $T_{fmc\_ker\_ck} + 0.5$ | -   |      |
| $t_{d(CLKL-NADV)}$    | FMC_CLK low to FMC_NADV low                | -                        | 0.5 |      |
| $t_{d(CLKL-NADVH)}$   | FMC_CLK low to FMC_NADV high               | 0                        | -   |      |
| $t_{d(CLKL-AV)}$      | FMC_CLK low to FMC_Ax valid (x=16...25)    | -                        | 2   |      |
| $t_{d(CLKH-AIV)}$     | FMC_CLK high to FMC_Ax invalid (x=16...25) | $T_{fmc\_ker\_ck}$       | -   |      |
| $t_{d(CLKL-NWEL)}$    | FMC_CLK low to FMC_NWE low                 | -                        | 1.5 |      |
| $t_{d(CLKH-NWEH)}$    | FMC_CLK high to FMC_NWE high               | $T_{fmc\_ker\_ck} + 1$   | -   |      |
| $t_{d(CLKL-Data)}$    | FMC_D[15:0] valid data after FMC_CLK low   | -                        | 3.5 |      |
| $t_{d(CLKL-NBL)}$     | FMC_CLK low to FMC_NBL low                 | -                        | 2   |      |
| $t_{d(CLKH-NBLH)}$    | FMC_CLK high to FMC_NBL high               | $T_{fmc\_ker\_ck} + 1$   | -   |      |
| $t_{su(NWAITV-CLKH)}$ | FMC_NWAIT valid before FMC_CLK high        | 2                        | -   |      |
| $t_{h(CLKH-NWAIT)}$   | FMC_NWAIT valid after FMC_CLK high         | 2                        | -   |      |

1. Guaranteed by characterization results.

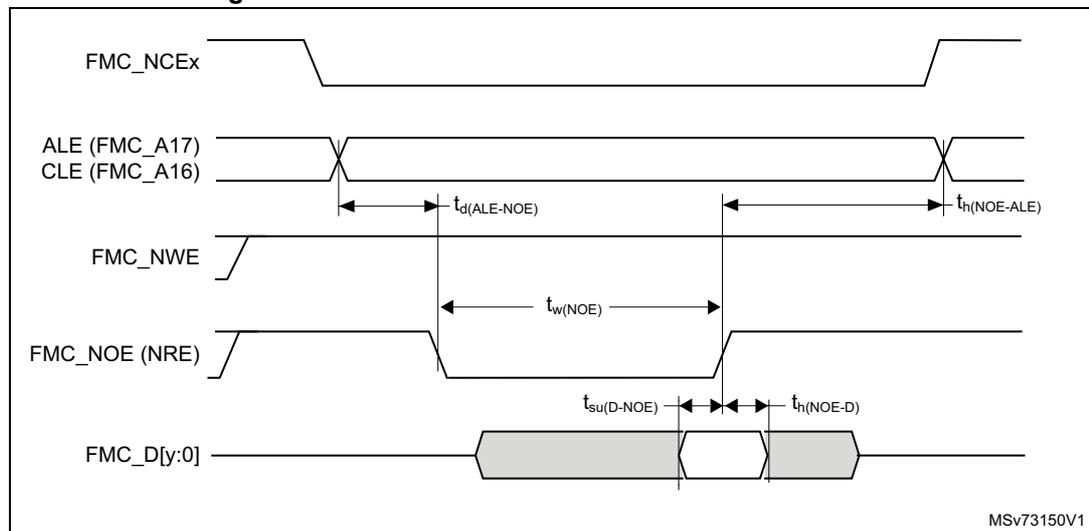
**NAND controller waveforms and timings**

Figure 31 and Figure 32 represent synchronous waveforms, and Table 67 and Table 68 provide the corresponding timings. The results shown in this table are obtained with the following FMC configuration:

- COM.FMC\_SetupTime = 0x01
- COM.FMC\_WaitSetupTime = 0x03
- COM.FMC\_HoldSetupTime = 0x02
- COM.FMC\_HiZSetupTime = 0x01
- ATT.FMC\_SetupTime = 0x01
- ATT.FMC\_WaitSetupTime = 0x03
- ATT.FMC\_HoldSetupTime = 0x02
- ATT.FMC\_HiZSetupTime = 0x01
- Bank = FMC\_Bank\_NAND
- MemoryDataWidth = FMC\_MemoryDataWidth\_16b
- ECC = FMC\_ECC\_Enable
- ECCPageSize = FMC\_ECCPageSize\_512Bytes
- TCLRSetupTime = 0
- TARSetupTime = 0
- $C_L = 30 \text{ pF}$

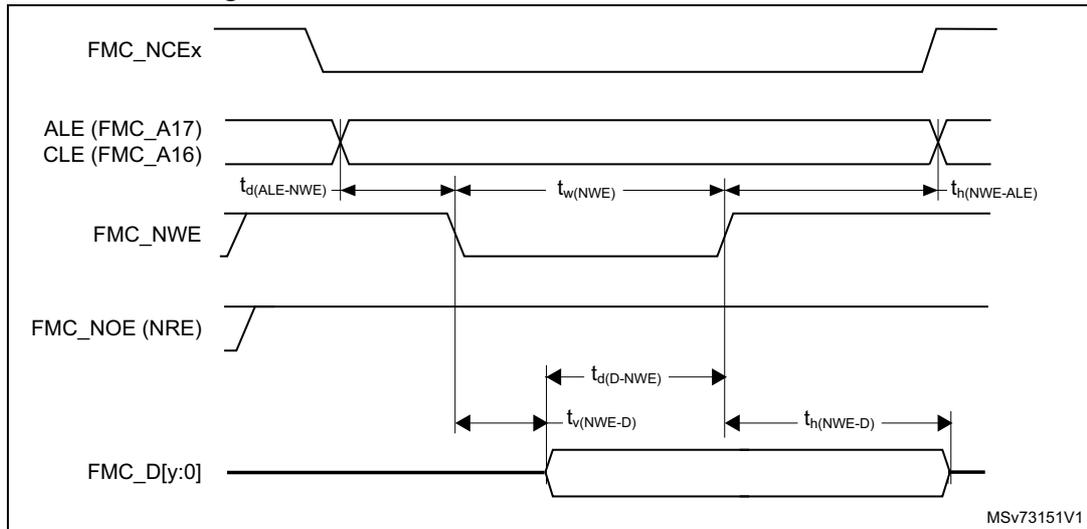
In all timing tables, the  $T_{fmc\_ker\_ck}$  is the `fmc_ker_ck` clock period.

**Figure 31. NAND controller waveforms for read access**



1.  $y=7$  or  $15$  depending on the NAND flash memory interface.

Figure 32. NAND controller waveforms for write access



1. y=7 or 15 depending on the NAND flash memory interface.

Table 67. Switching characteristics for NAND flash read cycles<sup>(1)</sup>

| Symbol          | Parameter                                  | Min                       | Max                       | Unit |
|-----------------|--|---------------------------|---------------------------|------|
| $t_w(NOE)$      | FMC_NOE low width                          | $4T_{fmc\_ker\_ck} - 0.5$ | $4T_{fmc\_ker\_ck} + 0.5$ | ns   |
| $t_{su}(D-NOE)$ | FMC_D[15-0] valid data before FMC_NOE high | 8                         | -                         |      |
| $t_h(NOE-D)$    | FMC_D[15-0] valid data after FMC_NOE high  | 0                         | -                         |      |
| $t_d(ALE-NOE)$  | FMC_ALE valid before FMC_NOE low           | -                         | $3T_{fmc\_ker\_ck} + 1$   |      |
| $t_h(NOE-ALE)$  | FMC_NWE high to FMC_ALE invalid            | $4T_{fmc\_ker\_ck} - 2$   | -                         |      |

1. Guaranteed by characterization results.

Table 68. Switching characteristics for NAND flash write cycles<sup>(1)</sup>

| Symbol         | Parameter                             | Min                       | Max                       | Unit |
|----------------|---------------------------------------|---------------------------|---------------------------|------|
| $t_w(NWE)$     | FMC_NWE low width                     | $4T_{fmc\_ker\_ck} - 0.5$ | $4T_{fmc\_ker\_ck} + 0.5$ | ns   |
| $t_v(NWE-D)$   | FMC_NWE low to FMC_D[15-0] valid      | 0                         | -                         |      |
| $t_h(NWE-D)$   | FMC_NWE high to FMC_D[15-0] invalid   | $2T_{fmc\_ker\_ck} - 0.5$ | -                         |      |
| $t_d(D-NWE)$   | FMC_D[15-0] valid before FMC_NWE high | $5T_{fmc\_ker\_ck} - 1$   | -                         |      |
| $t_d(ALE-NWE)$ | FMC_ALE valid before FMC_NWE low      | -                         | $3T_{fmc\_ker\_ck} + 0.5$ |      |
| $t_h(NWE-ALE)$ | FMC_NWE high to FMC_ALE invalid       | $2T_{fmc\_ker\_ck} - 1$   | -                         |      |

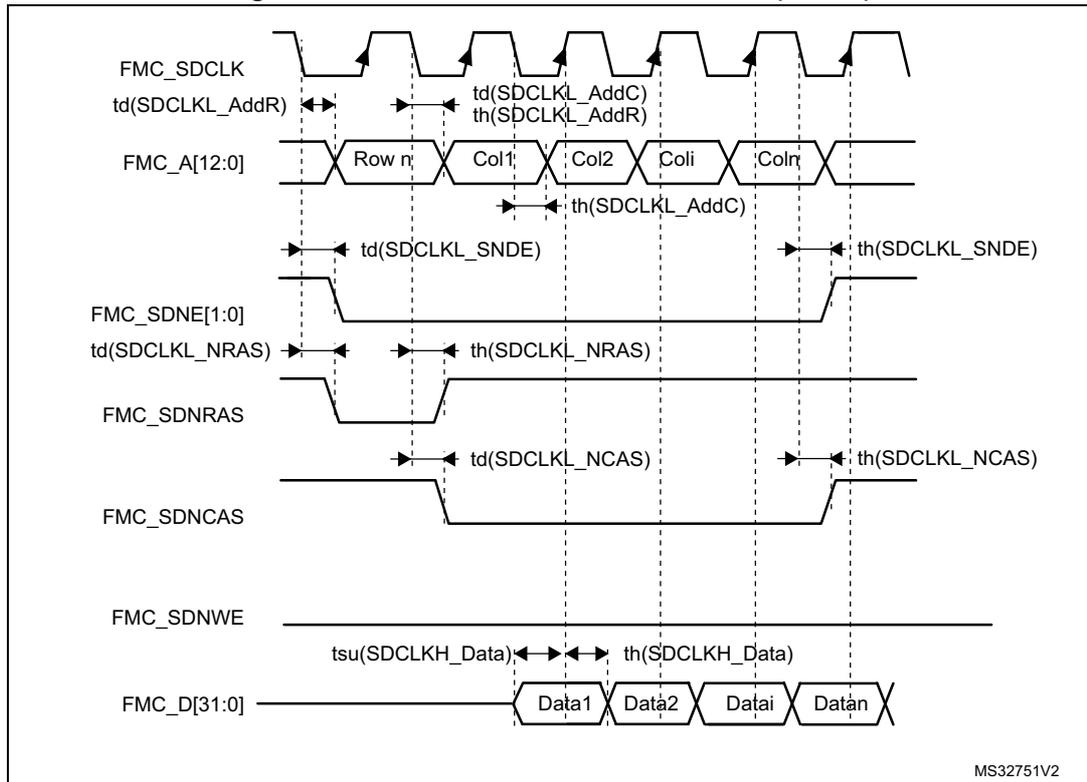
1. Guaranteed by characterization results.

**SDRAM waveforms and timings**

In all timing tables, the  $T_{fmc\_ker\_ck}$  is the  $fmc\_ker\_ck$  clock period, with the following FMC\_SDCLK maximum values:

- For  $1.8\text{ V} < V_{DD} < 3.6\text{ V}$ : FMC\_SDCLK = 100 MHz at 20 pF
- For  $1.62\text{ V} < V_{DD} < 1.8\text{ V}$ , FMC\_SDCLK = 100 MHz at 15 pF

Figure 33. SDRAM read access waveforms (CL = 1)



MS32751V2

Table 69. SDRAM read timings<sup>(1)</sup>

| Symbol                        | Parameter              | Min                     | Max                       | Unit |
|-------------------------------|------------------------|-------------------------|---------------------------|------|
| $t_w(\text{SDCLK})$           | FMC_SDCLK period       | $2T_{fmc\_ker\_ck} - 1$ | $2T_{fmc\_ker\_ck} + 0.5$ | ns   |
| $t_{su}(\text{SDCLKH\_Data})$ | Data input setup time  | 3                       | -                         |      |
| $t_h(\text{SDCLKH\_Data})$    | Data input hold time   | 0                       | -                         |      |
| $t_d(\text{SDCLKL\_Add})$     | Address valid time     | -                       | 1.5                       |      |
| $t_d(\text{SDCLKL\_SDNE})$    | Chip select valid time | -                       | 1.5                       |      |
| $t_h(\text{SDCLKL\_SDNE})$    | Chip select hold time  | 0.5                     | -                         |      |
| $t_d(\text{SDCLKL\_SDNRAS})$  | SDNRAS valid time      | -                       | 1                         |      |
| $t_h(\text{SDCLKL\_SDNRAS})$  | SDNRAS hold time       | 0.5                     | -                         |      |
| $t_d(\text{SDCLKL\_SDNCAS})$  | SDNCAS valid time      | -                       | 0.5                       |      |
| $t_h(\text{SDCLKL\_SDNCAS})$  | SDNCAS hold time       | 0                       | -                         |      |

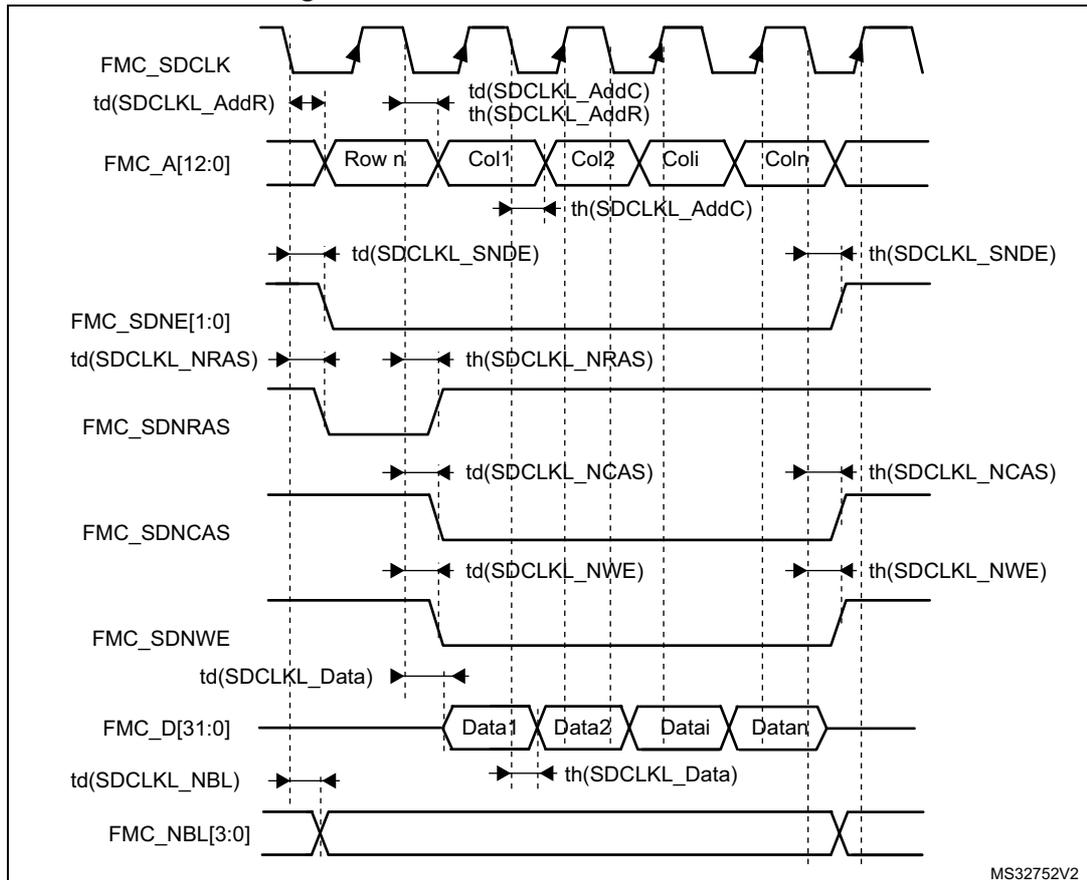
1. Guaranteed by characterization results.

Table 70. LPSDR SDRAM read timings<sup>(1)</sup>

| Symbol                 | Parameter              | Min                     | Max                       | Unit |
|------------------------|------------------------|-------------------------|---------------------------|------|
| $t_{W(SDCLK)}$         | FMC_SDCLK period       | $2T_{fmc\_ker\_ck} - 1$ | $2T_{fmc\_ker\_ck} + 0.5$ | ns   |
| $t_{su(SDCLKH\_Data)}$ | Data input setup time  | 3                       | -                         |      |
| $t_{h(SDCLKH\_Data)}$  | Data input hold time   | 0.5                     | -                         |      |
| $t_d(SDCLKL\_Add)$     | Address valid time     | -                       | 2.5                       |      |
| $t_d(SDCLKL\_SDNE)$    | Chip select valid time | -                       | 2.5                       |      |
| $t_h(SDCLKL\_SDNE)$    | Chip select hold time  | 0                       | -                         |      |
| $t_d(SDCLKL\_SDNRAS)$  | SDNRAS valid time      | -                       | 0.5                       |      |
| $t_h(SDCLKL\_SDNRAS)$  | SDNRAS hold time       | 0                       | -                         |      |
| $t_d(SDCLKL\_SDNCAS)$  | SDNCAS valid time      | -                       | 1.5                       |      |
| $t_h(SDCLKL\_SDNCAS)$  | SDNCAS hold time       | 0                       | -                         |      |

1. Guaranteed by characterization results.

Figure 34. SDRAM write access waveforms



MS32752V2

Table 71. SDRAM write timings<sup>(1)</sup>

| Symbol                       | Parameter              | Min                            | Max                              | Unit |
|------------------------------|------------------------|--------------------------------|----------------------------------|------|
| $t_w(\text{SDCLK})$          | FMC_SDCLK period       | $2T_{\text{fmc\_ker\_ck}} - 1$ | $2T_{\text{fmc\_ker\_ck}} + 0.5$ | ns   |
| $t_d(\text{SDCLKL\_Data})$   | Data output valid time | -                              | 3                                |      |
| $t_h(\text{SDCLKL\_Data})$   | Data output hold time  | 0                              | -                                |      |
| $t_d(\text{SDCLKL\_Add})$    | Address valid time     | -                              | 1.5                              |      |
| $t_d(\text{SDCLKL\_SDNWE})$  | SDNWE valid time       | -                              | 1.5                              |      |
| $t_h(\text{SDCLKL\_SDNWE})$  | SDNWE hold time        | 0.5                            | -                                |      |
| $t_d(\text{SDCLKL\_SDNE})$   | Chip select valid time | -                              | 1.5                              |      |
| $t_h(\text{SDCLKL\_SDNE})$   | Chip select hold time  | 0.5                            | -                                |      |
| $t_d(\text{SDCLKL\_SDNRAS})$ | SDNRAS valid time      | -                              | 1                                |      |
| $t_h(\text{SDCLKL\_SDNRAS})$ | SDNRAS hold time       | 0.5                            | -                                |      |
| $t_d(\text{SDCLKL\_SDNCAS})$ | SDNCAS valid time      | -                              | 1                                |      |
| $t_d(\text{SDCLKL\_SDNCAS})$ | SDNCAS hold time       | 0.5                            | -                                |      |

1. Guaranteed by characterization results.

Table 72. LPDDR SDRAM write timings<sup>(1)</sup>

| Symbol                      | Parameter              | Min                            | Max                              | Unit |
|-----------------------------|------------------------|--------------------------------|----------------------------------|------|
| $t_w(\text{SDCLK})$         | FMC_SDCLK period       | $2T_{\text{fmc\_ker\_ck}} - 1$ | $2T_{\text{fmc\_ker\_ck}} + 0.5$ | ns   |
| $t_d(\text{SDCLKL\_Data})$  | Data output valid time | -                              | 2.5                              |      |
| $t_h(\text{SDCLKL\_Data})$  | Data output hold time  | 0                              | -                                |      |
| $t_d(\text{SDCLKL\_Add})$   | Address valid time     | -                              | 2.5                              |      |
| $t_d(\text{SDCLKL-SDNWE})$  | SDNWE valid time       | -                              | 2.5                              |      |
| $t_h(\text{SDCLKL-SDNWE})$  | SDNWE hold time        | 0                              | -                                |      |
| $t_d(\text{SDCLKL-SDNE})$   | Chip select valid time | -                              | 3                                |      |
| $t_h(\text{SDCLKL-SDNE})$   | Chip select hold time  | 0                              | -                                |      |
| $t_d(\text{SDCLKL-SDNRAS})$ | SDNRAS valid time      | -                              | 1.5                              |      |
| $t_h(\text{SDCLKL-SDNRAS})$ | SDNRAS hold time       | 0                              | -                                |      |
| $t_d(\text{SDCLKL-SDNCAS})$ | SDNCAS valid time      | -                              | 1.5                              |      |
| $t_d(\text{SDCLKL-SDNCAS})$ | SDNCAS hold time       | 0                              | -                                |      |

1. Guaranteed by characterization results.

### 6.3.18 Quad-SPI interface characteristics

Unless otherwise specified, the parameters given in [Table 73](#) and [Table 74](#) for QUADSPI are derived from tests performed under the ambient temperature,  $f_{\text{rcc\_c\_ck}}$  frequency and  $V_{\text{DD}}$  supply voltage conditions summarized in [Table 13: General operating conditions](#), with the following configuration:

- Output speed is set to OSPEEDRy[1:0] = 11
- Measurement points are done at CMOS levels:  $0.5V_{\text{DD}}$
- I/O compensation cell enabled
- HSLV activated when  $V_{\text{DD}} \leq 2.7 \text{ V}$

Refer to [Section 6.3.15: I/O port characteristics](#) for more details on the input/output alternate function characteristics.

**Table 73. QUADSPI characteristics in SDR mode<sup>(1)</sup>**

| Symbol               | Parameter                       | Conditions  | Min                     | Typ | Max                     | Unit |
|----------------------|---------------------------------|---|-------------------------|-----|-------------------------|------|
| Fck1/T <sub>CK</sub> | QUADSPI clock frequency         | $2.7 \text{ V} \leq V_{\text{DD}} < 3.6 \text{ V}$<br>$C_L = 20 \text{ pF}$ | -                       | -   | 133                     | MHz  |
|                      |                                 | $1.62 \text{ V} < V_{\text{DD}} < 3.6 \text{ V}$<br>$C_L = 15 \text{ pF}$   | -                       | -   | 100                     |      |
| t <sub>w(CKH)</sub>  | QUADSPI clock high and low time | -   | $T_{\text{CK}}/2 - 0.5$ | -   | $T_{\text{CK}}/2$       | ns   |
| t <sub>w(CKL)</sub>  |                                 |   | $T_{\text{CK}}/2$       | -   | $T_{\text{CK}}/2 + 0.5$ |      |
| t <sub>s(IN)</sub>   | Data input setup time           | $2.7 \text{ V} \leq V_{\text{DD}} < 3.6 \text{ V}$                          | 2                       | -   | -                       |      |
|                      |                                 | $1.62 \text{ V} \leq V_{\text{DD}} < 3.6 \text{ V}$                         | 2.5                     | -   | -                       |      |
| t <sub>h(IN)</sub>   | Data input hold time            | $2.7 \text{ V} \leq V_{\text{DD}} < 3.6 \text{ V}$                          | 1                       | -   | -                       |      |
|                      |                                 | $1.62 \text{ V} \leq V_{\text{DD}} < 3.6 \text{ V}$                         | 1.5                     | -   | -                       |      |
| t <sub>v(OUT)</sub>  | Data output valid time          | -   | -                       | 1.5 | 2                       |      |
| t <sub>h(OUT)</sub>  | Data output hold time           | -   | 0.5                     | -   | -                       |      |

1. Guaranteed by characterization results.

Table 74. QUADSPI characteristics in DDR mode<sup>(1)</sup>

| Symbol                                      | Parameter                       | Conditions                                   | Min                      | Typ                      | Max                      | Unit |
|---|---------------------------------|--|--------------------------|--------------------------|--------------------------|------|
| F <sub>ck1/t(CK)</sub>                      | QUADSPI clock frequency         | 2.7 V < V <sub>DD</sub> < 3.6 V<br>CL=20 pF  | -                        | -                        | 100                      | MHz  |
|   |                                 | 1.62 V < V <sub>DD</sub> < 3.6 V<br>CL=15 pF | -                        | -                        | 100                      |      |
| t <sub>w(CKH)</sub>                         | QUADSPI clock high and low time | -  | T <sub>CK</sub> /2 - 0.5 | -                        | T <sub>CK</sub> /2       | ns   |
| t <sub>w(CKL)</sub>                         |                                 |  | T <sub>CK</sub> /2       | -                        | T <sub>CK</sub> /2 + 0.5 |      |
| t <sub>sr(IN)</sub> , t <sub>sf(IN)</sub>   | Data input setup time           | 2.7 V ≤ V <sub>DD</sub> < 3.6 V              | 3                        | -                        | -                        |      |
|   |                                 | 1.62 V ≤ V <sub>DD</sub> < 3.6 V             | 1                        | -                        | -                        |      |
| t <sub>hr(IN)</sub> , t <sub>hf(IN)</sub>   | Data input hold time            | 2.7 V ≤ V <sub>DD</sub> < 3.6 V              | 1                        | -                        | -                        |      |
|   |                                 | 1.62 V ≤ V <sub>DD</sub> < 3.6 V             | 1.5                      | -                        | -                        |      |
| t <sub>vr(OUT)</sub> , t <sub>vf(OUT)</sub> | Data output valid time          | DHHC=0                                       | -                        | 3.5                      | 4                        |      |
|   |                                 | DHHC=1<br>Pres=1, 2...                       | -                        | T <sub>CK</sub> /4 + 3.5 | T <sub>CK</sub> /4 + 4   |      |
| t <sub>hr(OUT)</sub> , t <sub>hf(OUT)</sub> | Data output hold time           | DHHC=0                                       | 3                        | -                        | -                        |      |
|   |                                 | DHHC=1<br>Pres=1, 2...                       | T <sub>CK</sub> /4 + 3   | -                        | -                        |      |

1. Guaranteed by characterization results.

Figure 35. Quad-SPI timing diagram - SDR mode

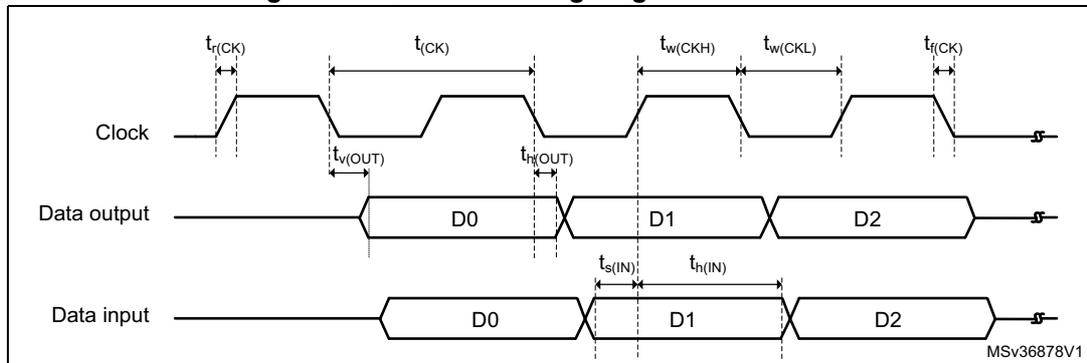
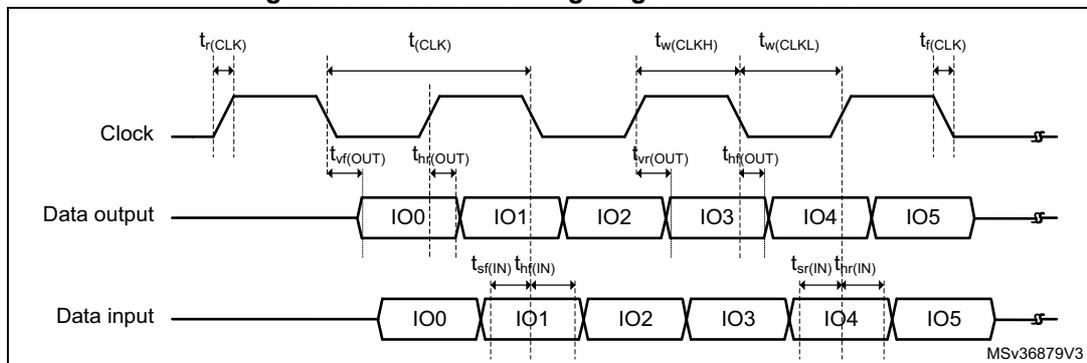


Figure 36. Quad-SPI timing diagram - DDR mode



### 6.3.19 Delay block (DLYB) characteristics

Unless otherwise specified, the parameters given in [Table 76](#) for the delay block are derived from tests performed under the ambient temperature,  $f_{\text{RCC\_C\_CK}}$  frequency and  $V_{\text{DD}}$  supply voltage summarized in [Table 13: General operating conditions](#).

**Table 75. Dynamics characteristics: Delay Block characteristics<sup>(1)</sup>**

| Symbol            | Parameter     | Conditions | Min  | Typ  | Max  | Unit |
|-------------------|---------------|------------|------|------|------|------|
| $t_{\text{init}}$ | Initial delay | -          | 1400 | 2200 | 2400 | ps   |
| $t_{\Delta}$      | Unit Delay    | -          | 35   | 40   | 45   |      |

1. Guaranteed by characterization results.

### 6.3.20 16-bit ADC characteristics

Unless otherwise specified, the parameters given in [Table 76](#) are derived from tests performed under the ambient temperature,  $f_{\text{HCLK}}$  frequency and  $V_{\text{DDA}}$  supply voltage conditions summarized in [Table 13: General operating conditions](#).

**Table 76. ADC characteristics<sup>(1)</sup>**

| Symbol            | Parameter   | Conditions   | Min   | Typ              | Max              | Unit |   |    |           |   |   |    |     |
|-------------------|---|--|---|------------------|------------------|------|---|----|-----------|---|---|----|-----|
| $V_{\text{DDA}}$  | Analog power supply   | -  | 1.62  | -                | 3.6              | V    |   |    |           |   |   |    |     |
| $V_{\text{REF+}}$ | Positive reference voltage  | $V_{\text{DDA}} \geq 2 \text{ V}$                    | 2   | -                | $V_{\text{DDA}}$ |      |   |    |           |   |   |    |     |
| $V_{\text{REF-}}$ |   | Negative reference voltage                           | -   | $V_{\text{SSA}}$ |                  |      |   |    |           |   |   |    |     |
| $f_{\text{ADC}}$  | ADC clock frequency   | $2 \text{ V} \leq V_{\text{DDA}} \leq 3.3 \text{ V}$ | <table border="1"> <tr> <td>BOOST = 1</td> <td>-</td> <td>-</td> <td>36</td> </tr> <tr> <td>BOOST = 0</td> <td>-</td> <td>-</td> <td>20</td> </tr> </table> |                  | BOOST = 1        | -    | - | 36 | BOOST = 0 | - | - | 20 | MHz |
| BOOST = 1         | -   | -  | 36  |                  |                  |      |   |    |           |   |   |    |     |
| BOOST = 0         | -   | -  | 20  |                  |                  |      |   |    |           |   |   |    |     |
| $f_{\text{S}}$    | Sampling rate for Fast channels, BOOST = 1, $f_{\text{ADC}} = 36 \text{ MHz}^{(2)}$ | 16-bit resolution                                    | -   | -                | $3.60^{(2)}$     | MSPS |   |    |           |   |   |    |     |
|                   |   | 14-bit resolution                                    | -   | -                | $4.00^{(2)}$     |      |   |    |           |   |   |    |     |
|                   |   | 12-bit resolution                                    | -   | -                | $4.50^{(2)}$     |      |   |    |           |   |   |    |     |
|                   |   | 10-bit resolution                                    | -   | -                | $5.00^{(2)}$     |      |   |    |           |   |   |    |     |
|                   |   | 8-bit resolution                                     | -   | -                | $6.00^{(2)}$     |      |   |    |           |   |   |    |     |
|                   | Sampling rate for Fast channels, BOOST = 0, $f_{\text{ADC}} = 20 \text{ MHz}$       | 16-bit resolution                                    | -   | -                | $2.00^{(2)}$     |      |   |    |           |   |   |    |     |
|                   |   | 14-bit resolution                                    | -   | -                | $2.20^{(2)}$     |      |   |    |           |   |   |    |     |
|                   |   | 12-bit resolution                                    | -   | -                | $2.50^{(2)}$     |      |   |    |           |   |   |    |     |
|                   |   | 10-bit resolution                                    | -   | -                | $2.80^{(2)}$     |      |   |    |           |   |   |    |     |
|                   |   | 8-bit resolution                                     | -   | -                | $3.30^{(2)}$     |      |   |    |           |   |   |    |     |
|                   | Sampling rate for Slow channels, BOOST = 0, $f_{\text{ADC}} = 10 \text{ MHz}$       | 16-bit resolution                                    | -   | -                | 1.00             |      |   |    |           |   |   |    |     |
|                   |   | 14-bit resolution                                    | -   | -                | 1.00             |      |   |    |           |   |   |    |     |
|                   |   | 12-bit resolution                                    | -   | -                | 1.00             |      |   |    |           |   |   |    |     |
|                   |   | 10-bit resolution                                    | -   | -                | 1.00             |      |   |    |           |   |   |    |     |
|                   |   | 8-bit resolution                                     | -   | -                | 1.00             |      |   |    |           |   |   |    |     |

Table 76. ADC characteristics<sup>(1)</sup> (continued)

| Symbol             | Parameter   | Conditions          | Min   | Typ         | Max              | Unit             |
|--------------------|---|---------------------|---|-------------|------------------|------------------|
| $V_{AIN}^{(3)}$    | Conversion voltage range  | -                   | 0   | -           | $V_{REF+}$       | V                |
| $V_{CMIV}$         | Common mode input voltage   | -                   | $V_{REF}/2-10\%$                                      | $V_{REF}/2$ | $V_{REF}/2+10\%$ |                  |
| $R_{AIN}$          | External input impedance  | -                   | -   | -           | 50               | k $\Omega$       |
| $C_{ADC}$          | Internal sample and hold capacitor  | -                   | -   | 4           | -                | pF               |
| $t_{ADCREG\_STUP}$ | ADC LDO startup time  | -                   | -   | 5           | 10               | $\mu$ s          |
| $t_{STAB}$         | ADC power-up time   | LDO already started | 1   |             |                  | conversion cycle |
| $t_{CAL}$          | Offset and linearity calibration time   | -                   | 165,010   |             |                  | $1/f_{ADC}$      |
| $t_{OFF\_CAL}$     | Offset calibration time   | -                   | 1,280   |             |                  |                  |
| $t_{LATR}$         | Trigger conversion latency for regular and injected channels without aborting the conversion      | CKMODE = 00         | 1.5   | 2           | 2.5              |                  |
|                    |   | CKMODE = 01         | -   | -           | 2                |                  |
|                    |   | CKMODE = 10         | -   | -           | 2.25             |                  |
|                    |   | CKMODE = 11         | -   | -           | 2.125            |                  |
| $t_{LATRINJ}$      | Trigger conversion latency for regular and injected channels when a regular conversion is aborted | CKMODE = 00         | 2.5   | 3           | 3.5              |                  |
|                    |   | CKMODE = 01         | -   | -           | 3                |                  |
|                    |   | CKMODE = 10         | -   | -           | 3.25             |                  |
|                    |   | CKMODE = 11         | -   | -           | 3.125            |                  |
| $t_S$              | Sampling time   | -                   | 1.5   | -           | 810.5            |                  |
| $t_{CONV}$         | Total conversion time (including sampling time)   | N-bit resolution    | $t_S + 0.5 + N/2$<br>(9 to 648 cycles in 14-bit mode) |             |                  |                  |
| $t_{TRIG}$         | External trigger period   | 16 bits resolution  | $t_{CONV} + [t_{LATR} \text{ or } t_{LATRINJ}]$       | -           | -                | $1/f_{ADC}$      |

- Guaranteed by design.
- These values are obtained using the following formula:  $f_S = f_{ADC} / t_{CONV}$ , where  $f_{ADC} = 36$  MHz and  $t_{CONV} = 1,5$  cycle sampling time +  $t_{SAR}$  sampling time. Refer to the product reference manual for the value of  $t_{SAR}$  depending on resolution.
- Depending on the package,  $V_{REF+}$  can be internally connected to  $V_{DDA}$  and  $V_{REF-}$  to  $V_{SSA}$ .

**Table 77. ADC accuracy<sup>(1)(2)(3)</sup>**

| Symbol               | Parameter                                     | Conditions <sup>(4)</sup> |           | Min | Typ   | Max | Unit |
|----------------------|---|---------------------------|-----------|-----|-------|-----|------|
| ET                   | Total unadjusted error                        | Single ended              | BOOST = 1 | -   | ±6    | -   | ±LSB |
|                      |   |                           | BOOST = 0 | -   | ±8    | -   |      |
|                      |   | Differential              | BOOST = 1 | -   | ±10   | -   |      |
|                      |   |                           | BOOST = 0 | -   | ±16   | -   |      |
| ED                   | Differential linearity error                  | Single ended              | BOOST = 1 | -   | 2     | -   |      |
|                      |   |                           | BOOST = 0 | -   | 1     | -   |      |
|                      |   | Differential              | BOOST = 1 | -   | 8     | -   |      |
|                      |   |                           | BOOST = 0 | -   | 2     | -   |      |
| EL                   | Integral linearity error                      | Single ended              | BOOST = 1 | -   | ±6    | -   |      |
|                      |   |                           | BOOST = 0 | -   | ±4    | -   |      |
|                      |   | Differential              | BOOST = 1 | -   | ±6    | -   |      |
|                      |   |                           | BOOST = 0 | -   | ±4    | -   |      |
| ENOB <sup>(5)</sup>  | Effective number of bits (2 MSPS)             | Single ended              | BOOST = 1 | -   | 11.6  | -   | bits |
|                      |   |                           | BOOST = 0 | -   | 12    | -   |      |
|                      |   | Differential              | BOOST = 1 | -   | 13.3  | -   |      |
|                      |   |                           | BOOST = 0 | -   | 13.5  | -   |      |
| SINAD <sup>(5)</sup> | Signal-to-noise and distortion ratio (2 MSPS) | Single ended              | BOOST = 1 | -   | 71.6  | -   | dB   |
|                      |   |                           | BOOST = 0 | -   | 74    | -   |      |
|                      |   | Differential              | BOOST = 1 | -   | 81.83 | -   |      |
|                      |   |                           | BOOST = 0 | -   | 83    | -   |      |
| SNR <sup>(5)</sup>   | Signal-to-noise ratio (2 MSPS)                | Single ended              | BOOST = 1 | -   | 72    | -   |      |
|                      |   |                           | BOOST = 0 | -   | 74    | -   |      |
|                      |   | Differential              | BOOST = 1 | -   | 82    | -   |      |
|                      |   |                           | BOOST = 0 | -   | 83    | -   |      |
| THD <sup>(5)</sup>   | Total harmonic distortion                     | Single ended              | BOOST = 1 | -   | -78   | -   |      |
|                      |   |                           | BOOST = 0 | -   | -80   | -   |      |
|                      |   | Differential              | BOOST = 1 | -   | -90   | -   |      |
|                      |   |                           | BOOST = 0 | -   | -95   | -   |      |

1. Guaranteed by characterization for BGA packages, the values for LQFP packages might differ.
2. ADC DC accuracy values are measured after internal calibration.
3. The above table gives the ADC performance in 16-bit mode.
4. ADC clock frequency ≤ 36 MHz, 2 V ≤ V<sub>DDA</sub> ≤ 3.3 V, 1.6 V ≤ V<sub>REF</sub> ≤ V<sub>DDA</sub>, BOOSTEN (for I/O) = 1.
5. ENOB, SINAD, SNR and THD are specified for V<sub>DDA</sub> = V<sub>REF</sub> = 3.3 V.

Note: ADC accuracy vs. negative injection current: injecting a negative current on any analog input pins should be avoided as this significantly reduces the accuracy of the conversion

being performed on another analog input. It is recommended to add a Schottky diode (pin to ground) to analog pins which may potentially inject negative currents.

Any positive injection current within the limits specified for  $I_{INJ(PIN)}$  and  $\Sigma I_{INJ(PIN)}$  in [Section 6.3.14](#) does not affect the ADC accuracy.

Figure 37. ADC accuracy characteristics

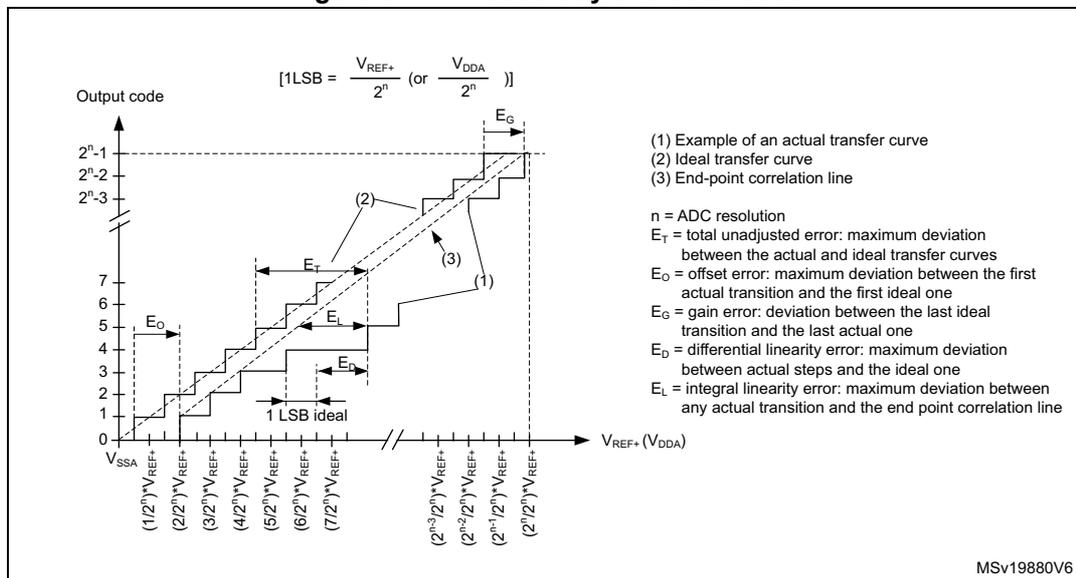
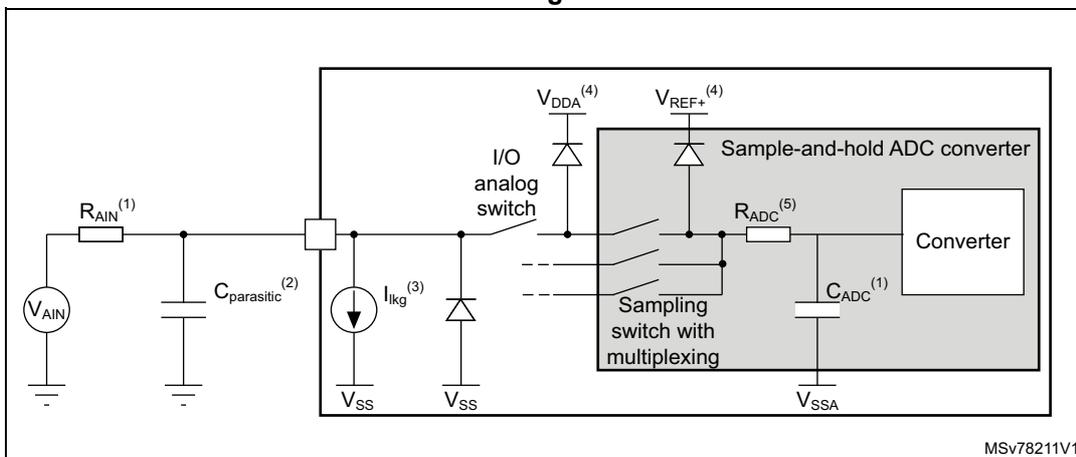


Figure 38. Typical connection diagram when using the ADC with FT/TT pins featuring analog switch function

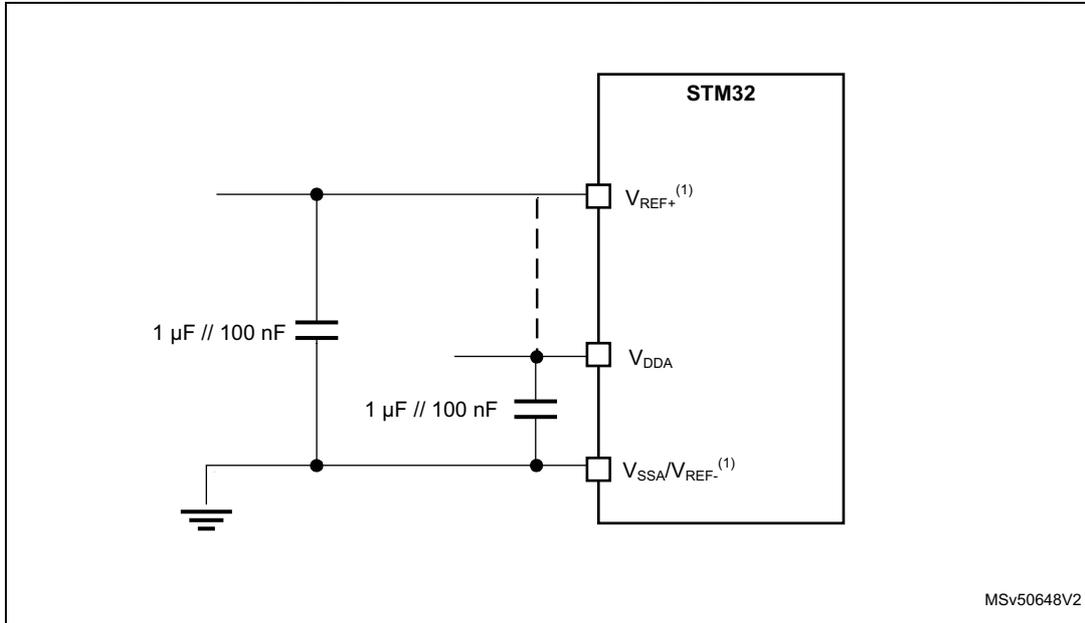


1. Refer to [Section 6.3.20: 16-bit ADC characteristics](#) for the values of  $R_{AIN}$  and  $C_{ADC}$ .
2.  $C_{parasitic}$  represents the capacitance of the PCB (dependent on soldering and PCB layout quality) plus the pad capacitance (refer to [Table 49: I/O static characteristics](#) for the value of the pad capacitance). A high  $C_{parasitic}$  value downgrades conversion accuracy. To remedy this,  $f_{ADC}$  should be reduced.
3. Refer to [Table 49: I/O static characteristics](#) for the value of  $I_{kg}$ .
4. Refer to [Figure 14: Power supply scheme](#).
5. The  $R_{ADC}$  is used to compute the minimum sampling time, refer to [Table 174: Minimum sampling time vs  \$R\_{AIN}\$](#) .

**General PCB design guidelines**

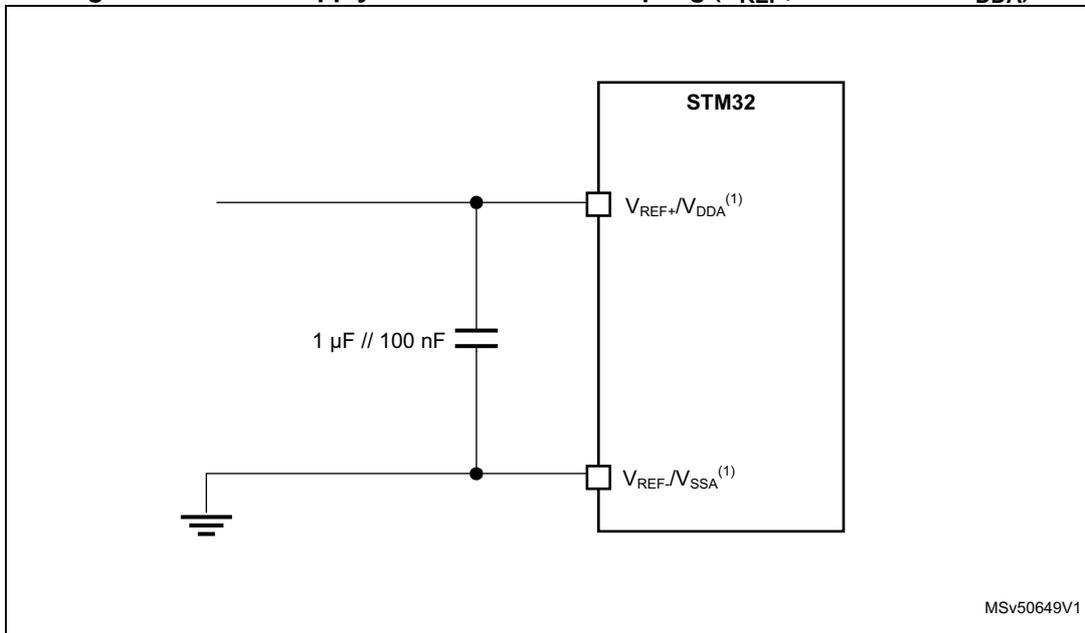
Power supply decoupling should be performed as shown in [Figure 39](#) or [Figure 40](#), depending on whether  $V_{REF+}$  is connected to  $V_{DDA}$  or not. The 100 nF capacitors should be ceramic (good quality). They should be placed them as close as possible to the chip.

**Figure 39. Power supply and reference decoupling ( $V_{REF+}$  not connected to  $V_{DDA}$ )**



1.  $V_{REF+}$  input is available on all package whereas the  $V_{REF-}$  s available only on UFBGA176+25 and TFBGA240+25. When  $V_{REF-}$  is not available, it is internally connected to  $V_{DDA}$  and  $V_{SSA}$ .

**Figure 40. Power supply and reference decoupling ( $V_{REF+}$  connected to  $V_{DDA}$ )**



1.  $V_{REF+}$  input is available on all package whereas the  $V_{REF-}$  s available only on UFBGA176+25 and TFBGA240+25. When  $V_{REF-}$  is not available, it is internally connected to  $V_{DDA}$  and  $V_{SSA}$ .

## 6.3.21 DAC electrical characteristics

Table 78. DAC characteristics<sup>(1)</sup>

| Symbol             | Parameter  | Conditions  | Min                     | Typ                | Max              | Unit          |            |
|--------------------|--|---|-------------------------|--------------------|------------------|---------------|------------|
| $V_{DDA}$          | Analog supply voltage  | -   | 1.8                     | 3.3                | 3.6              | V             |            |
| $V_{REF+}$         | Positive reference voltage   | -   | 1.80                    | -                  | $V_{DDA}$        |               |            |
| $V_{REF-}$         | Negative reference voltage   | -   | -                       | $V_{SSA}$          | -                |               |            |
| $R_L$              | Resistive Load   | DAC output buffer ON  | connected to $V_{SSA}$  | 5                  | -                | -             | k $\Omega$ |
|                    |  |   | connected to $V_{DDA}$  | 25                 | -                | -             |            |
| $R_O^{(2)}$        | Output Impedance   | DAC output buffer OFF   | 10.3                    | 13                 | 16               |               |            |
| $R_{BON}$          | Output impedance sample and hold mode, output buffer ON  | DAC output buffer ON  | $V_{DD} = 2.7\text{ V}$ | -                  | -                | 1.6           | k $\Omega$ |
|                    |  |   | $V_{DD} = 2.0\text{ V}$ | -                  | -                | 2.6           |            |
| $R_{BOFF}$         | Output impedance sample and hold mode, output buffer OFF   | DAC output buffer OFF   | $V_{DD} = 2.7\text{ V}$ | -                  | -                | 17.8          | k $\Omega$ |
|                    |  |   | $V_{DD} = 2.0\text{ V}$ | -                  | -                | 18.7          |            |
| $C_L^{(2)}$        | Capacitive Load  | DAC output buffer OFF   | -                       | -                  | 50               | pF            |            |
| $C_{SH}^{(2)}$     |  | Sample and Hold mode  | -                       | 0.1                | 1                | $\mu\text{F}$ |            |
| $V_{DAC\_OUT}$     | Voltage on DAC_OUT output  | DAC output buffer ON  | 0.2                     | -                  | $V_{REF+} - 0.2$ | V             |            |
|                    |  | DAC output buffer OFF   | 0                       | -                  | $V_{REF+}$       |               |            |
| $t_{SETTLING}$     | Settling time (full scale: for a 12-bit code transition between the lowest and the highest input codes when DAC_OUT reaches the final value of $\pm 0.5\text{LSB}$ , $\pm 1\text{LSB}$ , $\pm 2\text{LSB}$ , $\pm 4\text{LSB}$ , $\pm 8\text{LSB}$ ) | Normal mode, DAC output buffer OFF, $\pm 1\text{LSB}$ $C_L = 10\text{ pF}$      | -                       | 1.7 <sup>(2)</sup> | 2 <sup>(2)</sup> | $\mu\text{s}$ |            |
| $t_{WAKEUP}^{(3)}$ | Wakeup time from off state (setting the Enx bit in the DAC Control register) until the $\pm 1\text{LSB}$ final value   | Normal mode, DAC output buffer ON, $C_L \leq 50\text{ pF}$ , $R_L = 5\text{ ?}$ | -                       | 5                  | 7.5              | $\mu\text{s}$ |            |
| $V_{offset}^{(2)}$ | Middle code offset for 1 trim code step  | $V_{REF+} = 3.6\text{ V}$   | -                       | 850                | -                | $\mu\text{V}$ |            |
|                    |  | $V_{REF+} = 1.8\text{ V}$   | -                       | 425                | -                |               |            |

**Table 78. DAC characteristics<sup>(1)</sup> (continued)**

| Symbol                 | Parameter                                       | Conditions   |                                    | Min | Typ  | Max | Unit |
|------------------------|---|--|------------------------------------|-----|--|-----|------|
| I <sub>DDA</sub> (DAC) | DAC quiescent consumption from V <sub>DDA</sub> | DAC output buffer ON   | No load, middle code (0x800)       | -   | 360  | -   | μA   |
|                        |   |  | No load, worst code (0xF1C)        | -   | 490  | -   |      |
|                        |   | DAC output buffer OFF  | No load, middle/worst code (0x800) | -   | 20   | -   |      |
|                        |   | Sample and Hold mode, C <sub>SH</sub> =100 nF                          |                                    | -   | 360*T <sub>ON</sub> / (T <sub>ON</sub> +T <sub>OFF</sub> ) | -   |      |
| I <sub>DDV</sub> (DAC) | DAC consumption from V <sub>REF+</sub>          | DAC output buffer ON   | No load, middle code (0x800)       | -   | 170  | -   | μA   |
|                        |   |  | No load, worst code (0xF1C)        | -   | 170  | -   |      |
|                        |   | DAC output buffer OFF  | No load, middle/worst code (0x800) | -   | 160  | -   |      |
|                        |   | Sample and Hold mode, Buffer ON, C <sub>SH</sub> =100 nF (worst code)  |                                    | -   | 170*T <sub>ON</sub> / (T <sub>ON</sub> +T <sub>OFF</sub> ) | -   |      |
|                        |   | Sample and Hold mode, Buffer OFF, C <sub>SH</sub> =100 nF (worst code) |                                    | -   | 160*T <sub>ON</sub> / (T <sub>ON</sub> +T <sub>OFF</sub> ) | -   |      |

1. Guaranteed by characterization results.
2. Guaranteed by design.
3. In buffered mode, the output can overshoot above the final value for low input code (starting from the minimum value).

**Table 79. DAC accuracy<sup>(1)</sup>**

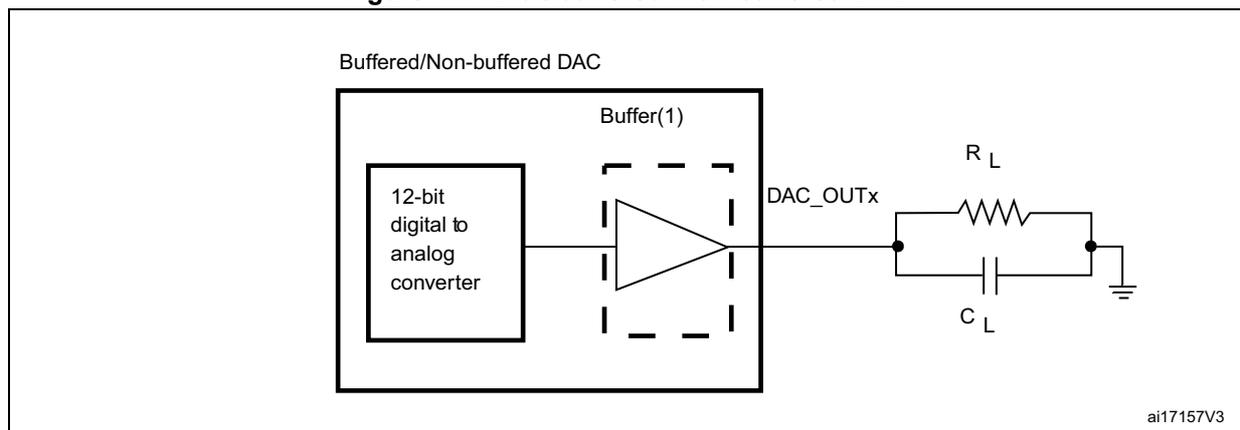
| Symbol  | Parameter                                 | Conditions                                  |               | Min | Typ | Max | Unit |
|---------|---|---|---------------|-----|-----|-----|------|
| DNL     | Differential non linearity <sup>(2)</sup> | DAC output buffer ON                        |               | -   | ±2  | -   | LSB  |
|         |   | DAC output buffer OFF                       |               | -   | ±2  | -   |      |
| INL     | Integral non linearity <sup>(3)</sup>     | DAC output buffer ON, CL≤50 pF, RL ≥ 5 kΩ   |               | -   | ±4  | -   | LSB  |
|         |   | DAC output buffer OFF, CL ≤ 50 pF, no RL    |               | -   | ±4  | -   |      |
| Offset  | Offset error at code 0x800 <sup>(3)</sup> | DAC output buffer ON, CL ≤ 50 pF, RL ≥ 5 kΩ | VREF+ = 3.6 V | -   | -   | ±12 | LSB  |
|         |   |   | VREF+ = 1.8 V | -   | -   | ±25 |      |
|         |   | DAC output buffer OFF, CL ≤ 50 pF, no RL    |               | -   | -   | ±8  |      |
| Offset1 | Offset error at code 0x001 <sup>(4)</sup> | DAC output buffer OFF, CL ≤ 50 pF, no RL    |               | -   | -   | ±5  | LSB  |

**Table 79. DAC accuracy<sup>(1)</sup> (continued)**

| Symbol    | Parameter  | Conditions   | Min           | Typ | Max  | Unit |      |
|-----------|--|--|---------------|-----|------|------|------|
| OffsetCal | Offset error at code 0x800 after factory calibration | DAC output buffer ON, CL≤50 pF, RL ≥ 5 kΩ                      | VREF+ = 3.6 V | -   | -    | ±5   | LSB  |
|           |  |  | VREF+ = 1.8 V | -   | -    | ±7   |      |
| Gain      | Gain error <sup>(5)</sup>                            | DAC output buffer ON, CL≤50 pF, RL ≥ 5 kΩ                      |               | -   | -    | ±1   | %    |
|           |  | DAC output buffer OFF, CL ≤ 50 pF, no RL                       |               | -   | -    | ±1   |      |
| TUE       | Total unadjusted error                               | DAC output buffer OFF, CL ≤ 50 pF, no RL                       |               | -   | -    | ±12  | LSB  |
| SNR       | Signal-to-noise ratio <sup>(6)</sup>                 | DAC output buffer ON, CL≤50 pF, RL ≥ 5 kΩ, 1 kHz, BW = 500 KHz |               | -   | 67.8 | -    | dB   |
| SINAD     | Signal-to-noise and distortion ratio <sup>(6)</sup>  | DAC output buffer ON, CL≤50 pF, RL ≥ 5 kΩ, 1 kHz               |               | -   | 67.5 | -    | dB   |
| ENOB      | Effective number of bits                             | DAC output buffer ON, CL ≤ 50 pF, RL ≥ 5 kΩ, 1 kHz             |               | -   | 10.9 | -    | bits |

1. Guaranteed by characterization.
2. Difference between two consecutive codes minus 1 LSB.
3. Difference between the value measured at Code i and the value measured at Code i on a line drawn between Code 0 and last Code 4095.
4. Difference between the value measured at Code (0x001) and the ideal value.
5. Difference between the ideal slope of the transfer function and the measured slope computed from code 0x000 and 0xFFFF when the buffer is OFF, and from code giving 0.2 V and (VREF+ - 0.2 V) when the buffer is ON.
6. Signal is -0.5dBFS with F<sub>sampling</sub>=1 MHz.

**Figure 41. 12-bit buffered /non-buffered DAC**



1. The DAC integrates an output buffer that can be used to reduce the output impedance and to drive external loads directly without the use of an external operational amplifier. The buffer can be bypassed by configuring the BOFFx bit in the DAC\_CR register.

6.3.22 Voltage reference buffer characteristics

Table 80. VREFBUF characteristics<sup>(1)</sup>

| Symbol                  | Parameter                                    | Conditions                        |                            | Min                       | Typ   | Max   | Unit   |
|-------------------------|--|-----------------------------------|----------------------------|---------------------------|-------|---|--------|
| V <sub>DDA</sub>        | Analog supply voltage                        | Normal mode                       | VSCALE = 000               | 2.8                       | 3.3   | 3.6   | V      |
|                         |  |                                   | VSCALE = 001               | 2.4                       | -     | 3.6   |        |
|                         |  |                                   | VSCALE = 010               | 2.1                       | -     | 3.6   |        |
|                         |  |                                   | VSCALE = 011               | 1.8                       | -     | 3.6   |        |
|                         |  | Degraded mode                     | VSCALE = 000               | 1.62                      | -     | 2.80  |        |
|                         |  |                                   | VSCALE = 001               | 1.62                      | -     | 2.40  |        |
|                         |  |                                   | VSCALE = 010               | 1.62                      | -     | 2.10  |        |
|                         |  |                                   | VSCALE = 011               | 1.62                      | -     | 1.80  |        |
| V <sub>REFBUF_OUT</sub> | Voltage Reference Buffer Output              | Normal mode                       | VSCALE = 000               | -                         | 2.5   | -   |        |
|                         |  |                                   | VSCALE = 001               | -                         | 2.048 | -   |        |
|                         |  |                                   | VSCALE = 010               | -                         | 1.8   | -   |        |
|                         |  |                                   | VSCALE = 011               | -                         | 1.5   | -   |        |
|                         |  | Degraded mode <sup>(2)</sup>      | VSCALE = 000               | V <sub>DDA</sub> - 150 mV | -     | V <sub>DDA</sub>                              |        |
|                         |  |                                   | VSCALE = 001               | V <sub>DDA</sub> - 150 mV | -     | V <sub>DDA</sub>                              |        |
|                         |  |                                   | VSCALE = 010               | V <sub>DDA</sub> - 150 mV | -     | V <sub>DDA</sub>                              |        |
|                         |  |                                   | VSCALE = 011               | V <sub>DDA</sub> - 150 mV | -     | V <sub>DDA</sub>                              |        |
| TRIM                    | Trim step resolution                         | -                                 | -                          | -                         | ±0.05 | ±0.2  | %      |
| C <sub>L</sub>          | Load capacitor                               | -                                 | -                          | 0.5                       | 1     | 1.50  | µF     |
| esr                     | Equivalent Serial Resistor of C <sub>L</sub> | -                                 | -                          | -                         | -     | 2   | Ω      |
| I <sub>load</sub>       | Static load current                          | -                                 | -                          | -                         | -     | 4   | mA     |
| I <sub>line_reg</sub>   | Line regulation                              | 2.8 V ≤ V <sub>DDA</sub> ≤ 3.6 V  | I <sub>load</sub> = 500 µA | -                         | 200   | -   | ppm/V  |
|                         |  |                                   | I <sub>load</sub> = 4 mA   | -                         | 100   | -   |        |
| I <sub>load_reg</sub>   | Load regulation                              | 500 µA ≤ I <sub>LOAD</sub> ≤ 4 mA | Normal Mode                | -                         | 50    | -   | ppm/mA |
| T <sub>coeff</sub>      | Temperature coefficient                      | -40 °C < T <sub>J</sub> < +125 °C | -                          | -                         | -     | T <sub>coeff</sub> × V <sub>REFINT</sub> + 75 | ppm/°C |
| PSRR                    | Power supply rejection                       | DC                                | -                          | -                         | 60    | -   | dB     |
|                         |  | 100KHz                            | -                          | -                         | 40    | -   |        |

Table 80. VREFBUF characteristics<sup>(1)</sup> (continued)

| Symbol                    | Parameter  | Conditions                 | Min | Typ | Max | Unit |
|---------------------------|--|----------------------------|-----|-----|-----|------|
| t <sub>START</sub>        | Start-up time  | C <sub>L</sub> =0.5 μF     | -   | 300 | -   | μs   |
|                           |  | C <sub>L</sub> =1 μF       | -   | 500 | -   |      |
|                           |  | C <sub>L</sub> =1.5 μF     | -   | 650 | -   |      |
| I <sub>INRUSH</sub>       | Control of maximum DC current drive on V <sub>REFBUF_OUT</sub> during startup phase <sup>(3)</sup> | -                          | -   | 8   | -   | mA   |
| I <sub>DDA(VREFBUF)</sub> | VREFBUF consumption from V <sub>DDA</sub>  | I <sub>LOAD</sub> = 0 μA   | -   | 15  | 25  | μA   |
|                           |  | I <sub>LOAD</sub> = 500 μA | -   | 16  | 30  |      |
|                           |  | I <sub>LOAD</sub> = 4 mA   | -   | 32  | 50  |      |

1. Guaranteed by design.
2. In degraded mode, the voltage reference buffer cannot accurately maintain the output voltage (V<sub>DDA</sub>-drop voltage).
3. To properly control VREFBUF I<sub>INRUSH</sub> current during the startup phase and the change of scaling, V<sub>DDA</sub> voltage should be in the range of 1.8 V-3.6 V, 2.1 V-3.6 V, 2.4 V-3.6 V and 2.8 V-3.6 V for VSCALE = 011, 010, 001 and 000, respectively.

### 6.3.23 Temperature sensor characteristics

Table 81. Temperature sensor characteristics

| Symbol                                | Parameter                                      | Min | Typ  | Max  | Unit  |
|---------------------------------------|--|-----|------|------|-------|
| T <sub>L</sub> <sup>(1)</sup>         | V <sub>SENSE</sub> linearity with temperature  | -   | -    | ±3   | °C    |
| Avg_Slope <sup>(2)</sup>              | Average slope                                  | -   | 2    | -    | mV/°C |
| V <sub>30</sub> <sup>(3)</sup>        | Voltage at 30°C ± 5 °C                         | -   | 0.62 | -    | V     |
| t <sub>start_run</sub> <sup>(1)</sup> | Startup time in Run mode (buffer startup)      | -   | -    | 25.2 | μs    |
| t <sub>S_temp</sub> <sup>(1)</sup>    | ADC sampling time when reading the temperature | 9   | -    | -    |       |
| I <sub>sens</sub> <sup>(1)</sup>      | Sensor consumption                             | -   | 0.18 | 0.31 | μA    |
| I <sub>sensbuf</sub> <sup>(1)</sup>   | Sensor buffer consumption                      | -   | 3.8  | 6.5  |       |

1. Guaranteed by design.
2. Guaranteed by characterization.
3. Measured at V<sub>DDA</sub> = V<sub>REF</sub> = 3.3 V ± 10 mV. The V<sub>30</sub> ADC conversion result is stored in the TS\_CAL1 byte.

Table 82. Temperature sensor calibration values

| Symbol  | Parameter   | Memory address            |
|---------|---|---------------------------|
| TS_CAL1 | Temperature sensor raw data acquired value at 30 °C, V <sub>DDA</sub> = V <sub>REF</sub> = 3.3 V  | 0x1FF1 E820 - 0x1FF1 E821 |
| TS_CAL2 | Temperature sensor raw data acquired value at 110 °C, V <sub>DDA</sub> = V <sub>REF</sub> = 3.3 V | 0x1FF1 E840 - 0x1FF1 E841 |

### 6.3.24 Temperature and $V_{BAT}$ monitoring

**Table 83.  $V_{BAT}$  monitoring characteristics**

| Symbol              | Parameter                                      | Min | Typ  | Max | Unit       |
|---------------------|--|-----|------|-----|------------|
| R                   | Resistor bridge for $V_{BAT}$                  | -   | 26   | -   | K $\Omega$ |
| Q                   | Ratio on $V_{BAT}$ measurement                 | -   | 4    | -   | -          |
| $Er^{(1)}$          | Error on Q                                     | -10 | -    | +10 | %          |
| $t_{S\_vbat}^{(1)}$ | ADC sampling time when reading $V_{BAT}$ input | 9   | -    | -   | $\mu s$    |
| $V_{BAThigh}$       | High supply monitoring                         | -   | 3.55 | -   | V          |
| $V_{BATlow}$        | Low supply monitoring                          | -   | 1.36 | -   |            |

1. Guaranteed by design.

**Table 84.  $V_{BAT}$  charging characteristics**

| Symbol   | Parameter                 | Condition          | Min | Typ | Max | Unit       |
|----------|---------------------------|--------------------|-----|-----|-----|------------|
| $R_{BC}$ | Battery charging resistor | VBRS in PWR_CR3= 0 | -   | 5   | -   | K $\Omega$ |
|          |                           | VBRS in PWR_CR3= 1 | -   | 1.5 | -   |            |

**Table 85. Temperature monitoring characteristics**

| Symbol        | Parameter                   | Min | Typ | Max | Unit        |
|---------------|-----------------------------|-----|-----|-----|-------------|
| $TEMP_{high}$ | High temperature monitoring | -   | 117 | -   | $^{\circ}C$ |
| $TEMP_{low}$  | Low temperature monitoring  | -   | -25 | -   |             |

### 6.3.25 Voltage booster for analog switch

**Table 86. Voltage booster for analog switch characteristics<sup>(1)</sup>**

| Symbol          | Parameter            | Condition                       | Min  | Typ | Max | Unit    |
|-----------------|----------------------|---------------------------------|------|-----|-----|---------|
| $V_{DD}$        | Supply voltage       | -                               | 1.62 | 2-6 | 3.6 | V       |
| $t_{SU(BOOST)}$ | Booster startup time | -                               | -    | -   | 50  | $\mu s$ |
| $I_{DD(BOOST)}$ | Booster consumption  | $1.62 V \leq V_{DD} \leq 2.7 V$ | -    | -   | 125 | $\mu A$ |
|                 |                      | $2.7 V < V_{DD} < 3.6 V$        | -    | -   | 250 |         |

1. Guaranteed by characterization results.

## 6.3.26 Comparator characteristics

Table 87. COMP characteristics<sup>(1)</sup>

| Symbol              | Parameter   | Conditions                | Min   | Typ | Max       | Unit |    |
|---------------------|---|---------------------------|---|-----|-----------|------|----|
| $V_{DDA}$           | Analog supply voltage   | -                         | 1.62  | 3.3 | 3.6       | V    |    |
| $V_{IN}$            | Comparator input voltage range  | -                         | 0   | -   | $V_{DDA}$ |      |    |
| $V_{BG}^{(2)}$      | Scaler input voltage  | -                         | Refer to $V_{REFINT}$                       |     |           |      |    |
| $V_{SC}$            | Scaler offset voltage   | -                         | -   | ±5  | ±10       | mV   |    |
| $I_{DDA(SCALER)}$   | Scaler static consumption from $V_{DDA}$  | BRG_EN=0 (bridge disable) | -   | 0.2 | 0.3       | µA   |    |
|                     |   | BRG_EN=1 (bridge enable)  | -   | 0.8 | 1         |      |    |
| $t_{START\_SCALER}$ | Scaler startup time   | -                         | -   | 140 | 250       | µs   |    |
| $t_{START}$         | Comparator startup time to reach propagation delay specification                  | High-speed mode           | -   | 2   | 5         | µs   |    |
|                     |   | Medium mode               | -   | 5   | 20        |      |    |
|                     |   | Ultra-low-power mode      | -   | 15  | 80        |      |    |
| $t_D$               | Propagation delay for 200 mV step with 100 mV overdrive                           | High-speed mode           | -   | 50  | 80        | ns   |    |
|                     |   | Medium mode               | -   | 0.5 | 1.2       |      | µs |
|                     |   | Ultra-low-power mode      | -   | 2.5 | 7         |      |    |
|                     | Propagation delay for step > 200 mV with 100 mV overdrive only on positive inputs | High-speed mode           | -   | 50  | 120       | ns   |    |
|                     |   | Medium mode               | -   | 0.5 | 1.2       |      | µs |
|                     |   | Ultra-low-power mode      | -   | 2.5 | 7         |      |    |
| $V_{offset}$        | Comparator offset error   | Full common mode range    | -   | ±5  | ±20       | mV   |    |
| $V_{hys}$           | Comparator hysteresis   | No hysteresis             | -   | 0   | -         | mV   |    |
|                     |   | Low hysteresis            | -   | 10  | -         |      |    |
|                     |   | Medium hysteresis         | -   | 20  | -         |      |    |
|                     |   | High hysteresis           | -   | 30  | -         |      |    |
| $I_{DDA(COMP)}$     | Comparator consumption from $V_{DDA}$   | Ultra-low-power mode      | Static                                      | -   | 400       | 600  | nA |
|                     |   |                           | With 50 kHz ±100 mV overdrive square signal | -   | 800       | -    |    |
|                     |   | Medium mode               | Static                                      | -   | 5         | 7    | µA |
|                     |   |                           | With 50 kHz ±100 mV overdrive square signal | -   | 6         | -    |    |
|                     |   | High-speed mode           | Static                                      | -   | 70        | 100  |    |
|                     |   |                           | With 50 kHz ±100 mV overdrive square signal | -   | 75        | -    |    |

1. Guaranteed by design, unless otherwise specified.
2. Refer to [Table 17: Embedded reference voltage](#).

## 6.3.27 Operational amplifier characteristics

Table 88. OPAMP characteristics<sup>(1)</sup>

| Symbol                       | Parameter   | Conditions  | Min | Typ       | Max       | Unit                         |
|------------------------------|---|---|-----|-----------|-----------|------------------------------|
| $V_{DDA}$                    | Analog supply voltage Range   | -   | 2   | 3.3       | 3.6       | V                            |
| CMIR                         | Common Mode Input Range   | -   | 0   | -         | $V_{DDA}$ |                              |
| $V_{I\text{OFFSET}}$         | Input offset voltage  | 25°C, no load on output   | -   | -         | $\pm 1.5$ | mV                           |
|                              |   | All voltages and temperature, no load   | -   | -         | $\pm 2.5$ |                              |
| $\Delta V_{I\text{OFFSET}}$  | Input offset voltage drift  | -   | -   | $\pm 3.0$ | -         | $\mu\text{V}/^\circ\text{C}$ |
| TRIMOFFSETP<br>TRIMLPOFFSETP | Offset trim step at low common input voltage ( $0.1 \cdot V_{DDA}$ )  | -   | -   | 1.1       | 1.5       | mV                           |
| TRIMOFFSETN<br>TRIMLPOFFSETN | Offset trim step at high common input voltage ( $0.9 \cdot V_{DDA}$ ) | -   | -   | 1.1       | 1.5       |                              |
| $I_{LOAD}$                   | Drive current   | -   | -   | -         | 500       | $\mu\text{A}$                |
| $I_{LOAD\_PGA}$              | Drive current in PGA mode   | -   | -   | -         | 270       |                              |
| $C_{LOAD}$                   | Capacitive load   | -   | -   | -         | 50        | pF                           |
| CMRR                         | Common mode rejection ratio   | -   | -   | 80        | -         | dB                           |
| PSRR                         | Power supply rejection ratio  | $C_{LOAD} \leq 50\text{pf} /$<br>$R_{LOAD} \geq 4\text{k}\Omega^{(2)}$ at 1 kHz,<br>$V_{com} = V_{DDA}/2$ | 50  | 66        | -         | dB                           |
| GBW                          | Gain bandwidth for high supply range                                  | -   | 4   | 7.3       | 12.3      | MHz                          |
| SR                           | Slew rate (from 10% and 90% of output voltage)                        | Normal mode   | -   | 3         | -         | V/ $\mu\text{s}$             |
|                              |   | High-speed mode   | -   | 30        | -         |                              |
| AO                           | Open loop gain  | -   | 59  | 90        | 129       | dB                           |
| $\phi_m$                     | Phase margin  | -   | -   | 55        | -         | $^\circ$                     |
| GM                           | Gain margin   | -   | -   | 12        | -         | dB                           |

Table 88. OPAMP characteristics<sup>(1)</sup> (continued)

| Symbol               | Parameter   | Conditions  | Min                         | Typ    | Max | Unit      |
|----------------------|---|---|-----------------------------|--------|-----|-----------|
| V <sub>OHSAT</sub>   | High saturation voltage   | I <sub>load</sub> =max or R <sub>LOAD</sub> =min <sup>(2)</sup> ,<br>Input at V <sub>DDA</sub>                  | V <sub>DDA</sub><br>-100 mV | -      | -   | mV        |
| V <sub>OLSAT</sub>   | Low saturation voltage  | I <sub>load</sub> =max or R <sub>LOAD</sub> =min <sup>(2)</sup> ,<br>Input at 0 V                               | -                           | -      | 100 |           |
| t <sub>WAKEUP</sub>  | Wake up time from OFF state   | Normal mode<br>C <sub>LOAD</sub> ≤ 50pf,<br>R <sub>LOAD</sub> ≥ 4 kΩ <sup>(2)</sup> ,<br>follower configuration | -                           | 0.8    | 3.2 | μs        |
|                      |   | High speed<br>C <sub>LOAD</sub> ≤ 50pf,<br>R <sub>LOAD</sub> ≥ 4 kΩ <sup>(2)</sup> ,<br>follower configuration  | -                           | 0.9    | 2.8 |           |
| PGA gain             | Non inverting gain value  | -   | -                           | 2      | -   | -         |
|                      |   | -   | -                           | 4      | -   | -         |
|                      |   | -   | -                           | 8      | -   | -         |
|                      |   | -   | -                           | 16     | -   | -         |
|                      | Inverting gain value  | -   | -                           | -1     | -   | -         |
|                      |   | -   | -                           | -3     | -   | -         |
|                      |   | -   | -                           | -7     | -   | -         |
| -                    | -   | -   | -15                         | -      | -   |           |
| R <sub>network</sub> | R2/R1 internal resistance values in non-inverting PGA mode <sup>(3)</sup> | PGA Gain=2  | -                           | 10/10  | -   | kΩ/<br>kΩ |
|                      |   | PGA Gain=4  | -                           | 30/10  | -   |           |
|                      |   | PGA Gain=8  | -                           | 70/10  | -   |           |
|                      |   | PGA Gain=16   | -                           | 150/10 | -   |           |
|                      | R2/R1 internal resistance values in inverting PGA mode <sup>(3)</sup>     | PGA Gain=-1   | -                           | 10/10  | -   |           |
|                      |   | PGA Gain=-3   | -                           | 30/10  | -   |           |
|                      |   | PGA Gain=-7   | -                           | 70/10  | -   |           |
|                      |   | PGA Gain=-15  | -                           | 150/10 | -   |           |
| Delta R              | Resistance variation (R1 or R2)   | -   | -15                         | -      | 15  | %         |
| PGA BW               | PGA bandwidth for different non inverting gain                            | Gain=2  | -                           | GBW/2  | -   | MHz       |
|                      |   | Gain=4  | -                           | GBW/4  | -   |           |
|                      |   | Gain=8  | -                           | GBW/8  | -   |           |
|                      |   | Gain=16   | -                           | GBW/16 | -   |           |

Table 88. OPAMP characteristics<sup>(1)</sup> (continued)

| Symbol                  | Parameter                                  | Conditions             |   | Min | Typ | Max  | Unit                   |
|-------------------------|--|------------------------|---|-----|-----|------|------------------------|
| en                      | Voltage noise density                      | at<br>1 KHz            | output loaded<br>with 4 kΩ              | -   | 140 | -    | nV/ $\sqrt{\text{Hz}}$ |
|                         |  | at<br>10 KHz           |   | -   | 55  | -    |                        |
| I <sub>DDA(OPAMP)</sub> | OPAMP consumption from<br>V <sub>DDA</sub> | Normal<br>mode         | no Load,<br>quiescent mode,<br>follower | -   | 570 | 1000 | μA                     |
|                         |  | High-<br>speed<br>mode |   | -   | 610 | 1200 |                        |

1. Guaranteed by design, unless otherwise specified.
2. R<sub>LOAD</sub> is the resistive load connected to VSSA or to VDDA.
3. R2 is the internal resistance between the OPAMP output and the OPAMP inverting input. R1 is the internal resistance between the OPAMP inverting input and ground. PGA gain = 1 + R2/R1.

### 6.3.28 Digital filter for Sigma-Delta Modulators (DFSDM) characteristics

Unless otherwise specified, the parameters given in [Table 89](#) for DFSDM are derived from tests performed under the ambient temperature,  $f_{PCLKx}$  frequency and  $V_{DD}$  supply voltage summarized in [Table 13: General operating conditions](#), with the following configuration:

- Output speed is set to  $OSPEEDRy[1:0] = 10$
- Capacitive load  $C = 30 \text{ pF}$
- Measurement points are done at CMOS levels:  $0.5V_{DD}$

Refer to [Section 6.3.15: I/O port characteristics](#) for more details on the input/output alternate function characteristics (DFSDMx\_CKINx, DFSDMx\_DATINx, DFSDMx\_CKOUT for DFSDMx).

**Table 89. DFSDM measured timing - 1.62-3.6 V<sup>(1)</sup>**

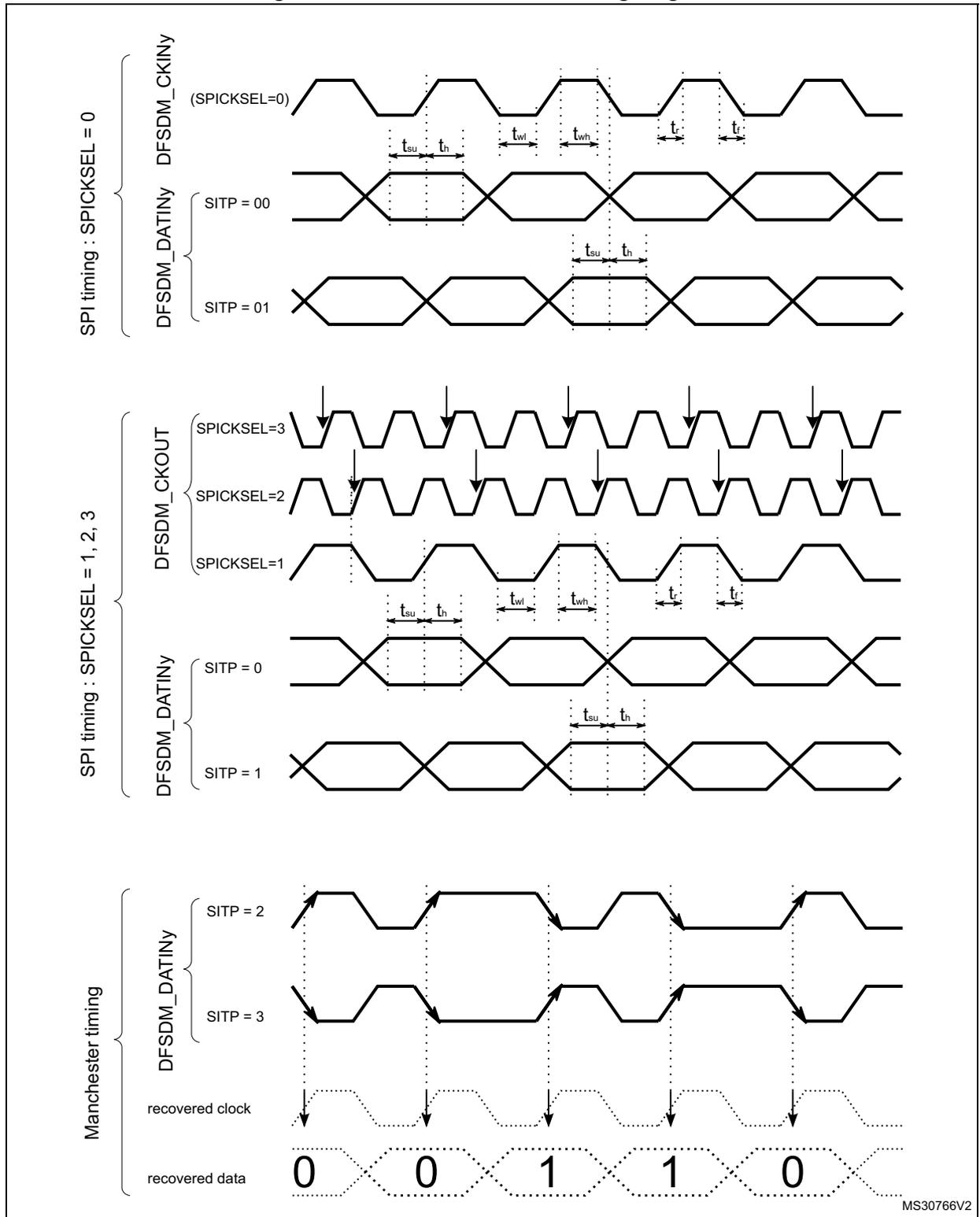
| Symbol                         | Parameter                         | Conditions  |   | Min                               | Typ                            | Max                               | Unit |
|--------------------------------|-----------------------------------|---|---|-----------------------------------|--------------------------------|-----------------------------------|------|
| $f_{DFSDMCLK}$                 | DFSDM clock                       | 1.62 V < $V_{DD}$ < 3.6 V   |   | -                                 | -                              | 250                               | MHz  |
| $f_{CKIN}$<br>( $1/T_{CKIN}$ ) | Input clock frequency             | SPI mode (SITP[1:0]=0,1),<br>External clock mode<br>(SPICKSEL[1:0]=0),<br>1.62 V < $V_{DD}$ < 3.6 V |   | -                                 | -                              | 20<br>( $f_{DFSDMCLK}/4$ )        |      |
|                                |                                   | SPI mode (SITP[1:0]=0,1),<br>External clock mode<br>(SPICKSEL[1:0]=0),<br>2.7 < $V_{DD}$ < 3.6 V    |   | -                                 | -                              | 20<br>( $f_{DFSDMCLK}/4$ )        |      |
|                                |                                   | SPI mode (SITP[1:0]=0,1),<br>Internal clock mode<br>(SPICKSEL[1:0]≠0),<br>1.62 < $V_{DD}$ < 3.6 V   |   | -                                 | -                              | 20<br>( $f_{DFSDMCLK}/4$ )        |      |
|                                |                                   | SPI mode (SITP[1:0]=0,1),<br>Internal clock mode<br>(SPICKSEL[1:0]≠0),<br>2.7 < $V_{DD}$ < 3.6 V    |   | -                                 | -                              | 20<br>( $f_{DFSDMCLK}/4$ )        |      |
| $f_{CKOUT}$                    | Output clock frequency            | 1.62 < $V_{DD}$ < 3.6 V   |   | -                                 | -                              | 20                                |      |
| $DuCY_{CKOUT}$                 | Output clock frequency duty cycle | 1.62 < $V_{DD}$ < 3.6 V   | Even division,<br>CKOUTDIV[7:0]<br>= 1, 3, 5... | 45                                | 50                             | 55                                | %    |
|                                |                                   |   | Odd division,<br>CKOUTDIV[7:0]<br>= 2, 4, 6...  | $\frac{((n/2+1)/(n+1))^*}{100}-5$ | $\frac{((n/2+1)/(n+1))}{*100}$ | $\frac{((n/2+1)/(n+1))^*}{100}+5$ |      |

Table 89. DFSDM measured timing - 1.62-3.6 V<sup>(1)</sup> (continued)

| Symbol                           | Parameter                                       | Conditions   | Min                           | Typ          | Max                           | Unit |
|----------------------------------|---|--|-------------------------------|--------------|-------------------------------|------|
| $t_{wh(CKIN)}$<br>$t_{wl(CKIN)}$ | Input clock high and low time                   | SPI mode (SITP[1:0]=0,1),<br>External clock mode (SPICKSEL[1:0]=0),<br>1.62 < V <sub>DD</sub> < 3.6 V        | $T_{CKIN}/2 - 0.5$            | $T_{CKIN}/2$ | -                             | ns   |
| $t_{su}$                         | Data input setup time                           | SPI mode (SITP[1:0]=0,1),<br>External clock mode (SPICKSEL[1:0]=0),<br>1.62 < V <sub>DD</sub> < 3.6 V        | 4                             | -            | -                             |      |
| $t_h$                            | Data input hold time                            | SPI mode (SITP[1:0]=0,1),<br>External clock mode (SPICKSEL[1:0]=0),<br>1.62 < V <sub>DD</sub> < 3.6 V        | 0.5                           | -            | -                             |      |
| $T_{Manchester}$                 | Manchester data period (recovered clock period) | Manchester mode (SITP[1:0]=2,3),<br>Internal clock mode (SPICKSEL[1:0]≠0),<br>1.62 < V <sub>DD</sub> < 3.6 V | $(CKOUTDIV+1) * T_{DFSDMCLK}$ | -            | $(2*CKOUTDIV) * T_{DFSDMCLK}$ |      |

1. Guaranteed by characterization results.

Figure 42. Channel transceiver timing diagrams



### 6.3.29 Camera interface (DCMI) timing specifications

Unless otherwise specified, the parameters given in [Table 90](#) for DCMI are derived from tests performed under the ambient temperature,  $f_{rcc\_c\_ck}$  frequency and  $V_{DD}$  supply voltage summarized in [Table 13: General operating conditions](#), with the following configuration:

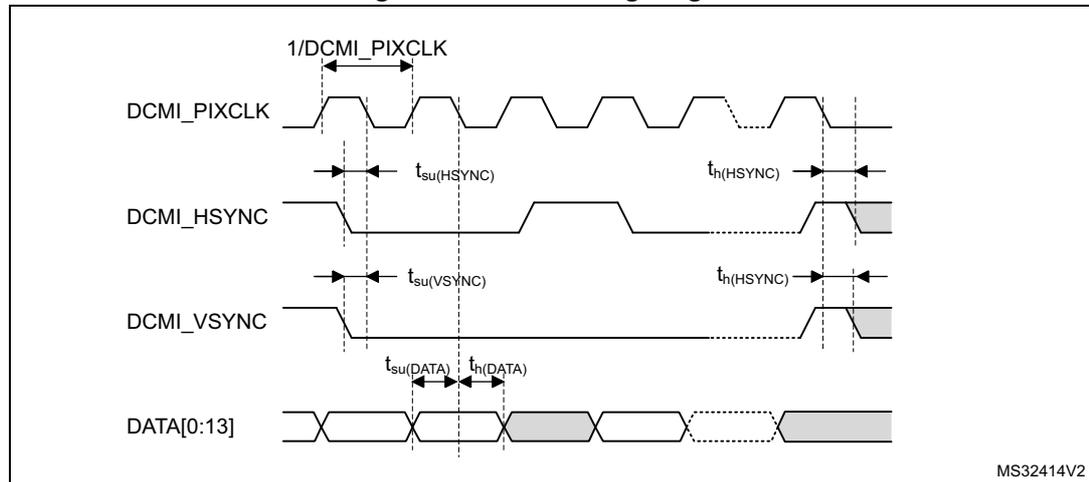
- DCMI\_PIXCLK polarity: falling
- DCMI\_VSYNC and DCMI\_HSYNC polarity: high
- Data formats: 14 bits
- Capacitive load  $C=30$  pF
- Measurement points are done at CMOS levels:  $0.5V_{DD}$

**Table 90. DCMI characteristics<sup>(1)</sup>**

| Symbol                             | Parameter                                     | Min | Max | Unit |
|------------------------------------|---|-----|-----|------|
| -                                  | Frequency ratio DCMI_PIXCLK/ $f_{rcc\_c\_ck}$ | -   | 0.4 | -    |
| DCMI_PIXCLK                        | Pixel clock input                             | -   | 80  | MHz  |
| $D_{Pixel}$                        | Pixel clock input duty cycle                  | 30  | 70  | %    |
| $t_{su}(DATA)$                     | Data input setup time                         | 1   | -   | ns   |
| $t_h(DATA)$                        | Data input hold time                          | 1   | -   |      |
| $t_{su}(HSYNC)$<br>$t_{su}(VSYNC)$ | DCMI_HSYNC/DCMI_VSYNC input setup time        | 1.5 | -   |      |
| $t_h(HSYNC)$<br>$t_h(VSYNC)$       | DCMI_HSYNC/DCMI_VSYNC input hold time         | 1   | -   |      |

1. Guaranteed by characterization results.

**Figure 43. DCMI timing diagram**



MS32414V2

### 6.3.30 LCD-TFT controller (LTDC) characteristics

Unless otherwise specified, the parameters given in [Table 91](#) for LCD-TFT are derived from tests performed under the ambient temperature,  $f_{\text{rcc\_c\_ck}}$  frequency and  $V_{\text{DD}}$  supply voltage summarized in [Table 13: General operating conditions](#), with the following configuration:

- LCD\_CLK polarity: high
- LCD\_DE polarity: low
- LCD\_VSYNC and LCD\_HSYNC polarity: high
- Pixel formats: 24 bits
- Output speed is set to OSPEEDRy[1:0] = 11
- Capacitive load C=30 pF
- Measurement points are done at CMOS levels:  $0.5V_{\text{DD}}$
- I/O compensation cell enabled

**Table 91. LTDC characteristics (1)**

| Symbol  | Parameter                        | Conditions   | Min                              | Max                              | Unit |
|---|----------------------------------|--|----------------------------------|----------------------------------|------|
| $f_{\text{CLK}}$  | LTDC clock output frequency      | $2.7\text{ V} < V_{\text{DD}} < 3.6\text{ V}$ ,<br>20 pF | -                                | 150                              | MHz  |
|   |                                  | $2.7\text{ V} < V_{\text{DD}} < 3.6\text{ V}$            | -                                | 133                              |      |
|   |                                  | $1.62\text{ V} < V_{\text{DD}} < 3.6\text{ V}$           | -                                | 90                               |      |
| $D_{\text{CLK}}$  | LTDC clock output duty cycle     | -  | 45                               | 55                               | %    |
| $t_{\text{w}}(\text{CLKH})$ ,<br>$t_{\text{w}}(\text{CLKL})$                                  | Clock High time, low time        | -  | $t_{\text{w}}(\text{CLK})/2-0.5$ | $t_{\text{w}}(\text{CLK})/2+0.5$ | ns   |
| $t_{\text{v}}(\text{DATA})$   | Data output valid time           | -  | -                                | 0.5                              |      |
| $t_{\text{h}}(\text{DATA})$   | Data output hold time            | -  | 0                                | -                                |      |
| $t_{\text{v}}(\text{HSYNC})$ ,<br>$t_{\text{v}}(\text{VSYNC})$ ,<br>$t_{\text{v}}(\text{DE})$ | HSYNC/VSYNC/DE output valid time | -  | -                                | 0.5                              |      |
| $t_{\text{h}}(\text{HSYNC})$ ,<br>$t_{\text{h}}(\text{VSYNC})$ ,<br>$t_{\text{h}}(\text{DE})$ | HSYNC/VSYNC/DE output hold time  | -  | 0.5                              | -                                |      |

1. Guaranteed by characterization results.

Figure 44. LCD-TFT horizontal timing diagram

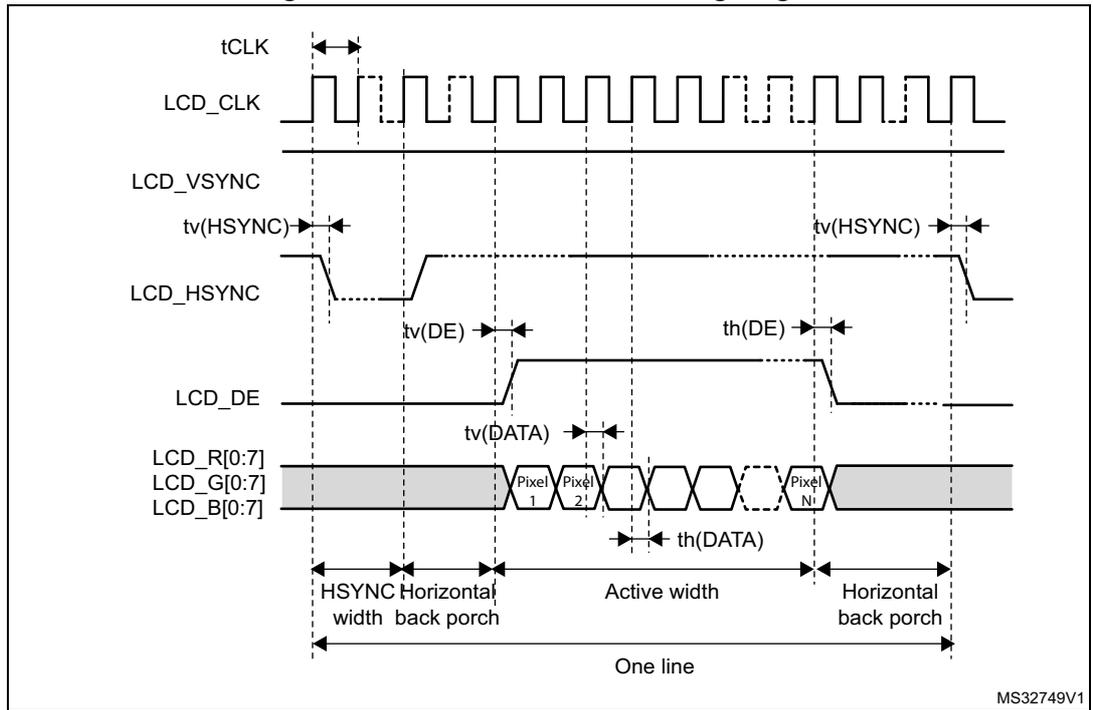
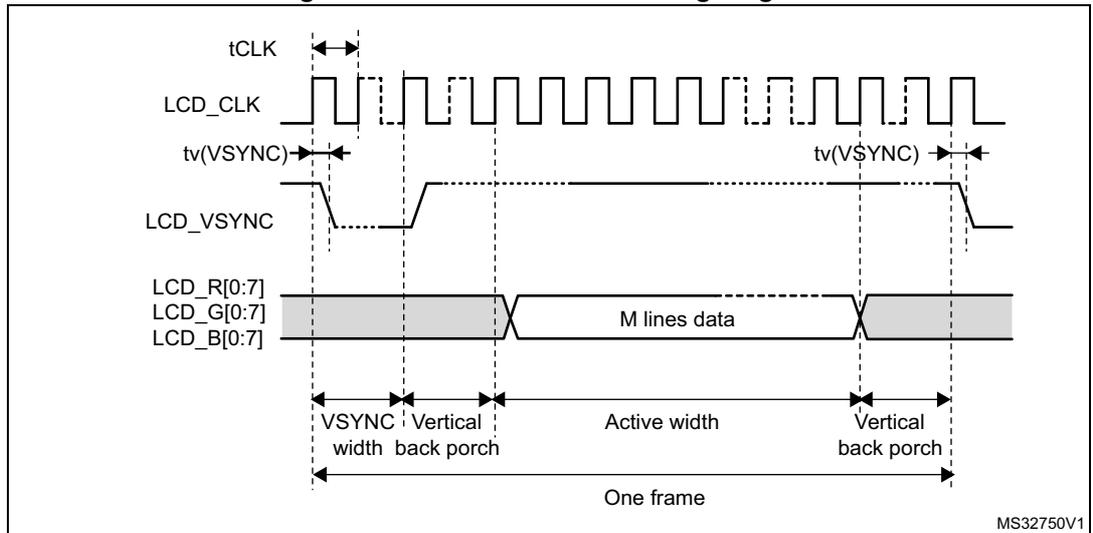


Figure 45. LCD-TFT vertical timing diagram



### 6.3.31 Timer characteristics

The parameters given in [Table 92](#) are guaranteed by design.

Refer to [Section 6.3.15: I/O port characteristics](#) for details on the input/output alternate function characteristics (output compare, input capture, external clock, PWM output).

**Table 92. TIMx characteristics<sup>(1)(2)</sup>**

| Symbol           | Parameter                                    | Conditions <sup>(3)</sup>                               | Min | Max                  | Unit          |
|------------------|--|---|-----|----------------------|---------------|
| $t_{res(TIM)}$   | Timer resolution time                        | AHB/APBx prescaler=1 or 2 or 4, $f_{TIMxCLK} = 240$ MHz | 1   | -                    | $t_{TIMxCLK}$ |
|                  |  | AHB/APBx prescaler>4, $f_{TIMxCLK} = 140$ MHz           | 1   | -                    | $t_{TIMxCLK}$ |
| $f_{EXT}$        | Timer external clock frequency on CH1 to CH4 | $f_{TIMxCLK} = 240$ MHz                                 | 0   | $f_{TIMxCLK}/2$      | MHz           |
| $Res_{TIM}$      | Timer resolution                             |   | -   | 16/32                | bit           |
| $t_{MAX\_COUNT}$ | Maximum possible count with 32-bit counter   | -   | -   | $65536 \times 65536$ | $t_{TIMxCLK}$ |

1. TIMx is used as a general term to refer to the TIM1 to TIM17 timers.
2. Guaranteed by design.
3. The maximum timer frequency on APB1 or APB2 is up to 240 MHz, by setting the TIMPRE bit in the RCC\_CFGR register, if APBx prescaler is 1 or 2 or 4, then  $TIMxCLK = rcc\_hclk1$ , otherwise  $TIMxCLK = 4 \times F_{rcc\_pclkx\_d2}$ .

### 6.3.32 Communications interfaces

#### I<sup>2</sup>C interface characteristics

The I<sup>2</sup>C interface meets the timings requirements of the I<sup>2</sup>C-bus specification and user manual revision 03 for:

- Standard-mode (Sm): with a bit rate up to 100 kbit/s
- Fast-mode (Fm): with a bit rate up to 400 kbit/s.
- Fast-mode Plus (Fm+): with a bit rate up to 1Mbit/s.

The I<sup>2</sup>C timings requirements are guaranteed by design when the I2C peripheral is properly configured (refer to RM0433 reference manual) and when the i2c\_ker\_ck frequency is greater than the minimum shown in the table below:

**Table 93. Minimum i2c\_ker\_ck frequency in all I<sup>2</sup>C modes**

| Symbol    | Parameter        | Condition      | Min                        | Unit |    |
|-----------|------------------|----------------|----------------------------|------|----|
| f(I2CCLK) | I2CCLK frequency | Standard-mode  | 2                          | MHz  |    |
|           |                  | Fast-mode      | Analog filter ON<br>DNF=0  |      | 8  |
|           |                  |                | Analog filter OFF<br>DNF=1 |      | 9  |
|           |                  | Fast-mode Plus | Analog filter ON<br>DNF=0  |      | 17 |
|           |                  |                | Analog filter OFF<br>DNF=1 |      | 16 |

The SDA and SCL I/O requirements are met with the following restrictions:

- The SDA and SCL I/O pins are not “true” open-drain. When configured as open-drain, the PMOS connected between the I/O pin and V<sub>DD</sub> is disabled, but still present.
- The 20 mA output drive requirement in Fast-mode Plus is not supported. This limits the maximum load C<sub>load</sub> supported in Fm+, which is given by these formulas:

$$t_{r(SDA/SCL)} = 0.8473 \times R_p \times C_{load}$$

$$R_{p(min)} = (V_{DD} - V_{OL(max)}) / I_{OL(max)}$$

Where R<sub>p</sub> is the I2C lines pull-up. Refer to [Section 6.3.15: I/O port characteristics](#) for the I2C I/Os characteristics.

All I<sup>2</sup>C SDA and SCL I/Os embed an analog filter. Refer to [Table 94](#) for the analog filter characteristics:

**Table 94. I2C analog filter characteristics<sup>(1)</sup>**

| Symbol          | Parameter  | Min               | Max                | Unit |
|-----------------|--|-------------------|--------------------|------|
| t <sub>AF</sub> | Maximum pulse width of spikes that are suppressed by the analog filter | 50 <sup>(2)</sup> | 260 <sup>(3)</sup> | ns   |

1. Guaranteed by design.
2. Spikes with widths below t<sub>AF(min)</sub> are filtered.
3. Spikes with widths above t<sub>AF(max)</sub> are not filtered.

**SPI interface characteristics**

Unless otherwise specified, the parameters given in [Table 95](#) for the SPI interface are derived from tests performed under the ambient temperature,  $f_{PCLKx}$  frequency and  $V_{DD}$  supply voltage conditions summarized in [Table 13: General operating conditions](#), with the following configuration:

- Output speed is set to  $OSPEEDRy[1:0] = 11$
- Capacitive load  $C = 30 \text{ pF}$
- Measurement points are done at CMOS levels:  $0.5V_{DD}$
- I/O compensation cell enabled
- HSLV activated when  $V_{DD} \leq 2.7 \text{ V}$

Refer to [Section 6.3.15: I/O port characteristics](#) for more details on the input/output alternate function characteristics (NSS, SCK, MOSI, MISO for SPI).

**Table 95. SPI dynamic characteristics<sup>(1)</sup>**

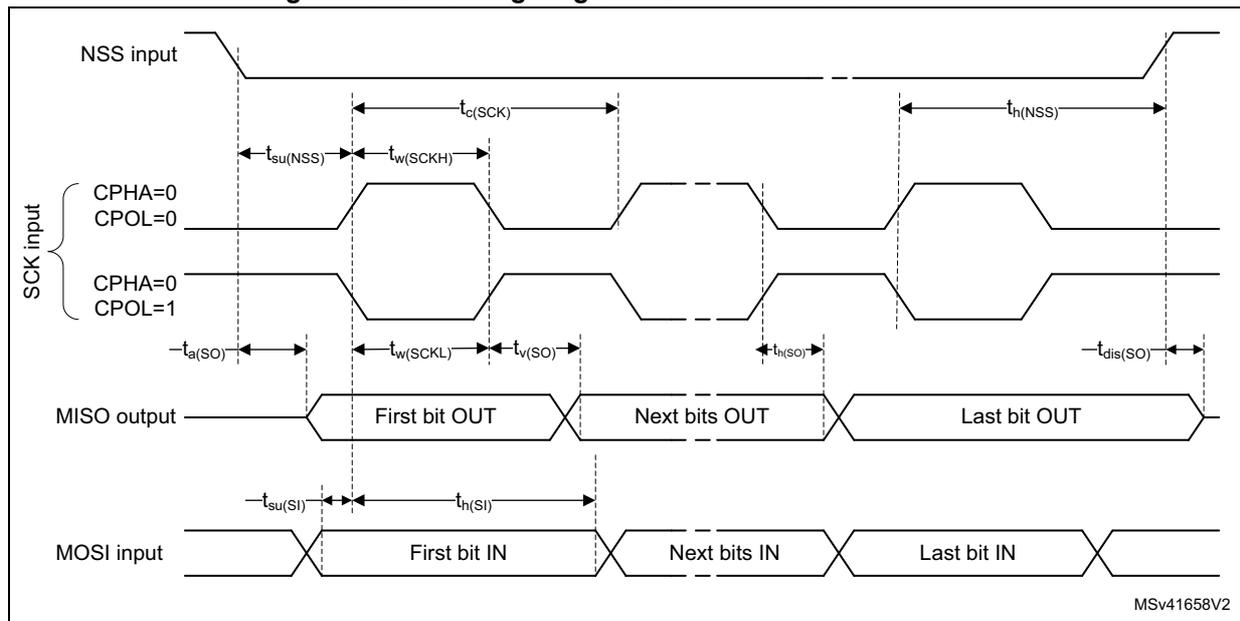
| Symbol                       | Parameter             | Conditions  | Min            | Typ        | Max            | Unit |
|------------------------------|-----------------------|---|----------------|------------|----------------|------|
| $f_{SCK}$<br>$1/t_{c(SCK)}$  | SPI clock frequency   | Master mode<br>$1.62 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$                        | -              | -          | 90             | MHz  |
|                              |                       | Master mode<br>$2.7 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$<br>SPI1,2,3             |                |            | 133            |      |
|                              |                       | Master mode<br>$2.7 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$<br>SPI4,5,6             |                |            | 100            |      |
|                              |                       | Slave receiver mode<br>$1.62 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$<br>SPI1,2,3    |                |            | 150            |      |
|                              |                       | Slave receiver mode<br>$1.62 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$<br>SPI4,5,6    |                |            | 100            |      |
|                              |                       | Slave mode transmitter/full duplex<br>$2.7 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$  |                |            | 31             |      |
|                              |                       | Slave mode transmitter/full duplex<br>$1.62 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$ |                |            | 25             |      |
| $t_{su(NSS)}$                | NSS setup time        | Slave mode  | 2              | -          | -              | ns   |
| $t_{h(NSS)}$                 | NSS hold time         |   | 1              | -          | -              |      |
| $t_w(SCKH)$ ,<br>$t_w(SCKL)$ | SCK high and low time | Master mode   | $T_{PLCK} - 2$ | $T_{PLCK}$ | $T_{PLCK} + 2$ |      |

Table 95. SPI dynamic characteristics<sup>(1)</sup> (continued)

| Symbol        | Parameter                | Conditions                                  | Min | Typ  | Max | Unit |
|---------------|--------------------------|---|-----|------|-----|------|
| $t_{su(MI)}$  | Data input setup time    | Master mode                                 | 2   | -    | -   | ns   |
| $t_{su(SI)}$  |                          | Slave mode                                  | 2   | -    | -   |      |
| $t_{h(MI)}$   | Data input hold time     | Master mode                                 | 1   | -    | -   |      |
| $t_{h(SI)}$   |                          | Slave mode                                  | 1   | -    | -   |      |
| $t_{a(SO)}$   | Data output access time  | Slave mode                                  | 9   | 13   | 27  |      |
| $t_{dis(SO)}$ | Data output disable time | Slave mode                                  | 0   | 1    | 5   |      |
| $t_{v(SO)}$   | Data output valid time   | Slave mode, $2.7 V \leq V_{DD} \leq 3.6 V$  | -   | 11.5 | 16  |      |
|               |                          | Slave mode $1.62 V \leq V_{DD} \leq 3.6 V$  | -   | 13   | 20  |      |
| $t_{v(MO)}$   |                          | Master mode                                 | -   | 1    | 3   |      |
| $t_{h(SO)}$   | Data output hold time    | Slave mode, $1.62 V \leq V_{DD} \leq 3.6 V$ | 9   | -    | -   |      |
| $t_{h(MO)}$   |                          | Master mode                                 | 0   | -    | -   |      |

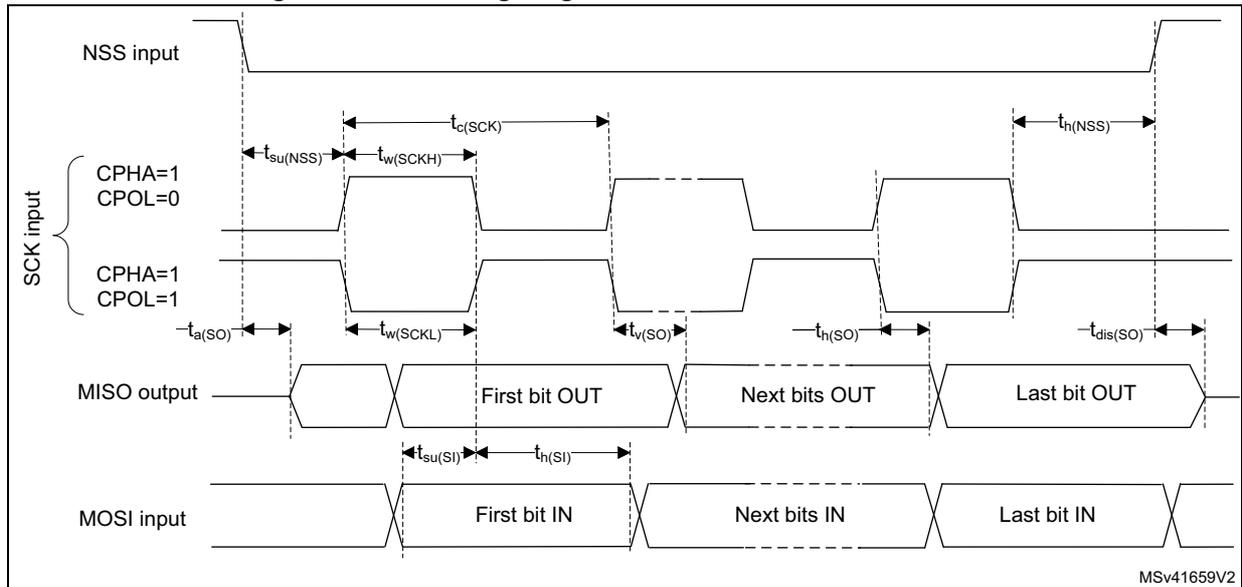
1. Guaranteed by characterization results.

Figure 46. SPI timing diagram - slave mode and CPHA = 0



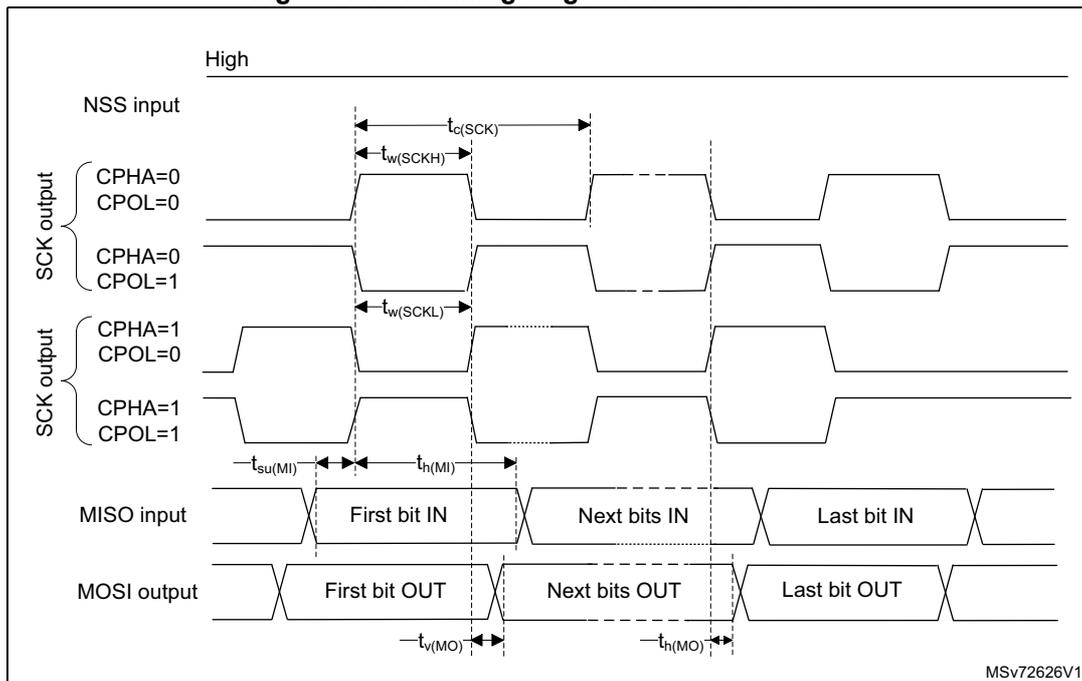
MSv41658V2

Figure 47. SPI timing diagram - slave mode and CPHA = 1<sup>(1)</sup>



1. Measurement points are done at  $0.5V_{DD}$  and with external  $C_L = 30 \text{ pF}$ .

Figure 48. SPI timing diagram - master mode<sup>(1)</sup>



1. Measurement points are done at  $0.5V_{DD}$  and with external  $C_L = 30 \text{ pF}$ .

### I<sup>2</sup>S interface characteristics

Unless otherwise specified, the parameters given in [Table 96](#) for the I<sup>2</sup>S interface are derived from tests performed under the ambient temperature,  $f_{PCLKx}$  frequency and  $V_{DD}$  supply voltage conditions summarized in [Table 13: General operating conditions](#), with the following configuration:

- Output speed is set to OSPEEDRy[1:0] = 10
- Capacitive load C = 30 pF
- Measurement points are done at CMOS levels:  $0.5V_{DD}$
- I/O compensation cell enabled

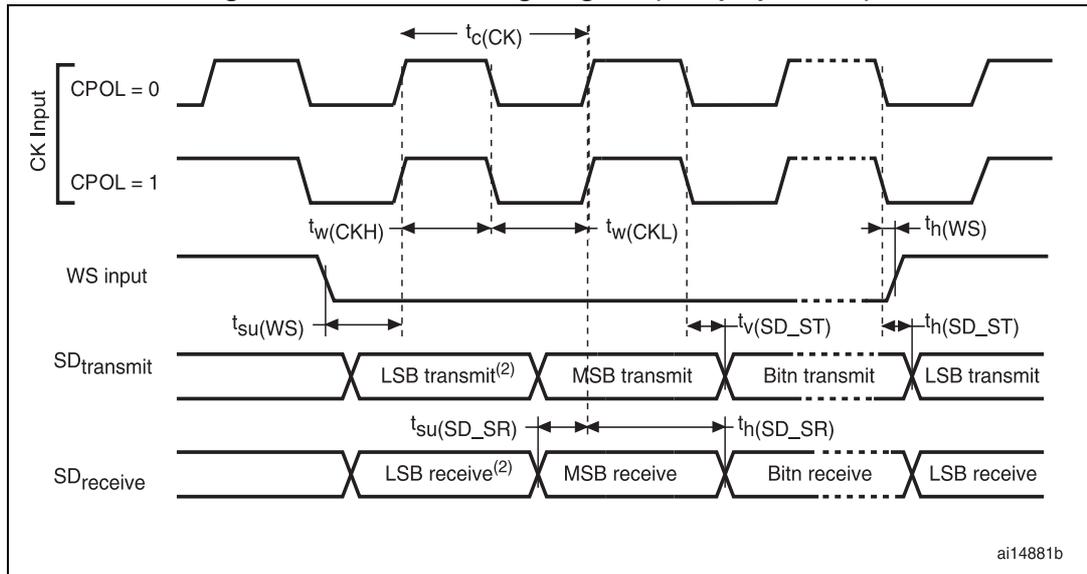
Refer to [Section 6.3.15: I/O port characteristics](#) for more details on the input/output alternate function characteristics (CK, SD, WS).

**Table 96. I<sup>2</sup>S dynamic characteristics<sup>(1)</sup>**

| Symbol           | Parameter              | Conditions                             | Min    | Max      | Unit |
|------------------|------------------------|--|--------|----------|------|
| $f_{MCK}$        | I2S Main clock output  | -                                      | 256x8K | $256F_S$ | MHz  |
| $f_{CK}$         | I2S clock frequency    | Master data                            | -      | $64F_S$  | MHz  |
|                  |                        | Slave data                             | -      | $64F_S$  |      |
| $t_{v(WS)}$      | WS valid time          | Master mode                            | -      | 3.5      | ns   |
| $t_{h(WS)}$      | WS hold time           | Master mode                            | 0      | -        |      |
| $t_{su(WS)}$     | WS setup time          | Slave mode                             | 1      | -        |      |
| $t_{h(WS)}$      | WS hold time           | Slave mode                             | 1      | -        |      |
| $t_{su(SD\_MR)}$ | Data input setup time  | Master receiver                        | 1      | -        |      |
| $t_{su(SD\_SR)}$ |                        | Slave receiver                         | 1      | -        |      |
| $t_{h(SD\_MR)}$  | Data input hold time   | Master receiver                        | 4      | -        |      |
| $t_{h(SD\_SR)}$  |                        | Slave receiver                         | 2      | -        |      |
| $t_{v(SD\_ST)}$  | Data output valid time | Slave transmitter (after enable edge)  | -      | 20       |      |
| $t_{v(SD\_MT)}$  |                        | Master transmitter (after enable edge) | -      | 3        |      |
| $t_{h(SD\_ST)}$  | Data output hold time  | Slave transmitter (after enable edge)  | 9      | -        |      |
| $t_{h(SD\_MT)}$  |                        | Master transmitter (after enable edge) | 0      | -        |      |

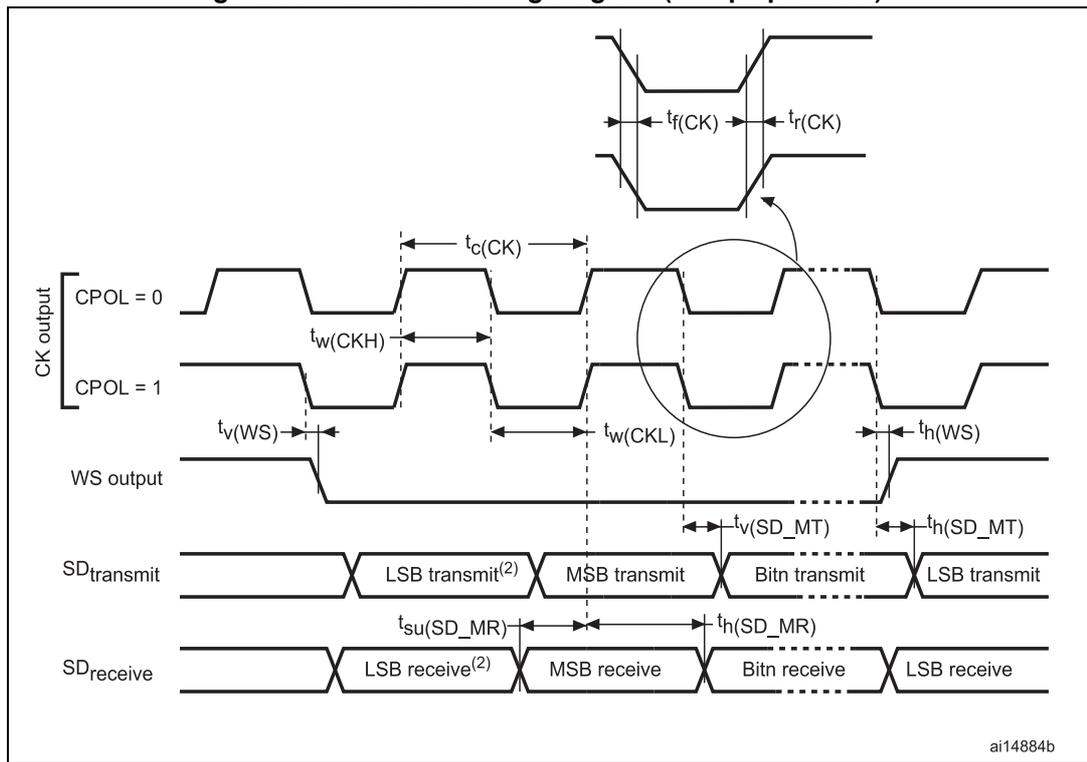
1. Guaranteed by characterization results.

Figure 49. I<sup>2</sup>S slave timing diagram (Philips protocol)<sup>(1)</sup>



1. LSB transmit/receive of the previously transmitted byte. No LSB transmit/receive is sent before the first byte.

Figure 50. I<sup>2</sup>S master timing diagram (Philips protocol)<sup>(1)</sup>



1. LSB transmit/receive of the previously transmitted byte. No LSB transmit/receive is sent before the first byte.

**SAI characteristics**

Unless otherwise specified, the parameters given in [Table 97](#) for SAI are derived from tests performed under the ambient temperature,  $f_{PCLKx}$  frequency and VDD supply voltage conditions summarized in [Table 13: General operating conditions](#), with the following configuration:

- Output speed is set to OSPEEDRy[1:0] = 10
- Capacitive load C=30 pF
- Measurement points are performed at CMOS levels:  $0.5V_{DD}$

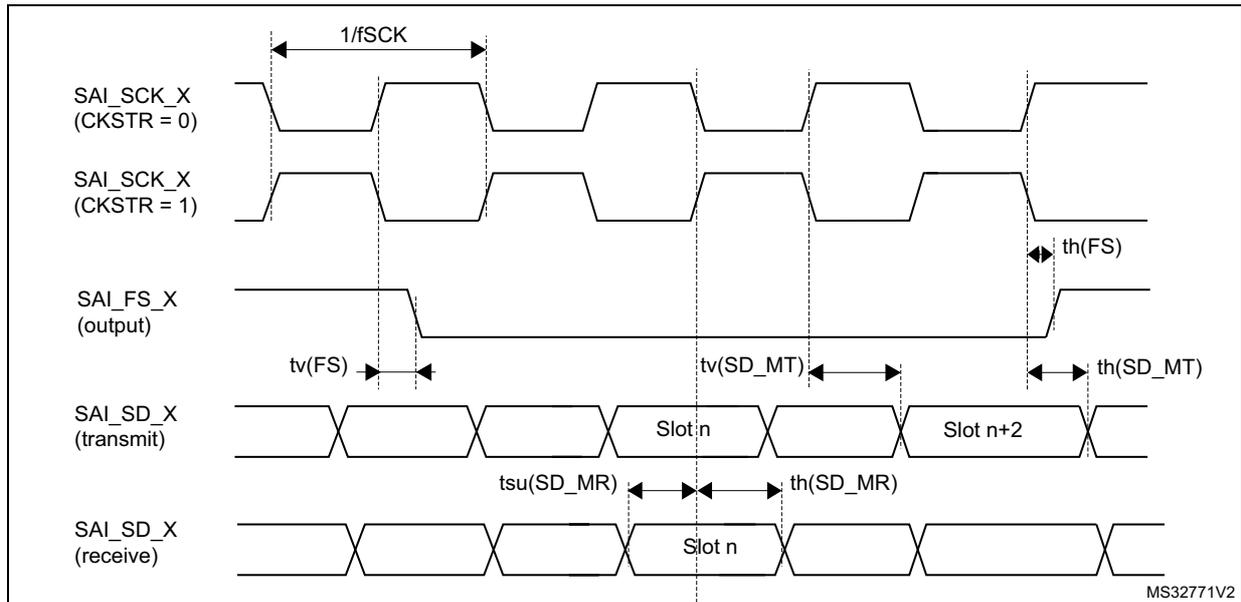
Refer to [Section 6.3.15: I/O port characteristics](#) for more details on the input/output alternate function characteristics (SCK,SD,WS).

**Table 97. SAI characteristics<sup>(1)</sup>**

| Symbol              | Parameter                          | Conditions   | Min      | Max                   | Unit |
|---------------------|------------------------------------|--|----------|-----------------------|------|
| $f_{MCK}$           | SAI Main clock output              | -  | 256 x 8K | 256xFs                | MHz  |
| $F_{CK}$            | SAI clock frequency <sup>(2)</sup> | Master data: 32 bits   | -        | 128xFs <sup>(3)</sup> | MHz  |
|                     |                                    | Slave data: 32 bits  | -        | 128xFs                |      |
| $t_{v(FS)}$         | FS valid time                      | Master mode<br>$2.7 \leq V_{DD} \leq 3.6V$                             | -        | 15                    | ns   |
|                     |                                    | Master mode<br>$1.71 \leq V_{DD} \leq 3.6V$                            | -        | 20                    |      |
| $t_{su(FS)}$        | FS setup time                      | Slave mode   | 7        | -                     |      |
| $t_{h(FS)}$         | FS hold time                       | Master mode  | 1        | -                     |      |
|                     |                                    | Slave mode   | 1        | -                     |      |
| $t_{su(SD\_A\_MR)}$ | Data input setup time              | Master receiver  | 0.5      | -                     |      |
| $t_{su(SD\_B\_SR)}$ |                                    | Slave receiver   | 1        | -                     |      |
| $t_{h(SD\_A\_MR)}$  | Data input hold time               | Master receiver  | 3.5      | -                     |      |
| $t_{h(SD\_B\_SR)}$  |                                    | Slave receiver   | 2        | -                     |      |
| $t_{v(SD\_B\_ST)}$  | Data output valid time             | Slave transmitter (after enable edge)<br>$2.7 \leq V_{DD} \leq 3.6V$   | -        | 17                    |      |
|                     |                                    | Slave transmitter (after enable edge)<br>$1.62 \leq V_{DD} \leq 3.6V$  | -        | 20                    |      |
| $t_{h(SD\_B\_ST)}$  | Data output hold time              | Slave transmitter (after enable edge)                                  | 7        | -                     |      |
| $t_{v(SD\_A\_MT)}$  | Data output valid time             | Master transmitter (after enable edge)<br>$2.7 \leq V_{DD} \leq 3.6V$  | -        | 17                    |      |
|                     |                                    | Master transmitter (after enable edge)<br>$1.62 \leq V_{DD} \leq 3.6V$ | -        | 20                    |      |
| $t_{h(SD\_A\_MT)}$  | Data output hold time              | Master transmitter (after enable edge)                                 | 7.55     | -                     |      |

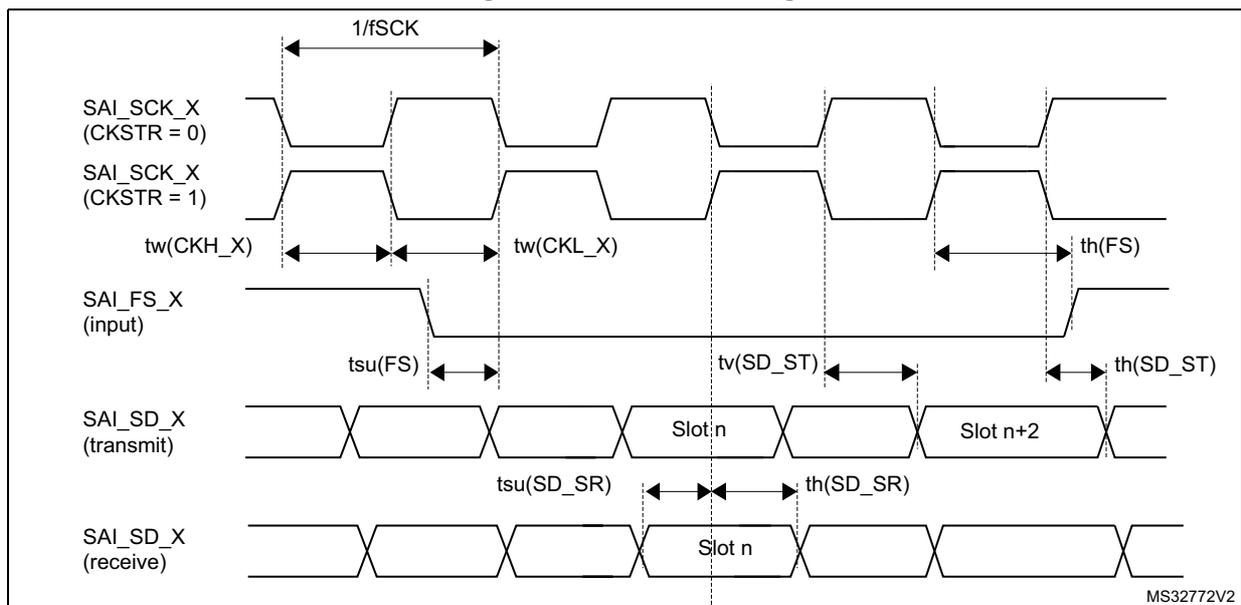
1. Guaranteed by characterization results.
2. APB clock frequency must be at least twice SAI clock frequency.
3. With  $F_S=192$  kHz.

Figure 51. SAI master timing waveforms



MS32771V2

Figure 52. SAI slave timing waveforms



MS32772V2

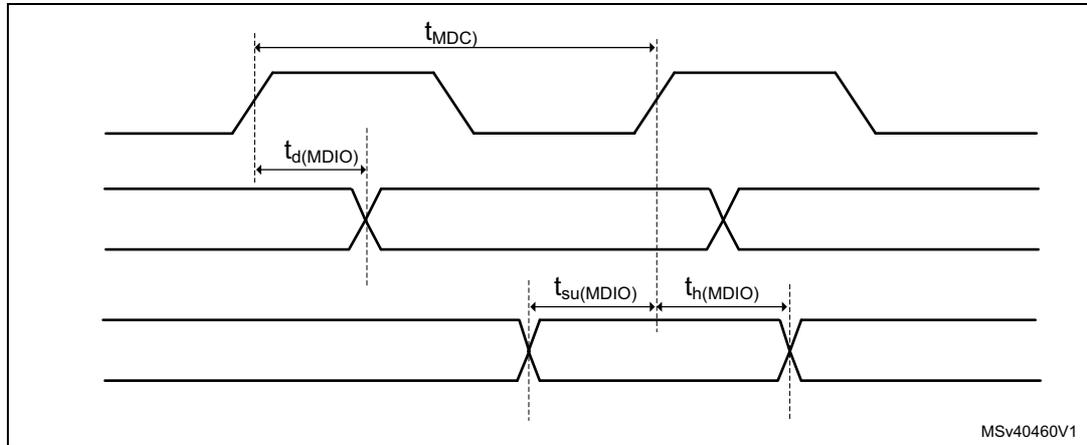
MDIO characteristics

Table 98. MDIO Slave timing parameters

| Symbol         | Parameter   | Min | Typ | Max | Unit |
|----------------|---|-----|-----|-----|------|
| $F_{sDC}$      | Management data clock                                 | -   | -   | 40  | MHz  |
| $t_{d(MDIO)}$  | Management data input/output <b>output valid time</b> | 7   | 8   | 20  | ns   |
| $t_{su(MDIO)}$ | Management data input/output <b>setup time</b>        | 4   | -   | -   |      |
| $t_h(MDIO)$    | Management data input/output <b>hold time</b>         | 1   | -   | -   |      |

The MDIO controller is mapped on APB2 domain. The frequency of the APB bus should at least 1.5 times the MDC frequency:  $F_{PCLK2} \geq 1.5 * F_{MDC}$ .

Figure 53. MDIO Slave timing diagram



**SD/SDIO MMC card host interface (SDMMC) characteristics**

Unless otherwise specified, the parameters given in [Table 99](#) for the SDIO/MMC interface are derived from tests performed under the ambient temperature,  $f_{PCLK2}$  frequency and  $V_{DD}$  supply voltage conditions summarized in [Table 13: General operating conditions](#), with the following configuration:

- Output speed is set to OSPEEDRy[1:0] = 11
- Capacitive load C = 30 pF
- Measurement points are done at CMOS levels:  $0.5V_{DD}$
- I/O compensation cell enabled
- HSLV activated when  $V_{DD} \leq 2.7 V$

Refer to [Section 6.3.15: I/O port characteristics](#) for more details on the input/output characteristics.

**Table 99. Dynamic characteristics: SD / MMC characteristics,  $V_{DD} = 2.7$  to  $3.6 V^{(1)(2)}$**

| Symbol   | Parameter                             | Conditions                   | Min | Typ  | Max | Unit |
|--|---------------------------------------|------------------------------|-----|------|-----|------|
| $f_{PP}$   | Clock frequency in data transfer mode | -                            | 0   | -    | 125 | MHz  |
| $t_{W(CKL)}$   | Clock low time                        | $f_{PP} = 50 \text{ MHz}$    | 9.5 | 10.5 | -   | ns   |
| $t_{W(CKH)}$   | Clock high time                       |                              | 8.5 | 9.5  | -   |      |
| <b>CMD, D inputs (referenced to CK) in MMC and SD HS/SDR/DDR mode</b>  |                                       |                              |     |      |     |      |
| $t_{ISU}$  | Input setup time HS                   | $f_{PP} \geq 50 \text{ MHz}$ | 3   | -    | -   | ns   |
| $t_{IH}$   | Input hold time HS                    |                              | 0.5 | -    | -   |      |
| $t_{IDW}^{(3)}$  | Input valid window (variable window)  |                              | 3   | -    | -   |      |
| <b>CMD, D outputs (referenced to CK) in MMC and SD HS/SDR/DDR mode</b> |                                       |                              |     |      |     |      |
| $t_{OV}$   | Output valid time HS                  | $f_{PP} \geq 50 \text{ MHz}$ | -   | 3.5  | 5   | ns   |
| $t_{OH}$   | Output hold time HS                   |                              | 2   | -    | -   |      |

Table 99. Dynamic characteristics: SD / MMC characteristics,  $V_{DD} = 2.7$  to  $3.6$  V<sup>(1)(2)</sup>

| Symbol  | Parameter                    | Conditions        | Min | Typ | Max | Unit |
|---|------------------------------|-------------------|-----|-----|-----|------|
| <b>CMD, D inputs (referenced to CK) in SD default mode</b>  |                              |                   |     |     |     |      |
| $t_{ISUD}$  | Input setup time SD          | $f_{PP} = 25$ MHz | 3   | -   | -   | ns   |
| $t_{IHD}$   | Input hold time SD           |                   | 0.5 | -   | -   |      |
| <b>CMD, D outputs (referenced to CK) in SD default mode</b> |                              |                   |     |     |     |      |
| $t_{OVD}$   | Output valid default time SD | $f_{PP} = 25$ MHz | -   | 1   | 2   | ns   |
| $t_{OHD}$   | Output hold default time SD  |                   | 0   | -   | -   |      |

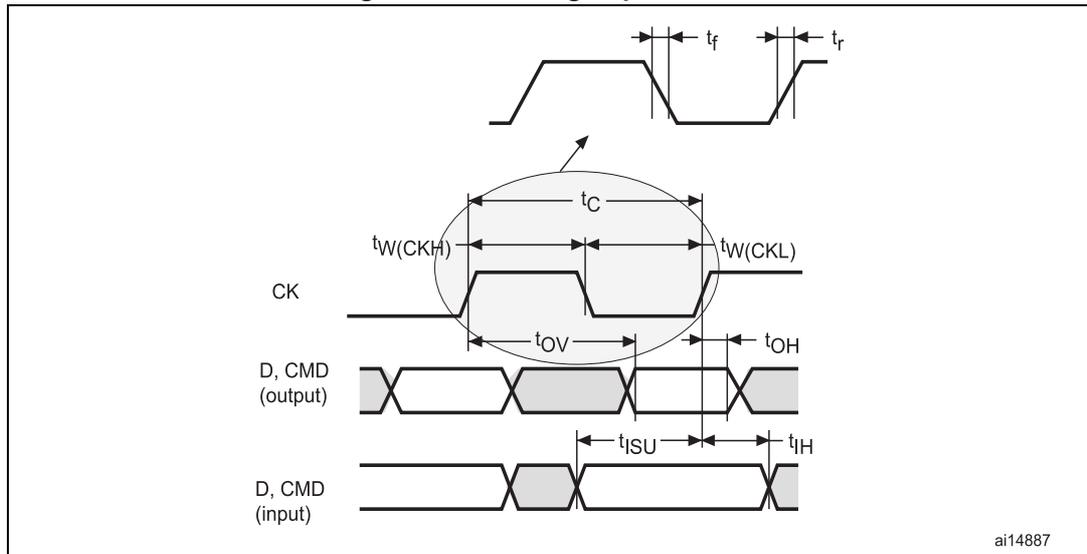
1. Guaranteed by characterization results.
2. Above 100 MHz,  $C_L = 20$  pF.
3. The minimum window of time where the data needs to be stable for proper sampling in tuning mode.

Table 100. Dynamic characteristics: eMMC characteristics,  $V_{DD} = 1.71$  to  $1.9$  V<sup>(1)(2)</sup>

| Symbol  | Parameter                             | Conditions           | Min | Typ  | Max | Unit |
|---|---------------------------------------|----------------------|-----|------|-----|------|
| $f_{PP}$  | Clock frequency in data transfer mode | -                    | 0   | -    | 120 | MHz  |
| $t_{W(CKL)}$  | Clock low time                        | $f_{PP} = 50$ MHz    | 9.5 | 10.5 | -   | ns   |
| $t_{W(CKH)}$  | Clock high time                       |                      | 8.5 | 9.5  | -   |      |
| <b>CMD, D inputs (referenced to CK) in eMMC mode</b>  |                                       |                      |     |      |     |      |
| $t_{ISU}$   | Input setup time HS                   | $f_{PP} \geq 50$ MHz | 2.5 | -    | -   | ns   |
| $t_{IH}$  | Input hold time HS                    |                      | 1   | -    | -   |      |
| $t_{IDW}^{(3)}$                                       | Input valid window (variable window)  |                      | 3.5 | -    | -   |      |
| <b>CMD, D outputs (referenced to CK) in eMMC mode</b> |                                       |                      |     |      |     |      |
| $t_{OV}$  | Output valid time HS                  | $f_{PP} \geq 50$ MHz | -   | 5    | 7   | ns   |
| $t_{OH}$  | Output hold time HS                   |                      | 3   | -    | -   |      |

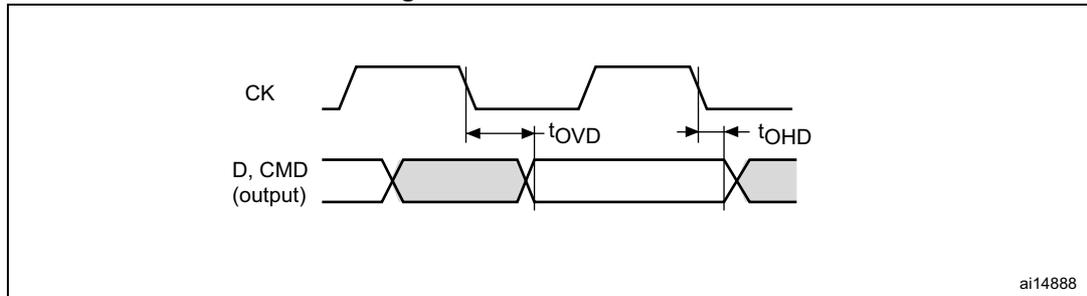
1. Guaranteed by characterization results.
2.  $C_L = 20$  pF.
3. The minimum window of time where the data needs to be stable for proper sampling in tuning mode.

Figure 54. SDIO high-speed mode



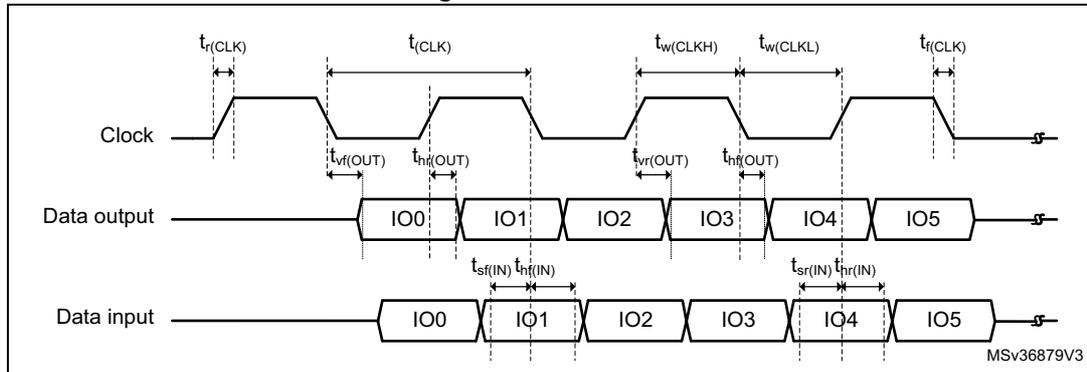
ai14887

Figure 55. SD default mode



ai14888

Figure 56. DDR mode



MSv36879V3

**CAN (controller area network) interface**

Refer to [Section 6.3.15: I/O port characteristics](#) for more details on the input/output alternate function characteristics (FDCANx\_TX and FDCANx\_RX).

### USB OTG\_FS characteristics

The USB interface is fully compliant with the USB specification version 2.0 and is USB-IF certified (for Full-speed device operation).

**Table 101. USB OTG\_FS electrical characteristics**

| Symbol        | Parameter                                      | Condition           | Min                | Typ  | Max  | Unit |
|---------------|--|---------------------|--------------------|------|------|------|
| $V_{DD33USB}$ | USB transceiver operating voltage              | -                   | 3.0 <sup>(1)</sup> | -    | 3.6  | V    |
| $R_{PUI}$     | Embedded USB_DP pull-up value during idle      | -                   | 900                | 1250 | 1600 | Ω    |
| $R_{PUR}$     | Embedded USB_DP pull-up value during reception | -                   | 1400               | 2300 | 3200 |      |
| $Z_{DRV}$     | Output driver impedance <sup>(2)</sup>         | Driver high and low | 28                 | 36   | 44   |      |

- The USB functionality is ensured down to 2.7 V but not the full USB electrical characteristics which are degraded in the 2.7 to 3.0 V voltage range.
- No external termination series resistors are required on USB\_DP (D+) and USB\_DM (D-); the matching impedance is already included in the embedded driver.

### USB OTG\_HS characteristics

Unless otherwise specified, the parameters given in [Table 102](#) for ULPI are derived from tests performed under the ambient temperature,  $f_{rcc\_c\_ck}$  frequency and  $V_{DD}$  supply voltage conditions summarized in [Table 13: General operating conditions](#), with the following configuration:

- Output speed is set to OSPEEDRy[1:0] = 11
- Capacitive load  $C = 20$  pF
- Measurement points are done at CMOS levels:  $0.5V_{DD}$ .

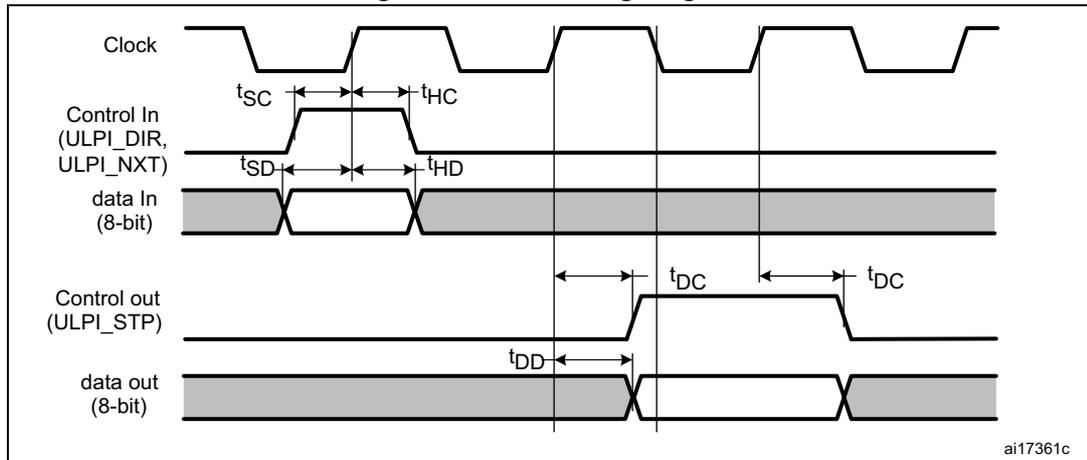
Refer to [Section 6.3.15: I/O port characteristics](#) for more details on the input/output characteristics.

**Table 102. Dynamic characteristics: USB ULPI<sup>(1)</sup>**

| Symbol          | Parameter                                  | Conditions   | Min | Typ | Max | Unit |
|-----------------|--|--|-----|-----|-----|------|
| $t_{SC}$        | Control in (ULPI_DIR, ULPI_NXT) setup time | -  | 0.5 | -   | -   | ns   |
| $t_{HC}$        | Control in (ULPI_DIR, ULPI_NXT) hold time  | -  | 6.5 | -   | -   |      |
| $t_{SD}$        | Data in setup time                         | -  | 2.5 | -   | -   |      |
| $t_{HD}$        | Data in hold time                          | -  | 0   | -   | -   |      |
| $t_{DC}/t_{DD}$ | Data/control output delay                  | $2.7\text{ V} < V_{DD} < 3.6\text{ V}$ ,<br>$C_L = 20\text{ pF}$ | -   | 6.5 | 8.5 |      |
|                 |  | -  | -   | 6.5 | 13  |      |
|                 |  | $1.7\text{ V} < V_{DD} < 3.6\text{ V}$ ,<br>$C_L = 15\text{ pF}$ | -   | -   | -   |      |

- Guaranteed by characterization results.

Figure 57. ULPI timing diagram



**Ethernet characteristics**

Unless otherwise specified, the parameters given in [Table 103](#), [Table 104](#) and [Table 105](#) for SMI, RMII and MII are derived from tests performed under the ambient temperature,  $f_{rcc\_c\_ck}$  frequency summarized in [Table 13: General operating conditions](#), with the following configuration:

- Output speed is set to  $OSPEEDRy[1:0] = 10$
- Capacitive load  $C = 20\text{ pF}$
- Measurement points are done at CMOS levels:  $0.5V_{DD}$ .

Refer to [Section 6.3.15: I/O port characteristics](#) for more details on the input/output characteristics.

[Table 103](#) gives the list of Ethernet MAC signals for the SMI and [Figure 58](#) shows the corresponding timing diagram.

**Table 103. Dynamics characteristics: Ethernet MAC signals for SMI<sup>(1)</sup>**

| Symbol         | Parameter               | Min | Typ | Max | Unit |
|----------------|-------------------------|-----|-----|-----|------|
| $t_{MDC}$      | MDC cycle time(2.5 MHz) | 400 | 400 | 403 | ns   |
| $T_{d(MDIO)}$  | Write data valid time   | 1   | 1.5 | 3   |      |
| $t_{su(MDIO)}$ | Read data setup time    | 8   | -   | -   |      |
| $t_h(MDIO)$    | Read data hold time     | 0   | -   | -   |      |

1. Guaranteed by characterization results.

Figure 58. Ethernet SMI timing diagram

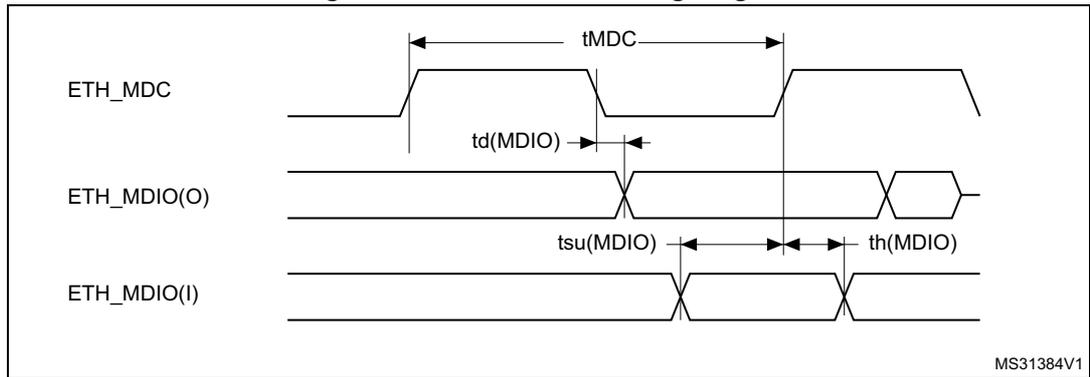


Table 104 gives the list of Ethernet MAC signals for the RMII and Figure 59 shows the corresponding timing diagram.

Table 104. Dynamics characteristics: Ethernet MAC signals for RMII<sup>(1)</sup>

| Symbol                | Parameter                        | Min | Typ | Max  | Unit |
|-----------------------|----------------------------------|-----|-----|------|------|
| t <sub>su</sub> (RXD) | Receive data setup time          | 2   | -   | -    | ns   |
| t <sub>ih</sub> (RXD) | Receive data hold time           | 3   | -   | -    |      |
| t <sub>su</sub> (CRS) | Carrier sense setup time         | 2.5 | -   | -    |      |
| t <sub>ih</sub> (CRS) | Carrier sense hold time          | 2   | -   | -    |      |
| t <sub>d</sub> (TXEN) | Transmit enable valid delay time | 4   | 4.5 | 7    |      |
| t <sub>d</sub> (TXD)  | Transmit data valid delay time   | 7   | 7.5 | 11.5 |      |

1. Guaranteed by characterization results.

Figure 59. Ethernet RMII timing diagram

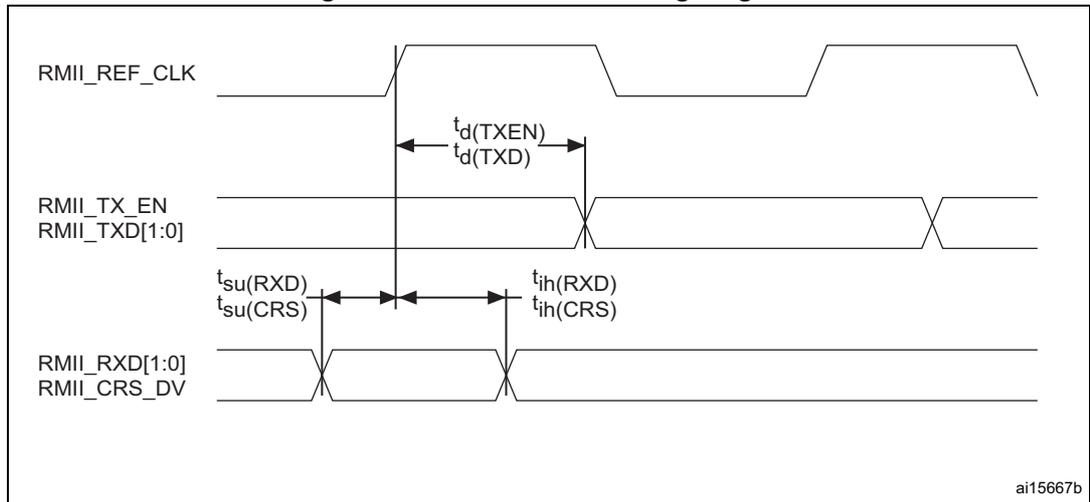


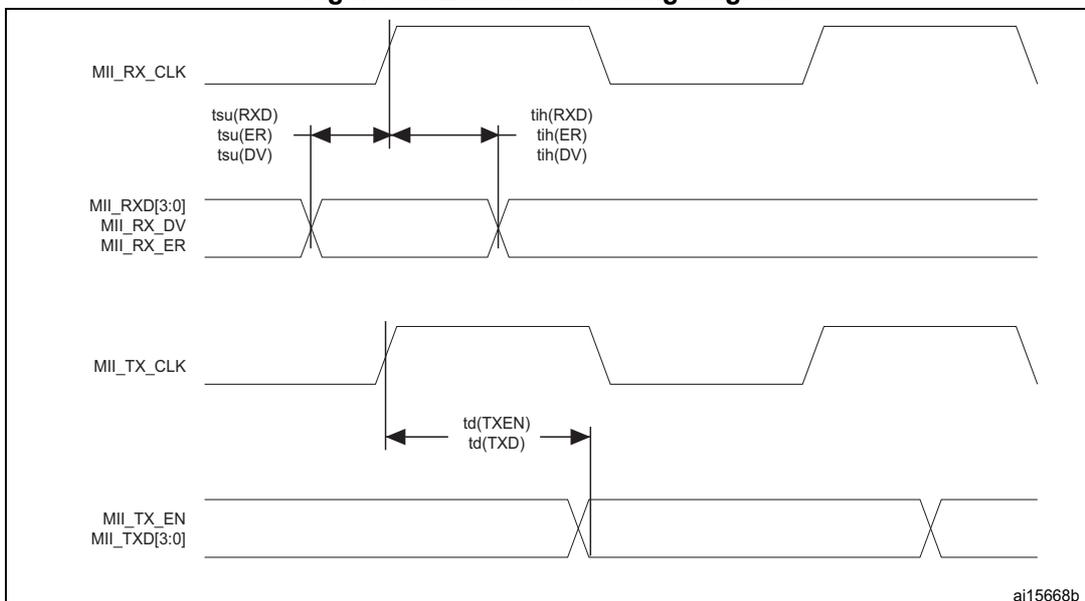
Table 105 gives the list of Ethernet MAC signals for MII and Figure 60 shows the corresponding timing diagram.

**Table 105. Dynamics characteristics: Ethernet MAC signals for MII<sup>(1)</sup>**

| Symbol        | Parameter                        | Min | Typ | Max | Unit |
|---------------|----------------------------------|-----|-----|-----|------|
| $t_{su}(RXD)$ | Receive data setup time          | 2   | -   | -   | ns   |
| $t_{ih}(RXD)$ | Receive data hold time           | 3   | -   | -   |      |
| $t_{su}(DV)$  | Data valid setup time            | 1.5 | -   | -   |      |
| $t_{ih}(DV)$  | Data valid hold time             | 1   | -   | -   |      |
| $t_{su}(ER)$  | Error setup time                 | 1.5 | -   | -   |      |
| $t_{ih}(ER)$  | Error hold time                  | 0.5 | -   | -   |      |
| $t_d(TXEN)$   | Transmit enable valid delay time | 4.5 | 6.5 | 11  |      |
| $t_d(TXD)$    | Transmit data valid delay time   | 7   | 7.5 | 15  |      |

1. Guaranteed by characterization results.

**Figure 60. Ethernet MII timing diagram**



### 6.3.33 JTAG/SWD interface characteristics

Unless otherwise specified, the parameters given in [Table 106](#) and [Table 107](#) for JTAG/SWD are derived from tests performed under the ambient temperature,  $f_{rcc\_c\_ck}$  frequency and  $V_{DD}$  supply voltage summarized in [Table 13: General operating conditions](#), with the following configuration:

- Output speed is set to OSPEEDRy[1:0] = 0x10
- Capacitive load C=30 pF
- Measurement points are done at CMOS levels:  $0.5V_{DD}$

Refer to [Section 6.3.15: I/O port characteristics](#) for more details on the input/output characteristics.

Table 106. Dynamics JTAG characteristics<sup>(1)</sup>

| Symbol         | Parameter                | Conditions                              | Min | Typ | Max  | Unit |
|----------------|--------------------------|---|-----|-----|------|------|
| $F_{pp}$       | $T_{CK}$ clock frequency | $2.7\text{ V} < V_{DD} < 3.6\text{ V}$  | -   | -   | 37   | MHz  |
| $1/t_{c(TCK)}$ |                          | $1.62\text{ V} < V_{DD} < 3.6\text{ V}$ | -   | -   | 27.5 |      |
| $t_{isu(TMS)}$ | TMS input setup time     | -                                       | 2   | -   | -    | ns   |
| $t_{ih(TMS)}$  | TMS input hold time      | -                                       | 1   | -   | -    |      |
| $t_{isu(TDI)}$ | TDI input setup time     | -                                       | 1.5 | -   | -    |      |
| $t_{ih(TDI)}$  | TDI input hold time      | -                                       | 1   | -   | -    |      |
| $t_{ov(TDO)}$  | TDO output valid time    | $2.7\text{ V} < V_{DD} < 3.6\text{ V}$  | -   | 8   | 13.5 |      |
|                |                          | $1.62\text{ V} < V_{DD} < 3.6\text{ V}$ | -   | 8   | 18   |      |
| $t_{oh(TDO)}$  | TDO output hold time     | -                                       | 7   | -   | -    |      |

1. Guaranteed by characterization results.

Table 107. Dynamics SWD characteristics<sup>(1)</sup>

| Symbol           | Parameter               | Conditions                              | Min | Typ | Max  | Unit |
|------------------|-------------------------|---|-----|-----|------|------|
| $F_{pp}$         | SWCLK clock frequency   | $2.7\text{ V} < V_{DD} < 3.6\text{ V}$  | -   | -   | 71   | MHz  |
| $1/t_{c(SWCLK)}$ |                         | $1.62\text{ V} < V_{DD} < 3.6\text{ V}$ | -   | -   | 55.5 |      |
| $t_{isu(SWDIO)}$ | SWDIO input setup time  | -                                       | 2.5 | -   | -    | ns   |
| $t_{ih(SWDIO)}$  | SWDIO input hold time   | -                                       | 1   | -   | -    |      |
| $t_{ov(SWDIO)}$  | SWDIO output valid time | $2.7\text{ V} < V_{DD} < 3.6\text{ V}$  | -   | 8.5 | 14   |      |
|                  |                         | $1.62\text{ V} < V_{DD} < 3.6\text{ V}$ | -   | 8.5 | 18   |      |
| $t_{oh(SWDIO)}$  | SWDIO output hold time  | -                                       | 8   | -   | -    |      |

1. Guaranteed by characterization results.

Figure 61. JTAG timing diagram

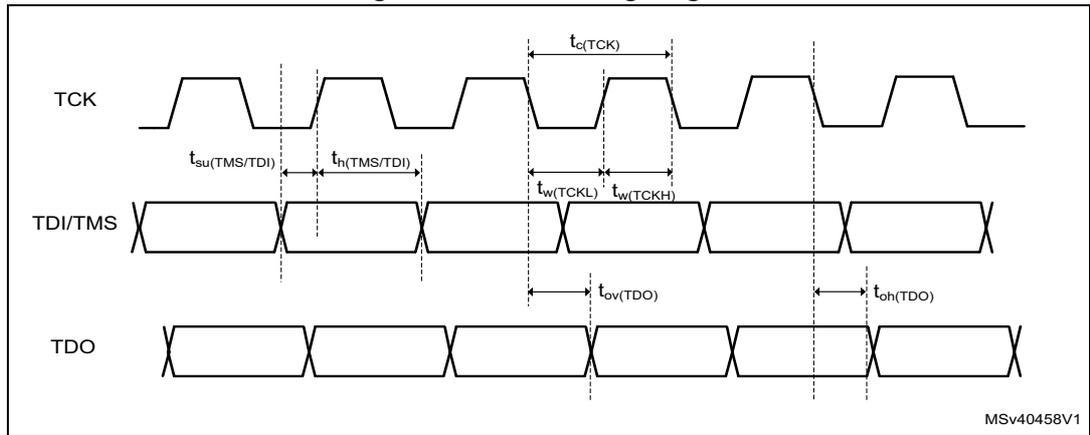
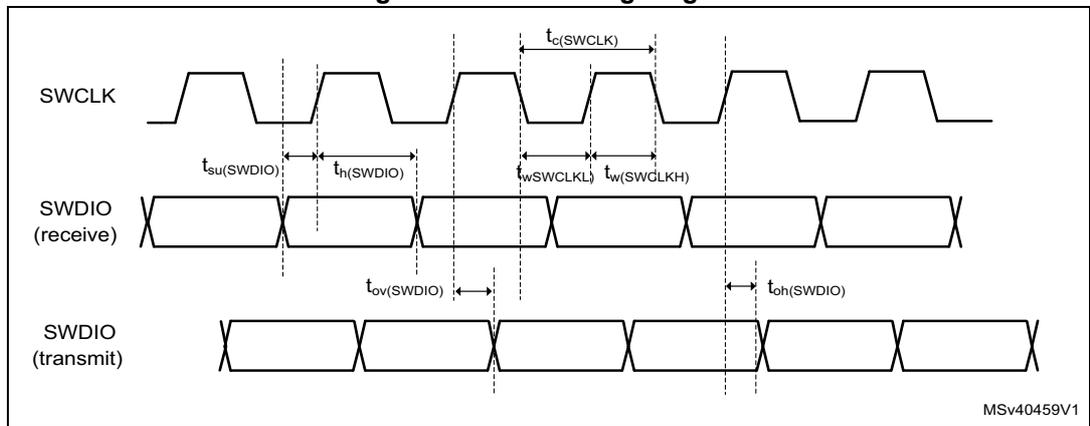


Figure 62. SWD timing diagram



## 7 Electrical characteristics (rev V)

### 7.1 Parameter conditions

Unless otherwise specified, all voltages are referenced to  $V_{SS}$ .

#### 7.1.1 Minimum and maximum values

Unless otherwise specified the minimum and maximum values are guaranteed in the worst conditions of junction temperature, supply voltage and frequencies by tests in production on 100% of the devices with an junction temperature at  $T_J = 25\text{ °C}$  and  $T_J = T_{Jmax}$  (given by the selected temperature range).

Data based on characterization results, design simulation and/or technology characteristics are indicated in the table footnotes. Based on characterization, the minimum and maximum values refer to sample tests and represent the mean value plus or minus three times the standard deviation ( $\text{mean} \pm 3\sigma$ ).

#### 7.1.2 Typical values

Unless otherwise specified, typical data are based on  $T_J = 25\text{ °C}$ ,  $V_{DD} = 3.3\text{ V}$  (for the  $1.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$  voltage range). They are given only as design guidelines and are not tested.

Typical ADC accuracy values are determined by characterization of a batch of samples from a standard diffusion lot over the full temperature range, where 95% of the devices have an error less than or equal to the value indicated ( $\text{mean} \pm 2\sigma$ ).

#### 7.1.3 Typical curves

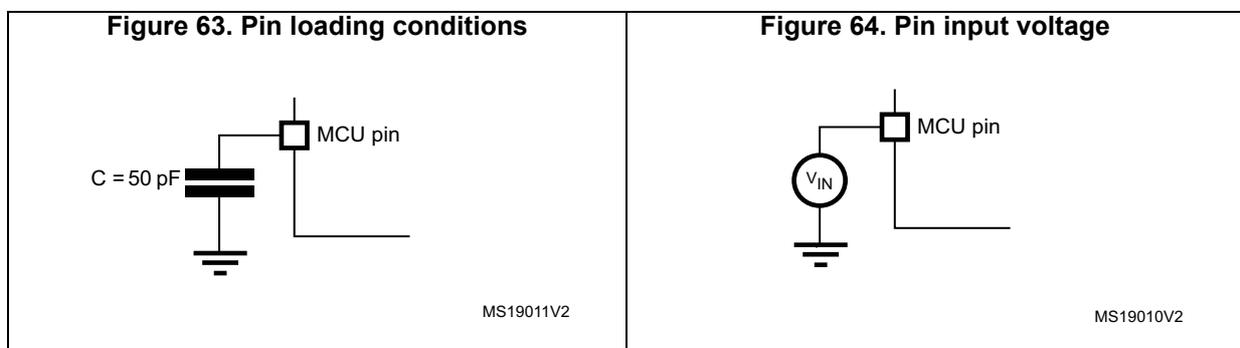
Unless otherwise specified, all typical curves are given only as design guidelines and are not tested.

#### 7.1.4 Loading capacitor

The loading conditions used for pin parameter measurement are shown in [Figure 63](#).

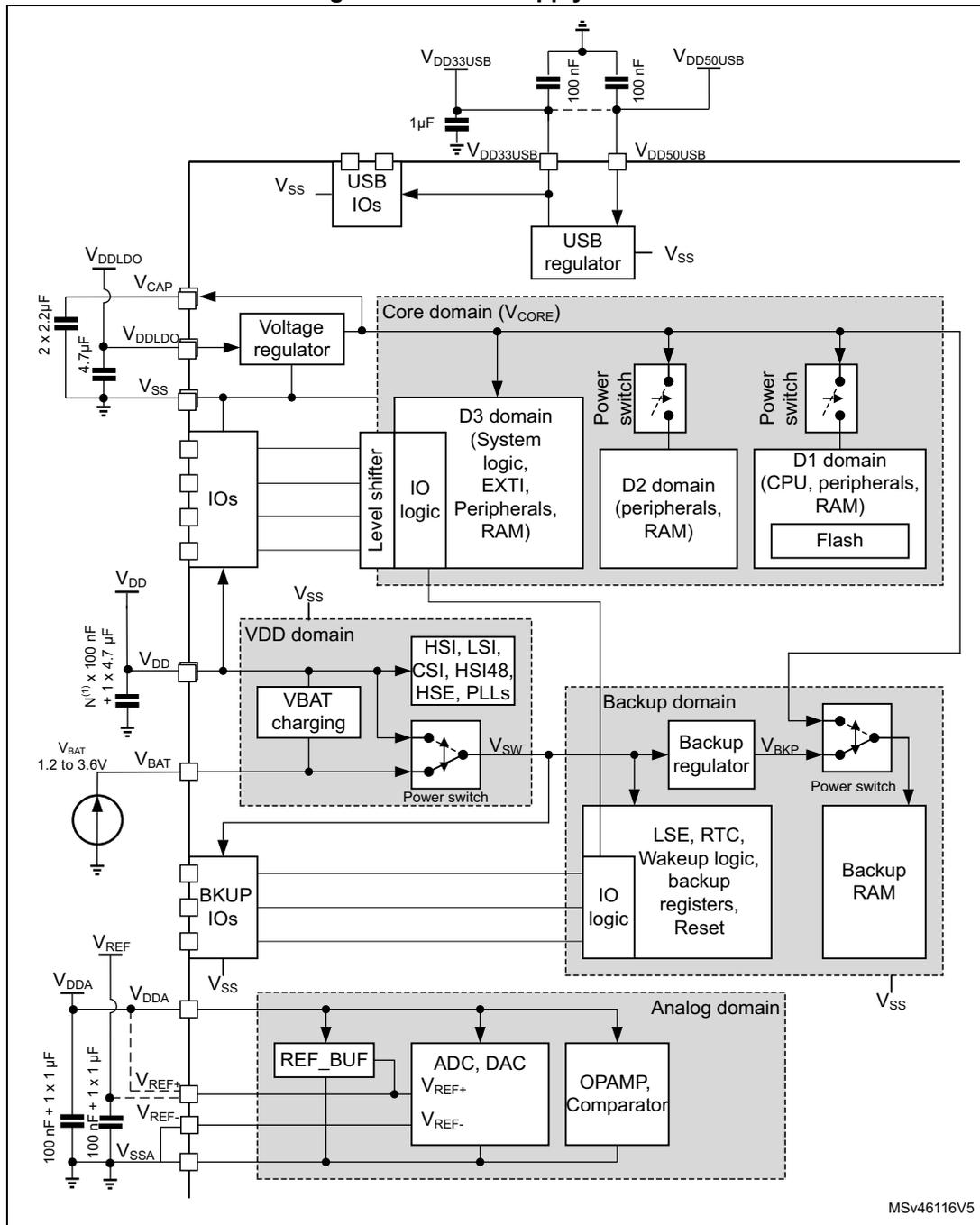
#### 7.1.5 Pin input voltage

The input voltage measurement on a pin of the device is described in [Figure 64](#).



7.1.6 Power supply scheme

Figure 65. Power supply scheme



MSv46116V5

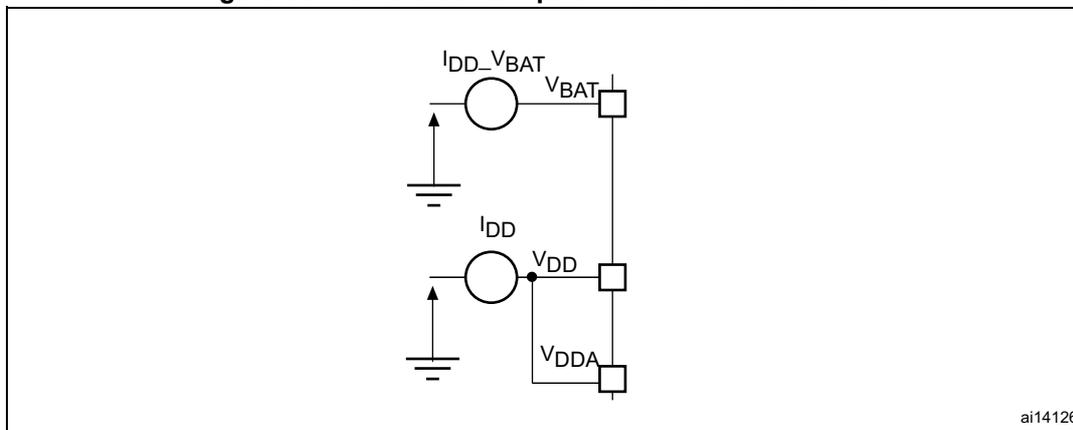
1. N corresponds to the number of VDD pins available on the package.
2. A tolerance of +/- 20% is acceptable on decoupling capacitors.

**Caution:** Each power supply pair ( $V_{DD}/V_{SS}$ ,  $V_{DDA}/V_{SSA}$  ...) must be decoupled with filtering ceramic capacitors as shown above. These capacitors must be placed as close as possible to, or below, the appropriate pins on the underside of the PCB to ensure good operation of the

device. It is not recommended to remove filtering capacitors to reduce PCB size or cost. This might cause incorrect operation of the device.

### 7.1.7 Current consumption measurement

Figure 66. Current consumption measurement scheme



## 7.2 Absolute maximum ratings

Stresses above the absolute maximum ratings listed in [Table 108: Voltage characteristics](#), [Table 109: Current characteristics](#), and [Table 110: Thermal characteristics](#) may cause permanent damage to the device. These are stress ratings only and the functional operation of the device at these conditions is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability. Device mission profile (application conditions) is compliant with JEDEC JESD47 Qualification Standard, extended mission profiles are available on demand.

Note: For information on product lifetime estimation, refer to application note AN5337: Guidelines for estimating STM32H7 MCUs lifetime, available from the STMicroelectronics website [www.st.com](http://www.st.com).

Table 108. Voltage characteristics (1)

| Symbols            | Ratings  | Min          | Max  | Unit |
|--------------------|--|--------------|--|------|
| $V_{DDX} - V_{SS}$ | External main supply voltage (including $V_{DD}$ , $V_{DDLDO}$ , $V_{DDA}$ , $V_{DD33USB}$ , $V_{BAT}$ ) | -0.3         | 4.0  | V    |
| $V_{IN}^{(2)}$     | Input voltage on FT_XXX pins   | $V_{SS}-0.3$ | $\text{Min}(\text{Min}(V_{DD}, V_{DDA}, V_{DD33USB}, V_{BAT}) + 4.0, 6 \text{ V})^{(3)(4)(5)}$ | V    |
|                    | Input voltage on TT_XX pins  | $V_{SS}-0.3$ | 4.0  | V    |
|                    | Input voltage on BOOT0 pin   | $V_{SS}$     | 9.0  | V    |
|                    | Input voltage on any other pins  | $V_{SS}-0.3$ | 4.0  | V    |
| $ \Delta V_{DDX} $ | Variations between different $V_{DDX}$ power pins of the same domain                                     | -            | 50   | mV   |
| $ V_{SSx}-V_{SS} $ | Variations between all the different ground pins   | -            | 50   | mV   |

1. All main power ( $V_{DD}$ ,  $V_{DDA}$ ,  $V_{DD33USB}$ ,  $V_{BAT}$ ) and ground ( $V_{SS}$ ,  $V_{SSA}$ ) pins must always be connected to the external power supply, in the permitted range.
2.  $V_{IN}$  maximum must always be respected. Refer to [Table 145: I/O current injection susceptibility](#) for the maximum allowed injected current values.
3. This formula has to be applied on power supplies related to the IO structure described by the pin definition table.
4. To sustain a voltage higher than 4V the internal pull-up/pull-down resistors must be disabled.
5. When an FT\_a pin is used by an analog peripheral such as an ADC, the maximum  $V_{IN}$  is 4 V.

**Table 109. Current characteristics**

| Symbols                 | Ratings   | Max   | Unit |
|-------------------------|---|-------|------|
| $\Sigma IV_{DD}$        | Total current into sum of all $V_{DD}$ power lines (source) <sup>(1)</sup>      | 620   | mA   |
| $\Sigma IV_{SS}$        | Total current out of sum of all $V_{SS}$ ground lines (sink) <sup>(1)</sup>     | 620   |      |
| $IV_{DD}$               | Maximum current into each $V_{DD}$ power pin (source) <sup>(1)</sup>            | 100   |      |
| $IV_{SS}$               | Maximum current out of each $V_{SS}$ ground pin (sink) <sup>(1)</sup>           | 100   |      |
| $I_{IO}$                | Output current sunk by any I/O and control pin, except Px_C                     | 20    |      |
|                         | Output current sunk by Px_C pins  | 1     |      |
| $\Sigma I_{(PIN)}$      | Total output current sunk by sum of all I/Os and control pins <sup>(2)</sup>    | 140   |      |
|                         | Total output current sourced by sum of all I/Os and control pins <sup>(2)</sup> | 140   |      |
| $I_{INJ(PIN)}^{(3)(4)}$ | Injected current on FT_xxx, TT_xx, RST and B pins except PA4, PA5               | -5/+0 |      |
|                         | Injected current on PA4, PA5  | -0/0  |      |
| $\Sigma I_{INJ(PIN)}$   | Total injected current (sum of all I/Os and control pins) <sup>(5)</sup>        | ±25   |      |

1. All main power ( $V_{DD}$ ,  $V_{DDA}$ ,  $V_{DD33USB}$ ) and ground ( $V_{SS}$ ,  $V_{SSA}$ ) pins must always be connected to the external power supplies, in the permitted range.
2. This current consumption must be correctly distributed over all I/Os and control pins. The total output current must not be sunk/sourced between two consecutive power supply pins referring to high pin count QFP packages.
3. Positive injection is not possible on these I/Os and does not occur for input voltages lower than the specified maximum value.
4. A positive injection is induced by  $V_{IN} > V_{DD}$  while a negative injection is induced by  $V_{IN} < V_{SS}$ .  $I_{INJ(PIN)}$  must never be exceeded. Refer also to [Table 108: Voltage characteristics](#) for the maximum allowed input voltage values.
5. When several inputs are submitted to a current injection, the maximum  $\Sigma I_{INJ(PIN)}$  is the absolute sum of the positive and negative injected currents (instantaneous values).

**Table 110. Thermal characteristics**

| Symbol    | Ratings                      | Value       | Unit |
|-----------|------------------------------|-------------|------|
| $T_{STG}$ | Storage temperature range    | -65 to +150 | °C   |
| $T_J$     | Maximum junction temperature | 125         |      |

## 7.3 Operating conditions

### 7.3.1 General operating conditions

Table 111. General operating conditions

| Symbol        | Parameter  | Operating conditions                                       | Min                 | Typ  | Max   | Unit |
|---------------|--|--|---------------------|------|---|------|
| $V_{DD}$      | Standard operating voltage   | -  | 1.62 <sup>(1)</sup> | -    | 3.6   | V    |
| $V_{DDLDO}$   | Supply voltage for the internal regulator  | $V_{DDLDO} \leq V_{DD}$                                    | 1.62 <sup>(1)</sup> | -    | 3.6   | V    |
| $V_{DD33USB}$ | Standard operating voltage, USB domain   | USB used   | 3.0                 | -    | 3.6   | V    |
|               |  | USB not used   | 0                   | -    | 3.6   |      |
| $V_{DDA}$     | Analog operating voltage   | ADC or COMP used   | 1.62                | -    | 3.6   | V    |
|               |  | DAC used   | 1.8                 | -    |   |      |
|               |  | OPAMP used   | 2.0                 | -    |   |      |
|               |  | VREFBUF used   | 1.8                 | -    |   |      |
|               |  | ADC, DAC, OPAMP, COMP, VREFBUF not used                    | 0                   | -    |   |      |
| $V_{IN}$      | I/O Input voltage  | TT_xx I/O  | -0.3                | -    | $V_{DD}+0.3$  | V    |
|               |  | BOOT0  | 0                   | -    | 9   |      |
|               |  | All I/O except BOOT0 and TT_xx                             | -0.3                | -    | $\text{Min}(V_{DD}, V_{DDA}, V_{DD33USB}) + 3.6V < 5.5V^{(2)(3)}$ |      |
| $V_{CORE}$    | Internal regulator ON (LDO)  | VOS3 (max frequency 200 MHz)                               | 0.95                | 1.0  | 1.05  | V    |
|               |  | VOS2 (max frequency 300 MHz)                               | 1.05                | 1.10 | 1.15  |      |
|               |  | VOS1 (max frequency 400 MHz)                               | 1.15                | 1.20 | 1.26  |      |
|               |  | VOS0 <sup>(4)</sup> (max frequency 480 MHz) <sup>(5)</sup> | 1.26                | 1.35 | 1.40  |      |
|               | Regulator OFF: external $V_{CORE}$ voltage must be supplied from external regulator on two VCAP pins | VOS3 (max frequency 200 MHz)                               | 0.98                | 1.03 | 1.08  |      |
|               |  | VOS2 (max frequency 300 MHz)                               | 1.08                | 1.13 | 1.17  |      |
|               |  | VOS1 (max frequency 400 MHz)                               | 1.17                | 1.23 | 1.26  |      |
|               |  | VOS0 (max frequency 480 MHz)                               | 1.37                | 1.38 | 1.40  |      |

Table 111. General operating conditions (continued)

| Symbol            | Parameter                                    | Operating conditions                 | Min | Typ | Max                | Unit |
|-------------------|--|--------------------------------------|-----|-----|--------------------|------|
| f <sub>CPU</sub>  | Arm® Cortex®-M7 clock frequency              | VOS3                                 | -   | -   | 200                | MHz  |
|                   |  | VOS2                                 | -   | -   | 300                |      |
|                   |  | VOS1                                 | -   | -   | 400                |      |
|                   |  | VOS0                                 | -   | -   | 480                |      |
| f <sub>HCLK</sub> | AHB clock frequency                          | VOS3                                 | -   | -   | 100                | MHz  |
|                   |  | VOS2                                 | -   | -   | 150                |      |
|                   |  | VOS1                                 | -   | -   | 200                |      |
|                   |  | VOS0                                 | -   | -   | 240 <sup>(5)</sup> |      |
| f <sub>PCLK</sub> | APB clock frequency                          | VOS3                                 | -   | -   | 50 <sup>(6)</sup>  | MHz  |
|                   |  | VOS2                                 | -   | -   | 75                 |      |
|                   |  | VOS1                                 | -   | -   | 100                |      |
|                   |  | VOS0                                 | -   | -   | 120 <sup>(5)</sup> |      |
| T <sub>A</sub>    | Ambient temperature for the suffix 6 version | Maximum power dissipation            |     | -40 | 85                 | °C   |
|                   |  | Low-power dissipation <sup>(7)</sup> |     | -40 | 105                |      |
|                   | Ambient temperature for the suffix 3 version | Maximum power dissipation            |     | -40 | 125                |      |
|                   |  | Low-power dissipation <sup>(7)</sup> |     | -40 | 130                |      |
| T <sub>J</sub>    | Junction temperature range                   | Suffix 6 version                     |     | -40 | 125                | °C   |

- When RESET is released functionality is guaranteed down to V<sub>BOR0</sub> min
- This formula has to be applied on power supplies related to the IO structure described by the pin definition table.
- For operation with voltage higher than Min (V<sub>DD</sub>, V<sub>DDA</sub>, V<sub>DD33USB</sub>) +0.3V, the internal Pull-up and Pull-Down resistors must be disabled.
- VOS0 is available only when the LDO regulator is ON.
- T<sub>JMax</sub> = 105 °C.
- Maximum APB clock frequency when at least one peripheral is enabled.
- In low-power dissipation state, T<sub>A</sub> can be extended to this range as long as T<sub>J</sub> does not exceed T<sub>Jmax</sub> (see [Section 8.10: Thermal characteristics](#)).

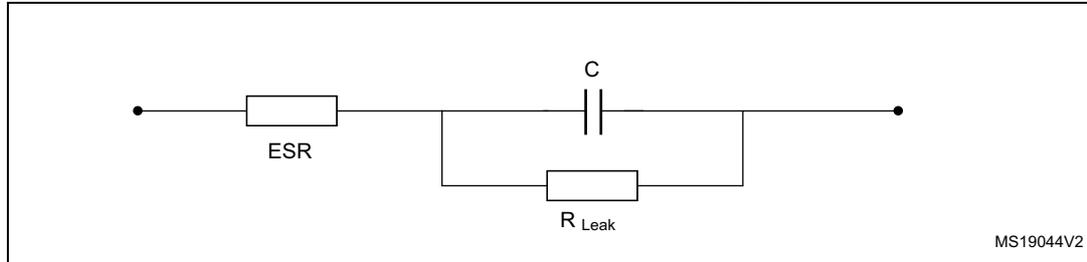
Table 112. Supply voltage and maximum frequency configuration

| Power scale | V <sub>CORE</sub> source | Max T <sub>J</sub> (°C) | Max frequency (MHz) | Min V <sub>DDLDO</sub> (V) |
|-------------|--------------------------|-------------------------|---------------------|----------------------------|
| VOS0        | LDO                      | 105                     | 480                 | 1.7                        |
| VOS1        | LDO                      | 125                     | 400                 | 1.62                       |
| VOS2        | LDO                      | 125                     | 300                 | 1.62                       |
| VOS3        | LDO                      | 125                     | 200                 | 1.62                       |
| SVOS4       | LDO                      | 105                     | N/A                 | 1.62                       |
| SVOS5       | LDO                      | 105                     | N/A                 | 1.62                       |

### 7.3.2 VCAP external capacitor

Stabilization for the main regulator is achieved by connecting an external capacitor  $C_{EXT}$  to the VCAP pin.  $C_{EXT}$  is specified in [Table 113](#). Two external capacitors can be connected to VCAP pins.

Figure 67. External capacitor  $C_{EXT}$



1. Legend: ESR is the equivalent series resistance.

Table 113. VCAP operating conditions<sup>(1)</sup>

| Symbol           | Parameter                         | Conditions                 |
|------------------|-----------------------------------|----------------------------|
| C <sub>EXT</sub> | Capacitance of external capacitor | 2.2 $\mu$ F <sup>(2)</sup> |
| ESR              | ESR of external capacitor         | < 100 m $\Omega$           |

1. In bypass mode, the two 2.2  $\mu$ F VCAP capacitors are not required and should be replaced by two 100 nF decoupling capacitors
2. This value corresponds to C<sub>EXT</sub> typical value. A variation of +/-20% is tolerated.

### 7.3.3 Operating conditions at power-up / power-down

Subject to general operating conditions for  $T_A$ .

Table 114. Operating conditions at power-up / power-down (regulator ON)

| Symbol       | Parameter                  | Min | Max      | Unit      |
|--------------|----------------------------|-----|----------|-----------|
| $t_{VDD}$    | $V_{DD}$ rise time rate    | 0   | $\infty$ | $\mu$ s/V |
|              | $V_{DD}$ fall time rate    | 10  | $\infty$ |           |
| $t_{VDDA}$   | $V_{DDA}$ rise time rate   | 0   | $\infty$ |           |
|              | $V_{DDA}$ fall time rate   | 10  | $\infty$ |           |
| $t_{VDDUSB}$ | $V_{DDUSB}$ rise time rate | 0   | $\infty$ |           |
|              | $V_{DDUSB}$ fall time rate | 10  | $\infty$ |           |

### 7.3.4 Embedded reset and power control block characteristics

The parameters given in [Table 115](#) are derived from tests performed under ambient temperature and  $V_{DD}$  supply voltage conditions summarized in [Table 111: General operating conditions](#).

**Table 115. Reset and power control block characteristics**

| Symbol                   | Parameter  | Conditions                 | Min  | Typ  | Max   | Unit    |
|--------------------------|--|----------------------------|------|------|-------|---------|
| $t_{RSTTEMPO}^{(1)}$     | Reset temporization after BOR0 released                            | -                          | -    | 377  | -     | $\mu s$ |
| $V_{BOR0/POR/PDR}$       | Brown-out reset threshold 0 ( $V_{POR}/V_{PDR}$ thresholds)        | Rising edge <sup>(1)</sup> | 1.62 | 1.67 | 1.71  | V       |
|                          |  | Falling edge               | 1.58 | 1.62 | 1.68  |         |
| $V_{BOR1}$               | Brown-out reset threshold 1  | Rising edge                | 2.04 | 2.10 | 2.15  |         |
|                          |  | Falling edge               | 1.95 | 2.00 | 2.06  |         |
| $V_{BOR2}$               | Brown-out reset threshold 2  | Rising edge                | 2.34 | 2.41 | 2.47  |         |
|                          |  | Falling edge               | 2.25 | 2.31 | 2.37  |         |
| $V_{BOR3}$               | Brown-out reset threshold 3  | Rising edge                | 2.63 | 2.70 | 2.78  |         |
|                          |  | Falling edge               | 2.54 | 2.61 | 2.68  |         |
| $V_{PVD0}$               | Programmable Voltage Detector threshold 0                          | Rising edge                | 1.90 | 1.96 | 2.01  |         |
|                          |  | Falling edge               | 1.81 | 1.86 | 1.91  |         |
| $V_{PVD1}$               | Programmable Voltage Detector threshold 1                          | Rising edge                | 2.05 | 2.10 | 2.16  |         |
|                          |  | Falling edge               | 1.96 | 2.01 | 2.06  |         |
| $V_{PVD2}$               | Programmable Voltage Detector threshold 2                          | Rising edge                | 2.19 | 2.26 | 2.32  |         |
|                          |  | Falling edge               | 2.10 | 2.15 | 2.21  |         |
| $V_{PVD3}$               | Programmable Voltage Detector threshold 3                          | Rising edge                | 2.35 | 2.41 | 2.47  |         |
|                          |  | Falling edge               | 2.25 | 2.31 | 2.37  |         |
| $V_{PVD4}$               | Programmable Voltage Detector threshold 4                          | Rising edge                | 2.49 | 2.56 | 2.62  |         |
|                          |  | Falling edge               | 2.39 | 2.45 | 2.51  |         |
| $V_{PVD5}$               | Programmable Voltage Detector threshold 5                          | Rising edge                | 2.64 | 2.71 | 2.78  |         |
|                          |  | Falling edge               | 2.55 | 2.61 | 2.68  |         |
| $V_{PVD6}$               | Programmable Voltage Detector threshold 6                          | Rising edge                | 2.78 | 2.86 | 2.94  |         |
|                          |  | Falling edge in Run mode   | 2.69 | 2.76 | 2.83  |         |
| $V_{hyst\_BOR\_PVD}$     | Hysteresis voltage of BOR (unless BOR0) and PVD                    | Hysteresis in Run mode     | -    | 100  | -     | mV      |
| $I_{DD\_BOR\_PVD}^{(1)}$ | BOR <sup>(2)</sup> (unless BOR0) and PVD consumption from $V_{DD}$ | -                          | -    | -    | 0.630 | $\mu A$ |

Table 115. Reset and power control block characteristics (continued)

| Symbol                 | Parameter  | Conditions      | Min  | Typ  | Max  | Unit |    |
|------------------------|--|-----------------|------|------|------|------|----|
| V <sub>AVM_0</sub>     | Analog voltage detector for V <sub>DDA</sub> threshold 0 | Rising edge     | 1.66 | 1.71 | 1.76 | V    |    |
|                        |  | Falling edge    | 1.56 | 1.61 | 1.66 |      |    |
| V <sub>AVM_1</sub>     | Analog voltage detector for V <sub>DDA</sub> threshold 1 | Rising edge     | 2.06 | 2.12 | 2.19 |      |    |
|                        |  | Falling edge    | 1.96 | 2.02 | 2.08 |      |    |
| V <sub>AVM_2</sub>     | Analog voltage detector for V <sub>DDA</sub> threshold 2 | Rising edge     | 2.42 | 2.50 | 2.58 |      |    |
|                        |  | Falling edge    | 2.35 | 2.42 | 2.49 |      |    |
| V <sub>AVM_3</sub>     | Analog voltage detector for V <sub>DDA</sub> threshold 3 | Rising edge     | 2.74 | 2.83 | 2.91 |      |    |
|                        |  | Falling edge    | 2.64 | 2.72 | 2.80 |      |    |
| V <sub>hyst_VDDA</sub> | Hysteresis of V <sub>DDA</sub> voltage detector          | -               | -    | 100  | -    |      | mV |
| I <sub>DD_PVM</sub>    | PVM consumption from V <sub>DD</sub> (1)                 | -               | -    | -    | 0.25 |      | μA |
| I <sub>DD_VDDA</sub>   | Voltage detector consumption on V <sub>DDA</sub> (1)     | Resistor bridge | -    | -    | 2.5  | μA   |    |

1. Guaranteed by design.
2. BOR0 is enabled in all modes and its consumption is therefore included in the supply current characteristics tables (refer to [Section 7.3.6: Supply current characteristics](#)).

### 7.3.5 Embedded reference voltage

The parameters given in [Table 116](#) are derived from tests performed under ambient temperature and V<sub>DD</sub> supply voltage conditions summarized in [Table 111: General operating conditions](#).

Table 116. Embedded reference voltage

| Symbol                        | Parameter   | Conditions  | Min   | Typ   | Max   | Unit   |
|-------------------------------|---|---|-------|-------|-------|--------|
| V <sub>REFINT</sub>           | Internal reference voltages   | -40°C < T <sub>J</sub> < 125 °C,<br>V <sub>DD</sub> = 3.3 V | 1.180 | 1.216 | 1.255 | V      |
| t <sub>S_vrefint</sub> (1)(2) | ADC sampling time when reading the internal reference voltage       | -   | 4.3   | -     | -     | μs     |
| t <sub>S_vbat</sub> (1)(2)    | VBAT sampling time when reading the internal VBAT reference voltage | -   | 9     | -     | -     |        |
| I <sub>refbuf</sub> (2)       | Reference Buffer consumption for ADC                                | V <sub>DDA</sub> =3.3 V                                     | 9     | 13.5  | 23    | μA     |
| Δ V <sub>REFINT</sub> (2)     | Internal reference voltage spread over the temperature range        | -40°C < T <sub>J</sub> < 125 °C                             | -     | 5     | 15    | mV     |
| T <sub>coeff</sub> (2)        | Average temperature coefficient                                     | Average temperature coefficient                             | -     | 20    | 70    | ppm/°C |
| V <sub>DDcoeff</sub> (2)      | Average Voltage coefficient   | 3.0V < V <sub>DD</sub> < 3.6V                               | -     | 10    | 1370  | ppm/V  |

**Table 116. Embedded reference voltage (continued)**

| Symbol                   | Parameter             | Conditions | Min | Typ | Max | Unit                     |
|--------------------------|-----------------------|------------|-----|-----|-----|--------------------------|
| V <sub>REFINT_DIV1</sub> | 1/4 reference voltage | -          | -   | 25  | -   | %<br>V <sub>REFINT</sub> |
| V <sub>REFINT_DIV2</sub> | 1/2 reference voltage | -          | -   | 50  | -   |                          |
| V <sub>REFINT_DIV3</sub> | 3/4 reference voltage | -          | -   | 75  | -   |                          |

1. The shortest sampling time for the application can be determined by multiple iterations.
2. Guaranteed by design.

**Table 117. Internal reference voltage calibration values**

| Symbol                 | Parameter   | Memory address      |
|------------------------|---|---------------------|
| V <sub>REFIN_CAL</sub> | Raw data acquired at temperature of 30 °C, V <sub>DDA</sub> = 3.3 V | 1FF1E860 - 1FF1E861 |

### 7.3.6 Supply current characteristics

The current consumption is a function of several parameters and factors such as the operating voltage, ambient temperature, I/O pin loading, device software configuration, operating frequencies, I/O pin switching rate, program location in memory and executed binary code.

The current consumption is measured as described in [Figure 66: Current consumption measurement scheme](#).

All the run-mode current consumption measurements given in this section are performed with a CoreMark code.

#### Typical and maximum current consumption

The MCU is placed under the following conditions:

- All I/O pins are in analog input mode.
- All peripherals are disabled except when explicitly mentioned.
- The flash memory access time is adjusted with the minimum wait states number, depending on the f<sub>ACLK</sub> frequency (refer to the table “Number of wait states according to CPU clock (f<sub>CC\_CK</sub>) frequency and V<sub>CORE</sub> range” available in the reference manual).
- When the peripherals are enabled, the AHB clock frequency is the CPU frequency divided by 2 and the APB clock frequency is AHB clock frequency divided by 2.

The parameters given in the below tables are derived from tests performed under ambient temperature and supply voltage conditions summarized in [Table 111: General operating conditions](#).

**Table 118. Typical and maximum current consumption in Run mode, code with data processing running from ITCM, LDO regulator ON<sup>(1)</sup>**

| Symbol          | Parameter                  | Conditions               | f <sub>HCLK</sub><br>(MHz) | Typ | Max <sup>(2)</sup>       |                          |                           |                           | Unit |    |
|-----------------|----------------------------|--------------------------|----------------------------|-----|--------------------------|--------------------------|---------------------------|---------------------------|------|----|
|                 |                            |                          |                            |     | T <sub>j</sub> =25<br>°C | T <sub>j</sub> =85<br>°C | T <sub>j</sub> =105<br>°C | T <sub>j</sub> =125<br>°C |      |    |
| I <sub>DD</sub> | Supply current in Run mode | All peripherals disabled | VOS0                       | 480 | 148                      | 226                      | 307                       | 390                       | -    | mA |
|                 |                            |                          |                            | 400 | 125                      | -                        | -                         | -                         | -    |    |
|                 |                            |                          | VOS1                       | 400 | 110                      | 168                      | 230                       | 296                       | 384  |    |
|                 |                            |                          |                            | 300 | 84                       | -                        | -                         | -                         | -    |    |
|                 |                            |                          | VOS2                       | 300 | 76                       | 114                      | 170                       | 224                       | 297  |    |
|                 |                            |                          |                            | 216 | 56                       | 88                       | 152                       | 205                       | 278  |    |
|                 |                            |                          | VOS3                       | 200 | 53                       | -                        | -                         | -                         | -    |    |
|                 |                            |                          |                            | 200 | 47                       | 71                       | 121                       | 164                       | 223  |    |
|                 |                            |                          |                            | 180 | 43                       | 64                       | 116                       | 159                       | 218  |    |
|                 |                            |                          |                            | 168 | 40                       | 63                       | 115                       | 158                       | 217  |    |
|                 |                            | 144                      |                            | 35  | 55                       | 109                      | 153                       | 212                       |      |    |
|                 |                            | 60                       |                            | 16  | 36                       | 92                       | 135                       | 194                       |      |    |
|                 |                            | All peripherals enabled  | VOS0                       | 25  | 12                       | 24                       | 83                        | 126                       | 185  |    |
|                 |                            |                          |                            | 480 | 226                      | 348                      | 439                       | 550                       | -    |    |
|                 |                            |                          | VOS1                       | 400 | 190                      | -                        | -                         | -                         | -    |    |
|                 |                            |                          |                            | 400 | 167                      | 256                      | 327                       | 416                       | 536  |    |
|                 |                            |                          | VOS2                       | 300 | 135                      | -                        | -                         | -                         | -    |    |
|                 |                            |                          |                            | 300 | 122                      | 183                      | 248                       | 320                       | 419  |    |
|                 |                            |                          | VOS3                       | 200 | 85                       | -                        | -                         | -                         | -    |    |
|                 |                            |                          |                            | 200 | 76                       | 116                      | 174                       | 233                       | 313  |    |

1. Data are in DTCM for best computation performance, the cache has no influence on consumption in this case.
2. Guaranteed by characterization results, unless otherwise specified.

**Table 119. Typical and maximum current consumption in Run mode, code with data processing running from flash memory, cache ON, LDO regulator ON**

| Symbol          | Parameter                  | Conditions               | f <sub>HCLK</sub> (MHz) | Typ  | Max <sup>(1)</sup>    |                       |                        |                        | Unit |    |
|-----------------|----------------------------|--------------------------|-------------------------|------|-----------------------|-----------------------|------------------------|------------------------|------|----|
|                 |                            |                          |                         |      | T <sub>j</sub> =25 °C | T <sub>j</sub> =85 °C | T <sub>j</sub> =105 °C | T <sub>j</sub> =125 °C |      |    |
| I <sub>DD</sub> | Supply current in Run mode | All peripherals disabled | VOS0                    | 480  | 110                   | 222                   | 304                    | 388                    | -    | mA |
|                 |                            |                          |                         | 400  | 91                    | -                     | -                      | -                      | -    |    |
|                 |                            |                          | VOS1                    | 400  | 80                    | 162                   | 228                    | 294                    | 381  |    |
|                 |                            |                          |                         | 300  | 61.5                  | -                     | -                      | -                      | -    |    |
|                 |                            |                          | VOS2                    | 300  | 55                    | 111                   | 168                    | 222                    | 294  |    |
|                 |                            |                          |                         | 200  | 38.5                  | -                     | -                      | -                      | -    |    |
|                 |                            | VOS3                     | 200                     | 34.5 | 69                    | 120                   | 163                    | 222                    |      |    |
|                 |                            | All peripherals enabled  | VOS0                    | 480  | 220                   | 342                   | 436                    | 546                    | -    |    |
|                 |                            |                          |                         | 400  | 195                   | -                     | -                      | -                      | -    |    |
|                 |                            |                          | VOS1                    | 400  | 175                   | 264                   | 336                    | 424                    | 544  |    |
|                 |                            |                          |                         | 300  | 135                   | -                     | -                      | -                      | -    |    |
|                 |                            |                          | VOS2                    | 300  | 120                   | 180                   | 246                    | 318                    | 418  |    |
|                 |                            |                          |                         | 200  | 83                    | -                     | -                      | -                      | -    |    |
|                 |                            | VOS3                     | 200                     | 75   | 114                   | 173                   | 232                    | 312                    |      |    |

1. Guaranteed by characterization results, unless otherwise specified.

**Table 120. Typical and maximum current consumption in Run mode, code with data processing running from flash memory, cache OFF, LDO regulator ON**

| Symbol          | Parameter                  | Conditions               | f <sub>HCLK</sub> (MHz) | Typ | Max <sup>(1)</sup>    |                       |                        |                        | Unit |    |
|-----------------|----------------------------|--------------------------|-------------------------|-----|-----------------------|-----------------------|------------------------|------------------------|------|----|
|                 |                            |                          |                         |     | T <sub>j</sub> =25 °C | T <sub>j</sub> =85 °C | T <sub>j</sub> =105 °C | T <sub>j</sub> =125 °C |      |    |
| I <sub>DD</sub> | Supply current in Run mode | All peripherals disabled | VOS0                    | 480 | 87                    | 157                   | 259                    | 342                    | 453  | mA |
|                 |                            |                          | VOS1                    | 400 | 73                    | 123                   | 201                    | 267                    | 355  |    |
|                 |                            |                          | VOS2                    | 300 | 52                    | 85                    | 150                    | 204                    | 277  |    |
|                 |                            |                          | VOS3                    | 200 | 34                    | 54                    | 109                    | 152                    | 212  |    |
|                 |                            | All peripherals enabled  | VOS0                    | 480 | 168                   | 276                   | 390                    | 504                    | 658  |    |
|                 |                            |                          | VOS1                    | 400 | 135                   | 224                   | 308                    | 397                    | 519  |    |
|                 |                            |                          | VOS2                    | 300 | 100                   | 154                   | 228                    | 301                    | 401  |    |
|                 |                            |                          | VOS3                    | 200 | 70                    | 103                   | 167                    | 226                    | 307  |    |

1. Guaranteed by characterization results, unless otherwise specified.

**Table 121. Typical and maximum current consumption batch acquisition mode, LDO regulator ON**

| Symbol          | Parameter                                | Conditions                     |      | f <sub>HCLK</sub> (MHz) | Typ | Max <sup>(1)</sup>   |                      |                       |                       | Unit |
|-----------------|--|--------------------------------|------|-------------------------|-----|----------------------|----------------------|-----------------------|-----------------------|------|
|                 |  |                                |      |                         |     | T <sub>j</sub> =25°C | T <sub>j</sub> =85°C | T <sub>j</sub> =105°C | T <sub>j</sub> =125°C |      |
| I <sub>DD</sub> | Supply current in batch acquisition mode | D1 Standby, D2 Standby, D3 Run | VOS3 | 64                      | 2.7 | 4.7                  | 12.9                 | 19.0                  | 27.5                  | mA   |
|                 |  |                                |      | 8                       | 1.1 | -                    | -                    | -                     | -                     |      |
|                 |  | D1 Stop, D2 Stop, D3 Run       | VOS3 | 64                      | 5.4 | 18.4                 | 83.7                 | 132.6                 | 202.4                 |      |
|                 |  |                                |      | 8                       | 3.8 | -                    | -                    | -                     | -                     |      |

1. Guaranteed by characterization results, unless otherwise specified.

**Table 122. Typical and maximum current consumption in Stop, LDO regulator ON**

| Symbol                 | Parameter                       | Conditions                |       | Typ  | Max <sup>(1)</sup>   |                      |                       |                       | Unit |
|------------------------|---------------------------------|---------------------------|-------|------|----------------------|----------------------|-----------------------|-----------------------|------|
|                        |                                 |                           |       |      | T <sub>j</sub> =25°C | T <sub>j</sub> =85°C | T <sub>j</sub> =105°C | T <sub>j</sub> =125°C |      |
| I <sub>DD</sub> (Stop) | D1 Stop, D2 Stop, D3 Stop       | Flash memory OFF, no IWDG | SVOS5 | 1.27 | 6.3                  | 42.5                 | 72.0                  | -                     |      |
|                        |                                 |                           | SVOS4 | 1.96 | 9.4                  | 57.4                 | 94.6                  | -                     |      |
|                        |                                 |                           | SVOS3 | 2.78 | 13.8                 | 75.9                 | 121.3                 | 183.8                 |      |
|                        |                                 | Flash memory ON, no IWDG  | SVOS5 | 1.27 | 6.3                  | 42.5                 | 72.0                  | -                     |      |
|                        |                                 |                           | SVOS4 | 2.25 | 9.8                  | 57.9                 | 95.2                  | -                     |      |
|                        |                                 |                           | SVOS3 | 3.07 | 14.1                 | 76.4                 | 122.0                 | 184.8                 |      |
|                        | D1 Stop, D2 Standby, D3 Stop    | Flash memory OFF, no IWDG | SVOS5 | 0.91 | 4.6                  | 30.4                 | 51.2                  | -                     |      |
|                        |                                 |                           | SVOS4 | 1.42 | 6.8                  | 41.1                 | 67.3                  | -                     |      |
|                        |                                 |                           | SVOS3 | 2.02 | 10.0                 | 54.4                 | 86.6                  | 130.0                 |      |
|                        |                                 | Flash memory ON, no IWDG  | SVOS5 | 0.91 | 4.6                  | 30.4                 | 51.2                  | -                     |      |
|                        |                                 |                           | SVOS4 | 1.70 | 7.2                  | 41.5                 | 67.9                  | -                     |      |
|                        |                                 |                           | SVOS3 | 2.31 | 10.3                 | 54.9                 | 87.1                  | 130.8                 |      |
|                        | D1 Standby, D2 Stop, D3 Stop    | Flash memory OFF, no IWDG | SVOS5 | 0.49 | 2.4                  | 16.5                 | 28.0                  | -                     |      |
|                        |                                 |                           | SVOS4 | 0.76 | 3.6                  | 22.2                 | 36.6                  | -                     |      |
|                        |                                 |                           | SVOS3 | 1.10 | 5.3                  | 29.3                 | 46.9                  | 71.2                  |      |
|                        | D1 Standby, D2 Standby, D3 Stop | Flash memory OFF, no IWDG | SVOS5 | 0.15 | 0.7                  | 4.3                  | 7.3                   | -                     |      |
|                        |                                 |                           | SVOS4 | 0.22 | 1.0                  | 5.8                  | 9.6                   | -                     |      |
|                        |                                 |                           | SVOS3 | 0.35 | 1.5                  | 7.8                  | 12.3                  | 18.6                  |      |

1. Guaranteed by characterization results, unless otherwise specified.

**Table 123. Typical and maximum current consumption in Sleep mode, LDO regulator**

| Symbol                  | Parameter                    | Conditions               |      | f <sub>HCLK</sub> (MHz) | Typ   | Max <sup>(1)</sup>    |                       |                        |                        | Unit |
|-------------------------|------------------------------|--------------------------|------|-------------------------|-------|-----------------------|-----------------------|------------------------|------------------------|------|
|                         |                              |                          |      |                         |       | T <sub>j</sub> =25 °C | T <sub>j</sub> =85 °C | T <sub>j</sub> =105 °C | T <sub>j</sub> =125 °C |      |
| I <sub>DD</sub> (Sleep) | Supply current in Sleep mode | All peripherals disabled | VOS0 | 480                     | 50.7  | 96.3                  | 253.4                 | 366.1                  | -                      | mA   |
|                         |                              |                          |      | 400                     | 43.4  | 87.8                  | 245.5                 | 357.9                  | -                      |      |
|                         |                              |                          | VOS1 | 400                     | 35.3  | 66.5                  | 181.3                 | 265.8                  | 379.6                  |      |
|                         |                              |                          |      | 300                     | 27.9  | -                     | -                     | -                      | -                      |      |
|                         |                              |                          | VOS2 | 300                     | 24.6  | 47.3                  | 139.1                 | 207.3                  | 300.4                  |      |
|                         |                              |                          |      | 200                     | 18.8  | -                     | -                     | -                      | -                      |      |
|                         |                              | VOS3                     | 200  | 16.5                    | 33.6  | 106.4                 | 160.9                 | 236.1                  |                        |      |
|                         |                              | All peripherals enabled  | VOS0 | 480                     | 136.0 | 194.7                 | 348.5                 | 464.4                  | -                      |      |
|                         |                              |                          |      | 400                     | 115.0 | 169.0                 | 325.9                 | 441.7                  | -                      |      |
|                         |                              |                          | VOS1 | 400                     | 97.7  | 138.2                 | 251.3                 | 338.4                  | 456.4                  |      |
|                         |                              |                          |      | 300                     | 74.9  | -                     | -                     | -                      | -                      |      |
|                         |                              |                          | VOS2 | 300                     | 67.3  | 95.8                  | 187.6                 | 257.9                  | 354.1                  |      |
|                         |                              |                          |      | 200                     | 52.8  | -                     | -                     | -                      | -                      |      |
|                         |                              |                          | VOS3 | 200                     | 47.1  | 69.3                  | 141.4                 | 197.7                  | 275.1                  |      |

1. Guaranteed by characterization results, unless otherwise specified.

**Table 124. Typical and maximum current consumption in Standby**

| Symbol                    | Parameter                      | Conditions  |             | Typ    |       |      |       | Max <sup>(1)</sup>    |                       |                        |                        | Unit |
|---------------------------|--------------------------------|-------------|-------------|--------|-------|------|-------|-----------------------|-----------------------|------------------------|------------------------|------|
|                           |                                |             |             | 1.62 V | 2.4 V | 3 V  | 3.3 V | 3 V                   |                       |                        |                        |      |
|                           |                                | Backup SRAM | RTC and LSE |        |       |      |       | T <sub>j</sub> =25 °C | T <sub>j</sub> =85 °C | T <sub>j</sub> =105 °C | T <sub>j</sub> =125 °C |      |
| I <sub>DD</sub> (Standby) | Supply current in Standby mode | OFF         | OFF         | 1,92   | 1,95  | 2,06 | 2,16  | 4                     | 18                    | 40                     | 90                     | µA   |
|                           |                                | ON          | OFF         | 3,33   | 3,44  | 3,6  | 3,79  | 8.2                   | 47                    | 83                     | 141                    |      |
|                           |                                | OFF         | ON          | 2,43   | 2,57  | 2,77 | 2,95  | -                     | -                     | -                      | -                      |      |
|                           |                                | ON          | ON          | 3,82   | 4,05  | 4,31 | 4,55  | -                     | -                     | -                      | -                      |      |

1. Guaranteed by characterization results, unless otherwise specified.

**Table 125. Typical and maximum current consumption in V<sub>BAT</sub> mode**

| Symbol                    | Parameter                               | Conditions  |             | Typ   |      |      |       | Max <sup>(1)</sup>    |                       |                        |                        | Unit |
|---------------------------|---|-------------|-------------|-------|------|------|-------|-----------------------|-----------------------|------------------------|------------------------|------|
|                           |   | Backup SRAM | RTC and LSE | 1.2 V | 2 V  | 3 V  | 3.4 V | 3 V                   |                       |                        |                        |      |
|                           |   |             |             |       |      |      |       | T <sub>j</sub> =25 °C | T <sub>j</sub> =85 °C | T <sub>j</sub> =105 °C | T <sub>j</sub> =125 °C |      |
| I <sub>DD</sub><br>(VBAT) | Supply current in V <sub>BAT</sub> mode | OFF         | OFF         | 0,02  | 0,02 | 0,03 | 0,05  | 0,5                   | 4,1                   | 10                     | 24                     | µA   |
|                           |   | ON          | OFF         | 1,33  | 1,45 | 1,58 | 1,7   | 4,4                   | 22                    | 48                     | 87                     |      |
|                           |   | OFF         | ON          | 0,46  | 0,57 | 0,75 | 0,87  | -                     | -                     | -                      | -                      |      |
|                           |   | ON          | ON          | 1,77  | 2    | 2,3  | 2,5   | -                     | -                     | -                      | -                      |      |

1. Guaranteed by characterization results, unless otherwise specified.

### I/O system current consumption

The current consumption of the I/O system has two components: static and dynamic.

#### I/O static current consumption

All the I/Os used as inputs with pull-up or pull-down generate a current consumption when the pin is externally held low. The value of this current consumption can be simply computed by using the pull-up/pull-down resistors values given in [Table 146: I/O static characteristics](#).

For the output pins, any internal or external pull-up or pull-down, and any external load must also be considered to estimate the current consumption.

An additional I/O current consumption is due to I/Os configured as inputs if an intermediate voltage level is externally applied. This current consumption is caused by the input Schmitt trigger circuits used to discriminate the input value. Unless this specific configuration is required by the application, this supply current consumption can be avoided by configuring these I/Os in analog mode. This is notably the case of ADC input pins which should be configured as analog inputs.

**Caution:** Any floating input pin can also settle to an intermediate voltage level or switch inadvertently, as a result of external electromagnetic noise. To avoid a current consumption related to floating pins, they must either be configured in analog mode, or forced internally to a definite digital value. This can be done either by using pull-up/down resistors or by configuring the pins in output mode.

### I/O dynamic current consumption

In addition to the internal peripheral current consumption (see [Table 126: Peripheral current consumption in Run mode](#)), the I/Os used by an application also contribute to the current consumption. When an I/O pin switches, it uses the current from the MCU supply voltage to supply the I/O pin circuitry and to charge/discharge the internal or external capacitive load connected to the pin:

$$I_{SW} = V_{DDx} \times f_{SW} \times C_L$$

where

$I_{SW}$  is the current sunk by a switching I/O to charge/discharge the capacitive load

$V_{DDx}$  is the MCU supply voltage

$f_{SW}$  is the I/O switching frequency

$C_L$  is the total capacitance seen by the I/O pin:  $C = C_{INT} + C_{EXT}$

The test pin is configured in push-pull output mode and is toggled by software at a fixed frequency.

### On-chip peripheral current consumption

The MCU is placed under the following conditions:

- At startup, all I/O pins are in analog input configuration.
- All peripherals are disabled unless otherwise mentioned.
- The I/O compensation cell is enabled.
- $f_{rcc\_c\_ck}$  is the CPU clock.  $f_{PCLK} = f_{rcc\_c\_ck}/4$ , and  $f_{HCLK} = f_{rcc\_c\_ck}/2$ .  
The given value is calculated by measuring the difference of current consumption
  - with all peripherals clocked off
  - with only one peripheral clocked on
  - $f_{rcc\_c\_ck} = 480$  MHz (Scale 0),  $f_{rcc\_c\_ck} = 400$  MHz (Scale 1),  $f_{rcc\_c\_ck} = 300$  MHz (Scale 2),  $f_{rcc\_c\_ck} = 200$  MHz (Scale 3)
- The ambient operating temperature is 25 °C and  $V_{DD}=3.3$  V.

**Table 126. Peripheral current consumption in Run mode**

| Bus  | Peripheral         | VOS0       | VOS1       | VOS2       | VOS3       | Unit   |
|------|--------------------|------------|------------|------------|------------|--------|
| AHB3 | MDMA               | 4.6        | 3.8        | 3.4        | 3.2        | μA/MHz |
|      | DMA2D              | 2.9        | 2.4        | 2.1        | 1.9        |        |
|      | JPGDEC             | 4.1        | 3.7        | 3.4        | 3.1        |        |
|      | FLASH              | 17.0       | 15.0       | 14.0       | 12.0       |        |
|      | FMC registers      | 0.9        | 1.1        | 0.9        | 0.8        |        |
|      | FMC kernel         | 7.0        | 6.1        | 5.6        | 5.0        |        |
|      | QUADSPI registers  | 1.5        | 1.5        | 1.4        | 1.3        |        |
|      | QSPI kernel        | 1.0        | 0.9        | 0.8        | 0.7        |        |
|      | SDMMC1 registers   | 8.2        | 7.2        | 6.7        | 6.0        |        |
|      | SDMMC1 kernel      | 1.3        | 1.2        | 0.9        | 0.9        |        |
|      | DTCM1              | 7.9        | 6.8        | 6.0        | 5.3        |        |
|      | DTCM2              | 8.3        | 7.2        | 6.4        | 5.7        |        |
|      | ITCM               | 7.0        | 6.3        | 5.6        | 5.1        |        |
|      | D1SRAM1            | 13.0       | 11.0       | 9.9        | 8.7        |        |
|      | AHB3 bridge        | 35.0       | 32.0       | 29.0       | 26.0       |        |
|      | <b>Total AHB3</b>  | <b>120</b> | <b>106</b> | <b>96</b>  | <b>86</b>  |        |
| AHB1 | DMA1               | 54.0       | 48.0       | 41.0       | 37.0       |        |
|      | DMA2               | 55.0       | 49.0       | 42.0       | 37.0       |        |
|      | ADC12 registers    | 4.5        | 4.1        | 3.7        | 3.3        |        |
|      | ADC12 kernel       | 1.0        | 0.7        | 0.4        | 0.6        |        |
|      | ART accelerator    | 4.1        | 3.7        | 3.2        | 2.9        |        |
|      | ETH1MAC            | 17.0       | 15.0       | 14.0       | 12.0       |        |
|      | ETH1TX             | 0.1        | 0.1        | 0.1        | 0.1        |        |
|      | ETH1RX             | 0.1        | 0.1        | 0.1        | 0.1        |        |
|      | USB1 OTG registers | 23.0       | 21.0       | 19.0       | 17.0       |        |
|      | USB1 OTG kernel    | 8.2        | 0.5        | 8.3        | 8.2        |        |
|      | USB1 ULPI          | 0.1        | 0.1        | 0.1        | 0.1        |        |
|      | USB2 OTG registers | 21.0       | 19.0       | 17.0       | 15.0       |        |
|      | USB2 OTG kernel    | 8.5        | 0.4        | 8.6        | 8.3        |        |
|      | USB2 ULPI          | 23.0       | 19.0       | 20.0       | 19.0       |        |
|      | AHB1 bridge        | 0.1        | 0.1        | 0.1        | 0.1        |        |
|      | <b>Total AHB1</b>  | <b>220</b> | <b>181</b> | <b>178</b> | <b>161</b> |        |

Table 126. Peripheral current consumption in Run mode (continued)

| Bus  | Peripheral        | VOS0      | VOS1      | VOS2      | VOS3      | Unit   |
|------|-------------------|-----------|-----------|-----------|-----------|--------|
| AHB2 | DCMI              | 2.1       | 1.9       | 1.8       | 1.6       | μA/MHz |
|      | CRYPT             | 0.1       | 0.1       | 0.1       | 0.1       |        |
|      | HASH              | 0.1       | 0.1       | 0.1       | 0.1       |        |
|      | RNG registers     | 1.7       | 2.0       | 1.3       | 1.2       |        |
|      | RNG kernel        | 11.0      | 0.1       | 9.7       | 9.4       |        |
|      | SDMMC2 registers  | 47.0      | 41.0      | 37.0      | 34.0      |        |
|      | SDMMC2 kernel     | 1.7       | 1.2       | 1.1       | 1.0       |        |
|      | D2SRAM1           | 5.7       | 4.9       | 4.4       | 3.9       |        |
|      | D2SRAM2           | 5.2       | 4.5       | 4.0       | 3.5       |        |
|      | D2SRAM3           | 4.1       | 3.6       | 3.2       | 2.8       |        |
|      | AHB2 bridge       | 0.1       | 0.1       | 0.1       | 0.1       |        |
|      | <b>Total AHB2</b> | <b>79</b> | <b>60</b> | <b>63</b> | <b>58</b> |        |
| AHB4 | GPIOA             | 1.5       | 1.3       | 1.3       | 1.1       | μA/MHz |
|      | GPIOB             | 1.2       | 1.0       | 1.0       | 0.9       |        |
|      | GPIOC             | 0.8       | 0.7       | 0.7       | 0.6       |        |
|      | GIPOD             | 1.1       | 1.0       | 1.0       | 0.9       |        |
|      | GPIOE             | 0.7       | 0.7       | 0.7       | 0.6       |        |
|      | GPIOF             | 0.8       | 0.8       | 0.7       | 0.6       |        |
|      | GPIOG             | 0.9       | 0.8       | 0.8       | 0.7       |        |
|      | GPIOH             | 1.1       | 1.0       | 1.0       | 0.9       |        |
|      | GPIOI             | 0.9       | 0.9       | 0.8       | 0.7       |        |
|      | GPIOJ             | 0.8       | 0.8       | 0.7       | 0.7       |        |
|      | GPIOK             | 0.7       | 0.8       | 0.7       | 0.6       |        |
|      | CRC               | 0.4       | 0.5       | 0.4       | 0.3       |        |
|      | BDMA              | 6.6       | 5.9       | 5.3       | 4.8       |        |
|      | ADC3 registers    | 1.7       | 1.5       | 1.2       | 1.2       |        |
|      | ADC3 kernel       | 0.4       | 0.3       | 0.5       | 0.2       |        |
|      | BKPRAM            | 2.3       | 1.9       | 1.7       | 1.5       |        |
|      | AHB4 bridge       | 0.1       | 0.1       | 0.1       | 0.1       |        |
|      | <b>Total AHB4</b> | <b>22</b> | <b>20</b> | <b>19</b> | <b>16</b> |        |
| APB3 | WWDG1             | 0.7       | 0.5       | 0.5       | 0.2       | μA/MHz |
|      | LCD-TFT           | 81.0      | 36.0      | 33.0      | 30.0      |        |
|      | APB3 bridge       | 0.3       | 0.2       | 0.1       | 0.1       |        |
|      | <b>Total APB3</b> | <b>87</b> | <b>41</b> | <b>38</b> | <b>34</b> |        |

Table 126. Peripheral current consumption in Run mode (continued)

| Bus            | Peripheral         | VOS0 | VOS1 | VOS2 | VOS3 | Unit   |
|----------------|--------------------|------|------|------|------|--------|
| APB1           | TIM2               | 7.7  | 3.6  | 3.3  | 3.0  | µA/MHz |
|                | TIM3               | 6.7  | 3.2  | 3.0  | 2.7  |        |
|                | TIM4               | 6.3  | 3.1  | 2.8  | 2.5  |        |
|                | TIM5               | 7.4  | 3.5  | 3.2  | 2.8  |        |
|                | TIM6               | 1.4  | 0.7  | 0.8  | 0.6  |        |
|                | TIM7               | 1.4  | 0.7  | 0.7  | 0.6  |        |
|                | TIM12              | 3.2  | 1.5  | 1.5  | 1.3  |        |
|                | TIM13              | 2.3  | 1.1  | 1.1  | 0.9  |        |
|                | TIM14              | 2.1  | 1.1  | 1.1  | 0.9  |        |
|                | LPTIM1 registers   | 0.7  | 0.5  | 0.8  | 0.7  |        |
|                | LPTIM1 kernel      | 2.4  | 2.3  | 1.9  | 1.7  |        |
|                | WWDG2              | 0.6  | 0.5  | 0.5  | 0.4  |        |
|                | SPI2 registers     | 2.0  | 1.8  | 1.7  | 1.4  |        |
|                | SPI2 kernel        | 0.8  | 0.6  | 0.5  | 0.6  |        |
|                | SPI3 registers     | 1.8  | 1.6  | 1.6  | 1.3  |        |
|                | SPI3 kernel        | 0.7  | 0.9  | 0.7  | 0.7  |        |
|                | SPDIFRX1 registers | 0.5  | 0.7  | 0.7  | 0.6  |        |
|                | SPDIFRX1 kernel    | 3.5  | 2.8  | 2.4  | 2.2  |        |
|                | USART2 registers   | 1.9  | 1.7  | 1.4  | 1.3  |        |
|                | USART2 kernel      | 4.3  | 3.9  | 3.6  | 3.2  |        |
|                | USART3 registers   | 1.9  | 1.7  | 1.4  | 1.3  |        |
|                | USART3 kernel      | 4.4  | 3.9  | 3.5  | 3.2  |        |
|                | UART4 registers    | 1.7  | 1.5  | 1.4  | 1.4  |        |
|                | UART4 kernel       | 3.9  | 3.4  | 3.1  | 2.8  |        |
|                | UART5 registers    | 1.6  | 1.4  | 1.4  | 1.3  |        |
|                | UART5 kernel       | 3.8  | 3.4  | 3.0  | 2.7  |        |
|                | I2C1 registers     | 1.1  | 0.8  | 0.9  | 0.8  |        |
|                | I2C1 kernel        | 2.5  | 2.3  | 2.0  | 1.9  |        |
| I2C2 registers | 1.0                | 0.8  | 0.9  | 0.8  |      |        |

**Table 126. Peripheral current consumption in Run mode (continued)**

| Bus                 | Peripheral         | VOS0       | VOS1       | VOS2       | VOS3      | Unit   |
|---------------------|--------------------|------------|------------|------------|-----------|--------|
| APB1<br>(continued) | I2C2 kernel        | 2.3        | 2.2        | 1.9        | 1.7       | μA/MHz |
|                     | I2C3 registers     | 0.8        | 1.0        | 0.8        | 0.8       |        |
|                     | I2C3 kernel        | 2.4        | 1.9        | 1.8        | 1.6       |        |
|                     | HDMI-CEC registers | 0.7        | 0.5        | 0.6        | 0.5       |        |
|                     | HDMI-CEC kernel    | 0.1        | 0.1        | 3.2        | 0.1       |        |
|                     | DAC12              | 3.6        | 1.3        | 1.2        | 1.0       |        |
|                     | USART7 registers   | 1.8        | 1.8        | 1.6        | 1.4       |        |
|                     | USART7 kernel      | 4.0        | 3.3        | 3.0        | 2.8       |        |
|                     | USART8 registers   | 2.0        | 1.6        | 1.6        | 1.4       |        |
|                     | USART8 kernel      | 3.9        | 3.4        | 3.1        | 2.8       |        |
|                     | CRS                | 6.4        | 5.5        | 5.0        | 4.5       |        |
|                     | SWPMI registers    | 2.7        | 2.4        | 2.3        | 1.9       |        |
|                     | SWPMI kernel       | 0.1        | 0.1        | 0.1        | 0.1       |        |
|                     | OPAMP              | 0.2        | 0.3        | 0.3        | 0.2       |        |
|                     | MDIO               | 3.3        | 2.9        | 2.6        | 2.3       |        |
|                     | FDCAN registers    | 19.0       | 17.0       | 15.0       | 13.0      |        |
|                     | FDCAN kernel       | 9.1        | 7.9        | 6.9        | 6.4       |        |
|                     | APB1 bridge        | 0.1        | 0.1        | 0.1        | 0.1       |        |
|                     | <b>Total APB1</b>  | <b>142</b> | <b>108</b> | <b>102</b> | <b>88</b> |        |
|                     | APB2               | TIM1       | 11.0       | 5.0        | 4.5       |        |
| TIM8                |                    | 10.0       | 4.7        | 4.3        | 3.8       |        |
| USART1 registers    |                    | 3.6        | 2.5        | 2.7        | 2.9       |        |
| USART1 kernel       |                    | 0.1        | 0.1        | 0.1        | 0.1       |        |
| USART6 registers    |                    | 4.5        | 3.0        | 3.1        | 3.4       |        |
| USART6 kernel       |                    | 0.1        | 0.1        | 0.1        | 0.1       |        |
| SPI1 registers      |                    | 2.0        | 1.7        | 1.6        | 1.4       |        |
| SPI1 kernel         |                    | 0.9        | 0.8        | 0.7        | 0.6       |        |
| SPI4 registers      |                    | 2.1        | 1.7        | 1.6        | 1.5       |        |
| SPI4 kernel         |                    | 0.6        | 0.5        | 0.5        | 0.3       |        |
| TIM15               |                    | 5.5        | 2.5        | 2.3        | 2.1       |        |
| TIM16               |                    | 4.1        | 2.0        | 1.8        | 1.7       |        |
| TIM17               |                    | 4.1        | 1.9        | 1.8        | 1.6       |        |
| SPI5 registers      |                    | 2.0        | 1.8        | 1.6        | 1.3       |        |
| SPI5 kernel         |                    | 0.5        | 0.4        | 0.4        | 0.5       |        |
| SAI1 registers      |                    | 1.3        | 1.1        | 1.1        | 1.0       |        |

**Table 126. Peripheral current consumption in Run mode (continued)**

| Bus                 | Peripheral        | VOS0        | VOS1        | VOS2        | VOS3      | Unit   |
|---------------------|-------------------|-------------|-------------|-------------|-----------|--------|
| APB2<br>(continued) | SAI1 kernel       | 1.4         | 1.1         | 1.0         | 0.8       | μA/MHz |
|                     | SAI2 registers    | 1.5         | 1.3         | 1.2         | 1.0       |        |
|                     | SAI2 kernel       | 1.1         | 1.0         | 0.9         | 0.9       |        |
|                     | SAI3 registers    | 1.6         | 1.3         | 1.1         | 1.0       |        |
|                     | SAI3 kernel       | 1.1         | 1.2         | 1.1         | 0.9       |        |
|                     | DFSDM1 registers  | 6.5         | 5.8         | 5.2         | 4.7       |        |
|                     | DFSDM1 kernel     | 0.3         | 0.2         | 0.2         | 0.4       |        |
|                     | HRTIM             | 84.0        | 39.0        | 35.0        | 32.0      |        |
|                     | APB2 bridge       | 0.2         | 0.1         | 0.1         | 0.2       |        |
|                     | <b>Total APB2</b> | <b>150</b>  | <b>81</b>   | <b>74</b>   | <b>68</b> |        |
| APB4                | SYSCFG            | 0.9         | 1.0         | 0.7         | 0.8       |        |
|                     | LPUART1 registers | 1.1         | 1.3         | 1.0         | 0.8       |        |
|                     | LPUART1 kernel    | 2.9         | 2.2         | 2.2         | 2.1       |        |
|                     | SPI6 registers    | 1.8         | 1.6         | 1.4         | 1.3       |        |
|                     | SPI6 kernel       | 0.4         | 0.4         | 0.5         | 0.3       |        |
|                     | I2C4 registers    | 0.9         | 0.7         | 0.7         | 0.4       |        |
|                     | I2C4 kernel       | 2.2         | 2.1         | 1.9         | 1.8       |        |
|                     | LPTIM2 registers  | 0.8         | 0.6         | 0.7         | 0.5       |        |
|                     | LPTIM2 kernel     | 2.3         | 2.1         | 1.8         | 1.4       |        |
|                     | LPTIM3 registers  | 0.7         | 0.7         | 0.7         | 0.4       |        |
|                     | LPTIM3 kernel     | 2.1         | 1.7         | 1.6         | 1.5       |        |
|                     | LPTIM4 registers  | 0.8         | 0.4         | 0.6         | 0.4       |        |
|                     | LPTIM4 kernel     | 2.2         | 2.0         | 1.7         | 1.5       |        |
|                     | LPTIM5 registers  | 0.5         | 0.4         | 0.6         | 0.4       |        |
|                     | LPTIM5 kernel     | 2.0         | 1.8         | 1.5         | 1.2       |        |
|                     | COMP12            | 0.6         | 0.4         | 0.5         | 0.2       |        |
|                     | VREF              | 0.4         | 0.2         | 0.2         | 0.1       |        |
|                     | RTC               | 1.1         | 0.9         | 1.0         | 0.6       |        |
|                     | SAI4 registers    | 1.7         | 1.4         | 1.3         | 1.0       |        |
|                     | SAI4 kernel       | 2.0         | 2.0         | 1.8         | 1.6       |        |
| APB4 bridge         | 0.1               | 0.1         | 0.1         | 0.1         |           |        |
| <b>Total APB4</b>   | <b>28</b>         | <b>24.4</b> | <b>22.4</b> | <b>18.9</b> |           |        |

### 7.3.7 Wakeup time from low-power modes

The wakeup times given in [Table 127](#) are measured starting from the wakeup event trigger up to the first instruction executed by the CPU:

- For Stop or Sleep modes: the wakeup event is WFE.
- WKUP (PC1) pin is used to wakeup from Standby, Stop and Sleep modes.

All timings are derived from tests performed under ambient temperature and  $V_{DD}=3.3\text{ V}$ .

**Table 127. Low-power mode wakeup timings**

| Symbol                    | Parameter                            | Conditions                                | Typ <sup>(1)</sup> | Max <sup>(1)</sup> | Unit             |
|---------------------------|--------------------------------------|---|--------------------|--------------------|------------------|
| $t_{WUSLEEP}^{(2)}$       | Wakeup from Sleep                    | -   | 9                  | 10                 | CPU clock cycles |
| $t_{WUSTOP}^{(2)}$        | Wakeup from Stop                     | VOS3, HSI, flash memory in normal mode    | 4.4                | 5.6                | $\mu\text{s}$    |
|                           |                                      | VOS3, HSI, flash memory in low-power mode | 12                 | 15                 |                  |
|                           |                                      | VOS4, HSI, flash memory in normal mode    | 15                 | 20                 |                  |
|                           |                                      | VOS4, HSI, flash memory in low-power mode | 23                 | 28                 |                  |
|                           |                                      | VOS5, HSI, flash memory in normal mode    | 39                 | 71                 |                  |
|                           |                                      | VOS5, HSI, flash memory in low-power mode | 39                 | 47                 |                  |
|                           |                                      | VOS3, CSI, flash memory in normal mode    | 30                 | 37                 |                  |
|                           |                                      | VOS3, CSI, flash memory in low power mode | 36                 | 50                 |                  |
|                           |                                      | VOS4, CSI, flash memory in normal mode    | 38                 | 48                 |                  |
|                           |                                      | VOS4, CSI, flash memory in low-power mode | 47                 | 61                 |                  |
|                           |                                      | VOS5, CSI, flash memory in normal mode    | 68                 | 75                 |                  |
|                           |                                      | VOS5, CSI, flash memory in low-power mode | 68                 | 77                 |                  |
| $t_{WUSTOP\_KERON}^{(2)}$ | Wakeup from Stop, clock kept running | VOS3, HSI, flash memory in normal mode    | 2.6                | 3.4                | $\mu\text{s}$    |
|                           |                                      | VOS3, CSI, flash memory in normal mode    | 26                 | 36                 |                  |
| $t_{WUSTDBY}^{(2)}$       | Wakeup from Standby mode             | -   | 390                | 500                | $\mu\text{s}$    |

1. Guaranteed by characterization results.

2. The wakeup times are measured from the wakeup event to the point in which the application code reads the first instruction.

### 7.3.8 External clock source characteristics

#### High-speed external user clock generated from an external source

In bypass mode the HSE oscillator is switched off and the input pin is a standard I/O.

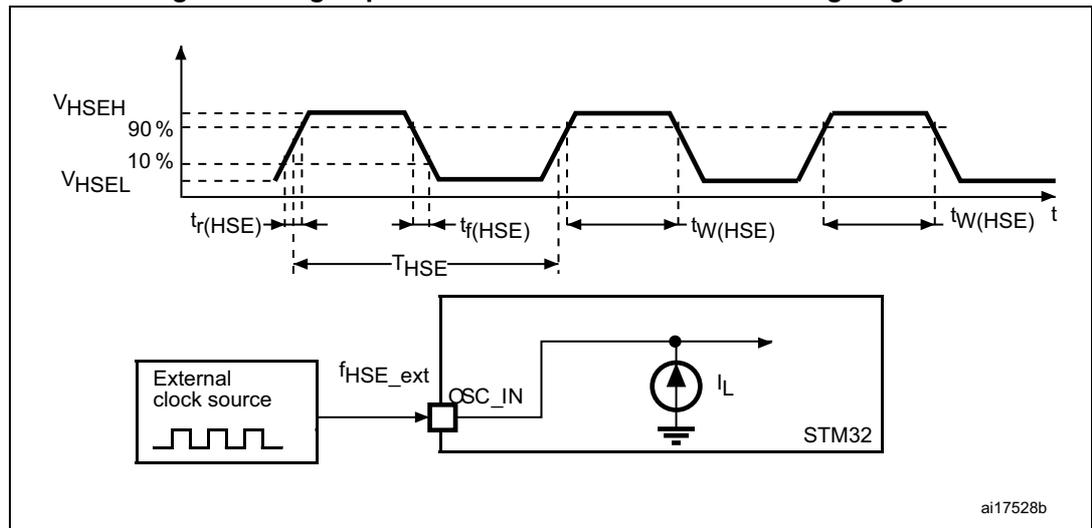
The external clock signal has to respect the [Table 146: I/O static characteristics](#). However, the recommended clock input waveform is shown in [Figure 68](#).

**Table 128. High-speed external user clock characteristics<sup>(1)</sup>**

| Symbol         | Parameter                               | Min          | Typ | Max          | Unit |
|----------------|---|--------------|-----|--------------|------|
| $f_{HSE\_ext}$ | User external clock source frequency    | 4            | 25  | 50           | MHz  |
| $V_{HSEH}$     | Digital OSC_IN input high-level voltage | $0.7 V_{DD}$ | -   | $V_{DD}$     | V    |
| $V_{HSEL}$     | Digital OSC_IN input low-level voltage  | $V_{SS}$     | -   | $0.3 V_{DD}$ |      |
| $t_{W(HSE)}$   | OSC_IN high or low time                 | 7            | -   | -            | ns   |

1. Guaranteed by design.

**Figure 68. High-speed external clock source AC timing diagram**



**Low-speed external user clock generated from an external source**

In bypass mode the LSE oscillator is switched off and the input pin is a standard I/O. The external clock signal has to respect the [Table 146: I/O static characteristics](#). However, the recommended clock input waveform is shown in [Figure 69](#).

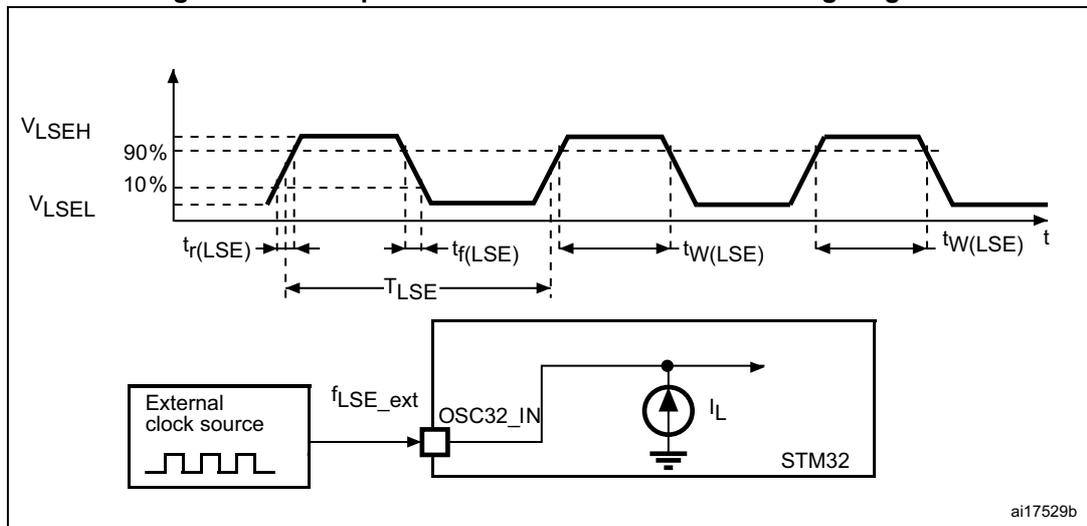
**Table 129. Low-speed external user clock characteristics<sup>(1)</sup>**

| Symbol                         | Parameter   | Min | Typ    | Max            | Unit    |
|--------------------------------|---|-----|--------|----------------|---------|
| $f_{LSE\_ext}$                 | User external clock source frequency              | 5   | 32.768 | 40             | kHz     |
| $V_{LSE\_ext\_PP}$             | OSC32_IN peak-to-peak amplitude                   | 0.3 | -      | $V_{SW}^{(2)}$ | V       |
| $V_{LSE\_ext}$                 | OSC32_IN input range                              | 0   | -      | $V_{SW}^{(2)}$ |         |
| $t_{w(LSEH)}$<br>$t_{w(LSEL)}$ | OSC32_IN high or low time for square signal input | 10  | -      | -              | $\mu s$ |

1. Specified by design. Not tested in production.
2.  $V_{SW} = V_{DD}$  when  $V_{DD} > V_{BOR0}$ ;  $V_{SW} = V_{BAT}$  when  $V_{DD} < V_{BOR0}$ . If the customer application includes  $V_{BAT}$  mode, OSC32\_IN peak-to-peak must be lower than  $V_{BOR0}$ . Otherwise, the LSE frequency is not guaranteed during switching to/from  $V_{BAT}$  mode.

*Note:* For information on selecting the crystal, refer to the application note AN2867 “Oscillator design guide for STM8AL/AF/S, STM32 MCUs and MPUs” available from the ST website [www.st.com](http://www.st.com).

**Figure 69. Low-speed external clock source AC timing diagram**



### High-speed external clock generated from a crystal/ceramic resonator

The high-speed external (HSE) clock can be supplied with a 4 to 48 MHz crystal/ceramic resonator oscillator. All the information given in this paragraph are based on characterization results obtained with typical external components specified in [Table 130](#). In the application, the resonator and the load capacitors have to be placed as close as possible to the oscillator pins in order to minimize output distortion and startup stabilization time. Refer to the crystal resonator manufacturer for more details on the resonator characteristics (frequency, package, accuracy).

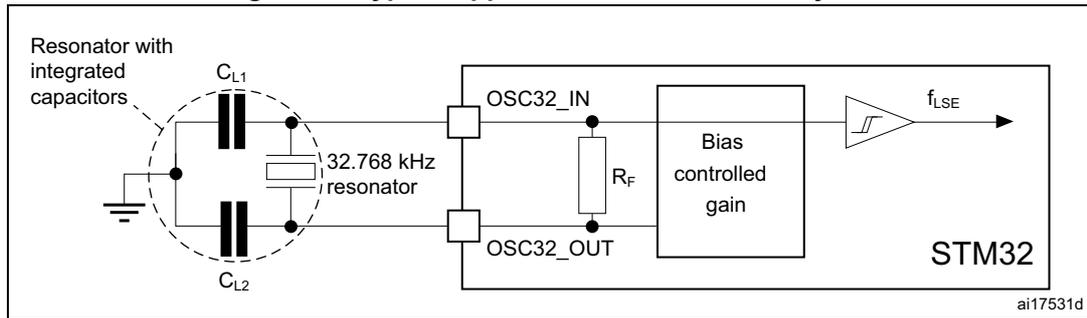
**Table 130. 4-48 MHz HSE oscillator characteristics<sup>(1)</sup>**

| Symbol                            | Parameter                   | Operating conditions <sup>(2)</sup>   | Min | Typ  | Max | Unit |
|-----------------------------------|-----------------------------|---|-----|------|-----|------|
| F                                 | Oscillator frequency        | -   | 4   | -    | 48  | MHz  |
| R <sub>F</sub>                    | Feedback resistor           | -   | -   | 200  | -   | kΩ   |
| I <sub>DD(HSE)</sub>              | HSE current consumption     | During startup <sup>(3)</sup>   | -   | -    | 4   | mA   |
|                                   |                             | V <sub>DD</sub> =3 V, R <sub>m</sub> =30 Ω<br>C <sub>L</sub> =10pF@4MHz       | -   | 0.35 | -   |      |
|                                   |                             | V <sub>DD</sub> =3 V, R <sub>m</sub> =30 Ω<br>C <sub>L</sub> =10 pF at 8 MHz  | -   | 0.40 | -   |      |
|                                   |                             | V <sub>DD</sub> =3 V, R <sub>m</sub> =30 Ω<br>C <sub>L</sub> =10 pF at 16 MHz | -   | 0.45 | -   |      |
|                                   |                             | V <sub>DD</sub> =3 V, R <sub>m</sub> =30 Ω<br>C <sub>L</sub> =10 pF at 32 MHz | -   | 0.65 | -   |      |
|                                   |                             | V <sub>DD</sub> =3 V, R <sub>m</sub> =30 Ω<br>C <sub>L</sub> =10 pF at 48 MHz | -   | 0.95 | -   |      |
| G <sub>m</sub> <sub>critmax</sub> | Maximum critical crystal gm | Startup   | -   | -    | 1.5 | mA/V |
| t <sub>SU</sub> <sup>(4)</sup>    | Start-up time               | V <sub>DD</sub> is stabilized   | -   | 2    | -   | ms   |

1. Guaranteed by design.
2. Resonator characteristics given by the crystal/ceramic resonator manufacturer.
3. This consumption level occurs during the first 2/3 of the t<sub>SU(HSE)</sub> startup time.
4. t<sub>SU(HSE)</sub> is the startup time measured from the moment it is enabled (by software) to a stabilized 8 MHz oscillation is reached. This value is measured for a standard crystal resonator and it can vary significantly with the crystal manufacturer.

**Note:** For information on selecting the crystal, refer to the application note AN2867 “Oscillator design guide for STM8AF/AL/S, STM32 MCUs and MPUs” available from the ST website [www.st.com](http://www.st.com).

Figure 70. Typical application with an 8 MHz crystal



1.  $R_{EXT}$  value depends on the crystal characteristics.

**Low-speed external clock generated from a crystal/ceramic resonator**

The low-speed external (LSE) clock can be supplied with a 32.768 kHz crystal/ceramic resonator oscillator. All the information given in this paragraph are based on characterization results obtained with typical external components specified in [Table 131](#). In the application, the resonator and the load capacitors have to be placed as close as possible to the oscillator pins in order to minimize output distortion and startup stabilization time. Refer to the crystal resonator manufacturer for more details on the resonator characteristics (frequency, package, accuracy).

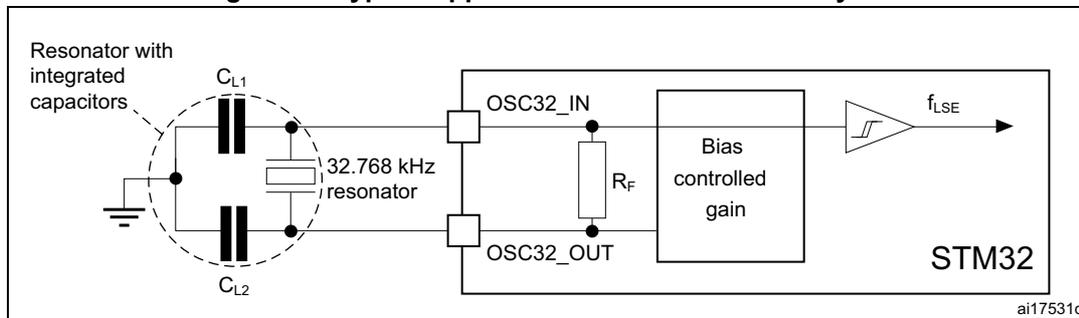
Table 131. Low-speed external user clock characteristics<sup>(1)</sup>

| Symbol            | Parameter                   | Operating conditions <sup>(2)</sup>               | Min | Typ    | Max  | Unit      |
|-------------------|-----------------------------|---|-----|--------|------|-----------|
| F                 | Oscillator frequency        | -   | -   | 32.768 | -    | kHz       |
| $I_{DD}$          | LSE current consumption     | LSEDRV[1:0] = 00,<br>Low drive capability         | -   | 290    | -    | nA        |
|                   |                             | LSEDRV[1:0] = 01,<br>Medium Low drive capability  | -   | 390    | -    |           |
|                   |                             | LSEDRV[1:0] = 10,<br>Medium high drive capability | -   | 550    | -    |           |
|                   |                             | LSEDRV[1:0] = 11,<br>High drive capability        | -   | 900    | -    |           |
| $G_{m_{critmax}}$ | Maximum critical crystal gm | LSEDRV[1:0] = 00,<br>Low drive capability         | -   | -      | 0.5  | $\mu A/V$ |
|                   |                             | LSEDRV[1:0] = 01,<br>Medium Low drive capability  | -   | -      | 0.75 |           |
|                   |                             | LSEDRV[1:0] = 10,<br>Medium high drive capability | -   | -      | 1.7  |           |
|                   |                             | LSEDRV[1:0] = 11,<br>High drive capability        | -   | -      | 2.7  |           |
| $t_{SU}^{(3)}$    | Startup time                | VDD is stabilized                                 | -   | 2      | -    | s         |

- Guaranteed by design.
- Refer to the note and caution paragraphs below the table, and to the application note AN2867 "Oscillator design guide for STM8AL/AF/S, STM32 MCUs and MPUs".
- $t_{SU}$  is the startup time measured from the moment it is enabled (by software) to a stabilized 32.768k Hz oscillation is reached. This value is measured for a standard crystal resonator and it can vary significantly with the crystal manufacturer.

Note: For information on selecting the crystal, refer to the application note AN2867 “Oscillator design guide for STM8AL/AF/S, STM32 MCUs and MPUs” available from the ST website [www.st.com](http://www.st.com).

Figure 71. Typical application with a 32.768 kHz crystal



1. An external resistor is not required between OSC32\_IN and OSC32\_OUT and it is forbidden to add one.

### 7.3.9 Internal clock source characteristics

The parameters given in [Table 132](#) to [Table 135](#) are derived from tests performed under ambient temperature and  $V_{DD}$  supply voltage conditions summarized in [Table 111: General operating conditions](#).

#### 48 MHz high-speed internal RC oscillator (HSI48)

Table 132. HSI48 oscillator characteristics

| Symbol                              | Parameter  | Conditions                                    | Min                 | Typ        | Max                 | Unit          |
|-------------------------------------|--|---|---------------------|------------|---------------------|---------------|
| $f_{HSI48}$                         | HSI48 frequency  | $V_{DD}=3.3\text{ V}$ ,<br>$T_J=30\text{ °C}$ | 47.5 <sup>(1)</sup> | 48         | 48.5 <sup>(1)</sup> | MHz           |
| TRIM <sup>(2)</sup>                 | USER trimming step   | -   | -                   | 0.175      | -                   | %             |
| USER TRIM COVERAGE <sup>(3)</sup>   | USER TRIMMING Coverage   | $\pm 32$ steps                                | $\pm 4.79$          | $\pm 5.60$ | -                   | %             |
| DuCy(HSI48) <sup>(2)</sup>          | Duty Cycle   | -   | 45                  | -          | 55                  | %             |
| ACC_HSI48_REL <sup>(3)(4)</sup>     | Accuracy of the HSI48 oscillator over temperature (factory calibrated)     | $T_J=-40\text{ to }125\text{ °C}$             | -4.5                | -          | 3.5                 | %             |
| $\Delta V_{DD}(\text{HSI48})^{(3)}$ | HSI48 oscillator frequency drift with $V_{DD}^{(5)}$                       | $V_{DD}=3\text{ to }3.6\text{ V}$             | -                   | 0.025      | 0.05                | %             |
|                                     |  | $V_{DD}=1.62\text{ V to }3.6\text{ V}$        | -                   | 0.05       | 0.1                 |               |
| $t_{su}(\text{HSI48})^{(2)}$        | HSI48 oscillator start-up time   | -   | -                   | 2.1        | 4.0                 | $\mu\text{s}$ |
| $I_{DD}(\text{HSI48})^{(2)}$        | HSI48 oscillator power consumption   | -   | -                   | 350        | 400                 | $\mu\text{A}$ |
| $N_T$ jitter                        | Next transition jitter<br>Accumulated jitter on 28 cycles <sup>(6)</sup>   | -   | -                   | $\pm 0.15$ | -                   | ns            |
| $P_T$ jitter                        | Paired transition jitter<br>Accumulated jitter on 56 cycles <sup>(6)</sup> | -   | -                   | $\pm 0.25$ | -                   | ns            |

1. Guaranteed by test in production.
2. Guaranteed by design.
3. Guaranteed by characterization.

4.  $\Delta f_{HSI} = ACCHSI48\_REL + \Delta V_{DD}$ .
5. These values are obtained by using the formula:  $(Freq(3.6V) - Freq(3.0V)) / Freq(3.0V)$  or  $(Freq(3.6V) - Freq(1.62V)) / Freq(1.62V)$ .
6. Jitter measurements are performed without clock source activated in parallel.

**64 MHz high-speed internal RC oscillator (HSI)**

**Table 133. HSI oscillator characteristics<sup>(1)</sup>**

| Symbol                  | Parameter  | Conditions   | Min                 | Typ   | Max                 | Unit |
|-------------------------|--|--|---------------------|-------|---------------------|------|
| f <sub>HSI</sub>        | HSI frequency  | V <sub>DD</sub> =3.3 V, T <sub>J</sub> =30 °C                              | 63.7 <sup>(2)</sup> | 64    | 64.3 <sup>(2)</sup> | MHz  |
| TRIM                    | HSI user trimming step   | Trimming is not a multiple of 32   | -                   | 0.24  | 0.32                | %    |
|                         |  | Trimming is 128, 256 and 384   | -5.2                | -1.8  | -                   |      |
|                         |  | Trimming is 64, 192, 320 and 448   | -1.4                | -0.8  | -                   |      |
|                         |  | Other trimming are a multiple of 32 (not including multiple of 64 and 128) | -0.6                | -0.25 | -                   |      |
| DuCy(HSI)               | Duty Cycle   | -  | 45                  | -     | 55                  | %    |
| ΔV <sub>DD</sub> (HSI)  | HSI oscillator frequency drift over V <sub>DD</sub> (reference is 3.3 V) | V <sub>DD</sub> =1.62 to 3.6 V   | -0.12               | -     | 0.03                | %    |
| ΔTEMP (HSI)             | HSI oscillator frequency drift over temperature (reference is 64 MHz)    | T <sub>J</sub> =-20 to 105 °C  | -1 <sup>(3)</sup>   | -     | 1 <sup>(3)</sup>    | %    |
|                         |  | T <sub>J</sub> =-40 to T <sub>J</sub> max °C                               | -2 <sup>(3)</sup>   | -     | 1 <sup>(3)</sup>    |      |
| t <sub>su</sub> (HSI)   | HSI oscillator start-up time   | -  | -                   | 1.4   | 2                   | μs   |
| t <sub>stab</sub> (HSI) | HSI oscillator stabilization time  | at 1% of target frequency  | -                   | 4     | 8                   | μs   |
| I <sub>DD</sub> (HSI)   | HSI oscillator power consumption   | -  | -                   | 300   | 400                 | μA   |

1. Guaranteed by design unless otherwise specified.
2. Guaranteed by test in production.
3. Guaranteed by characterization.

**4 MHz low-power internal RC oscillator (CSI)**

**Table 134. CSI oscillator characteristics<sup>(1)</sup>**

| Symbol           | Parameter                                       | Conditions                                    | Min                 | Typ                 | Max                 | Unit |
|------------------|---|---|---------------------|---------------------|---------------------|------|
| f <sub>CSI</sub> | CSI frequency                                   | V <sub>DD</sub> =3.3 V, T <sub>J</sub> =30 °C | 3.96 <sup>(2)</sup> | 4                   | 4.04 <sup>(2)</sup> | MHz  |
| TRIM             | Trimming step                                   | -   | -                   | 0.35                | -                   | %    |
| DuCy(CSI)        | Duty Cycle                                      | -   | 45                  | -                   | 55                  | %    |
| ΔTEMP (CSI)      | CSI oscillator frequency drift over temperature | T <sub>J</sub> = 0 to 85 °C                   | -                   | -3.7 <sup>(3)</sup> | 4.5 <sup>(3)</sup>  | %    |
|                  |   | T <sub>J</sub> = -40 to 125 °C                | -                   | -11 <sup>(3)</sup>  | 7.5 <sup>(3)</sup>  |      |

Table 134. CSI oscillator characteristics<sup>(1)</sup> (continued)

| Symbol          | Parameter  | Conditions                 | Min | Typ   | Max  | Unit    |
|-----------------|--|----------------------------|-----|-------|------|---------|
| $D_{VDD}$ (CSI) | CSI oscillator frequency drift over $V_{DD}$                         | $V_{DD} = 1.62$ to $3.6$ V | -   | -0.06 | 0.06 | %       |
| $t_{su}(CSI)$   | CSI oscillator startup time  | -                          | -   | 1     | 2    | $\mu$ s |
| $t_{stab}(CSI)$ | CSI oscillator stabilization time (to reach $\pm 3\%$ of $f_{CSI}$ ) | -                          | -   | -     | 4    | cycle   |
| $I_{DD}(CSI)$   | CSI oscillator power consumption                                     | -                          | -   | 23    | 30   | $\mu$ A |

1. Guaranteed by design.
2. Guaranteed by test in production.
3. Guaranteed by characterization.

### Low-speed internal (LSI) RC oscillator

Table 135. LSI oscillator characteristics

| Symbol                         | Parameter   | Conditions  | Min                  | Typ | Max                 | Unit    |
|--------------------------------|---|---|----------------------|-----|---------------------|---------|
| $f_{LSI}$                      | LSI frequency   | $V_{DD} = 3.3$ V, $T_J = 25$ °C                     | 31.4 <sup>(1)</sup>  | 32  | 32.6 <sup>(1)</sup> | kHz     |
|                                |   | $T_J = -40$ to $110$ °C, $V_{DD} = 1.62$ to $3.6$ V | 29.76 <sup>(2)</sup> | -   | 33.6 <sup>(2)</sup> |         |
|                                |   | $T_J = -40$ to $125$ °C, $V_{DD} = 1.62$ to $3.6$ V | 29.4                 | -   | 33.6                |         |
| $t_{su}(LSI)$ <sup>(3)</sup>   | LSI oscillator startup time                           | -   | -                    | 80  | 130                 | $\mu$ s |
| $t_{stab}(LSI)$ <sup>(3)</sup> | LSI oscillator stabilization time (5% of final value) | -   | -                    | 120 | 170                 |         |
| $I_{DD}(LSI)$ <sup>(3)</sup>   | LSI oscillator power consumption                      | -   | -                    | 130 | 280                 |         |

1. Guaranteed by test in production.
2. Guaranteed by characterization results.
3. Guaranteed by design.

7.3.10 PLL characteristics

The parameters given in [Table 136](#) are derived from tests performed under temperature and  $V_{DD}$  supply voltage conditions summarized in [Table 111: General operating conditions](#).

Table 136. PLL characteristics (wide VCO frequency range)<sup>(1)</sup>

| Symbol                       | Parameter                            | Conditions                           | Min                              | Typ               | Max                | Unit      |          |
|------------------------------|--------------------------------------|--------------------------------------|----------------------------------|-------------------|--------------------|-----------|----------|
| $f_{PLL\_IN}$                | PLL input clock                      | -                                    | 2                                | -                 | 16                 | MHz       |          |
|                              | PLL input clock duty cycle           | -                                    | 10                               | -                 | 90                 | %         |          |
| $f_{PLL\_P\_OUT}$            | PLL multiplier output clock P        | VOS0                                 | 1.5                              | -                 | 480 <sup>(2)</sup> | MHz       |          |
|                              |                                      | VOS1                                 | 1.5                              | -                 | 400 <sup>(2)</sup> |           |          |
|                              |                                      | VOS2                                 | 1.5                              | -                 | 300 <sup>(2)</sup> |           |          |
|                              |                                      | VOS3                                 | 1.5                              | -                 | 200 <sup>(2)</sup> |           |          |
| $f_{VCO\_OUT}$               | PLL VCO output                       | -                                    | 192                              | -                 | 960                |           |          |
| $t_{LOCK}$                   | PLL lock time                        | Normal mode                          | -                                | 50 <sup>(3)</sup> | 150 <sup>(3)</sup> | $\mu$ s   |          |
|                              |                                      | Sigma-delta mode (CKIN $\geq$ 8 MHz) | -                                | 58 <sup>(3)</sup> | 166 <sup>(3)</sup> |           |          |
| Jitter                       | Cycle-to-cycle jitter <sup>(4)</sup> | -                                    | VCO = 192 MHz                    | -                 | 134                | -         | $\pm$ ps |
|                              |                                      |                                      | VCO = 200 MHz                    | -                 | 134                | -         |          |
|                              |                                      |                                      | VCO = 400 MHz                    | -                 | 76                 | -         |          |
|                              |                                      |                                      | VCO = 800 MHz                    | -                 | 39                 | -         |          |
|                              | Long term jitter                     | Normal mode                          | VCO = 800 MHz                    | -                 | $\pm 0.7$          | -         | %        |
|                              |                                      |                                      | Sigma-delta mode (CKIN = 16 MHz) | VCO = 800 MHz     | -                  | $\pm 0.8$ |          |
| $I_{DD(PLL)}$ <sup>(3)</sup> | PLL power consumption on $V_{DD}$    | VCO freq = 836 MHz                   | $V_{DDA}$                        | -                 | 590                | 1500      | $\mu$ A  |
|                              |                                      |                                      | $V_{CORE}$                       | -                 | 720                | -         |          |
|                              |                                      | VCO freq = 192 MHz                   | $V_{DDA}$                        | -                 | 180                | 600       |          |
|                              |                                      |                                      | $V_{CORE}$                       | -                 | 280                | -         |          |

1. Guaranteed by design unless otherwise specified.
2. This value must be limited to the maximum frequency due to the product limitation (480 MHz for VOS0, 400 MHz for VOS1, 300 MHz for VOS2, 200 MHz for VOS3).
3. Guaranteed by characterization results.
4. Integer mode only.

Table 137. PLL characteristics (medium VCO frequency range)<sup>(1)</sup>

| Symbol                | Parameter                                | Conditions                    | Min           | Typ               | Max                | Unit |      |
|-----------------------|--|-------------------------------|---------------|-------------------|--------------------|------|------|
| f <sub>PLL_IN</sub>   | PLL input clock                          | -                             | 1             | -                 | 2                  | MHz  |      |
|                       | PLL input clock duty cycle               | -                             | 10            | -                 | 90                 | %    |      |
| f <sub>PLL_OUT</sub>  | PLL multiplier output clock P, Q, R      | VOS1                          | 1.17          | -                 | 210                | MHz  |      |
|                       |  | VOS2                          | 1.17          | -                 | 210                |      |      |
|                       |  | VOS3                          | 1.17          | -                 | 200                |      |      |
| f <sub>VCO_OUT</sub>  | PLL VCO output                           | -                             | 150           | -                 | 420                |      |      |
| t <sub>LOCK</sub>     | PLL lock time                            | Normal mode                   | -             | 60 <sup>(2)</sup> | 100 <sup>(2)</sup> | μs   |      |
|                       |  | Sigma-delta mode              | forbidden     |                   |                    |      |      |
| Jitter                | Cycle-to-cycle jitter <sup>(3)</sup>     | -                             | VCO = 150 MHz | -                 | 145                | -    | ±ps  |
|                       |  |                               | VCO = 300 MHz | -                 | 91                 | -    |      |
|                       |  |                               | VCO = 400 MHz | -                 | 64                 | -    |      |
|                       |  |                               | VCO = 420 MHz | -                 | 63                 | -    |      |
|                       | Period jitter                            | f <sub>PLL_OUT</sub> = 50 MHz | VCO = 150 MHz | -                 | 55                 | -    | ±-ps |
|                       |  |                               | VCO = 400 MHz | -                 | 30                 | -    |      |
| Long term jitter      | Normal mode                              | VCO = 400 MHz                 | -             | ±0.3              | -                  | %    |      |
| I(PLL) <sup>(2)</sup> | PLL power consumption on V <sub>DD</sub> | VCO freq = 420MHz             | VDD           | -                 | 440                | 1150 | μA   |
|                       |  |                               | VCORE         | -                 | 530                | -    |      |
|                       |  | VCO freq = 150MHz             | VDD           | -                 | 180                | 500  |      |
|                       |  |                               | VCORE         | -                 | 200                | -    |      |

1. Guaranteed by design unless otherwise specified.
2. Guaranteed by characterization results.
3. Integer mode only.

### 7.3.11 Memory characteristics

#### Flash memory

The characteristics are given at  $T_J = -40$  to  $125$  °C unless otherwise specified.

The devices are shipped to customers with the flash memory erased.

**Table 138. Flash memory characteristics**

| Symbol   | Parameter      | Conditions                | Min | Typ  | Max | Unit |
|----------|----------------|---------------------------|-----|------|-----|------|
| $I_{DD}$ | Supply current | Write / Erase 8-bit mode  | -   | 6.5  | -   | mA   |
|          |                | Write / Erase 16-bit mode | -   | 11.5 | -   |      |
|          |                | Write / Erase 32-bit mode | -   | 20   | -   |      |
|          |                | Write / Erase 64-bit mode | -   | 35   | -   |      |

**Table 139. Flash memory programming**

| Symbol           | Parameter                        | Conditions                     | Min <sup>(1)</sup> | Typ | Max <sup>(1)</sup> | Unit    |
|------------------|----------------------------------|--------------------------------|--------------------|-----|--------------------|---------|
| $t_{prog}$       | Word (266 bits) programming time | Program/erase parallelism x 8  | -                  | 290 | 580 <sup>(2)</sup> | $\mu$ s |
|                  |                                  | Program/erase parallelism x 16 | -                  | 180 | 360                |         |
|                  |                                  | Program/erase parallelism x 32 | -                  | 130 | 260                |         |
|                  |                                  | Program/erase parallelism x 64 | -                  | 100 | 200                |         |
| $t_{ERASE128KB}$ | Sector (128 KB) erase time       | Program/erase parallelism x 8  | -                  | 2   | 4                  | s       |
|                  |                                  | Program/erase parallelism x 16 | -                  | 1.8 | 3.6                |         |
|                  |                                  | Program/erase parallelism x 32 | -                  | 1.1 | 2.2                |         |
|                  |                                  | Program/erase parallelism x 64 | -                  | 1   | 2                  |         |
| $t_{ME}$         | Mass erase time                  | Program/erase parallelism x 8  | -                  | 13  | 26                 | s       |
|                  |                                  | Program/erase parallelism x 16 | -                  | 8   | 16                 |         |
|                  |                                  | Program/erase parallelism x 32 | -                  | 6   | 12                 |         |
|                  |                                  | Program/erase parallelism x 64 | -                  | 5   | 10                 |         |
| $V_{prog}$       | Programming voltage              | Program parallelism x 8        | 1.62               | -   | 3.6                | V       |
|                  |                                  | Program parallelism x 16       |                    |     |                    |         |
|                  |                                  | Program parallelism x 32       |                    |     |                    |         |
|                  |                                  | Program parallelism x 64       | 1.8                | -   | 3.6                |         |

1. Guaranteed by characterization results.
2. The maximum programming time is measured after 10K erase operations.

**Table 140. Flash memory endurance and data retention**

| Symbol           | Parameter      | Conditions  | Value              | Unit    |
|------------------|----------------|---|--------------------|---------|
|                  |                |   | Min <sup>(1)</sup> |         |
| N <sub>END</sub> | Endurance      | T <sub>J</sub> = -40 to +125 °C (6 suffix versions) | 10                 | kcycles |
| t <sub>RET</sub> | Data retention | 1 kcycle at T <sub>A</sub> = 85 °C                  | 30                 | Years   |
|                  |                | 10 kcycles at T <sub>A</sub> = 55 °C                | 20                 |         |

1. Guaranteed by characterization results.

### 7.3.12 EMC characteristics

Susceptibility tests are performed on a sample basis during device characterization.

#### Functional EMS (electromagnetic susceptibility)

While a simple application is executed on the device (toggling 2 LEDs through I/O ports), the device is stressed by two electromagnetic events until a failure occurs. The failure is indicated by the LEDs:

- **Electrostatic discharge (ESD)** (positive and negative) is applied to all device pins until a functional disturbance occurs. This test is compliant with the IEC 61000-4-2 standard.
- **FTB:** A burst of fast transient voltage (positive and negative) is applied to V<sub>DD</sub> and V<sub>SS</sub> through a 100 pF capacitor, until a functional disturbance occurs. This test is compliant with the IEC 61000-4-4 standard.

A device reset allows normal operations to be resumed.

The test results are given in [Table 141](#). They are based on the EMS levels and classes defined in application note AN1709.

**Table 141. EMS characteristics**

| Symbol            | Parameter   | Conditions   | Level/Class |
|-------------------|---|--|-------------|
| V <sub>FESD</sub> | Voltage limits to be applied on any I/O pin to induce a functional disturbance  | V <sub>DD</sub> = 3.3 V, T <sub>A</sub> = +25 °C, UFBGA240, f <sub>rcc_ck</sub> = 400 MHz, conforms to IEC 61000-4-2 | 3B          |
| V <sub>FTB</sub>  | Fast transient voltage burst limits to be applied through 100 pF on V <sub>DD</sub> and V <sub>SS</sub> pins to induce a functional disturbance |  | 5A          |

As a consequence, it is recommended to add a serial resistor (1 kΩ) located as close as possible to the MCU to the pins exposed to noise (connected to tracks longer than 50 mm on PCB).

**Designing hardened software to avoid noise problems**

EMC characterization and optimization are performed at component level with a typical application environment and simplified MCU software. It should be noted that good EMC performance is highly dependent on the user application and the software in particular.

Therefore it is recommended that the user applies EMC software optimization and prequalification tests in relation with the EMC level requested for his application.

**Software recommendations**

The software flowchart must include the management of runaway conditions such as:

- Corrupted program counter
- Unexpected reset
- Critical Data corruption (control registers...)

**Prequalification trials**

Most of the common failures (unexpected reset and program counter corruption) can be reproduced by manually forcing a low state on the NRST pin or the Oscillator pins for 1 second.

To complete these trials, ESD stress can be applied directly on the device, over the range of specification values. When unexpected behavior is detected, the software can be hardened to prevent unrecoverable errors occurring (see application note AN1015).

**Electromagnetic Interference (EMI)**

The electromagnetic field emitted by the device is monitored while a simple application, executing EEMBC code, is running. This emission test is compliant with SAE IEC61967-2 standard which specifies the test board and the pin loading.

**Table 142. EMI characteristics for  $f_{HSE} = 8 \text{ MHz}$  and  $f_{CPU} = 400 \text{ MHz}$**

| Symbol    | Parameter            | Conditions   | Monitored frequency band | Value | Unit       |
|-----------|----------------------|--|--------------------------|-------|------------|
| $S_{EMI}$ | Peak <sup>(1)</sup>  | $V_{DD} = 3.6 \text{ V}$ , $T_A = 25 \text{ °C}$ , UFBGA240 package, compliant with IEC61967-2 | 0.1 MHz to 30 MHz        | 11    | dB $\mu$ V |
|           |                      |  | 30 MHz to 130 MHz        | 6     |            |
|           |                      |  | 130 MHz to 1 GHz         | 12    |            |
|           |                      |  | 1 GHz to 2 GHz           | 7     |            |
|           | Level <sup>(2)</sup> |  | 0.1 MHz to 2 GHz         | 2.5   | -          |

1. Refer to AN1709 “EMI radiated test” chapter.
2. Refer to AN1709 “EMI level classification” chapter.

### 7.3.13 Absolute maximum ratings (electrical sensitivity)

Based on three different tests (ESD, LU) using specific measurement methods, the device is stressed in order to determine its performance in terms of electrical sensitivity.

#### Electrostatic discharge (ESD)

Electrostatic discharges (a positive then a negative pulse) are applied to the pins of each sample according to each pin combination. This test conforms to the ANSI/ESDA/JEDEC JS-001 and ANSI/ESDA/JEDEC JS-002 standards.

**Table 143. ESD absolute maximum ratings**

| Symbol         | Ratings   | Conditions   | Packages | Class | Maximum value <sup>(1)</sup> | Unit |
|----------------|---|--|----------|-------|------------------------------|------|
| $V_{ESD(HBM)}$ | Electrostatic discharge voltage (human body model)    | $T_A = +25\text{ °C}$ conforming to ANSI/ESDA/JEDEC JS-001 | All      | 1C    | 1000                         | V    |
| $V_{ESD(CDM)}$ | Electrostatic discharge voltage (charge device model) | $T_A = +25\text{ °C}$ conforming to ANSI/ESDA/JEDEC JS-002 | All      | C1    | 250                          |      |

1. Guaranteed by characterization results.

#### Static latchup

Two complementary static tests are required on six parts to assess the latchup performance:

- A supply overvoltage is applied to each power supply pin
- A current injection is applied to each input, output and configurable I/O pin

These tests are compliant with JESD78 IC latchup standard.

**Table 144. Electrical sensitivities**

| Symbol | Parameter            | Conditions                                 | Class      |
|--------|----------------------|--|------------|
| LU     | Static latchup class | $T_A = +25\text{ °C}$ conforming to JESD78 | II level A |

### 7.3.14 I/O current injection characteristics

As a general rule, a current injection to the I/O pins, due to external voltage below  $V_{SS}$  or above  $V_{DD}$  (for standard, 3.3 V-capable I/O pins) should be avoided during the normal product operation. However, in order to give an indication of the robustness of the microcontroller in cases when an abnormal injection accidentally happens, susceptibility tests are performed on a sample basis during the device characterization.

#### Functional susceptibility to I/O current injection

While a simple application is executed on the device, the device is stressed by injecting current into the I/O pins programmed in floating input mode. While current is injected into the I/O pin, one at a time, the device is checked for functional failures.

The failure is indicated by an out of range parameter: ADC error above a certain limit (higher than 5 LSB TUE), out of conventional limits of induced leakage current on adjacent pins (out of  $-5 \mu A/+0 \mu A$  range), or other functional failure (for example reset, oscillator frequency deviation).

The following tables are the compilation of the SIC1/SIC2 and functional ESD results.

Negative induced A negative induced leakage current is caused by negative injection and positive induced leakage current by positive injection.

**Table 145. I/O current injection susceptibility<sup>(1)</sup>**

| Symbol    | Description  | Functional susceptibility |                    | Unit |
|-----------|--|---------------------------|--------------------|------|
|           |  | Negative injection        | Positive injection |      |
| $I_{INJ}$ | PA7, PC5, PG1, PB14, PJ7, PA11, PA12, PA13, PA14, PA15, PJ12, PB4        | 5                         | 0                  | mA   |
|           | PA2, PH2, PH3, PE8, PA6, PA7, PC4, PE7, PE10, PE11                       | 0                         | NA                 |      |
|           | PA0, PA_C, PA1, PA1_C, PC2, PC2_C, PC3, PC3_C, PA4, PA5, PH4, PH5, BOOT0 | 0                         | 0                  |      |
|           | All other I/Os   | 5                         | NA                 |      |

1. Guaranteed by characterization.

### 7.3.15 I/O port characteristics

#### General input/output characteristics

Unless otherwise specified, the parameters given in [Table 146: I/O static characteristics](#) are derived from tests performed under the conditions summarized in [Table 111: General operating conditions](#). All I/Os are CMOS and TTL compliant (except for BOOT0).

For information on GPIO configuration, refer to the application note AN4899 “STM32 GPIO configuration for hardware settings and low-power consumption” available from the ST website [www.st.com](http://www.st.com).

**Table 146. I/O static characteristics**

| Symbol                                  | Parameter   | Condition   | Min                                      | Typ | Max                                     | Unit |
|---|---|---|--|-----|---|------|
| V <sub>IL</sub>                         | I/O input low level voltage except BOOT0          | 1.62 V < V <sub>DD</sub> < 3.6 V  | -  | -   | 0.3V <sub>DD</sub> <sup>(1)</sup>       | V    |
|   | I/O input low level voltage except BOOT0          |   | -  | -   | 0.4V <sub>DD</sub> -0.1 <sup>(2)</sup>  |      |
|   | BOOT0 I/O input low level voltage                 |   | -  | -   | 0.19V <sub>DD</sub> +0.1 <sup>(2)</sup> |      |
| V <sub>IH</sub>                         | I/O input high level voltage except BOOT0         | 1.62 V < V <sub>DD</sub> < 3.6 V  | 0.7V <sub>DD</sub> <sup>(1)</sup>        | -   | -                                       | V    |
|   | I/O input high level voltage except BOOT0         |   | 0.47V <sub>DD</sub> +0.25 <sup>(2)</sup> | -   | -                                       |      |
|   | BOOT0 I/O input high level voltage                |   | 0.17V <sub>DD</sub> +0.6 <sup>(2)</sup>  | -   | -                                       |      |
| V <sub>HYS</sub> <sup>(2)</sup>         | TT_xx, FT_xxx and NRST I/O input hysteresis       | 1.62 V < V <sub>DD</sub> < 3.6 V  | -  | 250 | -                                       | mV   |
|   | BOOT0 I/O input hysteresis                        |   | -  | 200 | -                                       |      |
| I <sub>lkg</sub> <sup>(3)</sup>         | FT_xx Input leakage current <sup>(2)</sup>        | 0 < V <sub>IN</sub> ≤ Max(V <sub>DDXXX</sub> ) <sup>(8)</sup>           | -  | -   | +/-250                                  | nA   |
|   |   | Max(V <sub>DDXXX</sub> ) < V <sub>IN</sub> ≤ 5.5 V <sup>(4)(5)(8)</sup> | -  | -   | 1500                                    |      |
|   | FT_u IO   | 0 < V <sub>IN</sub> ≤ Max(V <sub>DDXXX</sub> ) <sup>(8)</sup>           | -  | -   | +/- 350                                 |      |
|   |   | Max(V <sub>DDXXX</sub> ) < V <sub>IN</sub> ≤ 5.5 V <sup>(4)(5)(8)</sup> | -  | -   | 5000 <sup>(6)</sup>                     |      |
|   | TT_xx Input leakage current                       | 0 < V <sub>IN</sub> ≤ Max(V <sub>DDXXX</sub> ) <sup>(8)</sup>           | -  | -   | +/-250                                  |      |
|   | VPP (BOOT0 alternate function)                    | 0 < V <sub>IN</sub> ≤ V <sub>DD</sub>                                   | -  | -   | 15                                      |      |
| V <sub>DD</sub> < V <sub>IN</sub> ≤ 9 V |   | -   | -  | 35  |   |      |
| R <sub>PU</sub>                         | Weak pull-up equivalent resistor <sup>(7)</sup>   | V <sub>IN</sub> =V <sub>SS</sub>  | 30                                       | 40  | 50                                      | kΩ   |
| R <sub>PD</sub>                         | Weak pull-down equivalent resistor <sup>(7)</sup> | V <sub>IN</sub> =V <sub>DD</sub> <sup>(8)</sup>                         | 30                                       | 40  | 50                                      |      |
| C <sub>IO</sub>                         | I/O pin capacitance                               | -   | -  | 5   | -                                       | pF   |

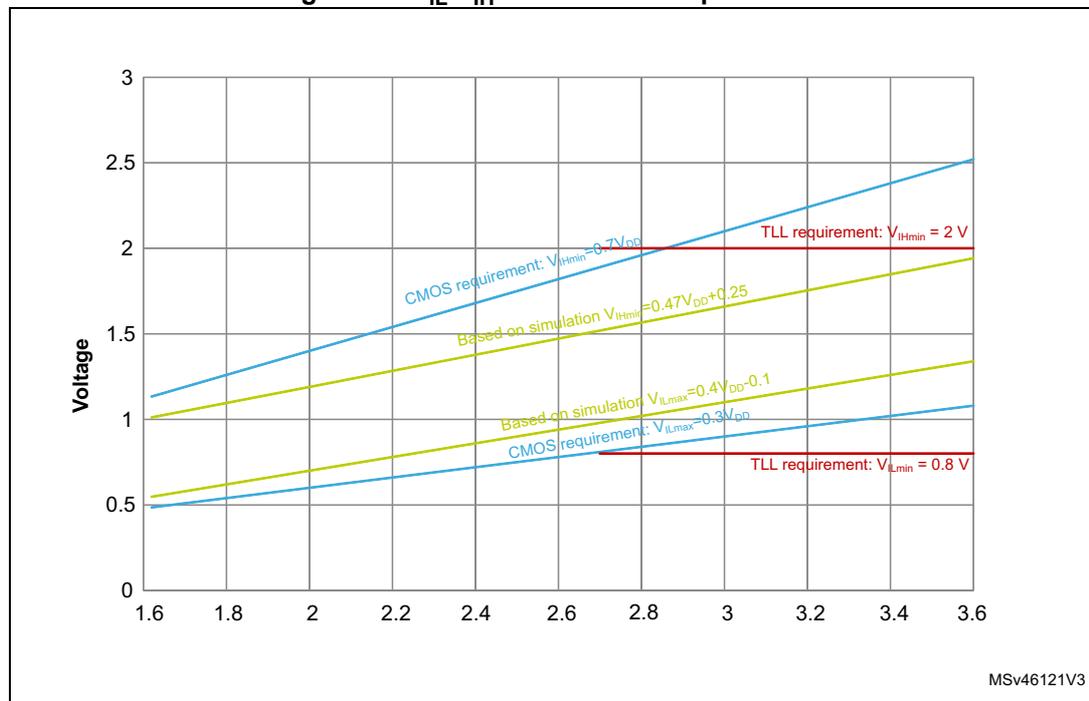
1. Compliant with CMOS requirements.

2. Guaranteed by design.

3. This parameter represents the pad leakage of the I/O itself. The total product pad leakage is provided by the following formula:  $I_{Total\_Ikg\_max} = 10 \mu A + [\text{number of I/Os where } V_{IN} \text{ is applied on the pad}] \times I_{kg(Max)}$ .
4. All FT\_xx IO except FT\_lu, FT\_u and PC3.
5.  $V_{IN}$  must be less than  $\text{Max}(V_{DDXXX}) + 3.6 \text{ V}$ .
6. To sustain a voltage higher than  $\text{MIN}(V_{DD}, V_{DDA}, V_{DD33USB}) + 0.3 \text{ V}$ , the internal pull-up and pull-down resistors must be disabled.
7. The pull-up and pull-down resistors are designed with a true resistance in series with a switchable PMOS/NMOS. This PMOS/NMOS contribution to the series resistance is minimal (~10% order).
8.  $\text{Max}(V_{DDXXX})$  is the maximum value of all the I/O supplies.

All I/Os are CMOS and TTL compliant (no software configuration required). Their characteristics cover more than the strict CMOS-technology or TTL parameters. The coverage of these requirements for FT I/Os is shown in [Figure 72](#).

Figure 72.  $V_{IL}/V_{IH}$  for all I/Os except BOOT0



### Output driving current

The GPIOs (general purpose input/outputs) can sink or source up to  $\pm 8 \text{ mA}$ , and sink or source up to  $\pm 20 \text{ mA}$  (with a relaxed  $V_{OL}/V_{OH}$ ).

In the user application, the number of I/O pins which can drive current must be limited to respect the absolute maximum rating specified in [Section 7.2](#). In particular:

- The sum of the currents sourced by all the I/Os on  $V_{DD}$ , plus the maximum Run consumption of the MCU sourced on  $V_{DD}$ , cannot exceed the absolute maximum rating  $\Sigma I_{VDD}$  (see [Table 109](#)).
- The sum of the currents sunk by all the I/Os on  $V_{SS}$  plus the maximum Run consumption of the MCU sunk on  $V_{SS}$  cannot exceed the absolute maximum rating  $\Sigma I_{VSS}$  (see [Table 109](#)).

### Output voltage levels

Unless otherwise specified, the parameters given in [Table 147: Output voltage characteristics for all I/Os except PC13, PC14, PC15 and PI8](#) and [Table 148: Output voltage characteristics for PC13, PC14, PC15 and PI8](#) are derived from tests performed under ambient temperature and  $V_{DD}$  supply voltage conditions summarized in [Table 111: General operating conditions](#). All I/Os are CMOS and TTL compliant.

**Table 147. Output voltage characteristics for all I/Os except PC13, PC14, PC15 and PI8<sup>(1)</sup>**

| Symbol            | Parameter   | Conditions <sup>(3)</sup>   | Min          | Max | Unit |
|-------------------|---|---|--------------|-----|------|
| $V_{OL}$          | Output low level voltage                                | CMOS port <sup>(2)</sup><br>$I_{IO}=8\text{ mA}$<br>$2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$  | -            | 0.4 | V    |
| $V_{OH}$          | Output high level voltage                               | CMOS port <sup>(2)</sup><br>$I_{IO}=-8\text{ mA}$<br>$2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ | $V_{DD}-0.4$ | -   |      |
| $V_{OL}^{(3)}$    | Output low level voltage                                | TTL port <sup>(2)</sup><br>$I_{IO}=8\text{ mA}$<br>$2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$   | -            | 0.4 |      |
| $V_{OH}^{(3)}$    | Output high level voltage                               | TTL port <sup>(2)</sup><br>$I_{IO}=-8\text{ mA}$<br>$2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$  | 2.4          | -   |      |
| $V_{OL}^{(3)}$    | Output low level voltage                                | $I_{IO}=20\text{ mA}$<br>$2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$                             | -            | 1.3 |      |
| $V_{OH}^{(3)}$    | Output high level voltage                               | $I_{IO}=-20\text{ mA}$<br>$2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$                            | $V_{DD}-1.3$ | -   |      |
| $V_{OL}^{(3)}$    | Output low level voltage                                | $I_{IO}=4\text{ mA}$<br>$1.62\text{ V} \leq V_{DD} \leq 3.6\text{ V}$                             | -            | 0.4 |      |
| $V_{OH}^{(3)}$    | Output high level voltage                               | $I_{IO}=-4\text{ mA}$<br>$1.62\text{ V} \leq V_{DD} < 3.6\text{ V}$                               | $V_{DD}-0.4$ | -   |      |
| $V_{OLFM+}^{(3)}$ | Output low level voltage for an FTf I/O pin in FM+ mode | $I_{IO}=20\text{ mA}$<br>$2.3\text{ V} \leq V_{DD} \leq 3.6\text{ V}$                             | -            | 0.4 |      |
|                   |   | $I_{IO}=10\text{ mA}$<br>$1.62\text{ V} \leq V_{DD} \leq 3.6\text{ V}$                            | -            | 0.4 |      |

- The I/O current sourced or sunk by the device must always respect the absolute maximum rating specified in [Table 108: Voltage characteristics](#), and the sum of the currents sourced or sunk by all the I/Os (I/O ports and control pins) must always respect the absolute maximum ratings  $\Sigma I_{IO}$ .
- TTL and CMOS outputs are compatible with JEDEC standards JESD36 and JESD52.
- Guaranteed by design.

Table 148. Output voltage characteristics for PC13, PC14, PC15 and PI8<sup>(1)</sup>

| Symbol         | Parameter                 | Conditions <sup>(3)</sup>   | Min          | Max | Unit |
|----------------|---------------------------|---|--------------|-----|------|
| $V_{OL}$       | Output low level voltage  | CMOS port <sup>(2)</sup><br>$I_{IO}=3\text{ mA}$<br>$2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$  | -            | 0.4 | V    |
| $V_{OH}$       | Output high level voltage | CMOS port <sup>(2)</sup><br>$I_{IO}=-3\text{ mA}$<br>$2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ | $V_{DD}-0.4$ | -   |      |
| $V_{OL}^{(3)}$ | Output low level voltage  | TTL port <sup>(2)</sup><br>$I_{IO}=3\text{ mA}$<br>$2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$   | -            | 0.4 |      |
| $V_{OH}^{(2)}$ | Output high level voltage | TTL port <sup>(2)</sup><br>$I_{IO}=-3\text{ mA}$<br>$2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$  | 2.4          | -   |      |
| $V_{OL}^{(2)}$ | Output low level voltage  | $I_{IO}=1.5\text{ mA}$<br>$1.62\text{ V} \leq V_{DD} \leq 3.6\text{ V}$                           | -            | 0.4 |      |
| $V_{OH}^{(2)}$ | Output high level voltage | $I_{IO}=-1.5\text{ mA}$<br>$1.62\text{ V} \leq V_{DD} \leq 3.6\text{ V}$                          | $V_{DD}-0.4$ | -   |      |

1. The I/O current sourced or sunk by the device must always respect the absolute maximum rating specified in [Table 108: Voltage characteristics](#), and the sum of the currents sourced or sunk by all the I/Os (I/O ports and control pins) must always respect the absolute maximum ratings  $\Sigma I/O$ .
2. TTL and CMOS outputs are compatible with JEDEC standards JESD36 and JESD52.
3. Guaranteed by design.

**Output buffer timing characteristics (HSLV option disabled)**

The HSLV bit of SYSCFG\_CCCSR register can be used to optimize the I/O speed when the product voltage is below 2.7 V.

**Table 149. Output timing characteristics (HSLV OFF)<sup>(1)(2)</sup>**

| Speed | Symbol           | Parameter   | conditions                                | Min | Max  | Unit |
|-------|------------------|---|---|-----|------|------|
| 00    | $F_{\max}^{(3)}$ | Maximum frequency   | C=50 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V  | -   | 12   | MHz  |
|       |                  |   | C=50 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V | -   | 3    |      |
|       |                  |   | C=30 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V  | -   | 12   |      |
|       |                  |   | C=30 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V | -   | 3    |      |
|       |                  |   | C=10 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V  | -   | 16   |      |
|       |                  |   | C=10 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V | -   | 4    |      |
|       | $t_r/t_f^{(4)}$  | Output high to low level fall time and output low to high level rise time | C=50 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V  | -   | 16.6 | ns   |
|       |                  |   | C=50 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V | -   | 33.3 |      |
|       |                  |   | C=30 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V  | -   | 13.3 |      |
|       |                  |   | C=30 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V | -   | 25   |      |
|       |                  |   | C=10 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V  | -   | 10   |      |
|       |                  |   | C=10 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V | -   | 20   |      |
| 01    | $F_{\max}^{(3)}$ | Maximum frequency   | C=50 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V  | -   | 60   | MHz  |
|       |                  |   | C=50 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V | -   | 15   |      |
|       |                  |   | C=30 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V  | -   | 80   |      |
|       |                  |   | C=30 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V | -   | 15   |      |
|       |                  |   | C=10 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V  | -   | 110  |      |
|       |                  |   | C=10 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V | -   | 20   |      |
|       | $t_r/t_f^{(4)}$  | Output high to low level fall time and output low to high level rise time | C=50 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V  | -   | 5.2  | ns   |
|       |                  |   | C=50 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V | -   | 10   |      |
|       |                  |   | C=30 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V  | -   | 4.2  |      |
|       |                  |   | C=30 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V | -   | 7.5  |      |
|       |                  |   | C=10 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V  | -   | 2.8  |      |
|       |                  |   | C=10 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V | -   | 5.2  |      |

Table 149. Output timing characteristics (HSLV OFF)<sup>(1)(2)</sup> (continued)

| Speed | Symbol  | Parameter   | conditions   | Min | Max | Unit |
|-------|---|---|--|-----|-----|------|
| 10    | F <sub>max</sub> <sup>(3)</sup>               | Maximum frequency   | C=50 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V <sup>(5)</sup>  | -   | 85  | MHz  |
|       |   |   | C=50 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(5)</sup> | -   | 35  |      |
|       |   |   | C=30 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V <sup>(5)</sup>  | -   | 110 |      |
|       |   |   | C=30 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(5)</sup> | -   | 40  |      |
|       |   |   | C=10 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V <sup>(5)</sup>  | -   | 166 |      |
|       |   |   | C=10 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(5)</sup> | -   | 85  |      |
|       | t <sub>r</sub> /t <sub>f</sub> <sup>(4)</sup> | Output high to low level fall time and output low to high level rise time | C=50 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V <sup>(5)</sup>  | -   | 3.8 | ns   |
|       |   |   | C=50 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(5)</sup> | -   | 6.9 |      |
|       |   |   | C=30 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V <sup>(5)</sup>  | -   | 2.8 |      |
|       |   |   | C=30 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(5)</sup> | -   | 5.2 |      |
| 11    | F <sub>max</sub> <sup>(3)</sup>               | Maximum frequency   | C=50 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V <sup>V</sup>    | -   | 100 | MHz  |
|       |   |   | C=50 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(5)</sup> | -   | 50  |      |
|       |   |   | C=30 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V <sup>V</sup>    | -   | 133 |      |
|       |   |   | C=30 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(5)</sup> | -   | 66  |      |
|       |   |   | C=10 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V <sup>(5)</sup>  | -   | 220 |      |
|       |   |   | C=10 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(5)</sup> | -   | 100 |      |
|       | t <sub>r</sub> /t <sub>f</sub> <sup>(4)</sup> | Output high to low level fall time and output low to high level rise time | C=50 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V <sup>(5)</sup>  | -   | 3.3 | ns   |
|       |   |   | C=50 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(5)</sup> | -   | 6.6 |      |
|       |   |   | C=30 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V <sup>(5)</sup>  | -   | 2.4 |      |
|       |   |   | C=30 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(5)</sup> | -   | 4.5 |      |
|       |   |   | C=10 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V <sup>(5)</sup>  | -   | 1.5 |      |
|       |   |   | C=10 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(5)</sup> | -   | 2.7 |      |

- Guaranteed by design.
- The frequency of the GPIOs that can be supplied in V<sub>BAT</sub> mode (PC13, PC14, PC15 and PI8) is limited to 2 MHz
- The maximum frequency is defined with the following conditions:  
 (t<sub>r</sub>+t<sub>f</sub>) ≤ 2/3 T  
 Skew ≤ 1/20 T  
 45% < Duty cycle < 55%
- The fall and rise times are defined between 90% and 10% and between 10% and 90% of the output waveform, respectively.
- Compensation system enabled.

## Output buffer timing characteristics (HSLV option enabled)

Table 150. Output timing characteristics (HSLV ON)<sup>(1)</sup>

| Speed | Symbol  | Parameter   | conditions   | Min | Max | Unit |
|-------|---|---|--|-----|-----|------|
| 00    | F <sub>max</sub> <sup>(2)</sup>               | Maximum frequency   | C=50 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V                | -   | 10  | MHz  |
|       |   |   | C=30 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V                | -   | 10  |      |
|       |   |   | C=10 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V                | -   | 10  |      |
|       | t <sub>r</sub> /t <sub>f</sub> <sup>(3)</sup> | Output high to low level fall time and output low to high level rise time | C=50 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V                | -   | 11  | ns   |
|       |   |   | C=30 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V                | -   | 9   |      |
|       |   |   | C=10 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V                | -   | 6.6 |      |
| 01    | F <sub>max</sub> <sup>(2)</sup>               | Maximum frequency   | C=50 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V                | -   | 50  | MHz  |
|       |   |   | C=30 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V                | -   | 58  |      |
|       |   |   | C=10 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V                | -   | 66  |      |
|       | t <sub>r</sub> /t <sub>f</sub> <sup>(3)</sup> | Output high to low level fall time and output low to high level rise time | C=50 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V                | -   | 6.6 | ns   |
|       |   |   | C=30 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V                | -   | 4.8 |      |
|       |   |   | C=10 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V                | -   | 3   |      |
| 10    | F <sub>max</sub> <sup>(2)</sup>               | Maximum frequency   | C=50 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(4)</sup> | -   | 55  | MHz  |
|       |   |   | C=30 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(4)</sup> | -   | 80  |      |
|       |   |   | C=10 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(4)</sup> | -   | 133 |      |
|       | t <sub>r</sub> /t <sub>f</sub> <sup>(3)</sup> | Output high to low level fall time and output low to high level rise time | C=50 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(4)</sup> | -   | 5.8 | ns   |
|       |   |   | C=30 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(4)</sup> | -   | 4   |      |
|       |   |   | C=10 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(4)</sup> | -   | 2.4 |      |
| 11    | F <sub>max</sub> <sup>(2)</sup>               | Maximum frequency   | C=50 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(4)</sup> | -   | 60  | MHz  |
|       |   |   | C=30 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(4)</sup> | -   | 90  |      |
|       |   |   | C=10 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(4)</sup> | -   | 175 |      |
|       | t <sub>r</sub> /t <sub>f</sub> <sup>(3)</sup> | Output high to low level fall time and output low to high level rise time | C=50 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(4)</sup> | -   | 5.3 | ns   |
|       |   |   | C=30 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(4)</sup> | -   | 3.6 |      |
|       |   |   | C=10 pF, 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V <sup>(4)</sup> | -   | 1.9 |      |

1. Guaranteed by design.

2. The maximum frequency is defined with the following conditions:  
 $(t_r + t_f) \leq 2/3 T$   
 Skew  $\leq 1/20 T$   
 $45\% < \text{Duty cycle} < 55\%$

3. The fall and rise times are defined between 90% and 10% and between 10% and 90% of the output waveform, respectively.

4. Compensation system enabled.

### 7.3.16 NRST pin characteristics

The NRST pin input driver uses CMOS technology. It is connected to a permanent pull-up resistor,  $R_{PU}$  (see [Table 146: I/O static characteristics](#)).

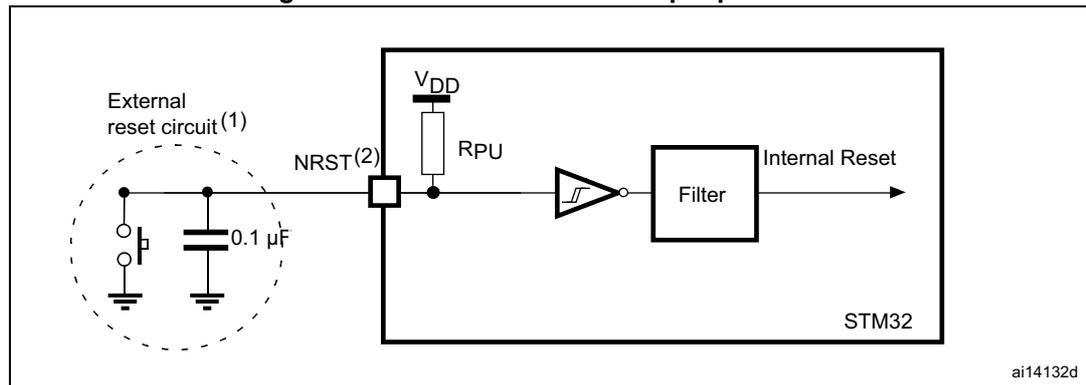
Unless otherwise specified, the parameters given in [Table 151](#) are derived from tests performed under the ambient temperature and  $V_{DD}$  supply voltage conditions summarized in [Table 111: General operating conditions](#).

**Table 151. NRST pin characteristics**

| Symbol               | Parameter                                       | Conditions                              | Min  | Typ | Max | Unit       |
|----------------------|---|---|------|-----|-----|------------|
| $R_{PU}^{(2)}$       | Weak pull-up equivalent resistor <sup>(1)</sup> | $V_{IN} = V_{SS}$                       | 30   | 40  | 50  | k $\Omega$ |
| $V_{F(NRST)}^{(2)}$  | NRST Input filtered pulse                       | $1.71\text{ V} < V_{DD} < 3.6\text{ V}$ | -    | -   | 50  | ns         |
| $V_{NF(NRST)}^{(2)}$ | NRST Input not filtered pulse                   | $1.71\text{ V} < V_{DD} < 3.6\text{ V}$ | 300  | -   | -   |            |
|                      |   | $1.62\text{ V} < V_{DD} < 3.6\text{ V}$ | 1000 | -   | -   |            |

1. The pull-up is designed with a true resistance in series with a switchable PMOS. This PMOS contribution to the series resistance must be minimum (~10% order).
2. Guaranteed by design.

**Figure 73. Recommended NRST pin protection**



1. The reset network protects the device against parasitic resets.
2. The user must ensure that the level on the NRST pin can go below the  $V_{IL(NRST)}$  max level specified in [Table 146](#). Otherwise the reset is not taken into account by the device.

### 7.3.17 FMC characteristics

Unless otherwise specified, the parameters given in [Table 152](#) to [Table 165](#) for the FMC interface are derived from tests performed under the ambient temperature,  $f_{HCLK}$  frequency and  $V_{DD}$  supply voltage conditions summarized in [Table 111: General operating conditions](#), with the following configuration:

- Output speed is set to  $OSPEEDRy[1:0] = 11$
- Measurement points are done at CMOS levels:  $0.5V_{DD}$
- IO Compensation cell activated.
- HSLV activated when  $V_{DD} \leq 2.7\text{ V}$
- VOS level set to VOS1.

Refer to [Section 7.3.15: I/O port characteristics](#) for more details on the input/output alternate function characteristics.

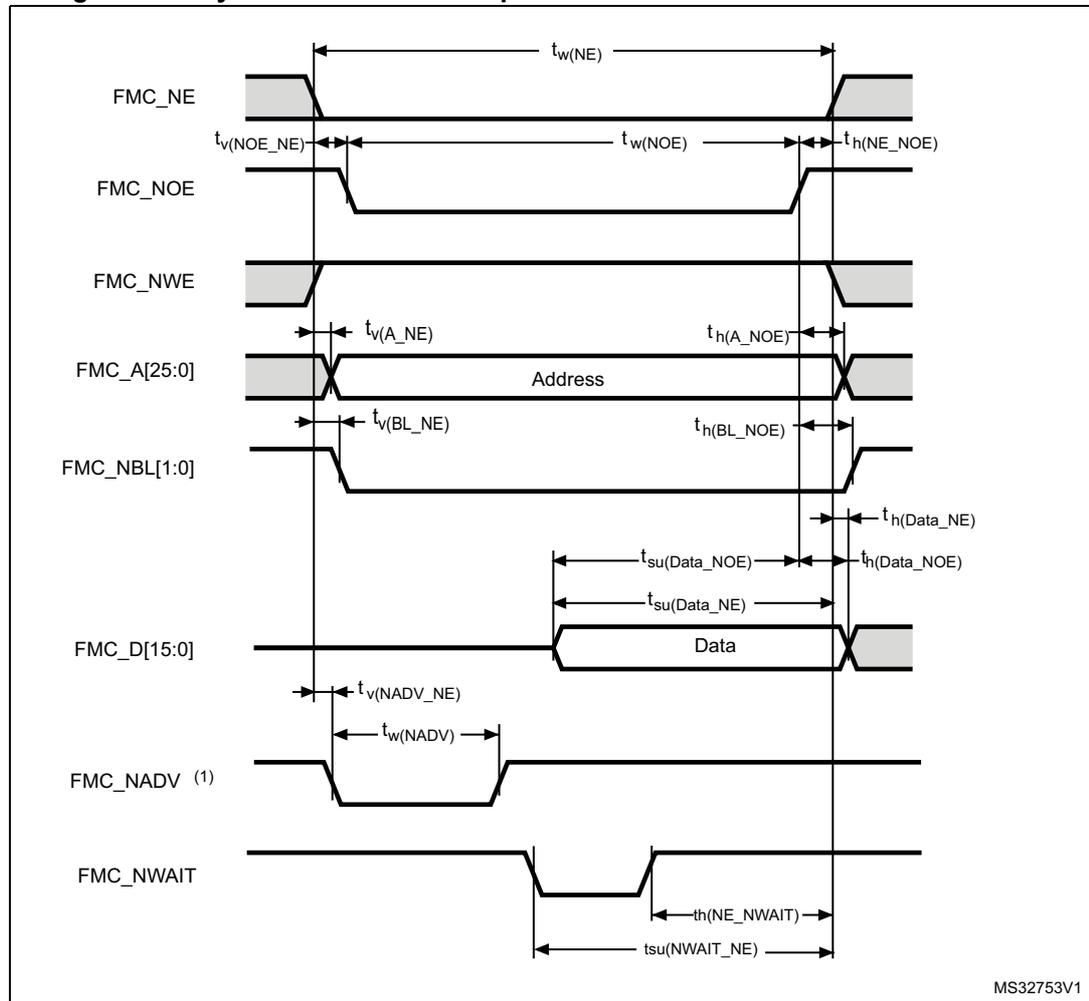
**Asynchronous waveforms and timings**

[Figure 74](#) through [Figure 76](#) represent asynchronous waveforms and [Table 152](#) through [Table 159](#) provide the corresponding timings. The results shown in these tables are obtained with the following FMC configuration:

- AddressSetupTime = 0x1
- AddressHoldTime = 0x1
- DataSetupTime = 0x1 (except for asynchronous NWAIT mode , DataSetupTime = 0x5)
- BusTurnAroundDuration = 0x0
- Capacitive load  $C_L = 30$  pF

In all timing tables, the  $T_{KERCK}$  is the  $f_{mc\_ker\_ck}$  clock period.

**Figure 74. Asynchronous non-multiplexed SRAM/PSRAM/NOR read waveforms**



1. Mode 2/B, C and D only. In Mode 1, FMC\_NADV is not used.

**Table 152. Asynchronous non-multiplexed SRAM/PSRAM/NOR read timings<sup>(1)</sup>**

| Symbol              | Parameter                             | Min                   | Max                   | Unit |
|---------------------|---------------------------------------|-----------------------|-----------------------|------|
| $t_{w(NE)}$         | FMC_NE low time                       | $3T_{fmc\_ker\_ck}-1$ | $3T_{fmc\_ker\_ck}+1$ | ns   |
| $t_{v(NO\_NE)}$     | FMC_NEx low to FMC_NOE low            | 0                     | 0.5                   |      |
| $t_{w(NO\_E)}$      | FMC_NOE low time                      | $2T_{fmc\_ker\_ck}-1$ | $2T_{fmc\_ker\_ck}+1$ |      |
| $t_{h(NE\_NOE)}$    | FMC_NOE high to FMC_NE high hold time | 0                     | -                     |      |
| $t_{v(A\_NE)}$      | FMC_NEx low to FMC_A valid            | -                     | 0.5                   |      |
| $t_{h(A\_NOE)}$     | Address hold time after FMC_NOE high  | 0                     | -                     |      |
| $t_{su(Data\_NE)}$  | Data to FMC_NEx high setup time       | 11                    | -                     |      |
| $t_{su(Data\_NOE)}$ | Data to FMC_NOEx high setup time      | 11                    | -                     |      |
| $t_{h(Data\_NOE)}$  | Data hold time after FMC_NOE high     | 0                     | -                     |      |
| $t_{h(Data\_NE)}$   | Data hold time after FMC_NEx high     | 0                     | -                     |      |
| $t_{v(NADV\_NE)}$   | FMC_NEx low to FMC_NADV low           | -                     | 0                     |      |
| $t_{w(NADV)}$       | FMC_NADV low time                     | -                     | $T_{fmc\_ker\_ck}+1$  |      |

1. Guaranteed by characterization results.

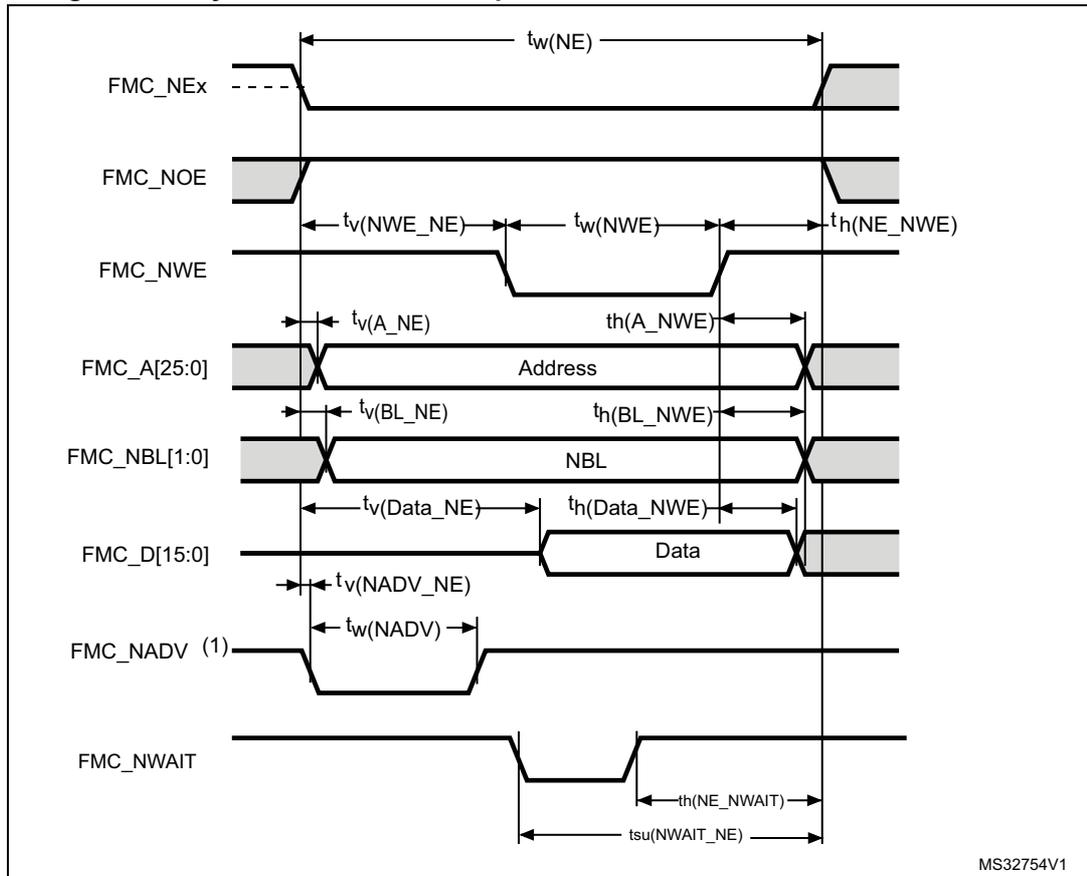
**Table 153. Asynchronous non-multiplexed SRAM/PSRAM/NOR read-NWAIT timings<sup>(1)(2)</sup>**

| Symbol              | Parameter                                 | Min                      | Max                   | Unit |
|---------------------|---|--------------------------|-----------------------|------|
| $t_{w(NE)}$         | FMC_NE low time                           | $7T_{fmc\_ker\_ck}+1$    | $7T_{fmc\_ker\_ck}+1$ | ns   |
| $t_{w(NO\_E)}$      | FMC_NOE low time                          | $5T_{fmc\_ker\_ck}-1$    | $5T_{fmc\_ker\_ck}+1$ |      |
| $t_{w(NWAIT)}$      | FMC_NWAIT low time                        | $T_{fmc\_ker\_ck}-0.5$   | -                     |      |
| $t_{su(NWAIT\_NE)}$ | FMC_NWAIT valid before FMC_NEx high       | $4T_{fmc\_ker\_ck}+11$   | -                     |      |
| $t_{h(NE\_NWAIT)}$  | FMC_NEx hold time after FMC_NWAIT invalid | $3T_{fmc\_ker\_ck}+11.5$ | -                     |      |

1. Guaranteed by characterization results.

2.  $N_{WAIT}$  pulse width is equal to 1 AHB cycle.

Figure 75. Asynchronous non-multiplexed SRAM/PSRAM/NOR write waveforms



1. Mode 2/B, C and D only. In Mode 1, FMC\_NADV is not used.

**Table 154. Asynchronous non-multiplexed SRAM/PSRAM/NOR write timings<sup>(1)</sup>**

| Symbol             | Parameter                             | Min                      | Max                      | Unit |
|--------------------|---------------------------------------|--------------------------|--------------------------|------|
| $t_{w(NE)}$        | FMC_NE low time                       | $3T_{fmc\_ker\_ck} - 1$  | $3T_{fmc\_ker\_ck}$      | ns   |
| $t_{v(NWE\_NE)}$   | FMC_NEx low to FMC_NWE low            | $T_{fmc\_ker\_ck}$       | $T_{fmc\_ker\_ck} + 1$   |      |
| $t_{w(NWE)}$       | FMC_NWE low time                      | $T_{fmc\_ker\_ck} - 0.5$ | $T_{fmc\_ker\_ck} + 0.5$ |      |
| $t_{h(NE\_NWE)}$   | FMC_NWE high to FMC_NE high hold time | $T_{fmc\_ker\_ck}$       | -                        |      |
| $t_{v(A\_NE)}$     | FMC_NEx low to FMC_A valid            | -                        | 2                        |      |
| $t_{h(A\_NWE)}$    | Address hold time after FMC_NWE high  | $T_{fmc\_ker\_ck} - 0.5$ | -                        |      |
| $t_{v(BL\_NE)}$    | FMC_NEx low to FMC_BL valid           | -                        | 0.5                      |      |
| $t_{h(BL\_NWE)}$   | FMC_BL hold time after FMC_NWE high   | $T_{fmc\_ker\_ck} - 0.5$ | -                        |      |
| $t_{v(Data\_NE)}$  | Data to FMC_NEx low to Data valid     | -                        | $T_{fmc\_ker\_ck} + 2.5$ |      |
| $t_{h(Data\_NWE)}$ | Data hold time after FMC_NWE high     | $T_{fmc\_ker\_ck} + 0.5$ | -                        |      |
| $t_{v(NADV\_NE)}$  | FMC_NEx low to FMC_NADV low           | -                        | 0                        |      |
| $t_{w(NADV)}$      | FMC_NADV low time                     | -                        | $T_{fmc\_ker\_ck} + 1$   |      |

1. Guaranteed by characterization results.

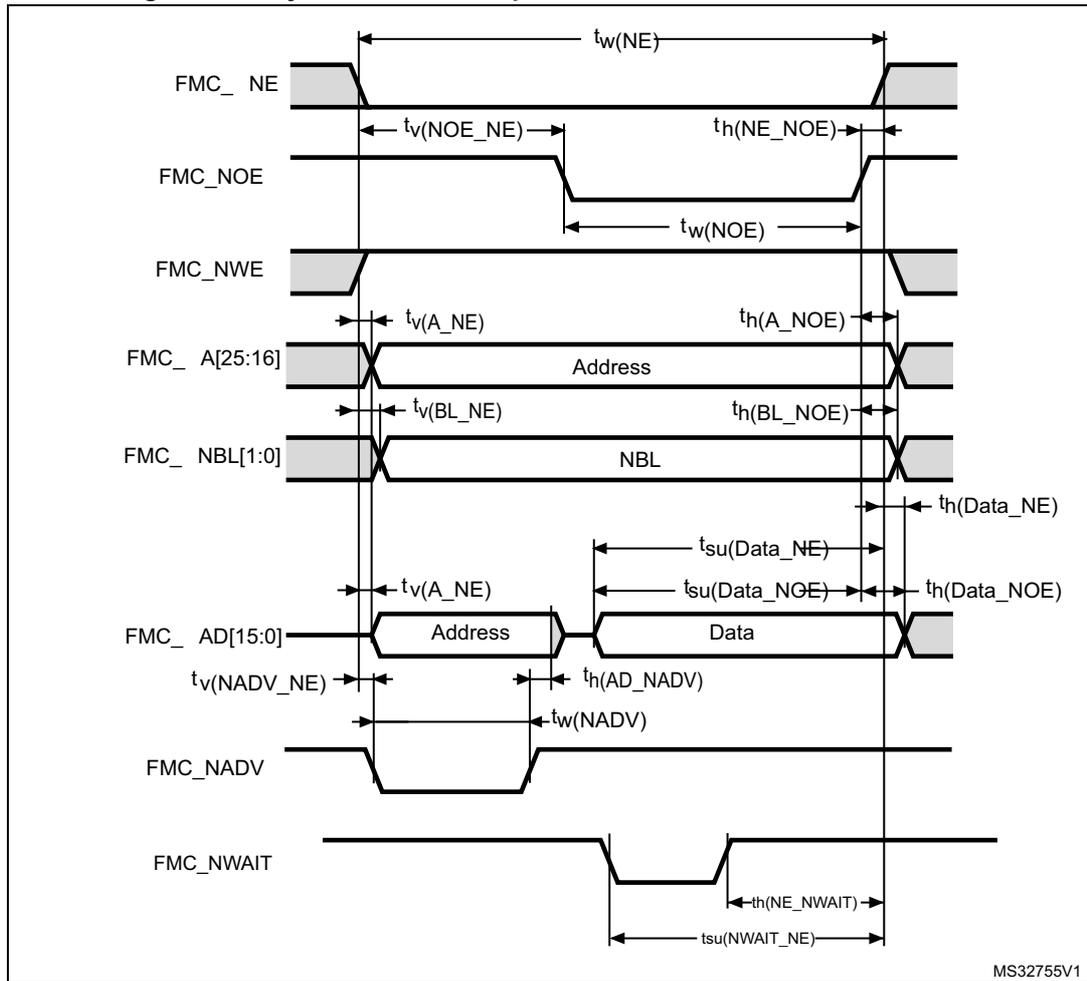
**Table 155. Asynchronous non-multiplexed SRAM/PSRAM/NOR write-NWAIT timings<sup>(1)(2)</sup>**

| Symbol              | Parameter                                 | Min                       | Max                       | Unit |
|---------------------|---|---------------------------|---------------------------|------|
| $t_{w(NE)}$         | FMC_NE low time                           | $8T_{fmc\_ker\_ck} - 1$   | $8T_{fmc\_ker\_ck} + 1$   | ns   |
| $t_{w(NWE)}$        | FMC_NWE low time                          | $6T_{fmc\_ker\_ck} - 1.5$ | $6T_{fmc\_ker\_ck} + 0.5$ |      |
| $t_{su(NWAIT\_NE)}$ | FMC_NWAIT valid before FMC_NEx high       | $5T_{fmc\_ker\_ck} + 13$  | -                         |      |
| $t_{h(NE\_NWAIT)}$  | FMC_NEx hold time after FMC_NWAIT invalid | $4T_{fmc\_ker\_ck} + 13$  | -                         |      |

1. Guaranteed by characterization results.

2.  $N_{WAIT}$  pulse width is equal to 1 AHB cycle.

Figure 76. Asynchronous multiplexed PSRAM/NOR read waveforms



**Table 156. Asynchronous multiplexed PSRAM/NOR read timings<sup>(1)</sup>**

| Symbol              | Parameter   | Min                      | Max                       | Unit |
|---------------------|---|--------------------------|---------------------------|------|
| $t_{w(NE)}$         | FMC_NE low time                                     | $4T_{fmc\_ker\_ck} - 1$  | $4T_{fmc\_ker\_ck} + 1$   | ns   |
| $t_{v(NOE\_NE)}$    | FMC_NEx low to FMC_NOE low                          | $2T_{fmc\_ker\_ck}$      | $2T_{fmc\_ker\_ck} + 0.5$ |      |
| $t_{tw(NOE)}$       | FMC_NOE low time                                    | $T_{fmc\_ker\_ck} - 1$   | $T_{fmc\_ker\_ck} + 1$    |      |
| $t_{h(NE\_NOE)}$    | FMC_NOE high to FMC_NE high hold time               | 0                        | -                         |      |
| $t_{v(A\_NE)}$      | FMC_NEx low to FMC_A valid                          | -                        | 0.5                       |      |
| $t_{v(NADV\_NE)}$   | FMC_NEx low to FMC_NADV low                         | 0                        | 0.5                       |      |
| $t_{w(NADV)}$       | FMC_NADV low time                                   | $T_{fmc\_ker\_ck} - 0.5$ | $T_{fmc\_ker\_ck} + 1$    |      |
| $t_{h(AD\_NADV)}$   | FMC_AD(address) valid hold time after FMC_NADV high | $T_{fmc\_ker\_ck} + 0.5$ | -                         |      |
| $t_{h(A\_NOE)}$     | Address hold time after FMC_NOE high                | $T_{fmc\_ker\_ck} - 0.5$ | -                         |      |
| $t_{su(Data\_NE)}$  | Data to FMC_NEx high setup time                     | 11                       | -                         |      |
| $t_{su(Data\_NOE)}$ | Data to FMC_NOE high setup time                     | 11                       | -                         |      |
| $t_{h(Data\_NE)}$   | Data hold time after FMC_NEx high                   | 0                        | -                         |      |
| $t_{h(Data\_NOE)}$  | Data hold time after FMC_NOE high                   | 0                        | -                         |      |

1. Guaranteed by characterization results.

**Table 157. Asynchronous multiplexed PSRAM/NOR read-NWAIT timings<sup>(1)(2)</sup>**

| Symbol              | Parameter                                 | Min                        | Max                       | Unit |
|---------------------|---|----------------------------|---------------------------|------|
| $t_{w(NE)}$         | FMC_NE low time                           | $8T_{fmc\_ker\_ck} - 1$    | $8T_{fmc\_ker\_ck}$       | ns   |
| $t_{w(NOE)}$        | FMC_NWE low time                          | $5T_{fmc\_ker\_ck} - 1.5$  | $5T_{fmc\_ker\_ck} + 0.5$ |      |
| $t_{su(NWAIT\_NE)}$ | FMC_NWAIT valid before FMC_NEx high       | $4T_{fmc\_ker\_ck} + 11$   | -                         |      |
| $t_{h(NE\_NWAIT)}$  | FMC_NEx hold time after FMC_NWAIT invalid | $3T_{fmc\_ker\_ck} + 11.5$ | -                         |      |

1. Guaranteed by characterization results.

2.  $N_{WAIT}$  pulse width is equal to 1 AHB cycle.

Table 158. Asynchronous multiplexed PSRAM/NOR write timings<sup>(1)</sup>

| Symbol              | Parameter   | Min                       | Max                       | Unit |
|---------------------|---|---------------------------|---------------------------|------|
| $t_{w(NE)}$         | FMC_NE low time                                     | $4T_{fmc\_ker\_ck} - 1$   | $4T_{fmc\_ker\_ck}$       | ns   |
| $t_{v(NWE\_NE)}$    | FMC_NEx low to FMC_NWE low                          | $T_{fmc\_ker\_ck} - 1$    | $T_{fmc\_ker\_ck} + 0.5$  |      |
| $t_{w(NWE)}$        | FMC_NWE low time                                    | $2T_{fmc\_ker\_ck} - 0.5$ | $2T_{fmc\_ker\_ck} + 0.5$ |      |
| $t_{h(NE\_NWE)}$    | FMC_NWE high to FMC_NE high hold time               | $T_{fmc\_ker\_ck} - 0.5$  | -                         |      |
| $t_{v(A\_NE)}$      | FMC_NEx low to FMC_A valid                          | -                         | 0                         |      |
| $t_{v(NADV\_NE)}$   | FMC_NEx low to FMC_NADV low                         | 0                         | 0.5                       |      |
| $t_{w(NADV)}$       | FMC_NADV low time                                   | $T_{fmc\_ker\_ck}$        | $T_{fmc\_ker\_ck} + 1$    |      |
| $t_{h(AD\_NADV)}$   | FMC_AD(address) valid hold time after FMC_NADV high | $T_{fmc\_ker\_ck} + 0.5$  | -                         |      |
| $t_{h(A\_NWE)}$     | Address hold time after FMC_NWE high                | $T_{fmc\_ker\_ck} + 0.5$  | -                         |      |
| $t_{h(BL\_NWE)}$    | FMC_BL hold time after FMC_NWE high                 | $T_{fmc\_ker\_ck} - 0.5$  | -                         |      |
| $t_{v(BL\_NE)}$     | FMC_NEx low to FMC_BL valid                         | -                         | 0.5                       |      |
| $t_{v(Data\_NADV)}$ | FMC_NADV high to Data valid                         | -                         | $T_{fmc\_ker\_ck} + 2$    |      |
| $t_{h(Data\_NWE)}$  | Data hold time after FMC_NWE high                   | $T_{fmc\_ker\_ck} + 0.5$  | -                         |      |

1. Guaranteed by characterization results.

Table 159. Asynchronous multiplexed PSRAM/NOR write-NWAIT timings<sup>(1)(2)</sup>

| Symbol              | Parameter                                 | Min                        | Max                       | Unit |
|---------------------|---|----------------------------|---------------------------|------|
| $t_{w(NE)}$         | FMC_NE low time                           | $9T_{fmc\_ker\_ck} - 1$    | $9T_{fmc\_ker\_ck}$       | ns   |
| $t_{w(NWE)}$        | FMC_NWE low time                          | $7T_{fmc\_ker\_ck} - 0.5$  | $7T_{fmc\_ker\_ck} + 0.5$ |      |
| $t_{su(NWAIT\_NE)}$ | FMC_NWAIT valid before FMC_NEx high       | $5T_{fmc\_ker\_ck} + 11$   | -                         |      |
| $t_{h(NE\_NWAIT)}$  | FMC_NEx hold time after FMC_NWAIT invalid | $4T_{fmc\_ker\_ck} + 11.5$ | -                         |      |

1. Guaranteed by characterization results.

2.  $N_{WAIT}$  pulse width is equal to 1 AHB cycle.

## Synchronous waveforms and timings

Figure 77 through Figure 80 represent synchronous waveforms and Table 160 through Table 163 provide the corresponding timings. The results shown in these tables are obtained with the following FMC configuration:

- BurstAccessMode = FMC\_BurstAccessMode\_Enable
- MemoryType = FMC\_MemoryType\_CRAM
- WriteBurst = FMC\_WriteBurst\_Enable
- CLKDivision = 1
- DataLatency = 1 for NOR flash; DataLatency = 0 for PSRAM

In all the timing tables, the  $T_{fmc\_ker\_ck}$  is the  $f_{fmc\_ker\_ck}$  clock period, with the following FMC\_CLK maximum values:

- For  $2.7\text{ V} < V_{DD} < 3.6\text{ V}$ , FMC\_CLK = 125 MHz at 20 pF
- For  $1.8\text{ V} < V_{DD} < 1.9\text{ V}$ , FMC\_CLK = 100 MHz at 20 pF
- For  $1.62\text{ V} < V_{DD} < 1.8\text{ V}$ , FMC\_CLK = 100 MHz at 15 pF

Figure 77. Synchronous multiplexed NOR/PSRAM read timings

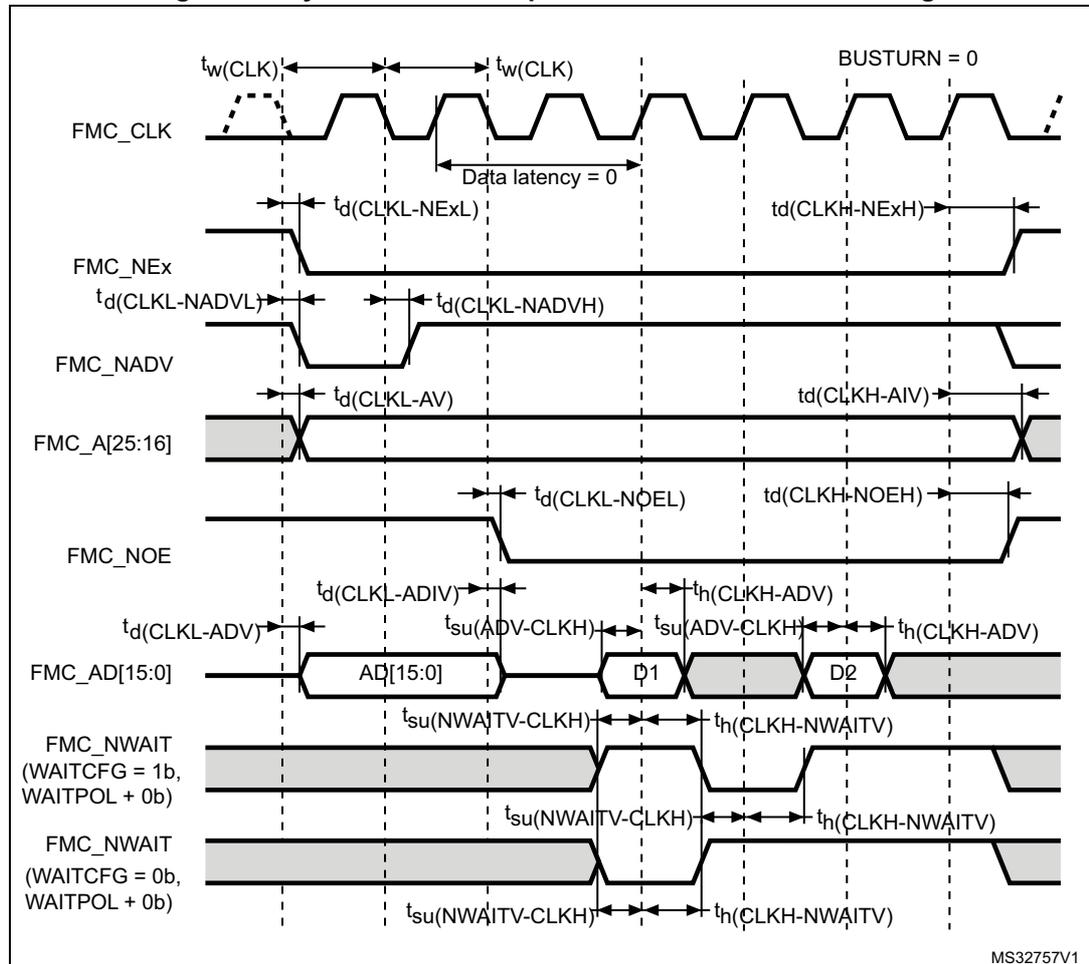


Table 160. Synchronous multiplexed NOR/PSRAM read timings<sup>(1)</sup>

| Symbol                             | Parameter                                     | Min                             | Max | Unit |
|------------------------------------|---|---------------------------------|-----|------|
| $t_w(\text{CLK})$                  | FMC_CLK period                                | $2T_{\text{fmc\_ker\_ck}} - 1$  | -   | ns   |
| $t_d(\text{CLKL-NEXL})$            | FMC_CLK low to FMC_NEx low ( $x=0..2$ )       | -                               | 1   |      |
| $t_d(\text{CLKH-NEXH})$            | FMC_CLK high to FMC_NEx high ( $x=0..2$ )     | $T_{\text{fmc\_ker\_ck}} + 0.5$ | -   |      |
| $t_d(\text{CLKL-NADV})$            | FMC_CLK low to FMC_NADV low                   | -                               | 1   |      |
| $t_d(\text{CLKL-NADVH})$           | FMC_CLK low to FMC_NADV high                  | 0                               | -   |      |
| $t_d(\text{CLKL-AV})$              | FMC_CLK low to FMC_Ax valid ( $x=16..25$ )    | -                               | 2.5 |      |
| $t_d(\text{CLKH-AIV})$             | FMC_CLK high to FMC_Ax invalid ( $x=16..25$ ) | $T_{\text{fmc\_ker\_ck}}$       | -   |      |
| $t_d(\text{CLKL-NOEL})$            | FMC_CLK low to FMC_NOE low                    | -                               | 1.5 |      |
| $t_d(\text{CLKH-NOEH})$            | FMC_CLK high to FMC_NOE high                  | $T_{\text{fmc\_ker\_ck}} - 0.5$ | -   |      |
| $t_d(\text{CLKL-ADV})$             | FMC_CLK low to FMC_AD[15:0] valid             | -                               | 3   |      |
| $t_d(\text{CLKL-ADIV})$            | FMC_CLK low to FMC_AD[15:0] invalid           | 0                               | -   |      |
| $t_{\text{su}}(\text{ADV-CLKH})$   | FMC_A/D[15:0] valid data before FMC_CLK high  | 3                               | -   |      |
| $t_h(\text{CLKH-ADV})$             | FMC_A/D[15:0] valid data after FMC_CLK high   | 0                               | -   |      |
| $t_{\text{su}}(\text{NWAIT-CLKH})$ | FMC_NWAIT valid before FMC_CLK high           | 3                               | -   |      |
| $t_h(\text{CLKH-NWAIT})$           | FMC_NWAIT valid after FMC_CLK high            | 1                               | -   |      |

1. Guaranteed by characterization results.

Figure 78. Synchronous multiplexed PSRAM write timings

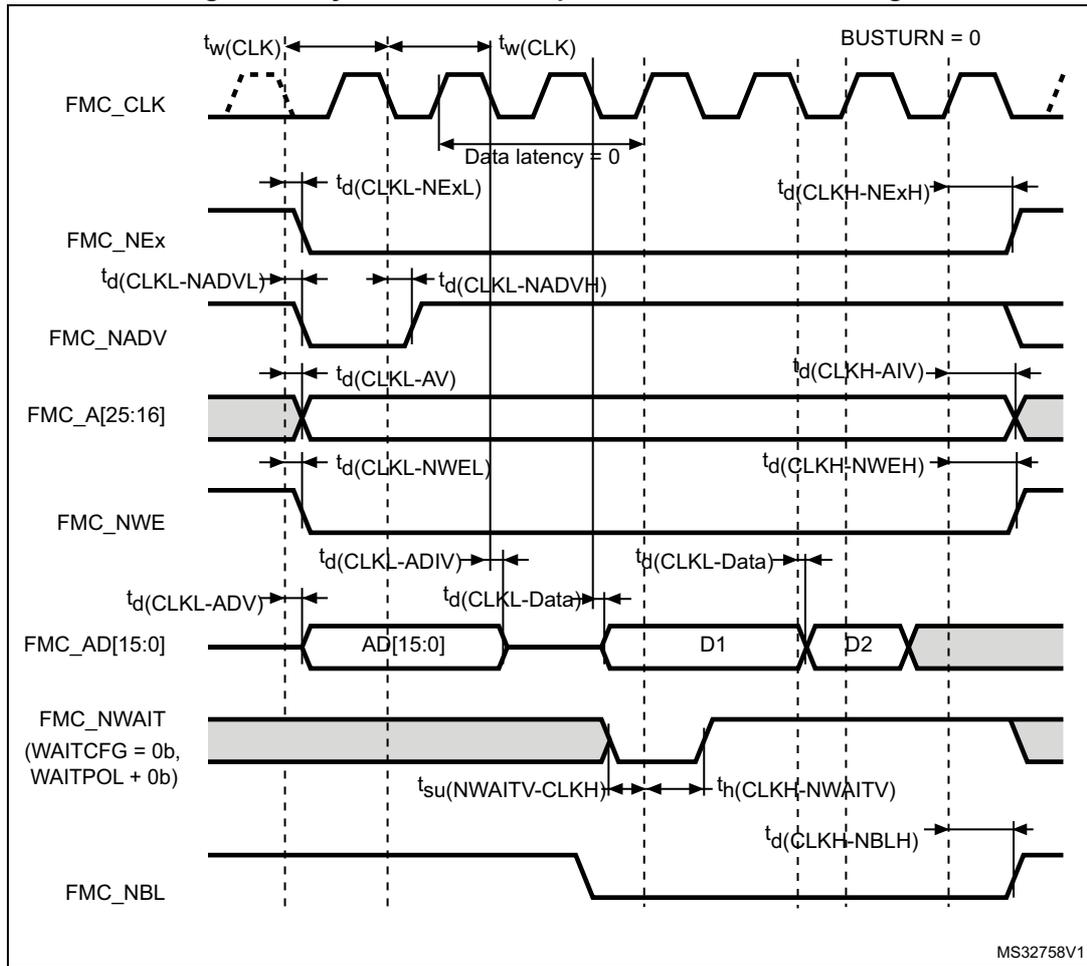


Table 161. Synchronous multiplexed PSRAM write timings<sup>(1)</sup>

| Symbol                      | Parameter  | Min                               | Max | Unit |
|-----------------------------|--|-----------------------------------|-----|------|
| $t_w(\text{CLK})$           | FMC_CLK period, $V_{DD} = 2.7$ to $3.6$ V          | $\frac{2T_{fmc\_ker\_ck} - 1}{1}$ | -   | Ns   |
| $t_d(\text{CLKL-NEXL})$     | FMC_CLK low to FMC_NEx low ( $x = 0..2$ )          | -                                 | 1   |      |
| $t_d(\text{CLKH-NEXH})$     | FMC_CLK high to FMC_NEx high<br>( $x = 0..2$ )     | $T_{fmc\_ker\_ck} + 0.5$          | -   |      |
| $t_d(\text{CLKL-NADV})$     | FMC_CLK low to FMC_NADV low                        | -                                 | 1.5 |      |
| $t_d(\text{CLKL-NADVH})$    | FMC_CLK low to FMC_NADV high                       | 0                                 | -   |      |
| $t_d(\text{CLKL-AV})$       | FMC_CLK low to FMC_Ax valid<br>( $x = 16..25$ )    | -                                 | 2   |      |
| $t_d(\text{CLKH-AIV})$      | FMC_CLK high to FMC_Ax invalid<br>( $x = 16..25$ ) | $T_{fmc\_ker\_ck}$                | -   |      |
| $t_d(\text{CLKL-NWEL})$     | FMC_CLK low to FMC_NWE low                         | -                                 | 1.5 |      |
| $t_d(\text{CLKH-NWEH})$     | FMC_CLK high to FMC_NWE high                       | $T_{fmc\_ker\_ck} + 0.5$          | -   |      |
| $t_d(\text{CLKL-ADV})$      | FMC_CLK low to FMC_AD[15:0] valid                  | -                                 | 2.5 |      |
| $t_d(\text{CLKL-ADIV})$     | FMC_CLK low to FMC_AD[15:0] invalid                | 0                                 | -   |      |
| $t_d(\text{CLKL-DATA})$     | FMC_A/D[15:0] valid data after FMC_CLK low         | -                                 | 2.5 |      |
| $t_d(\text{CLKL-NBLL})$     | FMC_CLK low to FMC_NBL low                         | -                                 | 2   |      |
| $t_d(\text{CLKH-NBLH})$     | FMC_CLK high to FMC_NBL high                       | $T_{fmc\_ker\_ck} + 0.5$          | -   |      |
| $t_{su}(\text{NWAIT-CLKH})$ | FMC_NWAIT valid before FMC_CLK high                | 2                                 | -   |      |
| $t_h(\text{CLKH-NWAIT})$    | FMC_NWAIT valid after FMC_CLK high                 | 2                                 | -   |      |

1. Guaranteed by characterization results.

Figure 79. Synchronous non-multiplexed NOR/PSRAM read timings

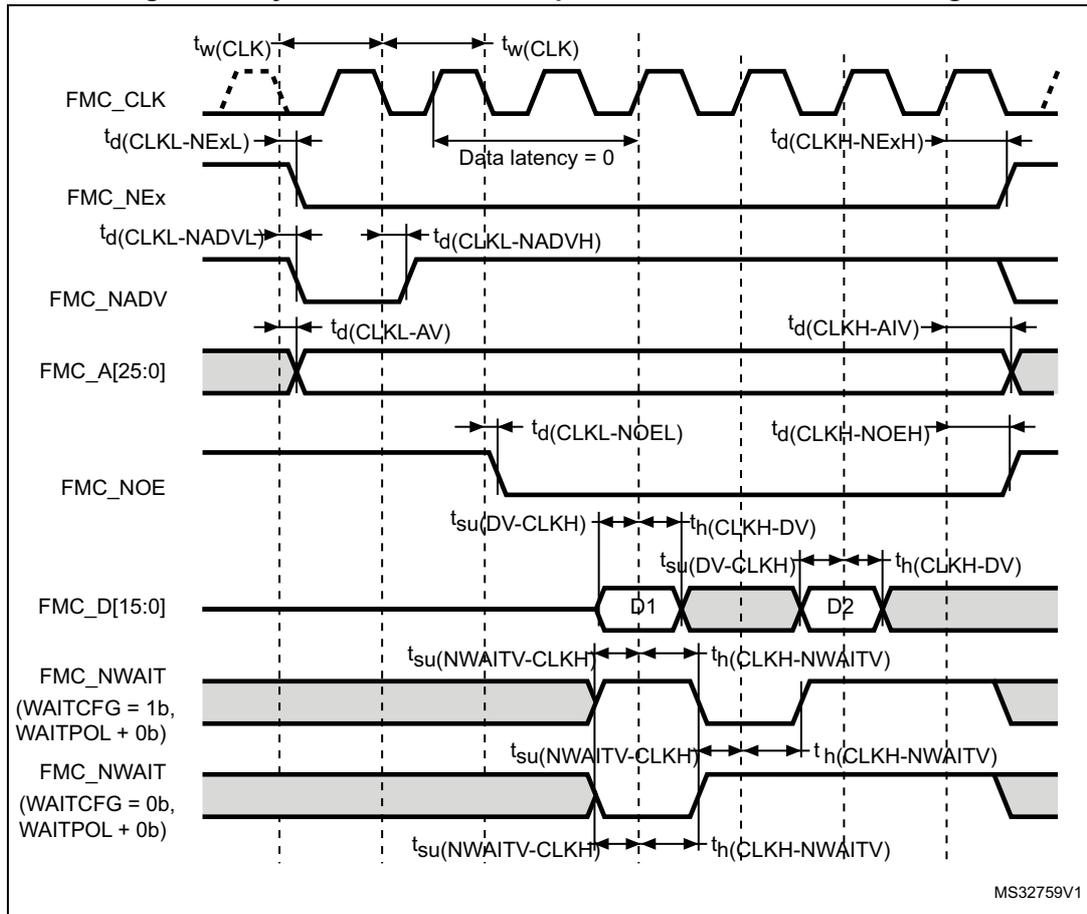


Table 162. Synchronous non-multiplexed NOR/PSRAM read timings<sup>(1)</sup>

| Symbol                             | Parameter                                  | Min                            | Max | Unit |
|------------------------------------|--|--------------------------------|-----|------|
| $t_{w(\text{CLK})}$                | FMC_CLK period                             | $2T_{\text{fmc\_ker\_ck}}-1$   | -   | ns   |
| $t_{(\text{CLKL-NExL})}$           | FMC_CLK low to FMC_NEx low (x=0..2)        | -                              | 1   |      |
| $t_{d(\text{CLKH-NExH})}$          | FMC_CLK high to FMC_NEx high (x= 0..2)     | $2T_{\text{fmc\_ker\_ck}}+0.5$ | -   |      |
| $t_{d(\text{CLKL-NADV})}$          | FMC_CLK low to FMC_NADV low                | -                              | 0.5 |      |
| $t_{d(\text{CLKL-NADVH})}$         | FMC_CLK low to FMC_NADV high               | 0                              | -   |      |
| $t_{d(\text{CLKL-AV})}$            | FMC_CLK low to FMC_Ax valid (x=16...25)    | -                              | 2   |      |
| $t_{d(\text{CLKH-AIV})}$           | FMC_CLK high to FMC_Ax invalid (x=16...25) | $2T_{\text{fmc\_ker\_ck}}$     | -   |      |
| $t_{d(\text{CLKL-NOEL})}$          | FMC_CLK low to FMC_NOE low                 | -                              | 1.5 |      |
| $t_{d(\text{CLKH-NOEH})}$          | FMC_CLK high to FMC_NOE high               | $2T_{\text{fmc\_ker\_ck}}-0.5$ | -   |      |
| $t_{\text{su}(\text{DV-CLKH})}$    | FMC_D[15:0] valid data before FMC_CLK high | 3                              | -   |      |
| $t_{\text{h}(\text{CLKH-DV})}$     | FMC_D[15:0] valid data after FMC_CLK high  | 0                              | -   |      |
| $t_{\text{su}(\text{NWAIT-CLKH})}$ | FMC_NWAIT valid before FMC_CLK high        | 3                              | -   |      |
| $t_{\text{h}(\text{CLKH-NWAIT})}$  | FMC_NWAIT valid after FMC_CLK high         | 1                              | -   |      |

1. Guaranteed by characterization results.

Figure 80. Synchronous non-multiplexed PSRAM write timings

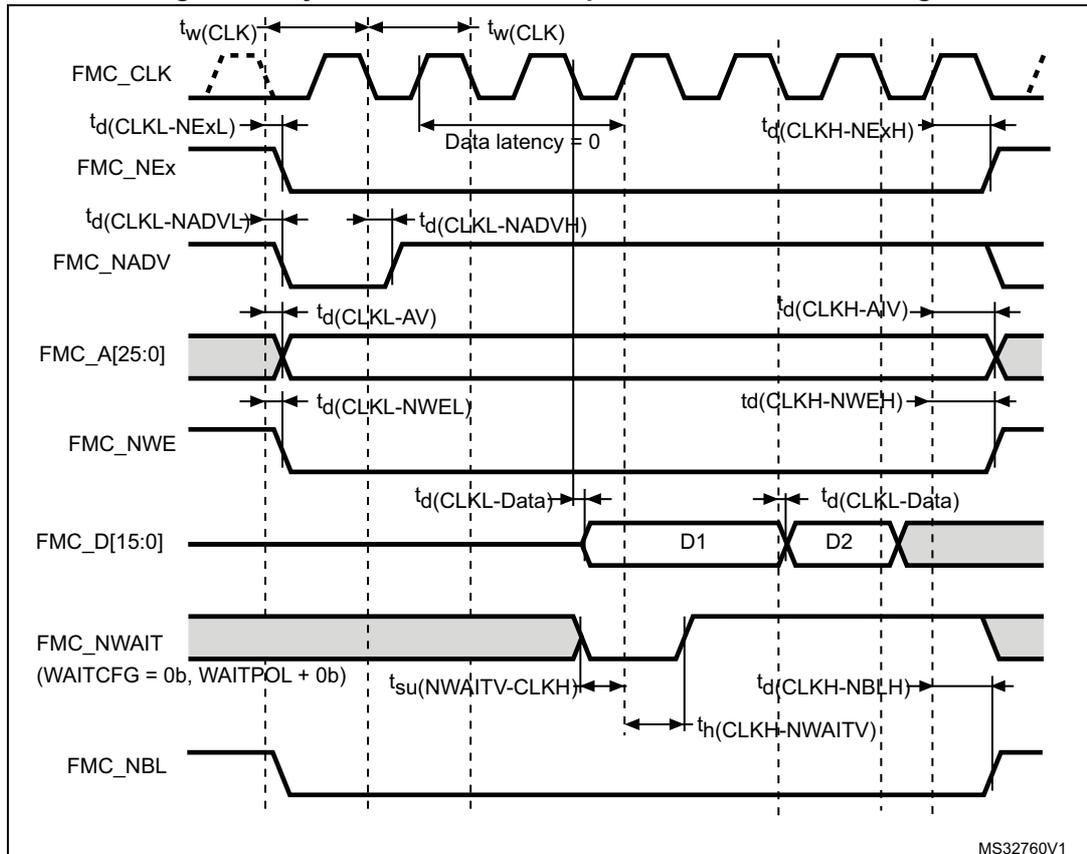


Table 163. Synchronous non-multiplexed PSRAM write timings<sup>(1)</sup>

| Symbol               | Parameter                                  | Min                      | Max | Unit |
|----------------------|--|--------------------------|-----|------|
| $t_{(CLK)}$          | FMC_CLK period                             | $2T_{fmc\_ker\_ck} - 1$  | -   | ns   |
| $t_{d(CLKL-NEXL)}$   | FMC_CLK low to FMC_NEx low (x=0..2)        | -                        | 2   |      |
| $t_{(CLKH-NEXH)}$    | FMC_CLK high to FMC_NEx high (x= 0..2)     | $T_{fmc\_ker\_ck} + 0.5$ | -   |      |
| $t_{d(CLKL-NADV)}$   | FMC_CLK low to FMC_NADV low                | -                        | 0.5 |      |
| $t_{d(CLKL-NADV)}$   | FMC_CLK low to FMC_NADV high               | 0                        | -   |      |
| $t_{d(CLKL-AV)}$     | FMC_CLK low to FMC_Ax valid (x=16...25)    | -                        | 2.  |      |
| $t_{d(CLKH-AIV)}$    | FMC_CLK high to FMC_Ax invalid (x=16...25) | $T_{fmc\_ker\_ck}$       | -   |      |
| $t_{d(CLKL-NWEL)}$   | FMC_CLK low to FMC_NWE low                 | -                        | 1.5 |      |
| $t_{d(CLKH-NWEH)}$   | FMC_CLK high to FMC_NWE high               | $T_{fmc\_ker\_ck} + 1$   | -   |      |
| $t_{d(CLKL-Data)}$   | FMC_D[15:0] valid data after FMC_CLK low   | -                        | 3.5 |      |
| $t_{d(CLKL-NBLL)}$   | FMC_CLK low to FMC_NBL low                 | -                        | 2   |      |
| $t_{d(CLKH-NBLH)}$   | FMC_CLK high to FMC_NBL high               | $T_{fmc\_ker\_ck} + 1$   | -   |      |
| $t_{su(NWAIT-CLKH)}$ | FMC_NWAIT valid before FMC_CLK high        | 2                        | -   |      |
| $t_{h(CLKH-NWAIT)}$  | FMC_NWAIT valid after FMC_CLK high         | 2                        | -   |      |

1. Guaranteed by characterization results.

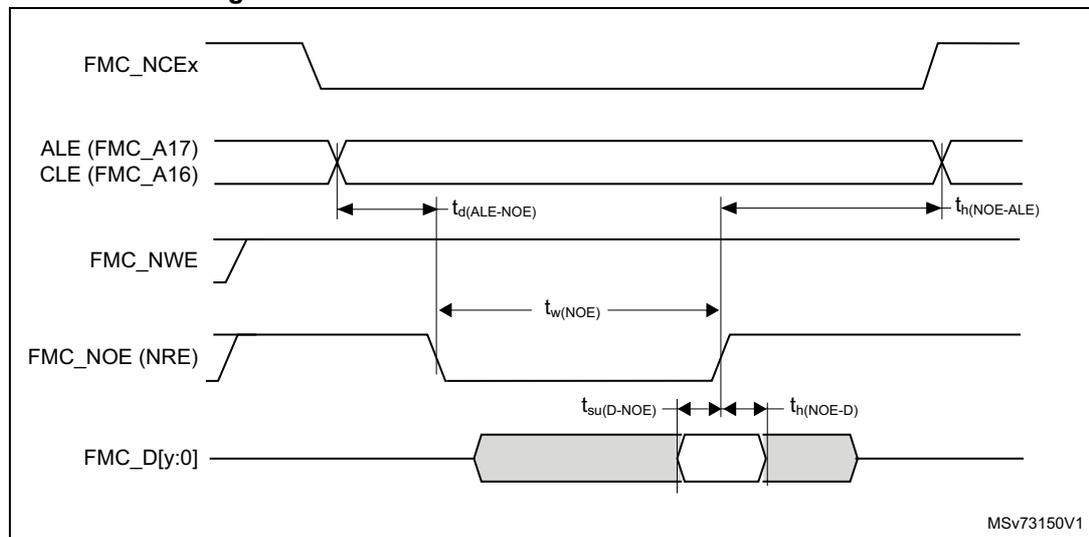
**NAND controller waveforms and timings**

Figure 81 and Figure 82 represent synchronous waveforms, and Table 164 and Table 165 provide the corresponding timings. The results shown in this table are obtained with the following FMC configuration:

- COM.FMC\_SetupTime = 0x01
- COM.FMC\_WaitSetupTime = 0x03
- COM.FMC\_HoldSetupTime = 0x02
- COM.FMC\_HiZSetupTime = 0x01
- ATT.FMC\_SetupTime = 0x01
- ATT.FMC\_WaitSetupTime = 0x03
- ATT.FMC\_HoldSetupTime = 0x02
- ATT.FMC\_HiZSetupTime = 0x01
- Bank = FMC\_Bank\_NAND
- MemoryDataWidth = FMC\_MemoryDataWidth\_16b
- ECC = FMC\_ECC\_Enable
- ECCPageSize = FMC\_ECCPageSize\_512Bytes
- TCLRSetupTime = 0
- TARSetupTime = 0
- Capacitive load  $C_L = 30$  pF

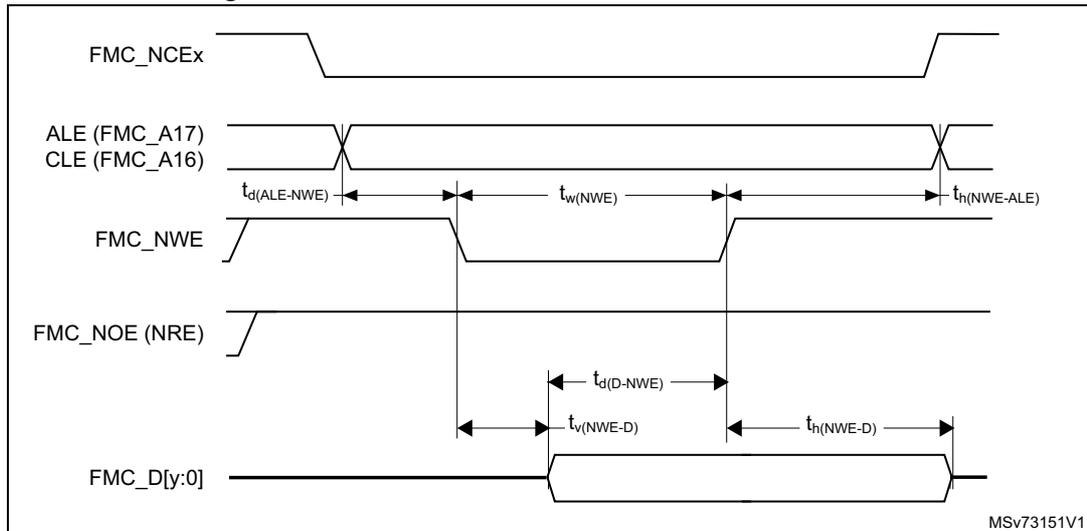
In all timing tables, the  $T_{fmc\_ker\_ck}$  is the `fmc_ker_ck` clock period.

**Figure 81. NAND controller waveforms for read access**



1.  $y = 7$  or  $15$ , depending on the NAND flash memory interface.

Figure 82. NAND controller waveforms for write access



1.  $y = 7$  or  $15$ , depending on the NAND flash memory interface.

Table 164. Switching characteristics for NAND flash read cycles<sup>(1)</sup>

| Symbol           | Parameter                                  | Min                       | Max                       | Unit |
|------------------|--|---------------------------|---------------------------|------|
| $t_{w(NOE)}$     | FMC_NOE low width                          | $4T_{fmc\_ker\_ck} - 0.5$ | $4T_{fmc\_ker\_ck} + 0.5$ | ns   |
| $t_{su(D-NOE)}$  | FMC_D[15-0] valid data before FMC_NOE high | 8                         | -                         |      |
| $t_{h(NOE-D)}$   | FMC_D[15-0] valid data after FMC_NOE high  | 0                         | -                         |      |
| $t_{d(ALE-NOE)}$ | FMC_ALE valid before FMC_NOE low           | -                         | $3T_{fmc\_ker\_ck} + 1$   |      |
| $t_{h(NOE-ALE)}$ | FMC_NWE high to FMC_ALE invalid            | $4T_{fmc\_ker\_ck} - 2$   | -                         |      |

1. Guaranteed by characterization results.

Table 165. Switching characteristics for NAND flash write cycles<sup>(1)</sup>

| Symbol           | Parameter                             | Min                       | Max                       | Unit |
|------------------|---------------------------------------|---------------------------|---------------------------|------|
| $t_{w(NWE)}$     | FMC_NWE low width                     | $4T_{fmc\_ker\_ck} - 0.5$ | $4T_{fmc\_ker\_ck} + 0.5$ | ns   |
| $t_{v(NWE-D)}$   | FMC_NWE low to FMC_D[15-0] valid      | 0                         | -                         |      |
| $t_{h(NWE-D)}$   | FMC_NWE high to FMC_D[15-0] invalid   | $2T_{fmc\_ker\_ck} - 0.5$ | -                         |      |
| $t_{d(D-NWE)}$   | FMC_D[15-0] valid before FMC_NWE high | $5T_{fmc\_ker\_ck} - 1$   | -                         |      |
| $t_{d(ALE-NWE)}$ | FMC_ALE valid before FMC_NWE low      | -                         | $3T_{fmc\_ker\_ck} + 0.5$ |      |
| $t_{h(NWE-ALE)}$ | FMC_NWE high to FMC_ALE invalid       | $2T_{fmc\_ker\_ck} - 1$   | -                         |      |

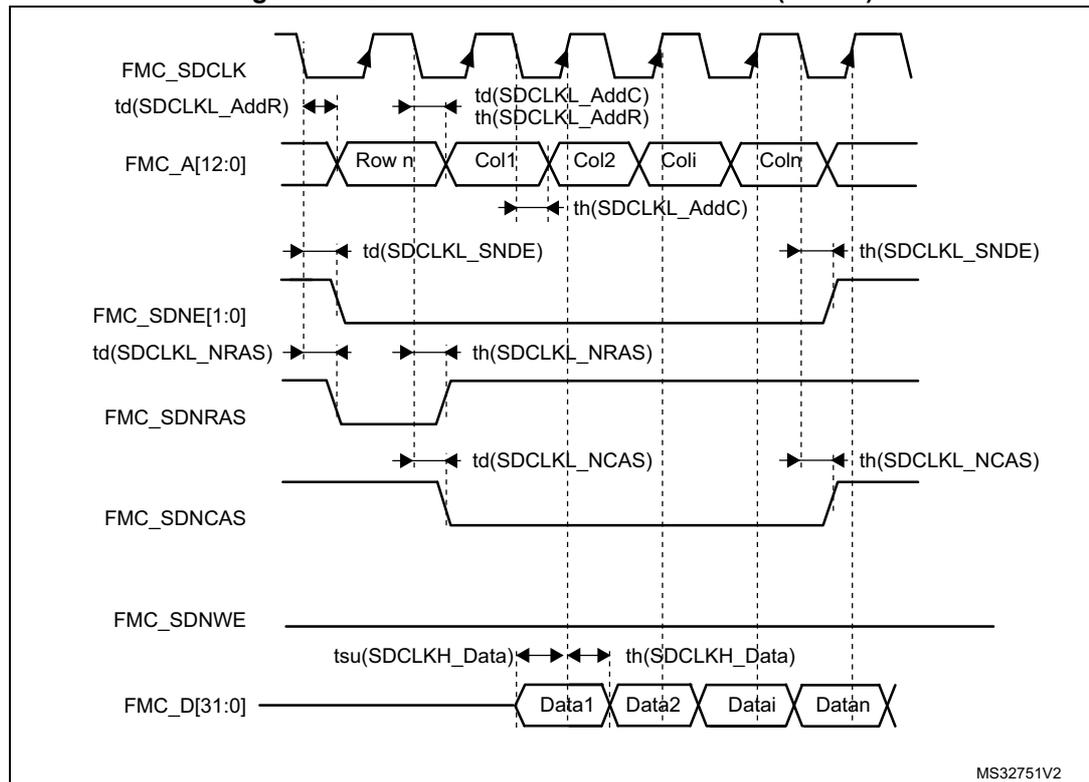
1. Guaranteed by characterization results.

**SDRAM waveforms and timings**

In all timing tables, the TKERCK is the fmc\_ker\_ck clock period, with the following FMC\_SDCLK maximum values:

- For  $2.7\text{ V} < V_{DD} < 3.6\text{ V}$ : FMC\_SDCLK = 110 MHz at 20 pF
- For  $1.8\text{ V} < V_{DD} < 1.9\text{ V}$ : FMC\_SDCLK = 100 MHz at 20 pF
- For  $1.62\text{ V} < V_{DD} < 1.8\text{ V}$ , FMC\_SDCLK = 100 MHz at 15 pF

**Figure 83. SDRAM read access waveforms (CL = 1)**



**Table 166. SDRAM read timings<sup>(1)</sup>**

| Symbol                               | Parameter              | Min                            | Max                              | Unit |
|--------------------------------------|------------------------|--------------------------------|----------------------------------|------|
| $t_w(\text{SDCLK})$                  | FMC_SDCLK period       | $2T_{\text{fmc\_ker\_ck}} - 1$ | $2T_{\text{fmc\_ker\_ck}} + 0.5$ | ns   |
| $t_{\text{su}}(\text{SDCLKH\_Data})$ | Data input setup time  | 3                              | -                                |      |
| $t_h(\text{SDCLKH\_Data})$           | Data input hold time   | 0                              | -                                |      |
| $t_d(\text{SDCLKL\_Add})$            | Address valid time     | -                              | 1.5                              |      |
| $t_d(\text{SDCLKL\_SDNE})$           | Chip select valid time | -                              | 1.5                              |      |
| $t_h(\text{SDCLKL\_SDNE})$           | Chip select hold time  | 0.5                            | -                                |      |
| $t_d(\text{SDCLKL\_SDNRAS})$         | SDNRAS valid time      | -                              | 1                                |      |
| $t_h(\text{SDCLKL\_SDNRAS})$         | SDNRAS hold time       | 0.5                            | -                                |      |
| $t_d(\text{SDCLKL\_SDNCAS})$         | SDNCAS valid time      | -                              | 0.5                              |      |
| $t_h(\text{SDCLKL\_SDNCAS})$         | SDNCAS hold time       | 0                              | -                                |      |

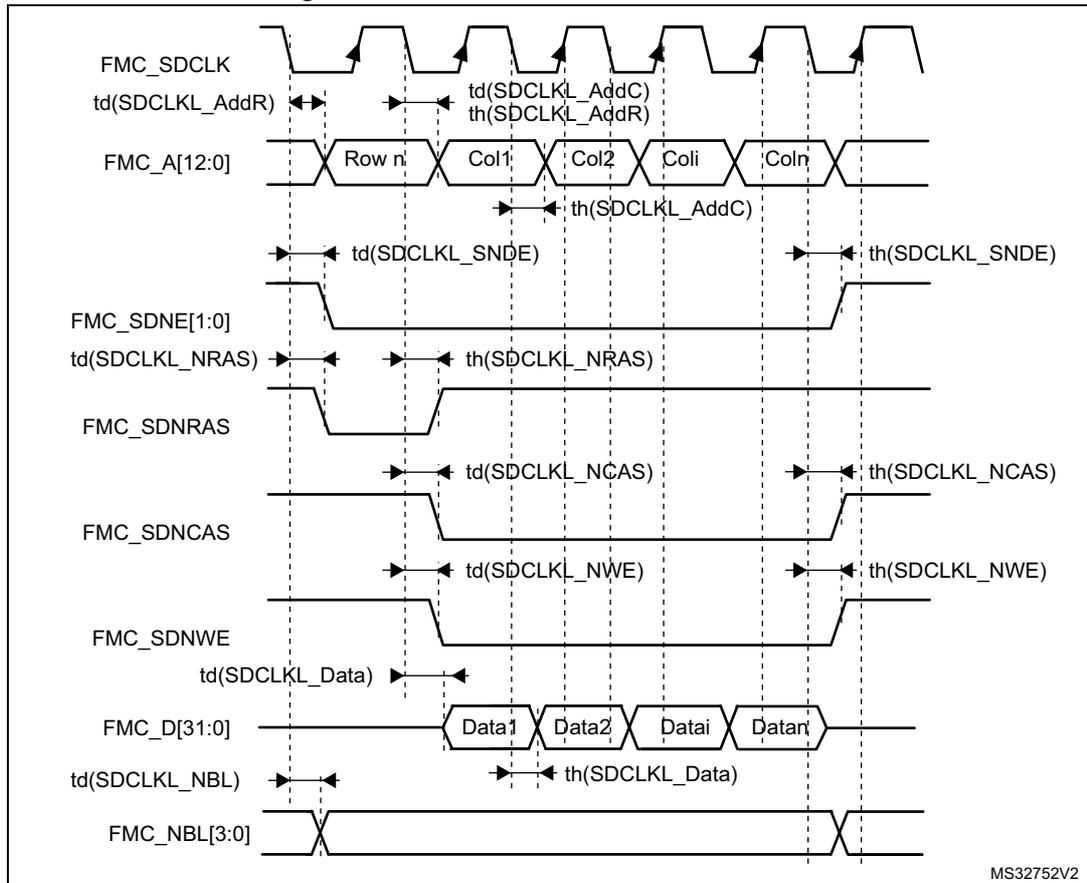
1. Guaranteed by characterization results.

**Table 167. LPDDR SDRAM read timings<sup>(1)</sup>**

| Symbol                               | Parameter              | Min                            | Max                              | Unit |
|--------------------------------------|------------------------|--------------------------------|----------------------------------|------|
| $t_w(\text{SDCLK})$                  | FMC_SDCLK period       | $2T_{\text{fmc\_ker\_ck}} - 1$ | $2T_{\text{fmc\_ker\_ck}} + 0.5$ | ns   |
| $t_{\text{su}}(\text{SDCLKH\_Data})$ | Data input setup time  | 3                              | -                                |      |
| $t_h(\text{SDCLKH\_Data})$           | Data input hold time   | 0.5                            | -                                |      |
| $t_d(\text{SDCLKL\_Add})$            | Address valid time     | -                              | 2.5                              |      |
| $t_d(\text{SDCLKL\_SDNE})$           | Chip select valid time | -                              | 2.5                              |      |
| $t_h(\text{SDCLKL\_SDNE})$           | Chip select hold time  | 0                              | -                                |      |
| $t_d(\text{SDCLKL\_SDNRAS})$         | SDNRAS valid time      | -                              | 0.5                              |      |
| $t_h(\text{SDCLKL\_SDNRAS})$         | SDNRAS hold time       | 0                              | -                                |      |
| $t_d(\text{SDCLKL\_SDNCAS})$         | SDNCAS valid time      | -                              | 1.5                              |      |
| $t_h(\text{SDCLKL\_SDNCAS})$         | SDNCAS hold time       | 0                              | -                                |      |

1. Guaranteed by characterization results.

Figure 84. SDRAM write access waveforms



MS32752V2

Table 168. SDRAM Write timings<sup>(1)</sup>

| Symbol                       | Parameter              | Min                            | Max                              | Unit |
|------------------------------|------------------------|--------------------------------|----------------------------------|------|
| $t_w(\text{SDCLK})$          | FMC_SDCLK period       | $2T_{\text{fmc\_ker\_ck}} - 1$ | $2T_{\text{fmc\_ker\_ck}} + 0.5$ | ns   |
| $t_d(\text{SDCLKL\_Data})$   | Data output valid time | -                              | 1                                |      |
| $t_h(\text{SDCLKL\_Data})$   | Data output hold time  | 0                              | -                                |      |
| $t_d(\text{SDCLKL\_Add})$    | Address valid time     | -                              | 1.5                              |      |
| $t_d(\text{SDCLKL\_SDNWE})$  | SDNWE valid time       | -                              | 1.5                              |      |
| $t_h(\text{SDCLKL\_SDNWE})$  | SDNWE hold time        | 0.5                            | -                                |      |
| $t_d(\text{SDCLKL\_SDNE})$   | Chip select valid time | -                              | 1.5                              |      |
| $t_h(\text{SDCLKL\_SDNE})$   | Chip select hold time  | 0.5                            | -                                |      |
| $t_d(\text{SDCLKL\_SDNRAS})$ | SDNRAS valid time      | -                              | 1                                |      |
| $t_h(\text{SDCLKL\_SDNRAS})$ | SDNRAS hold time       | 0.5                            | -                                |      |
| $t_d(\text{SDCLKL\_SDNCAS})$ | SDNCAS valid time      | -                              | 1                                |      |
| $t_d(\text{SDCLKL\_SDNCAS})$ | SDNCAS hold time       | 0.5                            | -                                |      |

1. Guaranteed by characterization results.

**Table 169. LPSDR SDRAM Write timings<sup>(1)</sup>**

| Symbol                      | Parameter              | Min                            | Max                              | Unit |
|-----------------------------|------------------------|--------------------------------|----------------------------------|------|
| $t_w(\text{SDCLK})$         | FMC_SDCLK period       | $2T_{\text{fmc\_ker\_ck}} - 1$ | $2T_{\text{fmc\_ker\_ck}} + 0.5$ | ns   |
| $t_d(\text{SDCLKL\_Data})$  | Data output valid time | -                              | 2.5                              |      |
| $t_h(\text{SDCLKL\_Data})$  | Data output hold time  | 0                              | -                                |      |
| $t_d(\text{SDCLKL\_Add})$   | Address valid time     | -                              | 2.5                              |      |
| $t_d(\text{SDCLKL-SDNWE})$  | SDNWE valid time       | -                              | 2.5                              |      |
| $t_h(\text{SDCLKL-SDNWE})$  | SDNWE hold time        | 0                              | -                                |      |
| $t_d(\text{SDCLKL-SDNE})$   | Chip select valid time | -                              | 3                                |      |
| $t_h(\text{SDCLKL-SDNE})$   | Chip select hold time  | 0                              | -                                |      |
| $t_d(\text{SDCLKL-SDNRAS})$ | SDNRAS valid time      | -                              | 1.5                              |      |
| $t_h(\text{SDCLKL-SDNRAS})$ | SDNRAS hold time       | 0                              | -                                |      |
| $t_d(\text{SDCLKL-SDNCAS})$ | SDNCAS valid time      | -                              | 1.5                              |      |
| $t_d(\text{SDCLKL-SDNCAS})$ | SDNCAS hold time       | 0                              | -                                |      |

1. Guaranteed by characterization results.

### 7.3.18 Quad-SPI interface characteristics

Unless otherwise specified, the parameters given in [Table 170](#) and [Table 171](#) for QUADSPI are derived from tests performed under the ambient temperature,  $f_{\text{AHB}}$  frequency and  $V_{\text{DD}}$  supply voltage conditions summarized in [Table 111: General operating conditions](#), with the following configuration:

- Output speed is set to  $\text{OSPEEDRy}[1:0] = 11$
- Measurement points are done at CMOS levels:  $0.5V_{\text{DD}}$
- IO Compensation cell activated.
- HSLV activated when  $V_{\text{DD}} \leq 2.7 \text{ V}$
- VOS level set to VOS1

Refer to [Section 7.3.15: I/O port characteristics](#) for more details on the input/output alternate function characteristics.

The following table summarizes the parameters measured in SDR mode.

Table 170. QUADSPI characteristics in SDR mode<sup>(1)</sup>

| Symbol                            | Parameter                                     | Conditions                                | Min                              | Typ | Max                                 | Unit |
|-----------------------------------|---|---|----------------------------------|-----|-------------------------------------|------|
| F <sub>ck1</sub> /T <sub>CK</sub> | QUADSPI clock frequency                       | 2.7<V <sub>DD</sub> <3.6 V<br>CL = 20 pF  | -                                | -   | 133                                 | MHz  |
|                                   |   | 1.62<V <sub>DD</sub> <3.6 V<br>CL = 15 pF | -                                | -   | 100                                 |      |
| t <sub>w(CKH)</sub>               | QUADSPI clock high and low time Even division | PRESCALER[7:0] =<br>n = 0,1,3,5...        | T <sub>CK</sub> /2-0.5           | -   | T <sub>CK</sub> /2                  | ns   |
| t <sub>w(CKL)</sub>               |   |   | T <sub>CK</sub> /2               | -   | T <sub>CK</sub> /2+0.5              |      |
| t <sub>w(CKH)</sub>               | QUADSPI clock high and low time Odd division  | PRESCALER[7:0] =<br>n = 2,4,6,8...        | (n/2)*T <sub>CK</sub> /(n+1)-0.5 | -   | (n/2)*T <sub>CK</sub> / (n+1)       |      |
| t <sub>w(CKL)</sub>               |   |   | (n/2+1)*T <sub>CK</sub> /(n+1)   | -   | (n/2+1)*T <sub>CK</sub> / (n+1)+0.5 |      |
| t <sub>s(IN)</sub>                | Data input setup time                         | 2.7<V <sub>DD</sub> <3.6 V                | 2                                | -   | -                                   |      |
|                                   |   | 1.62<V <sub>DD</sub> <3.6 V               | 2                                | -   | -                                   |      |
| t <sub>h(IN)</sub>                | Data input hold time                          | 2.7<V <sub>DD</sub> <3.6 V                | 1                                | -   | -                                   |      |
|                                   |   | 1.62<V <sub>DD</sub> <3.6 V               | 2.5                              | -   | -                                   |      |
| t <sub>v(OUT)</sub>               | Data output valid time                        | -   | -                                | 1   | 2                                   |      |
| t <sub>h(OUT)</sub>               | Data output hold time                         | -   | 0                                | -   | -                                   |      |

1. Guaranteed by characterization results.

The following table summarizes the parameters measured in DDR mode.

Table 171. QUADSPI characteristics in DDR mode<sup>(1)</sup>

| Symbol                     | Parameter                                     | Conditions                            | Min                            | Typ            | Max                              | Unit |
|----------------------------|---|---------------------------------------|--------------------------------|----------------|----------------------------------|------|
| $F_{ck1}/T_{CK}$           | QUADSPI clock frequency                       | $2.7 < V_{DD} < 3.6$ V<br>CL = 20 pF  | -                              | -              | 100                              | MHz  |
|                            |   | $1.62 < V_{DD} < 3.6$ V<br>CL = 15 pF | -                              | -              | 100                              |      |
| $t_{w(CKH)}$               | QUADSPI clock high and low time Even division | PRESCALER[7:0] =<br>n = 0,1,3,5...    | $T_{CK}/2 - 0.5$               | -              | $T_{CK}/2$                       | ns   |
| $t_{w(CKL)}$               |   |                                       | $T_{CK}/2$                     | -              | $T_{CK}/2 + 0.5$                 |      |
| $t_{w(CKH)}$               | QUADSPI clock high and low time Odd division  | PRESCALER[7:0] =<br>n = 2,4,6,8...    | $(n/2) * T_{CK} / (n+1) - 0.5$ | -              | $(n/2) * T_{CK} / (n+1)$         |      |
| $t_{w(CKL)}$               |   |                                       | $(n/2+1) * T_{CK} / (n+1)$     | -              | $(n/2+1) * T_{CK} / (n+1) + 0.5$ |      |
| $t_{sr(IN)}, t_{sf(IN)}$   | Data input setup time                         | $2.7 < V_{DD} < 3.6$ V                | 2.5                            | -              | -                                |      |
|                            |   | $1.62 < V_{DD} < 3.6$ V               | 1.5                            | -              | -                                |      |
| $t_{hr(IN)}, t_{hf(IN)}$   | Data input hold time                          | $2.7 < V_{DD} < 3.6$ V                | 1                              | -              | -                                |      |
|                            |   | $1.62 < V_{DD} < 3.6$ V               | 2.5                            | -              | -                                |      |
| $t_{vr(OUT)}, t_{vf(OUT)}$ | Data output valid time                        | DHHC=0                                | -                              | 5              | 6                                |      |
|                            |   | DHHC=1<br>PRESCALER[7:0] =<br>1,2...  | -                              | $T_{CK}/4 + 1$ | $T_{CK}/4 + 2$                   |      |
| $t_{hr(OUT)}, t_{hf(OUT)}$ | Data output hold time                         | DHHC=0                                | 3                              | -              | -                                |      |
|                            |   | DHHC=1<br>PRESCALER[7:0]=1,2...       | $T_{CK}/4$                     | -              | -                                |      |

1. Guaranteed by characterization results.

Figure 85. QUADSPI timing diagram - SDR mode

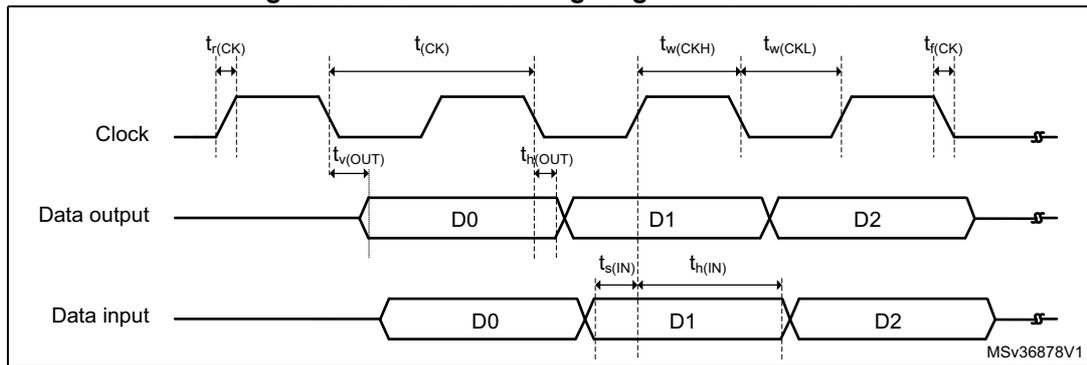
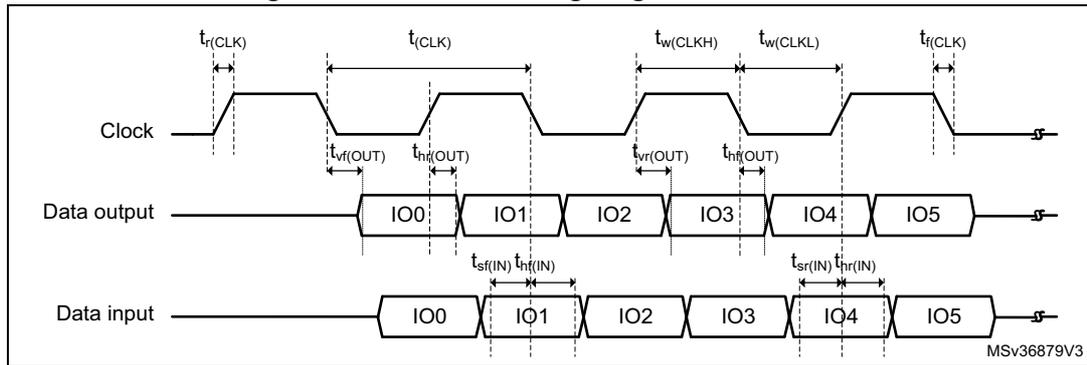


Figure 86. Quad-SPI timing diagram - DDR mode



### 7.3.19 Delay block (DLYB) characteristics

Unless otherwise specified, the parameters given in [Table 172](#) for Delay Block are derived from tests performed under the ambient temperature,  $f_{\text{rcc\_c\_ck}}$  frequency and  $V_{\text{DD}}$  supply voltage summarized in [Table 111: General operating conditions](#), with the following configuration:

Table 172. Delay Block characteristics

| Symbol            | Parameter     | Conditions | Min  | Typ  | Max  | Unit |
|-------------------|---------------|------------|------|------|------|------|
| $t_{\text{init}}$ | Initial delay | -          | 1400 | 2200 | 2400 | ps   |
| $t_{\Delta}$      | Unit Delay    | -          | 35   | 40   | 45   | -    |

### 7.3.20 16-bit ADC characteristics

Unless otherwise specified, the parameters given in [Table 173](#) are derived from tests performed under the ambient temperature,  $f_{\text{HCLK}}$  frequency and  $V_{\text{DDA}}$  supply voltage conditions summarized in [Table 111: General operating conditions](#).

Table 173. ADC characteristics<sup>(1)(2)(3)</sup>

| Symbol            | Parameter                        | Conditions  | Min              | Typ  | Max              | Unit |     |
|-------------------|----------------------------------|---|------------------|------|------------------|------|-----|
| $V_{\text{DDA}}$  | Analog supply voltage for ADC ON | -   | 1.62             | -    | 3.6              | V    |     |
| $V_{\text{REF+}}$ | Positive reference voltage       | -   | 1.62             | -    | $V_{\text{DDA}}$ | V    |     |
| $V_{\text{REF-}}$ | Negative reference voltage       | -   | $V_{\text{SSA}}$ |      |                  | V    |     |
| $f_{\text{ADC}}$  | ADC clock frequency              | $1.62 \text{ V} \leq V_{\text{DDA}} \leq 3.6 \text{ V}$ | BOOST = 11       | 0.12 | -                | 50   | MHz |
|                   |                                  |   | BOOST = 10       | 0.12 | -                | 25   |     |
|                   |                                  |   | BOOST = 01       | 0.12 | -                | 12.5 |     |
|                   |                                  |   | BOOST = 00       | -    | -                | 6.25 |     |

Table 173. ADC characteristics<sup>(1)(2)(3)</sup> (continued)

| Symbol              | Parameter   | Conditions                              |                |                    |                    | Min         | Typ                | Max              | Unit |
|---------------------|---|---|----------------|--------------------|--------------------|-------------|--------------------|------------------|------|
| $f_s^{(4)}$         | Sampling rate for Direct channels <sup>(5)</sup>                                  | Resolution = 16 bits, $V_{DDA} > 2.5$ V | $T_J = 90$ °C  | $f_{ADC} = 36$ MHz | SMP = 1.5          | -           | -                  | 3.60             | MSps |
|                     |   | Resolution = 16 bits                    |                | $f_{ADC} = 37$ MHz | SMP = 2.5          | -           | -                  | 3.35             |      |
|                     |   | Resolution = 14 bits                    | $T_J = 125$ °C | $f_{ADC} = 50$ MHz | SMP = 2.5          | -           | -                  | 5.00             |      |
|                     |   | Resolution = 12 bits                    |                | $f_{ADC} = 50$ MHz | SMP = 2.5          | -           | -                  | 5.50             |      |
|                     |   | Resolution = 10 bits                    |                | $f_{ADC} = 50$ MHz | SMP = 1.5          | -           | -                  | 7.10             |      |
|                     |   | Resolution = 8 bits                     |                | $f_{ADC} = 50$ MHz | SMP = 1.5          | -           | -                  | 8.30             |      |
|                     | Sampling rate for Fast channels   | Resolution = 16 bits, $V_{DDA} > 2.5$ V | $T_J = 90$ °C  | $f_{ADC} = 32$ MHz | SMP = 2.5          | -           | -                  | 2.90             |      |
|                     |   | Resolution = 16 bits                    |                | $f_{ADC} = 31$ MHz | SMP = 2.5          | -           | -                  | 2.80             |      |
|                     |   | Resolution = 14 bits                    | $T_J = 125$ °C | $f_{ADC} = 33$ MHz | SMP = 2.5          | -           | -                  | 3.30             |      |
|                     |   | Resolution = 12 bits                    |                | $f_{ADC} = 39$ MHz | SMP = 2.5          | -           | -                  | 4.30             |      |
|                     |   | Resolution = 10 bits                    |                | $f_{ADC} = 48$ MHz | SMP = 2.5          | -           | -                  | 6.00             |      |
|                     |   | Resolution = 8 bits                     |                | $f_{ADC} = 50$ MHz | SMP = 2.5          | -           | -                  | 7.10             |      |
|                     | Sampling rate for Slow channels   | Resolution = 16 bits                    | $T_J = 90$ °C  | $f_{ADC} = 10$ MHz | SMP = 1.5          | -           | -                  | 1.00             |      |
|                     |   | resolution = 14 bits                    |                |                    |                    | -           | -                  |                  |      |
|                     |   | resolution = 12 bits                    | $T_J = 125$ °C |                    |                    | -           | -                  |                  |      |
|                     |   | resolution = 10 bits                    |                |                    |                    | -           | -                  |                  |      |
|                     |   | resolution = 8 bits                     |                |                    |                    | -           | -                  |                  |      |
|                     | $V_{AIN}^{(6)}$   | Conversion voltage range                | -              | -                  | -                  | 0           | -                  | $V_{REF+}$       |      |
| $V_{CMIV}$          | Common mode input voltage   | -                                       | -              | -                  | $V_{REF}/2 - 10\%$ | $V_{REF}/2$ | $V_{REF}/2 + 10\%$ | V                |      |
| $R_{AIN}^{(7)}$     | External input impedance  | Resolution = 16 bits, $T_J = 125$ °C    | -              | -                  | -                  | -           | 170                | $\Omega$         |      |
|                     |   | Resolution = 14 bits, $T_J = 125$ °C    | -              | -                  | -                  | -           | 435                |                  |      |
|                     |   | Resolution = 12 bits, $T_J = 125$ °C    | -              | -                  | -                  | -           | 1150               |                  |      |
|                     |   | Resolution = 10 bits, $T_J = 125$ °C    | -              | -                  | -                  | -           | 5650               |                  |      |
|                     |   | Resolution = 8 bits, $T_J = 125$ °C     | -              | -                  | -                  | -           | 26500              |                  |      |
| $C_{ADC}$           | Internal sample and hold capacitor  | -                                       | -              | -                  | -                  | 4           | -                  | pF               |      |
| $t_{ADCVREG\_STUP}$ | ADC LDO startup time  | -                                       | -              | -                  | -                  | 5           | 10                 | us               |      |
| $t_{STAB}$          | ADC Power-up time   | LDO already started                     | -              | -                  | 1                  | -           | -                  | conversion cycle |      |
| $t_{CAL}$           | Offset and linearity calibration time   | -                                       | -              | -                  | 165010             | -           | -                  | $1/f_{ADC}$      |      |
| $t_{OFF\_CAL}$      | Offset calibration time   | -                                       | -              | -                  | 1280               | -           | -                  | $1/f_{ADC}$      |      |
| $t_{LATR}$          | Trigger conversion latency regular and injected channels without conversion abort | CKMODE = 00                             | -              | -                  | 1.5                | 2           | 2.5                | $1/f_{ADC}$      |      |
|                     |   | CKMODE = 01                             | -              | -                  | -                  | -           | 2.5                |                  |      |
|                     |   | CKMODE = 10                             | -              | -                  | -                  | -           | 2.5                |                  |      |
|                     |   | CKMODE = 11                             | -              | -                  | -                  | -           | 2.25               |                  |      |

Table 173. ADC characteristics<sup>(1)(2)(3)</sup> (continued)

| Symbol               | Parameter  | Conditions           |   |   | Min  | Typ | Max   | Unit               |
|----------------------|--|----------------------|---|---|--|-----|-------|--------------------|
| $t_{\text{LATRINJ}}$ | Trigger conversion latency regular injected channels aborting a regular conversion | CKMODE = 00          | - | - | 2.5  | 3   | 3.5   | $1/f_{\text{ADC}}$ |
|                      |  | CKMODE = 01          | - | - | -  | -   | 3.5   |                    |
|                      |  | CKMODE = 10          | - | - | -  | -   | 3.5   |                    |
|                      |  | CKMODE = 11          | - | - | -  | -   | 3.25  |                    |
| $t_{\text{S}}$       | Sampling time  | -                    | - | - | 1.5  | -   | 810.5 | $1/f_{\text{ADC}}$ |
| $t_{\text{CONV}}$    | Total conversion time (including sampling time)                                    | Resolution = N bits  | - | - | $t_{\text{S}} + 0.5 + N/2$   | -   | -     | $1/f_{\text{ADC}}$ |
| $t_{\text{TRIG}}$    | External trigger period  | Resolution = 16 bits | - | - | $t_{\text{CONV}} + [t_{\text{LATR}} \text{ or } t_{\text{LATRINJ}}]$ | -   | -     | $1/f_{\text{ADC}}$ |

Table 173. ADC characteristics<sup>(1)(2)(3)</sup> (continued)

| Symbol                       | Parameter   | Conditions                                     |   |   | Min | Typ   | Max | Unit |
|------------------------------|---|--|---|---|-----|-------|-----|------|
| I <sub>DDA_D</sub><br>(ADC)  | ADC consumption on V <sub>DDA</sub> , BOOST=11, Differential mode                             | Resolution = 16 bits, f <sub>ADC</sub> =25 MHz | - | - | -   | 1440  | -   | µA   |
|                              |   | Resolution = 14 bits, f <sub>ADC</sub> =30 MHz | - | - | -   | 1350  | -   |      |
|                              |   | Resolution = 12 bits, f <sub>ADC</sub> =40 MHz | - | - | -   | 990   | -   |      |
|                              | ADC consumption on V <sub>DDA</sub> , BOOST=10, Differential mode, f <sub>ADC</sub> =25 MHz   | Resolution = 16 bits                           | - | - | -   | 1080  | -   |      |
|                              |   | Resolution = 14 bits                           | - | - | -   | 810   | -   |      |
|                              |   | Resolution = 12 bits                           | - | - | -   | 585   | -   |      |
|                              | ADC consumption on V <sub>DDA</sub> , BOOST=01, Differential mode, f <sub>ADC</sub> =12.5 MHz | Resolution = 16 bits                           | - | - | -   | 630   | -   |      |
|                              |   | Resolution = 14 bits                           | - | - | -   | 432   | -   |      |
|                              |   | Resolution = 12 bits                           | - | - | -   | 315   | -   |      |
|                              | ADC consumption on V <sub>DDA</sub> , BOOST=00, Differential mode, f <sub>ADC</sub> =6.25 MHz | Resolution = 16 bits                           | - | - | -   | 360   | -   |      |
|                              |   | Resolution = 14 bits                           | - | - | -   | 270   | -   |      |
|                              |   | Resolution = 12 bits                           | - | - | -   | 225   | -   |      |
| I <sub>DDA_SE</sub><br>(ADC) | ADC consumption on V <sub>DDA</sub> , BOOST=11, Single-ended mode                             | Resolution = 16 bits, f <sub>ADC</sub> =25 MHz | - | - | -   | 720   | -   |      |
|                              |   | Resolution = 14 bits, f <sub>ADC</sub> =30 MHz | - | - | -   | 675   | -   |      |
|                              |   | Resolution = 12 bits, f <sub>ADC</sub> =40 MHz | - | - | -   | 495   | -   |      |
|                              | ADC consumption on V <sub>DDA</sub> , BOOST=10, Single-ended mode, f <sub>ADC</sub> =25 MHz   | Resolution = 16 bits                           | - | - | -   | 540   | -   |      |
|                              |   | Resolution = 14 bits                           | - | - | -   | 405   | -   |      |
|                              |   | Resolution = 12 bits                           | - | - | -   | 292.5 | -   |      |
|                              | ADC consumption on V <sub>DDA</sub> , BOOST=01, Single-ended mode, f <sub>ADC</sub> =12.5 MHz | Resolution = 16 bits                           | - | - | -   | 315   | -   |      |
|                              |   | Resolution = 14 bits                           | - | - | -   | 216   | -   |      |
|                              |   | Resolution = 12 bits                           | - | - | -   | 157.5 | -   |      |
|                              | ADC consumption on V <sub>DDA</sub> , BOOST=00, Single-ended mode, f <sub>ADC</sub> =6.25 MHz | Resolution = 16 bits                           | - | - | -   | 180   | -   |      |
|                              |   | Resolution = 14 bits                           | - | - | -   | 135   | -   |      |
|                              |   | Resolution = 12 bits                           | - | - | -   | 112.5 | -   |      |
| I <sub>DD</sub><br>(ADC)     | ADC consumption on V <sub>DD</sub>  | f <sub>ADC</sub> =50 MHz                       | - | - | -   | 400   | -   |      |
|                              |   | f <sub>ADC</sub> =25 MHz                       | - | - | -   | 220   | -   |      |
|                              |   | f <sub>ADC</sub> =12.5 MHz                     | - | - | -   | 180   | -   |      |
|                              |   | f <sub>ADC</sub> =6.25 MHz                     | - | - | -   | 120   | -   |      |
|                              |   | f <sub>ADC</sub> =3.125 MHz                    | - | - | -   | 80    | -   |      |

1. Guaranteed by design.
2. The voltage booster on ADC switches must be used for V<sub>DDA</sub> < 2.4 V (embedded I/O switches).
3. All ADC power consumption values reported for the 14-bit and 12-bit resolutions correspond to the power-optimized mode. The values provided for the 16-bit resolution also apply to the 14-bit and 12-bit resolutions in standard mode.
4. These values are valid for UFBGA169 and one ADC. Refer to *Getting started with the STM32H7 Series MCU 16-bit ADC (AN5354)* for values of other packages and multiple ADCs operation.
5. Direct channels are connected to analog I/Os (PA0\_C, PA1\_C, PC2\_C and PC3\_C) to optimize ADC performance.
6. Depending on the package, V<sub>REF+</sub> can be internally connected to V<sub>DDA</sub> and V<sub>REF-</sub> to V<sub>SSA</sub>.
7. The tolerance is 10 LSBs for 16-bit resolution, 4 LSBs for 14-bit resolution, and 2 LSBs for 12-bit, 10-bit and 8-bit resolutions.

Table 174. Minimum sampling time vs  $R_{AIN}^{(1)(2)}$ 

| Resolution | $R_{AIN}$ ( $\Omega$ ) | Minimum sampling time (s)      |                              |                              |
|------------|------------------------|--------------------------------|------------------------------|------------------------------|
|            |                        | Direct channels <sup>(3)</sup> | Fast channels <sup>(4)</sup> | Slow channels <sup>(5)</sup> |
| 16 bits    | 47                     | 7.37E-08                       | 1.14E-07                     | 1.72E-07                     |
| 14 bits    | 47                     | 6.29E-08                       | 9.74E-08                     | 1.55E-07                     |
|            | 68                     | 6.84E-08                       | 1.02E-07                     | 1.58E-07                     |
|            | 100                    | 7.80E-08                       | 1.12E-07                     | 1.62E-07                     |
|            | 150                    | 9.86E-08                       | 1.32E-07                     | 1.80E-07                     |
|            | 220                    | 1.32E-07                       | 1.61E-07                     | 2.01E-07                     |
| 12 bits    | 47                     | 5.32E-08                       | 8.00E-08                     | 1.29E-07                     |
|            | 68                     | 5.74E-08                       | 8.50E-08                     | 1.32E-07                     |
|            | 100                    | 6.58E-08                       | 9.31E-08                     | 1.40E-07                     |
|            | 150                    | 8.37E-08                       | 1.10E-07                     | 1.51E-07                     |
|            | 220                    | 1.11E-07                       | 1.34E-07                     | 1.73E-07                     |
|            | 330                    | 1.56E-07                       | 1.78E-07                     | 2.14E-07                     |
|            | 470                    | 2.16E-07                       | 2.39E-07                     | 2.68E-07                     |
|            | 680                    | 3.01E-07                       | 3.29E-07                     | 3.54E-07                     |
| 10 bits    | 47                     | 4.34E-08                       | 6.51E-08                     | 1.08E-07                     |
|            | 68                     | 4.68E-08                       | 6.89E-08                     | 1.11E-07                     |
|            | 100                    | 5.35E-08                       | 7.55E-08                     | 1.16E-07                     |
|            | 150                    | 6.68E-08                       | 8.77E-08                     | 1.26E-07                     |
|            | 220                    | 8.80E-08                       | 1.08E-07                     | 1.40E-07                     |
|            | 330                    | 1.24E-07                       | 1.43E-07                     | 1.71E-07                     |
|            | 470                    | 1.69E-07                       | 1.89E-07                     | 2.13E-07                     |
|            | 680                    | 2.38E-07                       | 2.60E-07                     | 2.80E-07                     |
|            | 1000                   | 3.45E-07                       | 3.66E-07                     | 3.84E-07                     |
|            | 1500                   | 5.15E-07                       | 5.35E-07                     | 5.48E-07                     |
|            | 2200                   | 7.42E-07                       | 7.75E-07                     | 7.78E-07                     |
|            | 3300                   | 1.10E-06                       | 1.14E-06                     | 1.14E-06                     |

Table 174. Minimum sampling time vs  $R_{AIN}^{(1)(2)}$  (continued)

| Resolution | $R_{AIN}$ ( $\Omega$ ) | Minimum sampling time (s)      |                              |                              |
|------------|------------------------|--------------------------------|------------------------------|------------------------------|
|            |                        | Direct channels <sup>(3)</sup> | Fast channels <sup>(4)</sup> | Slow channels <sup>(5)</sup> |
| 8 bits     | 47                     | 3.32E-08                       | 5.10E-08                     | 8.61E-08                     |
|            | 68                     | 3.59E-08                       | 5.35E-08                     | 8.83E-08                     |
|            | 100                    | 4.10E-08                       | 5.83E-08                     | 9.22E-08                     |
|            | 150                    | 5.06E-08                       | 6.76E-08                     | 9.95E-08                     |
|            | 220                    | 6.61E-08                       | 8.22E-08                     | 1.11E-07                     |
|            | 330                    | 9.17E-08                       | 1.08E-07                     | 1.32E-07                     |
|            | 470                    | 1.24E-07                       | 1.40E-07                     | 1.63E-07                     |
|            | 680                    | 1.74E-07                       | 1.91E-07                     | 2.12E-07                     |
|            | 1000                   | 2.53E-07                       | 2.70E-07                     | 2.85E-07                     |
|            | 1500                   | 3.73E-07                       | 3.93E-07                     | 4.05E-07                     |
|            | 2200                   | 5.39E-07                       | 5.67E-07                     | 5.75E-07                     |
|            | 3300                   | 8.02E-07                       | 8.36E-07                     | 8.38E-07                     |
|            | 4700                   | 1.13E-06                       | 1.18E-06                     | 1.18E-06                     |
|            | 6800                   | 1.62E-06                       | 1.69E-06                     | 1.68E-06                     |
|            | 10000                  | 2.36E-06                       | 2.47E-06                     | 2.45E-06                     |
| 15000      | 3.50E-06               | 3.69E-06                       | 3.65E-06                     |                              |

1. Guaranteed by design.
2. Data valid at up to 125 °C, with a 47 pF PCB capacitor, and  $V_{DDA}=1.6$  V.
3. Direct channels are connected to analog I/Os (PA0\_C, PA1\_C, PC2\_C and PC3\_C) to optimize ADC performance.
4. Fast channels correspond to PF3, PF5, PF7, PF9, PA6, PC4, PB1, PF11 and PF13.
5. Slow channels correspond to all ADC inputs except for the Direct and Fast channels.

Table 175. ADC accuracy<sup>(1)(2)</sup>

| Symbol | Parameter                            | Conditions <sup>(3)</sup> |              | Min | Typ     | Max | Unit |
|--------|--------------------------------------|---------------------------|--------------|-----|---------|-----|------|
| ET     | Total undadjusted error              | Direct channel            | Single ended | -   | +10/-20 | -   | LSB  |
|        |                                      |                           | Differential | -   | ±15     | -   |      |
|        |                                      | Fast channel              | Single ended | -   | +10/-20 | -   |      |
|        |                                      |                           | Differential | -   | ±15     | -   |      |
|        |                                      | Slow channel              | Single ended | -   | ±10     | -   |      |
|        |                                      |                           | Differential | -   | ±10     | -   |      |
| EO     | Offset error                         | -                         |              | -   | ±10     | -   | LSB  |
| EG     | Gain error                           | -                         |              | -   | ±15     | -   |      |
| ED     | Differential linearity error         | Single ended              |              | -   | +3/-1   | -   |      |
|        |                                      | Differential              |              | -   | +4.5/-1 | -   |      |
| EL     | Integral linearity error             | Direct channel            | Single ended | -   | ±11     | -   | LSB  |
|        |                                      |                           | Differential | -   | ±7      | -   |      |
|        |                                      | Fast channel              | Single ended | -   | ±13     | -   |      |
|        |                                      |                           | Differential | -   | ±7      | -   |      |
|        |                                      | Slow channel              | Single ended | -   | ±10     | -   |      |
|        |                                      |                           | Differential | -   | ±6      | -   |      |
| ENOB   | Effective number of bits             | Single ended              |              | -   | 12.2    | -   | Bits |
|        |                                      | Differential              |              | -   | 13.2    | -   |      |
| SINAD  | Signal-to-noise and distortion ratio | Single ended              |              | -   | 75.2    | -   | dB   |
|        |                                      | Differential              |              | -   | 81.2    | -   |      |
| SNR    | Signal-to-noise ratio                | Single ended              |              | -   | 77.0    | -   |      |
|        |                                      | Differential              |              | -   | 81.0    | -   |      |
| THD    | Total harmonic distortion            | Single ended              |              | -   | 87      | -   |      |
|        |                                      | Differential              |              | -   | 90      | -   |      |

1. Data guaranteed by characterization for BGA packages. The values for LQFP packages might differ.
2. ADC DC accuracy values are measured after internal calibration.
3. ADC clock frequency = 25 MHz, ADC resolution = 16 bits,  $V_{DDA}=V_{REF+}=3.3\text{ V}$  and BOOST=11.

Note: ADC accuracy vs. negative injection current: injecting a negative current on any analog input pins should be avoided as this significantly reduces the accuracy of the conversion being performed on another analog input. It is recommended to add a Schottky diode (pin to ground) to analog pins which may potentially inject negative currents.

Any positive injection current within the limits specified for  $I_{INJ(PIN)}$  and  $\sum I_{INJ(PIN)}$  in [Section 7.3.14](#) does not affect the ADC accuracy.

Figure 87. ADC accuracy characteristics

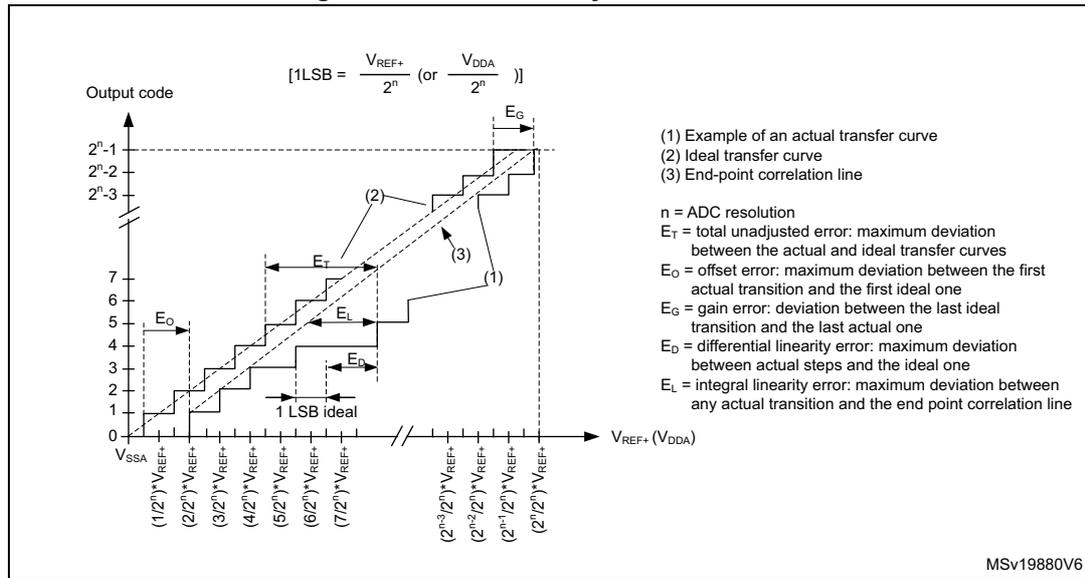
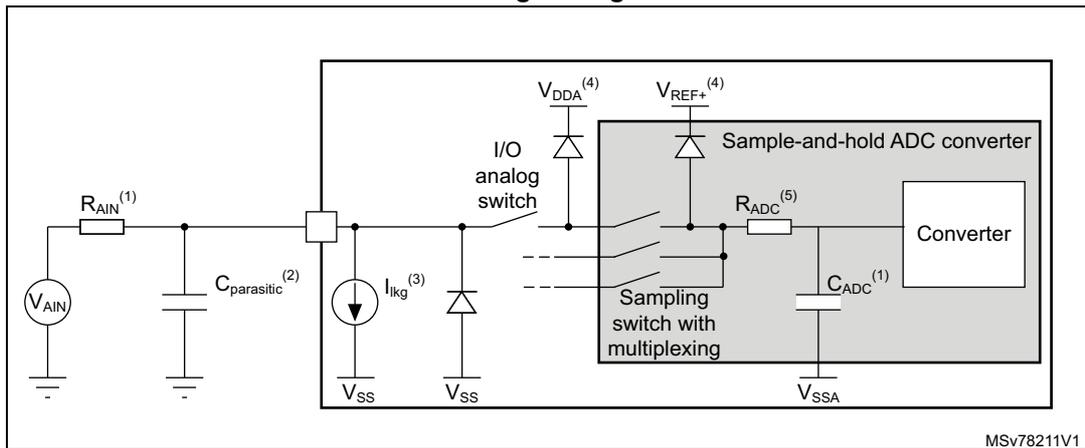


Figure 88. Typical connection diagram when using the ADC with FT/TT pins featuring analog switch function

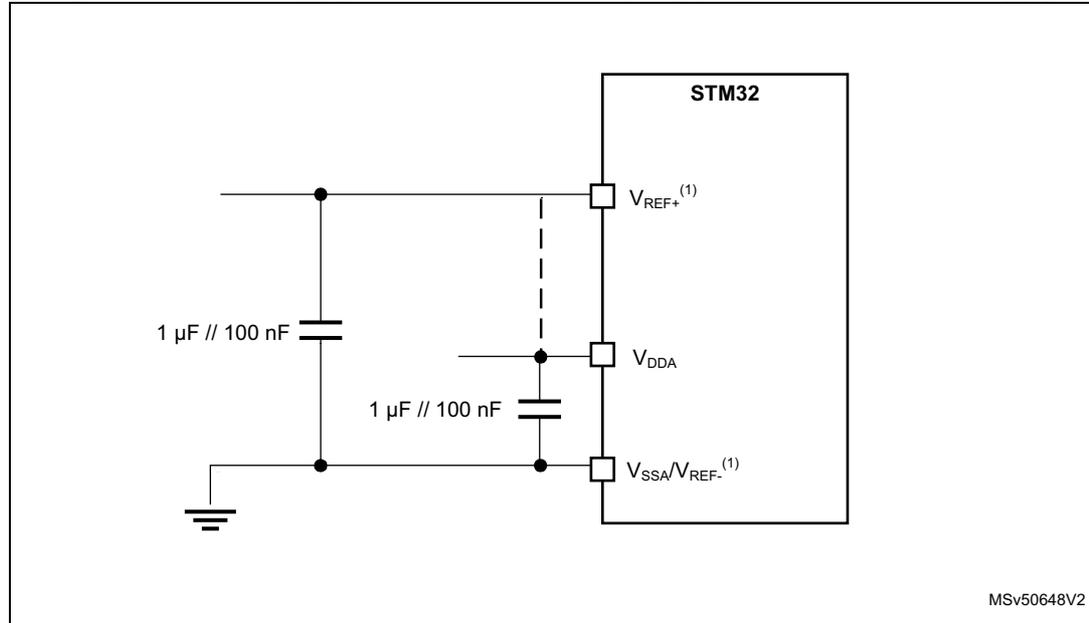


1. Refer to [Section 7.3.20: 16-bit ADC characteristics](#) for the values of  $R_{\text{AIN}}$  and  $C_{\text{ADC}}$ .
2.  $C_{\text{parasitic}}$  represents the capacitance of the PCB (dependent on soldering and PCB layout quality) plus the pad capacitance (refer to [Table 146: I/O static characteristics](#) for the value of the pad capacitance). A high  $C_{\text{parasitic}}$  value downgrades conversion accuracy. To remedy this,  $f_{\text{ADC}}$  should be reduced.
3. Refer to [Table 146: I/O static characteristics](#) for the value of  $I_{\text{kg}}$ .
4. Refer to [Figure 65: Power supply scheme](#).
5. The  $R_{\text{ADC}}$  is used to compute the minimum sampling time, refer to [Table 174: Minimum sampling time vs  \$R\_{\text{AIN}}\$](#) .

**General PCB design guidelines**

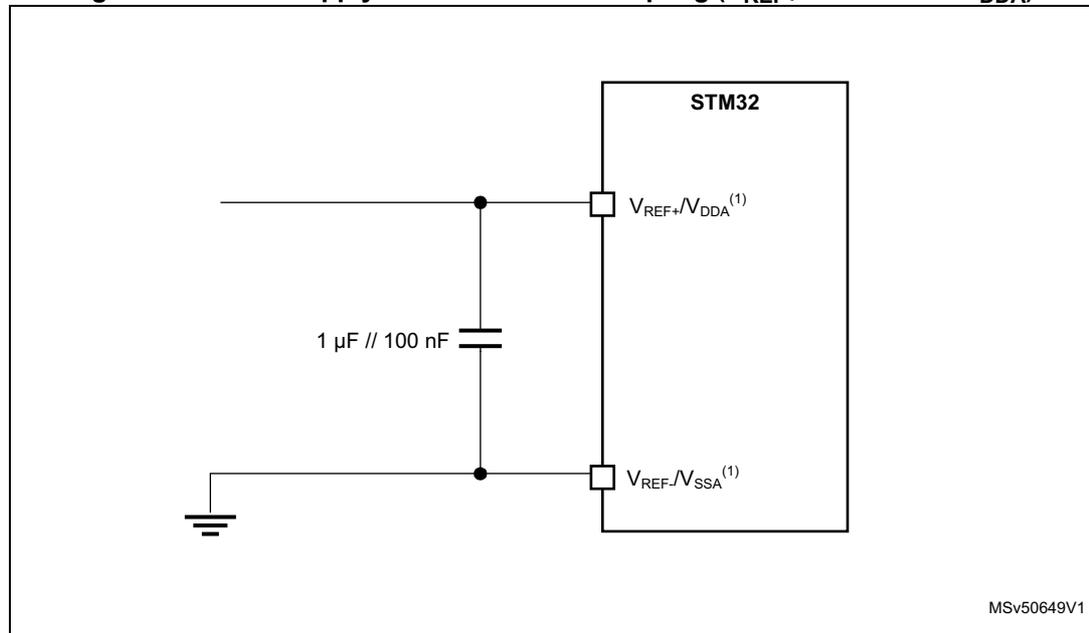
Power supply decoupling should be performed as shown in [Figure 89](#) or [Figure 90](#), depending on whether  $V_{REF+}$  is connected to  $V_{DDA}$  or not. The 100 nF capacitors should be ceramic (good quality). They should be placed them as close as possible to the chip.

**Figure 89. Power supply and reference decoupling ( $V_{REF+}$  not connected to  $V_{DDA}$ )**



1.  $V_{REF+}$  input is available on all package whereas the  $V_{REF-}$  s available only on UFBGA176+25 and TFBGA240+25. When  $V_{REF-}$  is not available, it is internally connected to  $V_{DDA}$  and  $V_{SSA}$ .

**Figure 90. Power supply and reference decoupling ( $V_{REF+}$  connected to  $V_{DDA}$ )**



1.  $V_{REF+}$  input is available on all package whereas the  $V_{REF-}$  s available only on UFBGA176+25 and TFBGA240+25. When  $V_{REF-}$  is not available, it is internally connected to  $V_{DDA}$  and  $V_{SSA}$ .

## 7.3.21 DAC characteristics

Table 176. DAC characteristics<sup>(1)(2)</sup>

| Symbol             | Parameter  | Conditions   | Min                     | Typ       | Max       | Unit             |               |
|--------------------|--|--|-------------------------|-----------|-----------|------------------|---------------|
| $V_{DDA}$          | Analog supply voltage  | -  | 1.8                     | 3.3       | 3.6       | V                |               |
| $V_{REF+}$         | Positive reference voltage   | -  | 1.80                    | -         | $V_{DDA}$ |                  |               |
| $V_{REF-}$         | Negative reference voltage   | -  | -                       | $V_{SSA}$ | -         |                  |               |
| $R_L$              | Resistive Load   | DAC output buffer ON   | connected to $V_{SSA}$  | 5         | -         | -                | k $\Omega$    |
|                    |  |  | connected to $V_{DDA}$  | 25        | -         | -                |               |
| $R_O$              | Output Impedance   | DAC output buffer OFF  |                         | 10.3      | 13        | 16               |               |
| $R_{BON}$          | Output impedance sample and hold mode, output buffer ON  | DAC output buffer ON   | $V_{DD} = 2.7\text{ V}$ | -         | -         | 1.6              | k $\Omega$    |
|                    |  |  | $V_{DD} = 2.0\text{ V}$ | -         | -         | 2.6              |               |
| $R_{BOFF}$         | Output impedance sample and hold mode, output buffer OFF   | DAC output buffer OFF  | $V_{DD} = 2.7\text{ V}$ | -         | -         | 17.8             | k $\Omega$    |
|                    |  |  | $V_{DD} = 2.0\text{ V}$ | -         | -         | 18.7             |               |
| $C_L$              | Capacitive Load  | DAC output buffer OFF  |                         | -         | -         | 50               | pF            |
| $C_{SH}$           |  | Sample and Hold mode   |                         | -         | 0.1       | 1                | $\mu\text{F}$ |
| $V_{DAC\_OUT}$     | Voltage on DAC_OUT output  | DAC output buffer ON   |                         | 0.2       | -         | $V_{REF+} - 0.2$ | V             |
|                    |  | DAC output buffer OFF  |                         | 0         | -         | $V_{REF+}$       |               |
| $t_{SETTLING}$     | Settling time (full scale: for a 12-bit code transition between the lowest and the highest input codes when DAC_OUT reaches the final value of $\pm 0.5\text{LSB}$ , $\pm 1\text{LSB}$ , $\pm 2\text{LSB}$ , $\pm 4\text{LSB}$ , $\pm 8\text{LSB}$ ) | Normal mode, DAC output buffer ON, $C_L \leq 50\text{ pF}$ , $R_L \geq 5\text{ k}\Omega$ | $\pm 0.5\text{ LSB}$    | -         | 2.05      | -                | $\mu\text{s}$ |
|                    |  |  | $\pm 1\text{ LSB}$      | -         | 1.97      | -                |               |
|                    |  |  | $\pm 2\text{ LSB}$      | -         | 1.67      | -                |               |
|                    |  |  | $\pm 4\text{ LSB}$      | -         | 1.66      | -                |               |
|                    |  |  | $\pm 8\text{ LSB}$      | -         | 1.65      | -                |               |
|                    |  | Normal mode, DAC output buffer OFF, $\pm 1\text{LSB}$ $C_L = 10\text{ pF}$               | -                       | 1.7       | 2         |                  |               |
| $t_{WAKEUP}^{(3)}$ | Wakeup time from off state (setting the ENx bit in the DAC Control register) until the final value of $\pm 1\text{LSB}$ is reached   | Normal mode, DAC output buffer ON, $C_L \leq 50\text{ pF}$ , $R_L = 5\text{ k}\Omega$    |                         | -         | 5         | 7.5              | $\mu\text{s}$ |
|                    |  | Normal mode, DAC output buffer OFF, $C_L \leq 10\text{ pF}$                              |                         | -         | 2         | 5                |               |
| PSRR               | DC $V_{DDA}$ supply rejection ratio  | Normal mode, DAC output buffer ON, $C_L \leq 50\text{ pF}$ , $R_L = 5\text{ k}\Omega$    |                         | -         | -80       | -28              | dB            |

Table 176. DAC characteristics<sup>(1)(2)</sup> (continued)

| Symbol                | Parameter  | Conditions   | Min                                | Typ   | Max  | Unit |    |
|-----------------------|--|--|------------------------------------|---|------|------|----|
| t <sub>SAMP</sub>     | Sampling time in Sample and Hold mode<br>C <sub>L</sub> =100 nF<br>(code transition between the lowest input code and the highest input code when DAC_OUT reaches the ±1LSB final value) | MODE<2:0>_V12=100/101 (BUFFER ON)                                      | -                                  | 0.7   | 2.6  | ms   |    |
|                       |  | MODE<2:0>_V12=110 (BUFFER OFF)   | -                                  | 11.5  | 18.7 |      |    |
|                       |  | MODE<2:0>_V12=111 (INTERNAL BUFFER OFF)                                | -                                  | 0.3   | 0.6  | µs   |    |
| C <sub>lint</sub>     | Internal sample and hold capacitor   | -  | 1.8                                | 2.2   | 2.6  | pF   |    |
| t <sub>TRIM</sub>     | Middle code offset trim time   | Minimum time to verify the each code                                   | 50                                 | -   | -    | µs   |    |
| V <sub>offset</sub>   | Middle code offset for 1 trim code step  | V <sub>REF+</sub> = 3.6 V  | -                                  | 850   | -    | µV   |    |
|                       |  | V <sub>REF+</sub> = 1.8 V  | -                                  | 425   | -    |      |    |
| I <sub>DDA(DAC)</sub> | DAC quiescent consumption from V <sub>DDA</sub>  | DAC output buffer ON   | No load, middle code (0x800)       | -   | 360  | -    | µA |
|                       |  |  | No load, worst code (0xF1C)        | -   | 490  | -    |    |
|                       |  | DAC output buffer OFF  | No load, middle/worst code (0x800) | -   | 20   | -    |    |
|                       |  | Sample and Hold mode, C <sub>SH</sub> =100 nF                          | -                                  | 360*T <sub>ON</sub> / (T <sub>ON</sub> +T <sub>OFF</sub> ) <sup>(4)</sup> | -    |      |    |
| I <sub>DDV(DAC)</sub> | DAC consumption from V <sub>REF+</sub>   | DAC output buffer ON   | No load, middle code (0x800)       | -   | 170  | -    | µA |
|                       |  |  | No load, worst code (0xF1C)        | -   | 170  | -    |    |
|                       |  | DAC output buffer OFF  | No load, middle/worst code (0x800) | -   | 160  | -    |    |
|                       |  | Sample and Hold mode, Buffer ON, C <sub>SH</sub> =100 nF (worst code)  | -                                  | 170*T <sub>ON</sub> / (T <sub>ON</sub> +T <sub>OFF</sub> ) <sup>(4)</sup> | -    |      |    |
|                       |  | Sample and Hold mode, Buffer OFF, C <sub>SH</sub> =100 nF (worst code) | -                                  | 160*T <sub>ON</sub> / (T <sub>ON</sub> +T <sub>OFF</sub> ) <sup>(4)</sup> | -    |      |    |
|                       |  |  |                                    |   |      |      |    |

1. Guaranteed by design unless otherwise specified.

2. TBD stands for "to be defined".
3. In buffered mode, the output can overshoot above the final value for low input code (starting from the minimum value).
4.  $T_{ON}$  is the refresh phase duration, while  $T_{OFF}$  is the hold phase duration. Refer to the product reference manual for more details.

**Table 177. DAC accuracy<sup>(1)</sup>**

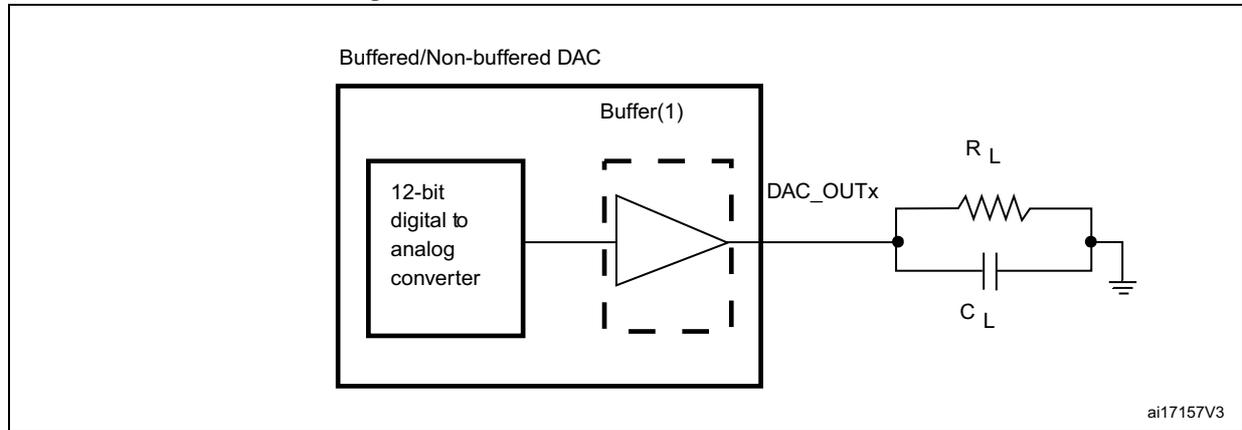
| Symbol    | Parameter  | Conditions  | Min                | Typ   | Max     | Unit     |     |
|-----------|--|---|--------------------|-------|---------|----------|-----|
| DNL       | Differential non linearity <sup>(2)</sup>            | DAC output buffer ON  | -2                 | -     | 2       | LSB      |     |
|           |  | DAC output buffer OFF   | -2                 | -     | 2       |          |     |
| -         | Monotonicity   | 10 bits   | -                  | -     | -       | -        |     |
| INL       | Integral non linearity <sup>(3)</sup>                | DAC output buffer ON, $C_L \leq 50$ pF, $R_L \geq 5$ k $\Omega$                       | -4                 | -     | 4       | LSB      |     |
|           |  | DAC output buffer OFF, $C_L \leq 50$ pF, no $R_L$                                     | -4                 | -     | 4       |          |     |
| Offset    | Offset error at code 0x800 <sup>(3)</sup>            | DAC output buffer ON, $C_L \leq 50$ pF, $R_L \geq 5$ k $\Omega$                       | $V_{REF+} = 3.6$ V | -     | -       | $\pm 15$ | LSB |
|           |  |   | $V_{REF+} = 1.8$ V | -     | -       | $\pm 30$ |     |
|           |  | DAC output buffer OFF, $C_L \leq 50$ pF, no $R_L$                                     | -                  | -     | $\pm 8$ |          |     |
| Offset1   | Offset error at code 0x001 <sup>(4)</sup>            | DAC output buffer OFF, $C_L \leq 50$ pF, no $R_L$                                     | -                  | -     | $\pm 5$ | LSB      |     |
| OffsetCal | Offset error at code 0x800 after factory calibration | DAC output buffer ON, $C_L \leq 50$ pF, $R_L \geq 5$ k $\Omega$                       | $V_{REF+} = 3.6$ V | -     | -       | $\pm 6$  | LSB |
|           |  |   | $V_{REF+} = 1.8$ V | -     | -       | $\pm 7$  |     |
| Gain      | Gain error <sup>(5)</sup>                            | DAC output buffer ON, $C_L \leq 50$ pF, $R_L \geq 5$ k $\Omega$                       | -                  | -     | $\pm 1$ | %        |     |
|           |  | DAC output buffer OFF, $C_L \leq 50$ pF, no $R_L$                                     | -                  | -     | $\pm 1$ |          |     |
| SNR       | Signal-to-noise ratio <sup>(6)</sup>                 | DAC output buffer ON, $C_L \leq 50$ pF, $R_L \geq 5$ k $\Omega$ , 1 kHz, BW = 500 KHz | -                  | 67.8  | -       | dB       |     |
|           |  | DAC output buffer OFF, $C_L \leq 50$ pF, no $R_L$ , 1 kHz, BW = 500 KHz               | -                  | 67.8  | -       |          |     |
| THD       | Total harmonic distortion <sup>(6)</sup>             | DAC output buffer ON, $C_L \leq 50$ pF, $R_L \geq 5$ k $\Omega$ , 1 kHz               | -                  | -78.6 | -       | dB       |     |
|           |  | DAC output buffer OFF, $C_L \leq 50$ pF, no $R_L$ , 1 kHz                             | -                  | -78.6 | -       |          |     |
| SINAD     | Signal-to-noise and distortion ratio <sup>(6)</sup>  | DAC output buffer ON, $C_L \leq 50$ pF, $R_L \geq 5$ k $\Omega$ , 1 kHz               | -                  | 67.5  | -       | dB       |     |
|           |  | DAC output buffer OFF, $C_L \leq 50$ pF, no $R_L$ , 1 kHz                             | -                  | 67.5  | -       |          |     |

Table 177. DAC accuracy<sup>(1)</sup> (continued)

| Symbol | Parameter                | Conditions   | Min | Typ  | Max | Unit |
|--------|--------------------------|--|-----|------|-----|------|
| ENOB   | Effective number of bits | DAC output buffer ON,<br>$C_L \leq 50 \text{ pF}$ , $R_L \geq 5 \text{ k}\Omega$ , 1 kHz | -   | 10.9 | -   | bits |
|        |                          | DAC output buffer OFF,<br>$C_L \leq 50 \text{ pF}$ , no $R_L$ , 1 kHz                    | -   | 10.9 | -   |      |

1. Guaranteed by characterization.
2. Difference between two consecutive codes minus 1 LSB.
3. Difference between the value measured at Code *i* and the value measured at Code *i* on a line drawn between Code 0 and last Code 4095.
4. Difference between the value measured at Code (0x001) and the ideal value.
5. Difference between the ideal slope of the transfer function and the measured slope computed from code 0x000 and 0xFFFF when the buffer is OFF, and from code giving 0.2 V and ( $V_{REF+} - 0.2 \text{ V}$ ) when the buffer is ON.
6. Signal is -0.5dBFS with  $F_{\text{sampling}}=1 \text{ MHz}$ .

Figure 91. 12-bit buffered /non-buffered DAC



1. The DAC integrates an output buffer that can be used to reduce the output impedance and to drive external loads directly without the use of an external operational amplifier. The buffer can be bypassed by configuring the BOFFx bit in the DAC\_CR register.

## 7.3.22 Voltage reference buffer characteristics

Table 178. VREFBUF characteristics<sup>(1)</sup>

| Symbol                  | Parameter   | Conditions                        |                            | Min                       | Typ    | Max  | Unit   |
|-------------------------|---|-----------------------------------|----------------------------|---------------------------|--------|--|--------|
| V <sub>DDA</sub>        | Analog supply voltage   | Normal mode                       | VSCALE = 000               | 2.8                       | 3.3    | 3.6  | V      |
|                         |   |                                   | VSCALE = 001               | 2.4                       | -      | 3.6  |        |
|                         |   |                                   | VSCALE = 010               | 2.1                       | -      | 3.6  |        |
|                         |   |                                   | VSCALE = 011               | 1.8                       | -      | 3.6  |        |
|                         |   | Degraded mode                     | VSCALE = 000               | 1.62                      | -      | 2.80   |        |
|                         |   |                                   | VSCALE = 001               | 1.62                      | -      | 2.40   |        |
|                         |   |                                   | VSCALE = 010               | 1.62                      | -      | 2.10   |        |
|                         |   |                                   | VSCALE = 011               | 1.62                      | -      | 1.80   |        |
| V <sub>REFBUF_OUT</sub> | Voltage Reference Buffer Output, at 30 °C, I <sub>load</sub> = 100 μA | Normal mode                       | VSCALE = 000               | 2.498                     | 2.5    | 2.5035   | V      |
|                         |   |                                   | VSCALE = 001               | 2.046                     | 2.049  | 2.052  |        |
|                         |   |                                   | VSCALE = 010               | 1.801                     | 1.804  | 1.806  |        |
|                         |   |                                   | VSCALE = 011               | 1.4995                    | 1.5015 | 1.504  |        |
|                         |   | Degraded mode <sup>(2)</sup>      | VSCALE = 000               | V <sub>DDA</sub> - 150 mV | -      | V <sub>DDA</sub>                                   |        |
|                         |   |                                   | VSCALE = 001               | V <sub>DDA</sub> - 150 mV | -      | V <sub>DDA</sub>                                   |        |
|                         |   |                                   | VSCALE = 010               | V <sub>DDA</sub> - 150 mV | -      | V <sub>DDA</sub>                                   |        |
|                         |   |                                   | VSCALE = 011               | V <sub>DDA</sub> - 150 mV | -      | V <sub>DDA</sub>                                   |        |
| TRIM                    | Trim step resolution  | -                                 | -                          | -                         | ±0.05  | ±0.1   | %      |
| C <sub>L</sub>          | Load capacitor  | -                                 | -                          | 0.5                       | 1      | 1.50   | μF     |
| esr                     | Equivalent Serial Resistor of C <sub>L</sub>                          | -                                 | -                          | -                         | -      | 2  | Ω      |
| I <sub>load</sub>       | Static load current   | -                                 | -                          | -                         | -      | 4  | mA     |
| I <sub>line_reg</sub>   | Line regulation   | 2.8 V ≤ V <sub>DDA</sub> ≤ 3.6 V  | I <sub>load</sub> = 500 μA | -                         | 200    | -  | ppm/V  |
|                         |   |                                   | I <sub>load</sub> = 4 mA   | -                         | 100    | -  |        |
| I <sub>load_reg</sub>   | Load regulation   | 500 μA ≤ I <sub>LOAD</sub> ≤ 4 mA | Normal Mode                | -                         | 50     | -  | ppm/mA |
| T <sub>coeff</sub>      | Temperature coefficient   | -40 °C < T <sub>J</sub> < +125 °C |                            | -                         | -      | T <sub>coeff</sub><br>V <sub>REFINT</sub><br>+ 100 | ppm/°C |
| PSRR                    | Power supply rejection  | DC                                | -                          | -                         | 60     | -  | dB     |
|                         |   | 100KHz                            | -                          | -                         | 40     | -  |        |

**Table 178. VREFBUF characteristics<sup>(1)</sup> (continued)**

| Symbol                    | Parameter  | Conditions                 |   | Min | Typ | Max | Unit |
|---------------------------|--|----------------------------|---|-----|-----|-----|------|
| t <sub>START</sub>        | Start-up time  | C <sub>L</sub> =0.5 μF     | - | -   | 300 | -   | μs   |
|                           |  | C <sub>L</sub> =1 μF       | - | -   | 500 | -   |      |
|                           |  | C <sub>L</sub> =1.5 μF     | - | -   | 650 | -   |      |
| I <sub>INRUSH</sub>       | Control of maximum DC current drive on V <sub>REFBUF_OUT</sub> during startup phase <sup>(3)</sup> | -                          |   | -   | 8   | -   | mA   |
| I <sub>DDA(VREFBUF)</sub> | VREFBUF consumption from V <sub>DDA</sub>  | I <sub>LOAD</sub> = 0 μA   | - | -   | 15  | 25  | μA   |
|                           |  | I <sub>LOAD</sub> = 500 μA | - | -   | 16  | 30  |      |
|                           |  | I <sub>LOAD</sub> = 4 mA   | - | -   | 32  | 50  |      |

1. Guaranteed by design.
2. In degraded mode, the voltage reference buffer cannot accurately maintain the output voltage (V<sub>DDA</sub>-drop voltage).
3. To properly control VREFBUF I<sub>INRUSH</sub> current during the startup phase and the change of scaling, V<sub>DDA</sub> voltage should be in the range of 1.8 V-3.6 V, 2.1 V-3.6 V, 2.4 V-3.6 V and 2.8 V-3.6 V for VSCALE = 011, 010, 001 and 000, respectively.

### 7.3.23 Temperature sensor characteristics

**Table 179. Temperature sensor characteristics**

| Symbol                              | Parameter                                      | Min | Typ  | Max  | Unit  |
|-------------------------------------|--|-----|------|------|-------|
| T <sub>L</sub> <sup>(1)</sup>       | V <sub>SENSE</sub> linearity with temperature  | -   | -    | ±3   | °C    |
| Avg_Slope <sup>(2)</sup>            | Average slope                                  | -   | 2    | -    | mV/°C |
| V <sub>30</sub> <sup>(3)</sup>      | Voltage at 30°C ± 5 °C                         | -   | 0.62 | -    | V     |
| t <sub>start_run</sub>              | Startup time in Run mode (buffer startup)      | -   | -    | 25.2 | μs    |
| t <sub>S_temp</sub> <sup>(1)</sup>  | ADC sampling time when reading the temperature | 9   | -    | -    |       |
| I <sub>sens</sub> <sup>(1)</sup>    | Sensor consumption                             | -   | 0.18 | 0.31 | μA    |
| I <sub>sensbuf</sub> <sup>(1)</sup> | Sensor buffer consumption                      | -   | 3.8  | 6.5  |       |

1. Guaranteed by design.
2. Guaranteed by characterization.
3. Measured at V<sub>DDA</sub> = V<sub>REF</sub> = 3.3 V ± 10 mV. The V<sub>30</sub> ADC conversion result is stored in the TS\_CAL1 byte.

**Table 180. Temperature sensor calibration values**

| Symbol  | Parameter   | Memory address            |
|---------|---|---------------------------|
| TS_CAL1 | Temperature sensor raw data acquired value at 30 °C, V <sub>DDA</sub> = V <sub>REF</sub> = 3.3 V  | 0x1FF1 E820 - 0x1FF1 E821 |
| TS_CAL2 | Temperature sensor raw data acquired value at 130 °C, V <sub>DDA</sub> = V <sub>REF</sub> = 3.3 V | 0x1FF1 E840 - 0x1FF1 E841 |

### 7.3.24 Temperature and V<sub>BAT</sub> monitoring

**Table 181. V<sub>BAT</sub> monitoring characteristics**

| Symbol                             | Parameter   | Min | Typ  | Max | Unit |
|------------------------------------|---|-----|------|-----|------|
| R                                  | Resistor bridge for V <sub>BAT</sub>                  | -   | 26   | -   | KΩ   |
| Q                                  | Ratio on V <sub>BAT</sub> measurement                 | -   | 4    | -   | -    |
| Er <sup>(1)</sup>                  | Error on Q  | -10 | -    | +10 | %    |
| t <sub>S_vbat</sub> <sup>(1)</sup> | ADC sampling time when reading V <sub>BAT</sub> input | 9   | -    | -   | μs   |
| V <sub>BAThigh</sub>               | High supply monitoring                                | -   | 3.55 | -   | V    |
| V <sub>BATlow</sub>                | Low supply monitoring                                 | -   | 1.36 | -   |      |

1. Guaranteed by design.

**Table 182. V<sub>BAT</sub> charging characteristics**

| Symbol          | Parameter                 | Condition          | Min | Typ | Max | Unit |
|-----------------|---------------------------|--------------------|-----|-----|-----|------|
| R <sub>BC</sub> | Battery charging resistor | VBRS in PWR_CR3= 0 | -   | 5   | -   | KΩ   |
|                 |                           | VBRS in PWR_CR3= 1 | -   | 1.5 | -   |      |

**Table 183. Temperature monitoring characteristics**

| Symbol               | Parameter                   | Min | Typ | Max | Unit |
|----------------------|-----------------------------|-----|-----|-----|------|
| TEMP <sub>high</sub> | High temperature monitoring | -   | 117 | -   | °C   |
| TEMP <sub>low</sub>  | Low temperature monitoring  | -   | -25 | -   |      |

### 7.3.25 Voltage booster for analog switch

**Table 184. Voltage booster for analog switch characteristics<sup>(1)</sup>**

| Symbol                 | Parameter            | Condition                        | Min  | Typ | Max | Unit |
|------------------------|----------------------|----------------------------------|------|-----|-----|------|
| V <sub>DD</sub>        | Supply voltage       | -                                | 1.62 | 2.6 | 3.6 | V    |
| t <sub>SU(BOOST)</sub> | Booster startup time | -                                | -    | -   | 50  | μs   |
| I <sub>DD(BOOST)</sub> | Booster consumption  | 1.62 V ≤ V <sub>DD</sub> ≤ 2.7 V | -    | -   | 125 | μA   |
|                        |                      | 2.7 V < V <sub>DD</sub> < 3.6 V  | -    | -   | 250 |      |

1. Guaranteed by characterization results.

7.3.26 Comparator characteristics

Table 185. COMP characteristics<sup>(1)</sup>

| Symbol                        | Parameter   | Conditions                | Min   | Typ | Max              | Unit |    |
|-------------------------------|---|---------------------------|---|-----|------------------|------|----|
| V <sub>DDA</sub>              | Analog supply voltage   | -                         | 1.62  | 3.3 | 3.6              | V    |    |
| V <sub>IN</sub>               | Comparator input voltage range  | -                         | 0   | -   | V <sub>DDA</sub> |      |    |
| V <sub>BG</sub>               | Scaler input voltage  | -                         | (2)   |     |                  |      |    |
| V <sub>SC</sub>               | Scaler offset voltage   | -                         | -   | ±5  | ±10              | mV   |    |
| I <sub>DDA(SCALER)</sub>      | Scaler static consumption from V <sub>DDA</sub>                                   | BRG_EN=0 (bridge disable) | -   | 0.2 | 0.3              | µA   |    |
|                               |   | BRG_EN=1 (bridge enable)  | -   | 0.8 | 1                |      |    |
| t <sub>START_SCALER</sub>     | Scaler startup time   | -                         | -   | 140 | 250              | µs   |    |
| t <sub>START</sub>            | Comparator startup time to reach propagation delay specification                  | High-speed mode           | -   | 2   | 5                | µs   |    |
|                               |   | Medium mode               | -   | 5   | 20               |      |    |
|                               |   | Ultra-low-power mode      | -   | 15  | 80               |      |    |
| t <sub>D</sub> <sup>(3)</sup> | Propagation delay for 200 mV step with 100 mV overdrive                           | High-speed mode           | -   | 50  | 80               | ns   |    |
|                               |   | Medium mode               | -   | 0.5 | 1.2              | µs   |    |
|                               |   | Ultra-low-power mode      | -   | 2.5 | 7                |      |    |
|                               | Propagation delay for step > 200 mV with 100 mV overdrive only on positive inputs | High-speed mode           | -   | 50  | 120              | ns   |    |
|                               |   | Medium mode               | -   | 0.5 | 1.2              | µs   |    |
|                               |   | Ultra-low-power mode      | -   | 2.5 | 7                |      |    |
| V <sub>offset</sub>           | Comparator offset error   | Full common mode range    | -   | ±5  | ±20              | mV   |    |
| V <sub>hys</sub>              | Comparator hysteresis   | No hysteresis             | -   | 0   | -                | mV   |    |
|                               |   | Low hysteresis            | 5   | 10  | 22               |      |    |
|                               |   | Medium hysteresis         | 8   | 20  | 37               |      |    |
|                               |   | High hysteresis           | 16  | 30  | 52               |      |    |
| I <sub>DDA(COMP)</sub>        | Comparator consumption from V <sub>DDA</sub>                                      | Ultra-low-power mode      | Static                                      | -   | 400              | 600  | nA |
|                               |   |                           | With 50 kHz ±100 mV overdrive square signal | -   | 800              | -    |    |
|                               |   | Medium mode               | Static                                      | -   | 5                | 7    | µA |
|                               |   |                           | With 50 kHz ±100 mV overdrive square signal | -   | 6                | -    |    |
|                               |   | High-speed mode           | Static                                      | -   | 70               | 100  |    |
|                               |   |                           | With 50 kHz ±100 mV overdrive square signal | -   | 75               | -    |    |

1. Guaranteed by design, unless otherwise specified.
2. Refer to [Table 116: Embedded reference voltage](#).

3. Guaranteed by characterization results.

### 7.3.27 Operational amplifier characteristics

Table 186. Operational amplifier characteristics

| Symbol                       | Parameter   | Conditions   | Min                       | Typ  | Max       | Unit  |
|------------------------------|---|--|---------------------------|------|-----------|-------|
| $V_{DDA}$                    | Analog supply voltage Range                                     | -  | 2                         | 3.3  | 3.6       | V     |
| CMIR                         | Common Mode Input Range   | -  | 0                         | -    | $V_{DDA}$ |       |
| $V_{I\text{OFFSET}}$         | Input offset voltage  | 25°C, no load on output  | -                         | -    | ±1.5      | mV    |
|                              |   | All voltages and temperature, no load  | -                         | -    | ±2.5      |       |
| $\Delta V_{I\text{OFFSET}}$  | Input offset voltage drift                                      | -  | -                         | ±3.0 | -         | µV/°C |
| TRIMOFFSETP<br>TRIMLPOFFSETP | Offset trim step at low common input voltage (0.1* $V_{DDA}$ )  | -  | -                         | 1.1  | 1.5       | mV    |
| TRIMOFFSETN<br>TRIMLPOFFSETN | Offset trim step at high common input voltage (0.9* $V_{DDA}$ ) | -  | -                         | 1.1  | 1.5       |       |
| $I_{LOAD}$                   | Drive current   | -  | -                         | -    | 500       | µA    |
| $I_{LOAD\_PGA}$              | Drive current in PGA mode                                       | -  | -                         | -    | 270       |       |
| $C_{LOAD}$                   | Capacitive load   | -  | -                         | -    | 50        | pF    |
| CMRR                         | Common mode rejection ratio                                     | -  | -                         | 80   | -         | dB    |
| PSRR                         | Power supply rejection ratio                                    | $C_{LOAD} \leq 50\text{pf} /$<br>$R_{LOAD} \geq 4\text{ k}\Omega^{(1)}$ at 1 kHz,<br>$V_{com} = V_{DDA}/2$ | 50                        | 66   | -         | dB    |
| GBW                          | Gain bandwidth for high supply range                            | 200 mV ≤ Output dynamic range ≤ $V_{DDA} - 200\text{ mV}$  | 4                         | 7.3  | 12.3      | MHz   |
| SR                           | Slew rate (from 10% and 90% of output voltage)                  | Normal mode  | -                         | 3    | -         | V/µs  |
|                              |   | High-speed mode  | -                         | 30   | -         |       |
| AO                           | Open loop gain  | 200 mV ≤ Output dynamic range ≤ $V_{DDA} - 200\text{ mV}$  | 59                        | 90   | 129       | dB    |
| $\phi_m$                     | Phase margin  | -  | -                         | 55   | -         | °     |
| GM                           | Gain margin   | -  | -                         | 12   | -         | dB    |
| $V_{OHSAT}$                  | High saturation voltage   | $I_{load} = \text{max}$ or $R_{LOAD} = \text{min}$ ,<br>Input at $V_{DDA}$                                 | $V_{DDA} - 100\text{ mV}$ | -    | -         | mV    |
| $V_{OLSAT}$                  | Low saturation voltage  | $I_{load} = \text{max}$ or $R_{LOAD} = \text{min}$ ,<br>Input at 0 V                                       | -                         | -    | 100       |       |

Table 186. Operational amplifier characteristics (continued)

| Symbol               | Parameter   | Conditions  | Min  | Typ    | Max | Unit      |
|----------------------|---|---|------|--------|-----|-----------|
| t <sub>WAKEUP</sub>  | Wake up time from OFF state   | Normal mode<br>C <sub>LOAD</sub> ≤ 50pf,<br>R <sub>LOAD</sub> ≥ 4 kΩ,<br>follower configuration     | -    | 0.8    | 3.2 | μs        |
|                      |   | High speed mode<br>C <sub>LOAD</sub> ≤ 50pf,<br>R <sub>LOAD</sub> ≥ 4 kΩ,<br>follower configuration | -    | 0.9    | 2.8 |           |
| PGA gain             | Non inverting gain error value  | PGA gain = 2  | -1   | -      | 1   | %         |
|                      |   | PGA gain = 4  | -2   | -      | 2   |           |
|                      |   | PGA gain = 8  | -2.5 | -      | 2.5 |           |
|                      |   | PGA gain = 16   | -3   | -      | 3   |           |
|                      | Inverting gain error value  | PGA gain = 2  | -1   | -      | 1   |           |
|                      |   | PGA gain = 4  | -1   | -      | 1   |           |
|                      |   | PGA gain = 8  | -2   | -      | 2   |           |
|                      |   | PGA gain = 16   | -3   | -      | 3   |           |
|                      | External non-inverting gain error value                                   | PGA gain = 2  | -1   | -      | 1   |           |
|                      |   | PGA gain = 4  | -3   | -      | 3   |           |
|                      |   | PGA gain = 8  | -3.5 | -      | 3.5 |           |
|                      |   | PGA gain = 16   | -4   | -      | 4   |           |
| R <sub>network</sub> | R2/R1 internal resistance values in non-inverting PGA mode <sup>(2)</sup> | PGA Gain=2  | -    | 10/10  | -   | kΩ/<br>kΩ |
|                      |   | PGA Gain=4  | -    | 30/10  | -   |           |
|                      |   | PGA Gain=8  | -    | 70/10  | -   |           |
|                      |   | PGA Gain=16   | -    | 150/10 | -   |           |
|                      | R2/R1 internal resistance values in inverting PGA mode <sup>(2)</sup>     | PGA Gain = -1   | -    | 10/10  | -   |           |
|                      |   | PGA Gain = -3   | -    | 30/10  | -   |           |
|                      |   | PGA Gain = -7   | -    | 70/10  | -   |           |
|                      |   | PGA Gain = -15  | -    | 150/10 | -   |           |
| Delta R              | Resistance variation (R1 or R2)   | -   | -15  | -      | 15  | %         |

**Table 186. Operational amplifier characteristics (continued)**

| Symbol                  | Parameter                                      | Conditions      | Min                               | Typ    | Max | Unit |        |
|-------------------------|--|-----------------|-----------------------------------|--------|-----|------|--------|
| PGA BW                  | PGA bandwidth for different non inverting gain | Gain=2          | -                                 | GBW/2  | -   | MHz  |        |
|                         |  | Gain=4          | -                                 | GBW/4  | -   |      |        |
|                         |  | Gain=8          | -                                 | GBW/8  | -   |      |        |
|                         |  | Gain=16         | -                                 | GBW/16 | -   |      |        |
|                         | PGA bandwidth for different inverting gain     | Gain = -1       | -                                 | 5.00   | -   | MHz  |        |
|                         |  | Gain = -3       | -                                 | 3.00   | -   |      |        |
|                         |  | Gain = -7       | -                                 | 1.50   | -   |      |        |
|                         |  | Gain = -15      | -                                 | 0.80   | -   |      |        |
| en                      | Voltage noise density                          | at 1 KHz        | output loaded with 4 kΩ           | -      | 140 | -    | nV/√Hz |
|                         |  | at 10 KHz       |                                   | -      | 55  | -    |        |
| I <sub>DDA(OPAMP)</sub> | OPAMP consumption from V <sub>DDA</sub>        | Normal mode     | no Load, quiescent mode, follower | -      | 570 | 1000 | μA     |
|                         |  | High-speed mode |                                   | -      | 610 | 1200 |        |

- R<sub>LOAD</sub> is the resistive load connected to VSSA or to VDDA.
- R2 is the internal resistance between the OPAMP output and th OPAMP inverting input. R1 is the internal resistance between the OPAMP inverting input and ground. PGA gain = 1 + R2/R1.

### 7.3.28 Digital filter for Sigma-Delta Modulators (DFSDM) characteristics

Unless otherwise specified, the parameters given in [Table 187](#) for DFSDM are derived from tests performed under the ambient temperature, fPCLKx frequency and supply voltage conditions summarized in [Table 111: General operating conditions](#).

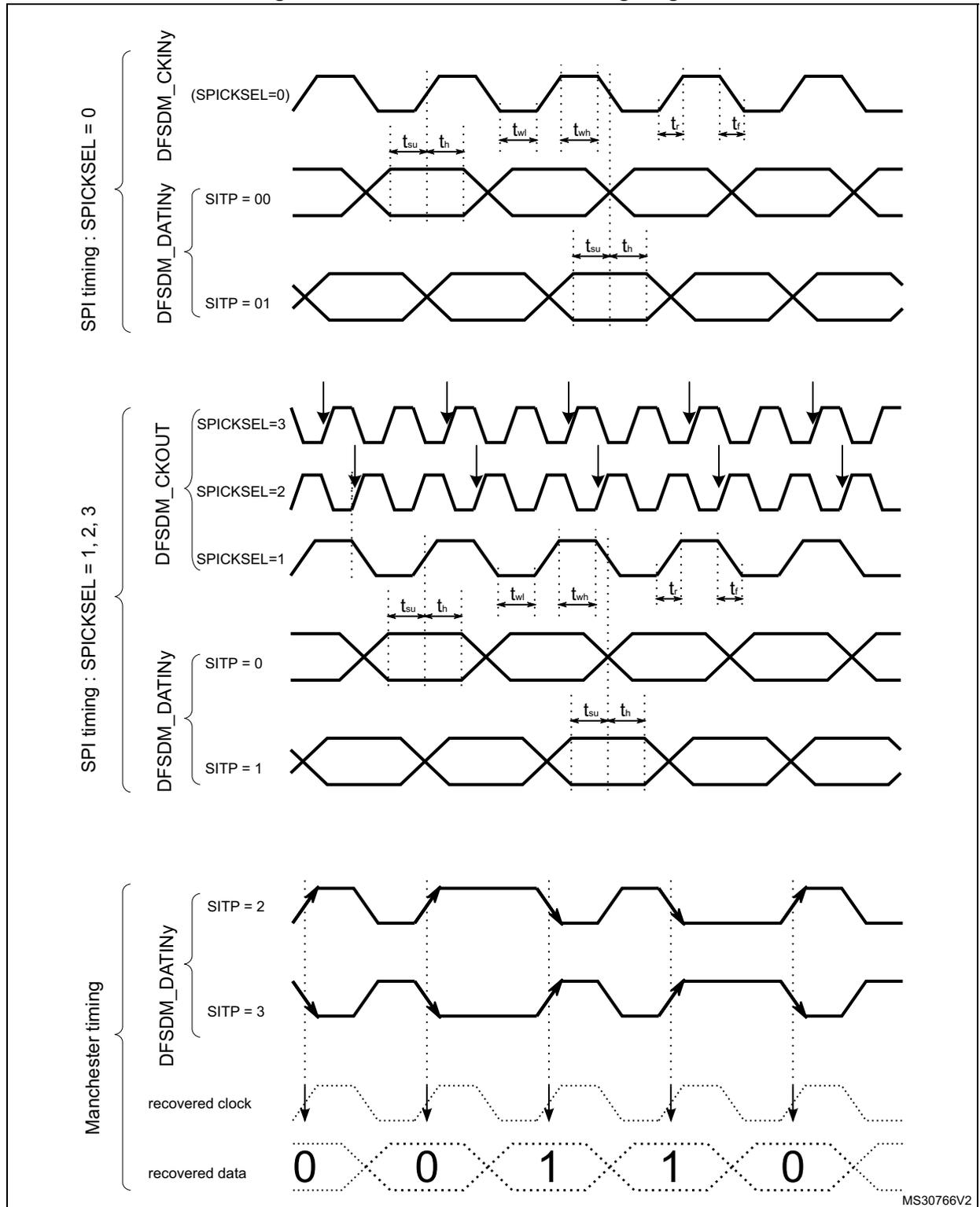
- Output speed is set to OSPEEDRy[1:0] = 10
- Capacitive load C<sub>L</sub> = 30 pF
- Measurement points are done at CMOS levels: 0.5V<sub>DD</sub>
- VOS level set to VOS1

Refer to [Section 7.3.15: I/O port characteristics](#) for more details on the input/output alternate function characteristics (DiFSDM\_CKINx, DFSDM\_DATINx, DFSDM\_CKOUT for DFSDM).

Table 187. DFSDM measured timing - 1.62-3.6 V

| Symbol                           | Parameter                                       | Conditions  | Min   | Typ                              | Max                            | Unit                             |   |
|----------------------------------|---|---|---|----------------------------------|--------------------------------|----------------------------------|---|
| $f_{DFSDMCLK}$                   | DFSDM clock                                     | $1.62 < V_{DD} < 3.6 V$   | -   | -                                | 250                            | MHz                              |   |
| $f_{CKIN}$<br>( $1/T_{CKIN}$ )   | Input clock frequency                           | SPI mode (SITP[1:0]=0,1),<br>External clock mode (SPICKSEL[1:0]=0),<br>$1.62 < V_{DD} < 3.6 V$        | -   | -                                | 20                             |                                  |   |
|                                  |   | SPI mode (SITP[1:0]=0,1),<br>External clock mode (SPICKSEL[1:0]=0),<br>$2.7 < V_{DD} < 3.6 V$         | -   | -                                | 20                             |                                  |   |
|                                  |   | SPI mode (SITP[1:0]=0,1),<br>Internal clock mode (SPICKSEL[1:0]=0),<br>$1.62 < V_{DD} < 3.6 V$        | -   | -                                | 20                             |                                  |   |
|                                  |   | SPI mode (SITP[1:0]=0,1),<br>Internal clock mode (SPICKSEL[1:0]=0),<br>$2.7 < V_{DD} < 3.6 V$         | -   | -                                | 20                             |                                  |   |
| $f_{CKOUT}$                      | Output clock frequency                          | $1.62 < V_{DD} < 3.6 V$   | -   | -                                | 20                             |                                  |   |
| $DuCy_{CKOUT}$                   | Output clock frequency duty cycle               | $1.62 < V_{DD} < 3.6 V$   | Even division,<br>CKOUTDIV[7:0] =<br>1, 3, 5... | 45                               | 50                             | 55                               | % |
|                                  |   |   | Odd division,<br>CKOUTDIV[7:0] =<br>2, 4, 6...  | $\frac{((n/2+1)/(n+1))}{*100}-5$ | $\frac{((n/2+1)/(n+1))}{*100}$ | $\frac{((n/2+1)/(n+1))}{*100}+5$ |   |
| $t_{wh(CKIN)}$<br>$t_{wl(CKIN)}$ | Input clock high and low time                   | SPI mode (SITP[1:0]=0,1),<br>External clock mode (SPICKSEL[1:0]=0),<br>$1.62 < V_{DD} < 3.6 V$        | $T_{CKIN}/2-0.5$                                | $T_{CKIN}/2$                     | -                              | ns                               |   |
| $t_{su}$                         | Data input setup time                           | SPI mode (SITP[1:0]=0,1),<br>External clock mode (SPICKSEL[1:0]=0),<br>$1.62 < V_{DD} < 3.6 V$        | 1.5   | -                                | -                              |                                  |   |
| $t_h$                            | Data input hold time                            | SPI mode (SITP[1:0]=0,1),<br>External clock mode (SPICKSEL[1:0]=0),<br>$1.62 < V_{DD} < 3.6 V$        | 0.5   | -                                | -                              |                                  |   |
| $T_{Manchester}$                 | Manchester data period (recovered clock period) | Manchester mode (SITP[1:0]=2,3),<br>Internal clock mode (SPICKSEL[1:0]=0),<br>$1.62 < V_{DD} < 3.6 V$ | $(CKOUTDIV+1) * T_{DFSDMCLK}$                   | -                                | $(2*CKOUTDIV) * T_{DFSDMCLK}$  |                                  |   |

Figure 92. Channel transceiver timing diagrams



### 7.3.29 Camera interface (DCMI) timing specifications

Unless otherwise specified, the parameters given in [Table 188](#) for DCMI are derived from tests performed under the ambient temperature,  $f_{HCLK}$  frequency and VDD supply voltage summarized in [Table 111: General operating conditions](#), with the following configuration:

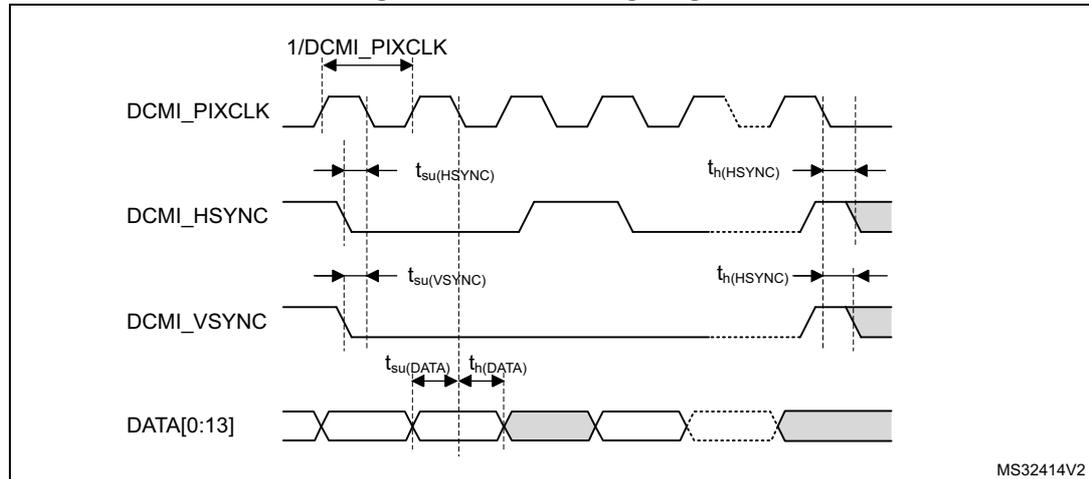
- DCMI\_PIXCLK polarity: falling
- DCMI\_VSYNC and DCMI\_HSYNC polarity: high
- Data formats: 14 bits
- Capacitive load  $C_L=30$  pF
- Measurement points are done at CMOS levels:  $0.5V_{DD}$
- VOS level set to VOS1

**Table 188. DCMI characteristics<sup>(1)</sup>**

| Symbol                               | Parameter                               | Min | Max | Unit |
|--------------------------------------|---|-----|-----|------|
| -                                    | Frequency ratio DCMI_PIXCLK/ $f_{HCLK}$ | -   | 0.4 | -    |
| DCMI_PIXCLK                          | Pixel Clock input                       | -   | 80  | MHz  |
| $D_{pixel}$                          | Pixel Clock input duty cycle            | 30  | 70  | %    |
| $t_{su}(DATA)$                       | Data input setup time                   | 3   | -   | -    |
| $t_h(DATA)$                          | Data hold time                          | 1   | -   | -    |
| $t_{su}(HSYNC)$ ,<br>$t_{su}(VSYNC)$ | DCMI_HSYNC/ DCMI_VSYNC input setup time | 2   | -   | ns   |
| $t_h(HSYNC)$ ,<br>$t_h(VSYNC)$       | DCMI_HSYNC/ DCMI_VSYNC input hold time  | 1   | -   | -    |

1. Guaranteed by characterization results.

**Figure 93. DCMI timing diagram**



### 7.3.30 LCD-TFT controller (LTDC) characteristics

Unless otherwise specified, the parameters given in [Table 189](#) for LCD-TFT are derived from tests performed under the ambient temperature,  $f_{HCLK}$  frequency and VDD supply voltage summarized in [Table 111: General operating conditions](#), with the following configuration:

- LCD\_CLK polarity: high
- LCD\_DE polarity: low
- LCD\_VSYNC and LCD\_HSYNC polarity: high
- Pixel formats: 24 bits
- Output speed is set to OSPEEDRy[1:0] = 11
- Capacitive load  $C_L=30$  pF
- Measurement points are done at CMOS levels: 0.5VDD
- IO Compensation cell activated.
- HSLV activated when  $V_{DD} \leq 2.7$  V
- VOS level set to VOS1

**Table 189. LTDC characteristics<sup>(1)</sup>**

| Symbol  | Parameter                        |                                    | Min                | Max                | Unit |
|---|----------------------------------|------------------------------------|--------------------|--------------------|------|
| $f_{CLK}$   | LTDC clock output frequency      | 2.7<V <sub>DD</sub> <3.6 V<br>20pF | -                  | 150                | MHz  |
|   |                                  | 2.7<V <sub>DD</sub> <3.6 V         |                    | 133                |      |
|   |                                  | 1.62<V <sub>DD</sub> <3.6 V        |                    | 90                 |      |
| D <sub>CLK</sub>                                    | LTDC clock output duty cycle     |                                    | 45                 | 55                 | %    |
| $t_{w(CLKH)}$ ,<br>$t_{w(CLKL)}$                    | Clock High time, low time        |                                    | $t_{w(CLK)}/2-0.5$ | $t_{w(CLK)}/2+0.5$ | -    |
| $t_{v(DATA)}$                                       | Data output valid time           | 2.7<V <sub>DD</sub> <3.6 V         | -                  | 0.5                | -    |
| $t_{h(DATA)}$                                       |                                  | 1.62<V <sub>DD</sub> <3.6 V        |                    | 5                  |      |
| $t_{v(DATA)}$                                       | Data output hold time            |                                    | 0                  | -                  | -    |
| $t_{v(HSYNC)}$ ,<br>$t_{v(VSYNC)}$ ,<br>$t_{v(DE)}$ | HSYNC/VSYNC/DE output valid time | 2.7<V <sub>DD</sub> <3.6 V         | -                  | 0.5                | -    |
|   |                                  | 1.62<V <sub>DD</sub> <3.6 V        | -                  | 5                  |      |
| $t_{h(HSYNC)}$ ,<br>$t_{h(VSYNC)}$ ,<br>$t_{h(DE)}$ | HSYNC/VSYNC/DE output hold time  |                                    | 0                  | -                  | -    |

1. Guaranteed by characterization results.

Figure 94. LCD-TFT horizontal timing diagram

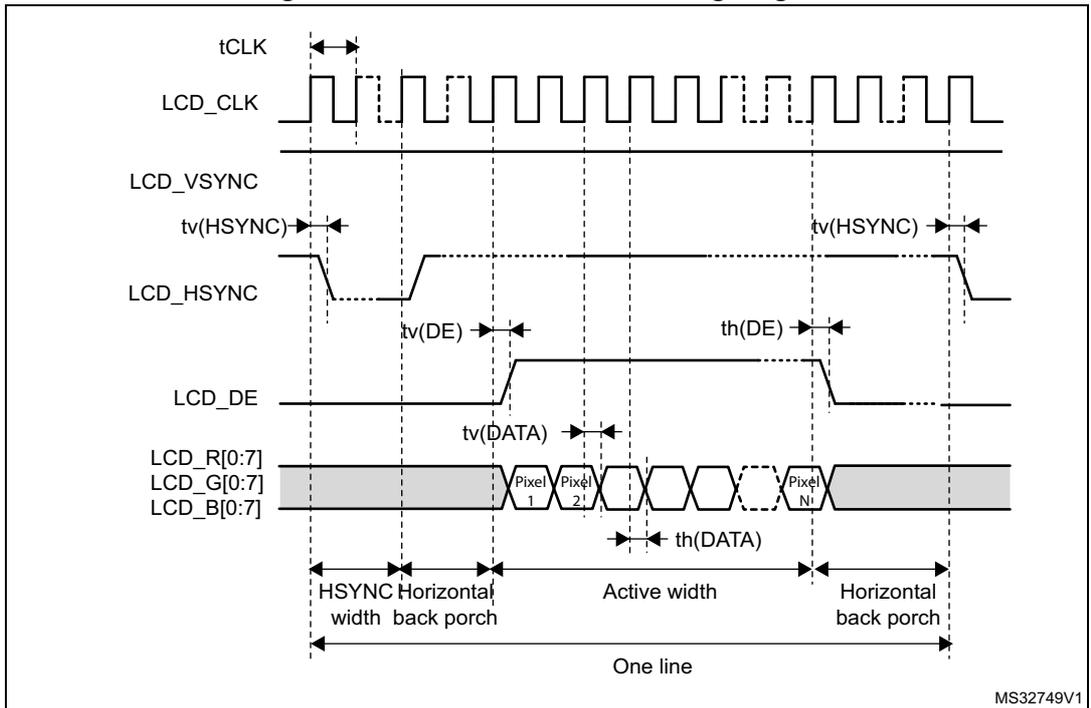
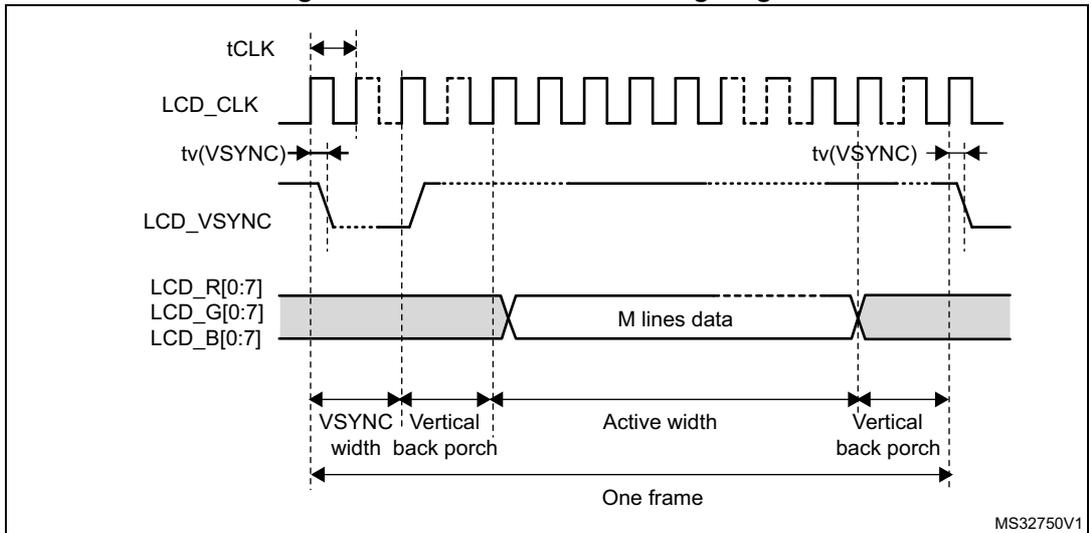


Figure 95. LCD-TFT vertical timing diagram



### 7.3.31 Timer characteristics

The parameters given in [Table 190](#) are guaranteed by design.

Refer to [Section 7.3.15: I/O port characteristics](#) for details on the input/output alternate function characteristics (output compare, input capture, external clock, PWM output).

**Table 190. TIMx characteristics<sup>(1)(2)</sup>**

| Symbol           | Parameter                                    | Conditions <sup>(3)</sup>                               | Min | Max                  | Unit          |
|------------------|--|---|-----|----------------------|---------------|
| $t_{res(TIM)}$   | Timer resolution time                        | AHB/APBx prescaler=1 or 2 or 4, $f_{TIMxCLK} = 240$ MHz | 1   | -                    | $t_{TIMxCLK}$ |
|                  |  | AHB/APBx prescaler>4, $f_{TIMxCLK} = 120$ MHz           | 1   | -                    | $t_{TIMxCLK}$ |
| $f_{EXT}$        | Timer external clock frequency on CH1 to CH4 | $f_{TIMxCLK} = 240$ MHz                                 | 0   | $f_{TIMxCLK}/2$      | MHz           |
| $Res_{TIM}$      | Timer resolution                             |   | -   | 16/32                | bit           |
| $t_{MAX\_COUNT}$ | Maximum possible count with 32-bit counter   | -   | -   | $65536 \times 65536$ | $t_{TIMxCLK}$ |

1. TIMx is used as a general term to refer to the TIM1 to TIM17 timers.
2. Guaranteed by design.
3. The maximum timer frequency on APB1 or APB2 is up to 240 MHz, by setting the TIMPRE bit in the RCC\_CFGR register, if APBx prescaler is 1 or 2 or 4, then  $TIMxCLK = rcc\_hclk1$ , otherwise  $TIMxCLK = 4 \times F_{rcc\_pclkx\_d2}$ .

### 7.3.32 Communication interfaces

#### I<sup>2</sup>C interface characteristics

The I<sup>2</sup>C interface meets the timings requirements of the I2C-bus specification and user manual revision 03 for:

- Standard-mode (Sm): with a bit rate up to 100 kbit/s
- Fast-mode (Fm): with a bit rate up to 400 kbit/s
- Fast-mode Plus (Fm+): with a bit rate up to 1 Mbit/s.

The I<sup>2</sup>C timings requirements are guaranteed by design when the I<sup>2</sup>C peripheral is properly configured (refer to RM0399 reference manual) and when the `i2c_ker_ck` frequency is greater than the minimum shown in the table below:

**Table 191. Minimum i2c\_ker\_ck frequency in all I<sup>2</sup>C modes**

| Symbol    | Parameter        | Condition      |                            | Min | Unit |
|-----------|------------------|----------------|----------------------------|-----|------|
| f(I2CCLK) | I2CCLK frequency | Standard-mode  | -                          | 2   | MHz  |
|           |                  | Fast-mode      | Analog Filtre ON<br>DNF=0  | 8   |      |
|           |                  |                | Analog Filtre OFF<br>DNF=1 | 9   |      |
|           |                  | Fast-mode Plus | Analog Filtre ON<br>DNF=0  | 17  |      |
|           |                  |                | Analog Filtre OFF<br>DNF=1 | 16  | -    |

The SDA and SCL I/O requirements are met with the following restrictions:

- The SDA and SCL I/O pins are not “true” open-drain. When configured as open-drain, the PMOS connected between the I/O pin and V<sub>DD</sub> is disabled, but still present.
- The 20 mA output drive requirement in Fast-mode Plus is not supported. This limits the maximum load C<sub>Load</sub> supported in Fm+, which is given by these formulas:

$$t_{r(SDA/SCL)} = 0.8473 \times R_P \times C_{Load}$$

$$R_{P(min)} = (V_{DD} - V_{OL(max)}) / I_{OL(max)}$$

Where R<sub>P</sub> is the I2C lines pull-up. Refer to [Section 7.3.15: I/O port characteristics](#) for the I<sup>2</sup>C I/Os characteristics.

All I<sup>2</sup>C SDA and SCL I/Os embed an analog filter. Refer to the table below for the analog filter characteristics:

**Table 192. I<sup>2</sup>C analog filter characteristics<sup>(1)</sup>**

| Symbol          | Parameter  | Min               | Max               | Unit |
|-----------------|--|-------------------|-------------------|------|
| t <sub>AF</sub> | Maximum pulse width of spikes that are suppressed by analog filter | 50 <sup>(2)</sup> | 80 <sup>(3)</sup> | ns   |

1. Guaranteed by characterization results.
2. Spikes with widths below t<sub>AF(min)</sub> are filtered.
3. Spikes with widths above t<sub>AF(max)</sub> are not filtered.

**USART (SPI mode) interface characteristics**

Unless otherwise specified, the parameters given in [Table 193](#) for USART are derived from tests performed under the ambient temperature, f<sub>PCLKx</sub> frequency and V<sub>DD</sub> supply voltage conditions summarized in [Table 111: General operating conditions](#), with the following configuration:

- Output speed is set to OSPEEDRy[1:0] = 10
- Capacitive load C<sub>L</sub> = 30 pF
- Measurement points are done at CMOS levels: 0.5V<sub>DD</sub>
- IO Compensation cell activated.
- VOS level set to VOS1

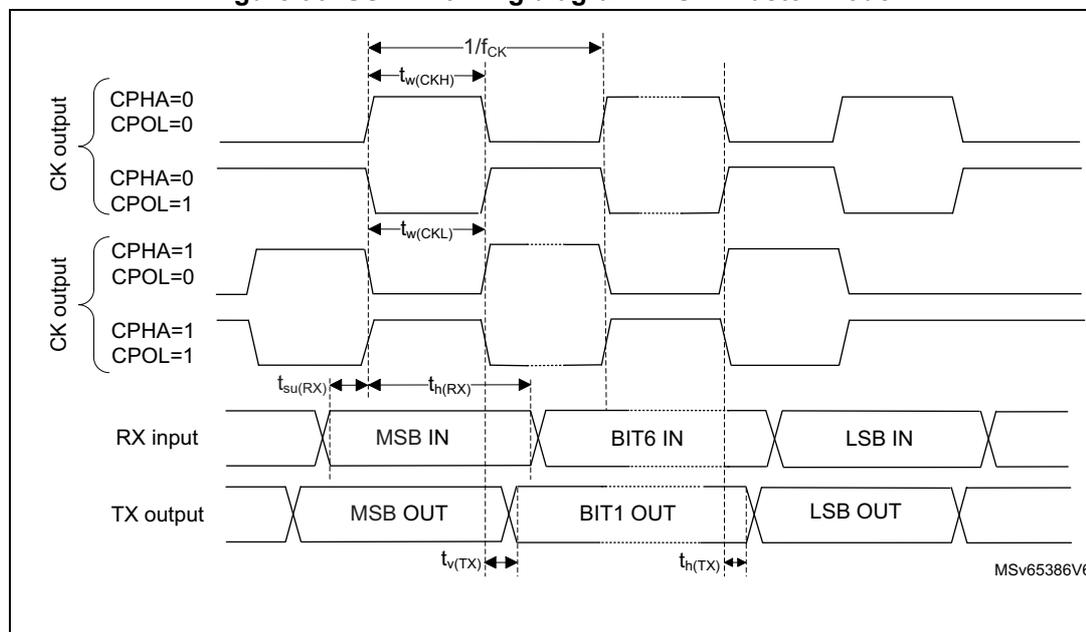
Refer to [Section 7.3.15: I/O port characteristics](#) for more details on the input/output alternate function characteristics (NSS, CK, TX, RX for USART).

**Table 193. USART (SPI mode) characteristics<sup>(1)</sup>**

| Symbol                                       | Parameter              | Conditions      | Min                    | Typ                  | Max                    | Unit |
|--|------------------------|-----------------|------------------------|----------------------|------------------------|------|
| f <sub>CK</sub>                              | USART clock frequency  | SPI master mode | -                      | -                    | 12.5                   | MHz  |
|  |                        | SPI slave mode  | -                      | -                    | 25                     |      |
| t <sub>su(NSS)</sub>                         | NSS setup time         | SPI slave mode  | t <sub>ker</sub> +1    | -                    | -                      | -    |
| t <sub>h(NSS)</sub>                          | NSS hold time          | SPI slave mode  | 2                      | -                    | -                      |      |
| t <sub>w(CKH)</sub> ,<br>t <sub>w(CKL)</sub> | CK high and low time   | SPI master mode | 1/f <sub>CK</sub> /2-2 | 1/f <sub>CK</sub> /2 | 1/f <sub>CK</sub> /2+2 |      |
| t <sub>su(RX)</sub>                          | Data input setup time  | SPI master mode | t <sub>ker</sub> +6    | -                    | -                      | ns   |
|  |                        | SPI slave mode  | 1.5                    | -                    | -                      |      |
| t <sub>h(RX)</sub>                           | Data input hold time   | SPI master mode | 0                      | -                    | -                      |      |
|  |                        | SPI slave mode  | 1.5                    | -                    | -                      |      |
| t <sub>v(TX)</sub>                           | Data output valid time | SPI slave mode  | -                      | 12                   | 20                     |      |
|  |                        | SPI master mode | -                      | 0.5                  | 1                      |      |
| t <sub>h(TX)</sub>                           | Data output hold time  | SPI slave mode  | 9                      | -                    | -                      |      |
|  |                        | SPI master mode | 0                      | -                    | -                      |      |

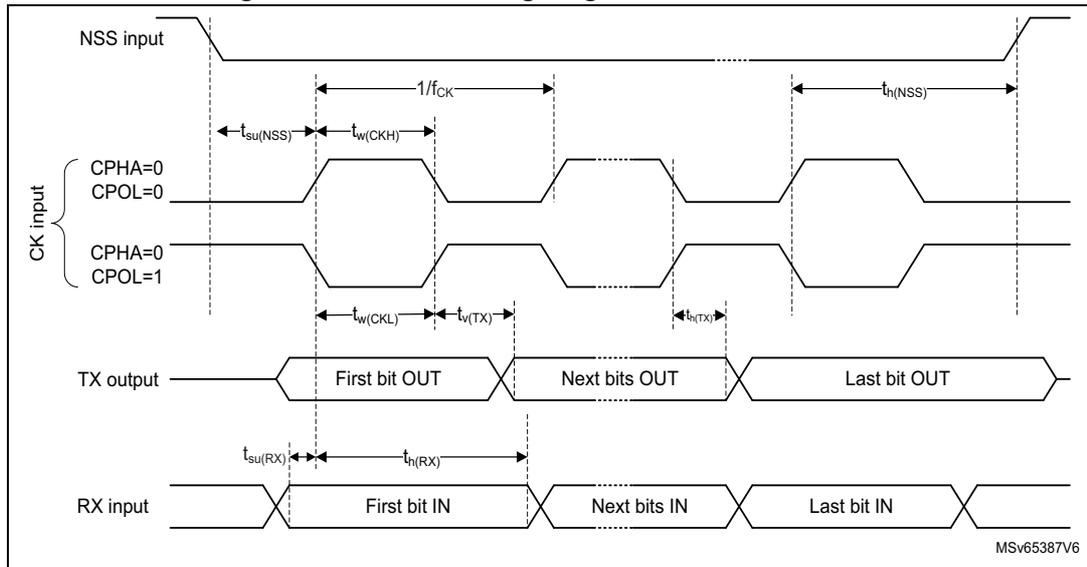
1. Guaranteed by characterization results.

**Figure 96. USART timing diagram in SPI master mode**



1. Measurement points are done at 0.5V<sub>DD</sub> and with external C<sub>L</sub> = 30 pF.

Figure 97. USART timing diagram in SPI slave mode



**SPI interface characteristics**

Unless otherwise specified, the parameters given in [Table 194](#) for SPI are derived from tests performed under the ambient temperature,  $f_{PCLKx}$  frequency and  $V_{DD}$  supply voltage conditions summarized in [Table 111: General operating conditions](#), with the following configuration:

- Output speed is set to  $OSPEEDRy[1:0] = 11$
- Capacitive load  $C_L = 30$  pF
- Measurement points are done at CMOS levels:  $0.5V_{DD}$
- IO Compensation cell activated.
- HSLV activated when  $V_{DD} \leq 2.7$  V
- VOS level set to VOS1

Refer to [Section 7.3.15: I/O port characteristics](#) for more details on the input/output alternate function characteristics (NSS, SCK, MOSI, MISO for SPI).

Table 194. SPI dynamic characteristics<sup>(1)</sup>

| Symbol                           | Parameter                | Conditions  | Min          | Typ        | Max          | Unit |
|----------------------------------|--------------------------|---|--------------|------------|--------------|------|
| $f_{SCK}$                        | SPI clock frequency      | Master mode<br>1.62 < $V_{DD}$ < 3.6 V<br>SPI1, 2, 3          | -            | -          | 80           | MHz  |
|                                  |                          | Master mode<br>2.7 < $V_{DD}$ < 3.6 V<br>SPI1, 2, 3           |              |            | 100          |      |
|                                  |                          | Master mode<br>1.62 < $V_{DD}$ < 3.6 V<br>SPI4, 5, 6          |              |            | 50           |      |
|                                  |                          | Slave receiver mode<br>1.62 < $V_{DD}$ < 3.6 V                |              |            | 100          |      |
|                                  |                          | Slave mode transmitter/full duplex<br>2.7 < $V_{DD}$ < 3.6 V  |              |            | 31           |      |
|                                  |                          | Slave mode transmitter/full duplex<br>1.62 < $V_{DD}$ < 3.6 V |              |            | 29           |      |
| $t_{su(NSS)}$                    | NSS setup time           | Slave mode  | 2            | -          | -            | -    |
| $t_{h(NSS)}$                     | NSS hold time            | Slave mode  | 1            | -          | -            |      |
| $t_{w(SCKH)}$ ,<br>$t_{w(SCKL)}$ | SCK high and low time    | Master mode   | $T_{PCLK}-2$ | $T_{PCLK}$ | $T_{PCLK}+2$ |      |
| $t_{su(MI)}$                     | Data input setup time    | Master mode   | 2            | -          | -            | ns   |
| $t_{su(SI)}$                     |                          | Slave mode  | 1            | -          | -            |      |
| $t_{h(MI)}$                      | Data input hold time     | Master mode   | 3            | -          | -            |      |
| $t_{h(SI)}$                      |                          | Slave mode  | 2            | -          | -            |      |
| $t_{a(SO)}$                      | Data output access time  | Slave mode  | 9            | 13         | 27           |      |
| $t_{dis(SO)}$                    | Data output disable time | Slave mode  | 0            | 1          | 5            |      |
| $t_{v(SO)}$                      | Data output valid time   | Slave mode<br>2.7 < $V_{DD}$ < 3.6 V                          | -            | 12.5       | 16           |      |
|                                  |                          | Slave mode<br>1.62 < $V_{DD}$ < 3.6 V                         | -            | 12.5       | 17           |      |
| $t_{v(MO)}$                      |                          | Master mode   | -            | 1          | 3            |      |
| $t_{h(SO)}$                      | Data output hold time    | Slave mode<br>1.62 < $V_{DD}$ < 3.6 V                         | 10           | -          | -            |      |
| $t_{h(MO)}$                      |                          | Master mode   | 0            | -          | -            |      |

1. Guaranteed by characterization results.

Figure 98. SPI timing diagram - slave mode and CPHA = 0

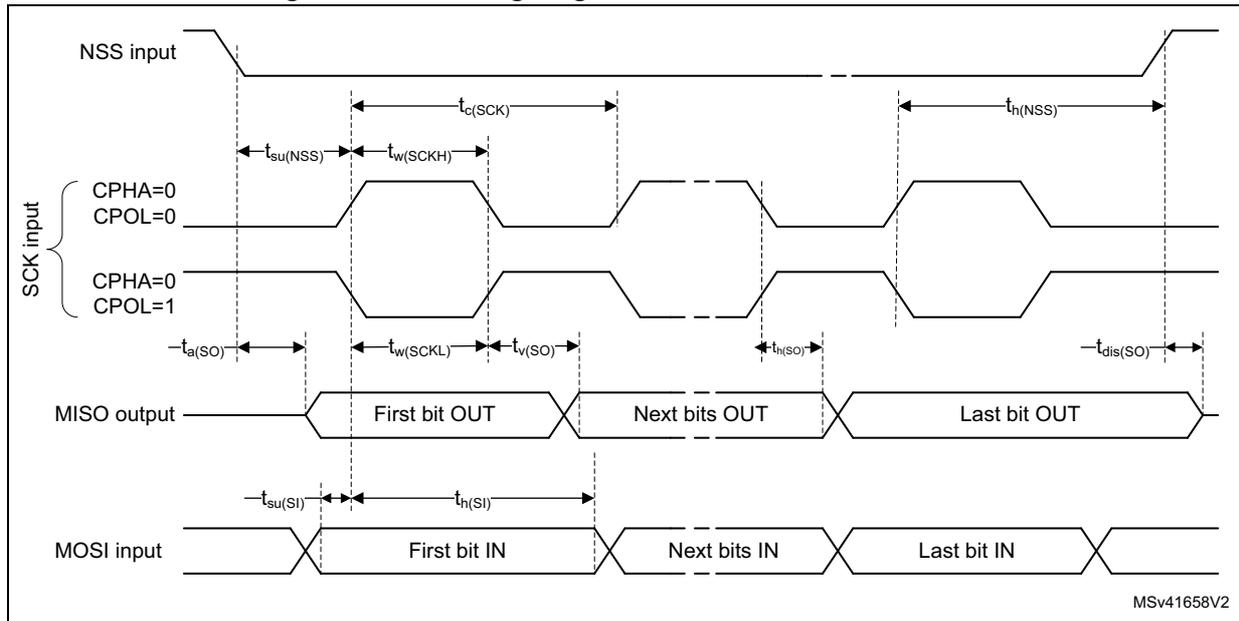


Figure 99. SPI timing diagram - slave mode and CPHA = 1

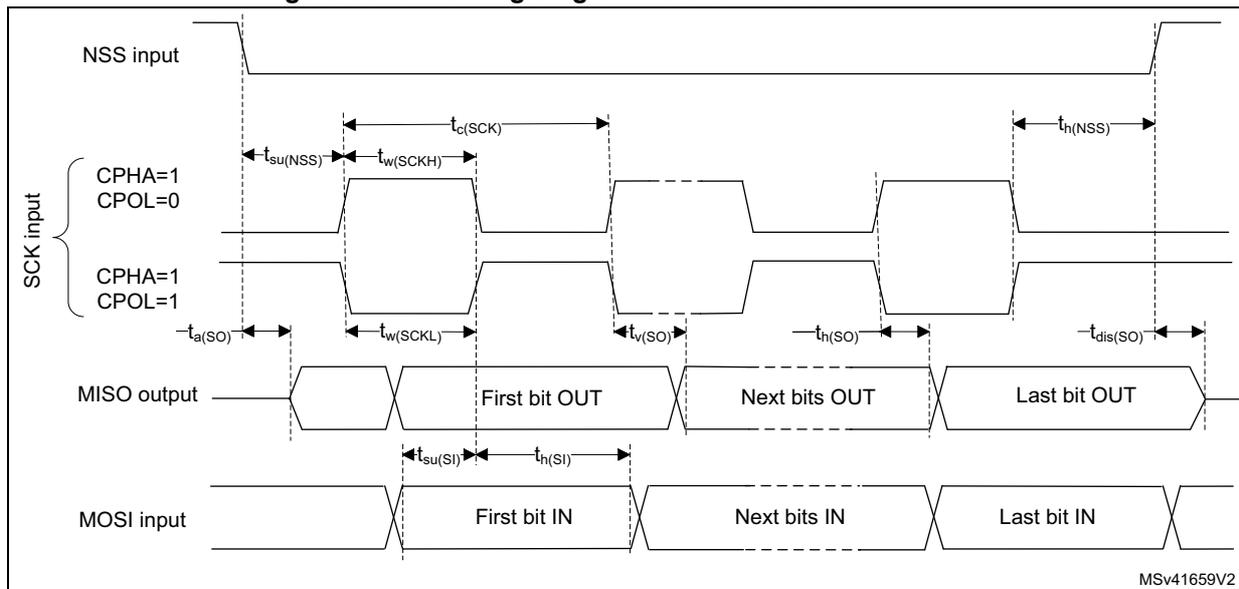
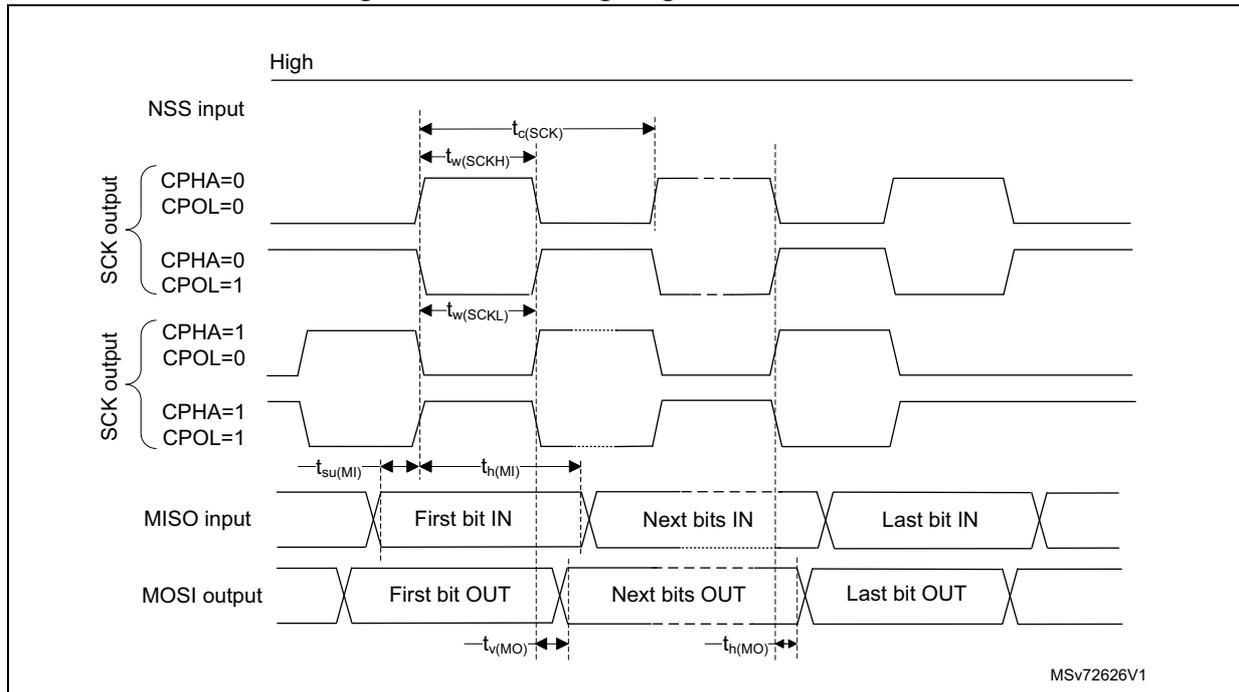


Figure 100. SPI timing diagram - master mode



### I<sup>2</sup>S Interface characteristics

Unless otherwise specified, the parameters given in [Table 195](#) for I<sup>2</sup>S are derived from tests performed under the ambient temperature,  $f_{PCLKx}$  frequency and  $V_{DD}$  supply voltage conditions summarized in [Table 111: General operating conditions](#), with the following configuration:

- Output speed is set to OSPEEDRy[1:0] = 10
- Capacitive load  $C_L = 30$  pF
- Measurement points are done at CMOS levels:  $0.5V_{DD}$
- IO Compensation cell activated.
- HSLV activated when  $V_{DD} \leq 2.7$  V
- VOS level set to VOS1

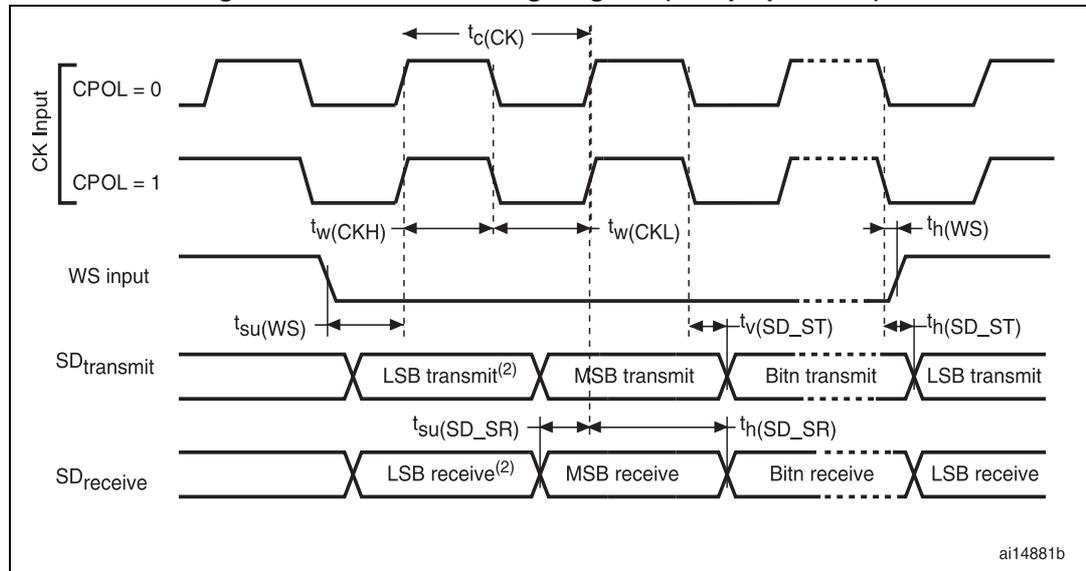
Refer to [Section 7.3.15: I/O port characteristics](#) for more details on the input/output alternate function characteristics (CK,SD,WS).

Table 195. I<sup>2</sup>S dynamic characteristics<sup>(1)</sup>

| Symbol                 | Parameter                          | Conditions                             | Min    | Max               | Unit |
|------------------------|------------------------------------|--|--------|-------------------|------|
| f <sub>MCK</sub>       | I <sup>2</sup> S main clock output | -                                      | 256x8K | 256F <sub>S</sub> | MHz  |
| f <sub>CK</sub>        | I <sup>2</sup> S clock frequency   | Master data                            | -      | 64F <sub>S</sub>  | MHz  |
|                        |                                    | Slave data                             | -      | 64F <sub>S</sub>  |      |
| t <sub>v(WS)</sub>     | WS valid time                      | Master mode                            | -      | 3                 | ns   |
| t <sub>h(WS)</sub>     | WS hold time                       | Master mode                            | 0      | -                 |      |
| t <sub>su(WS)</sub>    | WS setup time                      | Slave mode                             | 1      | -                 |      |
| t <sub>h(WS)</sub>     | WS hold time                       | Slave mode                             | 1      | -                 |      |
| t <sub>su(SD_MR)</sub> | Data input setup time              | Master receiver                        | 1      | -                 |      |
| t <sub>su(SD_SR)</sub> |                                    | Slave receiver                         | 1      | -                 |      |
| t <sub>h(SD_MR)</sub>  | Data input hold time               | Master receiver                        | 4      | -                 |      |
| t <sub>h(SD_SR)</sub>  |                                    | Slave receiver                         | 2      | -                 |      |
| t <sub>v(SD_ST)</sub>  | Data output valid time             | Slave transmitter (after enable edge)  | -      | 17                |      |
| t <sub>v(SD_MT)</sub>  |                                    | Master transmitter (after enable edge) | -      | 3                 |      |
| t <sub>h(SD_ST)</sub>  | Data output hold time              | Slave transmitter (after enable edge)  | 9      | -                 |      |
| t <sub>h(SD_MT)</sub>  |                                    | Master transmitter (after enable edge) | 0      | -                 |      |

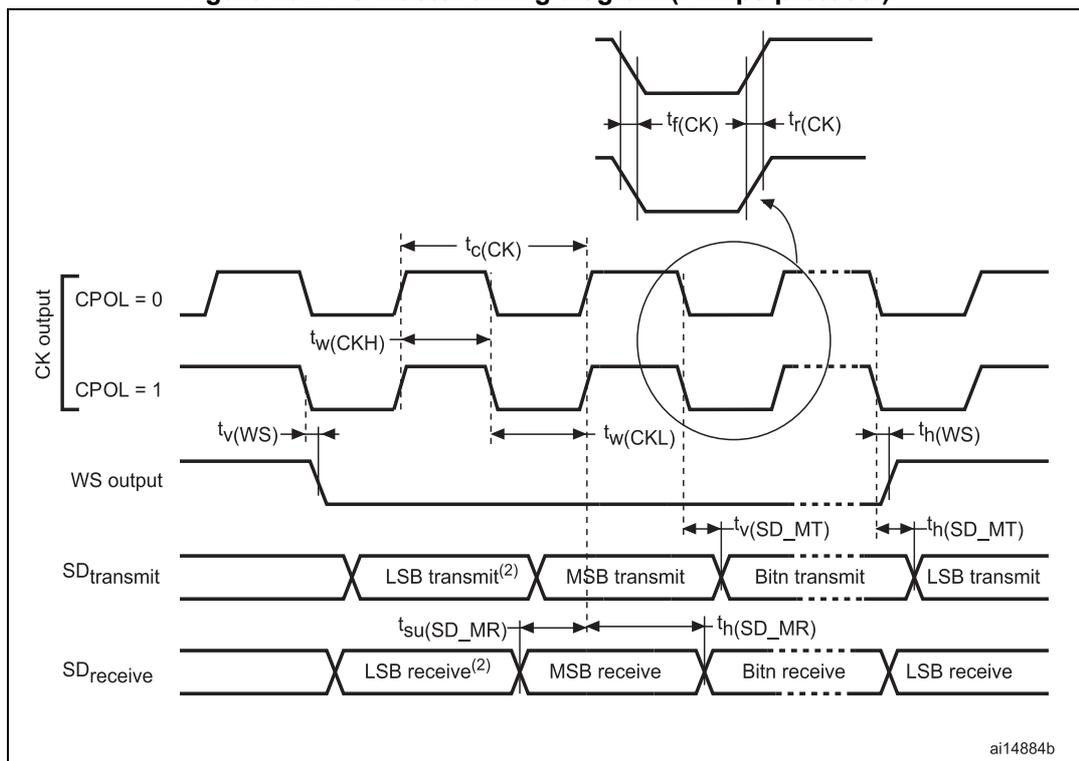
1. Guaranteed by characterization results.

Figure 101. I<sup>2</sup>S slave timing diagram (Philips protocol)<sup>(1)</sup>



1. LSB transmit/receive of the previously transmitted byte. No LSB transmit/receive is sent before the first byte.

Figure 102. I<sup>2</sup>S master timing diagram (Philips protocol)<sup>(1)</sup>



1. LSB transmit/receive of the previously transmitted byte. No LSB transmit/receive is sent before the first byte.

### SAI characteristics

Unless otherwise specified, the parameters given in [Table 196](#) for SAI are derived from tests performed under the ambient temperature,  $f_{PCLKx}$  frequency and VDD supply voltage conditions summarized in [Table 111: General operating conditions](#), with the following configuration:

- Output speed is set to OSPEEDRy[1:0] = 10
- Capacitive load  $C_L = 30$  pF
- IO Compensation cell activated.
- Measurement points are done at CMOS levels: 0.5VDD
- VOS level set to VOS1.

Refer to [Section 7.3.15: I/O port characteristics](#) for more details on the input/output alternate function characteristics (SCK,SD,WS).

Table 196. SAI characteristics<sup>(1)</sup>

| Symbol    | Parameter                          | Conditions           | Min    | Max                    | Unit |
|-----------|------------------------------------|----------------------|--------|------------------------|------|
| $f_{MCK}$ | SAI Main clock output              | -                    | 256x8K | $256 \times f_S$       | MHz  |
| $f_{CK}$  | SAI clock frequency <sup>(2)</sup> | Master Data: 32 bits | -      | $128 \times f_S^{(3)}$ |      |
|           |                                    | Slave Data: 32 bits  | -      | $128 \times f_S^{(3)}$ |      |

Table 196. SAI characteristics<sup>(1)</sup> (continued)

| Symbol                   | Parameter                 | Conditions   | Min | Max | Unit |
|--------------------------|---------------------------|--|-----|-----|------|
| t <sub>v(FS)</sub>       | F <sub>S</sub> valid time | Master mode<br>2.7 ≤ V <sub>DD</sub> ≤ 3.6                             | -   | 13  | ns   |
|                          |                           | Master mode<br>1.62 ≤ V <sub>DD</sub> ≤ 3.6                            | -   | 20  |      |
| t <sub>su(FS)</sub>      | F <sub>S</sub> hold time  | Master mode  | 8   | -   |      |
| t <sub>h(FS)</sub>       | F <sub>S</sub> setup time | Slave mode   | 1   | -   |      |
|                          | F <sub>S</sub> hold time  | Slave mode   | 1   | -   |      |
| t <sub>su(SD_A_MR)</sub> | Data input setup time     | Master receiver  | 0.5 | -   |      |
| t <sub>su(SD_B_SR)</sub> |                           | Slave receiver   | 1   | -   |      |
| t <sub>h(SD_A_MR)</sub>  | Data input hold time      | Master receiver  | 3.5 | -   |      |
| t <sub>h(SD_B_SR)</sub>  |                           | Slave receiver   | 2   | -   |      |
| t <sub>v(SD_B_ST)</sub>  | Data output valid time    | Slave transmitter (after enable edge)<br>2.7 ≤ V <sub>DD</sub> ≤ 3.6   | -   | 14  |      |
|                          |                           | Slave transmitter (after enable edge)<br>1.62 ≤ V <sub>DD</sub> ≤ 3.6  | -   | 20  |      |
| t <sub>h(SD_B_ST)</sub>  | Data output hold time     | Slave transmitter (after enable edge)                                  | 9   | -   |      |
| t <sub>v(SD_A_MT)</sub>  | Data output valid time    | Master transmitter (after enable edge)<br>2.7 ≤ V <sub>DD</sub> ≤ 3.6  | -   | 12  |      |
|                          |                           | Master transmitter (after enable edge)<br>1.62 ≤ V <sub>DD</sub> ≤ 3.6 | -   | 19  |      |
| t <sub>h(SD_A_MT)</sub>  | Data output hold time     | Master transmitter (after enable edge)                                 | 7.5 | -   |      |

1. Guaranteed by characterization results.
2. APB clock frequency must be at least twice SAI clock frequency.
3. With F<sub>S</sub>=192 kHz.

Figure 103. SAI master timing waveforms

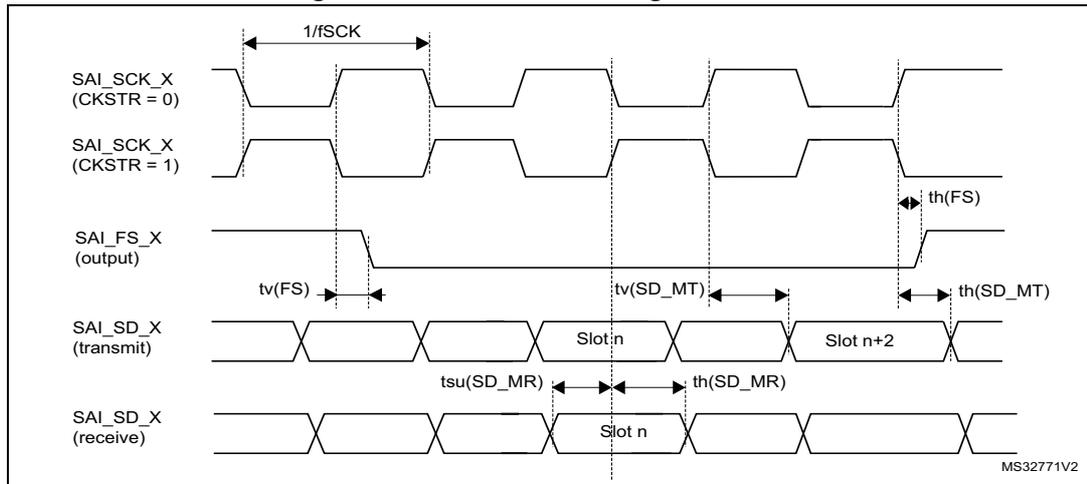
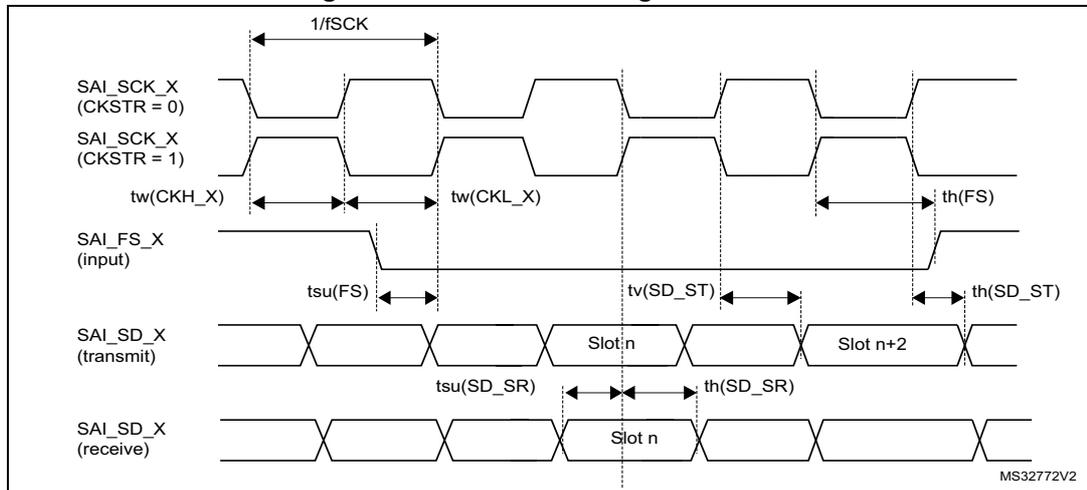


Figure 104. SAI slave timing waveforms

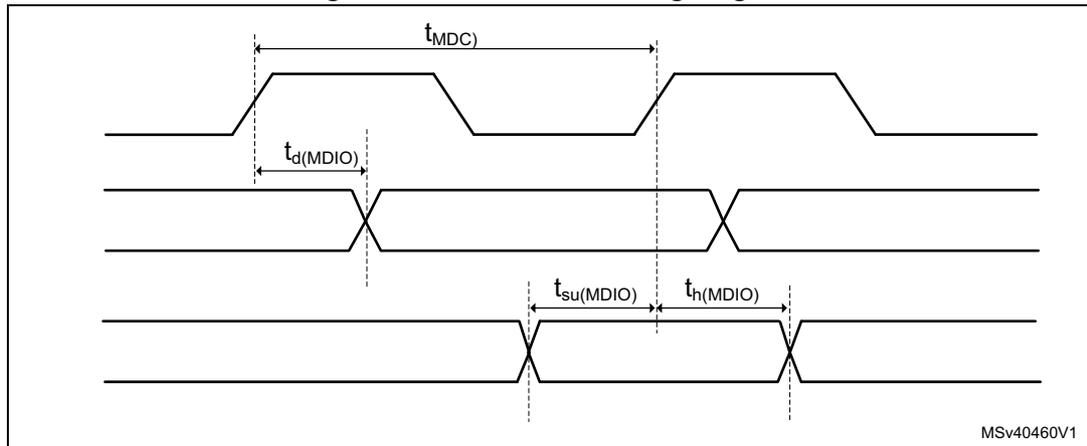


MDIO characteristics

Table 197. MDIO Slave timing parameters

| Symbol         | Parameter                                      | Min | Typ | Max | Unit |
|----------------|--|-----|-----|-----|------|
| $F_{MDC}$      | Management Data Clock                          | -   | -   | 30  | MHz  |
| $t_d(MDIO)$    | Management Data Input/output output valid time | 8   | 10  | 19  | ns   |
| $t_{su}(MDIO)$ | Management Data Input/output setup time        | 1   | -   | -   |      |
| $t_h(MDIO)$    | Management Data Input/output hold time         | 1   | -   | -   |      |

Figure 105. MDIO Slave timing diagram



**SD/SDIO MMC card host interface (SDMMC) characteristics**

Unless otherwise specified, the parameters given in [Table 198](#) and [Table 199](#) for SDIO are derived from tests performed under the ambient temperature,  $f_{PCLKx}$  frequency and VDD supply voltage summarized in [Table 111: General operating conditions](#), with the following configuration:

- Output speed is set to OSPEEDRy[1:0] = 0x11
- Capacitive load  $C_L=30$  pF
- Measurement points are done at CMOS levels:  $0.5V_{DD}$
- IO Compensation cell activated.
- HSLV activated when  $V_{DD} \leq 2.7$  V
- VOS level set to VOS1

Refer to [Section 7.3.15: I/O port characteristics](#) for more details on the input/output characteristics.

**Table 198. Dynamics characteristics: SD / MMC characteristics,  $V_{DD} = 2.7$  to  $3.6$  V<sup>(1)(2)</sup>**

| Symbol  | Parameter                             | Conditions              | Min | Typ | Max | Unit |
|---|---------------------------------------|-------------------------|-----|-----|-----|------|
| $f_{PP}$  | Clock frequency in data transfer mode | -                       | 0   | -   | 133 | MHz  |
| -   | SDIO_CK/fPCLK2 frequency ratio        | -                       | -   | -   | 8/3 | -    |
| $t_{W(CKL)}$  | Clock low time                        | $f_{PP} = 52\text{MHz}$ | 8.5 | 9.5 | -   | ns   |
| $t_{W(CKH)}$  | Clock high time                       | $f_{PP} = 52\text{MHz}$ | 8.5 | 9.5 | -   |      |
| <b>CMD, D inputs (referenced to CK) in eMMC legacy/SDR/DDR and SD HS/SDR<sup>(3)</sup>/DDR<sup>(3)</sup> mode</b> |                                       |                         |     |     |     |      |
| $t_{ISU}$   | Input setup time HS                   | -                       | 2.5 | -   | -   | ns   |
| $t_{IH}$  | Input hold time HS                    | -                       | 0.5 | -   | -   |      |
| $t_{IDW}^{(4)}$   | Input valid window (variable window)  | -                       | 3   | -   | -   | -    |
| <b>CMD, D outputs (referenced to CK) in eMMC legacy/SDR/DDR and SD HS/SDR/DDR<sup>(3)</sup> mode</b>              |                                       |                         |     |     |     |      |
| $t_{OV}$  | Output valid time HS                  | -                       | -   | 3.5 | 5   | ns   |
| $t_{OH}$  | Output hold time HS                   | -                       | 3   | -   | -   |      |

**Table 198. Dynamics characteristics: SD / MMC characteristics,  $V_{DD} = 2.7$  to  $3.6$  V<sup>(1)(2)</sup> (continued)**

| Symbol  | Parameter                    | Conditions | Min | Typ | Max | Unit |
|---|------------------------------|------------|-----|-----|-----|------|
| <b>CMD, D inputs (referenced to CK) in SD default mode</b>  |                              |            |     |     |     |      |
| $t_{ISUD}$  | Input setup time SD          | -          | 2.5 | -   | -   | ns   |
| $t_{IHD}$   | Input hold time SD           | -          | 0.5 | -   | -   |      |
| <b>CMD, D outputs (referenced to CK) in SD default mode</b> |                              |            |     |     |     |      |
| $t_{OVD}$   | Output valid default time SD | -          | -   | 0.5 | 2   | ns   |
| $t_{OHD}$   | Output hold default time SD  | -          | 0   | -   | -   |      |

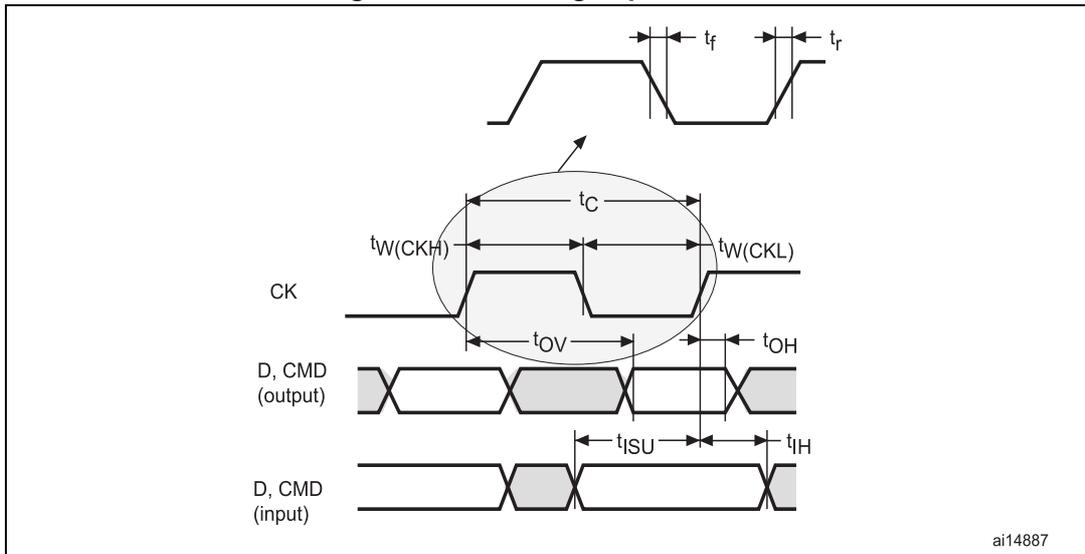
1. Guaranteed by characterization results.
2. Above 100 MHz,  $C_L = 20$  pF.
3. An external voltage converter is required to support SD 1.8 V.
4. The minimum window of time where the data needs to be stable for proper sampling in tuning mode.

**Table 199. Dynamics characteristics: eMMC characteristics  $V_{DD} = 1.71$ V to  $1.9$ V<sup>(1)(2)</sup>**

| Symbol  | Parameter                             | Conditions        | Min | Typ | Max | Unit |
|---|---------------------------------------|-------------------|-----|-----|-----|------|
| $f_{PP}$  | Clock frequency in data transfer mode | -                 | 0   | -   | 120 | MHz  |
| -   | SDIO_CK/fPCLK2 frequency ratio        | -                 | -   | -   | 8/3 | -    |
| $t_{W(CKL)}$  | Clock low time                        | $f_{PP} = 52$ MHz | 8.5 | 9.5 | -   | ns   |
| $t_{W(CKH)}$  | Clock high time                       | $f_{PP} = 52$ MHz | 8.5 | 9.5 | -   |      |
| <b>CMD, D inputs (referenced to CK) in eMMC mode</b>  |                                       |                   |     |     |     |      |
| $t_{ISU}$   | Input setup time HS                   | -                 | 2   | -   | -   | ns   |
| $t_{IH}$  | Input hold time HS                    | -                 | 1.5 | -   | -   |      |
| $t_{IDW}^{(3)}$                                       | Input valid window (variable window)  | -                 | 3.5 | -   | -   |      |
| <b>CMD, D outputs (referenced to CK) in eMMC mode</b> |                                       |                   |     |     |     |      |
| $t_{OVD}$   | Output valid time HS                  | -                 | -   | 5   | 7   | ns   |
| $t_{OHD}$   | Output hold time HS                   | -                 | 3   | -   | -   |      |

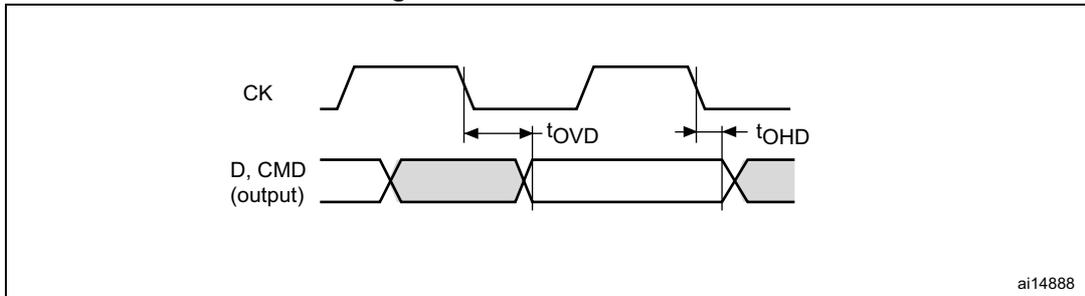
1. Guaranteed by characterization results.
2.  $C_L = 20$  pF.
3. The minimum window of time where the data needs to be stable for proper sampling in tuning mode.

Figure 106. SDIO high-speed mode



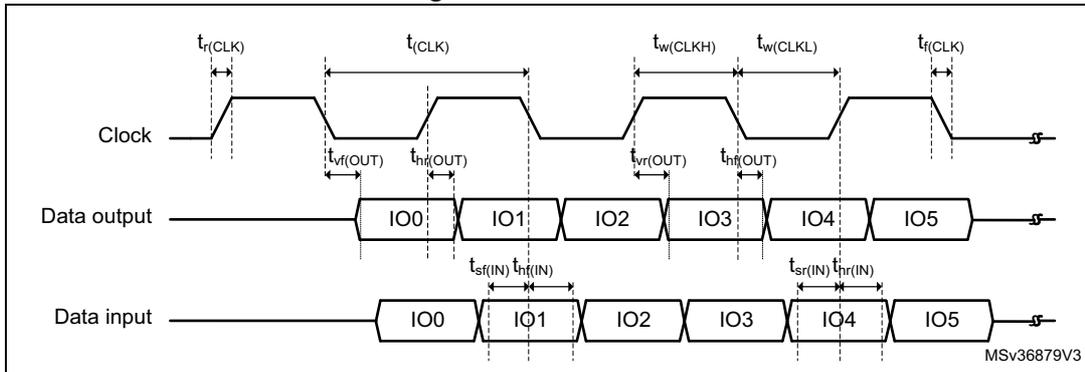
ai14887

Figure 107. SD default mode



ai14888

Figure 108. DDR mode



MSv36879V3

### USB OTG\_FS characteristics

The USB interface is fully compliant with the USB specification version 2.0 and is USB-IF certified (for Full-speed device operation).

**Table 200. USB OTG\_FS electrical characteristics**

| Symbol               | Parameter                                      | Condition           | Min                | Typ  | Max  | Unit |
|----------------------|--|---------------------|--------------------|------|------|------|
| V <sub>DD33USB</sub> | USB transceiver operating voltage              | -                   | 3.0 <sup>(1)</sup> | -    | 3.6  | V    |
| R <sub>PUI</sub>     | Embedded USB_DP pull-up value during idle      | -                   | 900                | 1250 | 1600 | Ω    |
| R <sub>PUR</sub>     | Embedded USB_DP pull-up value during reception | -                   | 1400               | 2300 | 3200 |      |
| Z <sub>DRV</sub>     | Output driver impedance <sup>(2)</sup>         | Driver high and low | 28                 | 36   | 44   |      |

- The USB functionality is ensured down to 2.7 V but not the full USB electrical characteristics which are degraded in the 2.7 to 3.0 V voltage range.
- No external termination series resistors are required on USB\_DP (D+) and USB\_DM (D-); the matching impedance is already included in the embedded driver.

### USB OTG\_HS characteristics

Unless otherwise specified, the parameters given in [Table 201](#) for ULPI are derived from tests performed under the ambient temperature, f<sub>PCLKx</sub> frequency and V<sub>DD</sub> supply voltage summarized in [Table 111: General operating conditions](#), with the following configuration:

- Output speed is set to OSPEEDRy[1:0] = 11
- Capacitive load C<sub>L</sub> = 20 pF
- Measurement points are done at CMOS levels: 0.5V<sub>DD</sub>
- IO Compensation cell activated.
- VOS level set to VOS1

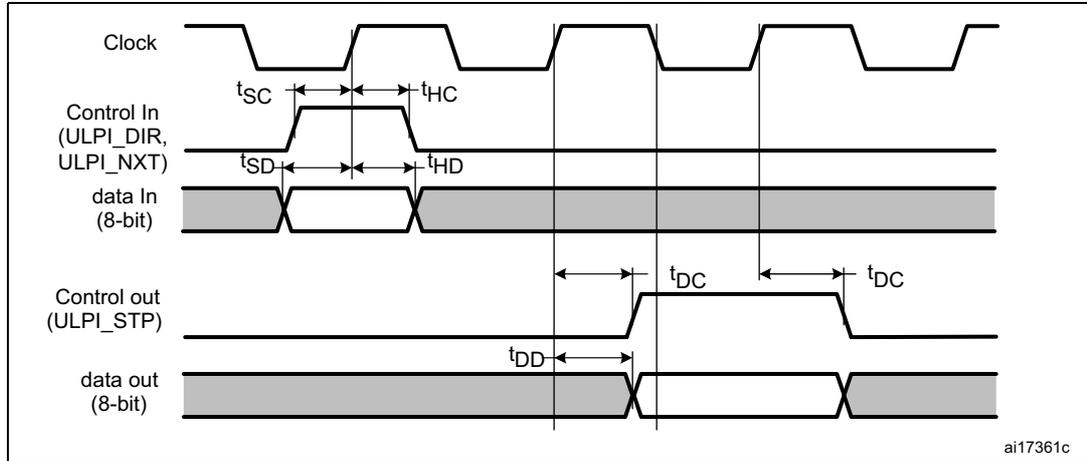
Refer to [Section 7.3.15: I/O port characteristics](#) for more details on the input/output characteristics.

**Table 201. Dynamics characteristics: USB ULPI<sup>(1)</sup>**

| Symbol                           | Parameter                                  | Condition  | Min                | Typ | Max | Unit |
|----------------------------------|--|--|--------------------|-----|-----|------|
| t <sub>SC</sub>                  | Control in (ULPI_DIR, ULPI_NXT) setup time | -  | 2.5                | -   | -   | ns   |
|                                  |  | -  | 4.5 <sup>(2)</sup> | -   | -   |      |
| t <sub>HC</sub>                  | Control in (ULPI_DIR, ULPI_NXT) hold time  | -  | 2                  | -   | -   |      |
| t <sub>SD</sub>                  | Data in setup time                         | -  | 2.5                | -   | -   |      |
| t <sub>HD</sub>                  | Data in hold time                          | -  | 0                  | -   | -   |      |
| t <sub>DC</sub> /t <sub>DD</sub> | Control/Data output delay                  | 2.7 < V <sub>DD</sub> < 3.6 V<br>C <sub>L</sub> = 20 pF  | -                  | 9   | 9.5 |      |
|                                  |  | 1.71 < V <sub>DD</sub> < 3.6 V<br>C <sub>L</sub> = 15 pF | -                  | 9   | 14  |      |

1. Guaranteed by characterization results.
2. When using PC2\_C/PC3\_C.

Figure 109. ULPI timing diagram



**Ethernet interface characteristics**

Unless otherwise specified, the parameters given in [Table 202](#), [Table 203](#) and [Table 204](#) for SMI, RMII and MII are derived from tests performed under the ambient temperature,  $f_{rcc\_c\_ck}$  frequency and  $V_{DD}$  supply voltage conditions summarized in [Table 111: General operating conditions](#), with the following configuration:

- Output speed is set to OSPEEDRy[1:0] = 10
- Capacitive load  $C_L = 20$  pF
- Measurement points are done at CMOS levels:  $0.5V_{DD}$
- IO Compensation cell activated.
- HSLV activated when  $V_{DD} \leq 2.7$  V
- VOS level set to VOS1

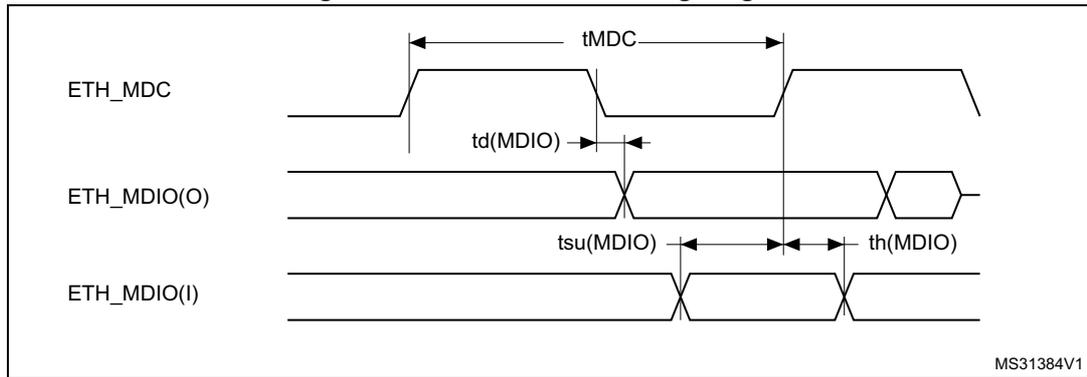
Refer to [Section 7.3.15: I/O port characteristics](#) for more details on the input/output characteristics:

**Table 202. Dynamics characteristics: Ethernet MAC signals for SMI <sup>(1)</sup>**

| Symbol         | Parameter                | Min  | Typ | Max | Unit |
|----------------|--------------------------|------|-----|-----|------|
| $t_{MDC}$      | MDC cycle time( 2.5 MHz) | 400  | 400 | 403 | ns   |
| $T_d(MDIO)$    | Write data valid time    | 0.5  | 1.5 | 4   |      |
| $t_{su}(MDIO)$ | Read data setup time     | 12.5 | -   | -   |      |
| $t_h(MDIO)$    | Read data hold time      | 0    | -   | -   |      |

1. Guaranteed by characterization results.

Figure 110. Ethernet SMI timing diagram



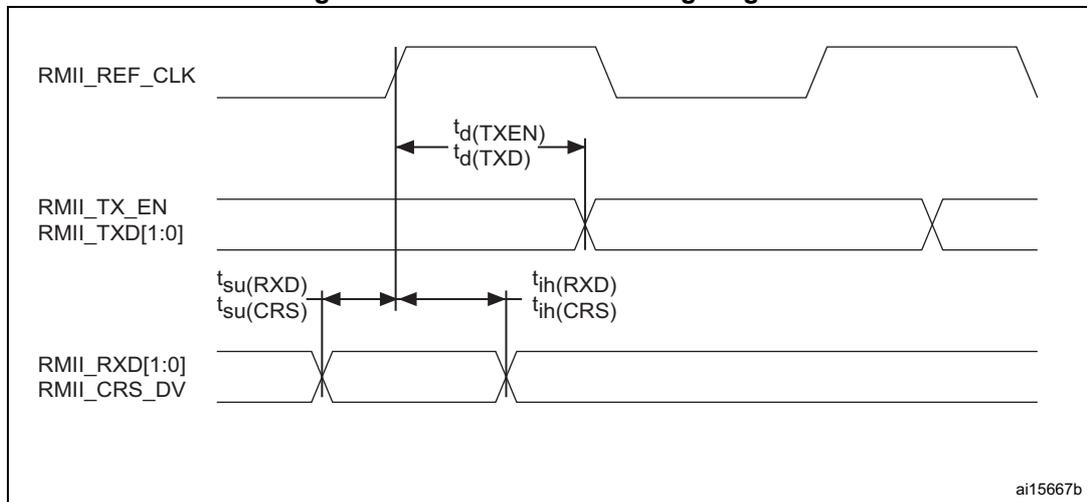
MS31384V1

Table 203. Dynamics characteristics: Ethernet MAC signals for RMII (1)

| Symbol        | Parameter                        | Min | Typ | Max | Unit |
|---------------|----------------------------------|-----|-----|-----|------|
| $t_{su}(RXD)$ | Receive data setup time          | 2   | -   | -   | ns   |
| $t_{ih}(RXD)$ | Receive data hold time           | 2   | -   | -   |      |
| $t_{su}(CRS)$ | Carrier sense setup time         | 1.5 | -   | -   |      |
| $t_{ih}(CRS)$ | Carrier sense hold time          | 1.5 | -   | -   |      |
| $t_d(TXEN)$   | Transmit enable valid delay time | 7   | 8   | 9.5 |      |
| $t_d(TXD)$    | Transmit data valid delay time   | 8   | 9   | 11  |      |

1. Guaranteed by characterization results.

Figure 111. Ethernet RMII timing diagram



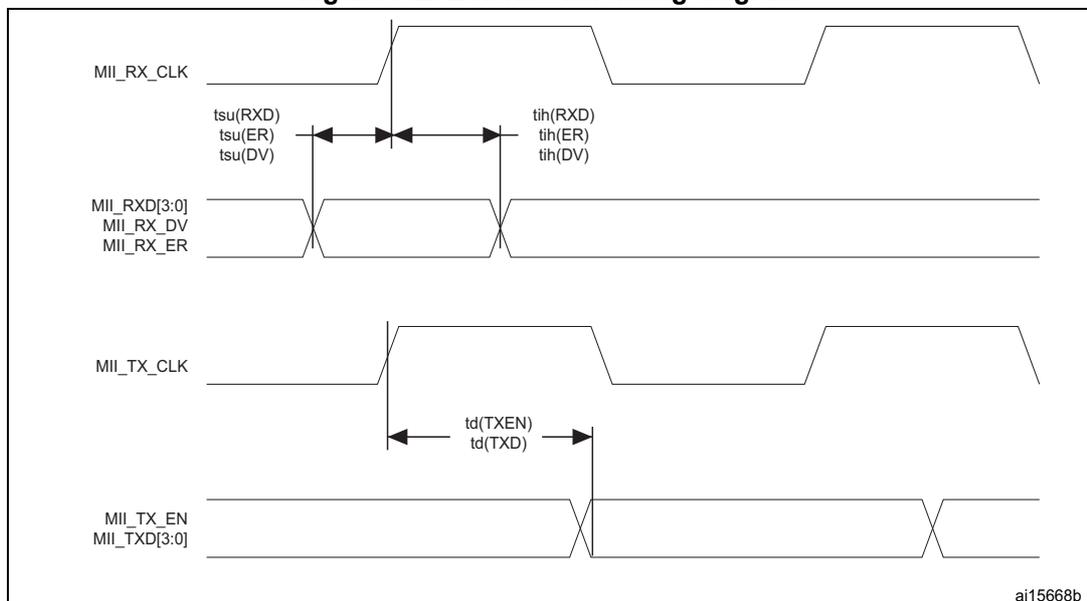
ai15667b

**Table 204. Dynamics characteristics: Ethernet MAC signals for MII (1)**

| Symbol        | Parameter                        | Min | Typ | Max  | Unit |
|---------------|----------------------------------|-----|-----|------|------|
| $t_{su}(RXD)$ | Receive data setup time          | 2   | -   | -    | ns   |
| $t_{ih}(RXD)$ | Receive data hold time           | 2   | -   | -    |      |
| $t_{su}(DV)$  | Data valid setup time            | 1.5 | -   | -    |      |
| $t_{ih}(DV)$  | Data valid hold time             | 1.5 | -   | -    |      |
| $t_{su}(ER)$  | Error setup time                 | 1.5 | -   | -    |      |
| $t_{ih}(ER)$  | Error hold time                  | 0.5 | -   | -    |      |
| $t_d(TXEN)$   | Transmit enable valid delay time | 9   | 10  | 11   |      |
| $t_d(TXD)$    | Transmit data valid delay time   | 8.5 | 9.5 | 12.5 |      |

1. Guaranteed by characterization results.

**Figure 112. Ethernet MII timing diagram**



**JTAG/SWD interface characteristics**

Unless otherwise specified, the parameters given in [Table 205](#) and [Table 206](#) for JTAG/SWD are derived from tests performed under the ambient temperature,  $f_{rcc\_c\_ck}$  frequency and  $V_{DD}$  supply voltage summarized in [Table 111: General operating conditions](#), with the following configuration:

- Output speed is set to  $OSPEEDRy[1:0] = 0x10$
- Capacitive load  $C_L = 30$  pF
- Measurement points are done at CMOS levels:  $0.5V_{DD}$
- VOS level set to VOS1

Refer to [Section 7.3.15: I/O port characteristics](#) for more details on the input/output characteristics:

**Table 205. Dynamics JTAG characteristics**

| Symbol         | Parameter                | Conditions              | Min | Typ | Max  | Unit |
|----------------|--------------------------|-------------------------|-----|-----|------|------|
| $F_{pp}$       | $T_{CK}$ clock frequency | $2.7V < V_{DD} < 3.6 V$ | -   | -   | 37   | MHz  |
| $1/t_c(TCK)$   |                          | $1.62 < V_{DD} < 3.6 V$ | -   | -   | 27.5 |      |
| $t_{isu}(TMS)$ | TMS input setup time     | -                       | 2.5 | -   | -    |      |
| $t_{ih}(TMS)$  | TMS input hold time      | -                       | 1   | -   | -    |      |
| $t_{isu}(TDI)$ | TDI input setup time     | -                       | 1.5 | -   | -    | -    |
| $t_{ih}(TDI)$  | TDI input hold time      | -                       | 1   | -   | -    | -    |
| $t_{ov}(TDO)$  | TDO output valid time    | $2.7V < V_{DD} < 3.6 V$ | -   | 8   | 13.5 | -    |
|                |                          | $1.62 < V_{DD} < 3.6 V$ | -   | 8   | 18   | -    |
| $t_{oh}(TDO)$  | TDO output hold time     | -                       | 7   | -   | -    | -    |

**Table 206. Dynamics SWD characteristics:**

| Symbol           | Parameter               | Conditions              | Min | Typ | Max  | Unit |
|------------------|-------------------------|-------------------------|-----|-----|------|------|
| $F_{pp}$         | SWCLK clock frequency   | $2.7V < V_{DD} < 3.6 V$ | -   | -   | 71   | MHz  |
| $1/t_c(SWCLK)$   |                         | $1.62 < V_{DD} < 3.6 V$ | -   | -   | 52.5 |      |
| $t_{isu}(SWDIO)$ | SWDIO input setup time  | -                       | 2.5 | -   | -    | ns   |
| $t_{ih}(SWDIO)$  | SWDIO input hold time   | -                       | 1   | -   | -    |      |
| $t_{ov}(SWDIO)$  | SWDIO output valid time | $2.7V < V_{DD} < 3.6 V$ | -   | 8.5 | 14   |      |
|                  |                         | $1.62 < V_{DD} < 3.6 V$ | -   | 8.5 | 19   |      |
| $t_{oh}(SWDIO)$  | SWDIO output hold time  | -                       | 8   | -   | -    |      |

**Figure 113. JTAG timing diagram**

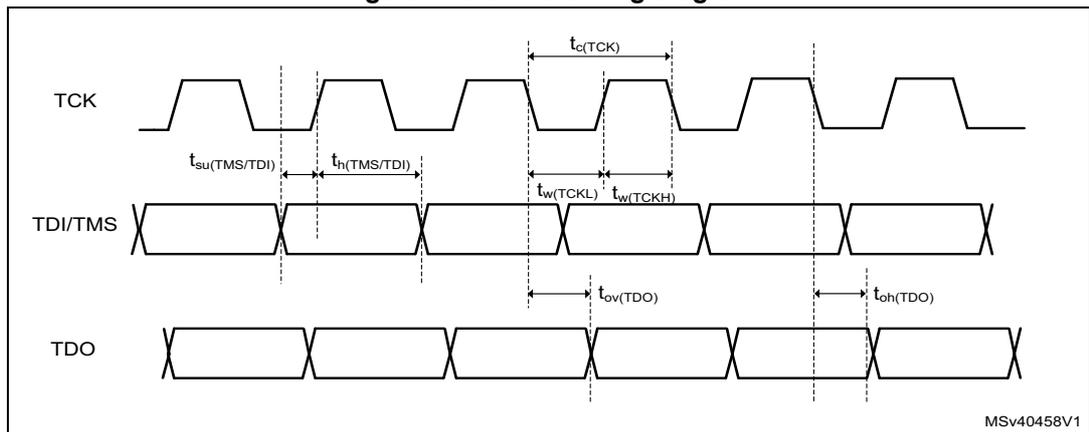
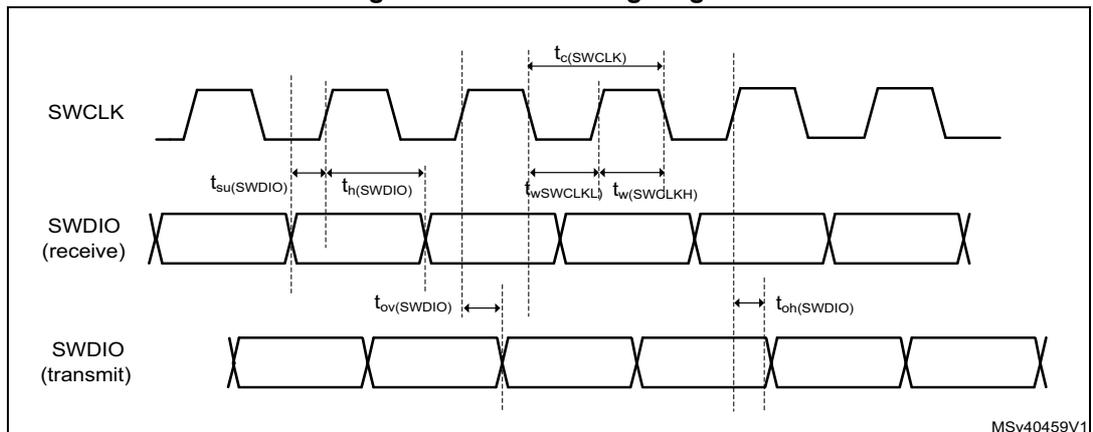


Figure 114. SWD timing diagram



## 8 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status *are available at* [www.st.com](http://www.st.com). ECOPACK is an ST trademark.

### 8.1 Device marking

Refer to technical note “Reference device marking schematics for STM32 microcontrollers and microprocessors” (TN1433) available on [www.st.com](http://www.st.com), for the location of pin 1 / ball A1 as well as the location and orientation of the marking areas versus pin 1 / ball A1.

Parts marked as “ES”, “E” or accompanied by an engineering sample notification letter, are not yet qualified and therefore not approved for use in production. ST is not responsible for any consequences resulting from such use. In no event will ST be liable for the customer using any of these engineering samples in production. ST’s Quality department must be contacted prior to any decision to use these engineering samples to run a qualification activity.

A WLCSP simplified marking example (if any) is provided in the corresponding package information subsection.

## 8.2 LQFP100 package information (1L)

This LQFP is 100 lead, 14 x 14 mm low-profile quad flat package.

Note: See list of notes in the notes section.

Figure 115. LQFP100 - Outline<sup>(15)</sup>

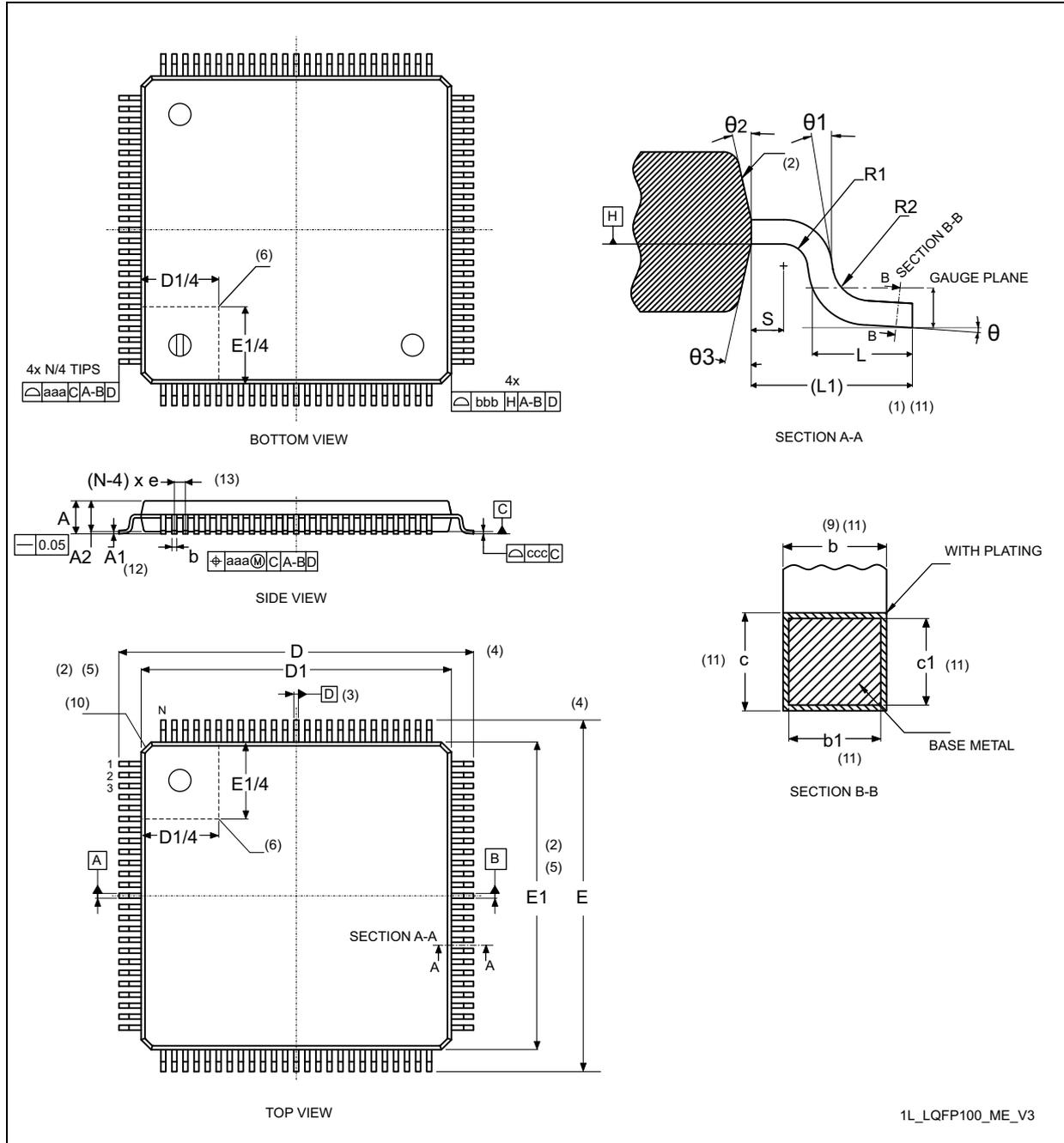


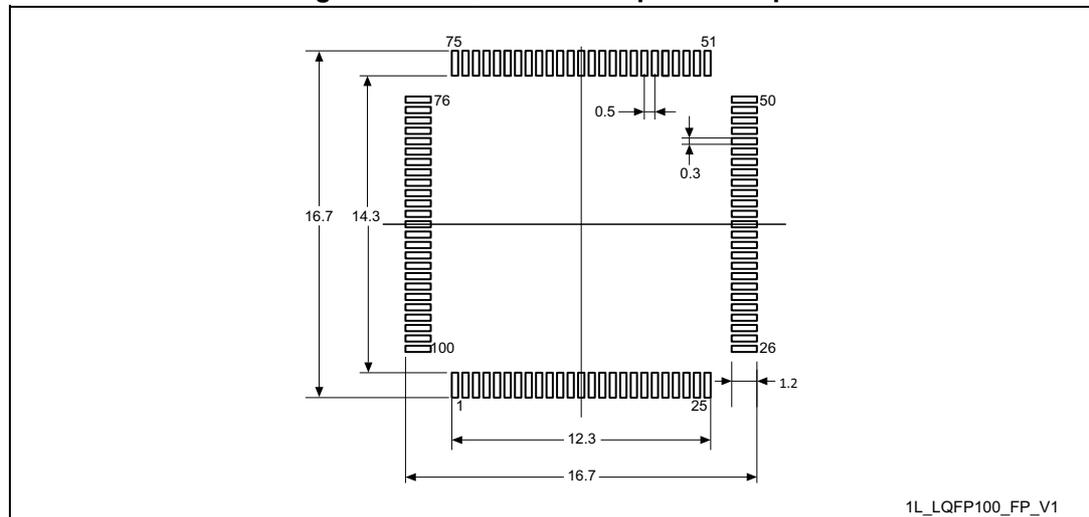
Table 207. LQFP100 - Mechanical data

| Symbol                | millimeters |      |      | inches <sup>(14)</sup> |        |        |
|-----------------------|-------------|------|------|------------------------|--------|--------|
|                       | Min         | Typ  | Max  | Min                    | Typ    | Max    |
| A                     | -           | 1.50 | 1.60 | -                      | 0.0590 | 0.0630 |
| A1 <sup>(12)</sup>    | 0.05        | -    | 0.15 | 0.0019                 | -      | 0.0059 |
| A2                    | 1.35        | 1.40 | 1.45 | 0.0531                 | 0.0551 | 0.0570 |
| b <sup>(9)(11)</sup>  | 0.17        | 0.22 | 0.27 | 0.0067                 | 0.0087 | 0.0106 |
| b1 <sup>(11)</sup>    | 0.17        | 0.20 | 0.23 | 0.0067                 | 0.0079 | 0.0090 |
| c <sup>(11)</sup>     | 0.09        | -    | 0.20 | 0.0035                 | -      | 0.0079 |
| c1 <sup>(11)</sup>    | 0.09        | -    | 0.16 | 0.0035                 | -      | 0.0063 |
| D <sup>(4)</sup>      | 16.00 BSC   |      |      | 0.6299 BSC             |        |        |
| D1 <sup>(2)(5)</sup>  | 14.00 BSC   |      |      | 0.5512 BSC             |        |        |
| E <sup>(4)</sup>      | 16.00 BSC   |      |      | 0.6299 BSC             |        |        |
| E1 <sup>(2)(5)</sup>  | 14.00 BSC   |      |      | 0.5512 BSC             |        |        |
| e                     | 0.50 BSC    |      |      | 0.0197 BSC             |        |        |
| L                     | 0.45        | 0.60 | 0.75 | 0.177                  | 0.0236 | 0.0295 |
| L1 <sup>(1)(11)</sup> | 1.00        |      |      | -                      | 0.0394 | -      |
| N <sup>(13)</sup>     | 100         |      |      |                        |        |        |
| θ                     | 0°          | 3.5° | 7°   | 0°                     | 3.5°   | 7°     |
| θ1                    | 0°          | -    | -    | 0°                     | -      | -      |
| θ2                    | 10°         | 12°  | 14°  | 10°                    | 12°    | 14°    |
| θ3                    | 10°         | 12°  | 14°  | 10°                    | 12°    | 14°    |
| R1                    | 0.08        | -    | -    | 0.0031                 | -      | -      |
| R2                    | 0.08        | -    | 0.20 | 0.0031                 | -      | 0.0079 |
| S                     | 0.20        | -    | -    | 0.0079                 | -      | -      |
| aaa <sup>(1)</sup>    | 0.20        |      |      | 0.0079                 |        |        |
| bbb <sup>(1)</sup>    | 0.20        |      |      | 0.0079                 |        |        |
| ccc <sup>(1)</sup>    | 0.08        |      |      | 0.0031                 |        |        |
| ddd <sup>(1)</sup>    | 0.08        |      |      | 0.0031                 |        |        |

**Notes:**

1. Dimensioning and tolerancing schemes conform to ASME Y14.5M-1994.
2. The Top package body size may be smaller than the bottom package size by as much as 0.15 mm.
3. Datums A-B and D to be determined at datum plane H.
4. To be determined at seating datum plane C.
5. Dimensions D1 and E1 do not include mold flash or protrusions. Allowable mold flash or protrusions is "0.25 mm" per side. D1 and E1 are Maximum plastic body size dimensions including mold mismatch.
6. Details of pin 1 identifier are optional but must be located within the zone indicated.
7. All dimensions are in millimeters.
8. No intrusion allowed inwards the leads.
9. Dimension "b" does not include dambar protrusion. Allowable dambar protrusion shall not cause the lead width to exceed the maximum "b" dimension by more than 0.08 mm. Dambar cannot be located on the lower radius or the foot. Minimum space between protrusion and an adjacent lead is 0.07 mm for 0.4 mm and 0.5 mm pitch packages.
10. Exact shape of each corner is optional.
11. These dimensions apply to the flat section of the lead between 0.10 mm and 0.25 mm from the lead tip.
12. A1 is defined as the distance from the seating plane to the lowest point on the package body.
13. "N" is the number of terminal positions for the specified body size.
14. Values in inches are converted from mm and rounded to 4 decimal digits.
15. Drawing is not to scale.

**Figure 116. LQFP100 - Footprint example**



1. Dimensions are expressed in millimeters.

### 8.3 TFBGA100 package information (A08Q)

This TFBGA is 100 - ball, 8X8 mm, 0.8 mm pitch fine pitch ball grid array package.

Note: See list of notes in the notes section.

Figure 117. TFBGA100 - Outline<sup>(13)</sup>

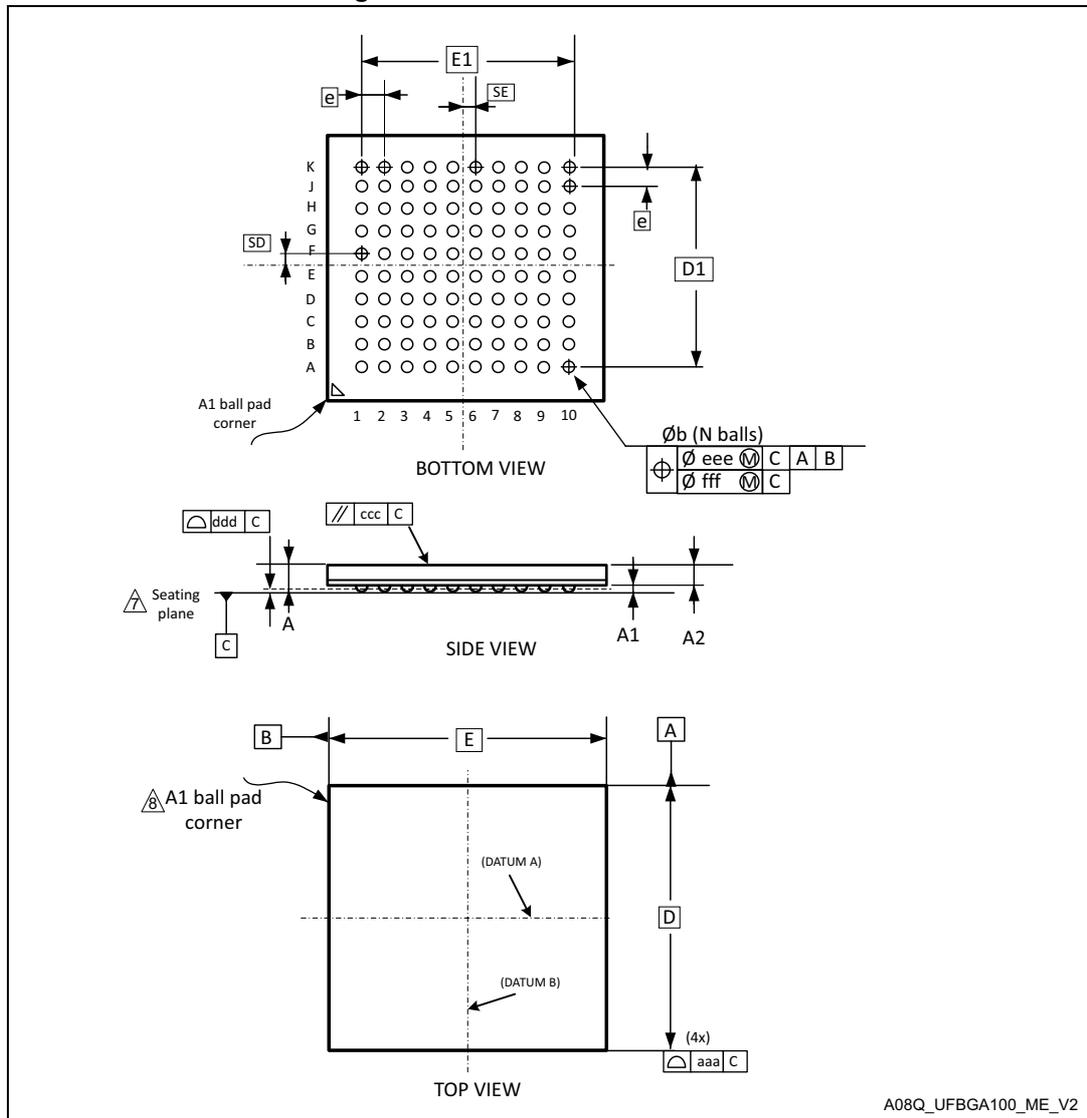


Table 208. TFBGA100 - Mechanical data

| Symbol              | millimeters <sup>(1)</sup> |      |      | inches <sup>(12)</sup> |        |        |
|---------------------|----------------------------|------|------|------------------------|--------|--------|
|                     | Min                        | Typ  | Max  | Min                    | Typ    | Max    |
| A <sup>(2)(3)</sup> | -                          | -    | 1.20 | -                      | -      | 0.0472 |
| A1 <sup>(4)</sup>   | 0.15                       | -    | -    | 0.0059                 | -      | -      |
| A2                  | -                          | 0.74 | -    | -                      | 0.0291 | -      |
| b <sup>(5)</sup>    | 0.35                       | 0.40 | 0.45 | 0.0138                 | 0.0157 | 0.0177 |
| D                   | 8.00 BSC <sup>(6)</sup>    |      |      | 0.3150 BSC             |        |        |
| D1                  | 7.20 BSC                   |      |      | 0.2835 BSC             |        |        |

**Table 208. TFBGA100 - Mechanical data (continued)**

| Symbol             | millimeters <sup>(1)</sup> |     |     | inches <sup>(12)</sup> |     |     |
|--------------------|----------------------------|-----|-----|------------------------|-----|-----|
|                    | Min                        | Typ | Max | Min                    | Typ | Max |
| E                  | 8.00 BSC                   |     |     | 0.3150 BSC             |     |     |
| E1                 | 7.20 BSC                   |     |     | 0.2835 BSC             |     |     |
| e <sup>(9)</sup>   | 0.80 BSC                   |     |     | 0.0315 BSC             |     |     |
| N <sup>(11)</sup>  | 100                        |     |     |                        |     |     |
| SD <sup>(12)</sup> | 0.40 BSC                   |     |     | 0.0157 BSC             |     |     |
| SE <sup>(12)</sup> | 0.40 BSC                   |     |     | 0.0157 BSC             |     |     |
| aaa                | 0.15                       |     |     | 0.0059                 |     |     |
| ccc                | 0.20                       |     |     | 0.0079                 |     |     |
| ddd                | 0.10                       |     |     | 0.0039                 |     |     |
| eee                | 0.15                       |     |     | 0.0059                 |     |     |
| fff                | 0.08                       |     |     | 0.0031                 |     |     |

**Notes:**

1. Dimensioning and tolerancing schemes conform to ASME Y14.5M-2018.
2. TFBGA stands for thin profile fine pitch ball grid array: 1.00 mm < A ≤ 1.20 mm / fine pitch e < 1.00 mm.
3. The profile height, A, is the distance from the seating plane to the highest point on the package. It is measured perpendicular to the seating plane.
4. A1 is defined as the distance from the seating plane to the lowest point on the package body.
5. Dimension b is measured at the maximum diameter of the terminal (ball) in a plane parallel to primary datum C.
6. BSC stands for BASIC dimensions. It corresponds to the nominal value and has no tolerance. For tolerances refer to form and position table. On the drawing these dimensions are framed.
7. Primary datum C is defined by the plane established by the contact points of three or more solder balls that support the device when it is placed on top of a planar surface.
8. The terminal (ball) A1 corner must be identified on the top surface of the package by using a corner chamfer, ink or metalized markings, or other feature of package body or integral heat slug. A distinguish feature is allowable on the bottom surface of the package to identify the terminal A1 corner. Exact shape of each corner is optional.
9. e represents the solder ball grid pitch.
10. N represents the total number of balls on the BGA.
11. Basic dimensions SD and SE are defined with respect to datums A and B. It defines the position of the centre ball(s) in the outer row or column of a fully populated matrix.
12. Values in inches are converted from mm and rounded to 4 decimal digits.
13. Drawing is not to scale.

Figure 118. TFBGA100 - Footprint example

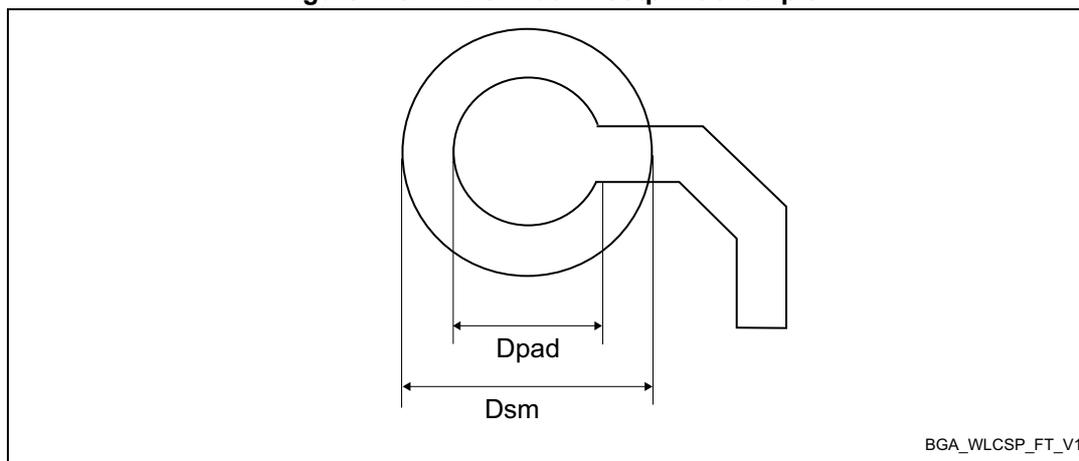


Table 209. TFBGA100 - Example of PCB design rules (0.8 mm pitch BGA)

| Dimension         | Values   |
|-------------------|--|
| Pitch             | 0.8  |
| $D_{pad}$         | 0.400 mm   |
| $D_{sm}$          | 0.470 mm typ. (depends on the soldermask registration tolerance) |
| Stencil opening   | 0.400 mm   |
| Stencil thickness | Between 0.100 mm and 0.125 mm                                    |
| Pad trace width   | 0.120 mm   |

### 8.4 LQFP144 package information (1A)

This LQFP is a 144-pin, 20 x 20 mm low-profile quad flat package.

Note: See list of notes in the notes section.

Figure 119. LQFP144 - Outline<sup>(15)</sup>

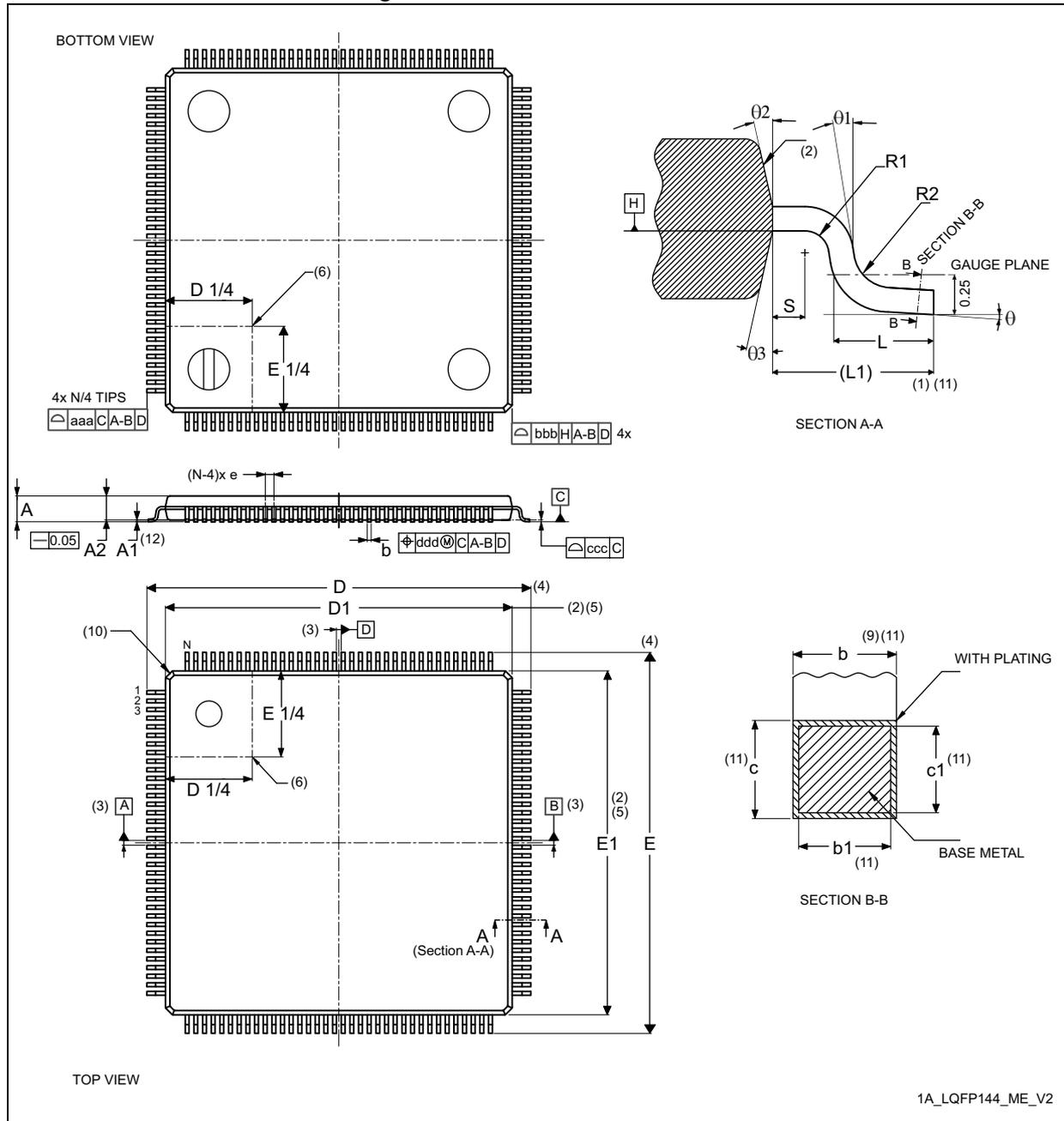


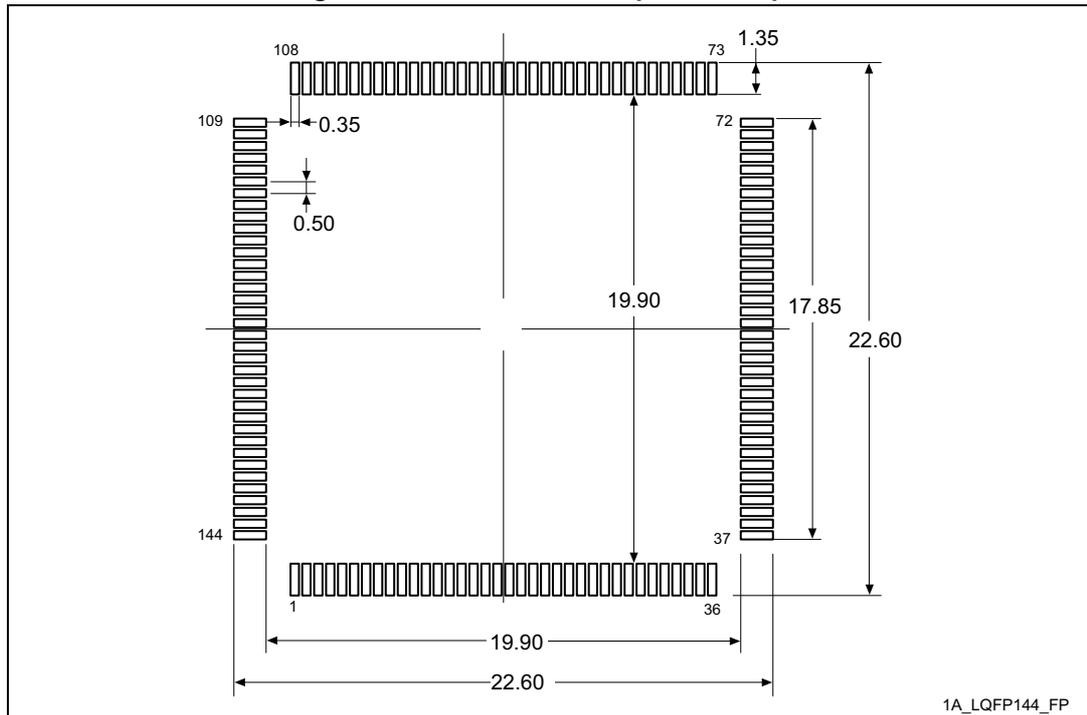
Table 210. LQFP144 - Mechanical data

| Symbol               | millimeters |      |      | inches <sup>(14)</sup> |        |        |
|----------------------|-------------|------|------|------------------------|--------|--------|
|                      | Min         | Typ  | Max  | Min                    | Typ    | Max    |
| A                    | -           | -    | 1.60 | -                      | -      | 0.0630 |
| A1 <sup>(12)</sup>   | 0.05        | -    | 0.15 | 0.0020                 | -      | 0.0059 |
| A2                   | 1.35        | 1.40 | 1.45 | 0.0531                 | 0.0551 | 0.0571 |
| b <sup>(9)(11)</sup> | 0.17        | 0.22 | 0.27 | 0.0067                 | 0.0087 | 0.0106 |
| b1 <sup>(11)</sup>   | 0.17        | 0.20 | 0.23 | 0.0067                 | 0.0079 | 0.0090 |
| c <sup>(11)</sup>    | 0.09        | -    | 0.20 | 0.0035                 | -      | 0.0079 |
| c1 <sup>(11)</sup>   | 0.09        | -    | 0.16 | 0.0035                 | -      | 0.0063 |
| D <sup>(4)</sup>     | 22.00 BSC   |      |      | 0.8661 BSC             |        |        |
| D1 <sup>(2)(5)</sup> | 20.00 BSC   |      |      | 0.7874 BSC             |        |        |
| E <sup>(4)</sup>     | 22.00 BSC   |      |      | 0.8661 BSC             |        |        |
| E1 <sup>(2)(5)</sup> | 20.00 BSC   |      |      | 0.7874 BSC             |        |        |
| e                    | 0.50 BSC    |      |      | 0.0197 BSC             |        |        |
| L                    | 0.45        | 0.60 | 0.75 | 0.0177                 | 0.0236 | 0.0295 |
| L1                   | 1.00 REF    |      |      | 0.0394 REF             |        |        |
| N <sup>(13)</sup>    | 144         |      |      |                        |        |        |
| θ                    | 0°          | 3.5° | 7°   | 0°                     | 3.5°   | 7°     |
| θ1                   | 0°          | -    | -    | 0°                     | -      | -      |
| θ2                   | 10°         | 12°  | 14°  | 10°                    | 12°    | 14°    |
| θ3                   | 10°         | 12°  | 14°  | 10°                    | 12°    | 14°    |
| R1                   | 0.08        | -    | -    | 0.0031                 | -      | -      |
| R2                   | 0.08        | -    | 0.20 | 0.0031                 | -      | 0.0079 |
| S                    | 0.20        | -    | -    | 0.0079                 | -      | -      |
| aaa                  | 0.20        |      |      | 0.0079                 |        |        |
| bbb                  | 0.20        |      |      | 0.0079                 |        |        |
| ccc                  | 0.08        |      |      | 0.0031                 |        |        |
| ddd                  | 0.08        |      |      | 0.0031                 |        |        |

**Notes:**

1. Dimensioning and tolerancing schemes conform to ASME Y14.5M-1994.
2. The Top package body size may be smaller than the bottom package size by as much as 0.15 mm.
3. Datums A-B and D to be determined at datum plane H.
4. To be determined at seating datum plane C.
5. Dimensions D1 and E1 do not include mold flash or protrusions. Allowable mold flash or protrusions is "0.25 mm" per side. D1 and E1 are Maximum plastic body size dimensions including mold mismatch.
6. Details of pin 1 identifier are optional but must be located within the zone indicated.
7. All dimensions are in millimeters.
8. No intrusion allowed inwards the leads.
9. Dimension "b" does not include dambar protrusion. Allowable dambar protrusion shall not cause the lead width to exceed the maximum "b" dimension by more than 0.08 mm. Dambar cannot be located on the lower radius or the foot. Minimum space between protrusion and an adjacent lead is 0.07 mm for 0.4 mm and 0.5 mm pitch packages.
10. Exact shape of each corner is optional.
11. These dimensions apply to the flat section of the lead between 0.10 mm and 0.25 mm from the lead tip.
12. A1 is defined as the distance from the seating plane to the lowest point on the package body.
13. "N" is the number of terminal positions for the specified body size.
14. Values in inches are converted from mm and rounded to 4 decimal digits.
15. Drawing is not to scale.

Figure 120. LQFP144 - Footprint example

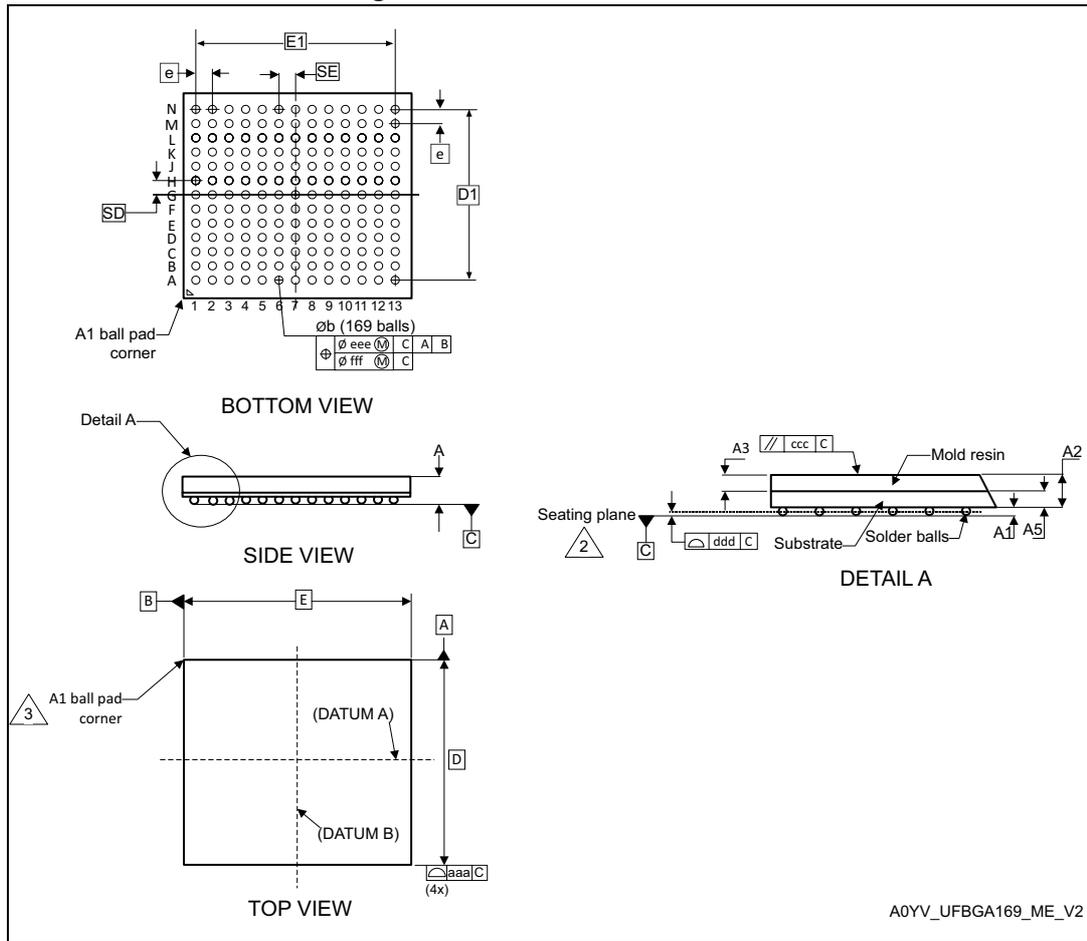


1. Dimensions are expressed in millimeters.

### 8.5 UFBGA169 package information (A0YV)

This UFBGA is a 169-ball, 7 x 7 mm, 0.50 mm pitch, ultra fine pitch ball grid array package.

Figure 121. UFBGA169 - Outline



1. Drawing is not to scale.
2. Primary datum C is defined by the plane established by the contact points of three or more solder balls that support the device when it is placed on top of a planar surface.
3. The terminal (ball) A1 corner must be identified on the top surface of the package by using a corner chamfer, ink or metallized markings, or other feature of package body or integral heat slug. A distinguish feature is allowable on the bottom surface of the package to identify the terminal A1 corner. Exact shape of each corner is optional.

Table 211. UFBGA169 - Mechanical data

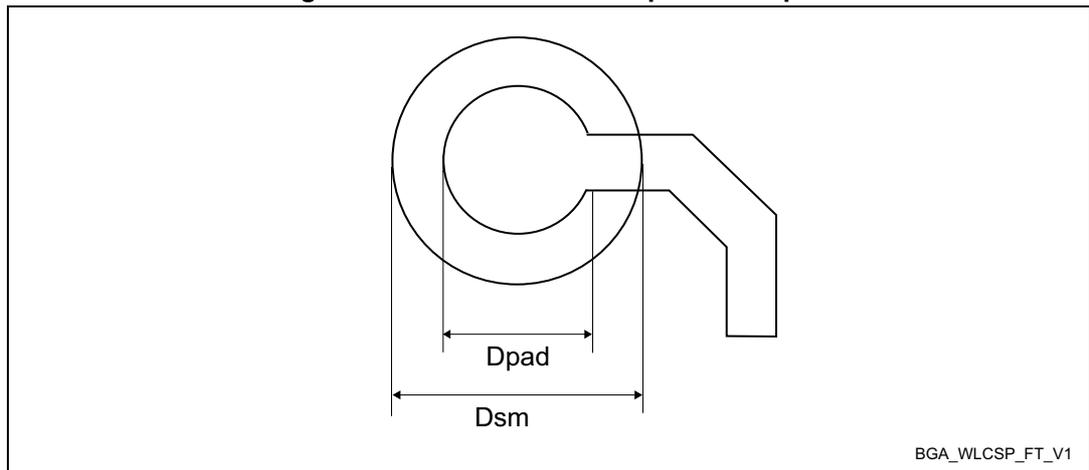
| Symbol            | millimeters |      |      | inches <sup>(1)</sup> |        |        |
|-------------------|-------------|------|------|-----------------------|--------|--------|
|                   | Min.        | Typ. | Max. | Min.                  | Typ.   | Max.   |
| A <sup>(2)</sup>  | -           | -    | 0.60 | -                     | -      | 0.0236 |
| A1 <sup>(3)</sup> | 0.05        | -    | -    | 0.0020                | -      | -      |
| A2                | -           | 0.43 | -    | -                     | 0.0169 | -      |
| b <sup>(4)</sup>  | 0.23        | 0.28 | 0.33 | 0.0091                | 0.0110 | 0.0130 |
| D <sup>(5)</sup>  | 7.00 BSC    |      |      | 0.2756 BSC            |        |        |
| D1 <sup>(5)</sup> | 6.00 BSC    |      |      | 0.2362 BSC            |        |        |
| E <sup>(5)</sup>  | 7.00 BSC    |      |      | 0.2756 BSC            |        |        |

**Table 211. UFBGA169 - Mechanical data (continued)**

| Symbol               | millimeters |      |      | inches <sup>(1)</sup> |      |      |
|----------------------|-------------|------|------|-----------------------|------|------|
|                      | Min.        | Typ. | Max. | Min.                  | Typ. | Max. |
| E1 <sup>(5)</sup>    | 6.00 BSC    |      |      | 0.2362 BSC            |      |      |
| e <sup>(5)(6)</sup>  | 0.50 BSC    |      |      | 0.0197 BSC            |      |      |
| N <sup>(7)</sup>     | 169         |      |      |                       |      |      |
| SD <sup>(5)(8)</sup> | 0.50 BSC    |      |      | 0.0197 BSC            |      |      |
| SE <sup>(5)(8)</sup> | 0.50 BSC    |      |      | 0.0197 BSC            |      |      |
| aaa <sup>(9)</sup>   | 0.15        |      |      | 0.0059                |      |      |
| ccc <sup>(9)</sup>   | 0.20        |      |      | 0.0079                |      |      |
| ddd <sup>(9)</sup>   | 0.08        |      |      | 0.0031                |      |      |
| eee <sup>(9)</sup>   | 0.15        |      |      | 0.0059                |      |      |
| fff <sup>(9)</sup>   | 0.05        |      |      | 0.0020                |      |      |

1. Values in inches are converted from mm and rounded to 4 decimal digits.
2. The profile height, A, is the distance from the seating plane to the highest point on the package. It is measured perpendicular to the seating plane.
3. A1 is defined as the distance from the seating plane to the lowest point on the package body.
4. Dimension b is measured at the maximum diameter of the terminal (ball) in a plane parallel to primary datum C.
5. BSC stands for BASIC dimensions. It corresponds to the nominal value and has no tolerance. For tolerances refer to form and position table.
6. e represents the solder ball grid pitch.
7. N represents the total number of balls on the BGA.
8. Basic dimensions SD and SE are defined with respect to datums A and B. It defines the position of the centre ball(s) in the outer row or column of a fully populated matrix.
9. Tolerance of form and position drawing

**Figure 122. UFBGA169 - Footprint example**



BGA\_WLCSP\_FT\_V1

Table 212. UFBGA169 - Example of PCB design rules (0.5 mm pitch BGA)

| Dimension    | Values  |
|--------------|---|
| Pitch        | 0.5 mm  |
| Dpad         | 0.27 mm   |
| Dsm          | 0.35 mm typ. (depends on the soldermask registration tolerance) |
| Solder paste | 0.27 mm aperture diameter.                                      |

*Note:* Non-solder mask defined (NSMD) pads are recommended.

*Note:* 4 to 6 mils solder paste screen printing process.

### 8.6 LQFP176 package information (1T)

This LQFP is a 176-pin, 24 x 24 mm, 0.5 mm pitch, low profile quad flat package.

Note: See list of notes in the notes section.

Figure 123. LQFP176 - Outline<sup>(15)</sup>

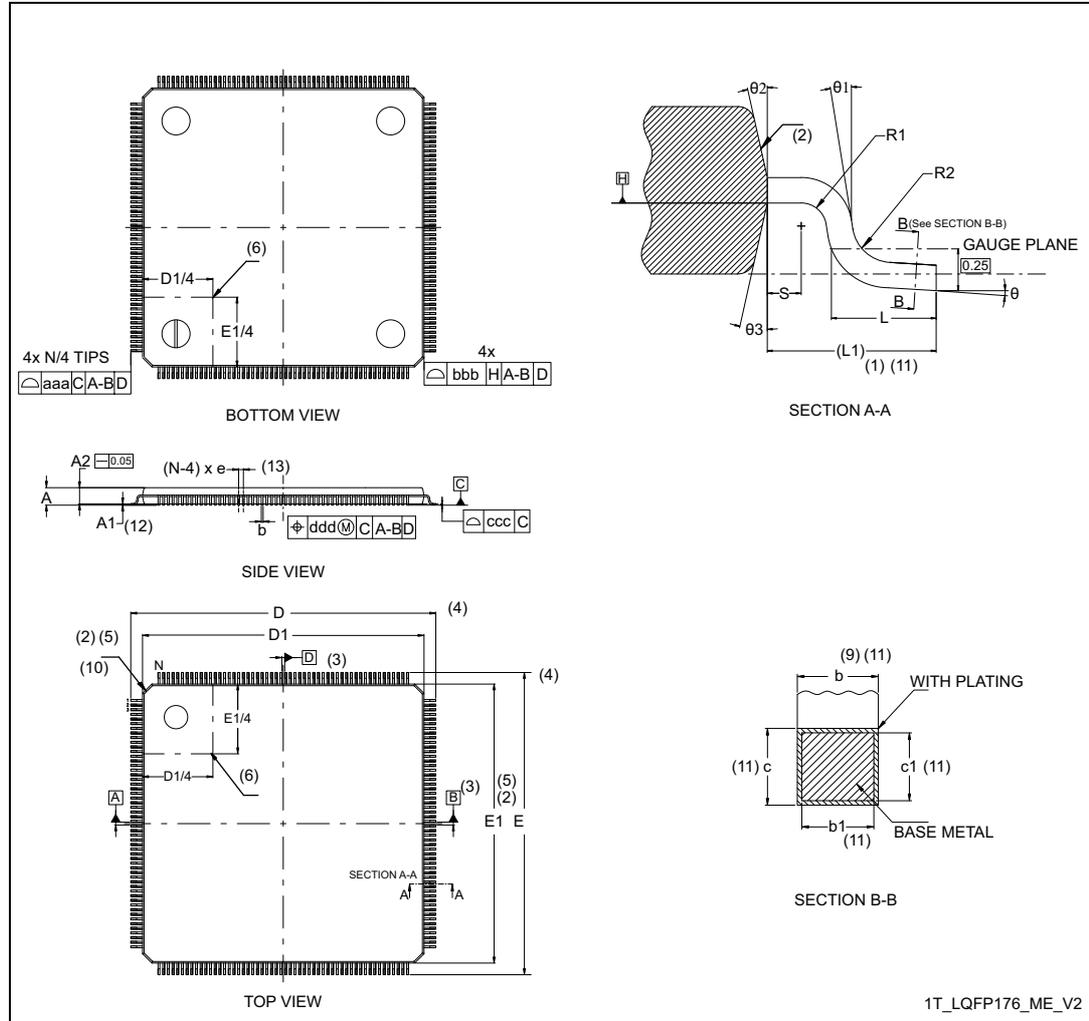


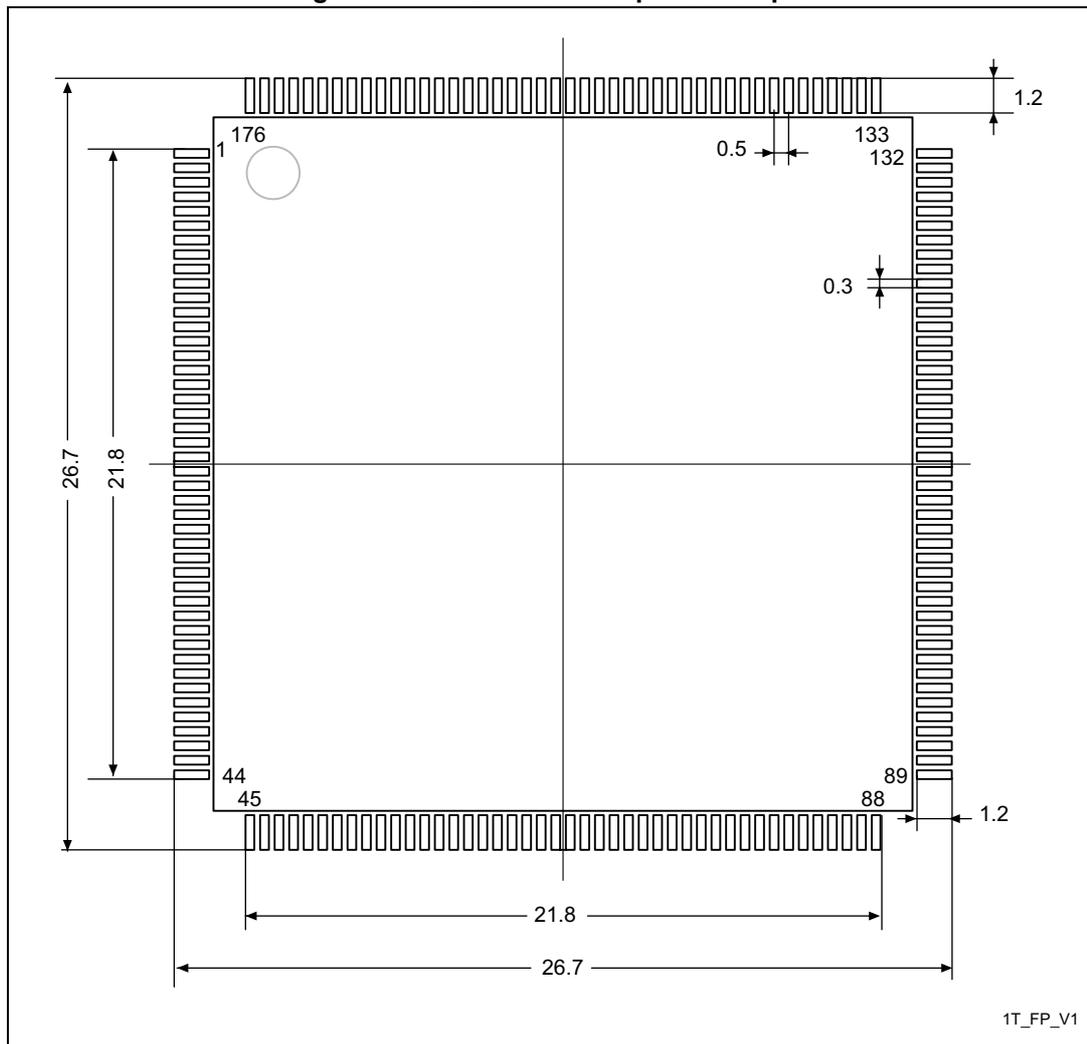
Table 213. LQFP176 - Mechanical data

| Symbol                | millimeters |       |       | inches <sup>(14)</sup> |        |        |
|-----------------------|-------------|-------|-------|------------------------|--------|--------|
|                       | Min         | Typ   | Max   | Min                    | Typ    | Max    |
| A                     | -           | -     | 1.600 | -                      | -      | 0.0630 |
| A1 <sup>(12)</sup>    | 0.050       | -     | 0.150 | 0.0020                 | -      | 0.0059 |
| A2                    | 1.350       | 1.400 | 1.450 | 0.0531                 | 0.0551 | 0.0571 |
| b <sup>(9)(11)</sup>  | 0.170       | 0.220 | 0.270 | 0.0067                 | 0.0087 | 0.0106 |
| b1 <sup>(11)</sup>    | 0.170       | 0.200 | 0.230 | 0.0067                 | 0.0079 | 0.0091 |
| c <sup>(11)</sup>     | 0.090       | -     | 0.200 | 0.0035                 | -      | 0.0079 |
| c1 <sup>(11)</sup>    | 0.090       | -     | 0.160 | 0.0035                 | -      | 0.063  |
| D <sup>(4)</sup>      | 26.000      |       |       | 1.0236                 |        |        |
| D1 <sup>(2)(5)</sup>  | 24.000      |       |       | 0.9449                 |        |        |
| E <sup>(4)</sup>      | 26.000      |       |       | 0.0197                 |        |        |
| E1 <sup>(2)(5)</sup>  | 24.000      |       |       | 0.9449                 |        |        |
| e                     | 0.500       |       |       | 0.1970                 |        |        |
| L                     | 0.450       | 0.600 | 0.750 | 0.0177                 | 0.0236 | 0.0295 |
| L1 <sup>(1)(11)</sup> | 1           |       |       | 0.0394 REF             |        |        |
| N <sup>(13)</sup>     | 176         |       |       |                        |        |        |
| θ                     | 0°          | 3.5°  | 7°    | 0°                     | 3.5°   | 7°     |
| θ1                    | 0°          | -     | -     | 0°                     | -      | -      |
| θ2                    | 10°         | 12°   | 14°   | 10°                    | 12°    | 14°    |
| θ3                    | 10°         | 12°   | 14°   | 10°                    | 12°    | 14°    |
| R1                    | 0.080       | -     | -     | 0.0031                 | -      | -      |
| R2                    | 0.080       | -     | 0.200 | 0.0031                 | -      | 0.0079 |
| S                     | 0.200       | -     | -     | 0.0079                 | -      | -      |
| aaa <sup>(1)</sup>    | 0.200       |       |       | 0.0079                 |        |        |
| bbb <sup>(1)</sup>    | 0.200       |       |       | 0.0079                 |        |        |
| ccc <sup>(1)</sup>    | 0.080       |       |       | 0.0031                 |        |        |
| ddd <sup>(1)</sup>    | 0.080       |       |       | 0.0031                 |        |        |

**Notes:**

1. Dimensioning and tolerancing schemes conform to ASME Y14.5M-1994.
2. The Top package body size may be smaller than the bottom package size by as much as 0.15 mm.
3. Datums A-B and D to be determined at datum plane H.
4. To be determined at seating datum plane C.
5. Dimensions D1 and E1 do not include mold flash or protrusions. Allowable mold flash or protrusions is "0.25 mm" per side. D1 and E1 are Maximum plastic body size dimensions including mold mismatch.
6. Details of pin 1 identifier are optional but must be located within the zone indicated.
7. All dimensions are in millimeters.
8. No intrusion allowed inwards the leads.
9. Dimension "b" does not include dambar protrusion. Allowable dambar protrusion shall not cause the lead width to exceed the maximum "b" dimension by more than 0.08 mm. Dambar cannot be located on the lower radius or the foot. Minimum space between protrusion and an adjacent lead is 0.07 mm for 0.4 mm and 0.5 mm pitch packages.
10. Exact shape of each corner is optional.
11. These dimensions apply to the flat section of the lead between 0.10 mm and 0.25 mm from the lead tip.
12. A1 is defined as the distance from the seating plane to the lowest point on the package body.
13. "N" is the number of terminal positions for the specified body size.
14. Values in inches are converted from mm and rounded to 4 decimal digits.
15. Drawing is not to scale.

Figure 124. LQFP176 - Footprint example



1. Dimensions are expressed in millimeters.

### 8.7 LQFP208 package information (UH)

This LQFP is a 208-pin, 28 x 28 mm low-profile quad flat package.

Note: See list of notes in the notes section.

Figure 125. LQFP208 - Outline<sup>(15)</sup>

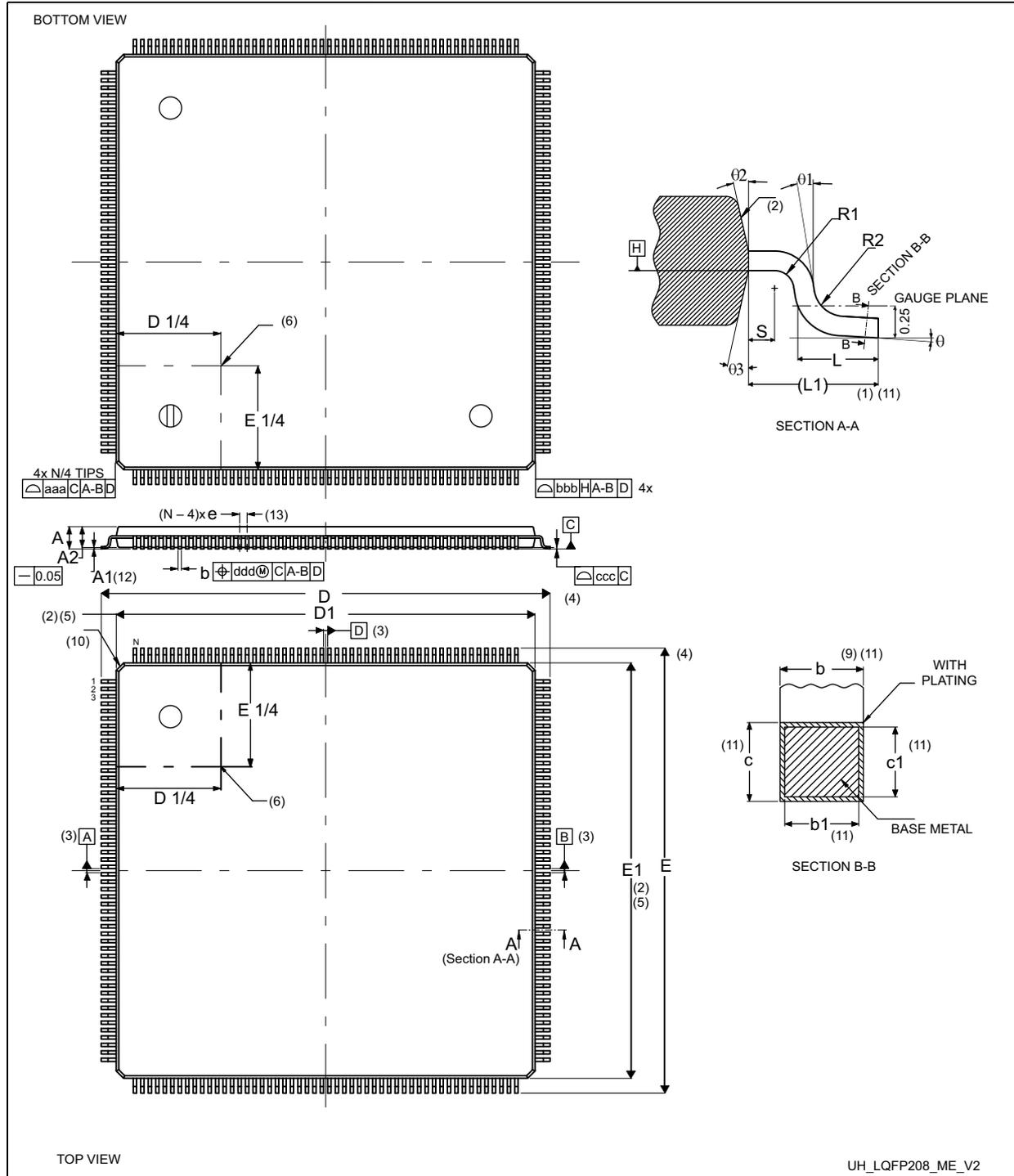


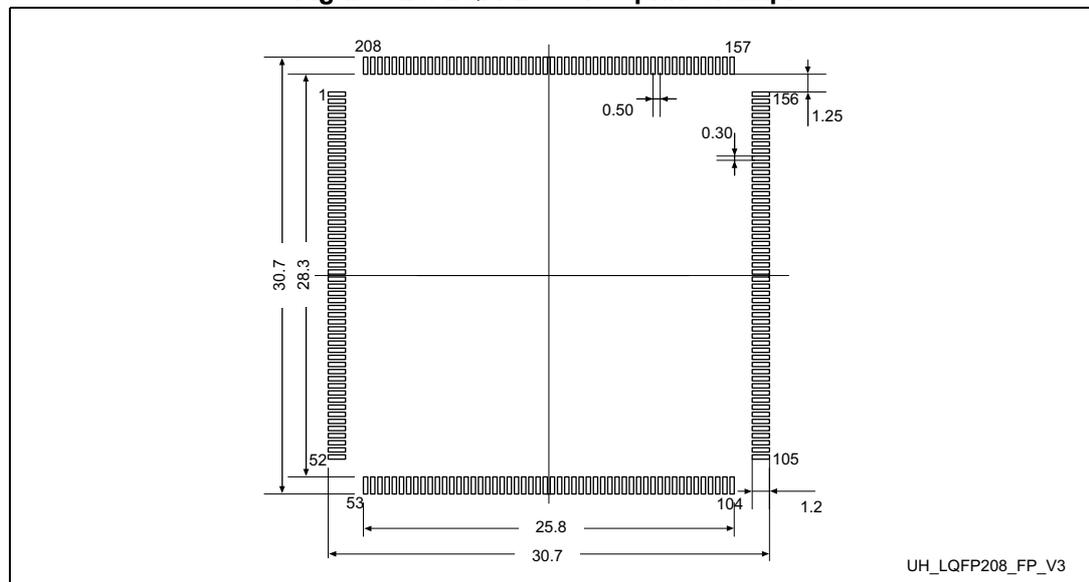
Table 214. LQFP208 - Mechanical data

| Symbol                | millimeters |      |      | inches <sup>(15)</sup> |        |        |
|-----------------------|-------------|------|------|------------------------|--------|--------|
|                       | Min         | Typ  | Max  | Min                    | Typ    | Max    |
| A                     | -           | -    | 1.60 | -                      | -      | 0.0630 |
| A1 <sup>(12)</sup>    | 0.05        | -    | 0.15 | 0.0020                 | -      | 0.0059 |
| A2                    | 1.35        | 1.40 | 1.45 | 0.0531                 | 0.0551 | 0.0571 |
| b <sup>(9)(11)</sup>  | 0.17        | 0.22 | 0.27 | 0.0067                 | 0.0087 | 0.0106 |
| b1 <sup>(11)</sup>    | 0.17        | 0.20 | 0.23 | 0.0067                 | 0.0079 | 0.0091 |
| c <sup>(11)</sup>     | 0.09        | -    | 0.20 | 0.0035                 | -      | 0.0079 |
| c1 <sup>(11)</sup>    | 0.09        | -    | 0.16 | 0.0035                 | -      | 0.0063 |
| D <sup>(4)</sup>      | 30.00 BSC   |      |      | 1.1732 BSC             |        |        |
| D1 <sup>(2)(5)</sup>  | 28.00 BSC   |      |      | 1.0945 BSC             |        |        |
| E <sup>(4)</sup>      | 30.00 BSC   |      |      | 1.1732 BSC             |        |        |
| E1 <sup>(2)(5)</sup>  | 28.00 BSC   |      |      | 1.0945 BSC             |        |        |
| e                     | 0.50 BSC    |      |      | 0.0197 BSC             |        |        |
| L                     | 0.45        | 0.60 | 0.75 | 0.0177                 | 0.0236 | 0.0295 |
| L1                    | 1.00 REF    |      |      | 0.0394 REF             |        |        |
| N <sup>(13)</sup>     | 208         |      |      |                        |        |        |
| θ                     | 0°          | 3.5° | 7°   | 0°                     | 3.5°   | 7°     |
| θ1                    | 0°          | -    | -    | 0°                     | -      | -      |
| θ2                    | 10°         | 12°  | 14°  | 10°                    | 12°    | 14°    |
| θ3                    | 10°         | 12°  | 14°  | 10°                    | 12°    | 14°    |
| R1                    | 0.08        | -    | -    | 0.0031                 | -      | -      |
| R2                    | 0.08        | -    | 0.20 | 0.0031                 | -      | 0.0079 |
| S                     | 0.20        | -    | -    | 0.0079                 | -      | -      |
| aaa <sup>(1)(7)</sup> | 0.20        |      |      | 0.0079                 |        |        |
| bbb <sup>(1)(7)</sup> | 0.20        |      |      | 0.0079                 |        |        |
| ccc <sup>(1)(7)</sup> | 0.08        |      |      | 0.0031                 |        |        |
| ddd <sup>(1)(7)</sup> | 0.08        |      |      | 0.0031                 |        |        |

**Notes:**

1. Dimensioning and tolerancing schemes conform to ASME Y14.5M-1994.
2. The Top package body size may be smaller than the bottom package size by as much as 0.15 mm.
3. Datums A-B and D to be determined at datum plane H.
4. To be determined at seating datum plane C.
5. Dimensions D1 and E1 do not include mold flash or protrusions. Allowable mold flash or protrusions is "0.25 mm" per side. D1 and E1 are Maximum plastic body size dimensions including mold mismatch.
6. Details of pin 1 identifier are optional but must be located within the zone indicated.
7. All dimensions are in millimeters.
8. No intrusion allowed inwards the leads.
9. Dimension "b" does not include dambar protrusion. Allowable dambar protrusion shall not cause the lead width to exceed the maximum "b" dimension by more than 0.08 mm. Dambar cannot be located on the lower radius or the foot. Minimum space between protrusion and an adjacent lead is 0.07 mm for 0.4 mm and 0.5 mm pitch packages.
10. Exact shape of each corner is optional.
11. These dimensions apply to the flat section of the lead between 0.10 mm and 0.25 mm from the lead tip.
12. A1 is defined as the distance from the seating plane to the lowest point on the package body.
13. "N" is the number of terminal positions for the specified body size.
14. Values in inches are converted from mm and rounded to 4 decimal digits.
15. Drawing is not to scale.

**Figure 126. LQFP208 - footprint example**

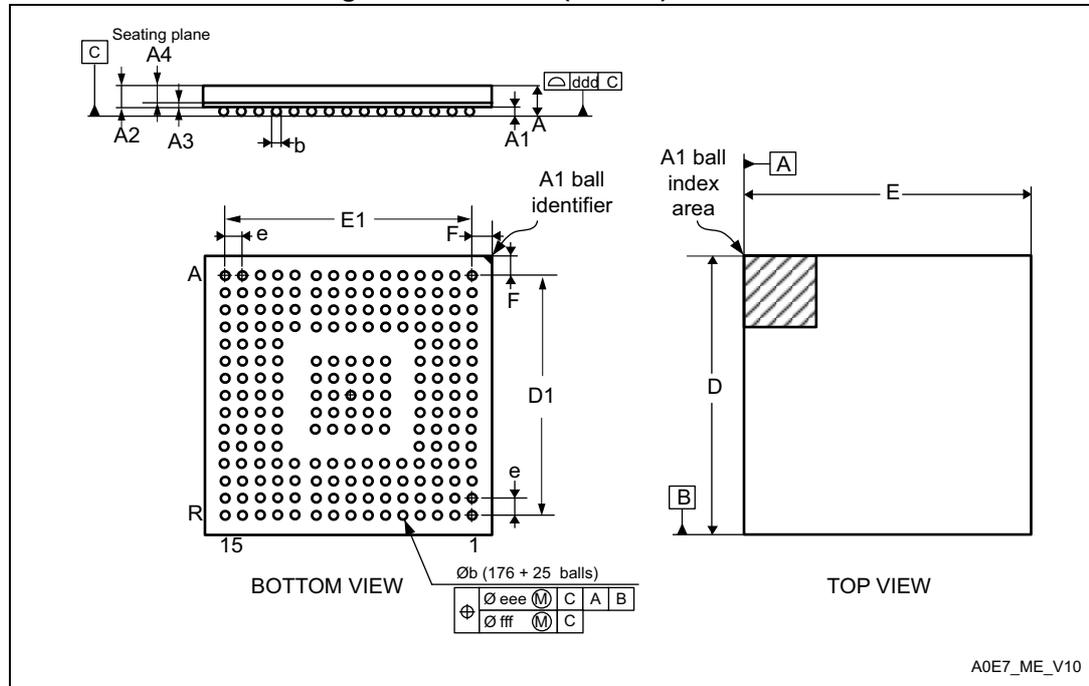


1. Dimensions are expressed in millimeters.

### 8.8 UFBGA(176+25) package information (A0E7)

This UFBGA is a 176+25-ball, 10 x 10 mm, 0.65 mm pitch, ultra fine pitch ball grid array package.

Figure 127. UFBGA(176+25) - Outline



1. Drawing is not to scale.

Table 215. UFBGA(176+25) - Mechanical data

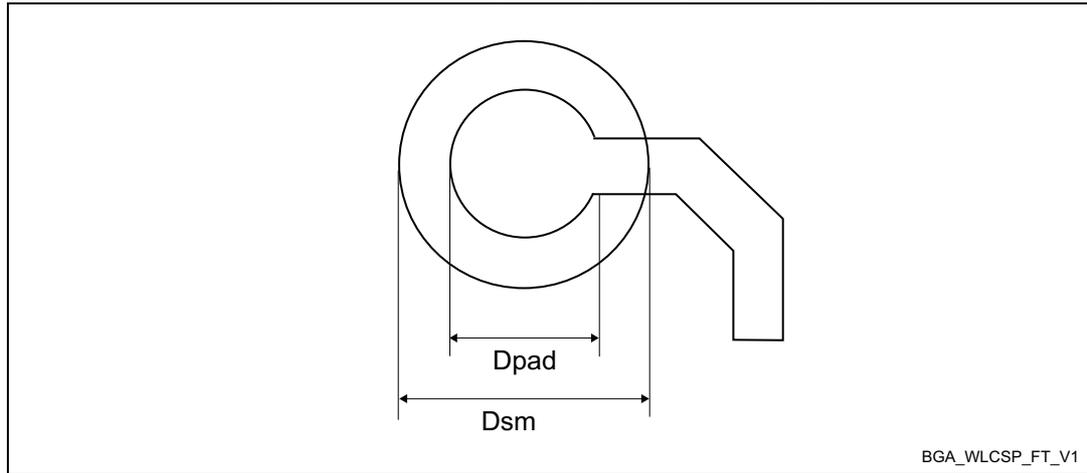
| Symbol | millimeters |        |        | inches <sup>(1)</sup> |        |        |
|--------|-------------|--------|--------|-----------------------|--------|--------|
|        | Min.        | Typ.   | Max.   | Min.                  | Typ.   | Max.   |
| A      | -           | -      | 0.600  | -                     | -      | 0.0236 |
| A1     | 0.050       | 0.080  | 0.110  | 0.0020                | 0.0031 | 0.0043 |
| A2     | -           | 0.450  | -      | -                     | 0.0177 | -      |
| A3     | -           | 0.130  | -      | -                     | 0.0051 | -      |
| A4     | -           | 0.320  | -      | -                     | 0.0126 | -      |
| b      | 0.240       | 0.290  | 0.340  | 0.0094                | 0.0114 | 0.0134 |
| D      | 9.850       | 10.000 | 10.150 | 0.3878                | 0.3937 | 0.3996 |
| D1     | -           | 9.100  | -      | -                     | 0.3583 | -      |
| E      | 9.850       | 10.000 | 10.150 | 0.3878                | 0.3937 | 0.3996 |
| E1     | -           | 9.100  | -      | -                     | 0.3583 | -      |
| e      | -           | 0.650  | -      | -                     | 0.0256 | -      |
| F      | -           | 0.450  | -      | -                     | 0.0177 | -      |
| ddd    | -           | -      | 0.080  | -                     | -      | 0.0031 |

**Table 215. UFBGA(176+25) - Mechanical data (continued)**

| Symbol | millimeters |      |       | inches <sup>(1)</sup> |      |        |
|--------|-------------|------|-------|-----------------------|------|--------|
|        | Min.        | Typ. | Max.  | Min.                  | Typ. | Max.   |
| eee    | -           | -    | 0.150 | -                     | -    | 0.0059 |
| fff    | -           | -    | 0.050 | -                     | -    | 0.0020 |

1. Values in inches are converted from mm and rounded to 4 decimal digits.

**Figure 128. UFBGA(176+25) - Footprint example**



**Table 216. UFBGA(176+25) - Example of PCB design rules (0.65 mm pitch BGA)**

| Dimension         | Values   |
|-------------------|--|
| Pitch             | 0.65 mm  |
| Dpad              | 0.300 mm   |
| Dsm               | 0.400 mm typ. (depends on the soldermask registration tolerance) |
| Stencil opening   | 0.300 mm   |
| Stencil thickness | Between 0.100 mm and 0.125 mm                                    |
| Pad trace width   | 0.100 mm   |

### 8.9 TFBGA240+25 package information (A07U)

This TFBGA is a 240+25-ball, 14 x 14 mm, 0.8 mm pitch, thin profile fine pitch ball grid array package.

Note: *Figure 129 and Figure 130 are not to scale.*

Refer to the notes section for the list of notes on *Figure 129, Table 217, and Table 218.*

Figure 129. TFBGA240+25 - Outline

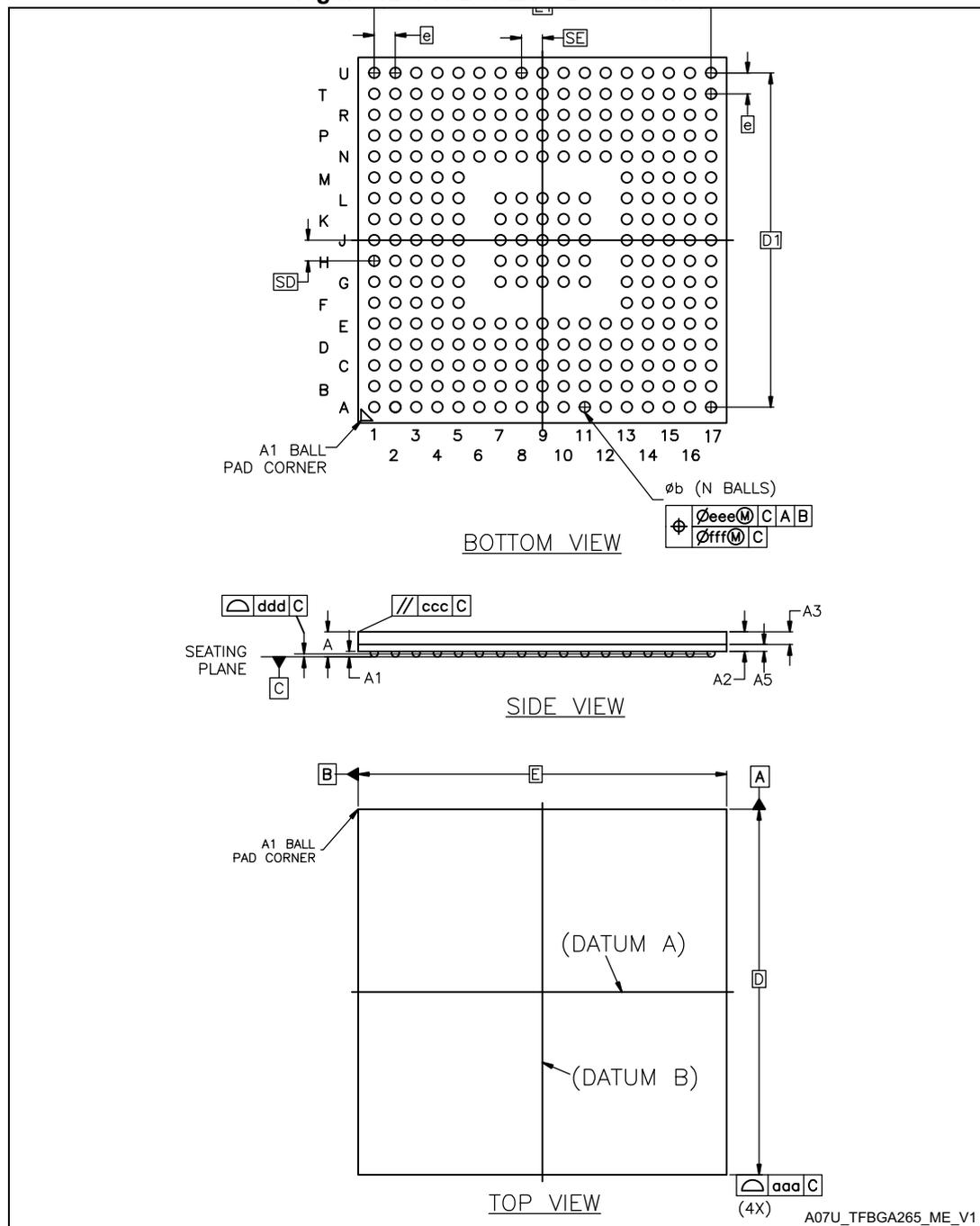


Table 217. TFBGA240+25 - Mechanical data

| Symbol             | Millimeters               |       |       | Inches <sup>(2)</sup> |        |        |
|--------------------|---------------------------|-------|-------|-----------------------|--------|--------|
|                    | Min                       | Typ   | Max   | Min                   | Typ    | Max    |
| A <sup>(3)</sup>   | -                         | -     | 1.200 | -                     | -      | 0.0472 |
| A1 <sup>(4)</sup>  | 0.150                     | -     | -     | 0.0059                | -      | -      |
| A2                 | -                         | 0.760 | -     | -                     | 0.0299 | -      |
| b <sup>(6)</sup>   | 0.320                     | 0.400 | 0.450 | 0.0126                | 0.0157 | 0.0177 |
| D                  | 14.000 BSC <sup>(7)</sup> |       |       | 0.5512 BSC            |        |        |
| D1                 | 12.800 BSC                |       |       | 0.5039 BSC            |        |        |
| E                  | 14.000 BSC                |       |       | 0.5512 BSC            |        |        |
| E1                 | 12.800 BSC                |       |       | 0.0315 BSC            |        |        |
| e <sup>(10)</sup>  | 0.800 BSC                 |       |       | 0.0315 BSC            |        |        |
| N <sup>(11)</sup>  | 265                       |       |       | 265                   |        |        |
| SD <sup>(12)</sup> | 0.800 BSC                 |       |       | 0.0315 BSC            |        |        |
| SE <sup>(12)</sup> | 0.800 BSC                 |       |       | 0.0315 BSC            |        |        |

Table 218. TFBGA240+25 - Tolerance of form and position

| Symbol              | Millimeters |     |     | Inches <sup>(2)</sup> |     |     |
|---------------------|-------------|-----|-----|-----------------------|-----|-----|
|                     | Min         | Typ | Max | Min                   | Typ | Max |
| aaa <sup>(13)</sup> | 0.150       |     |     | 0.0059                |     |     |
| ccc <sup>(13)</sup> | 0.200       |     |     | 0.0079                |     |     |
| ddd <sup>(13)</sup> | 0.100       |     |     | 0.0039                |     |     |
| eee <sup>(13)</sup> | 0.150       |     |     | 0.0059                |     |     |
| fff <sup>(13)</sup> | 0.080       |     |     | 0.0031                |     |     |

**Notes:**

1. Dimensioning and tolerancing schemes conform to ASME Y14.5M-1994.
2. Values in inches are converted from millimeters and rounded to four decimal digits.
3. The profile height, A, is the distance from the seating plane to the highest point on the package. It is measured perpendicular to the seating plane.
4. A1 is defined as the distance from the seating plane to the lowest point on the package body.
5. TFBGA stands for thin profile fine pitch ball grid array:  $1.00\text{ mm} < A \leq 1.20\text{ mm}$  / fine pitch  $e < 1.00\text{ mm}$ .
6. Dimension b is measured at the maximum diameter of the terminal (ball) in a plane parallel to primary datum C.
7. BSC stands for basic dimensions. It corresponds to the nominal value and has no tolerance. For tolerances, refer to [Table 218](#).
8. Primary datum C is defined by the plane established by the contact points of three or more solder balls that support the device when it is placed on top of a planar surface.
9. The terminal (ball) A1 corner must be identified on the top surface of the package by using a corner chamfer, ink or metallized markings, or other feature of package body or integral heat slug. A distinguishing feature is allowed on the bottom surface of the package to identify the terminal A1 corner. Exact shape of each corner is optional.
10. e represents the solder ball grid pitch.
11. N represents the total number of balls on the BGA.
12. Basic dimensions SD and SE are defined with respect to datums A and B. They define the position of the center ball(s) in the outer row or column of a fully populated matrix.
13. For the tolerance of form and position definitions, see the following table.

**Table 219. Tolerance of form and position definitions**

| Symbol | Definition   |
|--------|--|
| aaa    | The profile tolerance controls the location and orientation of the sides of the package.   |
| ccc    | The parallelism tolerance controls the orientation of the top surface of the package with respect to the seating plane, datum C. |
| ddd    | The profile tolerance controls the location of the crowns of the balls with respect to datum C (coplanarity).                    |
| eee    | The tolerance of position that controls the location of the pattern of balls with respect to datum's A and B.                    |
| fff    | The tolerance of position that controls the location of the balls within the matrix with respect to each other.                  |

Figure 130. TFBGA240+25 - Footprint example

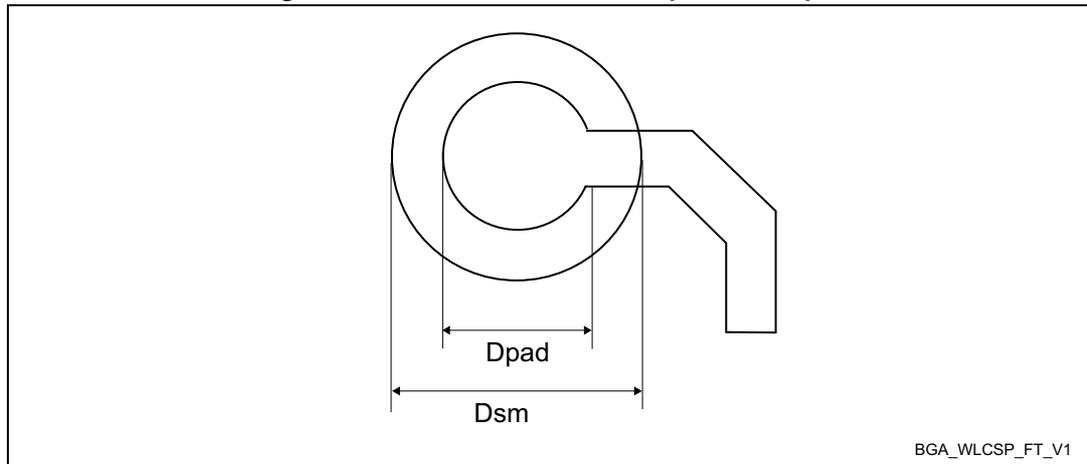


Table 220. TFBGA240+25 - Example of PCB design rules

| Dimension         | Values   |
|-------------------|--|
| Pitch             | 0.8 mm   |
| Dpad              | 0.400 mm   |
| Dsm               | 0.470 mm typical (depends on solder mask registration tolerance) |
| Stencil opening   | 0.400 mm   |
| Stencil thickness | Between 0.100 mm and 0.125 mm                                    |

## 8.10 Thermal characteristics

The maximum chip-junction temperature,  $T_J \text{ max}$ , in degrees Celsius, may be calculated using the following equation:

$$T_J \text{ max} = T_A \text{ max} + (P_D \text{ max} \times \Theta_{JA})$$

Where:

- $T_A \text{ max}$  is the maximum ambient temperature in °C,
- $\Theta_{JA}$  is the package junction-to-ambient thermal resistance, in °C/W,
- $P_D \text{ max}$  is the sum of  $P_{INT} \text{ max}$  and  $P_{I/O} \text{ max}$  ( $P_D \text{ max} = P_{INT} \text{ max} + P_{I/O} \text{ max}$ ),
- $P_{INT} \text{ max}$  is the product of  $I_{DD}$  and  $V_{DD}$ , expressed in Watts. This is the maximum chip internal power.

$P_{I/O} \text{ max}$  represents the maximum power dissipation on output pins where:

$$P_{I/O} \text{ max} = \Sigma (V_{OL} \times I_{OL}) + \Sigma ((V_{DD} - V_{OH}) \times I_{OH}),$$

taking into account the actual  $V_{OL} / I_{OL}$  and  $V_{OH} / I_{OH}$  of the I/Os at low and high level in the application.

Table 221. Thermal characteristics

| Symbol        | Definition                          | Parameter   | Value | Unit |
|---------------|-------------------------------------|---|-------|------|
| $\theta_{JA}$ | Thermal resistance junction-ambient | <b>Thermal resistance junction-ambient</b><br>LQFP100 - 14 x 14 mm /0.5 mm pitch      | 45.0  | °C/W |
|               |                                     | <b>Thermal resistance junction-ambient</b><br>TFBGA100 - 8 x 8 mm /0.8 mm pitch       | 39.3  |      |
|               |                                     | <b>Thermal resistance junction-ambient</b><br>LQFP144 - 20 x 20 mm /0.5 mm pitch      | 43.7  |      |
|               |                                     | <b>Thermal resistance junction-ambient</b><br>UFBGA169 - 7 x 7 mm /0.5 mm pitch       | 37.7  |      |
|               |                                     | <b>Thermal resistance junction-ambient</b><br>LQFP176 - 24 x 24 mm /0.5 mm pitch      | 43.0  |      |
|               |                                     | <b>Thermal resistance junction-ambient</b><br>LQFP208 - 28 x 28 mm /0.5 mm pitch      | 42.4  |      |
|               |                                     | <b>Thermal resistance junction-ambient</b><br>UFBGA176+25 - 10 x 10 mm /0.65 mm pitch | 37.4  |      |
|               |                                     | <b>Thermal resistance junction-ambient</b><br>TFBGA240+25 - 14 x 14 mm / 0.8 mm pitch | 36.6  |      |
| $\theta_{JB}$ | Thermal resistance junction-board   | <b>Thermal resistance junction-ambient</b><br>LQFP100 - 14 x 14 mm /0.5 mm pitch      | 36.3  | °C/W |
|               |                                     | <b>Thermal resistance junction-ambient</b><br>TFBGA100 - 8 x 8 mm /0.8 mm pitch       | 21.1  |      |
|               |                                     | <b>Thermal resistance junction-ambient</b><br>LQFP144 - 20 x 20 mm /0.5 mm pitch      | 38.3  |      |
|               |                                     | <b>Thermal resistance junction-ambient</b><br>UFBGA169 - 7 x 7 mm /0.5 mm pitch       | 17.3  |      |
|               |                                     | <b>Thermal resistance junction-ambient</b><br>LQFP176 - 24 x 24 mm /0.5 mm pitch      | 39.4  |      |
|               |                                     | <b>Thermal resistance junction-ambient</b><br>LQFP208 - 28 x 28 mm /0.5 mm pitch      | 40.3  |      |
|               |                                     | <b>Thermal resistance junction-ambient</b><br>UFBGA176+25 - 10 x 10 mm /0.65 mm pitch | 19.3  |      |
|               |                                     | <b>Thermal resistance junction-ambient</b><br>TFBGA240+25 - 14 x 14 mm / 0.8 mm pitch | 24.3  |      |

Table 221. Thermal characteristics (continued)

| Symbol        | Definition                       | Parameter   | Value | Unit |
|---------------|----------------------------------|---|-------|------|
| $\theta_{JC}$ | Thermal resistance junction-case | <b>Thermal resistance junction-ambient</b><br>LQFP100 - 14 x 14 mm /0.5 mm pitch      | 11.5  | °C/W |
|               |                                  | <b>Thermal resistance junction-ambient</b><br>TFBGA100 - 8 x 8 mm /0.8 mm pitch       | 17.1  |      |
|               |                                  | <b>Thermal resistance junction-ambient</b><br>LQFP144 - 20 x 20 mm /0.5 mm pitch      | 11.3  |      |
|               |                                  | <b>Thermal resistance junction-ambient</b><br>UFBGA169 - 7 x 7 mm /0.5 mm pitch       | 11    |      |
|               |                                  | <b>Thermal resistance junction-ambient</b><br>LQFP176 - 24 x 24 mm /0.5 mm pitch      | 11.2  |      |
|               |                                  | <b>Thermal resistance junction-ambient</b><br>LQFP208 - 28 x 28 mm /0.5 mm pitch      | 11.1  |      |
|               |                                  | <b>Thermal resistance junction-ambient</b><br>UFBGA176+25 - 10 x 10 mm /0.65 mm pitch | 23.9  |      |
|               |                                  | <b>Thermal resistance junction-ambient</b><br>TFBGA240+25 - 14 x 14 mm / 0.8 mm pitch | 7.4   |      |

### 8.10.1 Reference documents

- JESD51-2 Integrated Circuits Thermal Test Method Environment Conditions - Natural Convection (Still Air). Available from [www.jedec.org](http://www.jedec.org).
- For information on thermal management, refer to application note “Guidelines for thermal management on STM32 applications” (AN5036) available from [www.st.com](http://www.st.com).

## 9 Ordering information

Example: STM32 H 753 X I T 6 A TR<sup>(1)</sup>

**Device family**

STM32 = Arm-based 32-bit microcontroller

**Product type**

H = High performance

**Device subfamily**

753 = STM32H7x3 with cryptographic accelerator

**Pin count**

V = 100 pins

Z = 144 pins

A = 169 balls

I = 176 pins/176+25 balls

B = 208 pins

X = 240+25 balls

**Flash memory size**

I = 2 Mbytes

**Package**

T = LQFP ECOPACK2

K = UFBGA pitch 0.65 mm ECOPACK2

I = UFBGA pitch 0.5 mm ECOPACK2

H = TFBGA ECOPACK2

**Temperature range**

6 = -40 to 85 °C

**Option**

A = Advanced mission profile (VOS1, 480 MHz)

**Packing**

TR = tape and reel

No character = tray or tube

1. The tape and reel packing is not available on all packages.

For a list of available options (such as speed and package) or for further information on any aspect of this device, please contact your nearest ST sales office.

## 10 Important security notice

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- ST products may have been certified by one or more security certification bodies, such as Platform Security Architecture ([www.psacertified.org](http://www.psacertified.org)) and/or Security Evaluation standard for IoT Platforms ([www.trustcb.com](http://www.trustcb.com)). For details concerning whether the ST product(s) referenced herein have received security certification along with the level and current status of such certification, either visit the relevant certification standards website or go to the relevant product page on [www.st.com](http://www.st.com) for the most up to date information. As the status and/or level of security certification for an ST product can change from time to time, customers should re-check security certification status/level as needed. If an ST product is not shown to be certified under a particular security standard, customers should not assume it is certified.
- Certification bodies have the right to evaluate, grant and revoke security certification in relation to ST products. These certification bodies are therefore independently responsible for granting or revoking security certification for an ST product, and ST does not take any responsibility for mistakes, evaluations, assessments, testing, or other activity carried out by the certification body with respect to any ST product.
- Industry-based cryptographic algorithms (such as AES, DES, or MD5) and other open standard technologies which may be used in conjunction with an ST product are based on standards which were not developed by ST. ST does not take responsibility for any flaws in such cryptographic algorithms or open technologies or for any methods which have been or may be developed to bypass, decrypt or crack such algorithms or technologies.
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- All security features of ST products (inclusive of any hardware, software, documentation, and the like), including but not limited to any enhanced security features added by ST, are provided on an "AS IS" BASIS. AS SUCH, TO THE EXTENT PERMITTED BY APPLICABLE LAW, ST DISCLAIMS ALL WARRANTIES, EXPRESS OR IMPLIED, INCLUDING BUT NOT LIMITED TO THE IMPLIED WARRANTIES OF MERCHANTABILITY OR FITNESS FOR A PARTICULAR PURPOSE, unless the applicable written and signed contract terms specifically provide otherwise.

# 11 Revision history

**Table 222. Document revision history**

| Date        | Revision | Changes  |
|-------------|----------|--|
| 22-Jun-2017 | 1        | Initial release.   |
| 27-Sep-2017 | 2        | <p>Updated list of features.</p> <p>Changed datasheet status to “production data”.</p> <p>Added UFBGA169 and TFBGA100 packages as well as notes related to TFBGA100 and UFBGA169 status on cover page and in <i>Table 6: STM32H753xI features and peripheral counts</i>.</p> <p>Differentiated number of GPIOs for each package in <i>Table 6: STM32H753xI features and peripheral counts</i>.</p> <p>Updated <i>Error code correction (ECC)</i> in <i>Section 3.4.3: Embedded SRAM</i>.</p> <p>Change PWR_CR3 into PWR_D3CR in <i>Section 3.7.1: Power supply scheme</i>.</p> <p>Updated <i>Section 3.14: Nested vectored interrupt controller (NVIC)</i>.</p> <p>Added <i>Table 12: DFSDM implementation</i> in <i>Section 3.25: Digital filter for sigma-delta modulators (DFSDM)</i>.</p> <p>Changed PC2/3 to PC2/3_C and VDD33USB to VDD in <i>Figure 9: LQFP100 pinout</i>.</p> <p>Changed PC2/3 to PC2/3_C in <i>Figure 11: LQFP144 pinout</i>. Changed PC2/3 to PC2/3_C in <i>Figure 13: LQFP176 pinout</i>. Changed PC2/3 to PC2/3_C in <i>Figure 15: LQFP208 pinout</i>.</p> <p><i>Table 17: Pin/ball definition:</i></p> <ul style="list-style-type: none"> <li>– Modified PA7, PC4, PC5, PB1, PG1, PE7, PE8 and PE9 I/O structure</li> <li>– TFBGA240 +25: removed duplicate occurrence of F1, F2 and P17 pin; added notes related to F1, F2, G2 pin connection; added note on E1, L16, L17, M16, M17, K16, K17, N17.</li> <li>– UFBGA176+25: changed G10 pin name to VSS.</li> <li>– Added note to VREF+ pin.</li> </ul> <p>Added current consumption corresponding to 125 °C ambient temperature in <i>Section 6.3.6: Supply current characteristics</i>.</p> <p>Replaced FMC_CLK by FMC_SDCLK in <i>Section : SDRAM waveforms and timings</i>.</p> <p>Changed description of the last five <math>f_s</math> values and updated <math>t_{LATRINJ}</math> in <i>Table 96: ADC characteristics</i>.</p> <p>For TFBGA100, TFBGA240+25 and UFBGA169, updated thermal resistance power-junction in <i>Table 276: Thermal characteristics</i> as well as power dissipation in <i>Table 32: General operating conditions</i>.</p> |
| 23-Oct-2017 | 3        | <p>Total current consumption changed to 4 <math>\mu</math>A minimum in <i>Features</i>.</p> <p>Updated <i>Figure 12: UFBGA169 ballout</i>.</p> <p>Updated dpad and dsm in <i>Table 136: TFBGA240+25 - Recommended PCB design rules</i>.</p>  |

**Table 222. Document revision history**

| Date        | Revision | Changes   |
|-------------|----------|---|
| 18-May-2018 | 4        | <p>Updated LSI clock frequency and ADC on cover page. Removed note related to UFBGA169 package.</p> <p>Updated ADC features on cover page and in <i>Table 6: STM32H753xl features and peripheral counts</i>.</p> <p>Added Arm trademark notice in <i>Section 1: Introduction</i>.</p> <p>Updated USB OTG interfaces to add crystal-less capability.</p> <p>Updated <i>Figure 3: STM32H753xl block diagram</i>.</p> <p>Updated GPIO default mode in <i>Section 3.10: General-purpose input/outputs (GPIOs)</i>.</p> <p>Added ADC sampling rate values in <i>Section 3.19: Analog-to-digital converters (ADCs)</i>.</p> <p>Updated <i>Section 3.20: Temperature sensor</i>.</p> <p>Updated LCD-TFT FIFO Size in <i>Section 3.27: LCD-TFT controller</i>.</p> <p><i>Section 3.37: Serial peripheral interfaces (SPI)/integrated interchip sound interfaces (I2S)</i>: changed maximum SPI frequency to 150 Mbits/s.</p> <p>Modified number of bidirectional endpoints in <i>Section 3.44: Universal serial bus on-the-go high-speed (OTG_HS)</i>.</p> <p><i>Table 17: Pin/ball definition</i>:</p> <ul style="list-style-type: none"> <li>– Updated PC14 and PC15 function after reset.</li> <li>– Changed CAN1_TX/RX to FDCAN1_TX/RX and CAN1_TXFD/RXFD to FDCAN1_TXFD_MODE/RXFD_MODE</li> <li>– Changed CAN2_TX/RX to FDCAN2_TX/RX and CAN2_TXFD/RXFD to FDCAN2_TXFD_MODE/RXFD_MODE</li> </ul> <p>Replaced VCAP1/2/3 and VDDLDO1/2/3 by VCAP and VDDLDO, respectively.</p> <p>Updated PA0, PA13, PA14, PC14 and PC15 pin/ball signals in pinout/ballout schematics.</p> <p>Replaced <math>f_{ACLK}</math> by <math>f_{rcc\_c\_ck}</math> in <i>Section : Typical and maximum current consumption</i>.</p> <p>Replaced system clock by CPU clock and <math>f_{ACLK}</math> by <math>f_{rcc\_c\_ck}</math> in <i>Section : On-chip peripheral current consumption</i>.</p> <p>Updated Note 2. in <i>Table 35: Reset and power control block characteristics</i>.</p> <p>Updated <i>Table 36: Embedded reference voltage</i>, <i>Table 38: Typical and maximum current consumption in Run mode, code with data processing running from ITCM, regulator ON</i>, <i>Table 39: Typical and maximum current consumption in Run mode, code with data processing running from flash memory, cache ON, regulator ON</i> and <i>Table 44: Typical and maximum current consumption in Stop mode, regulator ON</i>.</p> <p>Updated typical and maximum current consumption in <i>Table 45: Typical and maximum current consumption in Standby mode</i> and <i>Table 46: Typical and maximum current consumption in VBAT mode</i>.</p> <p>Added note to <math>f_{LSI}</math> in <i>Table 57: LSI oscillator characteristics</i>.</p> |

Table 222. Document revision history

| Date        | Revision         | Changes  |
|-------------|------------------|--|
| 18-May-2018 | 4<br>(continued) | <p>Updated <i>Figure 28: VIL/VIH for all I/Os except BOOT0</i>.</p> <p>Added note in <i>Table 93: QUADSPI characteristics in SDR mode</i>, <i>Table 94: QUADSPI characteristics in DDR mode</i> and <i>Table 95: Dynamics characteristics: Delay Block characteristics</i>.</p> <p><i>Section 6.3.20: 16-bit ADC characteristics</i>: updated THD conditions in <i>Table 97: ADC accuracy</i>; removed formula to compute <math>R_{AIN}</math>.</p> <p>Changed decoupling capacitor value to 100 nF in <i>Section : General PCB design guidelines</i>.</p> <p>Added note in <i>Table 98: DAC characteristics</i>, <i>Table 106: Voltage booster for analog switch characteristics</i>, <i>Table 109: DFSDM measured timing - 1.62-3.6 V</i>, <i>Table 126: Dynamics JTAG characteristics</i> and <i>Table 127: Dynamics SWD characteristics</i>.</p> <p>Updated <i>Figure 145: LQFP144 marking example (package top view)</i>, <i>Figure 151: LQFP176 marking example (package top view)</i> and <i>Figure 154: LQFP208 marking example (package top view)</i>.</p> <p>Updated TFBGA240+25 package information to final mechanical data.</p> |
| 13-Jul-2018 | 5                | <p>Added description of power-up and power-down phases in <i>Section 3.7.1: Power supply scheme</i>.</p> <p>Removed ETH_TX_ER from <i>Table 17: Pin/ball definition</i> and <i>Table 18: Port A alternate functions</i> to <i>Table 28: Port K alternate functions</i>.</p> <p>Added note related to decoupling capacitor tolerance below <i>Figure 19: Power supply scheme</i>.</p> <p>Added note 2. related to CEXT in <i>Table 33: VCAP operating conditions</i>.</p> <p>Updated <i>Table 54: HSI48 oscillator characteristics</i>, <i>Table 55: HSI oscillator characteristics</i> and <i>Table 56: CSI oscillator characteristics</i>.</p> <p>Renamed <i>Table 58</i> into "PLL characteristics (wide VCO frequency range)" and updated note 2.. Added <i>Table 59: PLL characteristics (medium VCO frequency range)</i>.</p> <p>Updated <math>T_{coeff}</math> in <i>Table 100: VREFBUF characteristics</i>.</p> <p>Updated <math>t_{S\_vbat}</math> in <i>Table 103: V<sub>BAT</sub> monitoring characteristics</i>.</p> <p>Updated <i>Table 108: OPAMP characteristics</i>.</p>  |

Table 222. Document revision history

| Date        | Revision | Changes  |
|-------------|----------|--|
| 05-Apr-2019 | 6        | <p>Changed maximum Arm Core-M7 frequency to 480 MHz.</p> <p><i>Features:</i></p> <ul style="list-style-type: none"> <li>– Changed operational amplifier bandwidth to 7.3 MHz</li> <li>– Updated high-resolution timer to 2.1 ns</li> <li>– Updated low-power consumption feature</li> </ul> <p>Changed FMC NOR/NAND maximum clock frequency to 100 MHz in <i>Features</i> and <i>Synchronous waveforms and timings</i>.</p> <p>Updated voltage scaling in <i>Section 3.7.1: Power supply scheme</i>. Added VOS0 in <i>Section 3.7.3: Voltage regulator (SMPS step-down converter and LDO)</i>.</p> <p>Updated HSE clock in <i>Section 3.9.1: Clock management</i>.</p> <p>Added note related to VDDLDO in <i>Table 17: Pin/ball definition</i>.</p> <p>Updated <i>Section 6: Electrical characteristics (rev Y)</i>:</p> <ul style="list-style-type: none"> <li>– Added note 2. related to CEXT in <i>Table 33: VCAP operating conditions</i></li> <li>– Updated <math>f_{HSI48}</math> in <i>Table 54: HSI48 oscillator characteristics</i>.</li> <li>– Updated <math>t_{stab}</math> in <i>Table 55: HSI oscillator characteristics</i>.</li> <li>– Added <i>Table 70: Output voltage characteristics for PC13, PC14, PC15 and PI8</i>.</li> <li>– Updated <i>Table 68: I/O static characteristics</i> and <i>Figure 28: VIL/VIH for all I/Os except BOOT0</i>.</li> <li>– Added note related to PC13, PC14, PC15 and PI8 limited frequency in <i>Table 71: Output timing characteristics (HSLV OFF)</i>.</li> <li>– Updated note 2 below <i>Figure 30: Recommended NRST pin protection</i>.</li> <li>– <i>Table 96: ADC characteristics</i>: updated <math>f_S</math> and added note related to <math>f_S</math> formula; updated <math>t_{CAL}</math>.</li> <li>– Renamed <i>Section 6.3.24</i> into <i>Temperature and VBAT monitoring</i> and content updated.</li> <li>– Updated <math>f_{DFSDMCLK}</math> in <i>Table 109: DFSDM measured timing - 1.62-3.6 V</i>.</li> </ul> <p>Added <i>Section 7: Electrical characteristics (rev V)</i>.</p> <p><i>Section 8: Package information:</i></p> <ul style="list-style-type: none"> <li>– Updated paragraph introducing all package marking schematics to add the new sentence “The printed markings may differ depending on the supply chain.”</li> <li>– Added <i>Section : Device marking for TFBGA100</i> and <i>Section : Device marking for UFBGA169</i>.</li> <li>– Updated <i>Table 276: Thermal characteristics</i>.</li> </ul> <p>Added note related to ECOPACK<sup>®</sup>2 compliance in <i>Table 9: Ordering information</i>.</p> |
| 24-Apr-2019 | 7        | <p>Updated <i>Figure 3: STM32H753xl block diagram</i></p> <p>Updated <i>Table 17: Pin/ball definition</i>.</p> <p>Updated <i>Table 18 to Table 28</i> (alternate functions).</p> <p>Updated <i>Table 47: Peripheral current consumption in Run mode</i>.</p> <p>Updated <i>Table 181: Peripheral current consumption in Run mode</i>.</p> <p>Updated <i>Table 232: ADC characteristics</i>.</p> <p>Updated <i>Table 233: Minimum sampling time vs RAIN</i>.</p> <p>Updated <i>Table 234: ADC accuracy</i>.</p>   |

Table 222. Document revision history

| Date       | Revision | Changes  |
|------------|----------|--|
| 4-Mar-2022 | 8        | <p>Added reference to errata sheet ES0392 in <i>Section 1: Introduction</i>.</p> <p><b>Section 2: Description</b><br/> <i>Table 6: STM32H753xI features and peripheral counts</i>: removed note indicating that packages are under development, split number of ADC channels into Direct, Fast and Slow channels; and added number of wakeup and tamper pins.<br/> Changed APB1 and APB2 maximum frequency to 120 MHz in <i>Figure 3: STM32H753xI block diagram</i>.</p> <p><b>Section 3: Functional overview</b><br/> Added connection between SDMMC2 and D2-to-D3 AHB bus in <i>Figure 8: STM32H753xI bus matrix</i>.<br/> Updated <i>Section 3.30: True random number generator (RNG)</i>.<br/> Added Full-duplex mode in <i>Section 3.37: Serial peripheral interfaces (SPI)/integrated interchip sound interfaces (I2S)</i>.<br/> Updated number of microphones that can be supported by the SAI in <i>Section 3.38: Serial audio interfaces (SAI)</i>.</p> <p><b>Section 5: Pin descriptions</b><br/> Updated J1, F1, F2 and G2 signals and added notes 2, 3 and 4 in <i>Figure 16: TFBGA240+25 ballout</i>.<br/> Removed FDCAN1_RXFD_MODE, FDCAN1_TXFD_MODE, FDCAN2_RXFD_MODE and FDCAN2_TXFD_MODE functions from <i>Table 17: Pin/ball definition</i> and all alternate function tables.<br/> Additional modifications made on <i>Table 17: Pin/ball definition</i>: added note to VDD50USB, change PB1 I/O structure to TT_a, replaced PI8 WKUP3 additional function by WKUP2, replaced PC13 WKUP2 additional function by WKUP3, changed F1 and G2 to VSS.</p> <p><b>Section 6: Electrical characteristics (rev Y):</b></p> <ul style="list-style-type: none"> <li>– Updated <i>Section 6.2: Absolute maximum ratings</i> introduction to add device mission profile.</li> <li>– Updated <i>Figure 19: Power supply scheme</i>.</li> <li>– Power dissipation (<math>P_D</math>) removed from <i>Table 32: General operating conditions</i> since this parameter is redundant with <math>\Theta_{JA}</math> thermal resistance.</li> <li>– Updated <i>Table 50: High-speed external user clock characteristics</i>.</li> <li>– <i>Table 61: Flash memory programming</i>: removed reference to single bank configuration in title and updated <math>t_{ERASE128KB}</math> typical and maximum values.</li> <li>– Added reference to AN4899 in <i>Section 6.3.15: I/O port characteristics</i>. Updated <math>F_{max}</math> for speed 10 and 11 in <i>Table 71: Output timing characteristics (HSLV OFF)</i>. Updated notes in <i>Table 72: Output timing characteristics (HSLV ON)</i>.</li> <li>– Updated <math>t_{su(DV-CLKH)}/t_{h(DV-CLKH)}</math> and <math>t_{su(NWAIT-CLKH)}/t_{h(NWAIT-CLKH)}</math> in <i>Table 83: Synchronous multiplexed NOR/PSRAM read timings</i>. Changed <math>t_{su(NWAIT-CLKH)}</math> to <math>t_{su(NWAIT-CLKH)}</math> and updated <math>t_{su(DV-CLKH)}/t_{h(DV-CLKH)}</math> and <math>t_{su(NWAIT-CLKH)}/t_{h(NWAIT-CLKH)}</math> in <i>Table 85: Synchronous non-multiplexed NOR/PSRAM read timings</i>.</li> <li>– Replaced FMC_CLK by FMC_SDCLK in <i>Section : SDRAM waveforms and timings</i></li> <li>– Updated <math>t_{su(SDCLKH\_Data)}</math> and <math>t_{h(SDCLKH\_Data)}</math> in <i>Table 89: SDRAM read timings</i> and <i>Table 90: LPSDR SDRAM read timings</i>.</li> </ul> |

**Table 222. Document revision history**

| Date       | Revision         | Changes  |
|------------|------------------|--|
| 4-Mar-2022 | 8<br>(continued) | <p><b>Section 6: Electrical characteristics (rev Y) (continued)</b></p> <ul style="list-style-type: none"> <li>– Updated <math>t_{S(IN)}</math> and <math>t_{H(IN)}</math> in Table 93: QUADSPI characteristics in SDR mode</li> <li><math>t_{SR(IN)}/t_{SF(IN)}</math> and <math>t_{HR(IN)}/t_{HF(IN)}</math> in Table 94: QUADSPI characteristics in DDR mode.</li> <li>Updated Figure 46: Quad-SPI timing diagram - DDR mode.</li> <li>– Updated maximum sampling time (<math>t_S</math>) value in Table 96: ADC characteristics.</li> <li>Updated Figure 47: ADC accuracy characteristics, Figure 48: Typical connection diagram when using the ADC with FT/TT pins featuring analog switch function and Figure 49: Power supply and reference decoupling (<math>V_{REF+}</math> not connected to <math>V_{DDA}</math>).</li> <li>– Updated <math>T_L</math> maximum value in Table 101: Temperature sensor characteristics.</li> <li>– Updated <math>f_{DFSDMCLK}</math> and <math>DuCYCKOUT</math> in Table 109: DFSDM measured timing - 1.62-3.6 V.</li> <li>– Updated <math>f_{TIMxCLK}</math> to match an APB1/2 maximum frequency of 120 MHz in Table 112: TIMx characteristics.</li> <li>– Updated <math>t_{SU(MI)}</math> and <math>t_{H(MI)}</math> minimum values in Table 115: SPI dynamic characteristics.</li> <li>– Updated <math>t_{ISU}</math>, <math>t_{IH}</math>, <math>t_{ISUD}</math> and <math>t_{IHD}</math> in Table 119: Dynamic characteristics: SD / MMC characteristics, <math>V_{DD} = 2.7</math> to <math>3.6</math> V, and <math>t_{ISU}</math>, <math>t_{IH}</math> in Table 120: Dynamic characteristics: eMMC characteristics, <math>V_{DD} = 1.71</math> to <math>1.9</math> V. Updated Figure 66: DDR mode.</li> </ul> <p><b>Section 7: Electrical characteristics (rev V):</b></p> <ul style="list-style-type: none"> <li>– Updated Figure 75: Power supply scheme.</li> <li>– Updated Section 7.2: Absolute maximum ratings introduction to device mission profile.</li> <li>– Power dissipation (<math>P_D</math>) removed from Table 132: General operating conditions since this parameter is redundant with <math>\Theta_{JA}</math> thermal resistance.</li> <li>– Replaced Min <math>V_{DD}</math> by Min <math>V_{DDLDO}</math> in Table 133: Supply voltage and maximum frequency configuration.</li> <li>– Updated Table 183: High-speed external user clock characteristics.</li> <li>– Table 197: Flash memory programming: removed reference to single bank configuration in title, and updated <math>t_{ERASE128KB}</math>.</li> <li>– Updated condition related to <math>f_{rcc\_c\_ck}</math> in Section : On-chip peripheral current consumption.</li> <li>– Added reference to AN4899 in Section 7.3.19: I/O port characteristics. Updated <math>F_{max}</math> for speed 10 and 11 in Table 207: Output timing characteristics (HSLV OFF). Changed capacitance value for speed 10 and <math>t_r/t_f</math>, and speed for 11 and <math>t_r/t_f/F_{max}</math> Table 208: Output timing characteristics (HSLV ON).</li> <li>– Updated <math>t_{SU(DV-CLKH)}/t_{H(DV-CLKH)}</math> and <math>t_{SU(NWAIT-CLKH)}/t_{H(NWAIT-CLKH)}</math> in Table 219: Synchronous multiplexed NOR/PSRAM read timings. Changed <math>t_{(NWAIT-CLKH)}</math> to <math>t_{SU(NWAIT-CLKH)}</math> and updated <math>t_{SU(DV-CLKH)}/t_{H(DV-CLKH)}</math> and <math>t_{SU(NWAIT-CLKH)}/t_{H(NWAIT-CLKH)}</math> in Table 221: Synchronous non-multiplexed NOR/PSRAM read timings.</li> <li>Updated <math>t_{SU(SDCLKH\_Data)}</math> and <math>t_{H(SDCLKH\_Data)}</math> in Table 225: SDRAM read timings and Table 226: LPSDR SDRAM read timings. Replaced FMC_CLK by FMC_SDCLK in Section : SDRAM waveforms and timings.</li> <li>– Updated <math>t_{S(IN)}</math> and <math>t_{H(IN)}</math> in Table 229: QUADSPI characteristics in SDR mode and <math>t_{SR(IN)}/t_{SF(IN)}</math> and <math>t_{HR(IN)}/t_{HF(IN)}</math> in Table 230: QUADSPI characteristics in DDR mode. Updated Figure 108: Quad-SPI timing diagram - DDR mode.</li> </ul> |

Table 222. Document revision history

| Date       | Revision         | Changes  |
|------------|------------------|--|
| 4-Mar-2022 | 8<br>(continued) | <p><b>Section 7: Electrical characteristics (rev V) (continued):</b></p> <ul style="list-style-type: none"> <li>– Updated notes 4. and 5. in <i>Table 233: Minimum sampling time vs RAIN</i>. Added reference to AN5354 application note in note of <i>Table 232: ADC characteristics</i>. Updated <i>Figure 109: ADC accuracy characteristics</i> and <i>Figure 110: Typical connection diagram when using the ADC with FT/TT pins featuring analog switch function</i></li> <li>– Changed <math>V_{DAC\_OUT}</math> maximum value to <math>V_{REF+} - 0.2</math> in <i>Table 235: DAC characteristics</i></li> <li>– Updated <math>T_L</math> maximum value in <i>Table 238: Temperature sensor characteristics</i>.</li> <li>– Modified <i>Figure 111: Power supply and reference decoupling (<math>V_{REF+}</math> not connected to <math>V_{DDA}</math>)</i>.</li> <li>– Updated <math>DuCy_{CKOUT}</math> in <i>Table 246: DFSDM measured timing - 1.62-3.6 V</i>.</li> <li>– Updated <i>Figure 118: USART timing diagram in Master mode</i> and <i>Figure 119: USART timing diagram in Slave mode</i></li> <li>– Updated <math>t_{su(MI)}</math> and <math>t_{h(MI)}</math> in <i>Table 253: SPI dynamic characteristics</i>.</li> <li>– Updated <math>t_{ISU}</math>, <math>t_{IH}</math>, <math>t_{ISUD}</math>, <math>t_{IHD}</math> and <math>t_{OH}</math> in <i>Table 257: Dynamics characteristics: SD / MMC characteristics, <math>V_{DD} = 2.7</math> to <math>3.6</math> V</i>, and <math>t_{ISU}</math>, <math>t_{IH}</math> in <i>Table 258: Dynamics characteristics: eMMC characteristics <math>V_{DD} = 1.71V</math> to <math>1.9V</math></i>. Modified <i>Figure 130: DDR mode</i>.</li> <li>– Added <i>Section : USB OTG_FS characteristics</i>.</li> </ul> <p><b>Section 8: Package information</b></p> <p>Added <math>\Theta_{JB}</math> and <math>\Theta_{JC}</math> for UFBGA169.</p> <p>Updated <i>Section 8.1: LQFP100 package information</i>, <i>Section 8.3: LQFP144 package information</i>, <i>Figure 141: TFBGA100 - Recommended footprint</i>, <i>Section 8.6: LQFP176 package information</i>, <i>Section : Device marking for UFBGA176+25</i>, <i>Figure 154: LQFP208 marking example (package top view)</i> and <i>Table 136: TFBGA240+25 - Recommended PCB design rules</i>.</p> <p>Added <i>Figure 151: UFBGA169 - Recommended footprint</i> and <i>Table 304: UFBGA169 - Recommended PCB design rules (0.5 mm pitch BGA)</i>.</p> <p><b>Section 9: Ordering information</b></p> <p>Added note related to the availability of tape and reel packing in <i>Section 9: Ordering information</i>.</p> |

**Table 222. Document revision history**

| Date        | Revision | Changes   |
|-------------|----------|---|
| 28-Mar-2023 | 9        | <p>Updated <a href="#">Figure 1: STM32H750xB block diagram</a> changed APB1 and APB2 maximum frequency to 120 MHz, and WKUP[5:0] to WKUP[6:1].</p> <p>Changed WKUP[5:0] to WKUP[6:1] in <a href="#">Table 8: Pin/ball definition</a></p> <p>Updated <a href="#">Figure 3: STM32H753xl bus matrix</a></p> <p>Updated <a href="#">Table 11: Current characteristics</a> and <a href="#">Table 109: Current characteristics</a></p> <p>Changed <math>I_{leak}</math> to <math>I_{lk}</math> in <a href="#">Table 49: I/O static characteristics</a> and <a href="#">Table 146: I/O static characteristics</a></p> <p>Updated <a href="#">Section 3.24: Digital camera interface (DCMI)</a> (modified supported format)</p> <p>Modified <a href="#">Table 45: EMI characteristics for fHSE = 8 MHz and fCPU = 400 MHz</a> and <a href="#">Table 142: EMI characteristics for fHSE = 8 MHz and fCPU = 400 MHz</a></p> <p>Updated section <a href="#">I/O dynamic current consumption</a> and <a href="#">I/O static current consumption</a> in <a href="#">Section 6: Electrical characteristics (rev Y)</a> and <a href="#">Section 7: Electrical characteristics (rev V)</a>.</p> <p>Updated note below <a href="#">Figure 38: Typical connection diagram when using the ADC with FT/TT pins featuring analog switch function</a> and <a href="#">Figure 88: Typical connection diagram when using the ADC with FT/TT pins featuring analog switch function</a> and</p> <p>Updated <a href="#">Table 11: Current characteristics</a> and <a href="#">Table 109: Current characteristics</a></p> <p>Updated <math>V_{CORE}</math> max value in <a href="#">Table 111: General operating conditions</a></p> <p>Updated <a href="#">Table 201: Dynamics characteristics: USB ULPI</a></p> <p>Updated <a href="#">Section 8: Package information</a>:</p> <p>Modified title for footprint figure and PCB design rules table (examples instead of recommendations)</p> <p>Added <a href="#">Section 8.1: Device marking</a> (device marking information removed from package sections and moved to this section)</p> <p>Updated information on pin count in <a href="#">Section 9: Ordering information</a></p> <p>Added <a href="#">Section 10: Important security notice</a>.</p> |
| 13-Jan-2026 | 10       | <p>In the context of I2C, replaced master and slave by controller and target, respectively.</p> <p>Updated features on cover page.</p> <p>Updated <a href="#">Table 2: STM32H753xl features and peripheral counts</a>.</p> <p>Updated <a href="#">Figure 1: STM32H753xl block diagram</a>.</p> <p>Updated <a href="#">Section 3.4: Boot modes</a>.</p> <p>Updated <a href="#">Figure 11: TFBGA240+25 ballout</a></p> <p>Updated <a href="#">Table 7: Legend/abbreviations used in the pinout table</a>.</p> <p>Updated <a href="#">Table 8: Pin/ball definition</a>.</p> <p>Updated <a href="#">Table 9: Alternate functions</a>.</p> <p>Updated <a href="#">Table 13: General operating conditions</a>.</p> <p>Suppressed <a href="#">Figure: NAND controller waveforms for common memory write access</a>.</p> <p>Updated <a href="#">Table 76: ADC characteristics</a>.</p> <p>Updated <a href="#">Figure 65: Power supply scheme</a>.</p> <p>Updated <a href="#">Table 111: General operating conditions</a>.</p> <p>Updated <a href="#">Table 113: VCAP operating conditions</a>.</p> <p>Updated <a href="#">Table 126: Peripheral current consumption in Run mode</a>.</p> <p>Updated <a href="#">Section : Low-speed external user clock generated from an external source</a>.</p> <p>Updated <a href="#">Figure 70: Typical application with an 8 MHz crystal</a>.</p> <p>Updated <a href="#">Table 146: I/O static characteristics</a>.</p> <p>Updated <a href="#">Figure 87: ADC accuracy characteristics</a>.</p>   |

Table 222. Document revision history

| Date        | Revision          | Changes  |
|-------------|-------------------|--|
| 13-Jan-2026 | 10<br>(continued) | Updated <a href="#">Table 173: ADC characteristics</a> .<br>Updated <a href="#">Table 179: Temperature sensor characteristics</a> .<br>Updated <a href="#">Table 180: Temperature sensor calibration values</a> .<br>Updated <a href="#">Section : I2C interface characteristics</a> .<br>Updated <a href="#">Table 207: LQFP100 - Mechanical data</a> .<br>Updated <a href="#">Table 210: LQFP144 - Mechanical data</a> .<br>Updated <a href="#">Table 213: LQFP176 - Mechanical data</a> .<br>Updated <a href="#">Table 214: LQFP208 - Mechanical data</a> .<br>Updated <a href="#">Table 220: TFBGA240+25 - Example of PCB design rules</a> . |

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